

SEMICONDUCTORS SELECTION GUIDE

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April 1999

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ITRON is short for Industrial TRON.

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Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Note that this product can not be used for the IC card (SMART CARD).

Caution: The I²C bus interface circuit is incorporated in the μ PD17709 subseries, 17719 subseries, 178018A subseries, 178048 subseries, 178078 subseries, 178098 subseries, 780018AY subseries, 780024AY subseries, 780034AY subseries, 780058Y subseries, 780078Y subseries, 78018FY subseries, 780308Y subseries, 78054Y subseries, 78058FY subseries, 78064Y subseries, 780701Y subseries, 78078Y subseries, 780833Y subseries, 784038Y subseries, 784216Y subseries, 784218Y subseries, 784225Y subseries, 784928Y subseries, 789197AY subseries, 789217AY subseries, μ PD17001, 17P001, 17003A, 17005, 17P005, 17010, 17P010, 703008Y, 70F3008Y, 703015Y, 703017Y, 70F3017Y, 703033Y, 70F3033Y, 70F3035Y, 78070AY, μ PC1851B, 1853, 1854A, 1857A, 1884, μ PD61882, 6221, 6222 and 72254Y.

Those who use the I²C bus interface can be granted the license below by giving prior notification before ordering the custom code.

Purchase of NEC I²C components conveys a license under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification as defined by Philips.

[MEMO]

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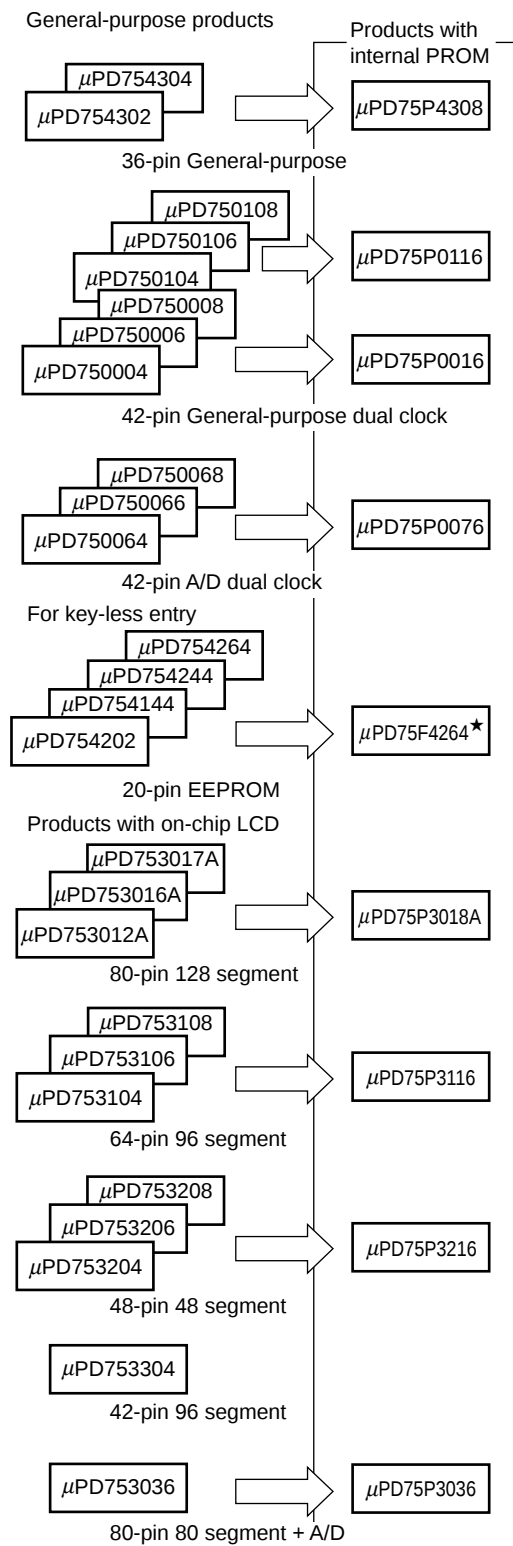
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4-Bit Single-Chip Microcontroller

75XL Series

75XL Series Products Product Evolution



★ : Under development

4-Bit Single-Chip Microcontroller

75XL Series

■ General-Purpose 42-pin (1/2)

Part number		μ PD750004		μ PD750006	μ PD750008	μ PD75P0016
ROM (bytes)		4096 (Mask ROM)		6144 (Mask ROM)	8192 (Mask ROM)	16384 (One-time PROM)
RAM ($\times$ 4 bits)		512				
General-purpose register		(4-bit $\times$ 8) $\times$ 4 banks or (8-bit $\times$ 4) $\times$ 4 banks				
Instruction cycle		• 0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) • 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock) • 122 μs (with 32.768 kHz subsystem clock)				
Minimum instruction execution time		• 0.67 μs (V_{DD} = 2.7 to 5.5 V) • 0.95 μs (V_{DD} = 2.2 to 5.5 V)				
I/O port	CMOS input	34	8	On-chip pull-up resistors are connectable by software: 7		
	CMOS I/O		18	Can drive LED On-chip pull-up resistors are connectable by software		
	N-ch open-drain I/O		8	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option		Can drive LED 13 V withstand voltage No on-chip pull-up resistors
Timer		4 channels		• 8-bit timer/event counter $\times$ 1 channel • Basic interval timer/watchdog timer $\times$ 1 channel • Watch timer $\times$ 1 channel • 8-bit timer $\times$ 1 channel		
Serial interface		Any of three modes can be used: • 3-wire serial I/O mode: MSB/LSB switchable • 2-wire serial I/O mode • SBI mode				
Vectored interrupt		External: 3, Internal: 4				
Test input		External: 1, Internal: 1				
Clock output (PCL)		• Φ, 524 kHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) • Φ, 750 kHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)				
Buzzer output (BUZ)		• 2 kHz, 4 kHz, 32 kHz (with 4.19 MHz main system clock, or 32.768 kHz subsystem clock) • 2.93 kHz, 5.86 kHz, 46.9 kHz (with 6.0 MHz main system clock)				
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison				
Power supply voltage		V_{DD} = 2.2 to 5.5 V (V_{DD} = 1.8 to 5.5 V with external clock)				
Package		• 42-pin plastic shrink DIP (600 mil) • 44-pin plastic QFP (10 $\times$ 10 mm)				
Development tools		Assembler, IE controller, device file, in-circuit emulator				
Applications		VCRs, CD players, cordless telephones, radios, cameras, home electric appliances, etc.				

4-Bit Single-Chip Microcontroller

75XL Series

■ General-Purpose 42-pin (2/2)

Part number		μ PD750104		μ PD750106	μ PD750108	μ PD75P0116
ROM (bytes)		4096 (Mask ROM)		6144 (Mask ROM)	8192 (Mask ROM)	16384 (One-time PROM)
RAM ($\times$ 4 bits)		512				
General-purpose register		(4-bit $\times$ 8) $\times$ 4 banks or (8-bit $\times$ 4) $\times$ 4 banks				
Instruction cycle		• 2 μs, 4 μs, 8 μs, 32 μs (with RC 2.0 MHz main system clock) • 4 μs, 8 μs, 16 μs, 64 μs (with RC 1.0 MHz main system clock) • 122 μs (with 32.768 kHz subsystem clock)				
Minimum instruction execution time		2 μ s (V_{DD} = 1.8 to 5.5 V)				
I/O port	CMOS input	34	8	On-chip pull-up resistors are connectable by software: 7		
	CMOS I/O		18	Can drive LED On-chip pull-up resistors are connectable by software		
	N-ch open-drain I/O		8	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option		Can drive LED 13 V withstand voltage No on-chip pull-up resistors
Timer		4 channels		• 8-bit timer/event counter $\times$ 1 channel • Basic interval timer/watchdog timer $\times$ 1 channel • Watch timer $\times$ 1 channel • 8-bit timer $\times$ 1 channel		
Serial interface		Any of three modes can be used: • 3-wire serial I/O mode: MSB/LSB switchable • 2-wire serial I/O mode • SBI mode				
Vectored interrupt		External: 3, Internal: 4				
Test input		External: 1, Internal: 1				
Clock output (PCL)		Φ , 125 kHz, 62.5 kHz, 15.6 kHz (with 1.0 MHz main system clock)				
Buzzer output (BUZ)		• 2 kHz, 4 kHz, 32 kHz (with 32.768 kHz subsystem clock) • 0.49 kHz, 0.98 kHz, 7.81 kHz (with 1.0 MHz main system clock)				
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison				
Power supply voltage		V_{DD} = 1.8 to 5.5 V				
Package		• 42-pin plastic shrink DIP (600 mil) • 44-pin plastic QFP (10 $\times$ 10 mm)				
Development tools		Assembler, IE controller, device file, in-circuit emulator				
Applications		VCRs, CD players, cordless telephones, radios, cameras, home electric appliances, etc.				

4-Bit Single-Chip Microcontroller

75XL Series

■ General-Purpose 42-pin (A/D)

Part number		μ PD750064		μ PD750066	μ PD750068	μ PD75P0076
ROM (bytes)		4096 (Mask ROM)		6144 (Mask ROM)	8192 (Mask ROM)	16384 (One-time PROM)
RAM (× 4 bits)		512				
General-purpose register		(4-bit × 8) × 4 banks or (8-bit × 4) × 4 banks				
Instruction cycle		• 0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) • 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock) • 122 μs (with 32.768 kHz subsystem clock)				
Minimum instruction execution time		• 0.67 μs (V_{DD} = 2.7 to 5.5 V) • 0.95 μs (V_{DD} = 1.8 to 5.5 V)				
I/O port	CMOS input	32	12	On-chip pull-up resistors are connectable by software: 7 Also used for analog input pins: 4		
	CMOS I/O		12	Can drive LED On-chip pull-up resistors are connectable by software Also used for analog input pins: 4		
	N-ch open-drain I/O		8	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option		Can drive LED 13 V withstand voltage No on-chip pull-up resistors
Timer		4 channels		• 8-bit timer/event counter: 2 channels (Usable as 16-bit timer/event counter) • Basic interval timer/watchdog timer: 1 channel • Watch timer: 1 channel		
Serial interface		Any of two modes can be used: • 3-wire serial I/O mode (MSB/LSB switchable) • 2-wire serial I/O mode				
A/D converter		8-bit resolution × 8 channels				
Vectored interrupt		External: 3, Internal: 4				
Test input		External: 1, Internal: 1				
Clock output (PCL)		• Φ, 1.05 MHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) • Φ, 1.5 MHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)				
Buzzer output (BUZ)		• 2 kHz, 4 kHz, 32 kHz (with 4.19 MHz main system clock, or 32.768 kHz subsystem clock) • 2.93 kHz, 5.86 kHz, 46.9 kHz (with 6.0 MHz main system clock)				
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison				
Power supply voltage		V _{DD} = 1.8 to 5.5 V				
Package		• 42-pin plastic shrink DIP (600 mil, 1.778-mm pitch) • 42-pin plastic shrink SOP (375 mil, 0.8-mm pitch)				
Development tools		Assembler, IE controller, device file, in-circuit emulator				
Applications		Cordless telephones, AV equipment, home electric appliances, OA equipment, health equipment, meters, gas tables, etc.				

4-Bit Single-Chip Microcontroller

75XL Series

■ General-Purpose 36-pin

Part number		μ PD754302		μ PD754304	μ PD75P4308
ROM (bytes)		2048 (Mask ROM)		4096 (Mask ROM)	8192 (One-time PROM)
RAM ($\times$ 4 bits)		256			
General-purpose register		(4-bit $\times$ 8) $\times$ 4 banks or (8-bit $\times$ 4) $\times$ 4 banks			
Instruction cycle		• 0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) • 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock)			
Minimum instruction execution time		• 0.67 μs (V_{DD} = 2.7 to 5.5 V) • 0.95 μs (V_{DD} = 1.8 to 5.5 V)			
I/O port	CMOS input	30	8	On-chip pull-up resistors are connectable by software: 7	
	CMOS I/O		18	Can drive LED On-chip pull-up resistors are connectable by software	
	N-ch open-drain I/O		4	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option	Can drive LED 13 V withstand voltage No on-chip pull-up resistors
Timer		3 channels		8-bit timer/event counter $\times$ 2 channels (usable as 16-bit timer/event counter) Basic interval timer/watchdog timer $\times$ 1 channel	
Serial interface		Either of two modes can be used: • 3-wire serial I/O mode: MSB/LSB switchable • 2-wire serial I/O mode			
Vectored interrupt		External: 3, Internal: 4			
Test input		External: 1			
Clock output (PCL)		• Φ, 524 kHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) • Φ, 750 kHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)			
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison			
Power supply voltage		V_{DD} = 1.8 to 5.5 V			
Package		• 36-pin plastic shrink SOP (300 mil, 0.8-mm pitch)			
Development tools		Assembler, IE controller, device file, in-circuit emulator			
Applications		Cordless telephones, TVs, VCRs, audio equipment, home electric appliances, OA equipment, etc.			

4-Bit Single-Chip Microcontroller

75XL Series

■ Keyless Entry

Part number		μ PD754202		μ PD754144	μ PD754244	μ PD754264	μ PD75F4264*
ROM (bytes)		2048 (Mask ROM)		4096 (Mask ROM)			4096 (Flash memory)
RAM (× 4 bits)		128					
EEPROM™ (bytes)		—		16		32	
General-purpose register		(4-bit × 8) × 4 banks or (8-bit × 4) × 4 banks					
Instruction cycle		• 0.95 μ s, 1.91 μ s, 3.81 μ s, 15.3 μ s (with 4.19 MHz System clock) • 0.67 μ s, 1.33 μ s, 2.67 μ s, 10.7 μ s (with 6.0 MHz System clock)		• 4 μ s, 8 μ s, 16 μ s, 64 μ s (with 1 MHz system clock)		• 0.95 μ s, 1.91 μ s, 3.81 μ s, 15.3 μ s (with 4.19 MHz system clock) • 0.67 μ s, 1.33 μ s, 2.67 μ s, 10.7 μ s (with 6.0 MHz system clock)	
Minimum instruction execution time		• 0.67 μ s (V _{DD} = 2.7 to 6.0 V) • 0.95 μ s (V _{DD} = 1.8 to 6.0 V)		2 μ s (V _{DD} = 1.8 to 6.0 V)		• 0.67 μ s (V _{DD} = 2.7 to 6.0 V) • 0.95 μ s (V _{DD} = 1.8 to 6.0 V)	
I/O port	CMOS input	13	4	Pull-up resistors can be incorporated by mask option			No on-chip pull-up resistors
	CMOS I/O		9	Can drive LED On-chip pull-up resistors are connectable by software			
System clock oscillator		Crystal/ceramic oscillator		RC oscillator (external resistors and capacitors)		Crystal/ceramic oscillator	
Timer		4 channels		• 8-bit timer counter: 3 channels (Usable as 16-bit timer counter or remote controller signal carrier generator) • Basic interval timer/watchdog timer: 1 channel			
Programmable threshold port		—		4-bit resolution × 2		—	
A/D converter		—		—		8-bit resolution × 2	
Others		Key return reset function					
Vectored interrupt		External: 1, internal: 5					
Test input		External: 1					
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison					
Power supply voltage		V _{DD} = 1.8 to 6.0 V					
Package		• 20-pin plastic SOP (300 mil, 1.27-mm pitch) • 20-pin plastic shrink SOP (300 mil, 0.65-mm pitch)				20-pin plastic SOP (300 mil, 1.27-mm pitch)	
Development tools		Assembler, IE controller, device file, in-circuit emulator					
Applications		Keyless entries, data carriers					

★: Under development

4-Bit Single-Chip Microcontroller

75XL Series

■ LCD-Driver 80-pin

Part number		μ PD753012A		μ PD753016A	μ PD753017A	μ PD75P3018A
ROM (bytes)		12288 (Mask ROM)		16384 (Mask ROM)	24576 (Mask ROM)	32768 (One-time PROM)
RAM ($\times$ 4 bits)		1024				
General-purpose register		(4-bit $\times$ 8) $\times$ 4 banks or (8-bit $\times$ 4) $\times$ 4 banks				
Instruction cycle		• 0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) • 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock) • 122 μs (with 32.768 kHz subsystem clock)				
Minimum instruction execution time		• 0.67 μs (V_{DD} = 2.7 to 5.5 V) • 0.95 μs (V_{DD} = 1.8 to 5.5 V)				
I/O port	CMOS input	40	8	On-chip pull-up resistors are connectable by software: 7		
	CMOS I/O		16	Can drive LED On-chip pull-up resistors are connectable by software		
	CMOS I/O		8	Also used for segment pins		
	N-ch open-drain I/O		8	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option	Can drive LED 13 V withstand voltage No on-chip pull-up resistors	
LCD controller/driver		• Number of segments selectable: 24/28/32 segments (switchable to CMOS ports in multiples of 4: 8 maximum) • Selectable display mode: Static, 1/2 duty (1/2 bias), 1/3 duty (1/2 bias), 1/3 duty (1/3 bias), 1/4 duty (1/3 bias)				
		Voltage divider resistors for LCD drive can be incorporated by mask option			No on-chip voltage divider resistors for LCD drive	
Timer		5 channels		• 8-bit timer/event counter: 3 channels (usable as 16-bit timer/event counter or remote-controller signal carrier generator) • Basic interval timer/watchdog timer $\times$ 1 channel • Watch timer $\times$ 1 channel		
Serial interface		Any of three modes can be used: • 3-wire serial I/O mode: MSB/LSB switchable • 2-wire serial I/O mode • SBI mode				
Vectored interrupt		External: 3, Internal: 5				
Test input		External: 1, Internal: 1				
Clock output (PCL)		• Φ, 524 kHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) • Φ, 750 kHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)				
Buzzer output (BUZ)		• 2 kHz, 4 kHz, 32 kHz (with 4.19 MHz main system clock, or with 32.768 kHz subsystem clock) • 2.93 kHz, 5.86 kHz, 46.9 kHz (with 6.0 MHz main system clock)				
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison				
Power supply voltage		V_{DD} = 1.8 to 5.5 V				
Package		• 80-pin plastic QFP (14 $\times$ 14 mm) • 80-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm)				
Development tools		Assembler, IE controller, device file, in-circuit emulator				
Applications		Camcorders, CD players, telephones, cameras, pagers, remote controllers, etc.				

4-Bit Single-Chip Microcontroller

75XL Series

■ LCD-Driver 64-pin

Part number		μ PD753104		μ PD753106	μ PD753108	μ PD75P3116
ROM (bytes)		4096 (Mask ROM)		6144 (Mask ROM)	8192 (Mask ROM)	16384 (One-time PROM)
RAM ($\times$ 4 bits)		512				
General-purpose register		(4-bit $\times$ 8) $\times$ 4 banks or (8-bit $\times$ 4) $\times$ 4 banks				
Instruction cycle		0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock) 122 μs (with 32.768 kHz subsystem clock)				
Minimum instruction execution time		0.67 μs (V_{DD} = 2.7 to 5.5 V) 0.95 μs (V_{DD} = 1.8 to 5.5 V)				
I/O port	CMOS input	32	8	On-chip pull-up resistors are connectable by software: 7		
	CMOS I/O		12	Can drive LED On-chip pull-up resistors are connectable by software		
	CMOS I/O		8	Also used for segment pins		
	N-ch open-drain I/O		4	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option	Can drive LED 13 V withstand voltage No on-chip pull-up resistors	
LCD controller/driver		- Number of segments selectable: 16/20/24 segments (switchable to CMOS ports in multiples of 4: 8 maximum) - Selectable display mode: Static, 1/2 duty (1/2 bias), 1/3 duty (1/2 bias), 1/3 duty (1/3 bias), 1/4 duty (1/3 bias)				
		Voltage divider resistors for LCD drive can be incorporated by mask option			No on-chip voltage divider resistors for LCD drive	
Timer		5 channels		8-bit timer/event counter: 3 channels (usable as 16-bit timer/event counter or remote-controller signal carrier generator) - Basic interval timer/watchdog timer $\times$ 1 channel - Watch timer $\times$ 1 channel		
Serial interface		Any of three modes can be used: 3-wire serial I/O mode: MSB/LSB switchable 2-wire serial I/O mode - SBI mode				
Vectored interrupt		External: 3, Internal: 5				
Test input		External: 1, Internal: 1				
Clock output (PCL)		Φ, 524 kHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) Φ, 750 kHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)				
Buzzer output (BUZ)		2 kHz, 4 kHz, 32 kHz (with 4.19 MHz main system clock, or with 32.768 kHz subsystem clock) 2.93 kHz, 5.86 kHz, 46.9 kHz (with 6.0 MHz main system clock)				
Instruction set		- Bit data set/reset/test/boolean operations 4-/8-bit data transfer/operations/increment and decrement/comparison				
Power supply voltage		V_{DD} = 1.8 to 5.5 V				
Package		64-pin plastic QFP (14 $\times$ 14 mm) 64-pin plastic TQFP (12 $\times$ 12 mm)				
Development tools		Assembler, IE controller, device file, in-circuit emulator				
Applications		Telephones, cameras, sphygmomanometers, gas meters, electronic scales, remote controllers, etc.				

4-Bit Single-Chip Microcontroller

75XL Series

■ LCD-Driver 48-pin

Part number		μ PD753204		μ PD753206	μ PD753208	μ PD75P3216
ROM (bytes)		4096 (Mask ROM)		6144 (Mask ROM)	8192 (Mask ROM)	16384 (One-time PROM)
RAM ($\times$ 4 bits)		512				
General-purpose register		(4-bit $\times$ 8) $\times$ 4 banks or (8-bit $\times$ 4) $\times$ 4 banks				
Instruction cycle		• 0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) • 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock)				
Minimum instruction execution time		• 0.67 μs (V_{DD} = 2.7 to 5.5 V) • 0.95 μs (V_{DD} = 1.8 to 5.5 V)				
I/O port	CMOS input	30	6	On-chip pull-up resistors are connectable by software: 5		
	CMOS I/O		12	Can drive LED On-chip pull-up resistors are connectable by software		
	CMOS I/O		8	Also used for segment pins On-chip pull-up resistors are connectable by software		
	N-ch open-drain I/O		4	Can drive LED, 13 V withstand voltage Pull-up resistors can be incorporated by mask option	Can drive LED 13 V withstand voltage No on-chip pull-up resistors	
LCD controller/driver		• Number of segments selectable: 4/8/12 segments • Selectable display mode: Static, 1/2 duty (1/2 bias), 1/3 duty (1/2 bias), 1/3 duty (1/3 bias), 1/4 duty (1/3 bias)				
		Voltage divider resistors for LCD drive can be incorporated by mask option			No on-chip voltage divider resistors for LCD drive	
Timer		5 channels		• 8-bit timer/event counter $\times$ 1 channel • Basic interval timer/watchdog timer $\times$ 1 channel • Watch timer $\times$ 1 channel • 8-bit timer $\times$ 2 channels (usable as 16-bit timer or remote controller signal carrier generator)		
Serial interface		Any of three modes can be used: • 3-wire serial I/O mode: MSB/LSB switchable • 2-wire serial I/O mode • SBI mode				
Vectored interrupt		External: 2, Internal: 5				
Test input		External: 1, Internal: 1				
Clock output (PCL)		• Φ, 524 kHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) • Φ, 750 kHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)				
Buzzer output (BUZ)		• 2 kHz, 4 kHz, 32 kHz (with 4.19 MHz main system clock) • 2.93 kHz, 5.86 kHz, 46.9 kHz (with 6.0 MHz main system clock)				
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison				
Power supply voltage		V_{DD} = 1.8 to 5.5 V				
Package		48-pin plastic shrink SOP (375 mil, 0.65-mm pitch)				
Development tools		Assembler, IE controller, device file, in-circuit emulator				
Applications		Remote controllers, cameras, sphygmomanometers, CD radio cassette players, gas meters, etc.				

4-Bit Single-Chip Microcontroller

75XL Series

■ LCD-Driver 42-pin

Part number		μPD753304		
ROM (bytes)		4096 (Mask ROM)		
RAM (× 4 bits)		256		
General-purpose register		(4-bit × 8) × 4 banks or (8-bit × 4) × 4 banks		
Instruction cycle		1.1 μs, 2.2 μs, 4.4 μs, 17.8 μs (with 3.6 MHz main system clock, RC oscillator)		
		85.1 μs (with 47 kHz subsystem clock, RC oscillator)		
Minimum instruction execution time		• 0.67 μs (VDD = 4.5 to 5.5 V) • 0.8 μs (VDD = 2.5 to 5.5 V)		
I/O port	CMOS I/O	12	8	On-chip pull-up resistors are connectable by software: 4
	CMOS I/O		4	Also used for segment pins
LCD controller/driver		• Number of segments selectable: 20/24 segments (switchable to CMOS I/O ports in multiples of 4 : 4) • Selectable display mode: Static, 1/2 duty (1/2 bias), 1/3 duty (1/2 bias), 1/3 duty (1/3 bias), 1/4 duty (1/3 bias)		
		On-chip voltage divider resistors for LCD drive		
Timer		3 channels	• 8-bit timer: 1 channel • Basic interval timer/watchdog timer: 1 channel • Watch timer: 1 channel	
Vectored interrupt		External: 1, Internal: 2		
Test input		Internal: 1		
Clock output (PCL)		Φ, 3.6 MHz, 450 kHz, 225 kHz (with 3.6 MHz main system clock)		
Buzzer output (BUZ)		• 2.94 kHz, 5.88 kHz, 47 kHz (with 47 kHz subsystem clock) • 1.76 kHz, 3.52 kHz, 28.13 kHz (with 3.6 MHz main system clock)		
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison		
Power supply voltage		VDD = 2.5 to 5.5 V		
Operating ambient temperature		TA = −10 to +60°C		
Package		• 42-pin pellet/wafer • 42-pin ceramic shrink DIP (600 mil) (ES only)		
Development tools		Assembler, IE controller, device file, in-circuit emulator		
Applications		Small-size LCD displays, etc.		

4-Bit Single-Chip Microcontroller

75XL Series

■ LCD-Driver 80-pin (A/D)

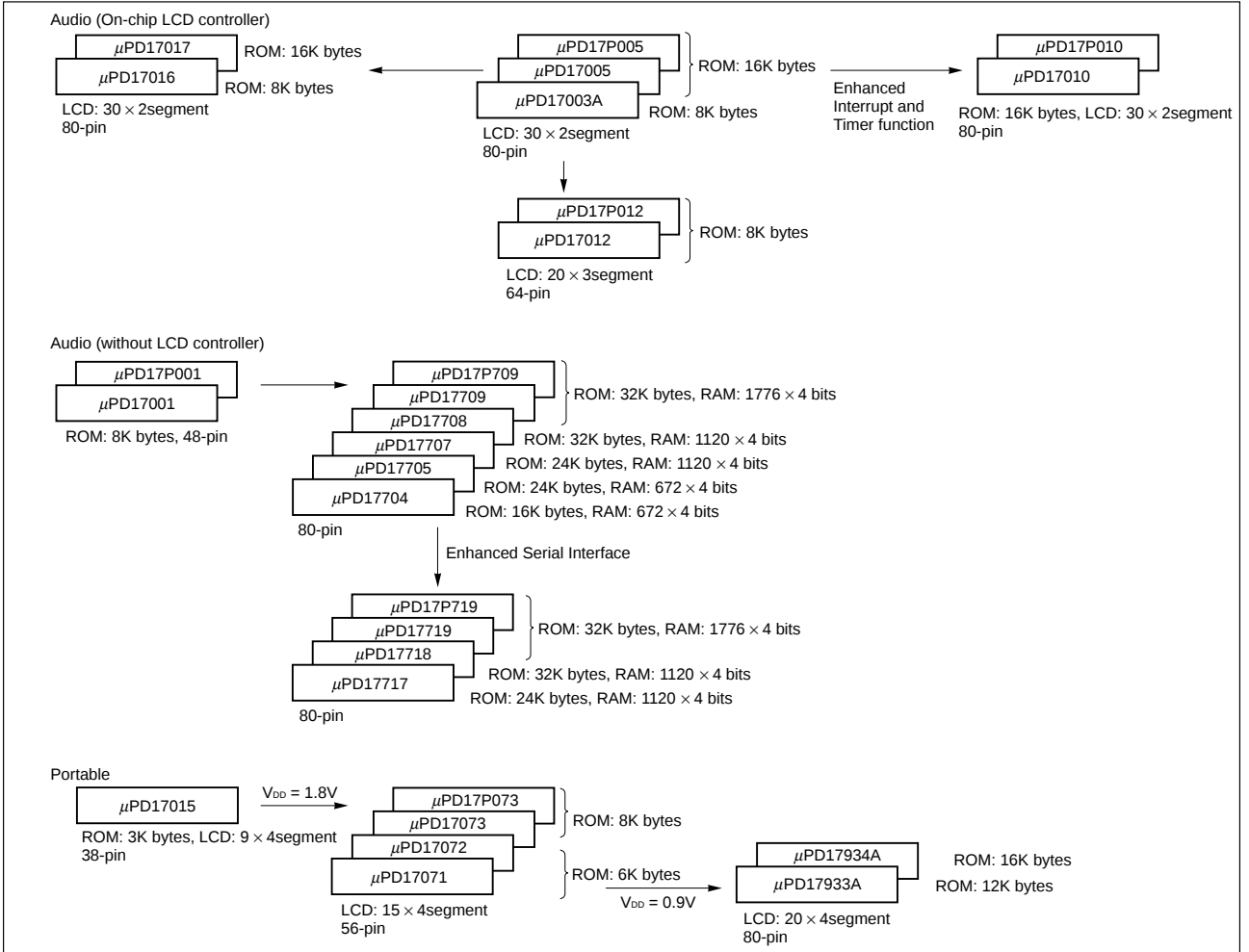
Part number		μ PD753036		μ PD75P3036	
ROM (bytes)		16384 (Mask ROM)		16384 (One-time PROM)	
RAM (× 4 bits)		768			
General-purpose register		(4-bit × 8) × 4 banks or (8-bit × 4) × 4 banks			
Instruction cycle		• 0.95 μs, 1.91 μs, 3.81 μs, 15.3 μs (with 4.19 MHz main system clock) • 0.67 μs, 1.33 μs, 2.67 μs, 10.7 μs (with 6.0 MHz main system clock) • 122 μs (with 32.768 kHz subsystem clock)			
Minimum instruction execution time		• 0.67 μs (V_{DD} = 2.7 to 5.5 V) • 0.95 μs (V_{DD} = 1.8 to 5.5 V)			
I/O port	CMOS input	44	8	On-chip pull-up resistors are connectable by software: 7	
	CMOS I/O		20	Can drive LED On-chip pull-up resistors are connectable by software	
	Bit-port output		8	Also used for segment pins	
	N-ch open-drain I/O		8	Can drive LED 13 V withstand voltage Pull-up resistors can be incorporated by mask option	Can drive LED, 13 V withstand voltage No on-chip pull-up resistors
LCD controller/driver		• Number of segments selectable: 12/16/20 segments (switchable to bit-port output in multiples of 4: 8 maximum) • Selectable display mode: Static, 1/2 duty (1/2 bias), 1/3 duty (1/2 bias), 1/3 duty (1/3 bias), 1/4 duty (1/3 bias)			
		Voltage divider resistors for LCD drive can be incorporated by mask option		No on-chip voltage divider resistors for LCD drive	
Timer		5 channels		• 8-bit timer/event counter: 3 channels (Usable as 16-bit timer/event counter or remote controller signal carrier generator) • Basic interval timer/watchdog timer: 1 channel • Watch timer: 1 channel	
Serial interface		Any of three modes can be used: • 3-wire serial I/O mode (MSB/LSB switchable) • 2-wire serial I/O mode • SBI mode			
A/D converter		8-bit resolution × 8 channels			
Vectored interrupt		External: 3, Internal: 5			
Test input		External: 1, Internal: 1			
Clock output (PCL)		• Φ, 524 kHz, 262 kHz, 65.5 kHz (with 4.19 MHz main system clock) • Φ, 750 kHz, 375 kHz, 93.8 kHz (with 6.0 MHz main system clock)			
Buzzer output (BUZ)		• 2 kHz, 4 kHz, 32 kHz (with 4.19 MHz main system clock, or 32.768 kHz subsystem clock) • 2.93 kHz, 5.86 kHz, 46.9 kHz (with 6.0 MHz main system clock)			
Instruction set		• Bit data set/reset/test/boolean operations • 4-/8-bit data transfer/operations/increment and decrement/comparison			
Power supply voltage		V_{DD} = 1.8 to 5.5 V			
Package		• 80-pin plastic QFP (14 × 14 mm) • 80-pin plastic TQFP (fine pitch) (12 × 12 mm)			
Development tools		Assembler, IE controller, device file, in-circuit emulator			
Applications		Cordless telephones, AV equipment, home electric appliances, OA equipment, health equipment, meters, gas tables, etc.			

4-Bit Single-Chip Microcontroller

17K Series

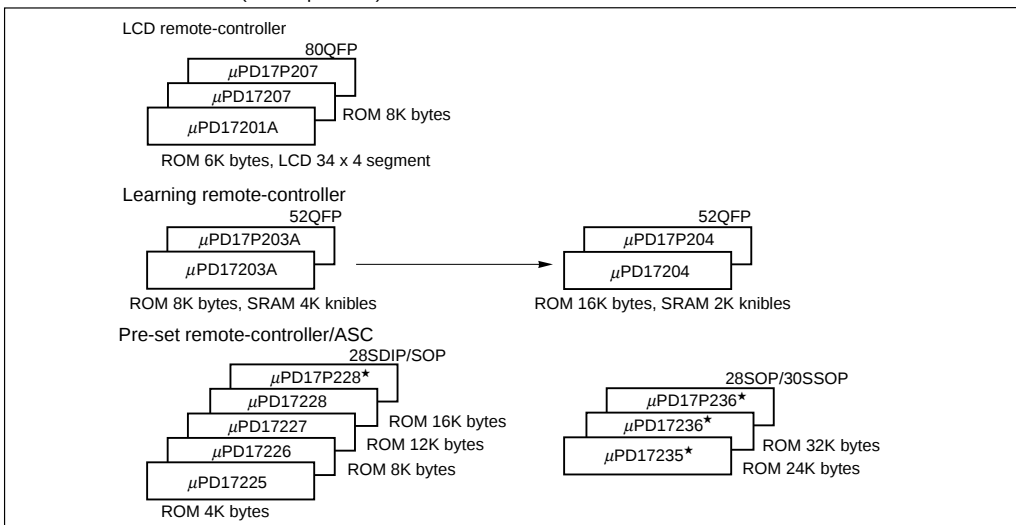
■ 17K Series Product Evolution

DTS



★: Under development

Remote control transmitter (2.2 V operation)



★: Under development

4-Bit Single-Chip Microcontroller

17K Series

■ Audio (On-Chip LCD Controller)

Part number	μ PD17003A	μ PD17005	μ PD17010	μ PD17016	μ PD17017	μ PD17012
Main application	High-end tuner, automotive radio					
ROM size	3836 $\times$ 16 bits	7932 $\times$ 16 bits	7932 $\times$ 16 bits	3836 $\times$ 16 bits	7932 $\times$ 16 bits	4096 $\times$ 16 bits
RAM size	320 $\times$ 4 bits	432 $\times$ 4 bits	432 $\times$ 4 bits	320 $\times$ 4 bits	432 $\times$ 4 bits	316 $\times$ 4 bits
Display	On-chip LCD driver Segment signal: 30 Common signal: 2					On-chip LCD driver Segment signal: 20 Common signal: 3
Input port	8					
Output port	9 (+30)			9 (+8)		8 (+ 20)
I/O port	16					14
D/A converter	4			2		2
A/D converter	6			6		2
Modulo timer	—					1
Power supply voltage	+5 V $\pm$ 10%					
Crystal	4.5 MHz					
PLL reference frequency	1, 1.25, 2.5, 3, 5, 6.25, 9, 10, 12.5, 25, 50, 100 kHz					
Applicable prescaler	On-chip (150 MHz)					On-chip (250 MHz)
Package	80-pin plastic QFP					64-pin plastic QFP
One-time PROM product	μ PD17P005		μ PD17P010	μ PD17P005		μ PD17P012
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator					

4-Bit Single-Chip Microcontroller

17K Series

■ Audio (without LCD Controller) (1/2)

Subseries name	—	μPD17709 Subseries				
Part number	μPD17001	μPD17704	μPD17705	μPD17707	μPD17708	μPD17709
Main application	High-end tuner, automotive radio					
ROM size	3836 × 16 bits	8192 × 16 bits	12288 × 16 bits		16384 × 16 bits	
RAM size	224 × 4 bits	672 × 4 bits		1120 × 4 bits		1776 × 4 bits
Input port	8	12				
Output port	12	4				
I/O port	12	46				
D/A converter	4	3				
A/D converter	6	6				
Modulo timer	—	4 (Used also PWM: 1)				
Power supply voltage	+5 V ±10%					
Crystal	4.5 MHz					
PLL reference frequency	*	1, 1.25, 2.5, 3, 5, 6.25, 9, 10, 12.5, 18, 20, 25, 50 kHz				
Applicable prescaler	On-chip (130 MHz)					
Package	48-pin plastic QFP	80-pin plastic QFP				
One-time PROM product	μPD17P001	μPD17P709				
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator					

*: 1, 1.25, 2.5, 3, 5, 6.25, 9, 10, 12.5, 25, 50, 100 kHz

4-Bit Single-Chip Microcontroller

17K Series

■ Audio (without LCD Controller) (2/2)

Subseries name	μ PD17719 Subseries		
Part number	μ PD17717	μ PD17718	μ PD17719
Main application	High-end tuner, automotive radio		
ROM size	12288 $\times$ 16 bits	16384 $\times$ 16 bits	
RAM size	1120 $\times$ 4 bits		1776 $\times$ 4 bits
Input port	12		
Output port	4		
I/O port	46		
D/A converter	3		
A/D converter	6		
Serial interface	2-wire/3-wire/SBI/I ² C bus (selectable): 1 channel 3-wire/UART (selectable): 1 channel		
Modulo timer	4 (Used also PWM: 1)		
Power supply voltage	+5 V $\pm$ 10%		
Crystal	4.5 MHz		
PLL reference frequency	1, 1.25, 2.5, 3, 5, 6.25, 9, 10, 12.5, 18, 20, 25, 50 kHz		
Applicable prescaler	On-chip (130 MHz)		
Package	80-pin plastic QFP		
One-time PROM product	μ PD17P719		
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator		

4-Bit Single-Chip Microcontroller

17K Series

■ Portable

Part number	μ PD17015	μ PD17071	μ PD17072	μ PD17073	μ PD17933A	μ PD17934A
Main application	Portable radio					
ROM size	1528 $\times$ 16 bits	3072 $\times$ 16 bits		4096 $\times$ 16 bits	6144 $\times$ 16 bits	8192 $\times$ 16 bits
RAM size	97 $\times$ 4 bits	174 $\times$ 4 bits			448 $\times$ 4 bits	
Display	On-chip LCD driver Segment signal: 9 Common signal: 4	On-chip LCD driver Segment signal: 15 Common signal: 4			On-chip LCD driver Segment signal: 20 Common signal: 4	
Input port	3	4			11	
Output port	7	9			6	
I/O port	2	8			20	
A/D converter	—		2		3	
Power supply voltage	1.7 to 2.6 V (when PLL is stopped) 1.8 to 3.6 V (when PLL is operating)	1.8 to 3.6 V			0.9 to 1.8 V	
Crystal	75 kHz					
PLL reference frequency	1, 3, 5, 12.5 kHz	1, 3, 5, 6.25, 12.5, 25 kHz				
Applicable prescaler	On-chip (220 MHz)	On-chip (230 MHz)				
Package	38-pin plastic shrink SOP	56-pin plastic QFP	56-pin plastic QFP 64-pin plastic TQFP		80-pin plastic TQFP	
One-time PROM product	—	μ PD17P073			—	
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator					

4-Bit Single-Chip Microcontroller

17K Series

■ LCD Remote-Controller, Learning Remote-Controller

Part number	μ PD17201A	μ PD17207	μ PD17203A	μ PD17204
Main application	Infrared remote controller with LCD display		Infrared remote controller for learning	
ROM size	3072×16 bits	4096×16 bits	4096×16 bits	7936×16 bits
RAM size	336×4 bits		336×4 bits	
Static RAM	—	—	4096×4 bits	2048×4 bits
LCD controller/driver	136 segments maximum		None	
Carrier generator for infrared remote-controller signal	On-chip		On-chip	
Infrared remote-controller signal receiver preamplifier	None		On-chip	
I/O port	19		28	
External interrupt	1		1	
Analog input	A/D converter: 4 channels (8-bit resolution)		—	
Timer	2 channels		4 channel	
Serial interface	1 channel		1 channel	
Watchdog timer	On-chip ($\overline{\text{WDOUT}}$ output)		On-chip ($\overline{\text{WDOUT}}$ output)	
Dual clock	On-chip		On-chip	
Instruction execution time	$4 \mu\text{s}$ at 4 MHz		$4 \mu\text{s}$ at 4 MHz	
Power supply voltage	2.2 to 5.5 V		2.2 to 5.5 V	
Package	80-pin plastic QFP		52-pin plastic QFP	
One-time PROM product	μ PD17P207	μ PD17P207	μ PD17P203A	μ PD17P204
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator			

4-Bit Single-Chip Microcontroller

17K Series

■ Pre-set Remote-Controller/ASC

Part number	μ PD17225	μ PD17226	μ PD17227	μ PD17228
Main application	Pre-set remote controller, toy, portable system			
ROM size	2048 $\times$ 16 bits	4096 $\times$ 16 bits	6144 $\times$ 16 bits	8192 $\times$ 16 bits
RAM size	111 $\times$ 4 bits		223 $\times$ 4 bits	
Carrier generator for infrared remote-controller signal	On-chip			
I/O port	CMOS input: 9 N-ch open-drain output: 8 CMOS I/O: 4			
External interrupt	1			
Timer	2 channels			
Watchdog timer	On-chip ($\overline{\text{WDOUT}}$ output)			
Low voltage detection circuit	On-chip ($\overline{\text{WDOUT}}$ output)			
P0C/P0D standby operation	The output level existing immediately before setting standby mode is maintained.			
Instruction execution time	High speed mode: 2 μ s (at 8 MHz) Normal mode: 4 μ s (at 8 MHz)			
Power supply voltage	2.2 to 3.6 V (4 μ s, 2.0 to 3.6 V)			
Package	28-pin plastic SDIP, 28-pin plastic SOP, 30-pin plastic shrink SOP			
One-time PROM product	μ PD17P228 $\star$			
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator			

Part number	μ PD17235*	μ PD17236*
Main application	Pre-set remote controller, toy, portable system	
ROM size	12288 $\times$ 16 bits	16384 $\times$ 16 bits
RAM size	223 $\times$ 4 bits	
Carrier generator for infrared remote-controller signal	On-chip	
I/O port	CMOS input: 9 or 10 N-ch open-drain output: 8 or 9 CMOS I/O: 4	
External interrupt	1	
Timer	2 channels	
Watchdog timer	On-chip	
Low voltage detection circuit	On-chip	
P0C/P0D standby operation	The output level existing immediately before setting standby mode is maintained.	
Instruction execution time	High speed mode: 2 μ s (at 8 MHz) Normal mode: 4 μ s (at 8 MHz)	
Power supply voltage	2.2 to 3.6 V (4 μ s, 2.0 to 3.6 V)	
Package	28-pin plastic SOP, 30-pin plastic shrink SOP	
One-time PROM product	μ PD17P236*	
Development tools	Assembler, C-like compiler, device file, integrated debugger, in-circuit emulator	

*: Under development

4-Bit Single-Chip Microcontroller**μPD6133, 6604, 63 Series****■ Remote Controller (μPD6133 Series)**

Part number	μPD6133	μPD6134	μPD61P34B
Main application	AV, household electric appliances		
ROM size	512 × 10 bits	1002 × 10 bits	
	Mask ROM		One time PROM
RAM size	32 × 4 bits		
Number of supported keys	32 (standard), 48 (when using key expansion pin), 96 (when expanded by diode)		
Operation clock frequency (f _x)	300 kHz to 1 MHz (ceramic oscillator)		
Instruction execution time	16 μs (at f _x = 500 kHz)		
Modulation carrier frequency	f _x , f _x /2, f _x /8, f _x /12, f _x /16, f _x /24, no carrier (high level)		
Timer	9-bit programmable timer		
POC circuit	Mask option		On-chip
Power supply voltage (V _{DD})	1.8 to 3.6 V, 2.2 to 3.6 V (when POC circuit is incorporated)		2.2 to 3.6 V
Package	20-pin plastic SOP, 20-pin plastic shrink SOP		
Development tools	Assembler		

■ Remote Controller (μPD6604 Series)

Part number	μPD6604	μPD66P04B
Main application	AV, household electric appliances	
ROM size	1002 × 10 bits	
	Mask ROM	One time PROM
RAM size	32 × 4 bits	
Number of supported keys	32 (standard), 48 (when using key expansion pin), 96 (when expanded by diode)	
Operation clock frequency (f _x)	300 kHz to 1 MHz (RC oscillator)	
Instruction execution time	16 μs (at f _x = 500 kHz)	
Modulation carrier frequency	f _x , f _x /2, f _x /8, f _x /12, f _x /16, f _x /24, no carrier (high level)	
Timer	9-bit programmable timer	
POC circuit	Mask option	On-chip
Power supply voltage (V _{DD})	1.8 to 3.6 V, 2.2 to 3.6 V (when POC circuit is incorporated)	2.2 to 3.6 V
Package	20-pin plastic SOP, 20-pin plastic shrink SOP	
Development tools	Assembler	

4-Bit Single-Chip Microcontroller

μPD6133, 6604, 63 Series

■ Remote Controller (μPD63 Series)

Part number	μPD62	μPD63A	μPD64	μPD6P4B	μPD65 [★]
Main application	AV, household electric appliances				
ROM size	512 × 10 bits	768 × 10 bits	1002 × 10 bits		2026 × 10 bits
	Mask ROM			One time PROM	Mask ROM
RAM size	32 × 4 bits				
Number of supported keys	32 (standard), 48 (when using key expansion pin), 96 (when expanded by diode)				56 (standard)
Operation clock frequency (f _x)	2.4 MHz to 8 MHz (ceramic oscillator)				
Instruction execution time	16 μs (at f _x = 4 MHz)				
Modulation carrier frequency	f _x /8, f _x /16, f _x /64, f _x /96, f _x /128, f _x /192, no carrier (high level)				
Timer	9-bit programmable timer				
POC circuit	Mask option			On-chip	Mask option
Power supply voltage (V _{DD})	1.8 to 3.6 V, 2.2 to 3.6 V (when POC circuit is incorporated)			2.2 to 3.6 V	
Package	20-pin plastic shrink SOP	20-pin plastic SOP	20-pin plastic SOP 20-pin plastic shrink SOP		20-pin plastic shrink SOP
Development tools	Assembler				

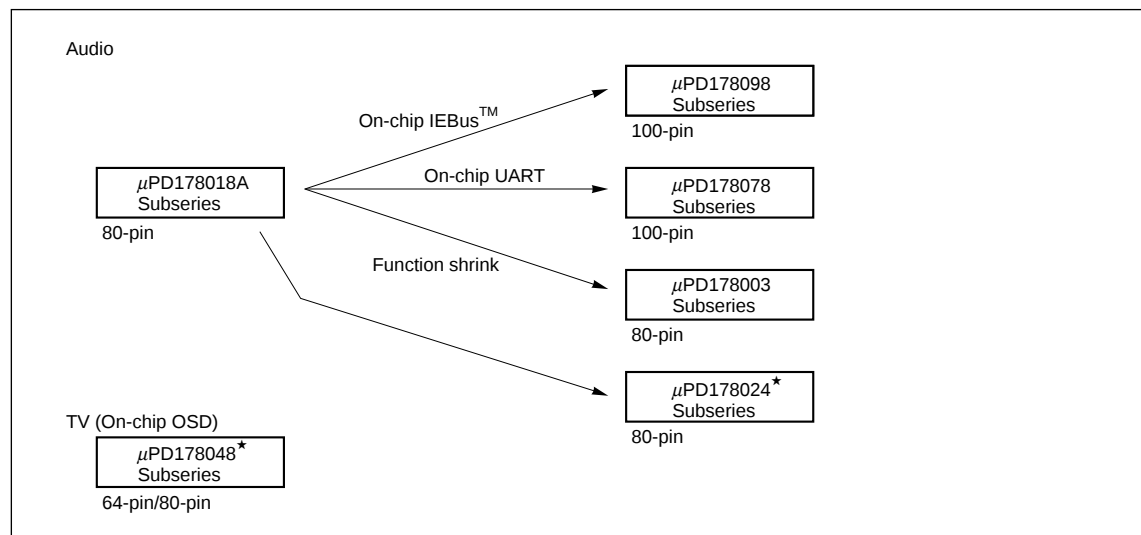
★: Under development

8-Bit Single-Chip Microcontroller

178K Series

■ 178K Series Product Evolution

DTS



★: Under development

■ Differences among the Subseries

Function Subseries name		ROM capacity	Timer			8-bit A/D	8-bit D/A	Serial interface	I/O	V _{DD} MIN. value	Remark
			8-bit	16-bit	WDT						
Audio	μPD178098	48K to 60K	2 ch	1 ch	1 ch	8 ch	—	4 ch (UART: 1 ch, I ² C: 1 ch)	80	4.5 V	—
	μPD178078							4 ch (UART: 1 ch, IEBus: 1 ch)			
	μPD178024	24K to 32K	—	6 ch	2 ch (I ² C: 1 ch)	62					
	μPD178018A	32K to 60K			3 ch		2 ch (I ² C: 1 ch)				
	μPD178003	16K to 24K			2 ch		—	—	1 ch		
TV	μPD178048	48K to 60K	4 ch	—	1 ch	4 ch	—	3 ch (I ² C: 2 ch)	46	4.5 V	—

8-Bit Single-Chip Microcontroller

178K Series

■ Audio (μPD178003, 178018A Subseries)

Subseries name	μPD178003 Subseries		μPD178018A Subseries			
Part number	μPD178002	μPD178003	μPD178004A	μPD178006A	μPD178016A	μPD178018A
Main application	High-end tuner, automotive radio					
ROM size	16K bytes	24K bytes	32K bytes	48K bytes		60K bytes
RAM size	512 bytes		1K bytes		3K bytes	
Input port	1					
Output port	3					
I/O port	58					
D/A converter	—		3			
A/D converter	6					
Modulo timer	2		3 (Used also PWM: 1)			
Power supply voltage	+5 V ±10%					
Crystal	4.5 MHz					
PLL reference frequency	1, 3, 9, 10, 12.5, 25, 50 kHz		1, 3, 5, 9, 10, 25, 50 kHz			
Applicable prescaler	On-chip (160 MHz)					
Package	80-pin plastic QFP					
One-time PROM product	μPD178P018A					
Development tools	Assembler, C compioler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					

■ Audio (μPD178024 Subseries)

Part number	μPD178023*	μPD178024*
Main application	High-end tuner, automotive radio	
ROM size	24K bytes	32K bytes
RAM size	1K bytes	
Input port	6	
Output port	3 (N-ch open drain)	
I/O port	53 (N-ch open drain: 2)	
Serial interface	I ² C bus: 1 channel 3-wire: 1 channel	
A/D converter	6	
Modulo timer	8 bits × 2 ch	
Power supply voltage	4.5 to 5.5 V (When PLL or A/D converter is operating) 3.5 to 5.5 V (When only CPU is operating)	
Crystal	4.5 MHz	
PLL reference frequency	1, 3, 9, 10, 12.5, 25, 50 kHz	
Applicable prescaler	On-chip (160 MHz)	
Package	80-pin plastic QFP (14 × 14 mm, 0.65 mm pitch) 80-pin plastic QFP (14 × 20 mm, 0.8 mm pitch)	
Development tools	Assembler, C compiler, real-time OS, integrated debugger, device file, in-circuit emulator	

★: Under development

8-Bit Single-Chip Microcontroller**178K Series****■ Audio (μ PD178098 Subseries)**

Part number	μ PD178096	μ PD178098
Main application	High-end tuner, automotive radio	
ROM size	48K bytes	60K bytes
RAM size	2048 bytes	3072 bytes
Input port	8	
Output port	8 (N-ch open drain)	
I/O port	64 (N-ch open drain: 3)	
Serial interface	IEBus (mode 1 only): 1 channel 3-wire/2-wire/SBI/I ² C bus (selectable): 1 channel 3-wire: 1 channel 3-wire (with function for automatic transmission and reception): 1 channel	
D/A converter	—	
A/D converter	8	
Modulo timer	16 bits $\times$ 1, 8 bits $\times$ 2	
Power supply voltage	+5 V $\pm$ 10%	
Crystal	6.3 MHz	
PLL reference frequency	1, 3, 9, 10, 12.5, 25, 50 kHz	
Applicable prescaler	On-chip (160 MHz)	
Package	100-pin plastic QFP	
Flash memory product	μ PD178F098	
Development tools	Assembler, C compiler, real-time OS, integrated debugger, device file, in-circuit emulator	

■ Audio (μ PD178078 Subseries)

Part number	μ PD178076	μ PD178078
Main application	High-end tuner, automotive radio	
ROM size	48K bytes	60K bytes
RAM size	2K bytes	3K bytes
Input port	8	
Output port	8 (N-ch open drain)	
I/O port	64 (N-ch open drain: 3)	
Serial interface	3-wire/2-wire/SBI/I ² C bus (selectable): 1 channel 3-wire: 1 channel 3-wire (with function for automatic transmission and reception): 1 channel UART: 1 channel	
A/D converter	8-bit resolution $\times$ 8 channels	
Power supply voltage	+5 V $\pm$ 10%	
Crystal	6.3 MHz, 4.5 MHz	
PLL reference frequency	1, 3, 9, 10, 12.5, 25, 50 kHz	
Applicable prescaler	On-chip (160 MHz)	
Package	100-pin plastic QFP	
Flash memory product	μ PD178F098	
Development tools	Assembler, C compiler, real-time OS, integrated debugger, device file, in-circuit emulator	

8-Bit Single-Chip Microcontroller

178K Series

■ TV (μPD178048 Subseries)

Part number	μPD178046★	μPD178048★
Main application	TV sets, CATV	
ROM size	48K bytes	60K bytes
RAM size	1K bytes	
Display	On-chip OSD Kind of character: 255 Display character: 12 lines × 24 columns Character type: 12 × 18 dot Character color: 8	
Input port	4	
Output port	5 (N-ch open drain)	
I/O port	37 (N-ch open drain: 4)	
Serial interface	I ² C bus: 2 channels 3-wire: 1 channel	
PWM	14-bit × 1 8-bit × 4	
A/D converter	8-bit resolution × 4 channels	
Power supply voltage	+5 V ±10%	
Crystal	5.0 MHz	
Package	64-pin plastic shrink DIP, 80-pin plastic TQFP	
Flash memory product	μPD178F048★	
Development tools	Assembler, C compiler, real-time OS, integrated debugger, device file, in-circuit emulator	

★: Under development

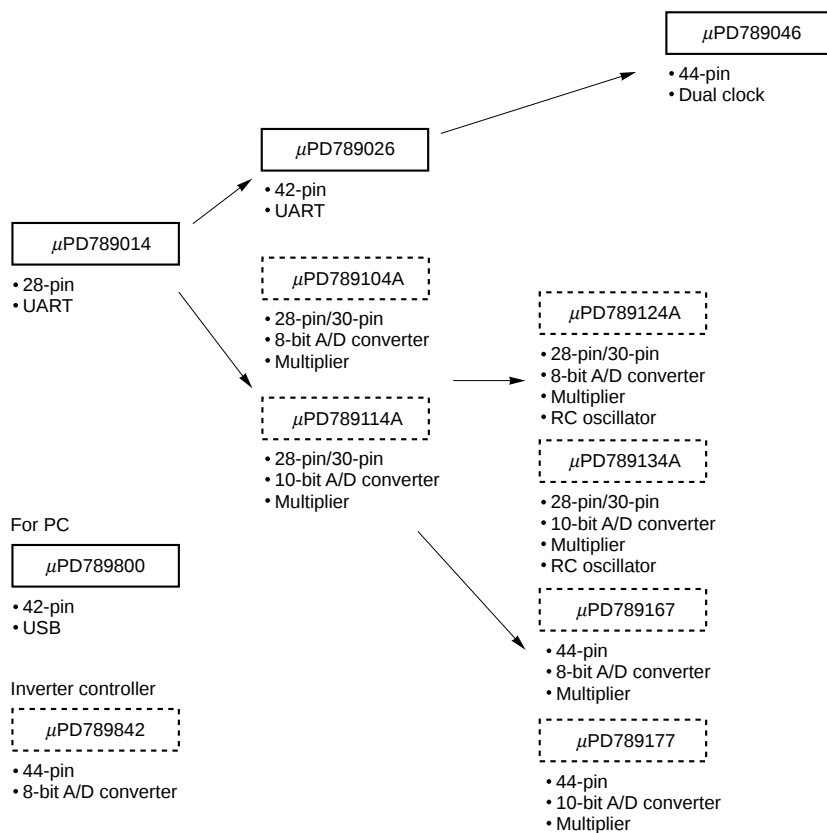
8-Bit Single-Chip Microcontroller

78K/0S Series

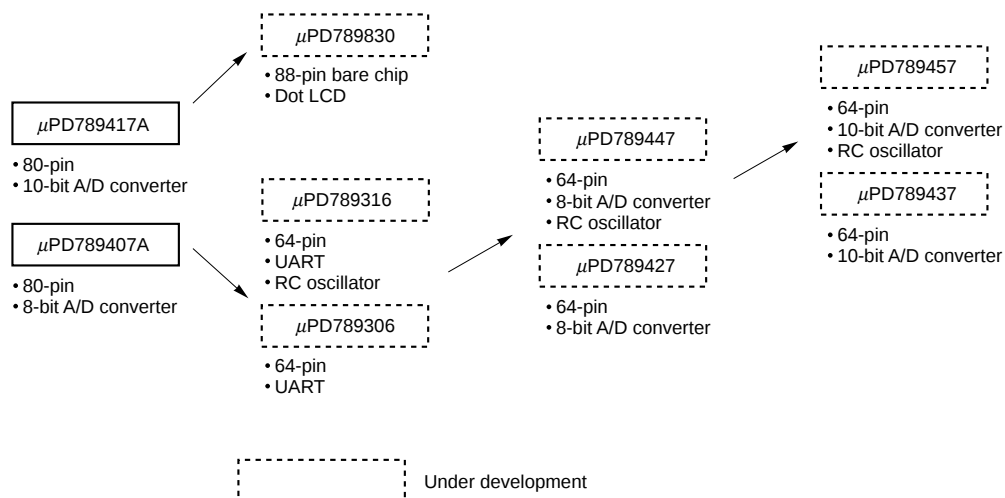
■ 78K/0S Series Product Evolution

Subseries names are shown inside frames.

Small-scale general purpose



LCD driver



8-Bit Single-Chip Microcontroller

78K/0S Series

■ Differences among the Subseries

Function Subseries name		ROM capacity	Timer				8-bit A/D	10-bit A/D	Serial interface	I/O	V _{DD} MIN. value	Remark
			8-bit	16-bit	Watch	WDT						
Small-scale general-purpose	μPD789046	16K	1 ch	1 ch	1 ch	1 ch	—	—	1 ch (UART: 1 ch)	34	1.8 V	—
	μPD789026	4K to 16K			—							
	μPD789014	2K to 4K	2 ch	—						22		
Small-scale general-purpose + A/D	μPD789177	16K to 24K	3 ch	1 ch	1 ch	1 ch	—	8 ch	1 ch (UART: 1 ch)	31	1.8 V	—
	μPD789167						8 ch	—				
	μPD789134A	2K to 8K	1 ch		—		—	4 ch		20		RC oscillation
	μPD789124A						4 ch	—				
	μPD789114A						—	4 ch				—
	μPD789104A						4 ch	—				
Inverter controller	μPD789842	8K to 16K	3 ch	*	1 ch	1 ch	8 ch	—	1 ch (UART: 1 ch)	30	4.0 V	—
LCD driver	μPD789417A	12K to 24K	3 ch	1 ch	1 ch	1 ch	—	7 ch	1 ch (UART: 1 ch)	43	1.8 V	—
	μPD789407A						7 ch	—				
	μPD789457	16K to 24K	2 ch				—	4 ch	2 ch (UART: 1 ch)	25	1.8 V	RC oscillation
	μPD789447						4 ch	—				
	μPD789437						—	4 ch				—
	μPD789427						4 ch	—				
	μPD789316	8K to 16K					—					RC oscillation
	μPD789306											—
	μPD789830	24K	1 ch							30	2.7 V	
For PC	μPD789800	8K	2 ch	1 ch	—	1 ch	—	—	2 ch (USB: 1 ch)	31	4.0 V	—

※: 10-bit timer 1 channel

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Small-Scale General-Purpose (μ PD789014 Subseries)

Part number			μ PD789011	μ PD789012	μ PD78P9014
Number of basic instructions			48		
Minimum instruction execution time			0.4 μ s (5.0 MHz)		
Instruction cycle			Selectable from 0.4 μ s and 1.6 μ s (5.0 MHz)		
Internal memory	ROM	Size (bytes)	2K	4K	8K (PROM)
	RAM	Size (bytes)	128		256
Address space			64K bytes		
Interrupt function		External	3		
		Internal	7		
I/O pin	CMOS I/O		22		
Timer			8-bit timer/event counter $\times$ 2 channels Watchdog timer $\times$ 1 channel		
Timer output			2		
Serial interface			3-wire/UART mode (selectable): 1 channel		
Standby function			STOP/HALT		
Operating power supply voltage range			V_{DD} = 1.8 to 5.5 V		
Package			• 28-pin plastic shrink DIP (400 mil) • 28-pin plastic SOP (375 mil)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Remote control, game machines, etc.		

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Small-Scale General-Purpose (μ PD789026 Subseries)

Part number			μ PD789022	μ PD789024	μ PD789025	μ PD789026	μ PD78F9026A*
Number of basic instructions			48				
Minimum instruction execution time			0.4 μ s (5.0 MHz)				
Instruction cycle			Selectable from 0.4 μ s and 1.6 μ s (5.0 MHz)				
Internal memory	ROM	Size (bytes)	4K	8K	12K	16K	16K (Flash memory)
	RAM	Size (bytes)	256		512		
Address space			64K bytes				
Interrupt function		External	4				
		Internal	6				
I/O pin	CMOS I/O		34				
Timer			16-bit timer counter $\times$ 1 channel 8-bit timer/event counter $\times$ 1 channel Watchdog timer $\times$ 1 channel				
Timer output			2				
Serial interface			3-wire/UART mode (selectable): 1 channel				
Standby function			STOP/HALT				
Operating power supply voltage range			V_{DD} = 1.8 to 5.5 V				
Package			• 42-pin plastic shrink DIP (600 mil) • 44-pin plastic QFP (10 $\times$ 10 mm)				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			Compact household appliances, car accessories, air-conditioners, games, etc.				

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Small-Scale General-Purpose (μ PD789046 Subseries)

Part number			μ PD789046	μ PD78F9046★
Number of basic instructions			48	
Minimum instruction execution time			0.4 μ s	
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s and 1.6 μ s (5.0 MHz)	
	When subsystem clock is selected		122 μ s (32.768 kHz)	
Internal memory	ROM	Size (bytes)	16K	16K (Flash memory)
	RAM	Size (bytes)	512	
Address space			64K bytes	
Interrupt function		External	4	
		Internal	8	
I/O pin	CMOS I/O		34	
Timer			16-bit timer counter $\times$ 1 channel 8-bit timer/event counter $\times$ 1 channel Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel	
Timer output			2	
Serial interface			3-wire/UART mode (selectable): 1 channel	
Standby function			STOP/HALT	
Operating power supply voltage range			V_{DD} = 1.8 to 5.5 V	
Package			• 44-pin plastic QFP (10 $\times$ 10 mm, resin thickness 2.7 mm) • 44-pin plastic QFP (10 $\times$ 10 mm, resin thickness 1.4 mm)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			Cordless phones, etc.	

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Small-Scale General-Purpose + A/D (μ PD789104A, 789114A Subseries)

Subseries name			μ PD789104A Subseries			μ PD789114A Subseries			
Part number			μ PD789101A*	μ PD789102A*	μ PD789104A*	μ PD789111A*	μ PD789112A*	μ PD789114A*	μ PD78F9116A*
Number of basic instructions			48						
Minimum instruction execution time			0.4 μ s (5.0 MHz)						
Instruction cycle			Selectable from 0.4 μ s and 1.6 μ s (5.0 MHz)						
System clock			Ceramic oscillator						
Internal memory	ROM	Size (bytes)	2K	4K	8K	2K	4K	8K	16K (Flash memory)
	RAM	Size (bytes)	256						
Address space			64K bytes						
Interrupt function		External	3						
		Internal	7						
Multiplier			$8 \times 8 = 16$ bits						
I/O pin	CMOS input		4						
	CMOS I/O		12						
	N-ch open-drain I/O		4						
Timer			16-bit timer counter $\times$ 1 channel 8-bit timer/event counter $\times$ 1 channel Watchdog timer $\times$ 1 channel						
Timer output			2						
Serial interface			3-wire/UART mode (selectable): 1 channel						
A/D converter			8-bit resolution $\times$ 4 channels			10-bit resolution $\times$ 4 channels			
Standby function			STOP/HALT						
Operating power supply voltage range			$V_{DD} = 1.8$ to 5.5 V						
Package			• 28-pin plastic shrink DIP (400 mil) • 30-pin plastic shrink SOP (300 mil)						
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator						
Applications			Cleaners, washing machines, refrigerators, etc.						

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Small-Scale General-Purpose + A/D (μ PD789124A, 789134A Subseries)

Subseries name			μ PD789124A Subseries			μ PD789134A Subseries			
Part number			μ PD789121A*	μ PD789122A*	μ PD789124A*	μ PD789131A*	μ PD789132A*	μ PD789134A*	μ PD78F9136A*
Number of basic instructions			48						
Minimum instruction execution time			0.5 μ s (4.0 MHz)						
Instruction cycle			Selectable from 0.5 μ s and 2.0 μ s (4.0 MHz)						
System clock			RC oscillator						
Internal memory	ROM	Size (bytes)	2K	4K	8K	2K	4K	8K	16K (Flash memory)
	RAM	Size (bytes)	256						
Address space			64K bytes						
Interrupt function		External	3						
		Internal	7						
Multiplier			$8 \times 8 = 16$ bits						
I/O pin	CMOS input		4						
	CMOS I/O		12						
	N-ch open-drain I/O		4						
Timer			16-bit timer counter $\times 1$ channel 8-bit timer/event counter $\times 1$ channel Watchdog timer $\times 1$ channel						
Timer output			2						
Serial interface			3-wire serial I/O mode/UART mode (selectable): 1 channel						
A/D converter			8-bit resolution $\times 4$ channels			10-bit resolution $\times 4$ channels			
Standby function			STOP/HALT						
Operating power supply voltage range			$V_{DD} = 1.8$ to 5.5 V						
Package			• 28-pin plastic shrink DIP (400 mil) • 30-pin plastic shrink SOP (300 mil)						
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator						
Applications			Battery chargers, etc.						

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Small-Scale General-Purpose + A/D (μ PD789167, 789177 Subseries)

Subseries name			μPD789167 Subseries		μPD789177 Subseries		
Part number			μPD789166*	μPD789167*	μPD789176*	μPD789177*	μPD78F9177*
Number of basic instructions			48				
Minimum instruction execution time			0.4 μs (5.0 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs and 1.6 μs (5.0 MHz)				
	When subsystem clock is selected		122 μs (32.768 kHz)				
System clock			Ceramic oscillator				
Internal memory	ROM	Size (bytes)	16K	24K	16K	24K	24K (Flash memory)
	RAM	Size (bytes)	512				
Address space			64K bytes				
Interrupt function		External	4				
		Internal	11				
Multiplier			8 × 8 =16 bits				
I/O pin	CMOS input		8				
	CMOS I/O		17				
	N-ch open-drain I/O		6				
Timer			16-bit timer counter × 1 channel 8-bit timer counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel				
Timer output			4				
Serial interface			3-wire/UART mode (selectable): 1 channel				
A/D converter			8-bit resolution × 8 channels		10-bit resolution × 8 channels		
Standby function			STOP/HALT				
Operating power supply voltage range			V _{DD} = 1.8 to 5.5 V				
Package			44-pin plastic QFP (10 × 10 mm)				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			Power windows, keyless entries, battery management units, side air bags, etc.				

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ LCD Driver (μ PD789306, 789316 Subseries)

Subseries name			μPD789306 Subseries			μPD789316 Subseries		
Part number			μPD789304★		μPD789306★	μPD789314★		μPD789316★
Number of basic instructions			48					
Minimum instruction execution time			0.4 μs (5.0 MHz)			0.5 μs (4.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs and 1.6 μs (5.0 MHz)			Selectable from 0.5 μs and 2.0 μs (4.0 MHz)		
	When subsystem clock is selected		122 μs (32.768 kHz)					
Resonator	Main		Ceramic/crystal 1 to 5 MHz			RC oscillator 2 to 4 MHz		
	Sub		Crystal 32.768 kHz					
Internal memory	ROM	Size (bytes)	8K	16K		8K		16K
	RAM	Size (bytes)	256					
	LCD data RAM	Size (bytes)	20					
Address space			64K bytes					
Interrupt function		External	4					
		Internal	10					
I/O pin	CMOS input		4					
	CMOS I/O		17					
	N-ch open-drain I/O		4					
Timer			16-bit timer counter × 1 channel 8-bit timer counter × 1 channel 8-bit timer/event counter × 1 channel Watch timer × 1 channel Watchdog timer × 1 channel					
Timer output			3					
Serial interface			3-wire/UART mode (selectable): 1 channel 3-wire: 1 channel					
LCD controller/driver			Segment signal outputs: 20 maximum Common signal outputs: 4 maximum Bias: 1/3, on-chip booster					
Standby function			STOP/HALT					
Operating power supply voltage range			V _{DD} = 1.8 to 5.5 V					
Package			• 64-pin plastic QFP (14 × 14 mm) • 64-pin plastic TQFP (fine pitch) (12 × 12 mm)					
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Remote controller, etc.					

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ LCD Driver (μ PD789407A, 789417A Subseries)

Subseries name			μPD789407A Subseries			μPD789417A Subseries			
Part number			μPD789405A	μPD789406A	μPD789407A	μPD789415A	μPD789416A	μPD789417A	μPD78F9418A*
Number of basic instructions			48						
Minimum instruction execution time			0.4 μs (5.0 MHz)						
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs and 1.6 μs (5.0 MHz)						
	When subsystem clock is selected		122 μs (32.768 kHz)						
Internal memory	ROM	Size (bytes)	12K	16K	24K	12K	16K	24K	32K (Flash memory)
	RAM	Size (bytes)	512						
	LCD data RAM	Size (bytes)	28						
Address space			64K bytes						
Interrupt function		External	5						
		Internal	12						
I/O pin	CMOS input		7						
	CMOS I/O		32						
	N-ch open-drain I/O		4						
Timer			16-bit timer counter × 1 channel 8-bit timer counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel						
Timer output			2						
Serial interface			3-wire/UART mode (selectable): 1 channel						
A/D converter			8-bit resolution × 7 channels			10-bit resolution × 7 channels			
LCD controller/driver			Segment signal outputs: 28 maximum Common signal outputs: 4 maximum Bias: 1/2 or 1/3 (switchable)						
Standby function			STOP/HALT						
Operating power supply voltage range			V _{DD} = 1.8 to 5.5 V						
Package			• 80-pin plastic QFP (14 × 14 mm) • 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.05 mm) • 80-pin plastic TQFP (fine pitch) (12 × 12 mm, resin thickness 1.0 mm)						
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator						
Applications			APS compact cameras, etc.						

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ LCD Driver (μ PD789427, 789437 Subseries)

Subseries name			μPD789427 Subseries		μPD789437 Subseries		
Part number			μPD789426★	μPD789427★	μPD789436★	μPD789437★	μPD78F9437★
Number of basic instructions			48				
Minimum instruction execution time			0.4 μs (5.0 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs and 1.6 μs (5.0 MHz)				
	When subsystem clock is selected		122 μs (32.768 kHz)				
Resonator	Main		Ceramic/crystal 1 to 5 MHz				
	Sub		Crystal 32.768 kHz				
Internal memory	ROM	Size (bytes)	16K	24K	16K	24K	24K (Flash memory)
	RAM	Size (bytes)	512				
	LCD data RAM	Size (bytes)	20				
Address space			64K bytes				
Interrupt function		External	4				
		Internal	10				
I/O pin	CMOS input		4				
	CMOS I/O		17				
	N-ch open-drain I/O		4				
Timer			16-bit timer counter × 1 channel 8-bit timer counter × 1 channel 8-bit timer/event counter × 1 channel Watch timer × 1 channel Watchdog timer × 1 channel				
Timer output			3				
Serial interface			3-wire/UART mode (selectable): 1 channel 3-wire: 1 channel				
A/D converter			8-bit resolution × 4 channels		10-bit resolution × 4 channels		
LCD controller/driver			Segment signal outputs: 20 maximum Common signal outputs: 4 maximum Bias: 1/3, on-chip booster				
Standby function			STOP/HALT				
Operating power supply voltage range			V _{DD} = 1.8 to 5.5 V				
Package			• 64-pin plastic QFP (14 × 14 mm) • 64-pin plastic TQFP (fine pitch) (12 × 12 mm)				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			Portable audio, etc.				

*: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ LCD Driver (μ PD789447, 789457 Subseries)

Subseries name			μ PD789447 Subseries		μ PD789457 Subseries		
Part number			μ PD789446 [★]	μ PD789447 [★]	μ PD789456 [★]	μ PD789457 [★]	μ PD78F9457 [★]
Number of basic instructions			48				
Minimum instruction execution time			0.5 μ s (4.0 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.5 μ s and 2.0 μ s (4.0 MHz)				
	When subsystem clock is selected		122 μ s (32.768 kHz)				
Resonator	Main		RC oscillator 2 to 4 MHz				
	Sub		Crystal 32.768 kHz				
Internal memory	ROM	Size (bytes)	16K	24K	16K	24K	24K (Flash memory)
	RAM	Size (bytes)	512				
	LCD data RAM	Size (bytes)	20				
Address space			64K bytes				
Interrupt function		External	4				
		Internal	10				
I/O pin	CMOS input		4				
	CMOS I/O		17				
	N-ch open-drain I/O		4				
Timer			16-bit timer counter $\times$ 1 channel 8-bit timer counter $\times$ 1 channel 8-bit timer/event counter $\times$ 1 channel Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel				
Timer output			3				
Serial interface			3-wire/UART mode (selectable): 1 channel 3-wire: 1 channel				
A/D converter			8-bit resolution $\times$ 4 channels		10-bit resolution $\times$ 4 channels		
LCD controller/driver			Segment signal outputs: 20 maximum Common signal outputs: 4 maximum Bias: 1/3, on-chip booster				
Standby function			STOP/HALT				
Operating power supply voltage range			V _{DD} = 1.8 to 5.5 V				
Package			• 64-pin plastic QFP (14 $\times$ 14 mm) • 64-pin plastic TQFP (fine pitch) (12 $\times$ 12 mm)				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			Portable audio, etc.				

*: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ LCD Driver (μ PD789830 Subseries)

Part number			μ PD789830 [★]	μ PD78F9831 [★]
Number of basic instructions			48	
Minimum instruction execution time			0.4 μ s	
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s and 1.6 μ s (5.0 MHz)	
	When subsystem clock is selected		122 μ s (32.768 kHz)	
Internal memory	ROM	Size (bytes)	24K	48K (Flash memory)
	RAM	Size (bytes)	1024	2048
	LCD data RAM	Size (bytes)	80	
Address space			64K bytes	
Interrupt function		External	3	5
		Internal	11	
I/O pin	CMOS I/O		30	38
Timer			16-bit timer counter $\times$ 1 channel 8-bit timer counter $\times$ 1 channel Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel	
Timer output			2	
Serial interface			UART: 1 channel	
LCD controller/driver			Segment signal outputs: 40 maximum Common signal outputs: 16 maximum	
Standby function			STOP/HALT	
Operating power supply voltage range			V_{DD} = 2.7 to 5.5 V	
Delivery form			88-pin bare chip	100-pin plastic LQFP (14 $\times$ 14 mm)
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			Card readers, etc.	

★: Under development

8-Bit Single-Chip Microcontroller

78K/0S Series

■ For PC (μ PD789800 Subseries)

Part number			μ PD789800	μ PD78F9801
Number of basic instructions			48	
Minimum instruction execution time			0.33 μ s (6.0 MHz)	
Instruction cycle			Selectable from 0.33 μ s and 1.33 μ s (6.0 MHz)	
Internal memory	ROM	Size (bytes)	8K	16K (Flash memory)
	RAM	Size (bytes)	256	
Address space			64K bytes	
Interrupt function		External	2	
		Internal	10	
I/O pin	CMOS I/O		31 (18 ports of the above CMOS I/O ports can be switched to N-ch open-drain I/O ports)	
Timer			8-bit timer $\times$ 1 channel 8-bit timer/event counter $\times$ 1 channel Watchdog timer $\times$ 1 channel	
Serial interface			USB (Universal Serial Bus): 1 channel 3-wire: 1 channel	
Regulator			Incorporated ($V_{\text{REG}} = 3.3 \pm 0.3$ V)	
Standby function			STOP/HALT	
Operating power supply voltage range			$V_{\text{DD}} = 4.0$ to 5.5 V	
Operating ambient temperature			$T_{\text{A}} = -40$ to $+85^{\circ}\text{C}$ (When the USB is not operating) $T_{\text{A}} = 0$ to 70°C (When the USB is operating)	
Package			• 42-pin plastic shrink DIP (600 mil) • 44-pin plastic QFP (10 $\times$ 10 mm, resin thickness 2.7 mm) • 44-pin plastic QFP (10 $\times$ 10 mm, resin thickness 1.4 mm)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			USB keyboards, etc.	

8-Bit Single-Chip Microcontroller

78K/0S Series

■ Inverter Controller (μ PD789842 Subseries)

Part number			μ PD789841★	μ PD789842★	μ PD78F9842★
Number of basic instructions			48		
Minimum instruction execution time			0.24 μ s (8.38 MHz)		
Instruction cycle			Selectable from 0.24 μ s and 0.96 μ s (8.38 MHz)		
Internal memory	ROM	Size (bytes)	8K	16K	16K (Flash memory)
	RAM	Size (bytes)	256		
Address space			64K bytes		
Interrupt function		External	2		
		Internal	12		
Multiplier			10 $\times$ 10 = 20 bits		
I/O pin	CMOS input		8		
	CMOS I/O		22		
Timer			10-bit timer for inverter control $\times$ 1 channel 8-bit timer counter $\times$ 1 channel 8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel		
Timer output			7 (Timer output: 1, inverter control output: 6)		
Serial interface			UART: 1 channel		
A/D converter			8 -bit resolution $\times$ 8 channels		
Standby function			STOP/HALT		
Operating power supply voltage range			V_{DD} = 4.0 to 5.5 V		
Package			• 44-pin plastic QFP (10 $\times$ 10 mm, resin thickness 2.7 mm) • 44-pin plastic QFP (10 $\times$ 10 mm, resin thickness 1.4 mm)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Motor control for inverter-type air conditioners, etc.		

★: Under development

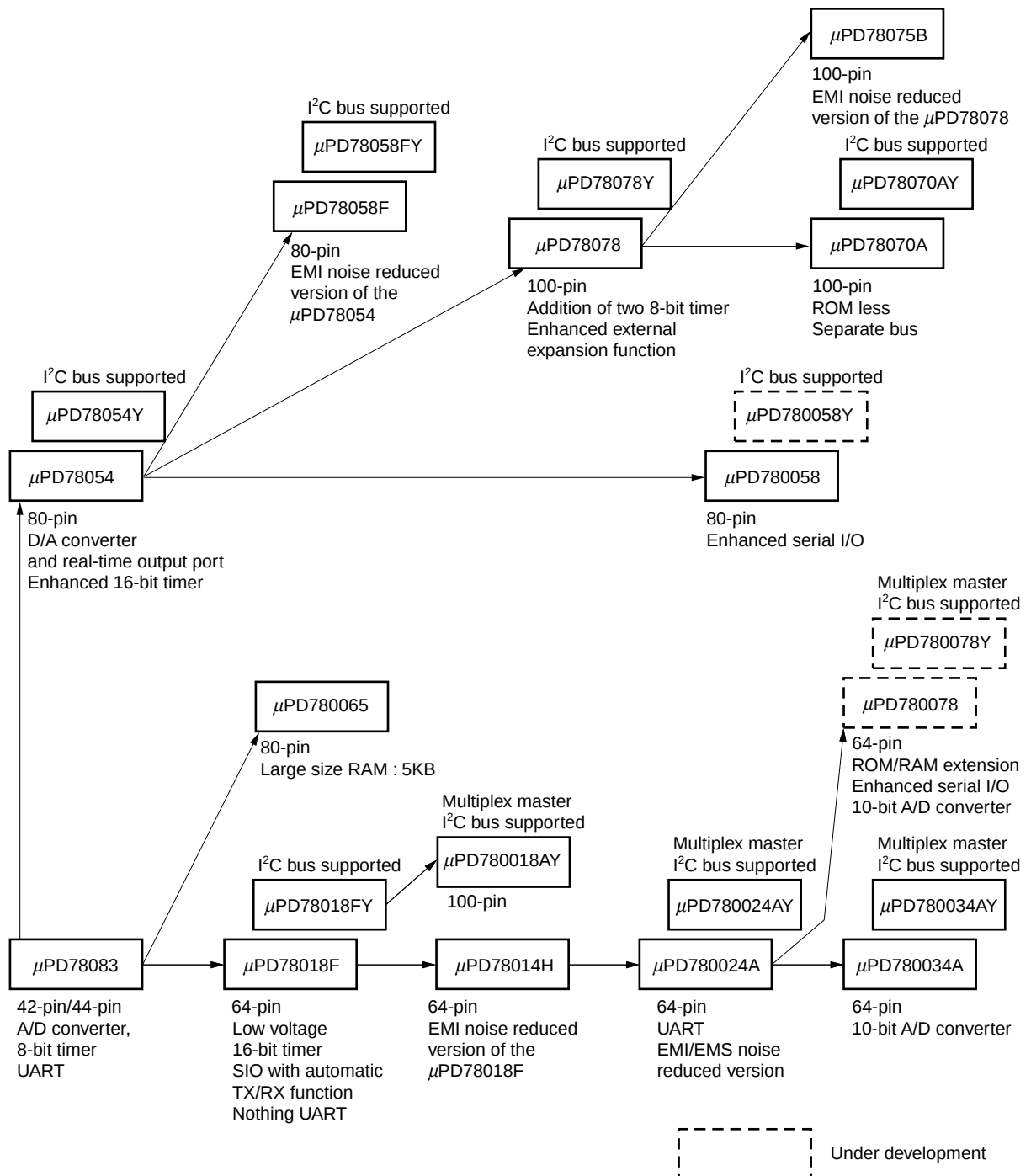
8-Bit Single-Chip Microcontroller

78K/0 Series

■ 78K/0 Series Product Evolution (1/3)

Subseries names are shown inside frames.

Controller series



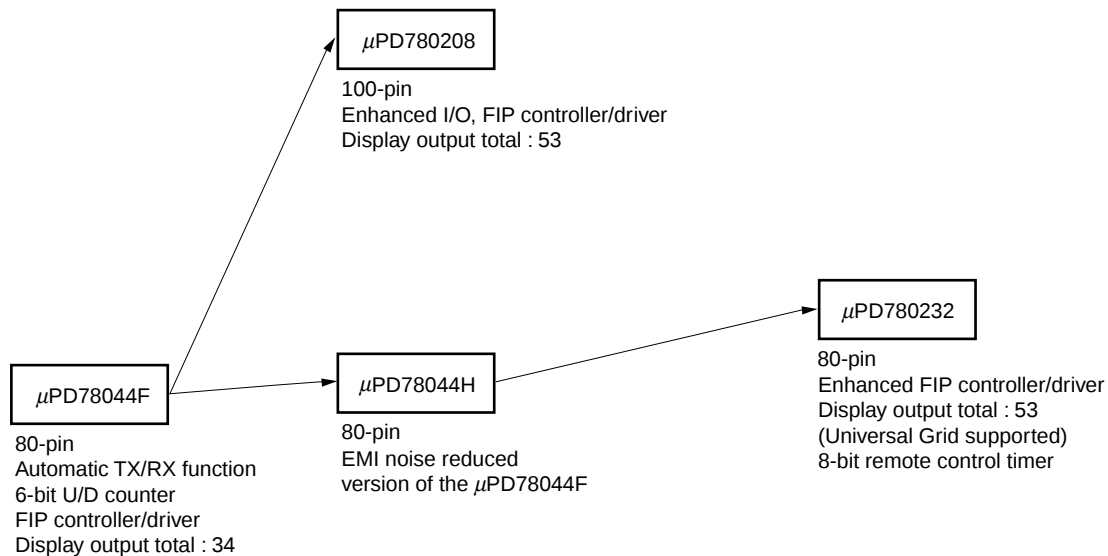
8-Bit Single-Chip Microcontroller

78K/0 Series

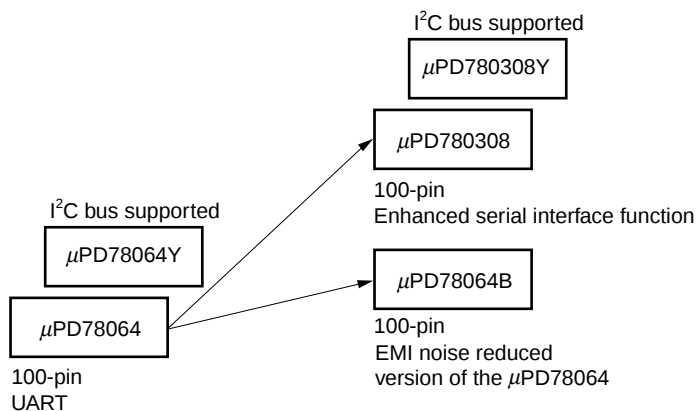
■ 78K/0 Series Product Evolution (2/3)

Subseries names are shown inside frames.

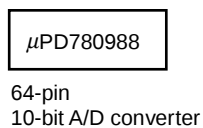
FIP™ drive series



LCD drive series



Inverter controller series



8-Bit Single-Chip Microcontroller

78K/0 Series

■ 78K/0 Series Product Evolution (3/3)

Subseries names are shown inside frames.

Call ID series

μ PD780841

80-pin
Call ID decoder
Simple DTMF

Super low power consumption (meter controller) series

μ PD780955

80-pin
Consumption current
When operating : $3.4\ \mu\text{A}$ typical
When HALT : $1.1\ \mu\text{A}$ typical

μ PD780958

100-pin
Consumption current
When operating : $200\ \mu\text{A}$ typical (1.0 MHz)
When operating : $4.5\ \mu\text{A}$ typical 32.768 kHz)
When HALT : $2\ \mu\text{A}$ typical 32.768 kHz)

Dashboard controller series

μ PD780973

80-pin
Meter controller/driver

Bus controller series

μ PD78098B

80-pin
IEBus controller

μ PD780701Y

80-pin
(μ PD780701Y : DCAN controller
 μ PD780702Y : IEBus controller
 μ PD78F0701Y : DCAN/IEBus controller)

μ PD780833Y

80-pin
J1850 (CLASS2) controller

μ PD780948

100-pin
DCAN controller

Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Differences among the Subseries (1/2)

Function Subseries name		ROM capacity	Timer				8-bit A/D	10-bit A/D	8-bit D/A	Serial interface	I/O	V _{DD} MIN. value	External expansion																																		
			8-bit	16-bit	Watch	WDT																																									
Controller	μPD78075B	32K to 40K	4 ch	1 ch	1 ch	1 ch	8 ch	—	2 ch	3 ch (UART: 1 ch)	88	1.8 V	√																																		
	μPD78078	48K to 60K	2 ch	1 ch	1 ch	8 ch	—	2 ch	3 ch (UART: 1 ch, I ² C: 1 ch)	61	2.7 V																																				
	μPD78078Y								3 ch (UART: 1 ch)																																						
	μPD78070A	—							3 ch (UART: 1 ch, I ² C: 1 ch)																																						
	μPD78070AY								3 ch (UART: 1 ch, I ² C: 1 ch)																																						
	μPD780018AY	48K to 60K							2 ch			1 ch		1 ch	8 ch	—	3 ch (I ² C: 1 ch)	88	1.8 V																												
	μPD780058	24K to 60K															3 ch (time-division UART: 1 ch)	68																													
	μPD780058Y	48K to 60K															3 ch (time-division UART: 1 ch, I ² C: 1 ch)	69		2.7 V																											
	μPD78058F																3 ch (UART: 1 ch)				2.0 V																										
	μPD78058FY																3 ch (UART: 1 ch, I ² C: 1 ch)																														
	μPD78054																16K to 60K					3 ch (UART: 1 ch)																									
	μPD78054Y																					3 ch (UART: 1 ch, I ² C: 1 ch)																									
	μPD780065																40K to 48K					—	4 ch (UART: 1 ch)	60	2.7 V																						
	μPD780078																48K to 60K							3 ch (UART: 2 ch)	52	1.8 V																					
	μPD780078Y																2 ch							4 ch (UART: 2 ch, I ² C: 1 ch)	51	1.8 V																					
	μPD780034A																							8K to 32K			3 ch (UART: 1 ch, time-division 3-wire: 1 ch)																				
	μPD780024A																							8 ch			—	3 ch (UART: 1 ch, I ² C: 1 ch)																			
	μPD780034AY																											3 ch (UART: 1 ch, I ² C: 1 ch)																			
	μPD780024AY																											8 ch	—	2 ch	53																
	μPD78014H																													8K to 60K	1 ch (UART: 1 ch)	33	4.0 V														
	μPD78018F																																	8K to 16K	—	—	1 ch	—	8 ch	—	3 ch (UART: 2 ch)	47	4.0 V	√			
	μPD78018FY																																														
	μPD78083																																														
Inverter controller	μPD780988												16K to 60K																																3 ch	*	—

*: 16-bit timer 2 channels
 10-bit timer 1 channel

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Differences among the Subseries (2/2)

Function Subseries name		ROM capacity	Timer				8-bit A/D	10-bit A/D	8-bit D/A	Serial interface	I/O	V _{DD} MIN. value	External expansion
			8-bit	16-bit	Watch	WDT							
FIP driver	μPD780208	32K to 60K	2 ch	1 ch	1 ch	1 ch	8 ch	—	—	2 ch	74	2.7 V	—
	μPD780232	16K to 24K	3 ch	—	—		4 ch				40	4.5 V	
	μPD78044H	32K to 48K	2 ch	1 ch	1 ch		8 ch			1 ch	67	2.7 V	
	μPD78044F	16K to 40K								2 ch			
LCD driver	μPD780308	48K to 60K	2 ch	1 ch	1 ch	1 ch	8 ch	—	—	3 ch (time-division UART: 1 ch)	57	2.0 V	—
	μPD780308Y									3 ch (time-division UART: 1 ch, I ² C: 1 ch)			
	μPD78064B	32K								2 ch (UART: 1 ch)			
	μPD78064	16K to 32K											
	μPD78064Y									2 ch (UART: 1 ch, I ² C: 1 ch)			
For Call ID	μPD780841	24K to 32K	2 ch	—	1 ch	1 ch	2 ch	—	—	2 ch (UART: 1 ch)	58	2.7 V	—
On-chip bus controller	μPD780948	60K	2 ch	2 ch	1 ch	1 ch	8 ch	—	—	3 ch (UART: 1 ch)	79	4.0 V	√
	μPD78098B	40K to 60K		1 ch						2 ch	69	2.7 V	—
	μPD780701Y	60K	3 ch	2 ch			16 ch			4 ch (UART: 1 ch, I ² C: 1 ch)	67	3.5 V	
	μPD780833Y	60K	3 ch								65	4.5 V	
Meter controller	μPD780958	40K to 60K	4 ch	2 ch	—	1 ch	—	—	—	2 ch (UART: 1 ch)	69	2.7 V	—
	μPD780955	40K	6 ch	1 ch			1 ch			2 ch (UART: 2 ch)	50	2.2 V	
Dashboard controller	μPD780973	24K to 32K	3 ch	1 ch	1 ch	1 ch	5 ch	—	—	2 ch (UART: 1 ch)	56	4.5 V	—

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78018F Subseries)

Part number			μPD78011F	μPD78012F	μPD78013F	μPD78014F	μPD78015F	μPD78016F	μPD78018F	μPD78P018F	
Number of basic instructions			63								
Minimum instruction execution time			0.4 μs (10.0 MHz)								
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, and 6.4 μs (10.0 MHz)								
	When subsystem clock is selected		122 μs (32.768 kHz)								
Internal memory	ROM	Size (bytes)	8K	16K	24K	32K	40K	48K	60K	60K (PROM)	
	RAM	Size (bytes)	544		1056		1568		2080		
Address space			64K bytes								
Interrupt function		External	4								
		Internal	10								
I/O pin	CMOS input		2								
	CMOS I/O		47								
	N-ch open-drain I/O		4								
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel								
Timer output			3 (PWM output: 1)								
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel								
A/D converter			8-bit resolution × 8 channels								
Others			Clock output function Buzzer output function								
Standby function			STOP/HALT								
Operating power supply voltage range			1.8 to 5.5 V								
Package			• 64-pin plastic shrink DIP (750 mil) • 64-pin plastic QFP (14 × 14 mm, 0.8-mm pitch) • 64-pin plastic LQFP (12 × 12 mm, 0.65-mm pitch)								*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator								
Applications			VCRs, TVs, audio equipments, etc.								

- *: • 64-pin plastic shrink DIP (750 mil)
• 64-pin plastic QFP (14 $\times$ 14 mm, 0.8-mm pitch)
• 64-pin plastic LQFP (12 $\times$ 12 mm, 0.65-mm pitch)
• 64-pin ceramic shrink DIP with window (750 mil)
• 64-pin ceramic WQFN (14 $\times$ 14 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78018FY Subseries)

Part number			μPD78011FY	μPD78012FY	μPD78013FY	μPD78014FY	μPD78015FY	μPD78016FY	μPD78018FY	μPD78P018FY	
Number of basic instructions			63								
Minimum instruction execution time			0.4 μs (10.0 MHz)								
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, and 6.4 μs (10.0 MHz)								
	When subsystem clock is selected		122 μs (32.768 kHz)								
Internal memory	ROM	Size (bytes)	8K	16K	24K	32K	40K	48K	60K	60K (PROM)	
	RAM	Size (bytes)	544		1056		1568		2080		
Address space			64K bytes								
Interrupt function		External	4								
		Internal	10								
I/O pin	CMOS input		2								
	CMOS I/O		47								
	N-ch open-drain I/O		4								
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel								
Timer output			3 (PWM output: 1)								
Serial interface			3-wire/2-wire/I ² C bus mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel								
A/D converter			8-bit resolution × 8 channels								
Others			Clock output function Buzzer output function								
Standby function			STOP/HALT								
Operating power supply voltage range			1.8 to 5.5 V								
Package			• 64-pin plastic shrink DIP (750 mil) • 64-pin plastic QFP (14 × 14 mm, 0.8-mm pitch) • 64-pin plastic LQFP (12 × 12 mm, 0.65-mm pitch) (except μPD78013FY, 78015FY, 78016FY)								*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator								
Applications			VCRs, TVs, audio equipments, etc.								

- *: • 64-pin plastic shrink DIP (750 mil)
• 64-pin plastic QFP (14 $\times$ 14 mm, 0.8-mm pitch)
• 64-pin plastic LQFP (12 $\times$ 12 mm, 0.65-mm pitch)
• 64-pin ceramic shrink DIP with window (750 mil)
• 64-pin ceramic WQFN (14 $\times$ 14 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78014H Subseries)

Part number			μPD78011H	μPD78012H	μPD78013H	μPD78014H
Number of basic instructions			63			
Minimum instruction execution time			0.4 μs (10.0 MHz)			
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, and 6.4 μs (10.0 MHz)			
	When subsystem clock is selected		122 μs (32.768 kHz)			
Internal memory	ROM	Size (bytes)	8K	16K	24K	32K
	RAM	Size (bytes)	544		1056	
Address space			64K bytes			
Interrupt function		External	4			
		Internal	10			
I/O pin	CMOS input		2			
	CMOS I/O		47			
	N-ch open-drain I/O		4			
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel			
Timer output			3 (PWM output: 1)			
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel			
A/D converter			8-bit resolution × 8 channels			
Others			Clock output function Buzzer output function			
Standby function			STOP/HALT			
Operating power supply voltage range			1.8 to 5.5 V			
Package			• 64-pin plastic shrink DIP (750 mil) • 64-pin plastic QFP (14 × 14 mm, 0.8-mm pitch) • 64-pin plastic LQFP (12 × 12 mm, 0.65-mm pitch)			
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator			
Applications			Cellular phones, VCRs, audio equipments, cameras, home appliances, etc.			

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780024A, 780034A Subseries)

Part number			μ PD780021A μ PD780031A	μ PD780022A μ PD780032A	μ PD780023A μ PD780033A	μ PD780024A μ PD780034A	μ PD78F0034A
Number of basic instructions			63				
Minimum instruction execution time			0.24 μ s (8.38 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.24 μ s, 0.48 μ s, 0.95 μ s, 1.91 μ s, and 3.81 μ s (8.38 MHz)				
	When subsystem clock is selected		122 μ s (32.768 kHz)				
Internal memory	ROM	Size (bytes)	8K	16K	24K	32K	32K (Flash memory)
	RAM	Size (bytes)	512			1024	
Address space			64K bytes				
Interrupt function		External	5				
		Internal	15				
I/O pin	CMOS input		8				
	CMOS I/O		39				
	N-ch open-drain I/O		4				
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel				
Timer output			3 (PWM output: 2)				
Serial interface			3-wire: 2 channels UART: 1 channel				
A/D converter			8-bit resolution $\times$ 8 channels (μ PD780021A, 780022A, 780023A, 780024A) 10-bit resolution $\times$ 8 channels (μ PD780031A, 780032A, 780033A, 780034A, 78F0034A)				
Others			Clock output function Buzzer output function				
Standby function			STOP/HALT				
Operating power supply voltage range			1.8 to 5.5 V				
Package			• 64-pin plastic shirink DIP (750 mil) • 64-pin plastic QFP (14 $\times$ 14 mm, 0.8-mm pitch) • 64-pin plastic LQFP (12 $\times$ 12 mm, 0.65-mm pitch)				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			VCRs, TVs, audio equipments, etc.				

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780024AY, 780034AY Subseries)

Part number			μ PD780021AY μ PD780031AY	μ PD780022AY μ PD780032AY	μ PD780023AY μ PD780033AY	μ PD780024AY μ PD780034AY	μ PD78F0034AY
Number of basic instructions			63				
Minimum instruction execution time			0.24 μ s (8.38 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.24 μ s, 0.48 μ s, 0.95 μ s, 1.91 μ s, and 3.81 μ s (8.38 MHz)				
	When subsystem clock is selected		122 μ s (32.768 kHz)				
Internal memory	ROM	Size (bytes)	8K	16K	24K	32K	32K (Flash memory)
	RAM	Size (bytes)	512		1024		
Address space			64K bytes				
Interrupt function		External	5				
		Internal	15				
I/O pin	CMOS input		8				
	CMOS I/O		39				
	N-ch open-drain I/O		4				
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel				
Timer output			3 (PWM output: 2)				
Serial interface			3-wire: 1 channel UART: 1 channel I ² C bus (supporting multiplex master): 1 channel				
A/D converter			8-bit resolution $\times$ 8 channels (μ PD780021AY, 780022AY, 780023AY, 780024AY) 10-bit resolution $\times$ 8 channels (μ PD780031AY, 780032AY, 780033AY, 780034AY, 78F0034AY)				
Others			Clock output function Buzzer output function				
Standby function			STOP/HALT				
Operating power supply voltage range			1.8 to 5.5 V				
Package			• 64-pin plastic shirink DIP (750 mil) • 64-pin plastic QFP (14 $\times$ 14 mm, 0.8-mm pitch) • 64-pin plastic LQFP (12 $\times$ 12 mm, 0.65-mm pitch)				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			VCRs, TVs, audio equipments, etc.				

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780078, 780078Y Subseries)

Subseries name			μPD780078 Subseries			μPD780078Y Subseries		
Part number			μPD780076★	μPD780078★	μPD78F0078★	μPD780076Y★	μPD780078Y★	μPD78F0078Y★
Number of basic instructions			63					
Minimum instruction execution time			0.24 μs (8.38 MHz)					
Instruction cycle	When main system clock is selected		Selectable from 0.24 μs, 0.48 μs, 0.95 μs, 1.91 μs, and 3.81 μs (8.38 MHz)					
	When subsystem clock is selected		122 μs (32.768 kHz)					
Internal memory	ROM	Size (bytes)	48K	60K	60K (Flash memory)	48K	60K	60K (Flash memory)
	RAM	Size (bytes)	2048					
Address space			64K bytes					
Interrupt function		External	5					
		Internal	15					
I/O pin	CMOS input		8					
	CMOS I/O		40					
	N-ch open-drain I/O		4					
Timer			16-bit timer/event counter × 2 channels 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel					
Timer output			4 (PWM output: 2)					
Serial interface			3-wire/UART mode (selectable): 1 channel UART: 1 channel 3-wire: 1 channel			3-wire/UART mode (selectable): 1 channel UART: 1 channel 3-wire: 1 channel I ² C bus (supporting multiplex master): 1 channel		
A/D converter			10-bit resolution × 8 channels					
Others			Clock output function Buzzer output function					
Standby function			STOP/HALT					
Operating power supply voltage range			V _{DD} = 1.8 to 5.5 V					
Package			• 64-pin plastic QFP (14 × 14 mm, 0.8-mm pitch) • 64-pin plastic LQFP (12 × 12 mm, 0.65-mm pitch)					
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Telephones, AV equipment, automotive electronics, etc.					

*: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780065 Subseries)

Part number			μ PD780065	μ PD78F0066*
Number of basic instructions			63	
Minimum instruction execution time			0.24 μ s (8.38 MHz)	
Instruction cycle	When main system clock is selected		Selectable from 0.24 μ s, 0.48 μ s, 0.96 μ s, 1.92 μ s, 3.84 μ s and 7.68 μ s (8.38 MHz)	
	When subsystem clock is selected		122 μ s (32.768 kHz)	
Internal memory	ROM	Size (bytes)	40K	48K (Flash memory)
	RAM	Size (bytes)	5K	
Address space			64K bytes	
Interrupt function		External	4	
		Internal	13	
I/O pin	CMOS I/O		53	
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel	
Timer output			3 (PWM output: 2)	
Serial interface			3-wire: 1 channel 2-wire: 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel UART: 1 channel	
A/D converter			8-bit resolution $\times$ 8 channels	
Others			Clock output function Buzzer output function	
Standby function			STOP/HALT	
Operating power supply voltage range			V_{DD} = 2.7 to 5.5 V	
Package			80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			Control of audio systems compatible with CD text, etc.	

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78054 Subseries)

Part number			μPD78052	μPD78053	μPD78054	μPD78P054	μPD78055	μPD78056	μPD78058	μPD78P058
Number of basic instructions			63							
Minimum instruction execution time			0.4 μs (5.0 MHz)							
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)							
	When subsystem clock is selected		122 μs (32.768 kHz)							
Internal memory	ROM	Size (bytes)	16K	24K	32K	32K (PROM)	40K	48K	60K	60K (PROM)
	RAM	Size (bytes)	544	1056					2080	
Address space			64K bytes							
Interrupt function		External	7							
		Internal	15							
I/O pin	CMOS input		2							
	CMOS I/O		63							
	N-ch open-drain I/O		4							
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel							
Timer output			3 (PWM output: 1)							
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel							
A/D converter			8-bit resolution × 8 channels							
D/A converter			8-bit resolution × 2 channels							
Others			Clock output function Buzzer output function							
Standby function			STOP/HALT							
Operating power supply voltage range			2.0 to 6.0 V							
Package			• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch) • 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)			*1	• 80-pin plastic QFP (14 × 14 mm) • 80-pin plastic TQFP (12 × 12 mm)			*2
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator							
Applications			Cellular phones, pagers, printers, AV equipments, air conditioners, cameras, PPCs, fuzzy home appliances, vending machines, etc.							

- *1: • 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)
 • 80-pin plastic TQFP (12 $\times$ 12 mm, 0.5-mm pitch)
 • 80-pin ceramic WQFN (14 $\times$ 14 mm)

- *2: • 80-pin plastic QFP (14 $\times$ 14 mm)
 • 80-pin ceramic WQFN (14 $\times$ 14 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78054Y Subseries)

Part number			μPD78052Y	μPD78053Y	μPD78054Y	μPD78055Y	μPD78056Y	μPD78058Y	μPD78P058Y
Number of basic instructions			63						
Minimum instruction execution time			0.4 μs (5.0 MHz)						
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)						
	When subsystem clock is selected		122 μs (32.768 kHz)						
Internal memory	ROM	Size (bytes)	16K	24K	32K	40K	48K	60K	60K (PROM)
	RAM	Size (bytes)	544	1056				2080	
Address space			64K bytes						
Interrupt function		External	7						
		Internal	15						
I/O pin	CMOS input		2						
	CMOS I/O		63						
	N-ch open-drain I/O		4						
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel						
Timer output			3 (PWM output: 1)						
Serial interface			3-wire/I ² C bus/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel						
A/D converter			8-bit resolution × 8 channels						
D/A converter			8-bit resolution × 2 channels						
Others			Clock output function Buzzer output function						
Standby function			STOP/HALT						
Operating power supply voltage range			2.0 to 6.0 V						
Package			• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch) • 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)				• 80-pin plastic QFP (14 × 14 mm)		*1 *2
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator						
Applications			Cellular phones, pagers, printers, AV equipments, air conditioners, cameras, PPCs, fuzzy home appliances, vending machines, etc.						

- *1: • 80-pin plastic QFP (14 $\times$ 14 mm)
 • 80-pin plastic TQFP (12 $\times$ 12 mm)
 *2: • 80-pin plastic QFP (14 $\times$ 14 mm)
 • 80-pin ceramic WQFN (14 $\times$ 14 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78058F Subseries)

Part number			μ PD78056F	μ PD78058F	μ PD78P058F
Number of basic instructions			63		
Minimum instruction execution time			0.4 μ s (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s, 6.4 μ s, and 12.8 μ s (5.0 MHz)		
	When subsystem clock is selected		122 μ s (32.768 kHz)		
Internal memory	ROM	Size (bytes)	48K	60K	60K (PROM)
	RAM	Size (bytes)	1056	2080	
Address space			64K bytes		
Interrupt function		External	7		
		Internal	15		
I/O pin	CMOS input		2		
	CMOS I/O		63		
	N-ch open-drain I/O		4		
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel		
Timer output			3 (PWM output: 1)		
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel		
A/D converter			8-bit resolution $\times$ 8 channels		
D/A converter			8-bit resolution $\times$ 2 channels		
Others			Clock output function Buzzer output function		
Standby function			STOP/HALT		
Operating power supply voltage range			2.7 to 6.0 V		
Package			• 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)	• 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch) • 80-pin plastic TQFP (12 $\times$ 12 mm, 0.5-mm pitch)	• 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Cellular phones, AV equipments, car stereo, cameras, PPCs, etc.		

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78058FY Subseries)

Part number			μPD78056FY	μPD78058FY	μPD78P058FY
Number of basic instructions			63		
Minimum instruction execution time			0.4 μs (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)		
	When subsystem clock is selected		122 μs (32.768 kHz)		
Internal memory	ROM	Size (bytes)	48K	60K	60K (PROM)
	RAM	Size (bytes)	1056	2080	
Address space			64K bytes		
Interrupt function		External	7		
		Internal	15		
I/O pin	CMOS input		2		
	CMOS I/O		63		
	N-ch open-drain I/O		4		
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel		
Timer output			3 (PWM output: 1)		
Serial interface			3-wire/I ² C bus/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel		
A/D converter			8-bit resolution × 8 channels		
D/A converter			8-bit resolution × 2 channels		
Others			Clock output function Buzzer output function		
Standby function			STOP/HALT		
Operating power supply voltage range			2.7 to 6.0 V		
Package			• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch)	• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch) • 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)	• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch)
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Cellular phones, AV equipments, car stereo, cameras, PPCs, etc.		

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780058 Subseries)

Part number			μPD780053	μPD780054	μPD780055	μPD780056	μPD780058	μPD78F0058*
Number of basic instructions			63					
Minimum instruction execution time			0.4 μs (5.0 MHz)					
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)					
	When subsystem clock is selected		122 μs (32.768 kHz)					
Internal memory	ROM	Size (bytes)	24K	32K	40K	48K	60K	60K (Flash memory)
	RAM	Size (bytes)	1056				2080	
Address space			64K bytes					
Interrupt function		External	7					
		Internal	15					
I/O pin	CMOS input		2					
	CMOS I/O		62					
	N-ch open-drain I/O		4					
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel					
Timer output			3 (PWM output: 1)					
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (with time-division transmission function) (selectable): 1 channel					
A/D converter			8-bit resolution × 8 channels					
D/A converter			8-bit resolution × 2 channels					
Others			Clock output function Buzzer output function					
Standby function			STOP/HALT					
Operating power supply voltage range			1.8 to 5.5 V					
Package			• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch) • 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)					
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Cellular phones, pagers, printers, AV equipments, air conditioners, cameras, PPCs, fuzzy home appliances, vending machines, etc.					

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780058Y Subseries)

Part number			μPD780053Y*	μPD780054Y*	μPD780055Y*	μPD780056Y*	μPD780058Y*	μPD78F0058Y*
Number of basic instructions			63					
Minimum instruction execution time			0.4 μs (5.0 MHz)					
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)					
	When subsystem clock is selected		122 μs (32.768 kHz)					
Internal memory	ROM	Size (bytes)	24K	32K	40K	48K	60K	60K (Flash memory)
	RAM	Size (bytes)	1056				2080	
Address space			64K bytes					
Interrupt function		External	7					
		Internal	15					
I/O pin	CMOS input		2					
	CMOS I/O		62					
	N-ch open-drain I/O		4					
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel					
Timer output			3 (PWM output: 1)					
Serial interface			3-wire/I ² C bus/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (with time-division transmission function) (selectable): 1 channel					
A/D converter			8-bit resolution × 8 channels					
D/A converter			8-bit resolution × 2 channels					
Others			Clock output function Buzzer output function					
Standby function			STOP/HALT					
Operating power supply voltage range			1.8 to 5.5 V					
Package			• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch) • 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)					
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Cellular phones, pagers, printers, AV equipments, air conditioners, cameras, PPCs, fuzzy home appliances, vending machines, etc.					

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD780018AY Subseries)

Part number			μ PD780016AY	μ PD780018AY	μ PD78P0018AY
Number of basic instructions			63		
Minimum instruction execution time			0.4 μ s (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s, and 6.4 μ s (5.0 MHz)		
	When subsystem clock is selected		122 μ s (32.768 kHz)		
Internal memory	ROM	Size (bytes)	48K	60K	60K (PROM)
	RAM	Size (bytes)	2080		
Address space			64K bytes		
Interrupt function		External	7		
		Internal	13		
I/O pin	CMOS input		9		
	CMOS I/O		79		
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 4 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel		
Timer output			5 (PWM output: 3)		
Serial interface			3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire (with time-division transmission function): 1 channel I ² C bus (supporting multiplex master): 1 channel		
A/D converter			8-bit resolution $\times$ 8 channels		
Others			Clock output function Buzzer output function		
Standby function			Main STOP/Sub STOP/HALT		
Operating power supply voltage range			2.7 to 5.5 V		
Package			• 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)		*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Mini-component stereo systems, car stereos, etc.		

*: • 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)
• 100-pin ceramic WQFN (14 $\times$ 20 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78075B, 78078 Subseries)

Subseries name			μ PD78075B Subseries		μ PD78078 Subseries		
Part number			μ PD78074B	μ PD78075B	μ PD78076	μ PD78078	μ PD78P078
Number of basic instructions			63				
Minimum instruction execution time			0.4 μ s (5.0 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s, 6.4 μ s, and 12.8 μ s (5.0 MHz)				
	When subsystem clock is selected		122 μ s (32.768 kHz)				
Internal memory	ROM	Size (bytes)	32K	40K	48K	60K	60K (PROM)
	RAM	Size (bytes)	1056		2080		
Address space			64K bytes				
Interrupt function		External	7				
		Internal	17				
I/O pin	CMOS input		2				
	CMOS I/O		78				
	N-ch open-drain I/O		8				
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 4 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel				
Timer output			5 (PWM output: 3)				
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel				
A/D converter			8-bit resolution $\times$ 8 channels				
D/A converter			8-bit resolution $\times$ 2 channels				
Others			Clock output function Buzzer output function				
Standby function			STOP/HALT				
Operating power supply voltage range			1.8 to 5.5 V				
Package			• 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch) *				
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			Cellular phones, cordless phones, audio equipments, VCRs, printers, etc.				

- *: • 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)
• 100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch)
• 100-pin ceramic WQFN (14 $\times$ 20 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78078Y Subseries)

Part number			μPD78076Y	μPD78078Y	μPD78P078Y
Number of basic instructions			63		
Minimum instruction execution time			0.4 μs (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)		
	When subsystem clock is selected		122 μs (32.768 kHz)		
Internal memory	ROM	Size (bytes)	48K	60K	60K (PROM)
	RAM	Size (bytes)	2080		
Address space			64K bytes		
Interrupt function		External	7		
		Internal	17		
I/O pin	CMOS input		2		
	CMOS I/O		78		
	N-ch open-drain I/O		8		
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 4 channels Watch timer × 1 channel Watchdog timer × 1 channel		
Timer output			5 (PWM output: 3)		
Serial interface			3-wire/2-wire/I ² C bus mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel		
A/D converter			8-bit resolution × 8 channels		
D/A converter			8-bit resolution × 2 channels		
Others			Clock output function Buzzer output function		
Standby function			STOP/HALT		
Operating power supply voltage range			1.8 to 5.5 V		
Package			• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 × 14 mm, 0.5-mm pitch)		*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			VCRs, TVs, audio equipments, etc.		

*: • 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)
• 100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch)
• 100-pin ceramic WQFN (14 $\times$ 20 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78070A, 78070AY)

Part number			μPD78070A	μPD78070AY
Number of basic instructions			63	
Minimum instruction execution time			0.4 μs (5.0 MHz)	
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)	
	When subsystem clock is selected		122 μs (32.768 kHz)	
Internal memory	ROM	Size (bytes)	—	
	RAM	Size (bytes)	1056	
Address space			64K bytes	
Interrupt function		External	7	
		Internal	17	
I/O pin	CMOS input		2	
	CMOS I/O		51	
	N-ch open-drain I/O		8	
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 4 channels Watch timer × 1 channel Watchdog timer × 1 channel	
Timer output			5 (PWM output: 3)	
Serial interface			*1	*2
A/D converter			8-bit resolution × 8 channels	
D/A converter			8-bit resolution × 2 channels	
Others			Clock output function Buzzer output function	
Standby function			STOP/HALT	
Operating power supply voltage range			2.7 to 5.5 V	
Package			• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 × 14 mm, 0.5-mm pitch)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			CD-ROMs, printers, PPCs, etc.	

- *1: • 3-wire/SBI/2-wire mode (selectable): 1 channel
 • 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel
 • 3-wire/UART mode (selectable): 1 channel
- *2: • 3-wire/2-wire/I²C bus mode selectable: 1 channel
 • 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel
 • 3-wire/UART mode (selectable): 1 channel

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Controller Series (μ PD78083 Subseries)

Part number			μ PD78081	μ PD78082	μ PD78P083
Number of basic instructions			63		
Minimum instruction execution time			0.4 μ s (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s, 6.4 μ s and 12.8 μ s (5.0 MHz)		
Internal memory	ROM	Size (bytes)	8K	16K	24K (PROM)
	RAM	Size (bytes)	256	384	512
Address space			64K bytes		
Interrupt function		External	3		
		Internal	10		
I/O pin	CMOS input		1		
	CMOS I/O		32		
Timer			8-bit timer/event counter $\times$ 2 channels Watchdog timer $\times$ 1 channel		
Timer output			2 (PWM output: 2)		
Serial interface			3-wire/UART mode (selectable): 1 channel		
A/D converter			8-bit resolution $\times$ 8 channels		
Others			Clock output function Buzzer output function		
Standby function			STOP/HALT		
Operating power supply voltage range			1.8 to 5.5 V		
Package			• 42-pin plastic shrink DIP (600 mil) • 44-pin plastic QFP (10 $\times$ 10 mm, 0.8-mm pitch)		• 42-pin plastic shrink DIP (600 mil) • 44-pin plastic QFP (10 $\times$ 10 mm, 0.8-mm pitch) • 42-pin ceramic shrink DIP with window (600 mil)
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Automotive electronics, OA equipments, display equipments, air conditioners, keyless entry, etc.		

8-Bit Single-Chip Microcontroller

78K/0 Series

■ FIP Drive Series (μ PD78044F Subseries)

Part number			μ PD78042F	μ PD78043F	μ PD78044F	μ PD78045F	μ PD78P048A
Number of basic instructions			63				
Minimum instruction execution time			0.4 μ s (5.0 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s, and 6.4 μ s (5.0 MHz)				
	When subsystem clock is selected		122 μ s (32.768 kHz)				
Internal memory	ROM	Size (bytes)	16K	24K	32K	40K	60K (PROM)
	RAM	Size (bytes)	624		1136		
Interrupt function		External	4				
		Internal	12				
I/O pin	CMOS input		2				
	CMOS I/O		27				
	N-ch open-drain I/O		5				
	P-ch open-drain I/O		16				
	P-ch open-drain output		18				
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel 6-bit up/down counter $\times$ 1 channel				
Timer output			3 (PWM output: 1)				
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 64 bytes): 1 channel				
A/D converter			8-bit resolution $\times$ 8 channels				
FIP controller/driver			Number of segments: 9 to 24 Number of digits: 2 to 16				
Others			Clock output function Buzzer output function				
Standby function			STOP/HALT				
Operating power supply voltage range			2.7 to 5.5 V				
Package			• 80-pin plastic QFP (14 $\times$ 20 mm, 0.8-mm pitch)				*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			VCRs, audio equipments, microwave ovens, etc.				

*: • 80-pin plastic QFP (14 $\times$ 20 mm, 0.8-mm pitch)
 • 80-pin ceramic WQFN (14 $\times$ 20 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ FIP Drive Series (μ PD78044H Subseries)

Part number			μPD78044H	μPD78045H	μPD78046H
Number of basic instructions			63		
Minimum instruction execution time			0.4 μs (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, and 6.4 μs (5.0 MHz)		
	When subsystem clock is selected		122 μs (32.768 kHz)		
Internal memory	ROM	Size (bytes)	32K	40K	48K
	RAM	Size (bytes)	1136		
Interrupt function		External	4		
		Internal	10		
I/O pin	CMOS input		2		
	CMOS I/O		19		
	N-ch open-drain I/O		13		
	P-ch open-drain I/O		16		
	P-ch open-drain output		18		
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel		
Timer output			3 (PWM output: 1)		
Serial interface			3-wire: 1 channel		
A/D converter			8-bit resolution × 8 channels		
FIP controller/driver			Number of segments: 9 to 24 Number of digits: 2 to 16		
Others			Clock output function Buzzer output function		
Standby function			STOP/HALT		
Operating power supply voltage range			2.7 to 5.5 V		
Package			• 80-pin plastic QFP (14 × 20 mm, 0.8-mm pitch)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Mini-component stereo systems, microwave ovens, ECRs, etc.		

8-Bit Single-Chip Microcontroller

78K/0 Series

■ FIP Drive Series (μ PD780208 Subseries)

Part number			μPD780204	μPD780205	μPD780206	μPD780208	μPD78P0208
Number of basic instructions			63				
Minimum instruction execution time			0.4 μs (5.0 MHz)				
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, and 6.4 μs (5.0 MHz)				
	When subsystem clock is selected		122 μs (32.768 kHz)				
Internal memory	ROM	Size (bytes)	32K	40K	48K	60K	60K (PROM)
	RAM	Size (bytes)	1168		2192		
Interrupt function		External	4				
		Internal	12				
I/O pin	CMOS input		2				
	CMOS I/O		27				
	N-ch open-drain I/O		5				
	P-ch open-drain I/O		24				
	P-ch open-drain output		16				
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel				
Timer output			3 (PWM output: 1)				
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 64 bytes): 1 channel				
A/D converter			8-bit resolution × 8 channels				
FIP controller/driver			Number of segments: 9 to 40 Number of digits: 2 to 16				
Others			Clock output function Buzzer output function				
Standby function			STOP/HALT				
Operating power supply voltage range			2.7 to 5.5 V				
Package			• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch)				*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications			VCRs, audio equipments, microwave ovens, etc.				

- *: • 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)
• 100-pin ceramic WQFN (14 $\times$ 20 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ FIP Drive Series (μ PD780232 Subseries)

Part number			μ PD780232	μ PD78F0233★
Number of basic instructions			63	
Minimum instruction execution time			0.4 μ s (5.0 MHz)	
Instruction cycle			Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s and 6.4 μ s (5.0 MHz)	
Internal memory	ROM	Size (bytes)	16K	24K (Flash memory)
	RAM	Size (bytes)	768	
Interrupt function		External	2	
		Internal	12	
I/O pin	CMOS I/O		11	
	P-ch open-drain I/O		29	
	P-ch open-drain output		24	
Timer			8-bit remote control timer $\times$ 1 channel 8-bit timer $\times$ 2 channels Watchdog timer $\times$ 1 channel	
Timer outupt			3 (PWM output: 2)	
Serial interface			2-wire: 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel	
A/D converter			8-bit resolution $\times$ 4 channels	
FIP controller/driver			Display outputs: 53	
Standby function			STOP/HALT	
Operating power supply voltage range			V _{DD} = 4.5 to 5.5 V	
Package			80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			Combined mini-component stereo systems, separate mini-component stereo systems, tuners, cassette tape decks, compact disc/mini disc players, audio amplifiers, etc.	

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ LCD Drive Series (μ PD78064, 78064B Subseries)

Subseries name			μPD78064 Subseries				μPD78064B Subseries	
Part number			μPD78062	μPD78063	μPD78064	μPD78P064	μPD78064B	μPD78P064B
Number of basic instructions			63					
Minimum instruction execution time			0.4 μs (5.0 MHz)					
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)					
	When subsystem clock is selected		122 μs (32.768 kHz)					
Internal memory	ROM	Size (bytes)	16K	24K	32K	32K (PROM)	32K	32K (PROM)
	RAM	Size (bytes)	532	1044				
Interrupt function		External	6					
		Internal	14					
I/O pin	CMOS input		2					
	CMOS I/O		55					
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel					
Timer output			3 (PWM output: 1)					
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire/UART mode (selectable): 1 channel					
A/D converter			8-bit resolution × 8 channels					
LCD controller/driver			Segment signal outputs: 40 maximum Common signal outputs: 4 maximum Bias: 1/2 or 1/3 (switchable)					
Others			Clock output function Buzzer output function					
Standby function			STOP/HALT					
Operating power supply voltage range			2.0 to 6.0 V					
Package			• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 × 14 mm, 0.5-mm pitch)			*	• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 × 14 mm, 0.5-mm pitch)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Cellular phones, CD players, cameras, etc.					

- *: • 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)
• 100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch)
• 100-pin ceramic WQFN (14 $\times$ 20 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ LCD Drive Series (μ PD78064Y Subseries)

Part number			μ PD78062Y	μ PD78063Y	μ PD78064Y
Number of basic instructions			63		
Minimum instruction execution time			0.4 μ s (5.0 MHz)		
Instruction cycle	When main system clock is selected		Selectable from 0.4 μ s, 0.8 μ s, 1.6 μ s, 3.2 μ s, 6.4 μ s, and 12.8 μ s (5.0 MHz)		
	When subsystem clock is selected		122 μ s (32.768 kHz)		
Internal memory	ROM	Size (bytes)	16K	24K	32K
	RAM	Size (bytes)	532	1044	
Interrupt function		External	6		
		Internal	14		
I/O pin	CMOS input		2		
	CMOS I/O		55		
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel		
Timer output			3 (PWM output: 1)		
Serial interface			3-wire/2-wire/I ² C bus mode (selectable): 1 channel 3-wire/UART mode (selectable): 1 channel		
A/D converter			8-bit resolution $\times$ 8 channels		
LCD controller/driver			Segment signal outputs: 40 maximum Common signal outputs: 4 maximum Bias: 1/2 or 1/3 (switchable)		
Others			Clock output function Buzzer output function		
Standby function			STOP/HALT		
Operating power supply voltage range			2.0 to 6.0 V		
Package			• 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Cellular phones, CD players, cameras, etc.		

8-Bit Single-Chip Microcontroller

78K/0 Series

■ LCD Drive Series (μ PD780308, 780308Y Subseries)

Subseries name			μPD780308 Subseries			μPD780308Y Subseries		
Part number			μPD780306	μPD780308	μPD78P0308*	μPD780306Y	μPD780308Y	μPD78P0308Y*
Number of basic instructions			63					
Minimum instruction execution time			0.4 μs (5.0 MHz)					
Instruction cycle	When main system clock is selected		Selectable from 0.4 μs, 0.8 μs, 1.6 μs, 3.2 μs, 6.4 μs, and 12.8 μs (5.0 MHz)					
	When subsystem clock is selected		122 μs (32.768 kHz)					
Internal memory	ROM	Size (bytes)	48K	60K		48K	60K	60K (PROM)
	RAM	Size (bytes)	2068					
Address space			64K bytes					
Interrupt function		External	6					
		Internal	15					
I/O pin	CMOS input		2					
	CMOS I/O		55					
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel					
Timer output			3 (PWM output: 1)					
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire/UART mode (selectable): 1 channel 3-wire (with time-division transmission function): 1 channel			3-wire/I ² C bus/2-wire mode (selectable): 1 channel 3-wire/UART mode (selectable): 1 channel 3-wire (with time-division transmission function): 1 channel		
A/D converter			8-bit resolution × 8 channels					
LCD controller/driver			Segment signal outputs: 40 maximum Common signal outputs: 4 maximum Bias: 1/2 or 1/3 (switchable)					
Others			Clock output function Buzzer output function					
Standby function			STOP/HALT					
Operating power supply voltage range			2.0 to 5.5 V					
Package			• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 × 14 mm, 0.5-mm pitch)		*	• 100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch) • 100-pin plastic LQFP (14 × 14 mm, 0.5-mm pitch)		*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Cellular phones, pagers, CD players, meters, etc.					

*: • 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)
• 100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch)
• 100-pin ceramic WQFN (14 $\times$ 20 mm)

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Inverter Controller Series (μ PD780988 Subseries)

Part number			μPD780982★	μPD780983★	μPD780984★	μPD780986	μPD780988	μPD78F0988★
Number of basic instructions			63					
Minimum instruction execution time			0.24 μs (8.38 MHz)					
Instruction cycle			Selectable from 0.24 μs, 0.48 μs, 0.95 μs, 1.9 μs and 3.8 μs (8.38 MHz)					
Internal memory	ROM	Size (bytes)	16K	24K	32K	48K	60K	60K (Flash memory)
	RAM	Size (bytes)	1024			2048		
Address space			64K bytes					
Interrupt function		External	8					
		Internal	16					
I/O pin	CMOS input		8					
	CMOS I/O		39					
Timer			10-bit timer for inverter control × 1 channel 16-bit timer/event counter × 2 channels 8-bit timer/event counter × 3 channels Watchdog timer × 1 channel					
Timer output			11 (PWM output: 3, inverter control output: 6)					
Serial interface			3-wire: 1 channel UART: 2 channels					
A/D converter			10-bit resolution × 8 channels					
Others			Real-time output port					
Standby function			STOP/HALT					
Operating power supply voltage range			V _{DD} = 4.0 to 5.5 V					
Package			64-pin plastic shrink DIP (750 mil) 64-pin plastic QFP (14 × 14 mm, 0.8 mm pitch)					
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator					
Applications			Motor control for inverter-type air conditioners, washing machines, etc.					

*: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Call ID Series (μ PD780841 Subseries)

Part number			μ PD780840 [★]	μ PD780841 [★]	μ PD78F0841 [★]
Number of basic instructions			63		
Instruction cycle	When main system clock is selected		0.56 μ s (3.58 MHz)		
	When subsystem clock is selected		122 μ s (32.768 kHz)		
Internal memory	ROM	Size (bytes)	24K	32K	32K (Flash memory)
	RAM	Size (bytes)	1024		
Address space			64K bytes		
Interrupt function		External	5		
		Internal	8		
I/O pin	CMOS input		2		
	CMOS I/O		55		
	N-ch open-drain I/O		4		
Timer			8-bit timer/event counter $\times$ 2 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel		
Timer output			2 (PWM output: 2)		
Serial interface			3-wire: 1 channel 3-wire/UART mode (selectable): 1 channel		
A/D converter			8-bit resolution $\times$ 2 channels		
Others			Call ID decoder function Simple DTMF function		
Standby function			STOP/HALT		
Operating power supply voltage range			V_{DD} = 2.7 to 5.5 V		
Package			80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Cordless phones, etc.		

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Super Low Power Consumption (Meter Controller) Series (μ PD780955)

Part number			μ PD780955*
Number of basic instructions			62
Minimum instruction execution time			52 μ s (38.4 kHz)
Internal memory	ROM	Size (bytes)	40K
	RAM	Size (bytes)	1024
Address space			64K bytes
Interrupt function		External	7
		Internal	10
I/O pin	CMOS I/O		47
	N-ch open drain I/O		3
Timer			16-bit counter $\times$ 1 channel 8-bit timer/event counter $\times$ 1 channel 8-bit timer $\times$ 5 channels Watchdog timer $\times$ 1 channel
Timer output			1
Serial interface			UART: 2 channels
A/D converter			8-bit resolution $\times$ 1 channel
LCD controller			Segment signal outputs: 19 maximum Common signal outputs: 1 Static display mode only
Others			Quality grade: Special (μ PD780955(A)) only (for high reliability electronic equipment)
Standby function			HALT
Operating power supply voltage range			V _{DD} = 2.2 to 3.5 V
Package			80-pin plastic QFP (14 $\times$ 20 mm, 0.8 mm pitch)
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator
Applications			Gas meters, etc.

*: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Super Low Power Consumption (Meter Controller) Series (μ PD780958 Subseries)

Part number			μ PD780957★	μ PD780958★
Number of basic instructions			62	
Minimum instruction execution time			2 μ s (1.0 MHz), 61 μ s (32.768 kHz)	
Internal memory	ROM	Size (bytes)	48K	60K
	RAM	Size (bytes)	2048	
Address space			64K bytes	
Interrupt function		External	7	
		Internal	17	
I/O pin	CMOS I/O		66	
	N-ch open-drain I/O		3	
Timer			16-bit timer/event counter $\times$ 2 channels 8-bit timer $\times$ 4 channels Watchdog timer $\times$ 1 channel	
Timer output			1	
Serial interface			UART: 1 channel 3-wire: 1 channel	
LCD controller/driver			Segment signal outputs: 30 maximum Common signal outputs: 3 maximum Bias: static or 1/3 (switchable)	
Others			MR control function Sampling output function Quality grade: Special (μ PD780957(A), μ PD780958(A)) only (for high reliability electronic equipment)	
Standby function			HALT	
Operating power supply voltage range			V_{DD} = 2.2 to 3.5 V	
Package			100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			Gas meters, etc.	

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Dashboard Controller Series (μ PD780973 Subseries)

Part number			μ PD780973 [★]	μ PD78F0974 [★]
Number of basic instructions			63	
Minimum instruction execution time			0.24 μ s (8.38 MHz)	
Instruction cycle			Selectable from 0.24 μ s, 0.48 μ s, 0.95 μ s, 1.91 μ s, and 3.81 μ s (8.38 MHz)	
Internal memory	ROM	Size (bytes)	24K	32K (Flash memory)
	RAM	Size (bytes)	778	1034
	EEPROM Size (bytes)		256	
Address space			64K bytes	
Interrupt function		External	3	
		Internal	18	
I/O pin	CMOS input		5	
	CMOS Output		16	
	CMOS I/O		35	
Timer			16-bit timer/event counter $\times$ 1 channel 8-bit timer/event counter $\times$ 3 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel	
Timer output			2 (PWM output: 2)	
Serial interface			3-wire: 1 channel UART: 1 channel	
A/D converter			8-bit resolution $\times$ 5 channels	
LCD controller/driver			Segment signal outputs: 20 maximum Common signal outputs: 4 maximum Bias: 1/3	
Sound generator			Buzzer output signal with composed amplitude	
Meter controller/driver			4 meter control (Cross-coil or stepper motor)	
Others			Clock output function	
Standby function			STOP/HALT	
Operating power supply voltage range			4.5 to 5.5 V	
Package			80-pin plastic QFP (14 $\times$ 20 mm, 0.8-mm pitch)	
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator	
Applications			Vehicle meters control (dashboard mounted)	

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■Bus Controller Series (μ PD78098B Subseries)

Part number			μPD78095B	μPD78096B	μPD78098B	μPD78P098B
Number of basic instructions			63			
Minimum instruction execution time			0.4 μs (5.0 MHz)			
Instruction cycle	When main system clock is selected		Selectable from 0.5 μs, 1.0 μs, 2.0 μs, 4.0 μs, 8.0 μs, and 16.0 μs (6.0 MHz)			
	When subsystem clock is selected		122 μs (32.768 kHz)			
Internal memory	ROM	Size (bytes)	40K	48K	60K	60K (PROM)
	RAM	Size (bytes)	1056		3104	
Address space			64K bytes			
Interrupt function		External	7			
		Internal	16			
I/O pin	CMOS input		2			
	CMOS I/O		63			
	N-ch open-drain I/O		4			
Timer			16-bit timer/event counter × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel			
Timer output			3 (PWM output: 1)			
Serial interface			3-wire/SBI/2-wire mode (selectable): 1 channel 3-wire (with function for automatic transmission and reception of up to 32 bytes): 1 channel 3-wire/UART mode (selectable): 1 channel			
A/D converter			8-bit resolution × 8 channels			
D/A converter			8-bit resolution × 2 channels			
IEBus controller			Effective transmission speed: 26 kbps maximum			
Others			Clock output function Buzzer output function			
Standby function			STOP/HALT			
Operating power supply voltage range			2.7 to 5.5 V			
Package			• 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch)			*
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator			
Applications			Car audios, CD changers, etc.			

- *: • 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)
 • 80-pin ceramic WQFN (14 $\times$ 14 mm)

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Bus Controller Series (μ PD780948 Subseries)

Part number			μPD780948★	μPD780949★	μPD78F0948★	μPD78F0949★
Number of basic instructions			63			
Minimum instruction execution time			0.25 μs (8.0 MHz)			
Instruction cycle	When main system clock is selected		Selectable from 0.25 μs, 0.5 μs, 1 μs, 2 μs and 4 μs (8.0 MHz)			
	When subsystem clock is selected		122 μs (32.768 kHz)			
Internal memory	ROM	Size (bytes)	60K		60K (Flash memory)	
	Internal fast RAM	Size (bytes)	1024			
	Internal expansion RAM	Size (bytes)	1024			
	EEPROM	Size (bytes)	—	256	—	256
Address space			64K bytes			
Interrupt function		External	5			
		Internal	24			
I/O pin	CMOS input		8			
	CMOS I/O		71			
Timer			16-bit timer/event counter × 1 channel 16-bit timer × 1 channel 8-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel			
Timer output			4 (16-bit PWM output: 1, 8-bit PWM output: 2)			
Serial interface			3-wire: 1 channel 2-wire: 1 channel UART: 1 channel			
CAN controller			Conformed on CAN protocol Ver. 2.0 (part B), transmission speed: 500 kbps maximum			
A/D converter			8-bit resolution × 8 channels			
LCD controller/driver			Segment signal output: 40 maximum Common signal output: 4 maximum Bias: 1/3 bias			
Power fail detect function			Battery voltage detect function			
Sound generator			Buzzer output function (with composed amplitude)			
Standby function			STOP/HALT			
Operating power supply voltage range			V _{DD} = 4.0 to 5.5 V			
Package			100-pin plastic QFP (14 × 20 mm, 0.65 mm pitch)			
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator			
Applications			Control of automotive dashboard and electrical equipment in car body, etc.			

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Bus Controller Series (μ PD780701Y Subseries)

Part number			μ PD780701Y★	μ PD780702Y★	μ PD78F0701Y★
Number of basic instructions			63		
Minimum instruction execution time			0.32 μ s (6.29 MHz)		
Instruction cycle			Selectable from 0.32 μ s, 0.64 μ s, 1.27 μ s, 2.54 μ s, and 5.09 μ s (6.29 MHz)		
Internal memory	ROM	Size (bytes)	60K		60K (Flash memory)
	RAM	Size (bytes)	3350		
Address space			64K bytes		
Interrupt function		External	8		
		Internal	21		
I/O pin	CMOS I/O		56		
	TTL input/CMOS output		8		
	N-ch open-drain I/O		3		
Timer			16-bit timer/event counter $\times$ 2 channels 8-bit timer/event counter $\times$ 3 channels Watch timer $\times$ 1 channel Watchdog timer $\times$ 1 channel		
Timer output			5 (PWM output: 3)		
Serial interface			3-wire: 2 channels UART: 1 channel I ² C bus (supporting multiplex master): 1 channel		
A/D converter			8-bit resolution $\times$ 16 channels		
Power fail detect function			Battery voltage detect function		
Others			Clock output function Buzzer output function		
Bus controller			DCAN controller	IEBus controller	DCAN controller or IEBus controller
Standby function			STOP/HALT		
Operating power supply voltage range			V _{DD} = 3.5 to 5.5 V		
Package			80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Car audio systems, etc.		

★: Under development

8-Bit Single-Chip Microcontroller

78K/0 Series

■ Bus Controller Series (μ PD780833Y Subseries)

Part number			μ PD780831Y*	μ PD780833Y*	μ PD78F0833Y*
Number of basic instructions			63		
Minimum instruction execution time			0.48 μ s (4.19 MHz)		
Instruction cycle			Selectable from 0.48 μ s, 0.96 μ s, 1.92 μ s, 3.84 μ s, and 7.68 μ s (4.19 MHz)		
Internal memory	ROM	Size (bytes)	60K		60K (Flash memory)
	RAM	Size (bytes)	3104		
Address space			64K bytes		
Interrupt function		External	9		
		Internal	20		
I/O pin	CMOS I/O		54		
	TTL input/CMOS output		8		
	N-ch open-drain I/O		3		
Timer			16-bit timer/event counter × 2 channels Watch timer × 1 channel Watchdog timer × 1 channel	16-bit timer/event counter × 2 channels 8-bit timer/event counter × 3 channels Watch timer × 1 channel Watchdog timer × 1 channel	
Timer output			5 (PWM output: 3)		
Serial interface			3-wire: 2 channels UART: 1 channel I ² C bus (supporting multiplex master): 1 channel		
A/D converter			8-bit resolution × 8 channels × 2		
Others			Clock output function		
Bus controller			J1850 (CLASS2) bus interface		
Standby function			STOP/HALT		
Operating power supply voltage range			V _{DD} = 4.5 to 5.5 V		
Package			80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch)		
Development tools			Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications			Car audio systems, etc.		

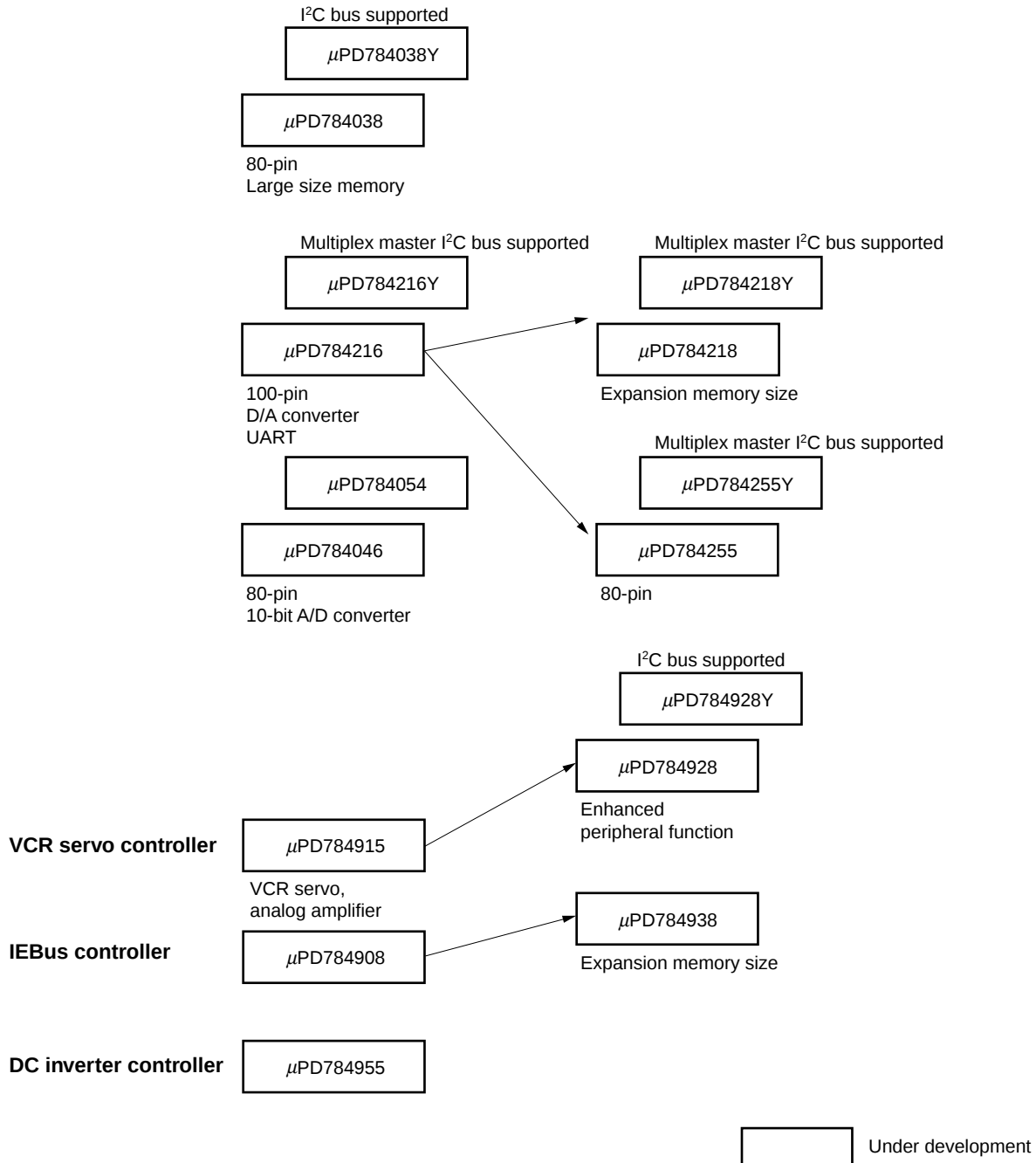
*: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ 78K/IV Series Product Evolution

Subseries names are shown inside frames.



16-Bit Single-Chip Microcontroller

78K/IV Series

■ Differences among the Subseries

Function Subseries name		ROM capacity	Timer				8-bit A/D	10-bit A/D	8-bit D/A	Serial interface	I/O	V _{DD} MIN. value
			8-bit	16-bit	Watch	WDT						
General-purpose	μ PD784225	96K to 128K	4 ch	1 ch	1 ch	1 ch	8 ch	—	2 ch	3 ch (UART: 2 ch)	67	1.8 V
	μ PD784225Y									3 ch (UART: 2 ch, I ² C: 1 ch)		
	μ PD784218	192K to 256K	6 ch							3 ch (UART: 2 ch)	86	2.2 V
	μ PD784218Y									3 ch (UART: 2 ch, I ² C: 1 ch)		
	μ PD784216	96K to 128K								3 ch (UART: 2 ch)		
	μ PD784216Y									3 ch (UART: 2 ch, I ² C: 1 ch)		
	μ PD784054	32K	—	3 ch	—		—	16 ch	—	2 ch (UART: 2 ch)	64	4.5 V
	μ PD784046	32K to 64K		5 ch							65	
	μ PD784038	48K to 128K		4 ch			8 ch	—	2 ch	3 ch (UART: 2 ch)	46/64	2.7 V
	μ PD784038Y									3 ch (UART: 2 ch, I ² C: 1 ch)		
VCR servo controller	μ PD784928	96K to 128K	2 ch	6 ch	—	—	12 ch	—	—	2 ch	74	2.7 V
	μ PD784928Y									3 ch (I ² C: 1 ch)		
	μ PD784915	48K to 62K								2 ch	54	
On-chip IEBus controller	μ PD784938	96K to 256K	—	4 ch	—	1 ch	8 ch	—	—	4 ch (UART: 2 ch)	80	4.0 V
	μ PD784908	96K to 128K										
DC inverter controller	μ PD784955	24K to 64K	2 ch	6 ch	—	1 ch	8 ch	—	—	2 ch (UART: 1 ch)	67	4.5 V

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784038 Subseries)

Part number		μPD784031	μPD784035	μPD784036	μPD784037	μPD784038	μPD78P4038
Number of instructions		113					
Minimum instruction cycle		125 ns (32 MHz)					
Memory expansion function		Total of 1M bytes for both programs and data					
Internal memory	ROM size (bytes)	—	48K	64K	96K	128K	128K (PROM)
	RAM size (bytes)	2K			3.5K	4.25K	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function					
	External source	7					
	Internal source	18					
	Number of interrupts supporting the use of a macro service	19					
	Type of macro service	4 types, 21 kinds					
I/O pin	Input	8					
	Output	4	0				
	I/O	34	56				
Timer/counter		16-bit timer/counter × 3 channels 16-bit timer × 1 channel					
Serial interface		UART/IOE (with on-chip baud rate generator): 2 channels CSI (3-wire/2wire mode): 1 channel					
A/D converter		8-bit resolution × 8 channels					
D/A converter		8-bit resolution × 2 channels					
PWM output		12-bit resolution × 2 channels					
Standby function		HALT/IDLE/STOP mode					
Pseudo-SRAM refresh function		Provided					
Feature		• Large internal memory • Wide operating voltage range (2.7 to 5.5 V) • System clock dividing function (1/2, 1/4, 1/8, 1/16)					
Package		80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch, 2.7-mm thick) 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch, 1.4-mm thick) 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)					*
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator					
Applications		PPCs, LBPs, autofocus cameras, etc.					

- *: • 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch, 2.7-mm thick)
 • 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch, 1.4-mm thick)
 • 80-pin plastic TQFP (12 $\times$ 12 mm, 0.5-mm pitch)
 • 80-pin ceramic WQFN (14 $\times$ 14 mm, 0.65-mm pitch)

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784038Y Subseries)

Part number		μPD784031Y	μPD784035Y	μPD784036Y	μPD784037Y	μPD784038Y	μPD78P4038Y
Number of instructions		113					
Minimum instruction cycle		125 ns (32 MHz)					
Memory expansion function		Total of 1M bytes for both programs and data					
Internal memory	ROM size (bytes)	—	48K	64K	96K	128K	128K (PROM)
	RAM size (bytes)	2K			3.5K	4.25K	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function					
	External source	8					
	Internal source	19					
	Number of interrupts supporting the use of a macro service	20					
	Type of macro service	4 types, 21 kinds					
I/O pin	Input	8					
	Output	4	0				
	I/O	34	56				
Timer/counter		16-bit timer/counter × 3 channels 16-bit timer × 1 channel					
Serial interface		UART/IOE (with on-chip baud rate generator): 2 channels CSI (3-wire/2wire/I ² C bus mode): 1 channel					
A/D converter		8-bit resolution × 8 channels					
D/A converter		8-bit resolution × 2 channels					
PWM output		12-bit resolution × 2 channels					
Standby function		HALT/IDLE/STOP mode					
Pseudo-SRAM refresh function		Provided					
Feature		• Large internal memory • Wide operating voltage range (2.7 to 5.5 V) • System clock dividing function (1/2, 1/4, 1/8, 1/16)					
Package		80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch, 2.7-mm thick) 80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch, 1.4-mm thick) 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)					*
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator					
Applications		Cellular phones, cordless phones, AV equipment, etc.					

- *: • 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch, 2.7-mm thick)
 • 80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch, 1.4-mm thick)
 • 80-pin plastic TQFP (12 $\times$ 12 mm, 0.5-mm pitch)
 • 80-pin ceramic WQFN (14 $\times$ 14 mm, 0.65-mm pitch)

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784046, 784054 Subseries)

Subseries name		μ PD784046 Subseries			μ PD784054 Subseries
Part number		μ PD784044	μ PD784046	μ PD78F4046	μ PD784054
Number of instructions		113			
Minimum instruction cycle		125 ns (32 MHz)			
Memory expansion function		Total of 1M bytes for both programs and data			
Internal memory	ROM size (bytes)	32K	64K	64K (flash memory)	32K
	RAM size (bytes)	1024	2048	2048	1024
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function			
	External source	8			
	Internal source	23			19
	Number of interrupts supporting the use of a macro service	25			21
	Type of macro service	7 types, 27 kinds			7 types, 23 kinds
I/O pin	Input	17			
	Output	0			
	I/O	48			47
Timer/counter		16-bit timer $\times$ 3 channels 16-bit timer/counter $\times$ 2 channels			16-bit timer $\times$ 3
Serial interface		UART/CSI $\times$ 2 channels			
A/D converter		10-bit resolution $\times$ 16 channels			
Standby function		HALT/IDLE/STOP mode			HALT/IDLE/STOP/standby invalidation mode
Feature		On-chip timer unit optimum for real-time control			
Package		80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch, 2.7-mm thick)			
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator			
Applications		Hot water supplier, vending machines, etc.			

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784216 Subseries)

Part number		μ PD784214	μ PD784215	μ PD784216	μ PD78F4216*
Number of instructions		113			
Minimum instruction cycle		160 ns (Main system clock 12.5 MHz)/61 μ s (Subsystem clock 32.768 kHz)			
Memory expansion function		Total of 1M bytes for both programs and data			
Internal memory	ROM size (bytes)	96K	128K	128K	128K (Flash memory)
	RAM size (bytes)	3584	5120	8192	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function			
	External source	9			
	Internal source	20			
	Number of interrupts supporting the use of a macro service	27			
	Type of macro service	4 types, 21kinds			
I/O pin	Input	8			
	I/O	72			
	N-ch open-drain I/O	6			
Timer/counter		16-bit timer/counter $\times$ 1 channel 8-bit timer/counter $\times$ 6 channels			
Real-time output port		4-bit $\times$ 2 ports or 8-bit $\times$ 1 port			
Serial interface		UART/IOE (with dedicated on-chip baud rate generator): 2 channels CSI (3-wire mode): 1 channel			
A/D converter		8-bit resolution $\times$ 8 channels			
D/A converter		8-bit resolution $\times$ 2 channels			
Clock output		Select of f_{xx} , $f_{xx}/2$, $f_{xx}/2^2$, $f_{xx}/2^3$, $f_{xx}/2^4$, $f_{xx}/2^5$, $f_{xx}/2^6$, $f_{xx}/2^7$, f_{XT}			
Buzzer output		Select of $f_{xx}/2^{10}$, $f_{xx}/2^{11}$, $f_{xx}/2^{12}$, $f_{xx}/2^{13}$			
Clock timer		1 channel			
Standby function		HALT/STOP/IDLE mode HALT/IDLE mode at Low power consumption mode (CPU operation using subsystem clock)			
Feature		• Large internal memory • Wide operation voltage range (Mask ROM version: 2.2 to 5.5 V, Flash memory version: 2.7 to 5.5 V) • Using peripheral functions of 78K/0 series			
Package		100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch) 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)			
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator			
Applications		Cellular phones, PHS, cordless phones, CD-ROMs, AV equipment, etc.			

*: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784216Y Subseries)

Part number		μ PD784214Y	μ PD784215Y	μ PD784216Y	μ PD78F4216Y*
Number of instructions		113			
Minimum instruction cycle		160 ns (Main system clock 12.5 MHz)/61 μ s (Subsystem clock 32.768 kHz)			
Memory expansion function		Total of 1M bytes for both programs and data			
Internal memory	ROM size (bytes)	96K	128K	128K	128K (Flash memory)
	RAM size (bytes)	3584	5120	8192	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function			
	External source	9			
	Internal source	20			
	Number of interrupts supporting the use of a macro service	27			
	Type of macro service	4 types, 21kinds			
I/O pin	Input	8			
	I/O	72			
	N-ch open-drain I/O	6			
Timer/counter		16-bit timer/counter $\times$ 1 channel 8-bit timer/counter $\times$ 6 channels			
Real-time output port		4-bit $\times$ 2 ports or 8-bit $\times$ 1 port			
Serial interface		UART/IOE (with dedicated on-chip baud rate generator): 2 channels CSI (3-wire/I ² C bus supporting multiplex master mode): 1 channel			
A/D converter		8-bit resolution $\times$ 8 channels			
D/A converter		8-bit resolution $\times$ 2 channels			
Clock output		Select of f_{xx} , $f_{xx}/2$, $f_{xx}/2^2$, $f_{xx}/2^3$, $f_{xx}/2^4$, $f_{xx}/2^5$, $f_{xx}/2^6$, $f_{xx}/2^7$, f_{XT}			
Buzzer output		Select of $f_{xx}/2^{10}$, $f_{xx}/2^{11}$, $f_{xx}/2^{12}$, $f_{xx}/2^{13}$			
Clock timer		1 channel			
Standby function		HALT/STOP/IDLE mode HALT/IDLE mode at Low power consumption mode (CPU operation using subsystem clock)			
Feature		• Large internal memory • Wide operation voltage range (Mask ROM version: 2.2 to 5.5 V, Flash memory version: 2.7 to 5.5 V) • Using peripheral functions of 78K/0 series			
Package		100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch) 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)			
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator			
Applications		Cellular phones, PHS, cordless phones, CD-ROMs, AV equipment, etc.			

★: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784218 Subseries)

Part number		μ PD784217*	μ PD784218	μ PD78F4218
Number of instructions		113		
Minimum instruction cycle		160 ns (Main system clock 12.5 MHz)/61 μ s (Subsystem clock 32.768 kHz)		
Memory expansion function		Total of 1M bytes for both programs and data		
Internal memory	ROM size (bytes)	192K	256K	256K (Flash memory)
	RAM size (bytes)	12800		
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function		
	External source	9		
	Internal source	20		
	Number of interrupts supporting the use of a macro service	27		
	Type of macro service	4 types, 21 kinds		
I/O pin	Input	8		
	I/O	72		
	N-ch open-drain I/O	6		
Timer/counter		16-bit timer/counter $\times$ 1 channel 8-bit timer/counter $\times$ 6 channels		
Real-time output port		4-bit $\times$ 2 ports or 8-bit $\times$ 1 port		
Serial interface		UART/IOE (with dedicated on-chip baud rate generator): 2 channels CSI (3-wire mode): 1 channel		
A/D converter		8-bit resolution $\times$ 8 channels		
D/A converter		8-bit resolution $\times$ 2 channels		
Clock output		Select of f_{xx} , $f_{xx}/2$, $f_{xx}/2^2$, $f_{xx}/2^3$, $f_{xx}/2^4$, $f_{xx}/2^5$, $f_{xx}/2^6$, $f_{xx}/2^7$, f_{XT}		
Buzzer output		Select of $f_{xx}/2^{10}$, $f_{xx}/2^{11}$, $f_{xx}/2^{12}$, $f_{xx}/2^{13}$		
Clock timer		1 channel		
Standby function		HALT/STOP/IDLE mode HALT/IDLE mode at Low power consumption mode (CPU operation using subsystem clock)		
Feature		• Large internal memory • Wide operation voltage range (Mask ROM version: 2.2 to 5.5 V, Flash memory version: 2.7 to 5.5 V) • Using peripheral functions of 78K/0 series		
Package		100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch) 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)		
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		Cellular phones, PHS, cordless phones, CD-ROMs, AV equipment, etc.		

*: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784218Y Subseries)

Part number		μ PD784217Y★	μ PD784218Y★	μ PD78F4218Y★
Number of instructions		113		
Minimum instruction cycle		160 ns (Main system clock 12.5 MHz)/61 μ s (Subsystem clock 32.768 kHz)		
Memory expansion function		Total of 1M bytes for both programs and data		
Internal memory	ROM size (bytes)	192K	256K	256K (Flash memory)
	RAM size (bytes)	12800		
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function		
	External source	9		
	Internal source	20		
	Number of interrupts supporting the use of a macro service	27		
	Type of macro service	4 types, 21 kinds		
I/O pin	Input	8		
	I/O	72		
	N-ch open-drain I/O	6		
Timer/counter		16-bit timer/counter $\times$ 1 channel 8-bit timer/counter $\times$ 6 channels		
Real-time output port		4-bit $\times$ 2 ports or 8-bit $\times$ 1 port		
Serial interface		UART/IOE (with dedicated on-chip baud rate generator): 2 channels CSI (3-wire/I ² C bus supporting multiplex master mode): 1 channel		
A/D converter		8-bit resolution $\times$ 8 channels		
D/A converter		8-bit resolution $\times$ 2 channels		
Clock output		Select of f_{xx} , $f_{xx}/2$, $f_{xx}/2^2$, $f_{xx}/2^3$, $f_{xx}/2^4$, $f_{xx}/2^5$, $f_{xx}/2^6$, $f_{xx}/2^7$, f_{XT}		
Buzzer output		Select of $f_{xx}/2^{10}$, $f_{xx}/2^{11}$, $f_{xx}/2^{12}$, $f_{xx}/2^{13}$		
Clock timer		1 channel		
Standby function		HALT/STOP/IDLE mode HALT/IDLE mode at Low power consumption mode (CPU operation using subsystem clock)		
Feature		• Large internal memory • Wide operation voltage range (Mask ROM version: 2.2 to 5.5 V, Flash memory version: 2.7 to 5.5 V) • Using peripheral functions of 78K/0 series		
Package		100-pin plastic LQFP (14 $\times$ 14 mm, 0.5-mm pitch) 100-pin plastic QFP (14 $\times$ 20 mm, 0.65-mm pitch)		
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		Cellular phones, PHS, cordless phones, CD-ROMs, AV equipment, etc.		

★: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784225 Subseries)

Part number		μ PD784224 $\star$	μ PD784225 $\star$	μ PD78F4225 $\star$
Number of instructions		113		
Minimum instruction cycle		160 ns (Main system clock 12.5 MHz)/61 μ s (Subsystem clock 32.768 kHz)		
Memory expansion function		Total of 1M bytes for both programs and data		
Internal memory	ROM size (bytes)	96K	128K	128K (Flash memory)
	RAM size (bytes)	3584	4352	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function		
	External source	7		
	Internal source	18		
	Number of interrupts supporting the use of a macro service	23		
	Type of macro service	4 types, 21 kinds		
I/O pin	Input	8		
	I/O	59		
Timer/counter		16-bit timer/counter $\times$ 1 channel 8-bit timer/counter $\times$ 4 channels		
Real-time output port		4-bit $\times$ 2 ports or 8-bit $\times$ 1 port		
Serial interface		UART/IOE (with dedicated on-chip baud rate generator): 2 channels CSI (3-wire mode): 1 channel		
A/D converter		8-bit resolution $\times$ 8 channels		
D/A converter		8-bit resolution $\times$ 2 channels		
Clock output		Select of f_{xx} , $f_{xx}/2$, $f_{xx}/2^2$, $f_{xx}/2^3$, $f_{xx}/2^4$, $f_{xx}/2^5$, $f_{xx}/2^6$, $f_{xx}/2^7$, f_{XT}		
Buzzer output		Select of $f_{xx}/2^{10}$, $f_{xx}/2^{11}$, $f_{xx}/2^{12}$, $f_{xx}/2^{13}$		
Clock timer		1 channel		
Standby function		HALT/STOP/IDLE mode HALT/IDLE mode at Low power consumption mode (CPU operation using subsystem clock)		
Feature		• Large internal memory • Wide operation voltage range (1.8 to 5.5 V) • Using peripheral functions of 78K/0 series		
Package		80-pin plastic QFP (14 $\times$ 14 mm, 0.65-mm pitch) 80-pin plastic TQFP (12 $\times$ 12 mm, 0.5-mm pitch)		
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		Car audio, portable audio, telephones, etc.		

*: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ General-Purpose (μ PD784225Y Subseries)

Part number		μPD784224Y★	μPD784225Y★	μPD78F4225Y★
Number of instructions		113		
Minimum instruction cycle		160 ns (Main system clock 12.5 MHz)/61 μs (Subsystem clock 32.768 kHz)		
Memory expansion function		Total of 1M bytes for both programs and data		
Internal memory	ROM size (bytes)	96K	128K	128K (Flash memory)
	RAM size (bytes)	3584	4352	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function		
	External source	7		
	Internal source	18		
	Number of interrupts supporting the use of a macro service	23		
	Type of macro service	4 types, 21 kinds		
I/O pin	Input	8		
	I/O	59		
Timer/counter		16-bit timer/counter × 1 channel 8-bit timer/counter × 4 channels		
Real-time output port		4-bit × 2 ports or 8-bit × 1 port		
Serial interface		UART/IOE (with dedicated on-chip baud rate generator): 2 channels CSI (3-wire I ² C bus supporting multiplex master mode): 1 channel		
A/D converter		8-bit resolution × 8 channels		
D/A converter		8-bit resolution × 2 channels		
Clock output		Select of f _{xx} , f _{xx} /2, f _{xx} /2 ² , f _{xx} /2 ³ , f _{xx} /2 ⁴ , f _{xx} /2 ⁵ , f _{xx} /2 ⁶ , f _{xx} /2 ⁷ , f _{XT}		
Buzzer output		Select of f _{xx} /2 ¹⁰ , f _{xx} /2 ¹¹ , f _{xx} /2 ¹² , f _{xx} /2 ¹³		
Clock timer		1 channel		
Standby function		HALT/STOP/IDLE mode HALT/IDLE mode at Low power consumption mode (CPU operation using subsystem clock)		
Feature		• Large internal memory • Wide operation voltage range (1.8 to 5.5 V) • Using peripheral functions of 78K/0 series		
Package		80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch) 80-pin plastic TQFP (12 × 12 mm, 0.5-mm pitch)		
Development tools		Assembler, C compiler, real-time OS, system performance analyzer, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		Car audio, portable audio, telephones, etc.		

★: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ VCR Servo Controller (μ PD784915 Subseries)

Part number		μPD784915, 784915A	μPD784915B	μPD784916A	μPD784916B	μPD78P4916
Number of instructions		113				
Minimum instruction cycle		250 ns (Internal clock: 8 MHz)				
Internal memory	ROM size (bytes)	48K		62K		62K (PROM)
	RAM size (bytes)	1280				2048
Interrupt function		4 levels (programmable), vectored interrupt, macro service, vectored interrupt, context switching function				
	External source	9 (including NMI)				
	Internal source	20 (including software interrupts)				
I/O pin	Input	8				
	Output	0				
	I/O	46				
Real-time output port		11 (including pseudo V sync, head amplifier switch, chroma-rotation outputs)				
Super timer unit	Timer/counter	22-bit FRC counter × 1 channel 16-bit timer × 6 channels (including 3 channels for general-purpose timers) 8-bit counter × 2 channels 5-bit UDC counter × 1 channel				
	Special circuit for VCR	V sync separator circuit, H sync separator circuit VISS detection circuit, wide aspect detection circuit Field identification circuit Head amplifier switch/chroma-rotation output circuit				
	PWM output	16-bit resolution × 3 channels (Carrier frequency: 62.5 kHz) 8-bit resolution × 3 channels (Carrier frequency: 62.5 kHz)				
Serial interface		Synchronous serial interface (3-wire): 2 channels (including 1 channel supporting BUSY/STRB control)				
A/D converter		8-bit resolution × 12 channels (Conversion time: 10 μs)				
Analog VCR circuits		CTL amplifier, RECCTL driver (with rewrite capability) CFG amplifier DFG amplifier, DPG comparator, DPFG separator circuit (3-value separator circuit) Reel FG comparator (2 channels) Csync comparator				
Standby function		HALT/STOP mode HALT mode for low power consumption				
Clock function		0.5-second measurement, low voltage operation (VDD = 2.7 V) allowed				
Package		100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch)				
Development tools		Assembler, C compiler, integrated debugger, system simulator, device file, in-circuit emulator				
Applications		VCRs, camcorder, integrated TV-VCR machines, etc.				

16-Bit Single-Chip Microcontroller

78K/IV Series

■ VCR Servo Controller (μPD784928 Subseries)

Part number		μPD784927	μPD784928	μPD78F4928*
Number of instructions		113		
Minimum instruction cycle		250 ns (Internal clock: 8 MHz)		
Internal memory	ROM size (bytes)	96K	128K	128K (Flash memory)
	RAM size (bytes)	2048	3584	
Interrupt function		4 levels (programmable), vectored interrupt, macro service, context switching function		
	External source	9 (including NMI)		
	Internal source	22 (including software interrupts)		
I/O pin	Input	20		
	Output	0		
	I/O	54		
Real-time output port		11 (including pseudo V sync, head amplifier switch, chroma-rotation outputs)		
Super timer unit	Timer/counter	22-bit FRC counter × 1 channel 16-bit timer × 6 channels (including 3 channels for general-purpose timers) 8-bit counter × 2 channels 5-bit UDC counter × 1 channel		
	Special circuit for VCR	V sync separator circuit, H sync separator circuit VSS detection circuit, wide aspect detection circuit Field identification circuit Head amplifier switch/chroma-rotation output circuit		
	PWM output	16-bit resolution × 3 channels (Carrier frequency: 62.5 kHz) 8-bit resolution × 3 channels (Carrier frequency: 62.5 kHz)		
Serial interface		Synchronous serial interface (3-wire): 2 channels (including 1 channel supporting BUSY/STRB control)		
A/D converter		8-bit resolution × 12 channels (Conversion time: 10 μs)		
Analog VCR circuits		CTL amplifier, RECCTL driver (with rewrite capability) CFG amplifier DFG amplifier, DPG amplifier, DPFG separator circuit (3-value separator circuit) Reel FG comparator (2 channels) Csync comparator		
Standby function		HALT/STOP mode Low power consumption mode/HALT mode for low power consumption		
Clock function		0.5-second measurement, low voltage operation (V _{DD} = 2.7 V) allowed		
Package		100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch)		
Development tools		Assembler, C compiler, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		VCRs, camcorder, integrated TV-VCR machines, etc.		

★: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ VCR Servo Controller (μ PD784928Y Subseries)

Part number		μPD784927Y	μPD784928Y	μPD78F4928Y★
Number of instructions		113		
Minimum instruction cycle		250 ns (Internal clock: 8 MHz)		
Internal memory	ROM size (bytes)	96K	128K	128K (Flash memory)
	RAM size (bytes)	2048	3584	
Interrupt function		4 levels (programmable), vectored interrupt, macro service, context switching function		
		External source	9 (including NMI)	
		Internal source	23 (including software interrupts)	
I/O pin	Input	20		
	Output	0		
	I/O	54		
Real-time output port		11 (including pseudo V sync, head amplifier switch, chroma-rotation outputs)		
Super timer unit	Timer/counter	22-bit FRC counter × 1 channel 16-bit timer × 6 channels (including 3 channels for general-purpose timers) 8-bit counter × 2 channels 5-bit UDC counter × 1 channel		
	Special circuit for VCR	V sync separator circuit, H sync separator circuit VISS detection circuit, wide aspect detection circuit Field identification circuit Head amplifier switch/chroma-rotation output circuit		
	PWM output	16-bit resolution × 3 channels (Carrier frequency: 62.5 kHz) 8-bit resolution × 3 channels (Carrier frequency: 62.5 kHz)		
Serial interface		Synchronous serial interface (3-wire): 2 channels (including 1 channel supporting BUSY/STRB control) I ² C bus interface: 1 channel		
A/D converter		8-bit resolution × 12 channels (Conversion time: 10 μs)		
Analog VCR circuits		CTL amplifier, RECCTL driver (with rewrite capability) CFG amplifier DFG amplifier, DPG amplifier, DPFG separator circuit (3-value separator circuit) Reel FG comparator (2 channels) Csync comparator		
Standby function		HALT/STOP mode Low power consumption mode/HALT mode for low power consumption		
Clock function		0.5-second measurement, low voltage operation (V _{DD} = 2.7 V) allowed		
Package		100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch)		
Development tools		Assembler, C compiler, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		VCRs, camcorder, integrated TV-VCR machines, etc.		

*: Under development

16-Bit Single-Chip Microcontroller

78K/IV Series

■ IEBus Controller (μ PD784908 Subseries)

Part number		μPD784907	μPD784908	μPD78P4908
Number of instructions		113		
Minimum instruction cycle		320 ns (6.29 MHz) 160 ns (12.58 MHz)		
Memory expansion function		Total of 1M bytes for both programs and data		
Internal memory	ROM size (bytes)	96K	128K	128K (PROM)
	RAM size (bytes)	3584	4352	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function		
	External source	7		
	Internal source	20		
I/O pin	Input	8		
	I/O	72		
	LED direct drive output	24		
	Transistor direct drive	8		
	N-ch open-drain I/O	4		
Timer/counter		16-bit timer/counter × 4 channels		
Real-time output port		4-bit × 2 ports or 8-bit × 1 port		
IEBus controller		Incorporated (simple version)		
Serial interface		UART/IOE (3-wire): 2 channels CSI (3-wire): 2 channels		
A/D converter		8-bit resolution × 8 channels		
PWM output		12-bit resolution × 2 channels		
Clock output		Select of f _{xx} , f _{xx} /2, f _{xx} /2 ² , f _{xx} /2 ³ , f _{xx} /2 ⁴		
Watchdog timer		1 channel		
Standby function		HALT/STOP/IDLE mode		
Power supply voltage		V _{DD} = 4.0 to 5.5 V (Main clock: f _{xx} = 12.58 MHz, internal system clock = f _{xx} , f _{CYK} = 79 ns) V _{DD} = 3.5 to 5.5 V (Other than above, f _{CYK} = 159 ns)		V _{DD} = 4.5 to 5.5 V (Main clock: f _{xx} = 12.58 MHz, internal system clock = f _{xx} , f _{CYK} = 79 ns) V _{DD} = 4.0 to 5.5 V (Other than above, f _{CYK} = 159 ns)
Package		100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch)		
Development tools		Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator		
Applications		Car audio, etc.		

16-Bit Single-Chip Microcontroller

78K/IV Series

■ IEBus Controller (μ PD784938 Subseries)

Part number		μPD784935	μPD784936	μPD784937★	μPD784938★	μPD78F4938★
Number of instructions		113				
Minimum instruction cycle		320 ns (6.29 MHz) 160 ns (12.58 MHz)				
Memory expansion function		Total of 1M bytes for both programs and data				
Internal memory	ROM size (bytes)	96K	128K	192K	256K	256K (Flash memory)
	RAM size (bytes)	5120	6656	8192	10240	
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function				
	External source	7				
	Internal source	20				
I/O pin	Input	8				
	I/O	72				
	LED direct drive output	24				
	Transistor direct drive	8				
	N-ch open-drain I/O	4				
Timer/counter		16-bit timer/counter × 4 channels				
Real-time output port		4-bit × 2 ports or 8-bit × 1 port				
IEBus controller		Incorporated (simple version)				
Serial interface		UART/IOE (3-wire): 2 channels CSI (3-wire): 2 channels				
A/D converter		8-bit resolution × 8 channels				
PWM output		12-bit resolution × 2 channels				
Clock output		Select of f _{xx} , f _{xx} /2, f _{xx} /2 ² , f _{xx} /2 ³ , f _{xx} /2 ⁴				
Watchdog timer		1 channel				
Standby function		HALT/STOP/IDLE mode				
Package		100-pin plastic QFP (14 × 20 mm, 0.65-mm pitch)				
Development tools		Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator				
Applications		Car audio, etc.				

★: Under development

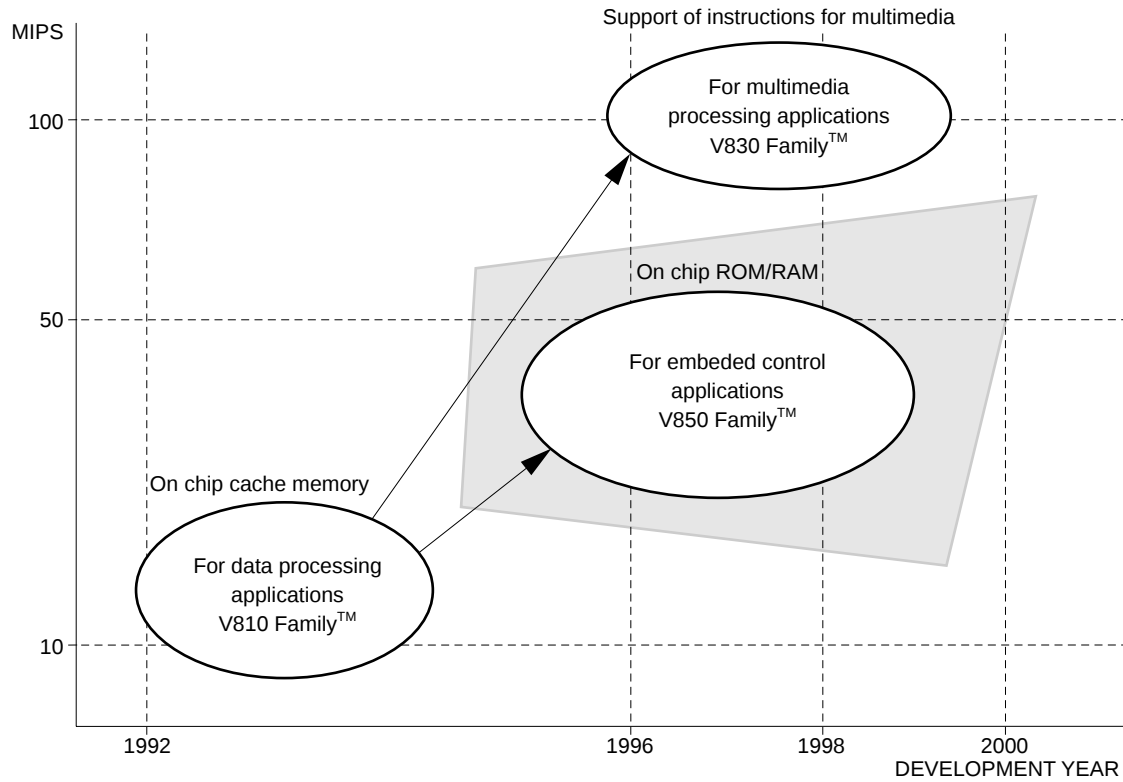
16-Bit Single-Chip Microcontroller

78K/IV Series

■ DC Inverter Controller (μPD784955 Subseries)

Part number		μPD784953★	μPD784955★	μPD78F4956★	
Number of instructions		113			
Minimum instruction cycle		160 ns (Internal 12.5 MHz)			
Internal memory	ROM size (bytes)	24K	48K	64K (Flash memory)	
	RAM size (bytes)	768	2048		
Interrupt function		4-level programmable priority, macro service, vectored interrupt, context switching function			
		External source			8 (Also internal source: 2)
		Internal source			22
I/O pin	Input	8			
	I/O	59			
	Pin with pull-up register	59			
	LED direct drive output	32			
Timer/counter		16-bit timer/counter × 6 channels 8-bit timer/counter × 2 channels			
Serial interface		Synchronous serial interface (3-wire): 1 channel UART: 1 channel			
A/D converter		8-bit resolution × 8 channels			
Watchdog timer		1 channel			
Standby function		HALT/STOP/IDLE mode			
Package		80-pin plastic QFP (14 × 14 mm, 0.65-mm pitch, 1.4-mm thick)			
Development tools		Assembler, C compiler, real-time OS, integrated debugger, system simulator, device file, in-circuit emulator			
Applications		Motor control for inverter air-conditioners, etc.			

★: Under development

32-Bit Microprocessor**V800 Series™****■ V800 Series Road Map**

32-Bit Microprocessor

V810 Family, V830 Family

Part number		μ PD70741	μ PD705101	μ PD705102*
Alias		V821™	V831™	V832™
Performance		16 MIPS/25 MHz	118 MIPS/100 MHz	170 MIPS/143 MHz
Operating frequency		25 MHz	100 MHz	143 MHz
Operating voltage		4.5 to 5.5 V	3.0 to 3.6 V	2.3 to 2.7 V 3.0 to 3.6 V
Power consumption (max.)		500 mW (5 V/25 MHz)	550 mW (3.3 V/100 MHz)	350 mW (2.5 V, 3.3 V/143 MHz)
Address bus		24-bit	24-bit	
Data bus		16-bit	16-/32-bit	
Address space		Internal: 4 G bytes External: 64M bytes (maximum)	Internal: 4 G bytes External: 128M bytes (maximum)	
Cache		Instruction cache: 1K bytes	Instruction cache: 4K bytes, Data cache: 4K bytes	
Internal RAM		—	Instruction RAM: 4K bytes, Data RAM: 4K bytes	
DSP		—	32 bits	
Peripheral I/O	Timer	2 channels	2 channels	
	Interrupt	External: 9, Internal: 11	External: 9, Internal: 11	
	Serial I/O	2 channels	2 channels	
	DMA	2 channels	4 channels	
	Memory interface	Fast page mode DRAM, SRAM, I/O, Page-ROM	EDO DRAM, SRAM, I/O, Page-ROM	SDRAM, SRAM, I/O, Page-ROM
Others		Watchdog timer	Debug controller	
Package		100-pin plastic QFP	160-pin plastic LQFP	
Development tools		Real-time OS	Real-time OS, task debugger, C compiler, system performance analyzer, device file	
Applications		Printers, facsimiles, word processors, game machines, car navigation, PDAs, etc.	Internet/intra-net systems, car navigation, color facsimile machines, high-performance TVs, etc.	Internet/intra-net systems, car navigation, color facsimile machines, digital still cameras, etc.

*: Under development

32-Bit Single-Chip Microcontroller

V850 Family

■ V850E/MS1™

Part number		μ PD703100/ μ PD703100-A*	μ PD703101/ μ PD703101-A*	μ PD703102/ μ PD703102-A*	μ PD70F3102/ μ PD70F3102-A*
CPU core		V850E			
CPU performance (Dhrystone)		—	43 MIPS (33 MHz)		
On-chip ROM (bytes)		—	96K	128K	128K (Flash memory)
On-chip RAM (bytes)		4K			
External bus interface	Address bus	24-bit			
	Data bus	16-bit			
	Programmable wait	0 to 7			
Interrupt controller		External: 25, Internal: 47			
DSP	$32 \times 32 \rightarrow 64$	0.025 to 0.05 μ s (40 MHz)	0.03 to 0.06 μ s (33 MHz)		
	$32 \times 32 + 32 \rightarrow 32$	0.075 μ s (40 MHz)	0.09 μ s (33 MHz)		
	$16 \times 16 \rightarrow 32$	—			
	$16 \times 16 + 32 \rightarrow 32$	—			
Timer/counter (RPU)		16-bit $\times$ 8 channels			
Serial interface (SIO)	CSI	2 channels			
	CSI/I ² C	—			
	CSI/UART	2 channels			
	UART	—			
	Dedicated baud rate generator	3 channels			
A/D converter		10-bit resolution $\times$ 8 channels			
DMA controller		4 channels			
Real-time output port		—			
Port	Input/output	114			
	Input	9			
Other peripheral function		Memory access control function (Direct connectable various memory)			
Power save function		HALT/IDLE/STOP			
Operating frequency		2 to 40 MHz	2 to 33 MHz		
Operating voltage		Internal unit: 3.3 V, A/D converter: 5 V/3.3 V, External pin: 5 V/3.3 V			
Power consumption (TYP.)		570 mW/ 360 mW (40 MHz)	470 mW/300 mW (33 MHz)		
Package		144-pin plastic LQFP (20 $\times$ 20 mm) 157-pin plastic FBGA (14 $\times$ 14 mm)*			
Development tools		Real-time OS, task debugger, C compiler, debugger, system performance analyzer, device file, in-circuit emulator			
Applications		Printers, facsimiles, PPCs, digital still cameras, video printers, DVD systems, etc.			

*: Except μ PD703100, 703101, 703102, 70F3102

★: Under development

32-Bit Single-Chip Microcontroller

V850 Family

■ V850/SA1™

Part number		μ PD703015/ μ PD703015Y	μ PD703017*/ μ PD703017Y*	μ PD70F3017*/ μ PD70F3017Y*
CPU core		V850		
CPU performance (Dhrystone)		19 MIPS (17 MHz)		
On-chip ROM (bytes)		128K	256K	256K (Flash memory)
On-chip RAM (bytes)		4K	8K	
External bus interface	Address bus	22-bit		
	Data bus	16-bit		
	Programmable wait	0 to 3		
Interrupt controller		External: 8, Internal: 23		
DSP	$32 \times 32 \rightarrow 64$	—		
	$32 \times 32 + 32 \rightarrow 32$	—		
	$16 \times 16 \rightarrow 32$	0.059 to 0.118 μ s (17 MHz)		
	$16 \times 16 + 32 \rightarrow 32$	0.177 μ s (17 MHz)		
Timer/counter (RPU)		16-bit $\times$ 2 channels 8-bit $\times$ 4 channels (Cascade connection supported)		
Serial interface (SIO)	CSI	2 channels/1 channel	2 channels/1 channel	2 channels/1 channel
	CSI/I ² C	0 channels/1 channel	0 channels/1 channel	0 channels/1 channel
	CSI/UART	1 channel		
	UART	1 channel		
	Dedicated baud rate generator	2 channels (UART only)		
A/D converter		10-bit resolution $\times$ 12 channels		
DMA controller		3 channels (internal RAM $\longleftrightarrow$ internal peripheral I/O)		
Real-time output port		8-bit $\times$ 1 or 4-bit $\times$ 2		
Port	Input/output	72		
	Input	13		
Other peripheral function		Watch timer: 1 channel Watchdog timer: 1 channel		
Power save function		HALT/IDLE/STOP		
Operating frequency		1 to 17 MHz (main clock, 3 V) 32.768 kHz (subclock)		
Operating voltage		2.7 to 3.6 V		
Power consumption (TYP.)		30 mW (main clock: 10 MHz, 3 V)		
Package		100-pin plastic LQFP (14 $\times$ 14 mm) 121-pin plastic FBGA (12 $\times$ 12 mm)		
Development tools		Real-time OS, task debugger, C compiler, debugger, system performance analyzer, device file, in-circuit emulator		
Applications		Portable equipment such as camcorders, PHS (Personal Handyphone System), digital still cameras, cellular phones, portable MDs, etc.		

★: Under development

32-Bit Single-Chip Microcontroller

V850 Family

■ V850/SB1™, V850/SB2™

Part number		μ PD703033 ^{*/I} μ PD703033Y [*]	μ PD70F3033 ^{*/I} μ PD70F3033Y [*]	μ PD70F3035 ^{*/I} μ PD70F3035Y [*]
Alias		V850/SB1™		V850/SB2™
CPU core		V850		
CPU performance (Dhrystone)		22 MIPS (20 MHz)		
On-chip ROM (bytes)		256K	256K (Flash memory)	
On-chip ROM (bytes)		16K		
External bus interface	Address bus	22-bit		
	Data bus	16-bit		
	Programmable wait	0 to 3		
Interrupt controller		External: 8, Internal: 30 (31 for Y products)		External: 8 Internal: 32 (33 for Y products)
DSP	32 × 32 → 64	—		
	32 × 32 + 32 → 32	—		
	16 × 16 → 32	0.050 to 0.100 μs (20 MHz)		
	16 × 16 + 32 → 32	0.150 μs (20 MHz)		
Timer/counter (RPU)		16-bit × 2 channels 8-bit × 6 channels (Cascade connection supported)		
Serial interface (SIO)	CSI	3 channels/1 channel	3 channels/1 channel	3 channels/1 channel
	CSI/I ² C	0 channels/2 channels	0 channels/2 channels	0 channels/2 channels
	CSI/UART	2 channels		
	UART	—		
	Dedicated baud rate generator	3 channels		
A/D converter		10-bit resolution × 12 channels		
DMA controller		6 channels (internal RAM ↔ internal peripheral I/O)		
Real-time output port		8-bit × 1 or 4-bit × 2		
Port	Input/output	71		
	Input	12		
Other peripheral function		Watch timer: 1 channel Watchdog timer: 1 channel		Watch timer: 1 channel Watchdog timer: 1 channel IEBus (Simple version)
Power save function		HALT/IDLE/STOP		
Operating frequency		2 to 20 MHz (main clock) 32.768 kHz (subclock)		
Operating voltage		4.5 to 5.5 V		
Power consumption (TYP.)		40 mW (target value) (main clock: 5 V, 10 MHz)		
Package		100-pin plastic LQFP (14 × 14 mm) 100-pin plastic QFP (14 × 20 mm)		
Development tools		Real-time OS, task debugger, C compiler, debugger, system performance analyzer, device file, in-circuit emulator		
Applications		AV equipment such as car audio systems, TVs, and VCRs, and other applications		

*: Under development

32-Bit Single-Chip Microcontroller

V850 Family

■ V854™

Part number		μPD703006	μPD703008	μPD703008Y	μPD70F3008*/ μPD70F3008Y*
CPU core		V850			
CPU performance (Dhrystone)		—	29 MIPS (25 MHz)	38 MIPS (33 MHz)	18 MIPS (16 MHz)
On-chip ROM (bytes)		—	128K		128K (Flash memory)
On-chip RAM (bytes)		4K			
External bus interface	Address bus	24-bit			
	Data bus	16-bit			
	Programmable wait	0 to 3			
Interrupt controller		External: 22, Internal: 31			
DSP	32 × 32 → 64	—			
	32 × 32 + 32 → 32	—			
	16 × 16 → 32	0.03 to 0.06 μs (33 MHz)	0.04 to 0.08 μs (25 MHz)	0.03 to 0.06 μs (33 MHz)	0.06 to 0.12 μs (16 MHz)
	16 × 16 + 32 → 32	0.09 μs (33 MHz)	0.12 μs (25 MHz)	0.09 μs (33 MHz)	0.18 μs (16 MHz)
Timer/counter (RPU)		24-bit × 2 channels 16-bit × 6 channels			
Serial interface (SIO)	CSI	3 channels	3 channels	2 channels	3 channels/2 channels
	CSI/I ² C	0 channels	0 channels	1 channel	0 channels/1 channel
	CSI/UART	1 channel			
	UART	—			
	Dedicated baud rate generator	4 channels			
A/D converter		8-bit resolution × 16 channels			
DMA controller		—			
Real-time output port		8			
Port	Input/output	96			
	Input	16			
Other peripheral function		PWM: 4 channels (12 to 16-bit resolution)			
Power save function		HALT/IDLE/STOP			
Operating frequency		2 to 33 MHz (3.3 V)	2 to 25 MHz (3 V)	2 to 33 MHz (3.3 V)	2 to 16 MHz (3.3 V)
Operating voltage		3.0 to 3.6 V	2.7 to 3.6 V	3.0 to 3.6 V	3.1 to 3.6 V
Power consumption (TYP.)		195 mW (3.3 V, 33 MHz)	120 mW (3 V, 25 MHz)	195 mW (3.3 V, 33 MHz)	136 mW (3.3 V, 16 MHz)
Package		144-pin plastic LQFP (20 × 20 mm)			
Development tools		Real-time OS, task debugger, C compiler, debugger, simulator, system performance analyzer, device file, in-circuit emulator			
Applications		Low-voltage-operation equipment including camcorders, VCRs, cellular phones, PDAs, and digital still cameras			

★: Under development

32-Bit Single-Chip Microcontroller

V850 Family

■ V853™

Part number		μPD703003/ μPD703003A★	μPD703004A★	μPD70F3003	μPD70F3003A★	μPD703025A★	μPD70F3025A★
CPU core		V850					
CPU performance (Dhrystone)		38 MIPS (33 MHz)		29 MIPS (25 MHz)	38 MIPS (33 MHz)		
On-chip ROM (bytes)		128K	96K	128K (Flash memory)		256K	256K (Flash memory)
On-chip RAM (bytes)		4K				8K	
External bus interface	Address bus	20-bit					
	Data bus	16-bit					
	Programmable wait	0 to 3					
Interrupt controller		External: 17, Internal: 32					
DSP	32 × 32 → 64	—					
	32 × 32 + 32 → 32	—					
	16 × 16 → 32	0.03 to 0.06 μs (33 MHz)					
	16 × 16 + 32 → 32	0.09 μs (33 MHz)					
Timer/counter (RPU)		16 bit × 5 channels					
Serial interface (SIO)	CSI	2 channels					
	CSI/I ² C	—					
	CSI/UART	2 channels					
	UART	—					
	Dedicated baud rate generator	3 channels					
A/D converter		10-bit resolution × 8 channels					
DMA controller		—					
Real-time output port		—					
Port	Input/output	67					
	Input	8					
Other peripheral function		PWM: 4 ch (8/9/10/12-bit resolution) D/A converter: 2 channels					
Power save function		HALT/IDLE/STOP					
Operating frequency		5 to 33 MHz (5 V)		5 to 25 MHz (5 V)	5 to 33 MHz (5 V)		
Operating voltage		4.5 to 5.5 V		4.75 to 5.25 V	4.5 to 5.5 V		
Power consumption (TYP.)		450 mW/365 mW (5 V, 33 MHz)	365 mW (5 V, 33 MHz)	385 mW (5 V, 25 MHz)	425 mW (5 V, 33 MHz)	450 mW (5 V, 33 MHz)	480 mW (5 V, 33 MHz)
Package		*	100-pin plastic LQFP (14 × 14 mm)	100-pin plastic QFP (14 × 14 mm)	100-pin plastic LQFP (14 × 14 mm)		
Development tools		Real-time OS, task debugger, C compiler, debugger, simulator, system performance analyzer, device file, in-circuit emulator					
Applications		HDDs, PPCs, VCRs, motor control, robots, LBPs, printers, NC machine tools, single-lens reflex cameras, digital still cameras, etc.					

*: • 100-pin plastic QFP (14 $\times$ 14 mm)
• 100-pin plastic LQFP (14 $\times$ 14 mm)

★: Under development

32-Bit Single-Chip Microcontroller

V850 Family

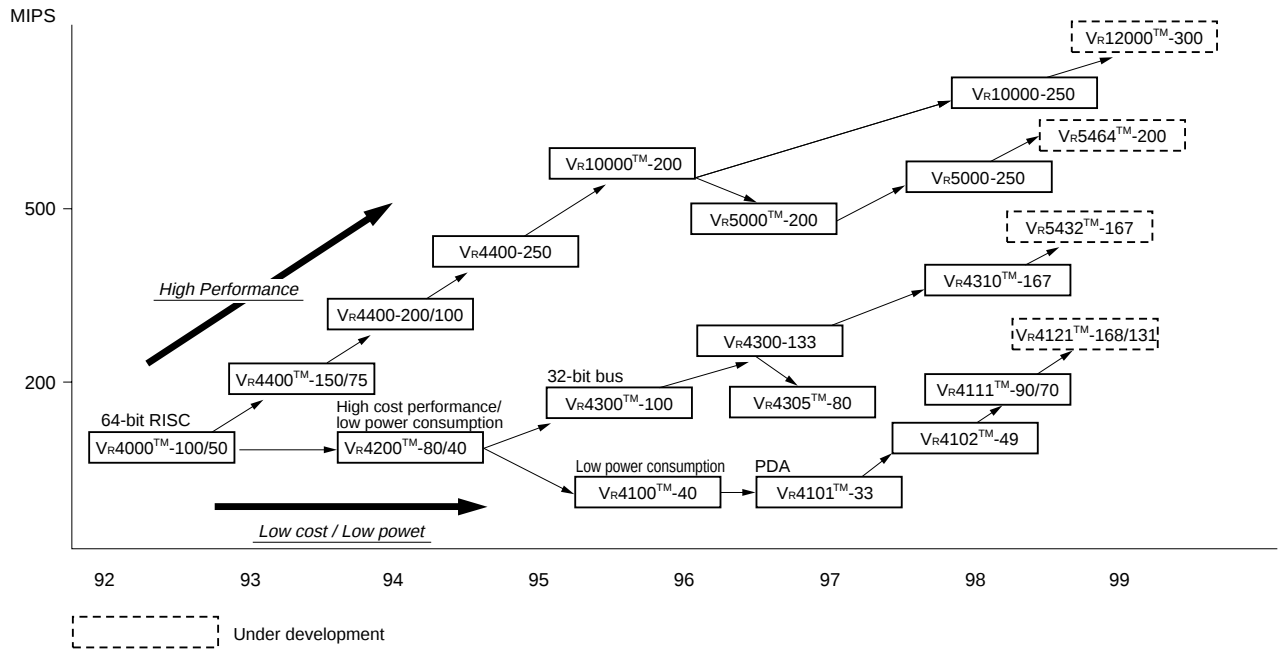
■ V852™

Part number		μPD703002	μPD70P3002
CPU core		V850	
CPU performance (Dhrystone)		29 MIPS (25 MHz)	
On-chip ROM (bytes)		90K	90K (PROM)
On-chip RAM (bytes)		3K	
External bus interface	Address bus	24-bit	
	Data bus	16-bit	
	Programmable wait	0 to 3	
Interrupt controller		External: 9, Internal: 16	
DSP	32 × 32 → 64	—	
	32 × 32 + 32 → 32	—	
	16 × 16 → 32	0.04 to 0.08 μs (25 MHz)	
	16 × 16 + 32 → 32	0.12 μs (25 MHz)	
Timer/counter (RPU)		16-bit × 2 channels	
Serial interface (SIO)	CSI	3 channels	
	CSI/I ² C	—	
	CSI/UART	—	
	UART	1 channel	
	Dedicated baud rate generator	2 channels	
A/D converter		—	
DMA controller		—	
Real-time output port		—	
Port	Input/output	67	
	Input	1	
Other peripheral function		—	
Power save function		HALT/IDLE/STOP	
Operating frequency		3 to 25 MHz (5 V)	
Operating voltage		4.5 to 5.5 V	
Power consumption (TYP.)		250 mW (5 V, 25 MHz)	320 mW (5 V, 25 MHz)
Package		• 100-pin plastic QFP (14 × 14 mm) • 100-pin plastic LQFP (14 × 14 mm)	100-pin plastic QFP (14 × 14 mm)
Development tools		Real-time OS, task debugger, C compiler, debugger, simulator, system performance analyzer, device file, in-circuit emulator	
Applications		HDDs, PPCs, VCRs, motor control, robots, LBPs, printers, NC machine tools, digital phones, engine control, etc.	

64-Bit Microprocessor

Vr Series™

■ Vr Series Road Map



64-Bit Microprocessor

VR Series

■ VR Series Products (1/2)

Part number	μ PD30121★		μ PD30200		μ PD30210	μ PD30500
Alias	VR4121		VR4300	VR4305	VR4310	VR5000
Internal frequency	131 MHz	168 MHz	100 MHz 133 MHz	80 MHz	167 MHz	200 MHz 250 MHz
Operating voltage	External: 3.3 V Internal: 2.5 V		3.3 V			3.3 V
Cache size	Instruction: 16K bytes Data: 8K bytes		Instruction: 16K bytes Data: 8K bytes			Instruction: 32K bytes Data: 32K bytes
Performance	163 MIPS	208 MIPS	177 MIPS 80 SPECint92 60 SPECfp92	106 MIPS 48 SPECint92 36 SPECfp92	222 MIPS 100 SPECint92 75 SPECfp92	391 MIPS 6.8 SPECint95 6.8 SPECfp95
Features	CPU core: VR4120™ On-chip peripheral function ideal for PDAs High-speed processing by 168 MHz operation and 0.25 μ m process rule Low power consumption design		Software compatible with VR4000 Series 32-bit external bus High-speed floating-point operation		Software compatible with VR4300 32-bit external bus High-speed floating-point operation	Two-way superscalar On-chip large primary cache On-chip secondary cache interface
Package	224-pin plastic FBGA		120-pin plastic QFP			272-pin plastic BGA 223-pin ceramic PGA
Applications	PDAs such as handheld PCs and palm-size PCs		Embedded equipment for LBP, and game machines			High-end embedded equipment for color LBPs, network routers, etc

★: Under development

■ VR Series Products (2/2)

Part number	μ PD30540★	μ PD30541★	μ PD30700		μ PD30710
Alias	VR5464	VR5432	VR10000		VR12000
Internal frequency	200 MHz	167 MHz	200 MHz	250 MHz	300 MHz
Operating voltage	External: 3.3 V, Internal: 2.5 V		3.3 V	2.6 V	2.6 V
Cache size	Instruction: 32K bytes Data: 32K bytes		Instruction: 32K bytes Data: 32K bytes		
Performance	309 MIPS 7 SPECint95 4 SPECfp95	258 MIPS 6.6 SPECint95 3.6 SPECfp95	9.0 SPECint95 19.0 SPECfp95	14 SPECint95 23 SPECfp95	16.8 SPECint95 27.8 SPECfp95
Features	Two-way superscalar On-chip large primary cache with line-lock function Hardware debugging function		Five-way superscalar On-chip FPU and MMU On-chip multiprocessor and secondary cache interface		
Package	272-pin plastic BGA	208-pin plastic QFP	599-pin ceramic LGA		
Applications	High-end embedded equipment for color LBPs and STB, etc.		Advanced WSs, servers		

★: Under development

Development Tools

75XL Series Software Tools

■ List of Software Tools

Host machine	Software tool name
PC-9800 Series	Relocatable assembler RA75X
IBM PC/AT™ and compatibles	
PC98-NX Series	IE control program IE75X

■ List of Device Files

Target device	Device file name	Target device	Device file name	Target device	Device file name
μPD750004	DF750008	μPD753036	DF753036	μPD754144	DF754244
μPD750006				μPD754244	
μPD750008					
μPD750104		μPD753104	DF753108	μPD754202	DF754202
μPD750106		μPD753106			
μPD750108		μPD753108			
μPD750064	DF750068	μPD753204	DF753208	μPD754264	DF754264
μPD750066		μPD753206			
μPD750068		μPD753208			
μPD753012A	DF753017	μPD753304	DF753304	μPD754302	DF754304
μPD753016A				μPD754304	
μPD753017A					

Development Tools

75XL Series Hardware Tools

■ Common Hardware Tools

Tool name	Product name
In-circuit emulator	IE-75001-R
Emulation board	IE-75300-R-EM

■ List of Hardware Tools

Target device		Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Device name	Package		
μPD750004	42-pin SDIP (600 mil)	EP-75008CU-R	—
μPD750006	44-pin QFP (10 × 10)	EP-75008GB-R	EV-9200G-44
μPD750008			
μPD750104	42-pin SDIP (600 mil)	EP-75008CU-R	—
μPD750106	44-pin QFP (10 × 10)	EP-75008GB-R	EV-9200G-44
μPD750108			
μPD750064	42-pin SDIP (600 mil)	EP-750068CU-R	—
μPD750066	42-pin SSOP (375 mil)	EP-750068GT-R	EV-9500GT-42
μPD750068			
μPD753012A	80-pin QFP (14 × 14)	EP-753017GC-R	EV-9200GC-80
μPD753016A	80-PIN TQFP (12 × 12)	EP-753017GK-R	TGK-080SDW*
μPD753017A			
μPD753036	80-pin QFP (14 × 14)	EP-75336GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)	EP-75336GK-R	TGK-080SDW*
μPD753104	64-pin QFP (14 × 14)	EP-753108GC-R	EV-9200GC-64
μPD753106	64-pin LQFP (12 × 12)	EP-753108GK-R	TGK-064SBW*
μPD753108			
μPD753204	48-pin SSOP (375 mil)	EP-753208GT-R	EV-9500GT-48
μPD753206			
μPD753208			
μPD753304	42-pin SDIP (600 mil) (ES only)	EP-753304DU-R (ES only)	—
μPD754144	20-pin SOP (300 mil)	EP-754144GS-R	EV-9501GS-20
μPD754244	20-pin SSOP (300 mil)		EV-9500GS-20
μPD754264	20-pin SOP (300 mil)		EV-9501GS-20
μPD754202	20-pin SOP (300 mil)	EP-754144GS-R	EV-9501GS-20
	20-pin SSOP (300 mil)		EV-9500GS-20
μPD754302	36-pin SSOP (300 mil)	EP-754304GS-R	EV-9500GS-36
μPD754304			

*: This is a product of Tokyo Eletech Corporation.

Development Tools

17K Series Software Tools

■ List of Software Tools

Host machine	Software tool name
PC-9800 Series	Relocatable assembler RA17K
IBM PC/AT and compatibles	C-like compiler <i>emlC-17K™</i>
PC98-NX Series	Integrated debugger <i>SIMPLEHOST™</i>

■ List of Device Files

Target device	Device file name	Target device	Device file name	Target device	Device file name
μ PD17001	AS17001	μ PD17053	AS17053	μ PD17933A	AS17934
μ PD17003A	AS17003	μ PD17062	AS17062	μ PD17934A	
μ PD17005	AS17005	μ PD17068	AS17068	μ PD17201A	AS17201
μ PD17010	AS17010	μ PD17071	AS17071	μ PD17203A	AS17203
		μ PD17072		μ PD17204	AS17204
		μ PD17073		μ PD17207	AS17207
μ PD17012	AS17012	μ PD17704	AS17707	μ PD17225	AS17225
		μ PD17705		μ PD17226	
		μ PD17707		μ PD17227	
μ PD17015	AS17015	μ PD17708		μ PD17228	
		μ PD17709		μ PD17235★	AS17235★
		μ PD17717		μ PD17236★	
μ PD17016	AS17016	μ PD17718			
μ PD17017		μ PD17719			

★: Under development

Development Tools

17K Series Hardware Tools

■ Common Hardware Tools

Tool name	Product name
In-circuit emulator	IE-17K IE-17K-ET EMU-17K*

*: This is a product of I.C Corporation.

■ List of Hardware Tools (1/2)

Target device		SE board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Device name	Package			
μPD17001	48-pin QFP	SE-17001	EP-17001GH	EV-9200GH-48
μPD17003A	80-pin QFP	SE-17010	EP-17003GF	EV-9200G-80
μPD17005	80-pin QFP	SE-17010	EP-17003GF	EV-9200G-80
μPD17010	80-pin QFP	SE-17010	EP-17003GF	EV-9200G-80
μPD17012	64-pin QFP	SE-17012	EP-17202GF	EV-9200G-64
μPD17015	38-pin SSOP	SE-17015	EP-17K38GT	EV-9500GT-38
μPD17016 μPD17017	80-pin QFP	SE-17010	EP-17003GF	EV-9200G-80
μPD17053	64-pin SDIP	SE-17053	EP-17052CW	—
μPD17062	48-pin SDIP	SE-17002	EP-17002CU	—
	64-pin QFP		EP-17002GC	EV-9200GC-64
μPD17068	100-pin QFP	SE-17008	EP-17068GF	EV-9200GF-100
μPD17071 μPD17072 μPD17073	56-pin QFP	SE-17072	EP-17K56GB -1 (Bend lead package) EP-17K56GB-2 (Inverted lead package)	TGB-056SBW*
	64-pin TQFP		EP-17K64GB	TGB-064SDP*

*: This is a product of Tokyo Eletech Corporation.

Development Tools

17K Series Hardware Tools

■ List of Hardware Tools (2/2)

Target device		SE board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Device name	Package			
μ PD17704 μ PD17705 μ PD17707 μ PD17708 μ PD17709 μ PD17717 μ PD17718 μ PD17719	80-pin QFP	SE-17709	EP-17K80GC	EV-9200GC-80
μ PD17933A μ PD17934A	80-pin QFP	SE-17934	EP-17K80GK	TGB-080SDP*
μ PD17201A	80-pin QFP (14 × 20)	SE-17207	EP-17201GF	EV-9200G-80
μ PD17203A μ PD17204	52-pin QFP (14 × 20)	SE-17204	EP-17203GC	EV-9200G-52
μ PD17207	80-pin QFP (14 × 20)	SE-17207	EP-17201GF	EV-9200G-80
μ PD17225	28-pin SDIP (400 mil)	SE-17225	EP-17K28CT	—
μ PD17226	28-pin SOP (375 mil)		EP-17K28GT	EV-9500GT-28
μ PD17227 μ PD17228	30-pin SSOP (300 mil)		EP-17K30GS*	EV-9500GT-30
μ PD17235*	28-pin SOP (375 mil)	SE-17235*	EP-17K28GT	EV-9500GT-28
μ PD17236*	30-pin SSOP (300 mil)		EP-17K30GS*	EV-9500GT-30

*: This is a product of Tokyo Eletech Corporation.

★: Under development

Development Tools

μPD6133, 6604, 63 Series Software Tools

■ List of Software Tools

Host machine	Product name
PC-9800 Series IBM PC/AT and compatibles PC98-NX Series	Absolute assembler AS6133

178K Series Software Tools

■ List of Device Files

Target device	Device file name	Target device	Device file name	Target device	Device file name
μPD178002	DF178018	μPD178023★	DF178134★	μPD178076★	DF178098
μPD178003		μPD178024★		μPD178078★	
μPD178004A		μPD178046★	DF178048★	μPD178096★	
μPD178006A		μPD178048★		μPD178098★	
μPD178016A					
μPD178018A					

★: Under development

Software tools other than device files are common to the 178K Series and the 78K/0 Series. See **78K/0 Series List of Software Tools** for details.

Development Tools

178K Series Hardware Tools

(1) When using the in-circuit emulator IE-78K0-NS

■ Common Hardware Tools (When using IE-78K0-NS)

Tool name	Product name
In-circuit emulator	IE-78K0-NS
Performance board	IE-78K0-NS-PA*
Power supply unit	IE-70000-MC-PS-B
Interface adapter	IE-70000-98-IF-C for C bus of PC-9800 Series IE-70000-PC-IF-C for ISA bus of PC/AT and compatibles IE-70000-PCI-IF for PCI bus IE-70000-CD-IF-A for PCMCIA socket

★: Under development

■ List of Hardware Tools (When using IE-78K0-NS)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Device name	Package			
μPD178002 μPD178003	80-pin QFP (14 × 14)	IE-178018-NS-EM1	NP-80GC*1	EV-9200GC-80
μPD178004A μPD178006A μPD178016A μPD178018A	80-pin QFP (14 × 14)	IE-178018-NS-EM1	NP-80GC*1	EV-9200GC-80
μPD178023* μPD178024*	80-pin QFP (14 × 20) 80-pin QFP (14 × 14)	IE-178134-NS-EM1*	NP-80GF*1	EV-9200G-80
			NP-80GC*1	EV-9200GC-80
μPD178046* μPD178048*	64-pin SDIP (750 mil) 80-pin TQFP (12 × 12)	IE-178048-NS-EM1*	NP-64CW*1	—
			NP-80GK*1	TGK-080SDW*2
μPD178076* μPD178078*	100-pin QFP (14 × 20)	IE-178098-NS-EM1	NP-100GF*1	EV-9200GF-100
μPD178096* μPD178098*	100-pin QFP (14 × 20)	IE-178098-NS-EM1	NP-100GF*1	EV-9200GF-100

*1: This is a product of Natio Densai Machida Mfg. Co., Ltd.

*2: This is a product of Tokyo Eletech Corporation.

★: Under development

Development Tools

178K Series Hardware Tools

(2) When using the in-circuit emulator IE-78001-R-A

■ Common Hardware Tools (When using IE-78001-R-A)

Tool name	Product name
In-circuit emulator	IE-78001-R-A
Interface adapter	IE-70000-98-IF-C for C bus of PC-9800 Series IE-70000-PC-IF-C for ISA bus of PC/AT and compatibles IE-70000-PCI-IF for PCI bus

■ List of Hardware Tools (When using IE-78001-R-A)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Device name	Package	Emulation probe conversion board		
μ PD178002 μ PD178003	80-pin QFP (14 × 14)	IE-178018-R-EM	EP-78230GC-R	EV-9200GC-80
μ PD178004A μ PD178006A μ PD178016A μ PD178018A	80-pin QFP (14 × 14)	IE-178018-R-EM	EP-78230GC-R	EV-9200GC-80
μ PD178023★	80-pin QFP (14 × 20)	IE-178134-NS-EM1★	EP-78130GF-R	EV-9200G-80
μ PD178024★	80-pin QFP (14 × 14)	IE-78K0-R-EX1	EP-78230GC-R	EV-9200GC-80
μ PD178046★	64-pin SDIP (750 mil)	Not supported. Use IE-78K0-NS for these devices.		
μ PD178048★	80-pin TQFP (12 × 12)			
μ PD178076★ μ PD178078★	100-pin QFP (14 × 20)	IE-178098-NS-EM1 IE-78K0-R-EX1	EP-78064GF-R	EV-9200GF-100
μ PD178096★ μ PD178098★	100-pin QFP (14 × 20)	IE-178098-NS-EM1 IE-78K0-R-EX1	EP-78064GF-R	EV-9200GF-100

★: Under development

Development Tools

78K/0S Series Software Tools

■ List of Software Tools

Host machine	Software tool name
PC-9800 Series IBM PC/AT and compatibles PC98-NX Series	Assembler package RA78K0S
	C compiler CC78K0S
	C library source file CC78K0S-L
	Integrated debugger ID78K0S-NS
	System simulator SM78K0S
	Embedded OS MX78K0S
EWS	Assembler package RA78K0S
	C compiler CC78K0S
	C library source file CC78K0S-L

■ List of Device Files

Subseries name	Device file name	Subseries name	Device file name
μ PD789014	DF789014	μ PD789167★	DF789178
μ PD789026	DF789026	μ PD789177★	
μ PD789046	DF789046	μ PD789407A	DF789418
μ PD789104A★	DF789134	μ PD789417A	
μ PD789114A★		μ PD789800	DF789801
μ PD789124A★		μ PD789830★	DF789831
μ PD789134A★		μ PD789842★	DF789842

★: Under development

Development Tools

78K/0S Series Hardware Tools

■ Common Hardware Tools

Tool name	Product name	
In-circuit emulator	IE-78K0S-NS	
Power supply unit	IE-70000-MC-PS-B	
Interface adapter	IE-70000-98-IF-C	for C bus of PC-9800 Series
	IE-70000-PC-IF-C	for ISA bus of PC/AT and compatibles
	IE-70000-PCI-IF	for PCI bus
	IE-70000-CD-IF-A	for PCMCIA socket

■ List of Hardware Tools (1/2)

Target device		Emulation board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package			
μPD789014	28-pin SDIP (400 mil)	IE-789014-NS-EM1	NP-28CT*	—
	28-pin SOP (375 mil)		NP-28GT*	AXS628119P* AXS662821*
μPD789026	42-pin SDIP (600 mil)	IE-789026-NS-EM1	NP-42CU*	—
	44-pin QFP (10 × 10)		NP-44GB*	EV-9200G-44
μPD789046	44-pin QFP (10 × 10)	IE-789046-NS-EM1	NP-44GB*	EV-9200G-44
μPD789104A★	28-pin SDIP (400 mil)	IE-789136-NS-EM1	NP-28CT*	—
	30-pin SSOP (300 mil)		NP-36GS*	NGS-30* (attached to NP-36GS*)
μPD789114A★	28-pin SDIP (400 mil)	IE-789136-NS-EM1	NP-28CT*	—
	30-pin SSOP (300 mil)		NP-36GS*	NGS-30* (attached to NP-36GS*)
μPD789124A★	28-pin SDIP (400 mil)	IE-789136-NS-EM1	NP-28CT*	—
	30-pin SSOP (300 mil)		NP-36GS*	NGS-30* (attached to NP-36GS*)

*: This is a product of Naito Densei Machida Mfg. Co., Ltd.

★: Under development

Development Tools

78K/0S Series Hardware Tools

■ List of Hardware Tools (2/2)

Target device		Emulation board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package			
μPD789134A [★]	28-pin SDIP (400 mil)	IE-789136-NS-EM1	NP-28CT ^{*1}	—
	30-pin SSOP (300 mil)		NP-36GS ^{*1}	NGS-30 ^{*1} (attached to NP-36GS ^{*1})
μPD789167 [★]	44-pin QFP (10 × 10)	IE-789177-NS-EM1 [★]	NP-44GB ^{*1}	EV-9200G-44
μPD789177 [★]	44-pin QFP (10 × 10)	IE-789177-NS-EM1 [★]	NP-44GB ^{*1}	EV-9200G-44
μPD789407A	80-pin QFP (14 × 14)	IE-789418-NS-EM1	NP-80GC ^{*1}	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK ^{*1}	TGK-080SDW ^{*2}
μPD789417A	80-pin QFP (14 × 14)	IE-789418-NS-EM1	NP-80GC ^{*1}	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK ^{*1}	TGK-080SDW ^{*2}
μPD789800	42-pin SDIP (600 mil)	IE-789801-NS-EM1	NP-42CU ^{*1}	—
	44-pin QFP (10 × 10)		NP-44GB ^{*1}	EV-9200G-44
μPD789830 [★]	88-pin bare chip	IE-789831-NS-EM1	—	—
μPD78F9831 [★]	100-pin LQFP (14 × 14)		NP-100GC ^{*1}	TGC-100SDW ^{*2}
μPD789842 [★]	44-pin QFP (10 × 10)	IE-789840-NS-EM1	NP-44GB ^{*1}	EV-9200G-44

*1: This is a product of Naito Densai Machida Mfg. Co., Ltd.

★: Under development

*2: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/0 Series Software Tools

■ List of Software Tools

Host machine	Software tool name
PC-9800 Series IBM PC/AT and compatibles PC98-NX Series	Assembler package RA78K0
	C compiler CC78K0
	C library source file CC78K0-L
	Integrated debugger ID78K0-NS
	Integrated debugger ID78K0
	System simulator SM78K0
	Real-time OS RX78K/0
	Embedded OS MX78K0
EWS	Assembler package RA78K0
	C compiler CC78K0
	C library source file CC78K0-L
	Integrated debugger ID78K0

■ List of Device Files

Subseries name	Device file name	Subseries name	Device file name	Subseries name	Device file name
μPD78018F	DF78014	μPD78078	DF78078	μPD780232	DF780233
μPD78018FY		μPD78078Y		μPD780308	DF780308
μPD78014H		μPD78075B		μPD780308Y	(μSxxxxDF78064)
μPD78044F	DF78044	μPD78083	DF78083	μPD780701Y*	DF780701*
μPD78044H		μPD78098B	DF78098	μPD780833Y*	DF780831*
μPD78054	DF78054	μPD780018AY	DF780018	μPD780948*	DF780948*
μPD78054Y		μPD780024A	DF780024	μPD780955*	DF780955
μPD78058F	DF78054	μPD780024AY	DF780034	μPD780958*	DF780958*
μPD78058FY		μPD780034A		μPD780973*	DF780974
μPD78064	DF78064	μPD780034AY	DF780058	μPD780988	DF780988
μPD78064Y		μPD780058			
μPD78064B		μPD780058Y*			
μPD78070A	DF78078	μPD780065*	DF780066*		
μPD78070AY		μPD780208	DF780208		

★: Under development

Development Tools

78K/0 Series Hardware Tools

(1) When using the in-circuit emulator IE-78K0-NS

■ Common Hardware Tools (When using IE-78K0-NS)

Tool name	Product name	
In-circuit emulator	IE-78K0-NS	
Performance board	IE-78K0-NS-PA*	
Power supply unit	IE-70000-MC-PS-B	
Interface adapter	IE-70000-98-IF-C	for C bus of PC-9800 Series
	IE-70000-PC-IF-C	for ISA bus of PC/AT and compatibles
	IE-70000-PCI-IF	for PCI bus
	IE-70000-CD-IF-A	for PCMCIA socket

*: Under development

■ List of Hardware Tools (When using IE-78K0-NS) (1/3)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package			
μPD78018F	64-pin SDIP (750 mil)	IE-78018-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2
μPD78018FY	64-pin SDIP (750 mil)	IE-78018-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2
μPD78014H	64-pin SDIP (750 mil)	IE-78018-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2
μPD78044F	80-pin QFP (14 × 20)	IE-78048-NS-EM1	NP-80GF*1	TGF-080RAW*2
μPD78044H	80-pin QFP (14 × 20)	IE-78048-NS-EM1	NP-80GF*1	TGF-080RAW*2
μPD78054	80-pin QFP (14 × 14)	IE-780308-NS-EM1	NP-80GC*1	EV-9200GC-80
	80-pin TQFP (12 × 12)	IE-780308-NS-EM1	NP-80GK*1	TGK-080SDW*2
μPD78054Y	80-pin QFP (14 × 14)	IE-780308-NS-EM1	NP-80GC*1	EV-9200GC-80
	80-pin TQFP (12 × 12)	IE-780308-NS-EM1	NP-80GK*1	TGK-080SDW*2
μPD78058F	80-pin QFP (14 × 14)	IE-780308-NS-EM1	NP-80GC*1	EV-9200GC-80
μPD78058FY	80-pin QFP (14 × 14)	IE-780308-NS-EM1	NP-80GC*1	EV-9200GC-80

*1: This is a product of Naito Densetsu Machida Mfg. Co., Ltd.

*2: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/0 Series Hardware Tools

■ List of Hardware Tools (When using IE-78K0-NS) (2/3)

Target device		Emulation board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package	I/O board		
μPD78064	100-pin SDIP (14 × 20)	IE-780308-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78064Y	100-pin QFP (14 × 20)	IE-780308-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78064B	100-pin QFP (14 × 20)	IE-780308-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78070A	100-pin QFP (14 × 20)	IE-78078-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78070AY	100-pin QFP (14 × 20)	IE-78078-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78078	100-pin QFP (14 × 20)	IE-78078-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78078Y	100-pin QFP (14 × 20)	IE-78078-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78075B	100-pin QFP (14 × 20)	IE-78078-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD78083	42-pin SDIP (600 mil)	IE-78078-NS-EM1	NP-42CU*1	—
	44-pin QFP (10 × 10)		NP-44GB*1	EV-9200G-44
μPD78098B	80-pin QFP (14 × 14)	Not supported. Use IE-78001-R-A for these devices.		
μPD780018AY	100-pin QFP (14 × 20)	IE-780018-NS-EM1	NP-100GF*1	EV-9200GF-100
μPD780024A	64-pin SDIP (750 mil)	IE-780034-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2
μPD780024AY	64-pin SDIP (750 mil)	IE-780034-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2
μPD780034A	64-pin SDIP (750 mil)	IE-780034-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2
μPD780034AY	64-pin SDIP (750 mil)	IE-780034-NS-EM1	NP-64CW*1	—
	64-pin QFP (14 × 14)		NP-64GC*1	EV-9200GC-64
	64-pin LQFP (12 × 12)		NP-64GK*1	TGK-064SBW*2

*1: This is a product of Naito Densetsu Machida Mfg. Co., Ltd.

*2: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/0 Series Hardware Tools

■ List of Hardware Tools (When using IE-78K0-NS) (3/3)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package			
μPD780058	80-pin QFP (14 × 14)	IE-780308-NS-EM1	NP-80GC* ¹	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK* ¹	TGK-080SDW* ²
μPD780058Y*	80-pin QFP (14 × 14)	IE-780308-NS-EM1	NP-80GC* ¹	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK* ¹	TGK-080SDW* ²
μPD780065*	80-pin QFP (14 × 14)	IE-780066-NS-EM4* IE-78K0-NS-P01	NP-80GC* ¹	EV-9200GC-80
μPD780208	100-pin QFP (14 × 20)	IE-780208-NS-EM1	NP-100GF* ¹	EV-9200GF-100
μPD780232	80-pin QFP (14 × 14)	IE-780233-NS-EM4* IE-78K0-NS-P01	NP-80GC* ¹	EV-9200GC-80
μPD780308	100-pin QFP (14 × 20)	IE-780308-NS-EM1	NP-100GF* ¹	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC* ¹	TGC-100SDW* ²
μPD780308Y	100-pin QFP (14 × 20)	IE-780308-NS-EM1	NP-100GF* ¹	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC* ¹	TGC-100SDW* ²
μPD780701Y*	80-pin QFP (14 × 14)	IE-780701-NS-EM1*	NP-80GC* ¹	EV-9200GC-80
μPD780833Y*	80-pin QFP (14 × 14)	IE-780831-NS-EM4 IE-78K0-NS-P02	NP-80GC* ¹	EV-9200GC-80
μPD780948*	100-pin QFP (14 × 20)	Not supported. Use IE-78001-R-A for these devices.		
μPD780955*	80-pin QFP (14 × 20)	We, NEC, will support each requirement for the development environment of this subseries' devices. Please contact an NEC sales representative.		
μPD780958*	100-pin LQFP (14 × 14)	IE-780958-NS-EM4* IE-78K0-NS-P01	NP-100GC* ¹	TGC-100SDW* ²
μPD780973*	80-pin QFP (14 × 20)	IE-780974-NS-EM1*	NP-80GF* ¹	EV-9200G-80
μPD780988	64-pin SDIP (750 mil)	IE-780988-NS-EM4	NP-64CW* ¹	—
	64-pin QFP (14 × 14)	IE-780K0-NS-P01	NP-64GC* ¹	EV-9200GC-64

*¹: This is a product of Naito Densei Machida Mfg. Co., Ltd.

★: Under development

*²: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/0 Series Hardware Tools

(2) When using the in-circuit emulator IE-78001-R-A

■ Common Hardware Tools (When using IE-78001-R-A)

Tool name	Product name
In-circuit emulator	IE-78001-R-A
Interface adapter	IE-70000-98-IF-C for C bus of PC-9800 Series IE-70000-PC-IF-C for ISA bus of PC/AT and compatibles IE-70000-PCI-IF for PCI bus

■ List of Hardware Tools (When using IE-78001-R-A) (1/3)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package	Emulation probe conversion board		
μPD78018F	64-pin SDIP (750 mil)	IE-78014-R-EM-A	EP-78240CW-R	—
	64-pin QFP (14 × 14)		EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (12 × 12)		EP-78012GK-R	TGK-064SBW*
μPD78018FY	64-pin SDIP (750 mil)	IE-78014-R-EM-A	EP-78240CW-R	—
	64-pin QFP (14 × 14)		EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (12 × 12)		EP-78012GK-R	TGK-064SBW*
μPD78014H	64-pin SDIP (750 mil)	IE-78014-R-EM-A	EP-78240CW-R	—
	64-pin QFP (14 × 14)		EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (12 × 12)		EP-78012GK-R	TGK-064SBW*
μPD78044F	80-pin QFP (14 × 20)	IE-78044-R-EM	EP-78130GF-R	EV-9200G-80
μPD78044H	80-pin QFP (14 × 20)	IE-78044-R-EM	EP-78130GF-R	EV-9200G-80
μPD78054	80-pin QFP (14 × 14)	IE-780308-R-EM	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)		EP-78054GK-R	TGK-080SDW*
μPD78054Y	80-pin QFP (14 × 14)	IE-780308-R-EM	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)		EP-78054GK-R	TGK-080SDW*
μPD78058F	80-pin QFP (14 × 14)	IE-780308-R-EM	EP-78230GC-R	EV-9200GC-80
μPD78058FY	80-pin QFP (14 × 14)	IE-780308-R-EM	EP-78230GC-R	EV-9200GC-80
μPD78064	100-pin QFP (14 × 20)	IE-780308-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78064Y	100-pin QFP (14 × 20)	IE-780308-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78064B	100-pin QFP (14 × 20)	IE-780308-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*

*: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/0 Series Hardware Tools

■ List of Hardware Tools (When using IE-78001-R-A) (2/3)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package	Emulation probe conversion board		
μPD78070A	100-pin QFP (14 × 20)	IE-78078-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78070AY	100-pin QFP (14 × 20)	IE-78078-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78078	100-pin QFP (14 × 20)	IE-78078-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78078Y	100-pin QFP (14 × 20)	IE-78078-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78075B	100-pin QFP (14 × 20)	IE-78078-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μPD78083	42-pin SDIP (600 mil)	IE-78078-R-EM	EP-78083CU-R	—
	44-pin QFP (10 × 10)		EP-78083GB-R	EV-9200G-44
μPD78098B	80-pin QFP (14 × 14)	IE-780908-R-EM	EP-78230GC-R	EV-9200GC-80
μPD780018AY	100-pin QFP (14 × 20)	IE-780018-R-EM	EP-78064GF-R	EV-9200GF-100
μPD780024A	64-pin SDIP (750 mil)	IE-780034-NS-EM1	EP-78240CW-R	—
	64-pin QFP (14 × 14)	IE-78K0-R-EX1	EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (14 × 14)		EP-78012GK-R	TGK-064SBW*
μPD780024AY	64-pin SDIP (750 mil)	IE-780034-NS-EM1	EP-78240CW-R	—
	64-pin QFP (14 × 14)	IE-78K0-R-EX1	EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (12 × 12)		EP-78012GK-R	TGK-064SBW*
μPD780034A	64-pin SDIP (750 mil)	IE-780034-NS-EM1	EP-78240CW-R	—
	64-pin QFP (14 × 14)	IE-78K0-R-EX1	EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (12 × 12)		EP-78012GK-R	TGK-064SBW*
μPD780034AY	64-pin SDIP (750 mil)	IE-780034-NS-EM1	EP-78240CW-R	—
	64-pin QFP (14 × 14)	IE-78K0-R-EX1	EP-78240GC-R	EV-9200GC-64
	64-pin LQFP (12 × 12)		EP-78012GK-R	TGK-064SBW*
μPD780058	80-pin QFP (14 × 14)	IE-780308-R-EM	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)		EP-78054GK-R	TGK-080SDW*
μPD780058Y*	80-pin QFP (14 × 14)	IE-780308-R-EM	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)		EP-78054GK-R	TGK-080SDW*

*: This is a product of Tokyo Eletech Corporation.

*: Under development

Development Tools

78K/0 Series Hardware Tools

■ List of Hardware Tools (When using IE-78001-R-A) (3/3)

Target device		Emulation board I/O board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package	Emulation probe conversion board		
μ PD780065★	80-pin QFP (14 × 14)	IE-780066-NS-EM4★ IE-78K0-NS-P01 IE-78K0-R-EX1	EP-78230GC-R	EV-9200GC-80
μ PD780208	100-pin QFP (14 × 20)	IE-780208-R-EM	EP-78064GF-R	EV-9200GF-100
μ PD780232	80-pin QFP (14 × 14)	IE-780233-NS-EM4★ IE-78K0-NS-P01 IE-78K0-R-EX1	EP-78230GC-R	EV-9200GC-80
μ PD780308	100-pin QFP (14 × 20)	IE-780308-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μ PD780308Y	100-pin QFP (14 × 20)	IE-780308-R-EM	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)		EP-78064GC-R	TGC-100SDW*
μ PD780701Y★	80-pin QFP (14 × 14)	IE-780701-NS-EM1★ IE-78K0-R-EX1	EP-78230GC-R	EV-9200GC-80
μ PD780833Y★	80-pin QFP (14 × 14)	IE-780831-NS-EM4 IE-78K0-NS-P02 IE-78K0-R-EX1	EP-78230GC-R	EV-9200GC-80
μ PD780948★	100-pin QFP (14 × 20)	IE-780948-SL-EM1 IE-780948-SL-EM4	EP-100GF-SL	TQPACK100RB* or YQPACK100RB* + NQPACK100RB*
μ PD780955★	80-pin QFP (14 × 20)	We, NEC, will support each requirement for the development environment of this subseries' devices. Please contact an NEC sales representative.		
μ PD780958★	100-pin LQFP (14 × 14)	IE-780958-NS-EM4★ IE-78K0-NS-P01 IE-78K0-R-EX1	EP-78064GC-R	TGC-100SDW*
μ PD780973★	80-pin QFP (14 × 20)	IE-780974-NS-EM1★ IE-78K0-R-EX1	EP-78130GF-R	EV-9200G-80
μ PD780988	64-pin SDIP (750 mil)	IE-780988-NS-EM4 IE-78K0-NS-P01	EP-78024CW-R	—
	64-pin QFP (14 × 14)	IE-78K0-R-EX1	EP-78240GC-R	EV-9200GC-64

*: This is a product of Tokyo Eletech Corporation.

★: Under development

Development Tools

78K/IV Series Software Tools

■ List of Software Tools

Host machine	Software tool name
PC-9800 Series IBM PC/AT and compatibles PC98-NX Series	Assembler package RA78K4
	C compiler CC78K4
	C library source file CC78K4-L
	Integrated debugger ID78K4-NS
	Integrated debugger ID78K4
	System simulator SM78K4
	System performance analyzer AZ78K4
	Real-time OS RX78K4
	Embedded OS MX78K4
EWS	Assembler package RA78K4
	C compiler CC78K4
	C library source file CC78K4-L
	Integrated debugger ID78K4

■ List of Device Files

Subseries name	Device file name	Subseries name	Device file name	Subseries name	Device file name
μ PD784038	DF784038	μ PD784218	DF784218	μ PD784928	DF784928
μ PD784038Y		μ PD784218Y		μ PD784928Y	
μ PD784046	DF784046	μ PD784225★	DF784225	μ PD784938★	DF784937★
μ PD784054		μ PD784225Y★		μ PD784955★	
μ PD784216	DF784218	μ PD784908	DF784908		
μ PD784216Y		μ PD784915			

★: Under development

Development Tools

78K/IV Series Hardware Tools

(1) When using the in-circuit emulator IE-78K4-NS

■ Common Hardware Tools (When using IE-78K4-NS)

Tool name	Product name	
In-circuit emulator	IE-78K4-NS	
Power supply unit	IE-70000-MC-PS-B	
Interface adapter	IE-70000-98-IF-C	for C bus of PC-9800 Series
	IE-70000-PC-IF-C	for ISA bus of PC/AT and compatibles
	IE-70000-PCI-IF	for PCI bus
	IE-70000-CD-IF-A	for PCMCIA socket

■ List of Hardware Tools (When using IE-78K4-NS)

Target device		Emulation board	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package			
μPD784038	80-pin QFP (14 × 14)	IE-784038-NS-EM1	NP-80GC*1	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK*1	TGK-080SDW*2
μPD784038Y	80-pin QFP (14 × 14)	IE-784038-NS-EM1	NP-80GC*1	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK*1	TGK-080SDW*2
μPD784046	80-pin QFP (14 × 14)	IE-784046-NS-EM1	NP-80GC*1	EV-9200GC-80
μPD784054	80-pin QFP (14 × 14)	IE-784046-NS-EM1	NP-80GC*1	EV-9200GC-80
μPD784216	100-pin QFP (14 × 20)	IE-784225-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD784216Y	100-pin QFP (14 × 20)	IE-784225-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD784218	100-pin QFP (14 × 20)	IE-784225-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD784218Y	100-pin QFP (14 × 20)	IE-784225-NS-EM1	NP-100GF*1	EV-9200GF-100
	100-pin LQFP (14 × 14)		NP-100GC*1	TGC-100SDW*2
μPD784225*	80-pin QFP (14 × 14)	IE-784225-NS-EM1	NP-80GC*1	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK*1	TGK-080SDW*2
μPD784225Y*	80-pin QFP (14 × 14)	IE-784225-NS-EM1	NP-80GC*1	EV-9200GC-80
	80-pin TQFP (12 × 12)		NP-80GK*1	TGK-080SDW*2
μPD784908	100-pin QFP (14 × 20)	IE-784908-NS-EM1	NP-100GF*1	EV-9200GF-100
μPD784915	100-pin QFP (14 × 20)	IE-784928-NS-EM1	EP-784928GF-NS	NEV-921GF-100
μPD784928	100-pin QFP (14 × 20)	IE-784928-NS-EM1	EP-784928GF-NS	NEV-921GF-100
μPD784928Y	100-pin QFP (14 × 20)	IE-784928-NS-EM1	EP-784928GF-NS	NEV-921GF-100
μPD784938*	100-pin QFP (14 × 20)	IE-784937-NS-EM1	NP-100GF*1	EV-9200GF-100
μPD784955*	80-pin QFP (14 × 14)	IE-784956-NS-EM1	NP-80GC*1	EV-9200GC-80

*1: This is a product of Naito Densai Machida Mfg. Co., Ltd.

*: Under development

*2: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/IV Series Hardware Tools

(2) When using the in-circuit emulator IE-784000-R

■ Common Hardware Tools (When using IE-784000-R)

Tool name	Product name
In-circuit emulator	IE-784000-R
Emulation board	IE-784000-R-EM
Interface board	IE-70000-98-IF-C for C bus of PC-9800 Series IE-70000-PC-IF-C for ISA bus of PC/AT and compatibles IE-70000-PCI-IF for PCI bus IE-70000-CD-IF-A for PCMCIA socket

■ List of Hardware Tools (When using IE-784000-R) (1/2)

Target device		I/O emulation board (emulation board)	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package	Emulation probe conversion board		
μ PD784038	80-pin QFP (14 × 14)	IE-784038-R-EM1	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)		EP-78054GK-R	TGK-080SDW*
μ PD784038Y	80-pin QFP (14 × 14)	IE-784038-R-EM1	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)		EP-78054GK-R	TGK-080SDW*
μ PD784046	80-pin QFP (14 × 14)	IE-784046-R-EM1	EP-78230GC-R	EV-9200GC-80
μ PD784054	80-pin QFP (14 × 14)	IE-784046-R-EM1	EP-78230GC-R	EV-9200GC-80
μ PD784216	100-pin QFP (14 × 20)	IE-784225-NS-EM1	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)	IE-78K4-R-EX3	EP-78064GC-R	TGC-100SDW*

*: This is a product of Tokyo Eletech Corporation.

Development Tools

78K/IV Series Hardware Tools

■ List of Hardware Tools (When using IE-784000-R) (2/2)

Target device		I/O emulation board (emulation board)	Emulation probe	Conversion socket/ Conversion adapter/ Flexible board
Subseries name	Package	Emulation probe conversion board		
μ PD784216Y	100-pin QFP (14 × 20)	IE-784225-NS-EM1	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)	IE-78K4-R-EX3	EP-78064GC-R	TGC-100SDW*
μ PD784218	100-pin QFP (14 × 20)	IE-784225-NS-EM1	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)	IE-78K4-R-EX3	EP-78064GC-R	TGC-100SDW*
μ PD784218Y	100-pin QFP (14 × 20)	IE-784225-NS-EM1	EP-78064GF-R	EV-9200GF-100
	100-pin LQFP (14 × 14)	IE-78K4-R-EX3	EP-78064GC-R	TGC-100SDW*
μ PD784225*	80-pin QFP (14 × 14)	IE-784225-NS-EM1	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)	IE-78K4-R-EX2	EP-78054GK-R	TGK-080SDW*
μ PD784225Y*	80-pin QFP (14 × 14)	IE-784225-NS-EM1	EP-78230GC-R	EV-9200GC-80
	80-pin TQFP (12 × 12)	IE-78K4-R-EX2	EP-78054GK-R	TGK-080SDW*
μ PD784908	100-pin QFP (14 × 20)	IE-784908-R-EM1	EP-784915GF-R	EV-9200GF-100
μ PD784915	100-pin QFP (14 × 20)	IE-784928-NS-EM1 IE-78K4-R-EX3	EP-784928GF-NS	EV-9200GF-100
μ PD784928	100-pin QFP (14 × 20)	IE-784928-NS-EM1 IE-78K4-R-EX3	EP-784928GF-NS	EV-9200GF-100
μ PD784928Y	100-pin QFP (14 × 20)	IE-784928-NS-EM1 IE-78K4-R-EX3	EP-784928GF-NS	EV-9200GF-100
μ PD784938*	100-pin QFP (14 × 20)	IE-784937-NS-EM1 IE-78K4-R-EX3	EP-78064GF-R	EV-9200GF-100
μ PD784955*	80-pin QFP (14 × 14)	IE-784956-NS-EM1 IE-78K4-R-EX2	EP-784915GF-R	EV-9200GC-80

*: This is a product of Tokyo Eletech Corporation.

★: Under development

Development Tools

V810 Family Development Tools

■ List of Software Tools

Product name		Target device	Host machine
Real-time OS	RX732	V821	PC-9800 Series IBM PC/AT and compatibles SPARCstation™
File system	RX-FS732		PC-9800 Series SPARCstation

Remark Please contact an NEC sales representative if you use host machines not mentioned above.

■ List of Hardware Tools

Product name	Target device	Part number	Remarks
In-circuit emulator	V821	IE-70741-BX	Conversion socket : TQPACK100SD* + TQSOCKET100SDW* (essential)
Interface board		IE-70000-98-IF-C	For PC-9800 Series
		IE-70000-PC-IF-C	For IBM PC/AT and compatibles
Expansion memory board		IE-70000-BX-MM2	Expands 2M bytes of the emulation memory
External logic probe		IE-70000-BX-EP	Consists of one GND and eight external inputs
Conversion adapter / Conversion socket		TQPACK100SD* TQSOCKET100SDW*	Probe included in the in-circuit emulator → 100-pin QFP

※: This is a product of Tokyo Eletech Corporation.

V830 Family Development Tools

■ List of Software Tools

Product name		Target device	Host machine
Real-time OS	RX830	V830 Family	PC-9800 Series IBM PC/AT and compatibles SPARCstation
Compiler	CA830	V830 V831	PC-9800 Series IBM PC/AT and compatibles SPARCstation
System performance analyzer	AZ830	V830 Family	PC-9800 Series IBM PC/AT and compatibles
Device file	DF705100	V830	PC-9800 Series IBM PC/AT and compatibles SPARCstation
	DF705101	V831	

Remark Please contact an NEC sales representative if you use host machines not mentioned above.

Hardware tools are not provided. Please contact an NEC sales representative about the development environment of the V830 Family.

Development Tools

V850 Family Software Tools

■ List of Software Tools

Product name		Target device	Host machine
Real-time OS	RX850	V850 Family	PC-9800 Series
	RX850 pro		IBM PC/AT and compatibles SPARCstation
Compiler	CA850		PC-9800 Series IBM PC/AT and compatibles SPARCstation
Debugger	ID850		PC-9800 Series IBM PC/AT and compatibles
Simulator	SM850		PC-9800 Series IBM PC/AT and compatibles
System performance analyzer	AZ850		PC-9800 Series IBM PC/AT and compatibles
Device file	DF703002	V852	PC-9800 Series
	DF703003	V853	IBM PC/AT and compatibles
	DF703008	V854	SPARCstation
	DF703017	V850/SA1	
	DF703037	V850/SB1 V850/SB2	
	DF703102	V850E/MS1	

Remark Please contact an NEC sales representative if you use host machines not mentioned above.

Development Tools

V850 Family Hardware Tools

■ List of Hardware Tools (1/2)

Product name	Target device	Part number	Remarks
In-circuit emulator	V850E/MS1	IE-703102-MC	A PC interface cable, external logic probe, and conversion sockets* ¹ are included
	V850/SA1, V850/SB1, V852, V853, V854	IE-703002-MC	
In-circuit emulator option board	V850/SA1	IE-703017-MC-EM1	NQPACK100SD* ² is included
	V850/SB1, V850/SB2	IE-703037-MC-EM1*	Conversion socket not included (the V850/SB2 version is under development)
	V853	IE-703003-MC-EM1	NQPACK100SD* ² is included
	V854	IE-703008-MC-EM1	NQPACK144SD* ² , YQPACK144SD* ² , HQPACK144SD* ² , and YQGUIDE* ² are included
	V850E/MS1	IE-703102-MC-EM1*	For 5V, conversion socket not included
		IE-703102-MC-EM1-A*	For 3.3V, conversion socket not included
Power supply unit	V850/SA1, V850/SB1, V850/SB2, V850E/MS1, V852, V853, V854	IE-70000-MC-PS-B	Power supply cable for AC100 to 240V is included
PC Interface board	V850/SA1, V850/SB1, V850/SB2, V850E/MS1, V852, V853, V854	IE-70000-98-IF-B or IE-70000-98-IF-C	For PC-9800 (C bus)* ³
		IE-70000-PC-IF-B or IE-70000-PC-IF-C	For IBM PC/AT and compatibles (ISA bus)* ³
		IE-70000-CD-IF-A	For PCMCIA socket* ⁴
		IE-70000-PCI-IF	For PCI bus* ⁴

*1: The following conversion sockets, which are products of Tokyo Eletech Corporation, are included. *: Under development

IE-703102-MC : NQPACK144SD, YQPACK144SD, HQPACK144SD, YQGUIDE

IE-703002-MC : NQPACK100SD, YQPACK100SD, HQPACK100SD, YQSOCKET100SDN, YQGUIDE

*2: This is a product of Tokyo Eletech Corporation.

*3: Not available for PC98-NX Series.

*4: Available for PC98-NX Series.

Development Tools

V850 Family Hardware Tools

■ List of Hardware Tools (2/2)

Product name	Target device	Part number	Remarks
Conversion adapter/ conversion socket	V850/SA1	CSPACK121A1312N02*	Conversion socket for 121-pin FPBGA
		CSICE121A1312N02*	Conversion adapter for 121-pin FPBGA CSPACK121A1312N02* is necessary when using this
	V850/SA1, V850/SB1, V850/SB2, V852, V853	NQPACK100SD*	Conversion socket for target board (for 100-pin QFP (0.5-mm pitch))
		YQPACK100SD*	Conversion socket for connection to an in-circuit emulator
		HQPACK100SD*	Cover of the socket for 100-pin QFP
		YQSOCKET100SDN*	Socket for spacer
		YQGUIDE*	Fixing screws
	V850/SB1, V850/SB2	NEXB-100SD/RB*	100-pin GC-GF conversion board
		NQPACK100RB*	Conversion socket for target board (for 100-pin QFP (14 × 20 mm, 0.65-mm pitch))
		YQPACK100RB*	Conversion socket for connection to an in-circuit emulator
		HQPACK100RB*	Cover of the socket for 100-pin QFP
		YQSOCKET100RBN*	Socket for spacer
		YQGUIDE*	Fixing screws
	V850E/MS1, V854	NQPACK144SD*	Conversion socket for target board (for 144-pin QFP (0.5-mm pitch))
		YQPACK144SD*	Conversion socket for connection to an in-circuit emulator
		HQPACK144SD*	Cover of the socket for 144-pin QFP
		YQSOCKET144SDN*	Socket for spacer
		YQGUIDE*	Fixing screws
	V850E/MS1	CSPACK157A1614N01*	Conversion socket for 157-pin FPBGA
		CSICE157A1614N01*	Conversion adapter for 157-pin FPBGA CSPACK157A1614N01* is necessary when using this
Expansion probe	V850/SA1, V850/SB1, V850/SB2, V852, V853	SC-100SDN*	Expansion probe for 100-pin QFP (0.5-mm pitch)
	V850E/MS1, V854	SC-144SDN*	Expansion probe for 144-pin QFP (0.5-mm pitch)

*: This is a product of Tokyo Eletech Corporation.

Development Tools

V_R Series Development Tools

■ List of Software Tools

Product name	Target device	Host machine
Real-time OS RX4000	V _R 4100 Series™	PC-9800 Series
	V _R 4300 Series™	IBM PC/AT and compatibles

Other than above, tools as follows are also provided by development tool makers for V_R Series.

Software tools	Hardware tools
Operating system	Evaluation board
Real-time OS	ROM emulator
Optimization compiler	
Source debugger	

Middleware

Middleware that Holds the Key to Multimedia

Various key technologies are needed to realize multimedia applications, such as a human-machine interface as speech recognition, and data compression/decompression including data communications. And these technologies require high-performance RISC microcomputers capable of high-speed data processing. The V800 Series and V_R Series answer these requirements with powerful CPU performance complemented by middleware support based on multimedia performance.

■ The positioning of middleware

◦ Software integration

- User programs
- Middleware
 - Human interface (speech recognition, handwritten character recognition, etc.)
 - Internet
 - Multimedia signal processing (JPEG, voice compression, moving picture processing)
 - Communication (modem, mobile communications, etc.)

◦ Hardware integration

- CPU
- Memory
- Standard macro
- Dedicated macro
- Analog circuit
- User logic

■ Features

◦ Reduced overall costs due to shorter TAT development and lower development costs

If middleware that has been optimized to the CPU architecture is used, the amount of time taken to develop each individual system can be markedly reduced. Moreover, as there is no need to use dedicated devices, the cost is further streamlined.

◦ Improved CPU performance

The CPU, due to the improvement in CPU performance, can now easily realize applications that could previously only be performed by dedicated hardware or personal computers/workstations. The addition, modification and deletion of functions difficult to perform with hardware, as well as the organization of user-friendly interfaces have now been made simpler.

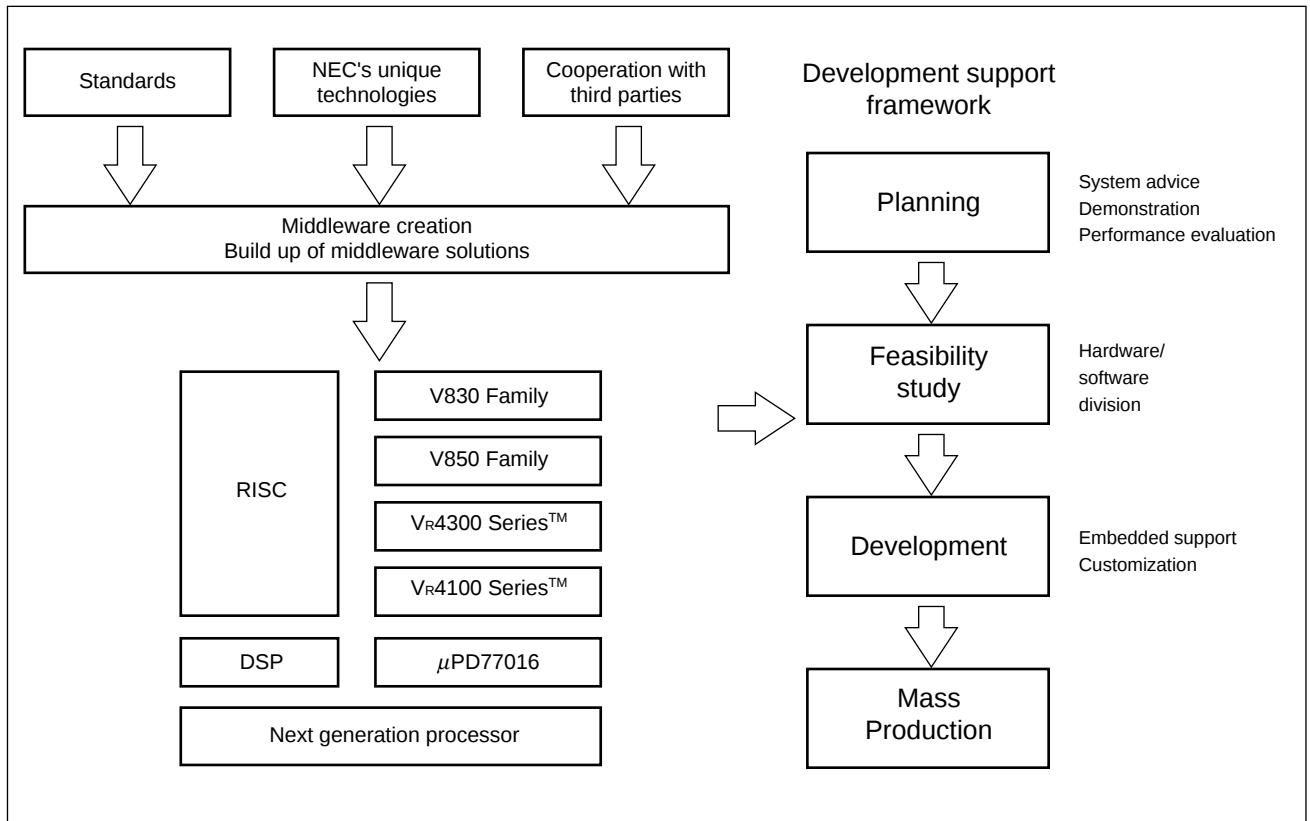
◦ Spread of Internet and multimedia signal-processing applications

Through the popularity of the Internet, the management of multimedia information such as picture images and speech has expanded considerably. To employ dedicated hardware to process this information would take a large-scale system and considerable cost. By using middleware, the processing of this information can be easily realized by the CPU alone.

Middleware

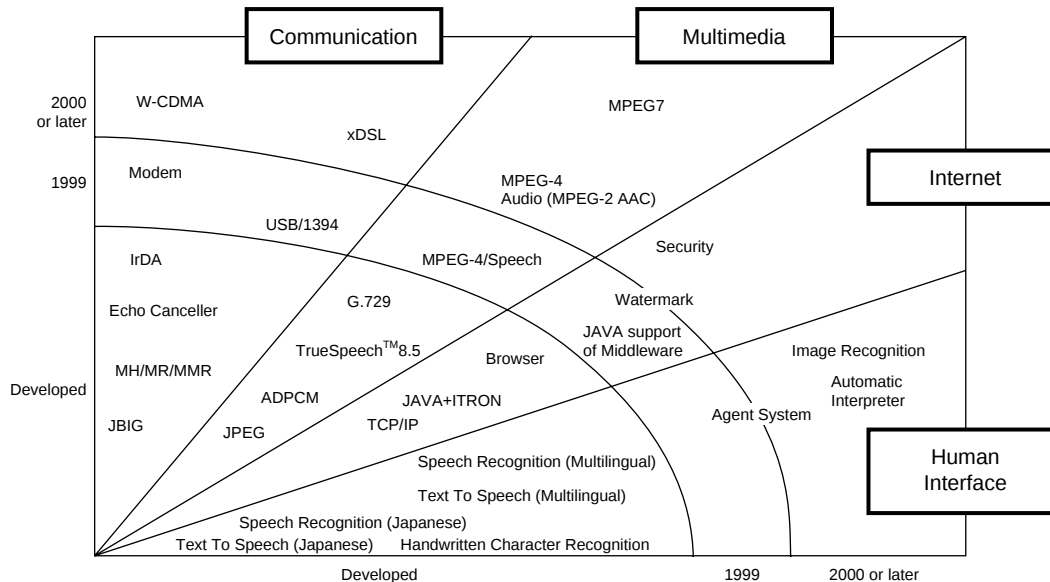
Middleware Development Framework

NEC middleware will gradually develop into optimal processor for each system. Furthermore, NEC plans to realize standardized middleware by using not only NEC's uniquely developed technologies, but also the most outstanding third party technologies and standards.



Middleware

Middleware Road Map



Middleware Products

Field	Middleware		V800 Series		V _R Series
			V830 Family	V850 Family	
Image	MH/MR/MMR		◎	◎	◎
	JBIG		◎	◎	◎
	JPEG		◎	◎	◎
Speech	Text To Speech	Japanese	◎	◎	○
		Multilingual Version (TTS3000*1)	◎	—	—
		English*2	—	—	○
	TrueSpeech8.5		◎	—	◎
	G.726 (ADPCM)		Sample	◎	△
	G.729/AnnexA/B		—	—	△
	MPEG-4/Speech (CELP)		—	—	△
	Echo Cancellor (for Hands-free operation)		◎	—	◎
Sound	MPEG-4 Audio (MPEG-2 AAC)		△	—	△
Recognition	Speech Recognition	Multilingual Version (ASR1600/C*1)	◎	—	△
		English*2	—	—	○
		Japanese (large vocabulary)	◎	—	○
	Handwritten Character Recognition		◎	◎	◎
Internet (Third party products)	Browser		◎	○	◎
	JAVA		◎	—	◎
	TCP/IP		◎	○	◎
Interface	IrDA protocol stack*3		◎	◎	△

*1: English/German/French/Italian/Dutch/Spanish (Jointly developed with L&H Inc.)

*2: WindowsCE supported

*3: This is a product of Okaya Systemware Co., Ltd.

Remark ◎: Developed, ○: Under Development, △: Under Planning

IC Memory

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Dynamic RAM

■ Synchronous DRAM: SDR (Single Data Rate)

(1/3)

Density (bits)	Organization (words × bits × banks)	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Clock access time MAX. (ns)	Self refresh current MAX. (mA)	Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Package	Remark						
256M*	16M×4×4	μPD45256441	A75	3	133	5.4	2	3.3±0.3	8K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	PC133 Compliant (3-3-3)						
				A80	3	125	6					PC100 Compliant (2-2-2)						
			A10		2	100	7					PC100 Compliant (3-2-2)						
				A10B	3	100						—						
			A80L		2	67	8					PC100 Compliant (2-2-2)						
				A10L	3	125	6					1	PC100 Compliant (3-2-2)					
			A10BL		2	100	7						—					
				A10L	3	100	7					1	PC100 Compliant (3-2-2)					
			A10BL		2	77	8						—					
				A10BL	3	100	8					1	PC100 Compliant (3-2-2)					
			A10BL		2	67	8						—					
				8M×8×4	μPD45256841	A75	3					133	5.4	2	3.3±0.3	8K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)
			A80				3					125	6	PC100 Compliant (2-2-2)				
						A10	2					100	7	PC100 Compliant (3-2-2)				
			A10B				3					100		—				
						A80L	2					67	8	PC100 Compliant (2-2-2)				
			A10L				3					125	6	1				
						A10BL	2					100	7					
	A10L	3	100				7	1	PC100 Compliant (3-2-2)									
		A10BL	2			77	8		—									
	A10BL		3			100	8	1	PC100 Compliant (3-2-2)									
		A10BL	2			67	8		—									
	4M×16×4		μPD45256163			A80	3	125	6	2	3.3±0.3	8K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)				
		A10					2	100	7	PC100 Compliant (3-2-2)								
						A10B	3	100		8								
		A80L					2	67	8	1								
						A10L	3	125	6									
		A10BL					2	100	7	—								
						A10BL	3	100	8	1								
		A10BL		2	77		8	—										
				A10BL	3	100	8	1	PC100 Compliant (3-2-2)									
		A10BL			2	67	8		—									

★: Under development

Dynamic RAM

■ Synchronous DRAM: SDR (Single Data Rate)

(2/3)

Density (bits)	Organization (words × bits × banks)	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Clock access time MAX. (ns)	Self refresh current MAX. (mA)	Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Package	Remark											
128M	8M×4×4	μPD45128441	A75	3	133	5.4	2	3.3±0.3	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	PC133 Compliant (3-3-3)											
			A80	3	125	6	0.8					PC100 Compliant (2-2-2)											
				2	100							PC100 Compliant (3-2-2)											
			A10	3	100	7						0.8	—										
				2	77								PC100 Compliant (2-2-2)										
			A10B	3	100	8							0.8	PC100 Compliant (3-2-2)									
				2	67									—									
			A80L	3	125	6								0.8	PC100 Compliant (2-2-2)								
				2	100										PC100 Compliant (3-2-2)								
			A10L	3	100	7									0.8	—							
				2	77											PC100 Compliant (2-2-2)							
			A10BL	3	100	8										0.8	—						
				2	67												PC100 Compliant (2-2-2)						
			4M×8×4	μPD45128841	A75	3	133										5.4	2	3.3±0.3	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	PC133 Compliant (3-3-3)
					A80	3	125										6	0.8					PC100 Compliant (2-2-2)
						2	100					PC100 Compliant (3-2-2)											
	A10	3			100	7	0.8	—															
		2			77			PC100 Compliant (2-2-2)															
	A10B	3			100	8		0.8	PC100 Compliant (3-2-2)														
		2			67				—														
	A80L	3			125	6			0.8	PC100 Compliant (2-2-2)													
		2	100	PC100 Compliant (3-2-2)																			
	A10L	3	100	7	0.8	—																	
		2	77			PC100 Compliant (2-2-2)																	
	A10BL	3	100	8		0.8				—													
		2	67							PC100 Compliant (2-2-2)													
	2M×16×4	μPD45128163	A80	3						125	6	2	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	PC100 Compliant (2-2-2)							
				2						100						PC100 Compliant (3-2-2)							
			A10	3			100			7	0.8					—							
				2			77									PC100 Compliant (2-2-2)							
			A10B	3			100	8		0.8						PC100 Compliant (3-2-2)							
				2			67									—							
			A80L	3			125	6	0.8							PC100 Compliant (2-2-2)							
				2			100									PC100 Compliant (3-2-2)							
			A10L	3	100		7	0.8								—							
				2	77											PC100 Compliant (2-2-2)							
			A10BL	3	100	8	0.8									—							
				2	67											PC100 Compliant (2-2-2)							

Dynamic RAM

■ Synchronous DRAM: SDR (Single Data Rate)

(3/3)

Density (bits)	Organization (words × bits × banks)	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Clock access time MAX. (ns)	Self refresh current MAX. (mA)	Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Package	Remark						
64M	4M×4×4	μPD4564441	A75	3	133	5.4	1	3.3±0.3	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	PC133 Compliant (3-3-3)						
				A80	3	125						6	PC100 Compliant (2-2-2)					
			2		100	PC100 Compliant (3-2-2)												
			A10	3	100	7						—						
				2	77							PC100 Compliant (2-2-2)						
			A10B	3	100	8						PC100 Compliant (2-2-2)						
				2	67		PC100 Compliant (3-2-2)											
			A80L	3	125	6	—											
				2	100		PC100 Compliant (2-2-2)											
			A10L	3	100	7	PC100 Compliant (3-2-2)											
				2	77		—											
			A10BL	3	100	8	—											
				2	67		PC133 Compliant (3-3-3)											
			2M×8×4	μPD4564841	A75	3	133					5.4	1	3.3±0.3	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	PC100 Compliant (2-2-2)
						A80	3					125						6
					2		100					PC100 Compliant (2-2-2)						
					A10	3	100					7						—
						2	77											PC100 Compliant (2-2-2)
	A10B	3			100	8	PC100 Compliant (2-2-2)											
		2			67		PC100 Compliant (3-2-2)											
	A80L	3			125	6	—											
		2			100		PC100 Compliant (2-2-2)											
	A10L	3			100	7	PC100 Compliant (3-2-2)											
		2			77		—											
	A10BL	3			100	8	—											
		2			67		PC100 Compliant (2-2-2)											
	1M×16×4	μPD4564163			A80	3	125	6	1	3.3±0.3	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)					PC100 Compliant (2-2-2)
						A10	3	100										7
					2		100	—										
					A10B	3	100	8										PC100 Compliant (2-2-2)
						2	67											PC100 Compliant (3-2-2)
			A80L	3	125	6	—											
				2	100		PC100 Compliant (2-2-2)											
			A10L	3	100	7	PC100 Compliant (3-2-2)											
				2	77		—											
			A10BL	3	100	8	—											
				2	67		PC100 Compliant (2-2-2)											
			512K×32×4	μPD4564323	A80*	3	125	6	1					3.3±0.3	4K/64	LVTTL	G5: 86-pin TSOP(II) (400 mil)	PC100 Compliant (2-2-2)
						A10*	3	100										7
					2		100	—										
					A10B	3	100	8										PC100 Compliant (2-2-2)
						2	67											PC100 Compliant (3-2-2)
					A80L*	3	125	6										—
						2	100		PC100 Compliant (2-2-2)									
	A10L*	3			100	7	PC100 Compliant (3-2-2)											
		2			77		—											
	A10BL*	3			100	8	—											
		2			67		PC100 Compliant (2-2-2)											

★: Under development

Dynamic RAM

■ Virtual Channel Synchronous DRAM:SDR (Single Data Rate)

Density (bits)	Organization (words × bits × banks)	Part number	Speed grade	Read latency	Clock frequency (MHz)	Clock access time MAX. (ns)	Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Package	Remark
64M	8M×4×2	μPD4565421	A70*	2	143	5.4	3.3±0.3	4K/64	LVTTL	G5: 54-pin TSOP(II) (400 mil)	
			A75		133	5.4					
			A10		100	6					
			A15	1	67	12					
	4M×8×2	μPD4565821	A70*	2	143	5.4					
			A75		133	5.4					
			A10		100	6					
			A15	1	67	12					
	2M×16×2	μPD4565161	A70*	2	143	5.4					
			A75		133	5.4					
			A10		100	6					
			A15	1	67	12					

★: Under development

■ Synchronous DRAM: DDR (Double Data Rate)

Density (bits)	Organization (words × bits × banks)	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Self refresh current MAX. (mA)	Supply voltage (V)		Refresh cycle (cycles /ms)	Interface level	Package	Remark
							Vcc	VccQ				
128M	8M×4×4	μPD45D128442	C80*	2.5	133	2	2.5±0.125	2.5±0.125	4K/64	SSTL_2	G5: 66-pin TSOP(II) (400 mil)	
				2	125							
			C10	2.5	125							
				2	100							
			C12	2.5	100							
				2	83							
	4M×8×4	μPD45D128842	C80*	2.5	133							
				2	125							
			C10	2.5	125							
				2	100							
			C12	2.5	100							
				2	83							
	2M×16×4	μPD45D128164	C80*	2.5	133							
				2	125							
			C10	2.5	125							
				2	100							
			C12	2.5	100							
				2	83							

★: Under development

■ Direct Rambus™ DRAM

Density (bits)	Organization (words × bits × banks)	Part number	Clock frequency		Access time		Maximum supply current (mA)			Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Package		Remark
			Class	1/t _{CYCLE} (MHz)	Class	t _{RAC} (ns)	Active	Refresh					Type	Pin configuration	
								Auto	Self						
72M	256K×18×16	μPD488385	C80	400	40	40	TBD	TBD	TBD	2.5±0.13	8K/32	RSL	FB: 74-pin D ² BGA™	BF1:Normal	
					45	45									
			C60	300	53	53									
128M	256K×16×32	μPD488448	C80	400	40	40	TBD	TBD	TBD				FB: 62-pin D ² BGA	• Normal • Mirrored	
					45	45									
			C60	300	53	53									
144M	256K×18×32	μPD488488	C80	400	40	40	TBD	TBD	TBD				FB: 62-pin D ² BGA	• Normal • Mirrored	
					45	45									
			C60	300	53	53									

Dynamic RAM Module

■ 168-pin SDRAM DIMM (Dual In-line Memory Module): Unbuffered Type

Density (bytes)	Organization (words × bits)	Bank organization	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Mounted devices	Package height (mm/inch)	Remark
256M	32M×72	2	MC-4532CC726	A80	3	125	3.3±0.3	4K/64	LVTTL	μPD45128841G5 ×18 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						PC100 Compliant (2-2-2)
					2	77						PC100 Compliant (3-2-2)
	32M×64	2	MC-4532CD646	A80	3	125				μPD45128841G5 ×16 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						PC100 Compliant (2-2-2)
					2	77						PC100 Compliant (3-2-2)
128M	16M×72	2	MC-4516CC726	A80	3	125				μPD4564841G5 ×18 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						PC100 Compliant (2-2-2)
					2	77						PC100 Compliant (3-2-2)
		2	MC-4516CC725	A10B	3	100				μPD4564841G5 ×16 pcs.	33.02/1.30	—
					2	67						—
				A80	3	125						PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
	16M×64	2	MC-4516CD646	A80	3	125				μPD4564841G5 ×16 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						PC100 Compliant (2-2-2)
					2	77						PC100 Compliant (3-2-2)
		2	MC-4516CD645	A10B	3	100				μPD4564841G5 ×16 pcs.	33.02/1.30	—
					2	67						—
				A80	3	125						PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
64M	8M×72	1	MC-458CA726	A80	3	125				μPD4564841G5 ×9 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						—
					2	77						—
		1	MC-458CA725	A10B	3	100				μPD4564841G5 ×8 pcs.	31.75/1.25	—
					2	67						—
				A80	3	125						PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
	8M×64	1	MC-458CB646	A80	3	125				μPD4564163G5 ×5 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						—
					2	77						—
		1	MC-458CB645	A10B	3	100				μPD4564163G5 ×4 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A80	3	100						—
					2	77						—
32M	4M×72	1	MC-454CA726	A80	3	125				μPD4564163G5 ×5 pcs.	34.93/1.375	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						—
					2	77						—
				A10B	3	125						PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
	4M×64	1	MC-454CB646	A10B	3	125				μPD4564163G5 ×4 pcs.	29.21/1.15	—
					2	100						—
				A80	3	100						—
					2	77						—
				A10B	3	100						—
					2	67						—

Dynamic RAM Module

■ 168-pin SDRAM DIMM (Dual In-line Memory Module): Registered Type

Density (bytes)	Organization (words × bits)	Bank organi- zation	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Supply voltage (V)	Refresh cycle (cycles /ms)	Inter- face level	Mounted devices	Package height (mm/inch)	Remark
512M	64M×72	2	MC-4564DC726	A80	3	125	3.3±0.3	4K/64	LVTTL	μPD45128441G5 ×36 pcs.	43.18/1.70	PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						PC133 Compliant (3-3-3)
					2	77						PC100 Compliant (2-2-2)
256M	32M×72	1	MC-4532DA727	A75	3	133				μPD45128441G5 ×18 pcs.	43.18/1.70	PC133 Compliant (3-3-3)
			MC-4532DA726	A80	3	125						PC100 Compliant (2-2-2)
					2	100						PC100 Compliant (3-2-2)
				A10	3	100						PC100 Compliant (2-2-2)
					2	77						PC100 Compliant (3-2-2)
			128M	16M×72	1	MC-4516DA727						A75
MC-4516DA726	A80	3				125				PC100 Compliant (2-2-2)		
		2				100				PC100 Compliant (3-2-2)		
	A10	3				100	PC100 Compliant (2-2-2)					
64M	8M×72	1	MC-458DA727	A75	3	133	μPD4564841G5 ×9 pcs.	38.1/1.50	PC133 Compliant (3-3-3)			
			MC-458DA726	A80	3	125			PC100 Compliant (2-2-2)			
					2	100			PC100 Compliant (3-2-2)			
				A10	3	100			PC100 Compliant (2-2-2)			
32M	4M×72	1	MC-454DA726	A80	3	125	μPD4564163G5 ×5 pcs.	38.1/1.50	PC100 Compliant (2-2-2)			
					2	100			PC100 Compliant (3-2-2)			
				A10	3	100			PC100 Compliant (2-2-2)			
					2	77			PC100 Compliant (3-2-2)			

Dynamic RAM Module

■ 144-pin SDRAM SO DIMM (Small Outline Dual In-line Memory Module)

Density (bytes)	Organization (words × bits)	Bank organi- zation	Part number	Speed grade	/CAS latency	Clock frequency (MHz)	Self refresh current (mA)	Supply voltage (V)	Refresh cycle (cycles /ms)	Inter- face level	Mounted devices	Package height (mm/inch)	Remark					
128M	16M×64	1	MC-4516CB64ES	A10B	3	100	16	3.3±0.3	4K/64	LVTTL	μPD45128841G5 ×8 pcs.	26.67/1.05	—					
					2	67	6.4											
				A10BL	3	100												
					2	67												
		2	MC-4516CD64ES	A10B	3	100	16				μPD45128163G5 ×8 pcs.	31.75/1.25	PC100 Compliant (2-2-2), Rev.1.0 PC100 Compliant (3-2-2), Rev.1.0					
					2	67	6.4											
				A10BL	3	100												
					2	67												
		2	MC-4516CD641ES	A80	3	125	16											
					2	100												
				A10	3	100												
					2	77												
		64M	8M×64	1	MC-458CB64LSA	A10B	3				100	8				μPD4564841G5 ×8 pcs.	26.67/1.05	—
							2				67	3.2						
A10BL	3					100												
	2					67												
1	MC-458CB641ES			A80	3	125	4	μPD45128163G5 ×4 pcs.	25.4/1.0	PC100 Compliant (2-2-2), Rev.1.0 PC100 Compliant (3-2-2), Rev.1.0								
					2	100												
				A10	3	100												
					2	77												
2	MC-458CD64LS			A10B	3	100	8	μPD4564163G5 ×8 pcs.	26.67/1.05	—								
					2	67	3.2											
				A10BL	3	100												
					2	67												
2	MC-458CD641LS			A80	3	125	8											
					2	100												
		A10	3	100														
			2	77														
32M	4M×64	1	MC-454CB64LS	A10B	3	100	4				μPD4564163G5 ×4 pcs.	25.4/1.00	—					
					2	67	2											
				A10BL	3	100												
					2	67												
				MC-454CB641LS	A80	3	125							4				
						2	100											
			A10		3	100												
					2	77												

Dynamic RAM Module

■ 168-pin Virtual Channel SDRAM DIMM (Dual In-line Memory Module): Unbuffered Type

Density (bytes)	Organization (words × bits)	Bank organization	Part number	Speed grade	Read latency	Prefetch read latency	Clock frequency (MHz)	Supply voltage (V)	Refresh cycle (cycles /ms)	Interface level	Mounted devices	Package height (mm/inch)	Remark
128M	16M×64	2	MC-45V16AD641	A75	2	4	133	3.3±0.3	4K/64	LVTTL	μPD4565821G5 ×16 pcs.	34.93/1.375	
				A10			100						
				A15			66						
64M	8M×64	1	MC-45V8AB641	A75	2		133				μPD4565821G5 ×8 pcs.		
				A10			100						
				A15			66						

■ 144-pin Virtual Channel SDRAM SO DIMM (Small Outline Dual In-line Memory Module)

Density (bytes)	Organization (words × bits)	Bank organiza- tion	Part number	Speed grade	Read latency	Prefetch read latency	Clock frequency (MHz)	Supply voltage (V)	Refresh cycle (cycles /ms)	Inter- face level	Mounted devices	Package height (mm/inch)	Remark
64M*	8M×64	1	MC-45V8AB641KS	A75	2	4	133	3.3±0.3	4K/64	LVTTL	μPD4565821G5 ×8 pcs.	31.75/1.25	
				A10			100						
				A15			66						
		2	MC-45V8AD641KS	A75	2	133	μPD4565161G5 ×8 pcs.						
				A10		100							
				A15		66							

★: Under development

■ 184-pin Direct Rambus™ RIMM™

Density (bytes)	Organization (words × bits)	Bank organization	Part number	Class	Clock frequency 1/t _{CYCLE} (MHz)	Access time t _{RAC} (ns)	Supply voltage (V)	Interface level	Mounted devices	Remark
128M	64M × 18	16 × 16	MC-4R128BKD8J	840	400	40	2.5±0.13	RSL	μPD488385FB ×16 pcs.	With heat spreader
				845		45				
				653	300	53				
64M	32M × 18	16 × 8	MC-4R64BKD8J	840	400	40			μPD488385FB ×8 pcs.	With heat spreader
				845		45				
				653	300	53				
—	—	—	MC-4RCNTYK	—	—	—	—	—	—	Note

Note This module is the Direct Rambus RIMM continuity module which is designed to be inserted into any unused RIMM sockets in Direct Rambus systems. It continues the Rambus channel through unused RIMM connectors to terminate signals properly on motherboard, and has no active components mounted on it.

Static RAM

■ Low Power SRAM (Temperature range TA = 0 to 70°C)

Density (bits)	Organization (words × bits)	Part number	Supply voltage (V)	Version	Class	Access time MAX. (ns)	Maximum supply current			Package			
							Active (mA)	Standby (μA)	Data retention (μA)				
1M	128K × 8	μPD431000A	4.5 to 5.5	L	70	70	70	100	50	GW: 32-pin SOP (525 mil)			
					85	85							
				LL	70	70	70	20	10	GW: 32-pin SOP (525 mil) GU: 32-pin TSOP(I) (8 × 13.4 mm) (Normal bent) (Reverse bent) GZ: 32-pin TSOP(I) (8 × 20 mm) (Normal bent) (Reverse bent)			
					85	85	70	20	10	GW: 32-pin SOP (525 mil)			
			3.0 to 5.5	A	10	100	35	13	10	GW: 32-pin SOP (525 mil) GU: 32-pin TSOP(I) (8 × 13.4 mm) (Normal bent) (Reverse bent) GZ: 32-pin TSOP(I) (8 × 20 mm) (Normal bent) (Reverse bent)			
						70 (V _{cc} =4.5 to 5.5)	70	20					
					12	120	35	13					
						70 (V _{cc} =4.5 to 5.5)	70	20					
			2.7 to 5.5	B	10	100	30	11	10	(Normal bent) (Reverse bent)			
						70 (V _{cc} =4.5 to 5.5)	70	20					
					12	120	30	11					
						70 (V _{cc} =4.5 to 5.5)	70	20					
				15	150	30	11						
					70 (V _{cc} =4.5 to 5.5)	70	20						
			256K	32K × 8	μPD43257B	4.5 to 5.5	L	70	70	45	50	20	GU: 28-pin SOP (450 mil)
								85	85				
LL	70	70					45	15	7				
	85	85											
μPD43256B	4.5 to 5.5	L			70	70	45	50	20	GU: 28-pin SOP (450 mil)			
					85	85							
		LL			70	70	45	15	7	GU: 28-pin SOP (450 mil) GW: 28-pin TSOP(I) (8 × 13.4 mm) (Normal bent) (Reverse bent)			
					85	85							
	3.0 to 5.5	A			85	85	45	15	7				
					10	100							
						85 (V _{cc} =4.5 to 5.5)							
					12	120							
					85 (V _{cc} =4.5 to 5.5)								
2.7 to 5.5	B	10			100	20	10	7					
					85 (V _{cc} =4.5 to 5.5)	45	15						
		12			120	20	10						
			85 (V _{cc} =4.5 to 5.5)	45	15								
	15	150	20	10									
		85 (V _{cc} =4.5 to 5.5)	45	15									

Static RAM

■ Low Power SRAM (Extended Temperature TA = -25 to +85°C)

Density (bits)	Organization (words × bits)	Part number	Supply voltage (V)	Version	Class	Access time MAX. (ns)	Maximum supply current			Package			
							Active (mA)	Standby (μ A)	Data retention (μ A)				
4M	512K × 8	μ PD444010L-X	2.7 to 3.6	B	70	70	40	7	7	GY: 48-pin TSOP(I) (12 × 18 mm) (Normal bent) (Reverse bent)			
					85	85							
			2.2 to 3.6	C	10	100							
					12	120							
			1.8 to 3.6	D	12	120							
					15	150							
	256K × 16	μ PD444012L-X	2.7 to 3.6	B	70	70	40	7	7	GY: 48-pin TSOP(I) (12 × 18 mm) (Normal bent) (Reverse bent)			
					85	85							
			2.2 to 3.6	C	10	100							
					12	120							
			1.8 to 3.6	D	12	120							
					15	150							
2M	256K × 8	μ PD442000L-X	2.7 to 3.6	B	85	85	35	2	2	GU: 32-pin TSOP(I) (8 × 13.4 mm) (Normal bent) (Reverse bent) GZ: 32-pin TSOP(I) (8 × 20 mm) (Normal bent) (Reverse bent) F1: 36-pin FPBGA (10.5 × 6.5 mm)			
					10	100							
			2.2 to 3.6	C	10	100	30						
					12	120							
					15	150							
			1.8 to 3.6	D	15	150	25						
	18	180											
	1M	128K × 8			μ PD441000L-X	2.7 to 3.6		B	70	70	25	2	2
			85	85									
						10	100						
						12	120						
			2.2 to 3.6	C		10	100						
12						120							
1.8 to 3.6			D	12	120								
				15	150								
			μ PD431000A-X	4.5 to 5.5	—	70	70	70	50	20	GU: 32-pin TSOP(I) (8 × 13.4 mm) (Normal bent) (Reverse bent) GZ: 32-pin TSOP(I) (8 × 20 mm) (Normal bent) (Reverse bent)		
						85	85						
						10	100						
				3.0 to 5.5	A	10	100	35	26				
	70 (V _{CC} =4.5 to 5.5)					70	50						
	12					120	35	26					
					70 (V _{CC} =4.5 to 5.5)	70	50						
					2.7 to 5.5	B	10	100	30			22	
					70 (V _{CC} =4.5 to 5.5)		70	50					
	12			120	30		22						
				70 (V _{CC} =4.5 to 5.5)	70	50							
				15	150	30	22						
70 (V _{CC} =4.5 to 5.5)			70	50									
256K	32K × 8	μ PD43256B-X	4.5 to 5.5	—	70	70	45	50	20	GW: 28-pin TSOP(I) (8 × 13.4 mm) (Normal bent) (Reverse bent)			
					85	85							
					10	100					40		
			3.0 to 5.5	A	85	85	45				50		
					10	100							
					12	120						40	
					100 (V _{CC} =4.5 to 5.5)								
					2.7 to 5.5	B	10	100				25	25
					12		120	25				25	
			100 (V _{CC} =4.5 to 5.5)	40	50								
					15	150	25	25					
					100 (V _{CC} =4.5 to 5.5)	40	50						

Static RAM

■ CMOS Fast SRAM

Density (bits)	Organization (words × bits)	Part number	Class	Access time MAX. (ns)	Maximum supply current		Supply voltage (V)	Package	Remark
					Active (mA)	Standby (mA)			
4M	4M × 1	μPD434001A	15	15	140	10	5.0±0.5	LE: 32-pin SOJ (400 mil)	
			17	17	130				
			20	20	120				
		μPD434001AL	A15	15	130	5	3.3±0.3	LE: 32-pin SOJ (400 mil) G5: 32-pin TSOP (II) (400 mil)	
			A17	17	120				
			A20	20	110				
	1M × 4	μPD434004A	15	15	140	10	5.0±0.5	LE: 32-pin SOJ (400 mil)	
			17	17	130				
			20	20	120				
		μPD434004AL	A15	15	130	5	3.3±0.3	LE: 32-pin SOJ (400 mil)	
			A17	17	120				
			A20	20	110				
	512K × 8	μPD434008A	12	12	200	10	5.0±0.5	LE: 36-pin SOJ (400 mil)	
			15	15	170				
			17	17	160				
			20	20	150				
		μPD434008AL	A15	15	150	5	3.3±0.3	LE: 36-pin SOJ (400 mil)	
			A17	17	140				
			A20	20	130				
	256K × 16	μPD434016A	12	12	230	10	5.0±0.5	LE: 44-pin SOJ (400 mil) G5: 44-pin TSOP (II) (400 mil)	
			15	15	200				
			17	17	190				
			20	20	180				
		μPD434016AL	A15	15	190	5	3.3±0.3	LE: 44-pin SOJ (400 mil) G5: 44-pin TSOP (II) (400 mil)	
			A17	17	180				
			A20	20	170				

Static RAM

■ CMOS Synchronous Fast SRAM

Density (bits)	Organization (words × bits)	Part number	Class	Clock frequency (MHz)	Clock access time MAX.(ns)	Maximum supply current			Supply voltage (V)		Package	Remark	
						Active (mA)	Standby (mA)	Power down (mA)	Chip	I/O			
2M	64K × 36	μPD432836AL	A36	275	3.53	350	3.5	—	3.3±0.2	2.0	GF: 100-pin LQFP	Pipeline operation	
			A37	267	3.65	350							
			A40	250	3.9	350							
			A44	225	4.34	350							
			A50	200	4.9	350							
			A55	183	5.3	335							
			A57	175	5.3	325							
		A60	167	5.3	290								
		μPD432836L	A40	250	3.9	350	3.5	3.5	3.3±0.2	2.0			
			A44	225	4.34	350							
			A50	200	4.9	350							
			A55	183	5.3	335							
			A57	175	5.3	325							
			A60	167	5.3	290							
	64K × 32		μPD432232L	A5	100	5.0					180	2	2
		A7		83	7.0								
		A8		66	8.0								
1M	32K × 32	μPD431231L	A7	83	7.0	130	5	1	3.3+0.3/-0.2	2.5	GF: 100-pin LQFP	Pipeline operation	
			A8	66	8.0							Pipeline operation	
		μPD431632L	A6	150	4.6	220	20	20	3.3±0.165	3.3 or 2.5		Pipeline operation	
			A7	133	5.0							200	Flow Through operation
		μPD431532L	A8	100	8.5	200	5	5	3.3±0.165	3.3 or 2.5		Flow Through operation	
			A9	100	9.0								
			A10	83	10.0								
			A12	66	12.0								
			32K × 36	μPD431636L	A6								150
		A7			133	5.0	200	Flow Through operation					
		μPD431536L		A8	100	8.5	200	5	5	3.3±0.165		3.3 or 2.5	Flow Through operation
				A9	100	9.0							
	A10			83	10.0								
	A12		66	12.0									

Static RAM

■ Bi-CMOS Synchronous Fast SRAM

Density (bits)	Organization (words × bits)	Part number	Class	Clock frequency (MHz)	Clock access time MAX.(ns)	Maximum supply current		Supply voltage (V)	Interface level	Package	Remark
						Active (mA)	Standby (mA)				
4M	256K × 18	μPD464318AL	A4	250	2.0	550	55	3.3±0.15	HSTL	S1: 119-pin BGA	Single clock RR mode
			A44	225	2.3						
			A5	200	2.5						
		μPD464318L	A5	200	2.6	600	—	3.3±0.15	HSTL		Single clock RR mode
			A6	167	3.0						
			A65	154	3.5						
		μPD464518AL	A55	182	5.5	400	45	3.3±0.15	LVTTTL		Single clock RL mode
			A6	166	6.0						
			A7	143	7.0						
		μPD464518L	A8	125	8.0	450	150	3.3±0.15	LVTTTL		Single clock RL mode
	128K × 36	μPD464336AL	A4	250	2.0	750	55	3.3±0.15	HSTL		Single clock RR mode
			A44	225	2.3						
			A5	200	2.5						
		μPD464336L	A5	200	2.6	700	—	3.3±0.15	HSTL		Single clock RR mode
			A6	167	3.0						
			A65	154	3.5						
		μPD464536AL	A55	182	5.5	650	45	3.3±0.15	LVTTTL		Single clock RL mode
			A6	166	6.0						
			A7	143	7.0						
		μPD464536L	A8	125	8.0	550	150	3.3±0.15	LVTTTL		Single clock RL mode

Mask ROM

■ Mask ROM

Density (bits)	Organization (words × bits)	Part number	Access time MAX. (ns)		Maximum supply current		Supply voltage (V)	Package
			Normal	Page access	Active (mA)	Standby (μA)		
128M	16M × 8 or 8M × 16	μPD23C128000L	120	—	TBD	TBD	3.3±0.3	GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent)
			140				3.0±0.3	
		μPD23C128040L	120	TBD	TBD	TBD	3.3±0.3	GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent)
			140				3.0±0.3	
64M	4M × 16	μPD23C64020	120	—	70	—	5.0±0.5	CZ: 42-pin DIP (600 mil)
	8M × 8 or 4M × 16	μPD23C64000AL	90	—	45	30	3.3±0.3	GX: 44-pin SOP (600 mil)
			100	—	40	30	3.0±0.3	GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent)
		μPD23C64040AL	90	25	60	30	3.3±0.3	GX: 44-pin SOP (600 mil)
			100	30	55	30	3.0±0.3	GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent)
32M	4M × 8 or 2M × 16	μPD23C32000A	120	—	70	100	5.0±0.5	GX: 44-pin SOP (600 mil) GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent) G5: 44-pin TSOP (II) (400 mil)
	2M × 16	μPD23C32020A	120	—	70	100	5.0±0.5	CZ: 42-pin DIP (600 mil)
	4M × 8 or 2M × 16	μPD23C32000L	120	—	40	30	3.3±0.3	GX: 44-pin SOP (600 mil)
			140		35	30	3.0±0.3	GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent) G5: 44-pin TSOP (II) (400 mil)
		μPD23C32040L	140	40	60	30	3.3±0.3	GX: 44-pin SOP (600 mil) GY: 48-pin TSOP (I) (12 × 18 mm) (Normal bent) (Reverse bent) G5: 44-pin TSOP (II) (400 mil)
	2M × 16 or 1M × 32	μPD23C32082L	100	30	80	30	3.3±0.3	G7: 70-pin SSOP (500 mil)
24M	3M × 8 or 1.5M × 16	μPD23C24000	120	—	70	100	5.0±0.5	GX: 44-pin SOP (600 mil)
	1.5M × 16	μPD23C24020	120	—	70	100	5.0±0.5	CZ: 42-pin DIP (600 mil)
16M	2M × 8 or 1M × 16	μPD23C16000AL	85	—	45	30	3.3±0.3	GY: 48-pin TSOP (I) (12 × 18 mm)
			100		40		3.0±0.3	(Normal bent) (Reverse bent)
		μPD23C16040AL	85	30	60	30	3.3±0.3	G5: 44-pin TSOP (II) (400 mil)
			100	40	55		3.0±0.3	

■ Synchronous Mask ROM

Density (bits)	Organization (words × bits)	Part number	Clock fre- quency (MHz)	/CAS latency MIN.	/RAS latency MIN.	Clock access time MAX. (ns)	Maximum supply current active (mA)	Supply voltage (V)	Interface level	Package	Remark
32M	2M × 16 or 1M × 32	μPD23C32202L	66	5	2	10	150	3.3±0.3	LVTTTL	G5: 86-pin TSOP (II) (400 mil)	
			50	4	1	15					
			33	3	1	25					

COMBO Memory

■ COMBO Memory

Part number	Function	Density (bits) Organization (words × bits)	Supply voltage (V)	Access time MAX. (ns)	Maximum supply current			Package
					Active (mA)	Standby (μ A)	Data Retention (μ A)	
μ PD26401	SRAM + ROM	1M (128K × 8) +	1.8 to 2.2	500	3.5	6.5	10	GU: 32-pin TSOP (I) (8 × 13.4 mm) (Normal bent) (Reverse bent)
			2.2 to 2.7	375	5.5	8.0		
		2M (256K × 8)	2.7 to 3.3	250	7.5	10.0		
μ PD26411	SRAM + ROM	1M (128K × 8) +	1.8 to 2.2	500	4.0	6.5	10	GZ: 32-pin TSOP (I) (8 × 20 mm) (Normal bent) (Reverse bent)
			2.2 to 2.7	375	6.0	8.0		
		2M (256K × 8)	2.7 to 3.3	250	10.0	10.0		

Flash Memory

■ Flash Memory

Density (bits)	Organization (words × bits)	Part number	Access time MAX. (ns)	Maximum supply current		Supply voltage (V)	Boot code Sector architecture	Package
				Active (mA)	Standby (μ A)			
8M	1M × 8	μ PD29F008AL-X*	90	12	5	2.7 to 3.6	top or bottom	GZ: 40-pin TSOP (I) (10 × 20 mm) (Normal bent) (Reverse bent)
			100					
			120	12	5	2.2 to 2.7		
			150					
	1M × 8 or 512K × 16	μ PD29F800AL-X*	90	12	5	2.7 to 3.6	top or bottom	GZ: 48-pin TSOP (I) (12 × 20 mm) (Normal bent) (Reverse bent)
			100					
			120	12	5	2.2 to 2.7		
			150					

★: Under development

MCP (Flash Memory + SRAM)

■ MCP (Flash Memory and SRAM)

Part number	Function	Density (bits) Organization (words × bits)	Access time MAX. (ns)	Maximum supply current			Supply Voltage (V)	Boot code Sector architecture	Package
				Active (mA)	Standby (μA)	Data Retention (μA)			
MC-22100	Flash Memory	16M (2M × 8)	100	35	5	—	2.7 to 3.6	Top	F1-DE: 48-pin BGA (10 × 14 mm)
	SRAM	2M (256K × 8)			2	2		—	
MC-22101	Flash Memory	16M (2M × 8)			5	—		Bottom	
	SRAM	2M (256K × 8)			2	2		—	
MC-22102	Flash Memory	16M (1M × 16)			5	—		Top	
	SRAM	2M (256K × 8)			2	2		—	
MC-22103	Flash Memory	16M (1M × 16)			5	—		Bottom	
	SRAM	2M (256K × 8)			2	2		—	
MC-22104	Flash Memory	16M (2M × 8)			5	—		Top	
	SRAM	1M (128K × 8)			26	20		—	
MC-22105	Flash Memory	16M (2M × 8)			5	—		Bottom	
	SRAM	1M (128K × 8)			26	20		—	
MC-22106	Flash Memory	16M (1M × 16)			5	—		Top	
	SRAM	1M (128K × 8)			26	20		—	
MC-22107	Flash Memory	16M (1M × 16)			5	—		Bottom	
	SRAM	1M (128K × 8)			26	20		—	
MC-22000	Flash Memory	8M (1M × 8)			5	—		Top	F1-DB: 48-pin BGA (10 × 11 mm)
	SRAM	2M (256K × 8)			2	2		—	
MC-22001	Flash Memory	8M (1M × 8)			5	—		Bottom	
	SRAM	2M (256K × 8)			2	2		—	
MC-22002	Flash Memory	8M (1M × 8 or 512K × 16)			5	—		Top	
	SRAM	2M (256K × 8)			2	2		—	
MC-22003	Flash Memory	8M (1M × 8 or 512K × 16)			5	—		Bottom	
	SRAM	2M (256K × 8)			2	2		—	
MC-22004	Flash Memory	8M (1M × 8)			5	—		Top	
	SRAM	1M (128K × 8)			26	20		—	
MC-22005	Flash Memory	8M (1M × 8)			5	—		Bottom	
	SRAM	1M (128K × 8)			26	20		—	
MC-22006	Flash Memory	8M (1M × 8 or 512K × 16)			5	—		Top	
	SRAM	1M (128K × 8)			26	20		—	
MC-22007	Flash Memory	8M (1M × 8 or 512K × 16)			5	—		Bottom	
	SRAM	1M (128K × 8)			26	20		—	

Other

■ Line Buffer

Density (bits)	Organi- zation (words × bits)	Part number	Read/Write cycle time MIN. (ns)	Data hold period (ms)	Maximum supply current active (mA)	Supply voltage (V)	Package	Remark
80K	10096 × 8 5048 × 16	μPD485506	25/25 35/35	—	140	5.0±0.5	• 44-pin TSOP II	FAX, PPC Line buffer FIFO structure
40K	5048 × 8	μPD485505	25/25 35/35	—	80		• 24-pin SOP	

[MEMO]

Semi-Custom IC

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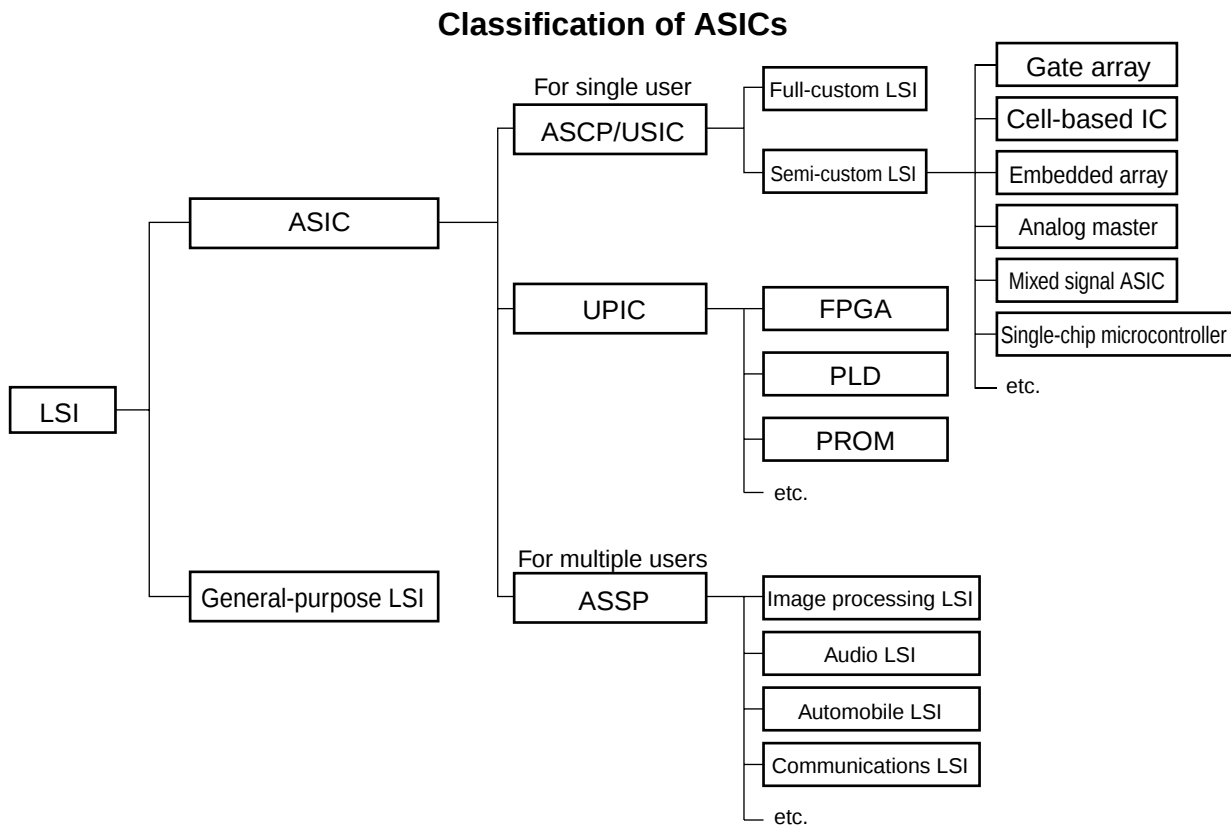
NEC's ASICs

■ What Is ASICs ? (1/2)

LSIs are broadly classified into two types: general-purpose LSIs and Application-Specific ICs (ASICs).

The general-purpose LSIs are designed and supplied as standard products by the manufacturers. Because these LSIs are mass-produced, generally they are inexpensive and do not require much work or expense for development from the user even if each user uses only a small quantity of these LSIs. However, because they are general-purpose products, some of their functions may be redundant for some users, and some functions may not be available. Moreover, the user's own unique functions cannot be provided.

In contrast, ASICs are for specific applications and can be further classified as illustrated below.



Remark ASCPApplication Specific Custom Product
 ASSPApplication Specific Standard Product
 FPGAField Programmable Gate Array
 PLD Programmable Logic Device
 PROMProgrammable Read Only Memory
 USICUser Specific IC
 UPICUser Programmable IC

ASICs are broadly classified into LSIs for single users (ASCPs, USICs, and UPICs) and those for multiple users, as shown above.

NEC's ASICs

■ What Is ASICs ? (2/2)

● ASIC for single users (ASCP/USIC)

ASICs of this type are designed for a specific user and are used for security and to improve performance (such as increasing speed and lowering power consumption). On the other hand, the load on the user for development is heavy. These ASICs are classified into full custom LSIs and semi-custom LSIs.

Full-custom LSIs are developed by the users who have mastered LSI production technologies, and require a long development time and incur large costs. A contract for production with the manufacturer is made on the assumption of mass production of the application system. Usually, the LSIs developed in this way offer extremely high performance.

The word semi-custom LSI is used to differentiate from full-custom LSIs. With full-custom LSIs, all the development processes, from circuit design to photo mask, are tailored to that particular design. In contrast, the elements on the chip of a semi-custom LSI are designed and produced in advance by the manufacturer, and the user builds his own unique functions using these elements. Take gate arrays for example. A common photo mask is used for the diffusion process and only the photo mask for the wiring process is created according to the specifications of the user. This means an LSI can be developed in a shorter time.

● ASIC for single user (UPIC)

FPGA, PLD, and PROM are collectively called UPIC. These are ASICs that can be developed by the user by using dedicated development tools for production runs as small as a single sample.

In particular, because the logical operations of FPGA and PLD are the same as those of gate arrays, these UPICs are highly useful as sample LSIs to evaluate the breadboard and circuit operations before the development of gate arrays. Compared with gate array products, the development cost of UPICs can be kept very low, and the development period is short. For these reasons, UPICs are also used to check parts of large-scale LSIs.

● ASIC for multiple users (ASSP)

ASSPs are standard LSIs produced by the manufacturer for specific fields. Because they are designed and produced by the manufacturer, the user does not have to shoulder any development burden and there is no limit to the production quantity. These LSIs include graphics display controllers and field memories.

NEC's ASICs**■ Selecting an LSI**

Users' products increasingly require the following features:

High added value
Implementation in software
Total solutions
System integration, etc.

Integrating the circuits formerly implemented with conventional ICs using an ASIC is the best way to achieve these things. Consequently, it is important to select an ASIC manufacturer who can provide you with powerful device technology, system technology, and upstream software support.

NEC offers a variety of ASIC products that can satisfy every user's needs, as well as comprehensive support. The key to selecting the most suitable ASIC product is completely understanding the characteristics required by the entire system to be developed and the circuits to be integrated into an ASIC.

These characteristics include the following conditions:

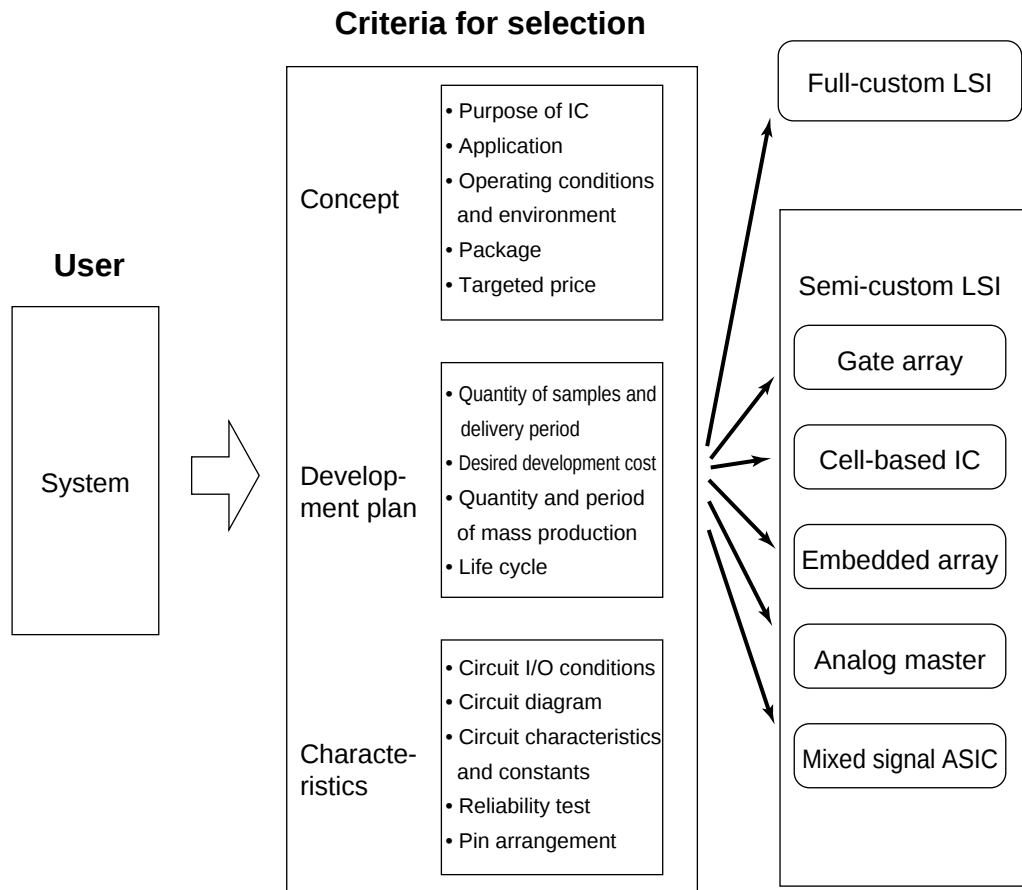
- Development investment
- Development period (delivery period)
- Quantity of production
- Necessary functions and performance
- Application

If you use the list of criteria on the next page, taking these points into consideration, you can find the ASIC you really need.

NEC's ASICs

■ Criteria for Selection (1/4)

Whether a full-custom or semi-custom LSI should be used, or whether ASSP or general-purpose LSI should be used depend on your concept, development plan, and the characteristics you require. By considering the items in the following diagram you can select the products that satisfy all your requirements. The subsequent sections 1 through 4 compare the major semi-custom products and full-custom products for your reference.



NEC's ASICs

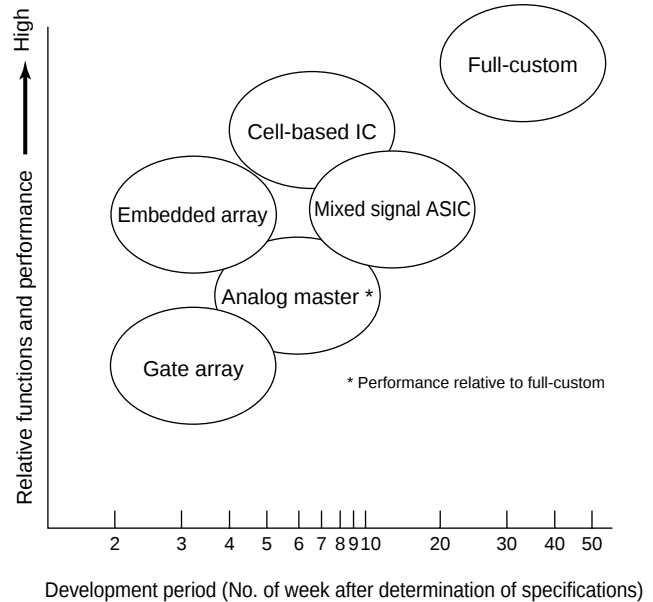
■ Criteria for Selection (2/4)

● Development Period and Relative Performance

As shown in the figure on the right, full-custom LSIs have high performance but require a long development period. In contrast, the development period of semi-custom LSIs, such as gate arrays and analog masters, is shorter, although these LSIs have some redundant functions.

For embedded arrays, the wafer is produced when the macros to be used have been determined. In the meantime, the circuits are determined through simulation. After simulation has been completed, only the wiring process is left, and development can be completed in almost the same period as gate arrays. If the macros and gate scale of the wafer are the same as those of gate arrays, the wafer can be used as a master wafer; consequently, the development period is equivalent to that of gate arrays.

Cell-based ICs, and new semi-custom LSIs fall somewhere between full-custom LSIs and gate arrays. Although these LSIs offer performance and functions comparable to those of full-custom LSIs, their development period is only slightly longer than that of gate arrays.



NEC's ASICs

■ Criteria for Selection (3/4)

● Development Investment and Element Cost

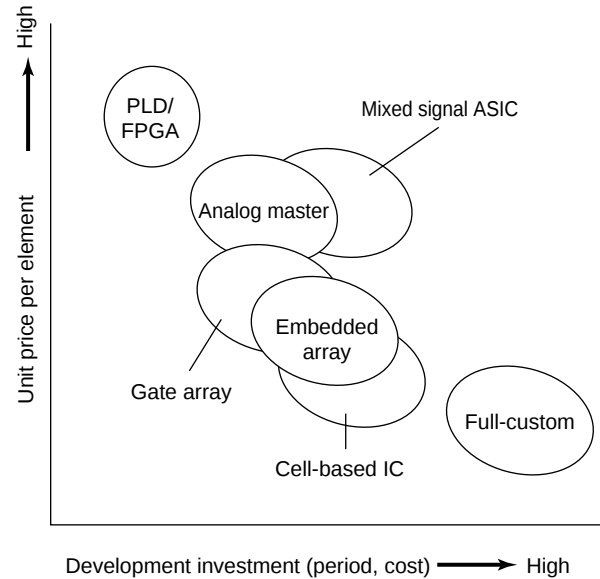
As shown in the figure on the right, there is an clear relationship between the development investment and unit cost.

PLD (Programmable Logic Device) and FPGA (Field Programmable Gate Array) are types of general-purpose LSIs with a design philosophy close to that of gate arrays. You can purchase one unit of these LSIs, and can program and use the LSI on the day you purchase it. Therefore, the development investment is extremely low. However, the price per element of PLDs and FPGAs is high.

Conversely, although the development period and cost of a full-custom LSI are higher, the unit price of each element is very low, partly because almost 100% of the elements are used and partly because the full-custom LSI is usually mass-produced.

The various semi-custom LSI products fall between these two. Therefore, semi-custom LSIs are ideal if the development period and cost are limited and at the same time, the unit price of the element must be kept low.

In addition, because many development tools and standard cell libraries are available for semi-custom LSIs, the development period can be further shortened.



NEC's ASICs

■ Criteria for Selection (4/4)

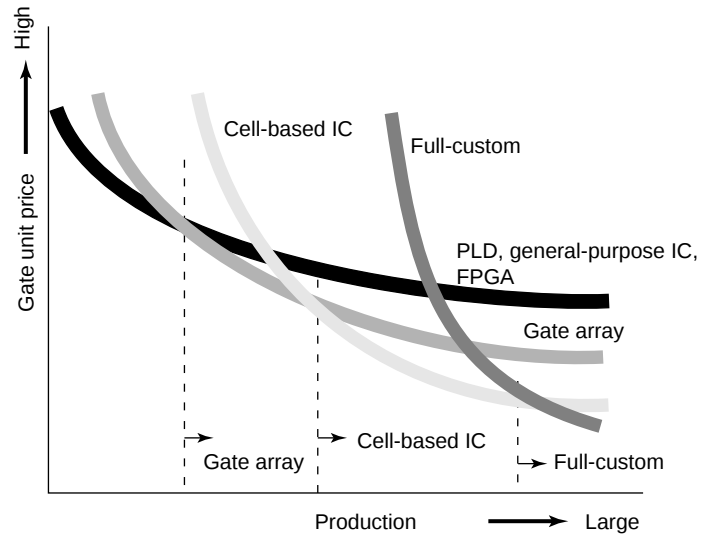
● Total Production and Gate Units (Guideline)

One of the indexes that indicate the price of an LSI is a gate unit price. The gate unit price of PLD and general-purpose LSIs is low if the production is small. However, the unit price does not decrease even if the volume of production increases.

Full-custom LSIs are not profitable unless they are produced in a large quantity.

Semi-custom LSIs can be profitable whether they are produced in a small or large quantity.

Of these semi-custom LSIs, gate arrays are more suitable for small-scale production than cell-based ICs.

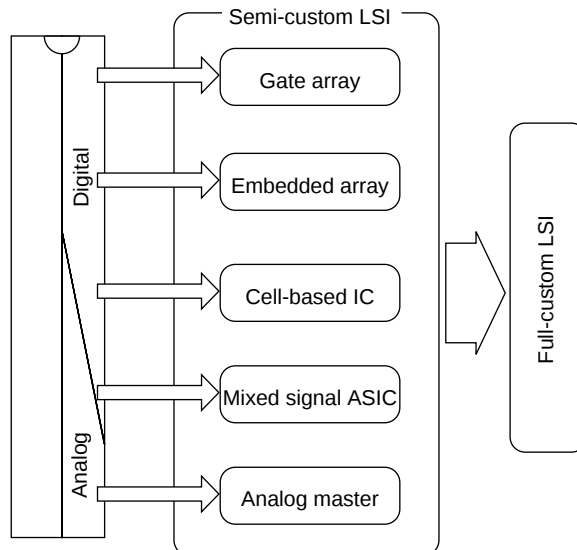


● Suitability for Different Types of Circuit

Circuits can be broadly classified into analog circuits and digital circuits.

As shown in the figure on the right, among the semi-custom LSIs gate arrays are suitable for digital circuits, and analog masters can be used to integrate analog circuits. Cell-based ICs are mainly used for digital circuits, but can also be used to combine analog and digital circuits.

A complicated circuit with a special configuration that cannot be realized using semi-custom LSI must be created as a full-custom LSI. A full-custom LSI can be used to integrate both analog circuits and digital circuits.



NEC's ASICs

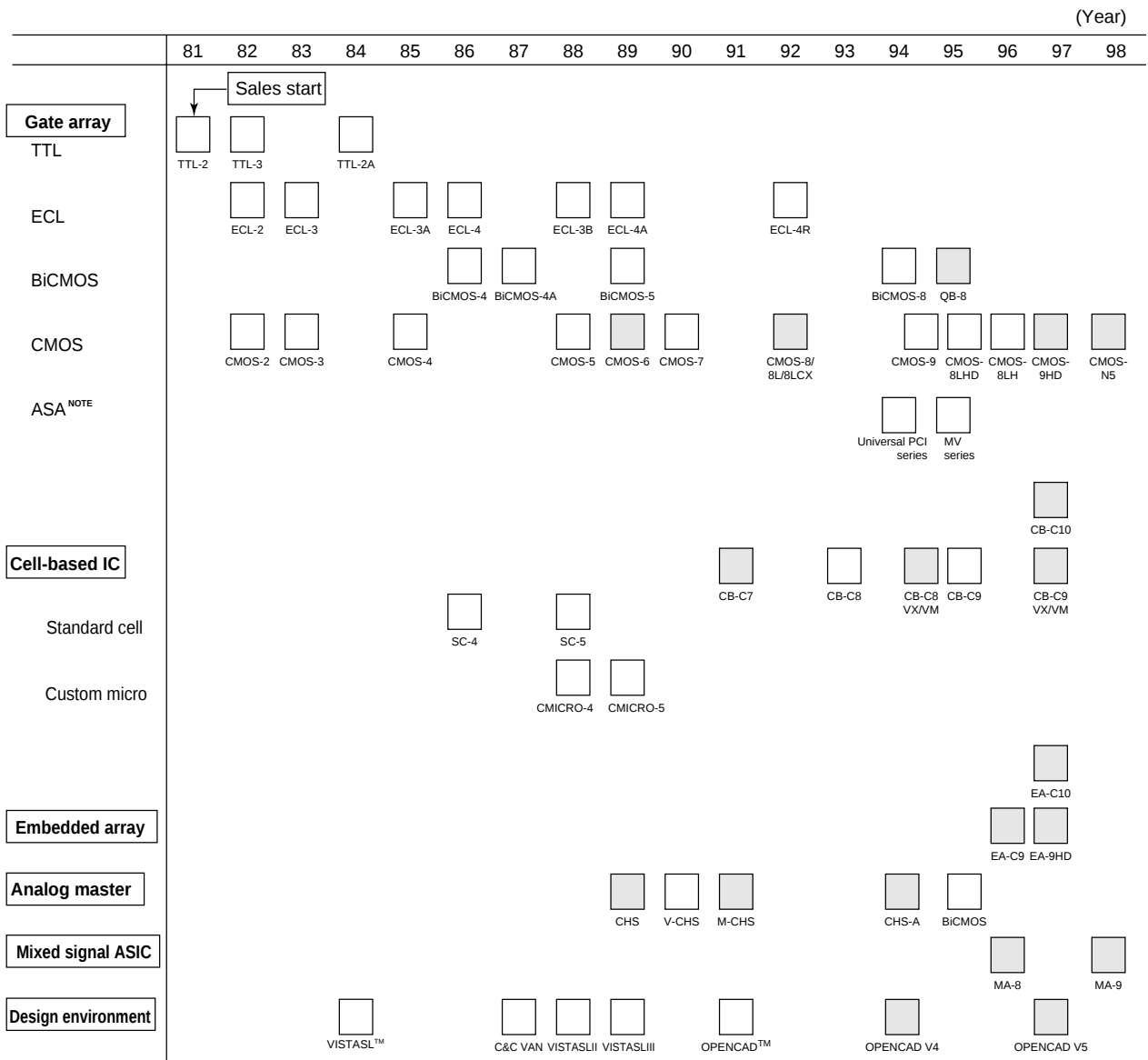
History of Development of ASIC

NEC developed device technology and basic software for its ASICs in the 1970's, and started sales of its ASICs from 1981.

Semi-custom LSIs were first developed in response to demands to improve the performance of systems such as computers and private branch exchanges. When the advantages of ASICs became more widely recognized as device development and tool organization advanced in the 1980's, the use of ASICs increasingly became widespread.

Today, users who have experience of development using gate arrays wish to develop using ASICs to achieve a larger scale and higher performance. Consequently, device manufacturers are required to supply state-of-the-art semiconductor chips and efficient design environments.

To satisfy these requirements, NEC supplies a wide range of services including an extensive line-up of processes and technologies, and integrated CAD systems using original EWS and networking.



Note Application Specific Arrays

Remark □ : Maintenance parts

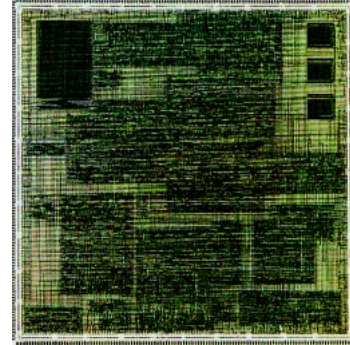
NEC's ASICs**■ NEC's ASIC Products (1/2)****● Gate array**

Gate arrays are semi-custom LSIs. Gates are laid out on master wafers in the form of an array. These gates are wired together to create the desired LSI.

To lay out gates, an area where no gates are placed may be provided on the wafer (channel structure) or gates may be laid out over the entire surface of the wafer (channel-less structure).

The channel gate arrays have fixed wiring areas and gate areas. Almost all the gates of these gate arrays can be used. However, it is difficult to integrate memories on these gate arrays.

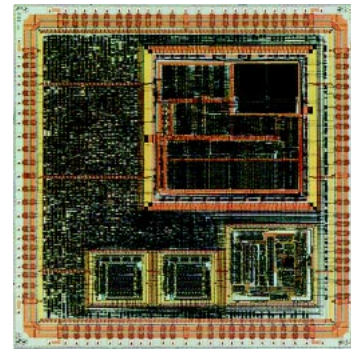
The channel-less gate arrays can be used to integrate a large-scale system on a single chip. They allow you to determine the width of the wiring area and the shape of the gates freely and to integrate memories efficiently.

**● Cell-based IC**

Cell-based ICs are high-performance semi-custom LSIs for integrating memories such as RAM and ROM, CPU, CPU peripherals, and analog circuits, as well as logic, on a single chip, by means of a building block type standard cell design technique.

Cell-based ICs cannot only realize a density higher than gate arrays and embedded arrays, but also integrate high-performance macros. Therefore, they have increasingly grown in popularity recently as semi-custom LSIs for achieving systems-on-chip.

Unlike gate arrays, no master wafers are available for cell-based ICs, and a cell-based IC is processed from the very first process, i.e., the diffusion process, to satisfy the user's particular requirements.



NEC's ASICs

■ NEC's ASIC Products (2/2)

● Embedded array

Embedded arrays are high-performance semi-custom LSIs that use the basic cells of a gate array in the internal area, and that can be used to integrate memories like cell-based ICs, such as RAM and ROM.

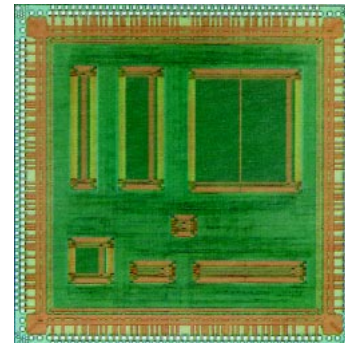
LSIs with sophisticated functions and high performance comparable to those of cell-based ICs can be created.

Because the wafer is produced in parallel with simulation, only the wiring process must be done after simulation has been completed. Consequently, the development period up to completion of a sample is as short as that of gate arrays.

If a cell-based IC is used for initial production, the production of the system can be started in a short time.

If the macro configuration and gate scale are the same, the same master wafer can be used to develop other LSIs. Therefore, many variations of LSIs can be created at a lower cost than cell-based ICs.

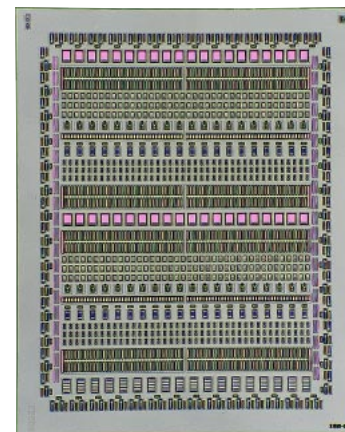
In addition, the circuits of embedded arrays can be easily modified, so that the risk involved in development can be lowered.



● Analog master

An analog master is used to create an analog LSI by using a master wafer on which transistors, resistors, and capacitors are laid out in advance, and designing the appropriate wiring in a similar way to when a gate array is used.

If you think it would be too difficult to create a full-custom analog circuit from the viewpoint of development period, cost, and the quantity of ICs used, the analog master is the ideal product.

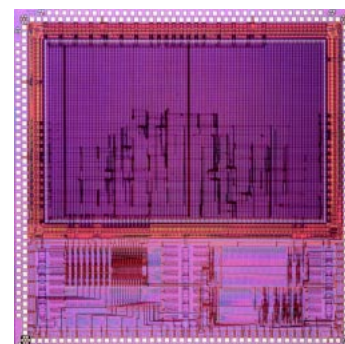


● Mixed signal ASIC

This is a semi-custom LSI that integrates the functions of a CMOS gate array and an analog semi-custom IC on a single chip.

The gate array block consists of the basic cells of a CMOS gate array, and can be designed in the same manner as a gate array.

The analog delay block incorporates CMOS transistors and bipolar transistors for analog circuits, so that high-performance analog circuits can be constructed.



0.25 μm ASIC**■ EA-C10 Family****● Features (1/3)**

High-density, super high-speed, and low-power consumption embedded array using the most advanced 0.25 μm technology

- High-level function and high-performance LSI compatible to cell-based IC
- 2.5 V/3.3 V interface
- Short turn around time equivalent to gate array
- High-density of system-on-a-chip level
- Easy development and modification of derivative models
- Macro maintenance common to cell-based IC (CB-C10) (including analog circuit)

Family Name		EA-C10
Maximum density (total number of gates)		7 million gates
Supply voltage		2.5 V $\pm$ 0.2 V
Delay time	Internal gate ^{Note 1}	59 ps
	Input buffer ^{Note 2}	79 ps
	Output buffer ^{Note 3}	1363 ps
Power consumption		0.14 $\mu\text{W}/\text{MHz}/\text{cell}$ (internal gates)

Notes 1. 2-input NAND power gate, fanout: 1, wiring length: 0.5 mm

2. Fanout: 2, wiring length: 0 mm

3. Load capacitance: 50 pF, $I_{OL} = 12 \text{ mA}$

0.25 μ m ASIC**■ EA-C10 Family****● Features (2/3)****Wide variety of macro libraries (1/2)**

Functional cell
Logic gate
Delay gate
Adder
Decoder
Multiplexer
Latch
Flip-flop
Shift register
Counter

Compiled macro (cell-based IC type)
High-speed 1-port RAM
High-speed 2-port RAM
Super high-speed 1-port RAM
High-density 1-port RAM
High-density 2-port RAM
High-speed ROM

Mega macro to be developed					
Macro name	PC	Consumer	Portable equipment	Communication	Graphic
PCI controller	○				
USB	○				
IEEE1394	○	○			
V8xx CPU		○	○		
Vr4xxx CPU		○	○		
V30MZ™		○	○		
MPEG2 (decoder)		○			
A/D, D/A		○			
Modem CODEC		○			
DSP (SPRX, OAK/Pine)	○	○	○		
ARM CPU		○	○		
ATM (25MHz, 155MHz)				○	
Ethernet 10/100 Base PHY, MAC				○	
RAC (Rambus™ ASIC Core cell)					○
2D, 3D accelerator					○

Remarks 1. The release schedule differs depending on the macro. For details, consult NEC.
2. Including macro libraries under development and under study

0.25 μ m ASIC**■ EA-C10 Family****● Features (3/3)****Wide variety of macro libraries (2/2)**

I/O buffer
LVC MOS/LVTTL
Slew rate buffer
3-state buffer
Open-drain buffer

Others
DPLL (to 250 MHz)
APLL (to 500 MHz)
Multiplier
UART
Register file
DRAM
Flash memory
Scan block
JTAG

High-speed I/O
GTL/GTL+ (Gunning Transceiver Logic)
PCI ^{Note 1} (Peripheral Component Interconnect)
HSTL (High Speed Transceiver Logic)
pECL (Pseudo Emitter Coupled Logic)
SSTL (Stub Series Terminated Transfer Logic)
LVDS (Low Voltage Differential Signaling)
USB (Universal Serial Bus)
IEEE1394

RAM macro (gate array type) ^{Note 2}
High-speed 1-port RAM
High-speed 2-port RAM

Notes 1. Interface standard proposed by Intel.

2. RAM macro for gate array. Bit/word fixed.

Remarks 1. The release schedule differs depending on the macro. For details, consult NEC.

2. Including macro libraries under development and under study

0.25 μm ASIC**■ CB-C10 Family****● Features (1/3)****High-density, super high-speed, and low-power consumption cell-based IC using the most advanced 0.25 μm technology**

In addition to featuring a high-density of 20 million gates (MAX.) and low-power consumption, high-speed internal gates, the EA-C10 Family achieves system-on-chip capabilities through a wide variety of application-oriented macros.

Furthermore, a macro library which operates on low voltage (to 1.8 V) is also being prepared.

Family Name		CB-C10
Maximum density (number of usable gates)		20M gates (15M gates)
Supply voltage		2.5 V $\pm$ 0.2 V
Delay time	Internal gate ^{Note 1}	93.4 ps
	Input buffer ^{Note 2}	31.5 ps
	Output buffer ^{Note 3}	1363 ps
Power consumption		0.04 $\mu\text{W}/\text{MHz}/\text{gate}$

Note 1. 2-input NAND power gate, fanout: 1, wiring length: 0 mm

2. Fanout: 2, wiring length: 0 mm

3. Load capacitance: 50 pF, I_{OL} = 12 mA

0.25 μ m ASIC**■ CB-C10 Family****● Features (2/3)****Wide variety of macro libraries (1/2)**

Functional cell
Logic gate
Delay gate
Adder
Decoder
Multiplexer
Latch
Flip-flop
Shift register
Counter

Compiled macro
High-speed 1-port RAM
High-speed 2-port RAM
Super high-speed 1-port RAM
High-density 1-port RAM
High-density 2-port RAM
High-speed ROM

Mega macro to be developed					
Macro name	PC	Consumer	Portable equipment	Communication	Graphic
PCI controller	○				
USB	○				
IEEE1394	○	○			
V8xx CPU		○	○		
Vr4xxx CPU		○	○		
V30MZ		○	○		
MPEG2 (decoder)		○			
A/D, D/A		○			
Modem CODEC		○			
DSP (SPRX, OAK/Pine)	○	○	○		
ARM CPU		○	○		
ATM (25MHz, 155MHz)				○	
Ethernet 10/100 Base PHY, MAC				○	
RAC (Rambus™ ASIC Core cell)					○
2D, 3D accelerator					○

- Remarks 1.** The release schedule differs depending on the macro. For details, consult NEC.
2. Including macro libraries under development and under study

0.25 μ m ASIC**■ CB-C10 Family****● Features (3/3)****Wide variety of macro libraries (2/2)**

I/O buffer
LVCMOS/LVTTL
Slew rate buffer
3-state buffer
Open-drain buffer

Others
DPLL (to 250 MHz)
APLL (to 500 MHz)
Multiplier
UART
Register file
DRAM
Flash memory
Scan block
JTAG

High-speed I/O
GTL/GTL+ (Gunning Transceiver Logic)
PCI ^{Note} (Peripheral Component Interconnect)
HSTL (High Speed Transceiver Logic)
pECL (Pseudo Emitter Coupled Logic)
SSTL (Stub Series Terminated Transfer Logic)
LVDS (Low Voltage Differential Signaling)
USB (Universal Serial Bus)
IEEE1394

Note Interface standard proposed by Intel.

Remarks 1. The release schedule differs depending on the macro. For details, consult NEC.
2. Including macro libraries under development and under study

Gate Array

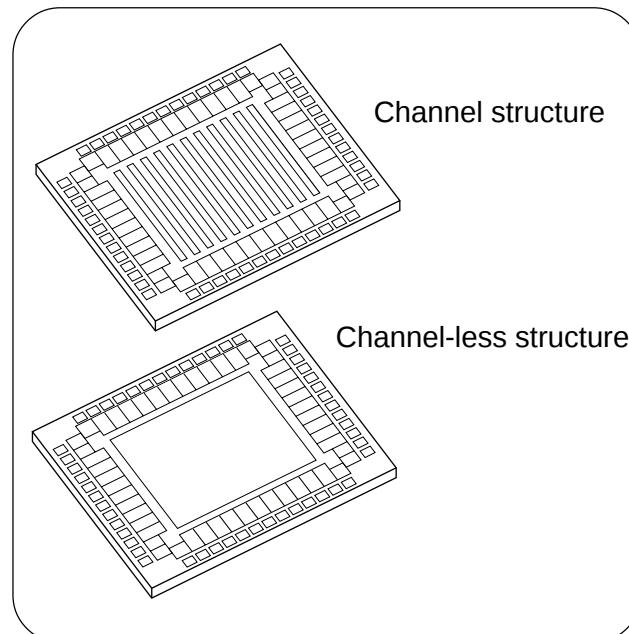
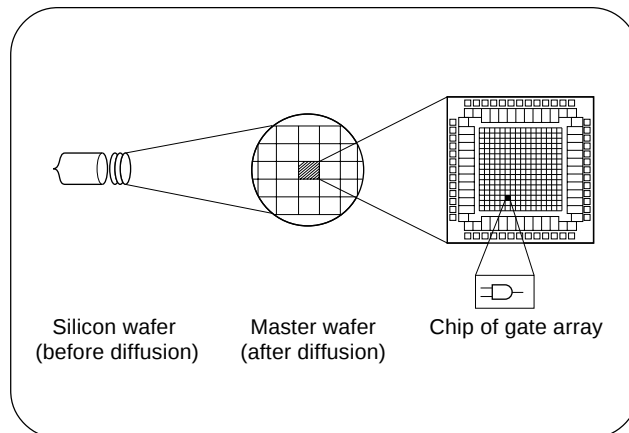
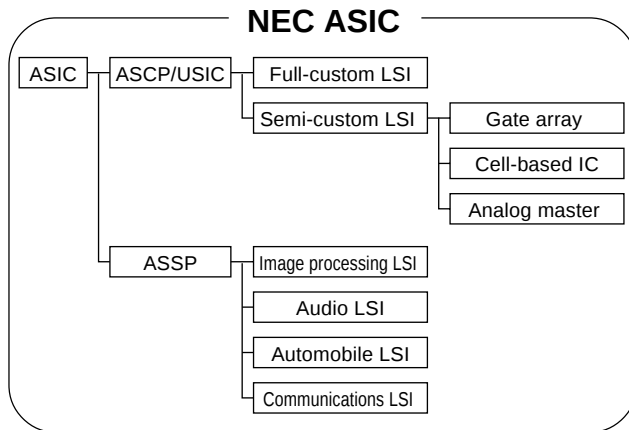
■ What Is a Gate Array ?

When producing LSIs, the diffusion process that forms elements such as transistors on a silicon wafer takes a long time. With gate arrays, manufacturers can supply wafers called master wafers whose diffusion process has been completed. On a master wafer, logic gates (basic cells) are arranged in the shape of a grid (array). These basic cells are not wired to each other at first, and are electrically independent. When the required circuit has been determined, these basic cells are combined to create it. Therefore, because the user produce product in the short time required for the processes following the wiring process, very short development times are possible. In addition, even a small quantity of products can be produced at a low cost by individually wiring master wafers chosen from the many different types readily available.

As the density of gate arrays has increased, a type called the channel-less gate array that can be used to integrate a large-scale system on a single chip has come into the spotlight.

A channel-less gate array does not have a wiring area, unlike conventional gate arrays, but has transistors over its entire surface. The major features of the channel-less gate array, in addition to a short development period, are as follows:

- Memories can be efficiently implemented.
- The width of the wiring area and the shapes of the gates can be determined as you like.

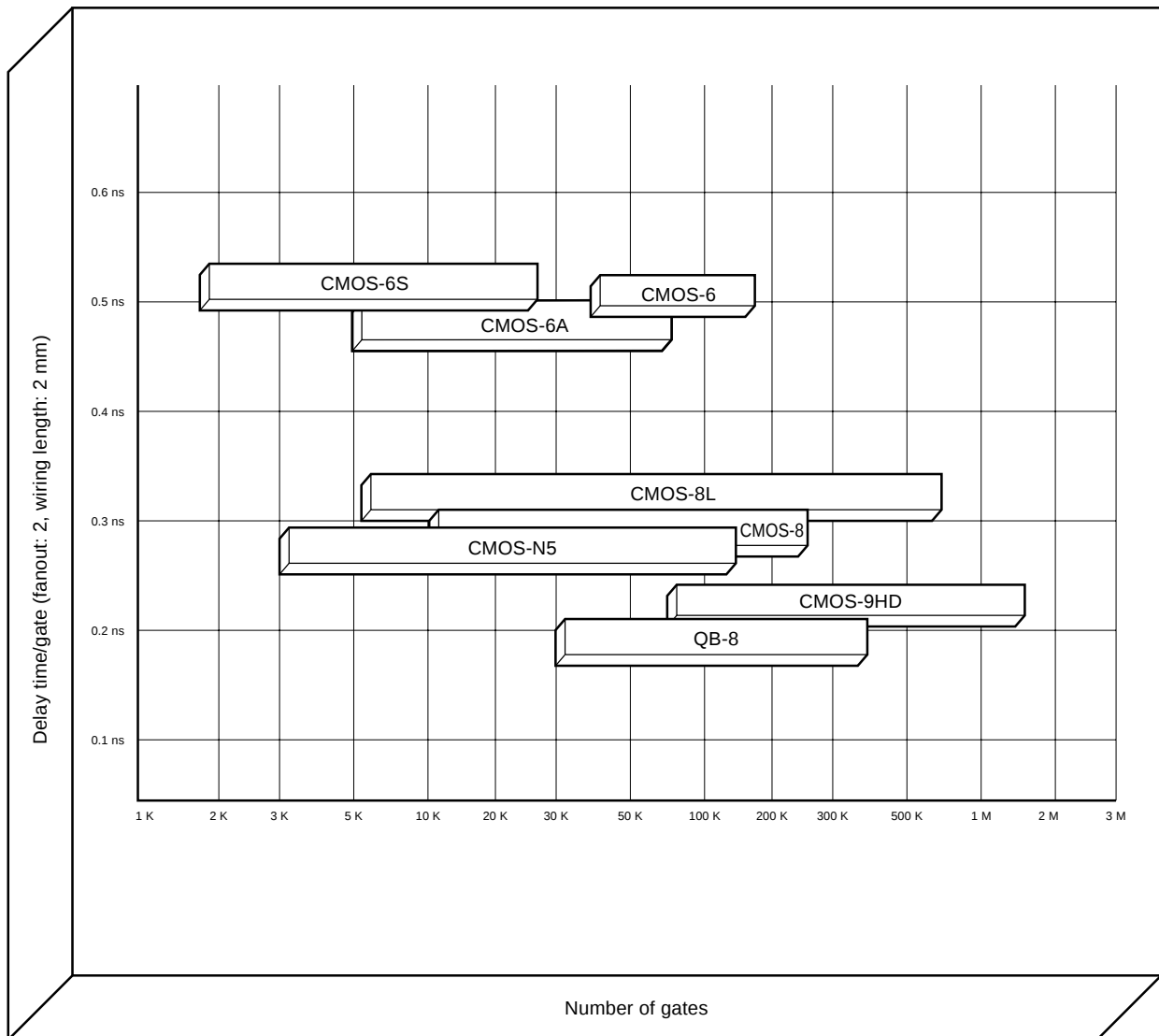


Gate Array

■ Product Line-Up

NEC offers 89 different gate array models (78 CMOS models, 11 BiCMOS models) with the world's highest performance and density, backed up by its leading-edge technology. These gate arrays are employed in a wide range of fields, such as electronic games, household appliances, optical communications equipment, and super computers.

Product Line-up



Channel-less CMOS : CMOS-N5, CMOS-9HD, CMOS-8, CMOS-8L, CMOS-6, CMOS-6A, CMOS-6S
 BiCMOS : QB-8

Gate Array**■ Features of NEC Gate Arrays****Wide variety of models**

Many different models are available, suitable for all kinds of systems.

CMOS gate arrays : 7 families, 78 models

BiCMOS gate arrays : 1 families, 11 models

High density and high speed thanks to leading edge technology

The CMOS-9HD family employs a 0.35- μm CMOS technology, 3-layer wiring technology, and channel-less structure. As a result, a density of up to 1.6M gates (1.1M usable gates) and a speed of 107ps have been achieved, enabling large-scale system integration on a single chip.

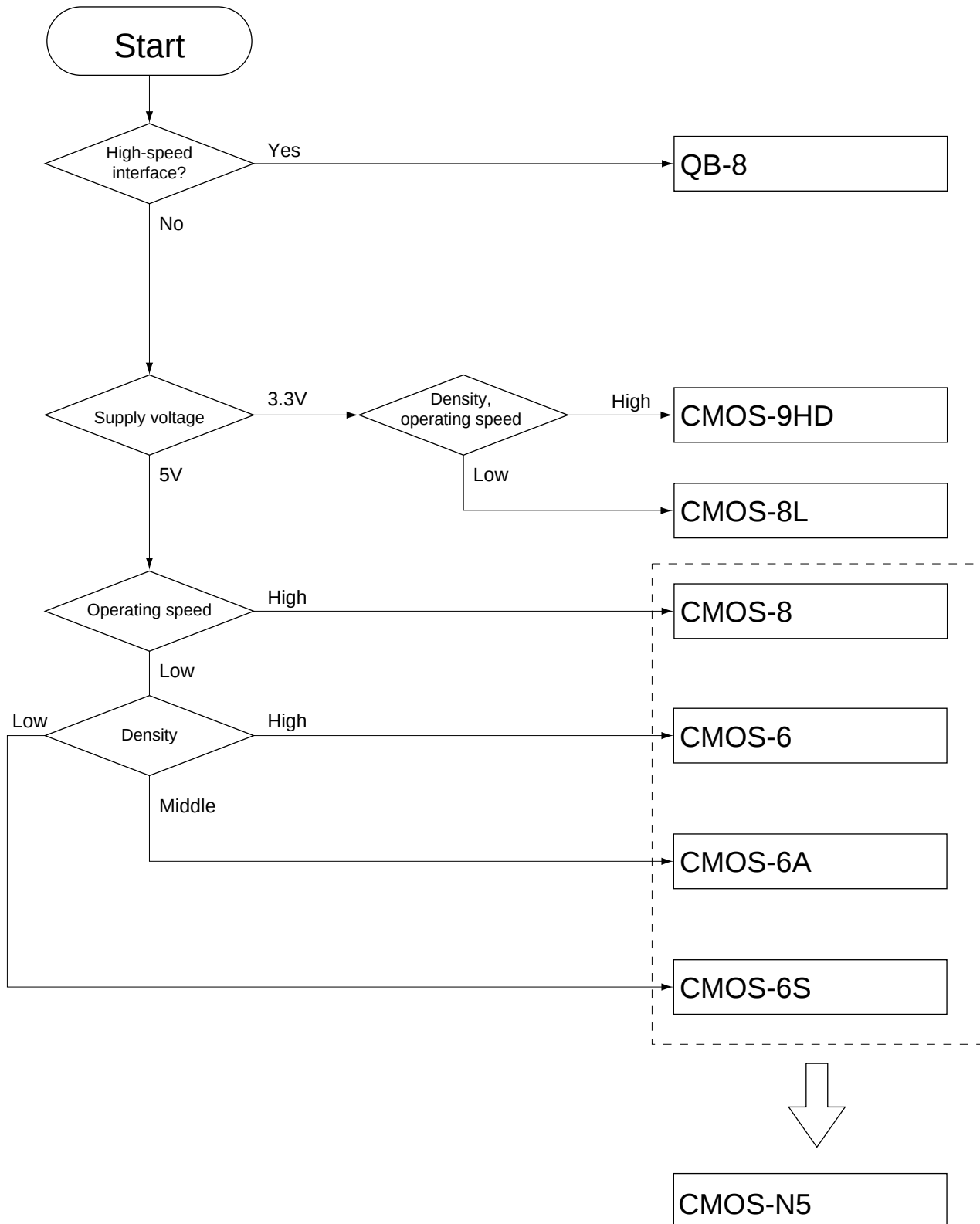
Drastic cost reduction

The CMOS-N5 family is a gate array that provides high-speed operation with a 5-V power supply voltage. Drastic cost reductions have been achieved thanks to higher integration by the adoption of 0.5 μm technology (2-layer wiring), and lowering the package assembly cost.

High-level gate arrays from many libraries

Because many library functions are available, it's easy to improve the functionality of your system. Moreover, every technology is standardized to facilitate design.

Macros of large-scale CPU peripheral circuits are available for CMOS gate arrays, shortening the designing period and improving the functionality of your systems.

Gate Array**■ Which Gate Arrays Is Best-Suited to Your System ?**

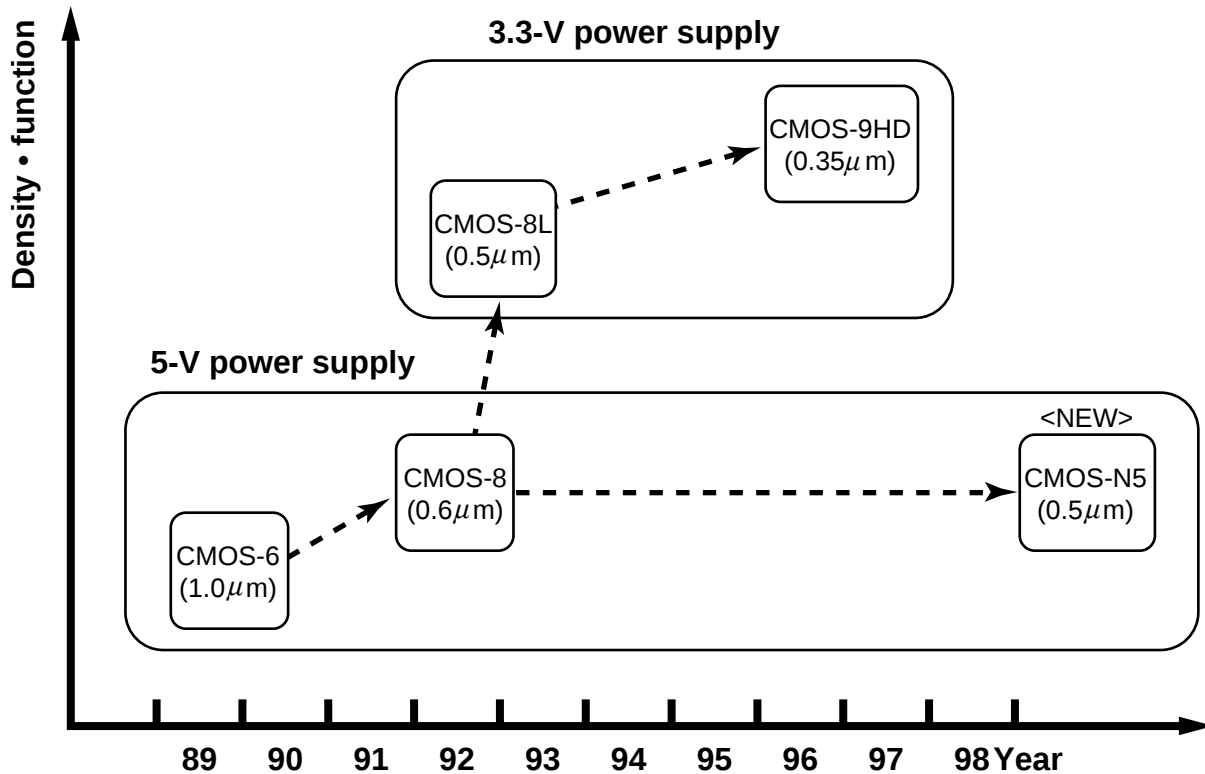
Gate Array

■ CMOS Gate Arrays

● Product Line-Up

NEC offer many types of CMOS gate arrays including the CMOS-6 family with a design rule of $1.0\ \mu\text{m}$ and the CMOS-9HD family with a design rule of $0.35\ \mu\text{m}$.

These CMOS gate arrays have densities from 1.8K gates to 1.6M gates (78 models) and satisfy a wide range of user needs by providing compound functions with integrated memories and keeping the operating voltage low.



Gate Array

CMOS Gate Array

■ CMOS-6 Family

● Available Models

		μ PD65658	μ PD65664	μ PD65672	μ PD65676
Density	Number of integrated gates*	42240	72576	119232	177408
	Number of usable gates**	31680	54432	89424	133056
	Number of pads ^{Note}	236	304	384	464
Delay time	Internal gate	0.5 ns (fanout: 2, wiring length: 2 mm)			
	Power gate	0.4 ns (fanout: 2, wiring length: 2 mm)			
	Input buffer	1.0 ns (fanout: 2, wiring length: 2 mm)			
	Output buffer	2.0 ns ($C_L = 15$ pF)			
Output drive capability		$I_{OL} = 4.5, 9.0, 13.5, 18.0, 24.0$ mA			
Supply voltage		5 V			
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 75 %			

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

■ CMOS-6A Family

● Available Models

		μ PD65630	μ PD65636	μ PD65640	μ PD65646	μ PD65650	μ PD65654	μ PD65656	μ PD65662
Density	Number of integrated gates*	5376	8000	11520	16240	21120	30720	40480	70272
	Number of usable gates**	3225	4800	6912	9744	12672	18432	24288	42163
	Number of pads ^{Note}	100	116	136	156	176	208	220	288
Delay time	Internal gate	0.5 ns (fanout: 2, wiring length: 2 mm)							
	Power gate	0.4 ns (fanout: 2, wiring length: 2 mm)							
	Input buffer	1.0 ns (fanout: 2, wiring length: 2 mm)							
	Output buffer	2.0 ns ($C_L = 15$ pF)							
Output drive capability		$I_{OL} = 4.5, 9.0, 13.5, 18.0, 24.0$ mA							
Supply voltage		5 V							
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 60 %							

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

CMOS Gate Array

■ CMOS-6S Family

● Available Models

		μ PD65611	μ PD65621	μ PD65625	μ PD65643	μ PD65653
Density	Internal gates*	1836	3484	5312	13416	25488
	Number of usable gates**	1101	2090	3187	8049	15292
	Number of pads ^{Note}	80	100	120	176	236
Delay time	Internal gate	0.5 ns (fanout: 2, wiring length: 2 mm)				
	Power gate	0.4 ns (fanout: 2, wiring length: 2 mm)				
	Input buffer	1.0 ns (fanout: 2, wiring length: 2 mm)				
	Output buffer	2.0 ns ($C_L = 15$ pF)				
Output drive capability		$I_{OL} = 4.5, 9.0, 13.5, 18.0, 24.0$ mA				
Supply voltage		5 V				
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 60 %				

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

CMOS Gate Array

■ CMOS-6/6A/6S Family

● Library

I/O buffer	Function block	Memory block	Mega macro
Function	Function	Function	Function
Input buffer Output buffer Bidirectional buffer Low-noise buffer Fail-safe buffer Oscillation circuit	Logic gate Buffer Inverter 3-state buffer Driver Delay Adder Decoder Multiplexer Latch Flip-flop Shift register Counter Others	High-speed single-port RAM High-speed dual-port RAM High-density single-port RAM Compiled RAM ROM	DMA controller Serial interface unit Parallel interface unit Timer/counter Interrupt controller

● Characteristics

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{DD}	-0.5 to +6.5	V
Input/output voltage	V_I/V_O	-0.5 to $V_{DD} + 0.5$	V
Output current	I_O	40 ^{Note1}	mA
Output current	I_O	30 ^{Note2}	mA
Output current	I_O	20 ^{Note3}	mA
Output current	I_O	10 ^{Note4}	mA
Operating temperature	T_A	-40 to +85	°C
Storage temperature	T_{Stg}	-65 to +150	°C

- Notes**
1. I_{OL} (MIN.) = 18.0 mA type
 2. I_{OL} (MIN.) = 13.5 mA type
 3. I_{OL} (MIN.) = 9.0 mA type
 4. I_{OL} (MIN.) = 4.5 mA type

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

Recommended Operating Conditions

Parameter	Symbol	CMOS Level		TTL Level		Unit
		MIN.	MAX.	MIN.	MAX.	
Supply voltage	V_{DD}	4.5	5.5	4.75	5.25	V
High-level input voltage	V_{IH}	0.7 V_{DD}	V_{DD}	2.2	V_{DD}	V
Low-level input voltage	V_{IL}	0	0.3 V_{DD}	0	0.8	V
Input rise time	t_r	0	200	0	200	ns
Input fall time	t_f	0	200	0	200	ns
Positive trigger voltage	V_P	1.8	4.0	1.2	2.4	V
Negative trigger voltage	V_N	0.6	3.1	0.6	1.8	V
Hysteresis voltage	V_H	0.3	1.5	0.3	1.5	V

DC Characteristics

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Static current consumption		I_{DDs}	$V_I = V_{DD}$ or GND		0.1	280	μA
Off-state output leakage current		I_{OZ}	$V_O = V_{DD}$ or GND			± 10	μA
Output short-circuit current		I_{OS}	$V_O = 0V$			-250	mA
Input leakage current	Normal input	I_I	$V_I = V_{DD}$ or GND		$\pm 10^{-5}$	± 10	μA
	with pull-up (50 k Ω)	I_I	$V_I = GND$	-45	-131	-320	μA
	with pull-up (5 k Ω)	I_I	$V_I = GND$	-0.35	-1.0	-2.2	mA
	with pull-down (50 k Ω)	I_I	$V_I = V_{DD}$	45	131	320	μA
High-level output voltage (CMOS)		V_{OH}	$I_{OH} = 0mA$	$V_{DD} - 0.1$			V
High-level output voltage (TTL)		V_{OH}	$I_{OH} = 0mA$	2.6			V
Low-level output voltage		V_{OL}	$I_{OL} = 0mA$			0.1	V

Remark The above values are under the recommended operating conditions shown above.

For the details of the DC characteristics when other supply voltage (3.0 V $\pm$ 10%) is used, refer to the **Design Manual**.

Gate Array

CMOS Gate Array

■ CMOS-8 Family

● Available Models (2-layer wiring)

		μ PD65800	μ PD65801	μ PD65802	μ PD65803
Density	Number of integrated gates*	11712	21504	32000	42688
	Number of usable gates**	7027	12902	19200	25612
	Number of pads ^{Note}	172	228	268	308
Delay time	Internal gate	0.29 ns (fanout: 2, wiring length: 2 mm)			
	Power gate	0.20 ns (fanout: 2, wiring length: 2 mm)			
	Input buffer	0.36 ns (fanout: 2, wiring length: 2 mm)			
	Output buffer	1.73 ns ($C_L = 15$ pF)			
Output drive capability		$I_{OL} = 3.0, 6.0, 9.0, 12.0, 18.0, 24.0$ mA			
Supply voltage		5 V $\pm$ 10% (CMOS level), 5 V $\pm$ 5% (TTL level)			
Remark		* 2-input NAND conversion ** Cell utilization rate: 60 %			

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

● Available Models (3-layer wiring)

		μ PD65804	μ PD65806	μ PD65808	μ PD65810	μ PD65811	μ PD65812	μ PD65813
Density	Number of integrated gates*	42688	58752	82432	103680	138776	176720	233280
	Number of usable gates**	32016	44064	61824	77760	104082	132540	174960
	Number of pads ^{Note}	308	356	420	468	524	588	676
Delay time	Internal gate	0.29 ns (fanout: 2, wiring length: 2 mm)						
	Power gate	0.20 ns (fanout: 2, wiring length: 2 mm)						
	Input buffer	0.36 ns (fanout: 2, wiring length: 2 mm)						
	Output buffer	1.73 ns ($C_L = 15$ pF)						
Output drive capability		$I_{OL} = 3.0, 6.0, 9.0, 12.0, 18.0, 24.0$ mA						
Supply voltage		5 V $\pm$ 10% (CMOS level), 5 V $\pm$ 5 % (TTL level)						
Remark		* 2-input NAND conversion ** Cell utilization rate: 75 %						

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

CMOS Gate Array

■ CMOS-8 Family

● Library

I/O buffer	Function block	Memory block	Mega macro
Function	Function	Function	Function
Input buffer Output buffer Bidirectional buffer Low-noise buffer Fail-safe buffer PCI buffer GTL (under development) D-PLL (under development) Oscillation circuit	Logic gate Buffer Inverter 3-state buffer Clock driver Delay Adder Decoder Multiplexer Latch Flip-flop Shift register Counter Others	High-speed single-port RAM High-speed dual-port RAM High-density single-port RAM ROM	DMA controller Serial interface unit Parallel interface unit Timer/counter Interrupt controller

● Characteristics

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{DD}	-0.5 to +6.5	V
Input/output voltage	V_I/V_O	-0.5 to $V_{DD} + 0.5$	V
Output current	I_O	60 ^{Note1}	mA
Output current	I_O	40 ^{Note2}	mA
Output current	I_O	30 ^{Note3}	mA
Output current	I_O	20 ^{Note4}	mA
Output current	I_O	15 ^{Note5}	mA
Output current	I_O	10 ^{Note6}	mA
Operating temperature	T_A	-40 to +85	°C
Storage temperature	T_{Stg}	-65 to +150	°C

Recommended Operating Conditions

Parameter	Symbol	CMOS Level		TTL Level		Unit
		MIN.	MAX.	MIN.	MAX.	
Supply voltage	V_{DD}	4.5	5.5	4.75	5.25	V
High-level input voltage	V_{IH}	0.7 V_{DD}	V_{DD}	2.2	V_{DD}	V
Low-level input voltage	V_{IL}	0	0.3 V_{DD}	0	0.8	V
Input rise time	t_r	0	200	0	200	ns
Input fall time	t_f	0	200	0	200	ns
Positive trigger voltage	V_P	1.8	4.0	1.2	2.4	V
Negative trigger voltage	V_N	0.6	3.1	0.6	1.8	V
Hysteresis voltage	V_H	0.3	1.5	0.3	1.5	V

Notes 1. I_{OL} (MIN.) = 24.0 mA type 4. I_{OL} (MIN.) = 9.0 mA type
 2. I_{OL} (MIN.) = 18.0 mA type 5. I_{OL} (MIN.) = 6.0 mA type
 3. I_{OL} (MIN.) = 12.0 mA type 6. I_{OL} (MIN.) = 3.0 mA type

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

DC Characteristics

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Static current consumption		I_{DDs}	$V_I = V_{DD}$ or GND		0.1	200	μA
Off-state output leakage current		I_{OZ}	$V_O = V_{DD}$ or GND			± 10	μA
Output short-circuit current		I_{OS}	$V_O = 0V$			-250	mA
Input leakage current	Normal input	I_I	$V_I = V_{DD}$ or GND		$\pm 10^{-5}$	± 10	μA
	with pull-up (50 k Ω)	I_I	$V_I = GND$	-45	-131	-320	μA
	with pull-up (5 k Ω)	I_I	$V_I = GND$	-0.35	-1.0	-2.2	mA
	with pull-down (50 k Ω)	I_I	$V_I = V_{DD}$	45	131	320	μA
High-level output voltage (CMOS)		V_{OH}	$I_{OH} = 0$ mA	$V_{DD} - 0.1$			V
High-level output voltage (TTL)		V_{OH}	$I_{OH} = 0$ mA	2.6			V
Low-level output voltage		V_{OL}	$I_{OL} = 0$ mA			0.1	V

Remark The above values are under the recommended operating conditions shown above. For the details refer to the **Design Manual**.

Gate Array

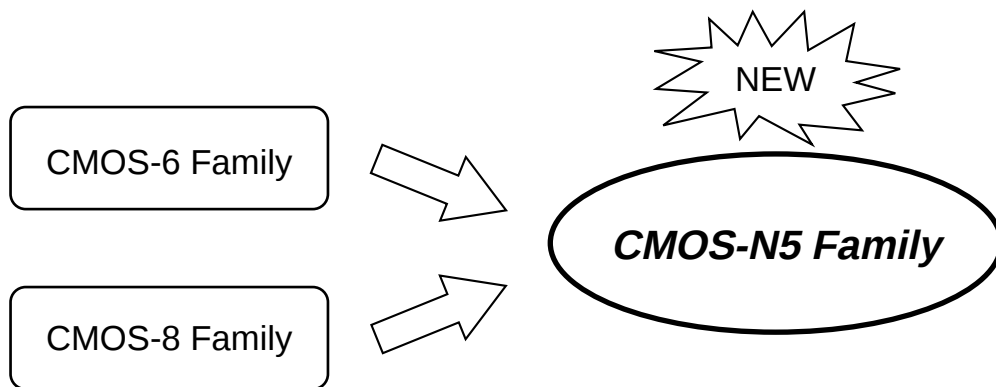
CMOS Gate Array

■ CMOS-N5 Family

● Features

The CMOS-N5 family is a channel-less type gate array that provides high speed operation with a 5-V power supply voltage.

Drastic cost reductions have been achieved compared with the conventional CMOS-6 and CMOS-8 families thanks to higher integration by the adoption of 0.5 μm technology (2-layer wiring), and lowering the package assembly cost.



Integration

- 3K to 120K gates (number of integrated gates)
- 2K to 74K gates (number of usable gates)

High-speed operation (preliminary)

- $t_{PD} = 0.2 \text{ ns}$ (2-input NAND (power gate), fanout = 2, standard wiring length)
- Operating frequency: 60 MHz max.

Function blocks

- RAM block (1 port/2 ports)
- Oscillation block
- CTS block

Gate Array

CMOS Gate Array

■ CMOS-N5 Family

● Available Models (Preliminary)

		μ PD65880	μ PD65881	μ PD65882	μ PD65883	μ PD65884	μ PD65885	μ PD65887	μ PD65889	μ PD65890	μ PD65893
Density	Number of integrated gates*	3456	5880	13952	25344	33864	40768	56496	76000	99528	123384
	Number of usable gates**	2073	3528	8371	15206	20318	24460	33897	45600	59716	74030
	Number of pads ^{Note}	72	88	120	160	184	244	284	324	372	412
Delay time	Internal gate	0.29 ns (fanout: 2, standard wiring length)									
	Power gate	0.20 ns (fanout: 2, standard wiring length)									
	Input buffer	0.36 ns (fanout: 2, standard wiring length)									
	Output buffer	1.73 ns ($C_L = 15$ pF)									
Output drive capability		$I_{OL} = 3, 6, 9, 12, 18, 24$ mA									
Supply voltage		5 V $\pm$ 10 % (CMOS level)									
Remark		* 2-input NAND conversion ** Cell utilization rate: 60 %									

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

CMOS Gate Array

■ CMOS-8L Family

● Available Models (2-layer wiring)

		μ PD65837	μ PD65839	μ PD65840	μ PD65841	μ PD65842	μ PD65843	μ PD65845	μ PD65846
Density	Number of integrated gates*	4480	7904	10912	20832	30192	40592	52528	61904
	Number of usable gates**	2912	5137	6547	12499	18115	24355	31516	37142
	Number of pads ^{Note}	80	104	164	204	212	244	276	300
Delay time	Internal gate	0.33 ns (fanout: 2, wiring length: 2 mm)							
	Power gate	0.21 ns (fanout: 2, wiring length: 2 mm)							
	Input buffer	0.71 ns (fanout: 2, wiring length: 2 mm)							
	Output buffer	1.44 ns ($C_L = 15$ pF)							
Output drive capability		$I_{OL} = 3, 6, 9, 12, 18, 24$ mA							
Supply voltage		3.3 V ± 0.3 V							
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 60 %							

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

		μ PD65848	μ PD65849	μ PD65850	μ PD65851	μ PD65852	μ PD65853	μ PD65855	μ PD65858
Density	Number of integrated gates*	81984	102272	120768	148256	202752	255744	342000	488720
	Number of usable gates**	49190	61363	72460	88953	121651	153446	205200	293232
	Number of pads ^{Note}	340	380	412	452	524	588	676	804
Delay time	Internal gate	0.33 ns (fanout: 2, wiring length: 2 mm)							
	Power gate	0.21 ns (fanout: 2, wiring length: 2 mm)							
	Input buffer	0.71 ns (fanout: 2, wiring length: 2 mm)							
	Output buffer	1.44 ns ($C_L = 15$ pF)							
Output drive capability		$I_{OL} = 3, 6, 9, 12, 18, 24$ mA							
Supply voltage		3.3 V ± 0.3 V							
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 60 %							

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

CMOS Gate Array

■ CMOS-8L Family

● Available Models (3-layer wiring)

		μ PD65860	μ PD65861	μ PD65862	μ PD65863	μ PD65865	μ PD65866	μ PD65868	μ PD65869
Density	Number of integrated gates*	10912	20832	30192	40592	52528	61904	81984	102272
	Number of usable gates**	8184	15624	22644	30444	39396	46428	61488	76704
	Number of pads ^{Note}	164	204	212	244	276	300	340	380
Delay time	Internal gate	0.33 ns (fanout: 2, wiring length: 2 mm)							
	Power gate	0.21 ns (fanout: 2, wiring length: 2 mm)							
	Input buffer	0.71 ns (fanout: 2, wiring length: 2 mm)							
	Output buffer	1.44 ns ($C_L = 15$ pF)							
Output drive capability		$I_{OL} = 3, 6, 9, 12, 18, 24$ mA							
Supply voltage		$3.3\text{ V} \pm 0.3\text{ V}$							
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 75 %							

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

		μ PD65870	μ PD65871	μ PD65872	μ PD65873	μ PD65875	μ PD65878
Density	Number of integrated gates*	120768	148256	202752	255744	342000	488720
	Number of usable gates**	90576	111192	152064	191808	256500	366540
	Number of pads ^{Note}	412	452	524	588	676	804
Delay time	Internal gate	0.33 ns (fanout: 2, wiring length: 2 mm)					
	Power gate	0.21 ns (fanout: 2, wiring length: 2 mm)					
	Input buffer	0.71 ns (fanout: 2, wiring length: 2 mm)					
	Output buffer	1.44 ns ($C_L = 15$ pF)					
Output drive capability		$I_{OL} = 3, 6, 9, 12, 18, 24$ mA					
Supply voltage		$3.3\text{ V} \pm 0.3\text{ V}$					
Remark		* 2-input NAND conversion (1 cell = 1 gate) ** Cell utilization rate: 75 %					

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

CMOS Gate Array

■ CMOS-8L Family

● Library

I/O buffer	Function block	Memory block	Mega macro
Function	Function	Function	Function
3 V Input buffer Output buffer Bidirectional buffer PCI buffer 5 V (level shifter) Input buffer Output buffer Bidirectional buffer GTL D-PLL	Logic gate Buffer Inverter 3-state buffer Clock driver Delay Adder Decoder Multiplexer Latch Flip-flop Shift register Counter Others	High-speed single-port RAM High-speed dual-port RAM High-density single-port RAM ROM	DMA controller Serial interface unit Parallel interface unit Timer/counter Interrupt controller

Gate Array

CMOS Gate Array

■ CMOS-8L Family

● Characteristics

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V_{DD}	-0.5 to +4.6	V
Input/output voltage (3-V interface block)	V_I/V_O	-0.5 to +4.6	V
Input/output voltage (5-V interface block)	V_I/V_O	-0.5 to +6.6	V
Output current	I_O	3 ^{Note1}	mA
Output current	I_O	7 ^{Note2}	mA
Output current	I_O	10 ^{Note3}	mA
Output current	I_O	20 ^{Note4}	mA
Output current	I_O	30 ^{Note5}	mA
Output current	I_O	40 ^{Note6}	mA
Output current	I_O	60 ^{Note7}	mA
Output current	I_O	80 ^{Note8}	mA
Operating temperature	T_A	-40 to +85	°C
Storage temperature	T_{stg}	-65 to +150	°C

- Notes**
1. I_{OL} (MIN.) = 1.0 mA type
 2. I_{OL} (MIN.) = 2.0 mA type
 3. I_{OL} (MIN.) = 3.0 mA type
 4. I_{OL} (MIN.) = 6.0 mA type
 5. I_{OL} (MIN.) = 9.0 mA type
 6. I_{OL} (MIN.) = 12.0 mA type
 7. I_{OL} (MIN.) = 18.0 mA type
 8. I_{OL} (MIN.) = 24.0 mA type

Recommended Operating Conditions

Parameter	Symbol	$V_{DD} = 3.3V \pm 0.3V$		Unit
		MIN.	MAX.	
Supply voltage	V_{DD}	3.0	3.6	V
High-level input voltage (3-V interface block)	V_{IH}	2.0	V_{DD}	V
High-level input voltage (5-V interface block)	V_{IH}	2.0	5.5	V
Low-level input voltage (3-V interface block)	V_{IL}	0	0.8	V
Low-level input voltage (5-V interface block)	V_{IL}	0	0.8	V
Input rise time	t_r	0	200	ns
Input fall time	t_f	0	200	ns
Positive trigger voltage (3-V interface block)	V_P	1.70	2.70	V
Positive trigger voltage (5-V interface block)	V_P	2.20	2.55	V
Negative trigger voltage (3-V interface block)	V_N	0.60	1.20	V
Negative trigger voltage (5-V interface block)	V_N	0.84	1.01	V
Hysteresis voltage (3-V interface block)	V_H	1.10	1.50	V
Hysteresis voltage (5-V interface block)	V_H	1.36	1.54	V

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

DC Characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Static current consumption	I_{DDS}				300	μA
Off-state output leakage current	I_{OZ}				± 18	μA
Output short-circuit current	I_{OS}				-250	mA
Input leakage current	Normal input	$V_I = V_{DD}$ or GND		$\pm 10^{-5}$	± 10	μA
	with pull-up (50 k Ω)	$V_I = GND$	-10	-40	-80	μA
	with pull-up (5 k Ω)	$V_I = GND$	-130	-350	-640	μA
	with pull-down (50 k Ω)	$V_I = V_{DD}$	30	65	130	μA
High-level output voltage (3-V interface block)	V_{OH}	$I_{OH} = 0$ mA	$V_{DD} - 0.1$			V
High-level output voltage (5-V interface block)	V_{OH}	$I_{OH} = 0$ mA	$V_{DD} - 0.2$			V
Low-level output voltage	V_{OL}	$I_{OL} = 0$ mA			0.1	V

- Remark 1.** The above values are under the recommended operating conditions shown above. For details, refer to the **Design Manual**.
2. Blank indicates value is under study.

Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Features

The CMOS-9HD family is a collection of channel-less gate arrays employing a 0.35- μm technology. This family consists of 10 masters with 75K to 1.6M gates.

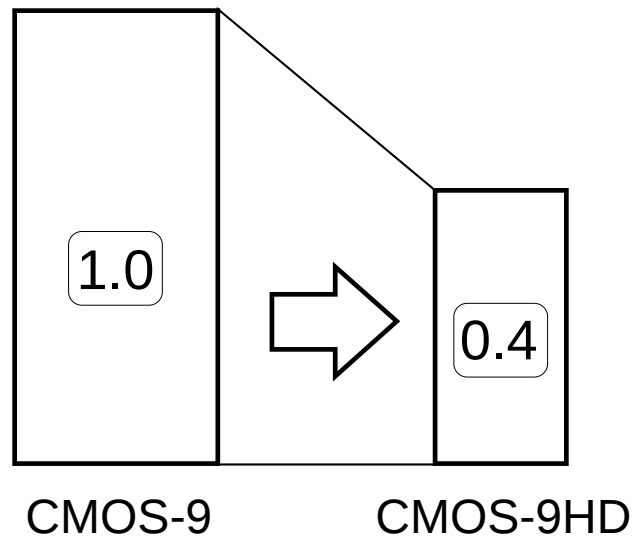
The most outstanding feature of this family is the scale of integration.

The gate density of this family is about 2.5 times higher than that of the existing CMOS-9 family 0.35- μm gate arrays, thanks to improvement of the cell structure.

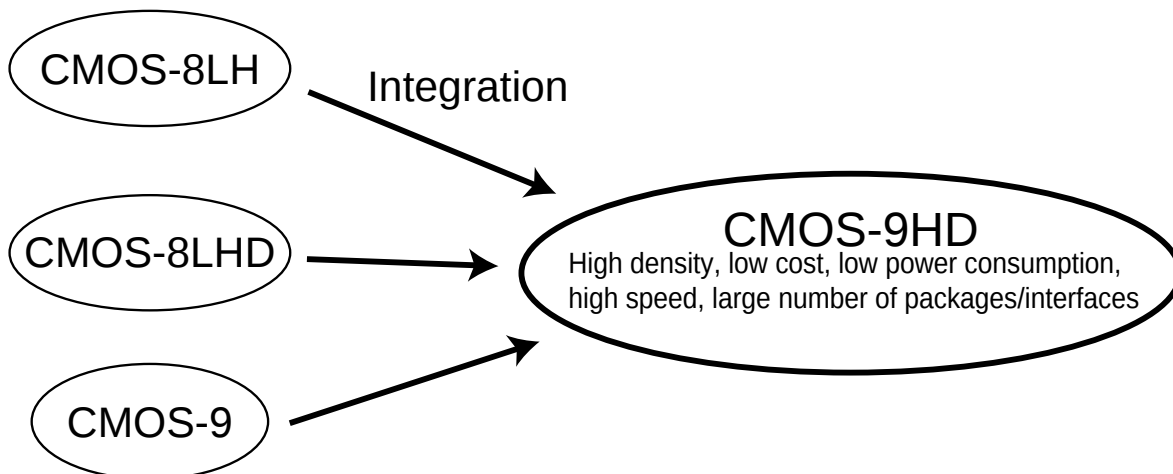
In addition, the power consumption is 30 % lower, and thanks to new I/O pad layout technology, this family offers a large number of pins in addition to the high density.

Conventional (CMOS-9)

Gate density: 2.5 times higher
Power consumption: 30% lower



Conventional



Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Available Models (3-layer wiring)

		μ PD65943	μ PD65944	μ PD65945	μ PD65946	μ PD65948	μ PD65949	μ PD65951	μ PD65954	μ PD65956	μ PD65958
Density	Internal gates*	75740	100602	128338	202630	312684	437136	585390	835664	1096452	1615646
	Number of usable gates**	53018	70421	89836	141841	218878	305995	351234	501398	657871	969387
	Number of pads ^{Note}	172	196	216	268	324	380	436	516	588	708
Delay time	Internal gate	131 ps (2-input NAND, fanout: 1, standard wiring length)									
	Power gate	107 ps (2-input NAND, fanout: 1, standard wiring length)									
	Input buffer	229 ps (fanout: 2, standard wiring length)									
	Output buffer	1396 ps ($C_L = 15$ pF, $I_{OL} = 9$ mA)									
Output drive capability		$I_{OL} = 1, 2, 3, 6, 9, 12, 18, 24$ mA									
Supply voltage		3.3 V $\pm$ 0.3 V									
Remark		* 2-input NAND conversion ** Cell utilization rate: 70 % (60 % in the largest four masters)									

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

● Library

I/O buffer	Function block	Memory block	Mega macro (under development)
Function	Function	Function	Function
3 V Input buffer Output buffer Bidirectional buffer PCI buffer Low-noise buffer Fail-safe buffer 5 V (level shifter) Input buffer Output buffer Bidirectional buffer GTL (under development) D-PLL (under development)	Logic gate Buffer Inverter 3-state buffer Clock driver Delay Adder Decoder Multiplexer Latch Flip-flop Shift register Counter Others	High-speed single-port RAM High-speed dual-port RAM	DMA controller Serial interface unit Parallel interface unit Timer/counter Interrupt controller

Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Characteristics (1/5)

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	V_{DD}		−0.5 to +4.6	V
Input voltage				
3-V input buffer	V_i	$V_i < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
3-V input buffer with fail-safe function	V_i	$V_i < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
5-V input buffer	V_i	$V_i < V_{DD} + 0.5 \text{ V}$	−0.5 to +6.6	V
Output voltage				
3-V output buffer	V_o	$V_o < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
TTL 5-V output buffer	V_o	$V_o < V_{DD} + 3.0 \text{ V}$	−0.5 to +6.6	V
CMOS 5-V output buffer	V_o	$V_o < V_{DD} + 3.0 \text{ V}$	−0.5 to +6.6	V
Output current ^{Note}	I_o	$I_{OL} = 1 \text{ mA(FV0B)}$	3	mA
		$I_{OL} = 2 \text{ mA(FV0B)}$	7	mA
		$I_{OL} = 3 \text{ mA(FO09,FV09)}$	10	mA
		$I_{OL} = 6 \text{ mA(FO04,FV04)}$	20	mA
		$I_{OL} = 9 \text{ mA(FO01,FV01)}$	30	mA
		$I_{OL} = 12 \text{ mA(FO02)}$	40	mA
		$I_{OL} = 18 \text{ mA(FO03)}$	60	mA
		$I_{OL} = 24 \text{ mA(FO06)}$	75	mA
Operating temperature	T_A		−40 to +85	°C
Storage temperature	T_{stg}		−65 to +150	°C

Note Input current: Maximum value of current that can flow via input protection diode. Output current: Maximum DC current that can flow through output pin

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

Remark Apart from the buffer with the fail-safe function, apply 5 V or 3 V to the I/O pin after the supply voltage has been stabilized.

Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Characteristics (2/5)

Recommended Operating Conditions

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply voltage	V_{DD}		3.00	3.30	3.60	V
High-level input voltage	V_{IH}	• LVTTL interface buffer	2.00		V_{DD}	V
Low-level input voltage	V_{IL}	• LVTTL interface buffer with fail-safe function	0		0.80	V
Positive trigger voltage	V_P	Schmitt input	1.50		2.70	V
Negative trigger voltage	V_N		0.60		1.40	V
Hysteresis voltage	V_H		1.10		1.50	V
High-level input voltage	V_{IH}	• TTL 5-V tolerant interface buffer	2.00		5.50	V
Low-level input voltage	V_{IL}	• 5-V input buffer	0		0.80	V
Positive trigger voltage	V_P	Schmitt input	2.20		2.55	V
Negative trigger voltage	V_N		0.84		1.01	V
Hysteresis voltage	V_H		1.36		1.54	V
Input rise time	t_{ri}	Normal input	0		200	ns
Input fall time	t_{fi}		0		200	ns
Input rise time	t_{ri}	Schmitt input ^{Note}	0		10	ms
Input fall time	t_{fi}		0		10	ms

Note Do not use this for the clock.

Remark If a signal with a long rise/fall time is input, use a Schmitt trigger input buffer to prevent malfunctioning due to noise superimposed on the signal line.

Fluctuation of power caused by simultaneous operation of output buffers lower the capability of the Schmitt trigger input buffer, and therefore, care must be exercised in laying out the pins.

Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Characteristics (3/5)

The following values are under the recommended operating conditions shown above. For details, refer to the **Design Manual**.

DC Characteristics (1/3)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Static current consumption ^{Note1}						
μ PD65943, 65944, 65945	I_{DD5}	$V_I = V_{DD}$ or GND		2.0	300	μA
μ PD65946, 65948, 65949	I_{DD5}	$V_O = V_{DD}$ or GND		0	400	μA
μ PD65951, 65954, 65956	I_{DD5}	$V_O = V_{DD}$ or GND		4.0	800	μA
Off-state output leakage current ^{Note2}						
3-V output	I_{OZ}	$V_O = V_{DD}$ or GND			± 10	μA
TTL 5-V output	I_{OZ}	$V_O = V_{DD}$ or GND			± 10	μA
CMOS 5-V output	I_{OZ}	$V_O = V_{DD}$ or GND			± 10	μA
Output sink current ^{Note3}						
CMOS 5-V output	I_R	$V_{PU} = 5.5 V$ $R_{PU} = 2 k\Omega$ $V_O = 3.0 V$			10	μA
Output short-circuit current ^{Note4}						
	I_{OS}	$V_O = GND$			-250	mA
Input leakage current						
Normal input	I_I	$V_I = V_{DD}$ or GND			± 1.0	μA
With pull-up resistor (50 k Ω)	I_I	$V_I = GND$	28	83	190	μA
With pull-up resistor (5 k Ω)	I_I	$V_I = GND$	280	700	1900	μA
With pull-down resistor (50 k Ω)	I_I	$V_I = V_{DD}$	28	83	190	μA
Pull-up resistor (50 k Ω) ^{Note5}	R_{PU}		18.9	39.8	107.1	k Ω
Pull-up resistor (5 k Ω) ^{Note5}	R_{PU}		1.9	4.7	10.7	k Ω
Pull-down resistor (50 k Ω) ^{Note5}	R_{PD}		18.9	39.8	107.1	k Ω

Notes 1. The static current consumption increases when an I/O block with pull-up/pull-down resistor is used.

2. The output off-state current of the TTL and CMOS 5-V 3-state buffer and I/O buffer slightly increases because of the bias of the 5-V protection circuit.

3. A sink current flows from the output pin to the internal circuit of the LSI if the TTL and CMOS 5-V output buffer are pulled up at a voltage higher than the supply voltage of the LSI.

4. The output short-circuit time is 1 second or less for only 1 pin of the LSI.

5. The pull-up resistance and pull-down resistance vary depending on the input and output voltages.

Remark The + and - symbols next to the current values in the above figure indicate the direction of the current. Current flowing into the device is indicated by + and current flowing out is indicated by -.

Note that the CMOS 5-V tolerant output buffer cannot output a DC high level because of its structure.

Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Characteristics (4/5)

DC Characteristics (2/3)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Low-level output current ^{Note1}						
3-V output type						
3.0-mA type FO09	I_{OL}	$V_{OL} = 0.4 \text{ V}$	3.00 ^{Note2}			mA
6.0-mA type FO04	I_{OL}	$V_{OL} = 0.4 \text{ V}$	6.00			mA
9.0-mA type FO01	I_{OL}	$V_{OL} = 0.4 \text{ V}$	9.00			mA
12.0-mA type FO02	I_{OL}	$V_{OL} = 0.4 \text{ V}$	12.00			mA
18.0-mA type FO03	I_{OL}	$V_{OL} = 0.4 \text{ V}$	18.00			mA
24.0-mA type FO06	I_{OL}	$V_{OL} = 0.4 \text{ V}$	24.00			mA
Low-level output current ^{Note1}						
TTL 5-V output						
1.0-mA type FV0A	I_{OL}	$V_{OL} = 0.4 \text{ V}$	1.00			mA
2.0-mA type FV0B	I_{OL}	$V_{OL} = 0.4 \text{ V}$	2.00			mA
3.0-mA type FV09	I_{OL}	$V_{OL} = 0.4 \text{ V}$	3.00			mA
6.0-mA type FV04	I_{OL}	$V_{OL} = 0.4 \text{ V}$	6.00			mA
9.0-mA type FV01	I_{OL}	$V_{OL} = 0.4 \text{ V}$	9.00			mA
12.0-mA type FV02	I_{OL}	$V_{OL} = 0.4 \text{ V}$	12.00			mA
18.0-mA type FV03	I_{OL}	$V_{OL} = 0.4 \text{ V}$	18.00			mA
24.0-mA type FV06	I_{OL}	$V_{OL} = 0.4 \text{ V}$	24.00			mA
Low-level output current ^{Note1}						
CMOS 5-V output						
3.0-mA type FY09	I_{OL}	$V_{OL} = 0.4 \text{ V}$	3.00			mA
6.0-mA type FY04	I_{OL}	$V_{OL} = 0.4 \text{ V}$	6.00			mA
9.0-mA type FY01	I_{OL}	$V_{OL} = 0.4 \text{ V}$	9.00			mA
12.0-mA type FY02	I_{OL}	$V_{OL} = 0.4 \text{ V}$	12.00			mA
18.0-mA type FY03	I_{OL}	$V_{OL} = 0.4 \text{ V}$	18.00			mA
24.0-mA type FY06	I_{OL}	$V_{OL} = 0.4 \text{ V}$	24.00			mA

Notes 1. The specifications of the buffers with the same driving capabilities are the same.

2. 2.00 mA for type with 5-k Ω pull-up resistor

Remark The + and – symbols next to the current values in the above figure indicate the direction of the current. Current flowing into the device is indicated by + and current flowing out is indicated by –.

Note that the CMOS 5-V tolerant output buffer cannot output a DC high level because of its structure.

Gate Array

CMOS Gate Array

■ CMOS-9HD Family

● Characteristics (5/5)

DC Characteristics (3/3)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
High-level output current ^{Note}						
3-V output type						
3.0-mA type FO09	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-3.00			mA
6.0-mA type FO04	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-6.00			mA
9.0-mA type FO01	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-9.00			mA
12.0-mA type FO02	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-12.00			mA
18.0-mA type FO03	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-18.00			mA
24.0-mA type FO06	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-24.00			mA
High-level output current ^{Note}						
TTL 5-V output						
1.0-mA type FV0A	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-1.00			mA
2.0-mA type FV0B	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-1.00			mA
3.0-mA type FV09	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-3.00			mA
6.0-mA type FV04	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-3.00			mA
9.0-mA type FV01	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-3.00			mA
12.0-mA type FV02	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-3.00			mA
18.0-mA type FV03	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-6.00			mA
24.0-mA type FV06	I_{OH}	$V_{OH} = 2.4 \text{ V}$	-6.00			mA
Low-level output current ^{Note}						
3-V output type	V_{OL}	$I_{OL} = 0 \text{ mA}$				
3-V output type (with 5-k Ω pull-up resistor)	V_{OL}	$I_{OL} = 0 \text{ mA}$			0.1	V
TTL 5-V output	V_{OL}	$I_{OL} = 0 \text{ mA}$			0.2	V
CMOS 5-V output	V_{OL}	$I_{OL} = 0 \text{ mA}$			0.1	V
					1	V
High-level output voltage						
3-V output type	V_{OH}	$I_{OH} = 0 \text{ mA}$	$V_{DD} - 0.1$			V
TTL 5-V output	V_{OH}	$I_{OH} = 0 \text{ mA}$	$V_{DD} - 0.2$			V

Note The specifications of the buffers with the same driving capabilities are the same.

Remark The + and - symbols next to the current values in the above figure indicate the direction of the current. Current flowing into the device is indicated by + and current flowing out is indicated by -.

Note that the CMOS 5-V tolerant output buffer can not output a DC high level because of its structure.

Gate Array

BiCMOS Gate Array

■ QB-8 Family

● Features

The QB-8 family is a collection of BiCMOS gate arrays that offer high speed, low power consumption, and high density, and a price comparable to CMOS devices through the use of an innovative cell structure and technology, radically changing the image of conventional BiCMOS gate arrays.

These gate arrays help increase the speed and decrease the power consumption of many electronic systems such as office machines and communications equipment.

High-speed operation

- Internal gate
 - $t_{PD} = 107 \text{ ps}$ (2-input NAND, fanout: 1, wiring length: 0 mm)
 - $t_{PD} = 191 \text{ ps}$ (2-input NAND, fanout: 2, wiring length: 2 mm)
- Power gate
 - $t_{PD} = 142 \text{ ps}$ (2-input NAND, fanout: 2, wiring length: 2 mm)

Super low power consumption

$1.09 \mu\text{W}$ = (per gate, $V_{DD} = 3.3 \text{ V}$ at 1 MHz)

Function block

Compatible with CMOS-8L family

Many high-speed interfaces

Maximum operating output frequency

- | | |
|----------|---------|
| • LVTTTL | 100 MHz |
| • GTL | 200 MHz |
| • PECL | 250 MHz |
| • PCI | 66 MHz |
| • HSTL | 250 MHz |
| • LVDS | 300 MHz |

Gate Array

BiCMOS Gate Array

■ QB-8 Family

● Available Models

		μ PD67821	μ PD67822	μ PD67823	μ PD67824	μ PD67825	μ PD67826
Density	Number of integrated gates*	32832	44352	56800	69520	93184	123808
	Number of usable gates**	22982	31046	39760	48664	65229	86666
	Number of pads ^{Note}	180	204	228	240	284	324
Delay time	Internal gate	107 ps (fanout: 1, wiring length: 0 mm), 191 ps (fanout: 2, wiring length: 2 mm)					
	Power gate	142 ps (fanout: 2, wiring length: 2 mm)					
	Input buffer	289 ps (fanout: 2, wiring length: 2 mm)					
	Output buffer	1.64 ns (load: 15 pF, $I_{OL} = 18$ mA)					
Supply voltage		3.3V $\pm$ 0.3V					
Output drive capability		$I_{OL} = 1, 2, 3, 6, 9, 12, 18, 24$ mA					
I/O interface level		LVTTTL, TTL, GTL, HSTL, PECL, PCI					
Remark		* 2-input NAND conversion **Cell utilization rate: 70 %					

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

		μ PD67827	μ PD67828	μ PD67829	μ PD67830	μ PD67831
Density	Number of integrated gates*	136752	167280	234280	292896	381840
	Number of usable gates**	95726	117096	164024	205027	267288
	Number of pads ^{Note}	340	372	436	484	548
Delay time	Internal gate	107 ps (fanout: 1, wiring length: 0 mm), 191 ps (fanout: 2, wiring length: 2 mm)				
	Power gate	142 ps (fanout: 2, wiring length: 2 mm)				
	Input buffer	289 ps (fanout: 2, wiring length: 2 mm)				
	Output buffer	1.64 ns (load: 15 pF, $I_{OL} = 18$ mA)				
Supply voltage		3.3 V $\pm$ 0.3 V				
Output drive capability		$I_{OL} = 1, 2, 3, 6, 9, 12, 18, 24$ mA				
I/O interface level		LVTTTL, TTL, GTL, HSTL, PECL, PCI				
Remark		* 2-input NAND conversion **Cell utilization rate: 70 %				

Note Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of the package.

Gate Array

BiCMOS Gate Array

■ QB-8 Family

● Library

I/O buffer	Function block	Memory block	Mega macro (under development)
Function	Function	Function	Function
3 V Input buffer Output buffer Bidirectional buffer PCI buffer HSTL buffer Low-noise buffer Fail-safe buffer 5 V (level shifter) Input buffer GTL PECL LVDS	Logic gate Buffer Inverter 3-state buffer Clock driver Delay Adder Decoder Multiplexer Latch Flip-flop Shift register Counter Others	High-speed single-port RAM High-speed dual-port RAM High-density single-port RAM High-density dual-port RAM	DMA controller Serial interface unit Parallel interface unit Timer/counter Interrupt controller

Gate Array

BiCMOS Gate Array

■ QB-8 Family

● Characteristics (1/2)

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	V_{DD}		−0.5 to +4.6	V
Input voltage				
3-V input buffer	V_I	$V_I < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
3-V input buffer with fail-safe function	V_I	$V_I < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
5-V input buffer	V_I	$V_I < V_{DD} + 0.5 \text{ V}$	−0.5 to +6.6	V
Output voltage				
3-V output buffer	V_O	$V_O < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
5-V output buffer	V_O	$V_O < V_{DD} + 3.0 \text{ V}$	−0.5 to +6.6	V
Output current ^{Note}	I_O	$I_{OL} = 1 \text{ mA (FV0A)}$	3	mA
		$I_{OL} = 2 \text{ mA (FV0B)}$	7	mA
		$I_{OL} = 3 \text{ mA (FO09, FV09, FW09)}$	10	mA
		$I_{OL} = 6 \text{ mA (FO04, FV04, FW04)}$	20	mA
		$I_{OL} = 9 \text{ mA (FO01)}$	30	mA
		$I_{OL} = 12 \text{ mA (FO02)}$	40	mA
		$I_{OL} = 18 \text{ mA (FO03)}$	60	mA
		$I_{OL} = 24 \text{ mA (FO06)}$	80	mA
Operating temperature	T_A		−40 to +85	°C
Storage temperature	T_{stg}		−65 to +150	°C

Note Output current: Maximum DC current that can flow through output pin

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

Remark Apart from the buffer with the fail-safe function, apply 5 V or 3 V to the I/O pin after the supply voltage has been stabilized.

Recommended Operating Conditions

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply voltage	V_{DD}		3.00	3.30	3.60	V
High-level input voltage	V_{IH}	3-V interface	2.00		V_{DD}	V
Low-level input voltage	V_{IL}		0		0.80	V
Positive trigger voltage	V_P		1.50		2.70	V
Negative trigger voltage	V_N		0.60		1.40	V
Hysteresis voltage	V_H		1.10		1.50	V
High-level input voltage	V_{IH}	5-V interface	2.00		5.50	V
Low-level input voltage	V_{IL}		0		0.80	V
Positive trigger voltage	V_P		2.20		2.25	V
Negative trigger voltage	V_N		0.84		1.01	V
Hysteresis voltage	V_H		1.36		1.54	V
Input rise time	t_{ri}	Normal input	0		200	ns
Input fall time	t_{fi}		0		200	ns
Input rise time	t_{ri}	Schmitt input ^{Note}	0		10	ms
Input fall time	t_{fi}		0		10	ms

Note Do not use this for the clock.

Gate Array

BiCMOS Gate Array

■ QB-8 Family

● Characteristics (2/2)

DC Characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Static current consumption						
μ PD67830,67831	I_{DDS}	$V_i = V_{DD}$ or GND		15	4800	μA
μ PD67827,67828,67829				9	3000	μA
μ PD67824,67825,67826				5	1500	μA
μ PD67821,67822,67823				2	700	μA
Off-state output current						
3-V output	I_{OZ}	$V_o = V_{DD}$ or GND			± 10	μA
5-V output	I_{OZ}	$V_o = V_{DD}$ or GND			± 14	μA
Output sink current	I_R	$V_{PU} = 5.5 V$ $R_{PU} = 2 k\Omega$			14	μA
5-V output		$V_o = 3.0 V$				
Output short-circuit current	I_{OS}	$V_o = GND$			-250	mA
Input leakage current						
Normal input	I_i	$V_i = V_{DD}$ or GND			± 10	μA
with pull-up resistor (50 k Ω)	I_i	$V_i = GND$	-30	-66	-144	μA
with pull-up resistor (5 k Ω)	I_i	$V_i = GND$	-300	-660	-1440	μA
with pull-down resistor (50 k Ω)	I_i	$V_i = V_{DD}$	30	66	144	μA
High-level output voltage						
3-V output	V_{OH}	$I_{OH} = 0 mA$	$V_{DD} - 0.1$			V
5-V output	V_{OH}	$I_{OH} = 0 mA$	$V_{DD} - 0.2$			V
Low-level output voltage						
3-V output	V_{OL}	$I_{OL} = 0 mA$			0.1	V
5-V output	V_{OL}	$I_{OL} = 0 mA$			0.1	V

Remarks 1. The above values are under the recommended operating conditions shown above.

For details, refer to the **Design Manual**.

2. Blank indicates values are under study.

Cell-Based IC

Cell-Based IC Line-Up (1/2)

A cell-based IC is an LSI that is designed combining large-scale macros such as existing CPU and memories, and user's own circuits. Because its internal logic cells are optimally designed according to their functions, a large scale of integration with low current consumption can be realized even if the circuit consists of only logic, as compared with gate arrays.

In addition, a system-on-chip that integrates a high-performance CPU core with analog macros such as A/D and D/A converters can be realized.

Many families available

Families are available for each technology.

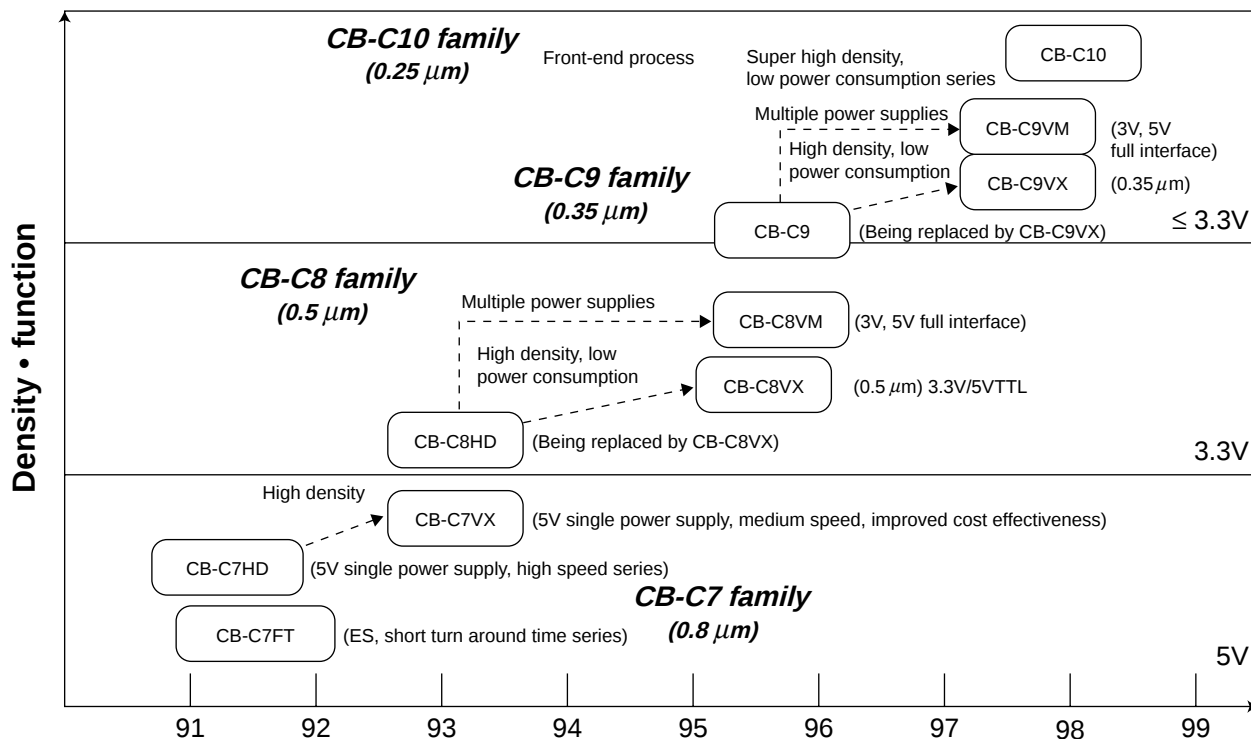
0.8 μ m CMOS family	:CB-C7 family (HD/FT/VX type)
0.5 μ m CMOS family	:CB-C8 family (VX/VM type)
0.35 μ m CMOS family	:CB-C9 family (VX/VM type)
0.25 μ m CMOS family	:CB-C10 family

The CB-C8 family VM type and CB-C9 family VM type can easily interface with 5-V and 3.3-V signals by using a buffer with level shifter in a system where 5 V and 3.3 V are used together.

The CB-C9 family VX type internally operates at 2.0 V and has a 3.3-V interface, and is ideal for portable systems where low power consumption is required, such as cellular telephones.

The CB-C10 family can internally operate at 2.5 V and have a 2.5 or 3.3 V interface to allow larger-scale systems with lower power consumption. (For details of the CB-C10 family, refer to the description in the section titled 0.25 μ m ASIC in this pamphlet.)

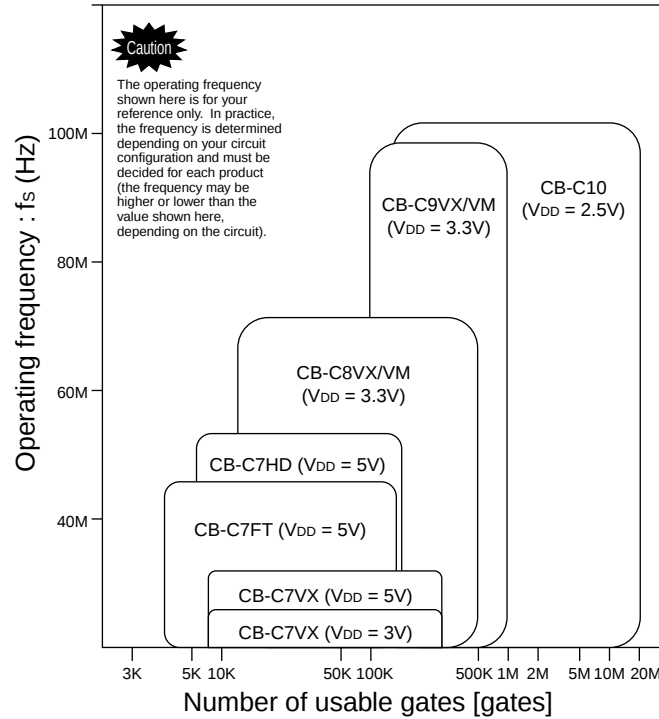
Series development of Cell-Based ICs



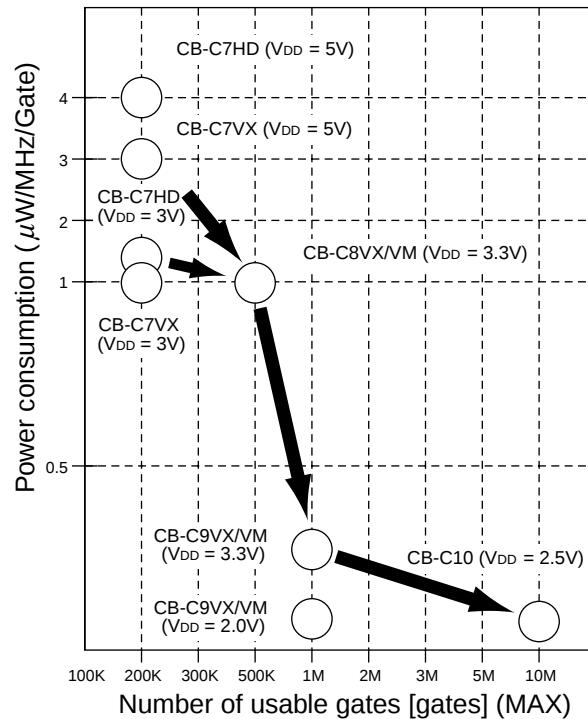
Cell-Based IC

■ Cell-Based IC Line-Up (2/2)

Comparison of performance of each series

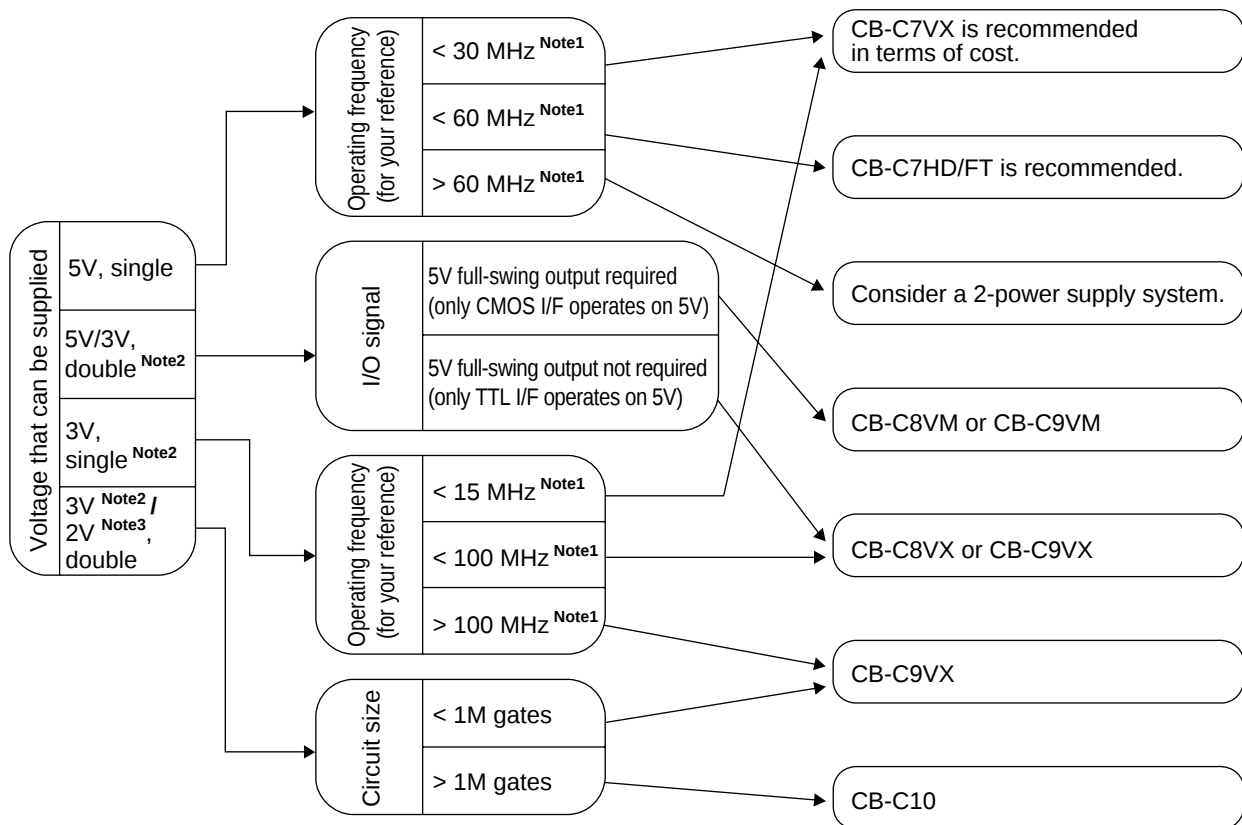


Transition of power consumption



Cell-Based IC

■ Guide to Selecting Cell-Based ICs



Notes 1. The values of the operating frequency shown above are for your reference only. In practice, the value of the operating frequency varies depending on your circuit configuration.

2. CB-C7, 3V: $V_{DD} = 3.0\text{ V} \pm 0.3\text{ V}$

CB-C8VX/VM, CB-C9VX/VM, CB-C10: $V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$

3. CB-C9VX, 2V: $V_{DD} = 2.0\text{ V} \pm 0.2\text{ V}$

CB-C10: $V_{DD} = 2.5\text{ V} \pm 0.2\text{ V}$

Many cores available

The need for system-on-chip is satisfied by CPU peripheral cores, memory macros, and analog masters such as A/D and D/A, as well as a high-performance CPU.

High-density memory macros, RAM and ROM, can be integrated by means of the memory compiled method.

Cell-Based IC

■ CB-C7 Family

● Features

Three types available

- FT type : Short turn around time realized by gate array method (substrate is developed first)
- HD type : High speed and high density by employing dedicated cells
- VX type ^{Note} : Super high density by employing dedicated cells and small transistors

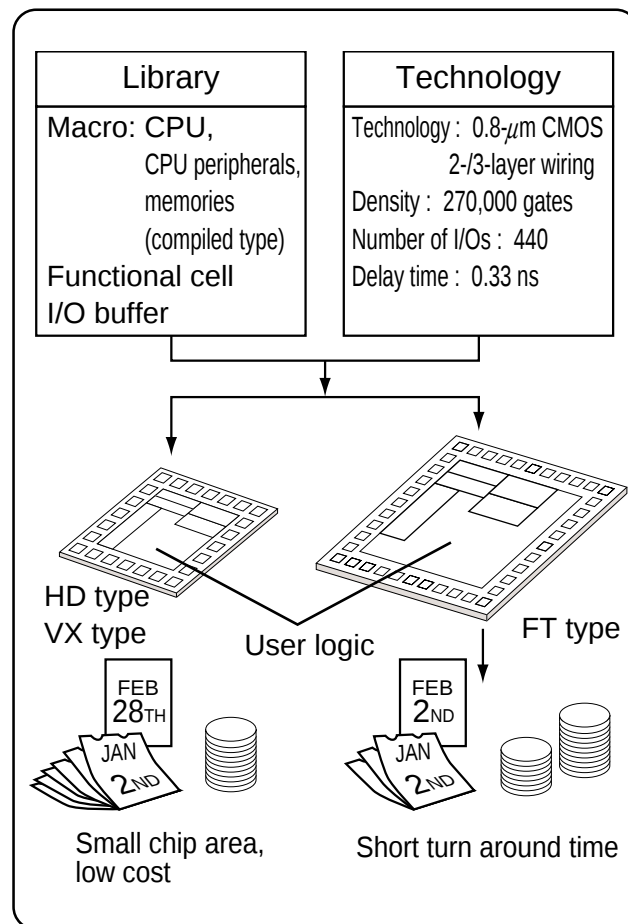
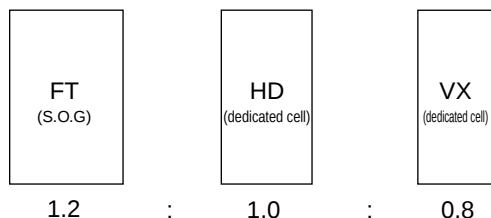
Note The applications of the VX type are limited.

FT vs. HD vs. VX selection

• Comparison of features of each type

	FT	HD	VX
Turn around time	◎	0	0
Speed	0	◎	△
Density	△	0	◎
Power consumption	0	0	◎

• Comparison of cell area (average of all blocks)



Cell-Based IC

■ CB-C7 Family

● Product Outline

Type name		FT type/HD type/VX type			
Part number		μ PD93000	μ PD94000	μ PD95100	μ PD96100
CPU, peripherals		—		O	
Derivative models ^{Note 1}		—	O	—	O
Supply voltage		5 V $\pm$ 10 %, 3 V $\pm$ 10 %			
Interface level		CMOS, TTL compatible			
Number of usable gates ^{Note 2}		FT: 167K gates (MAX.)/HD: 223K gates (MAX.)/VX: 273K gates (MAX.)			
Delay time	Internal gate	FT,HD : 0.33ns ^{Note 3} /0.44ns(5V), 0.67ns ^{Note 3} /0.90ns(3V) [F/O=2,L=2mm] VX : 0.90ns ^{Note 3} /2.10ns(5V), 1.54ns ^{Note 3} /3.42ns(3V) [F/O=2,L=2mm]			
	Input buffer	FT,HD : 0.60 ns(5 V), 0.76 ns(3 V) [F/O = 2, L = 2 mm] VX : 1.25 ns(5 V), 2.18 ns(3 V) [F/O = 2, L = 2 mm]			
	Output buffer	FT,HD : 1.6 ns(5 V, I_{OL} = 8 mA), 3.0 ns(3 V, I_{OL} = 4.4 mA) [C_L = 15 pF] VX : 1.7 ns(5 V, I_{OL} = 8 mA), 3.0 ns(3 V, I_{OL} = 4.4 mA) [C_L = 15 pF]			
Power consumption (internal gate)		FT,HD : 3.90 μ W/MHz/gate(5 V), 1.41 μ W/MHz/gate(3 V) VX : 3.21 μ W/MHz/gate(5 V), 1.17 μ W/MHz/gate(3 V)			
Output drive capability		I_{OL} = 4,8,12,24,48 mA(5 V) I_{OL} = 2.2,4,4,6.6 mA(3 V)			

Notes 1. ROM code changeable. O: Derivative models available, —: No derivative models available

2. Number of gates if hard macro is not integrated (2-input NAND gate conversion)

3. Power gate

Cell-Based IC

■ CB-C8 Family VX/VM Type

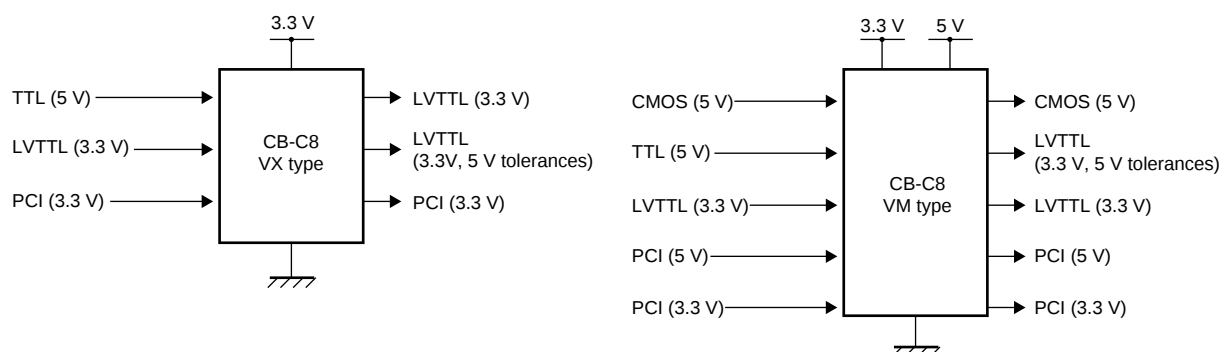
● Features

High-density, power-saving type and 2-power supply type available

VX type : Density 1.5 times (MAX.) higher and power consumption 20% lower than existing type

VM type : 2-power supply full-swing interface in system where 5-V and 3.3-V power sources are used together

Interface level



● Product Outline (VX/VM type)

Type name		VX type	VM type
Part number		μ PD97000	μ PD99000
Derivative models Note 1		O	O
Technology		0.5 μ m rule CMOS (Ti silicide), aluminum 2-layer/3-layer wiring	
Supply voltage		3.3V $\pm$ 0.3V, single	Internal: 3.3V $\pm$ 0.3V I/O block: 5V $\pm$ 10%, 3.3V $\pm$ 0.3V
Interface level		LVTTL (including 5V tolerance)	5V CMOS/TTL LVTTL (including 5V tolerance)
Number of usable gates Note 2		1000K gates (MAX.)	
Delay time	Internal gate	0.16 ns Note 3 /0.34 ns [F/O = 2, L = 1mm]	
	Input buffer	3.3-V LVTTL: 0.26 ns [F/O = 2, L = 1 mm] 5-V tolerant LVTTL: 0.33 ns [F/O = 2, L = 1 mm] 5-V full swing: 0.72 ns [F/O = 2, L = 1 mm]	
	Output buffer	3.3-V LVTTL: 1.24 ns (I_{OL} = 9 mA) [C_L = 15 pF] 5-V tolerant LVTTL: 1.88 ns (I_{OL} = 9 mA) [C_L = 15 pF] 5-V full swing: 2.30 ns (I_{OL} = 9 mA) [C_L = 15 pF]	
Power consumption (internal gate)		Standard block (F, L blocks): 1.04 μ W/MHz/gate (3.3V) Low power consumption block (Y block): 0.75 μ W/MHz/gate (3.3V)	
Output drive capability		I_{OL} = 3, 6, 9, 12, 18, 24 mA [for 3-V interface] I_{OL} = 1, 2, 3, 6, 9 mA [for 5-V interface (5V tolerance)]	
		—	I_{OL} = 1, 2, 3, 6, 9, 12, 18 mA [for 5-V full swing]

Notes 1. ROM code changeable. O: Derivative models available

2. Number of gates if hard macro is not integrated [2-input NAND gate conversion]

3. 2 NAND power gate

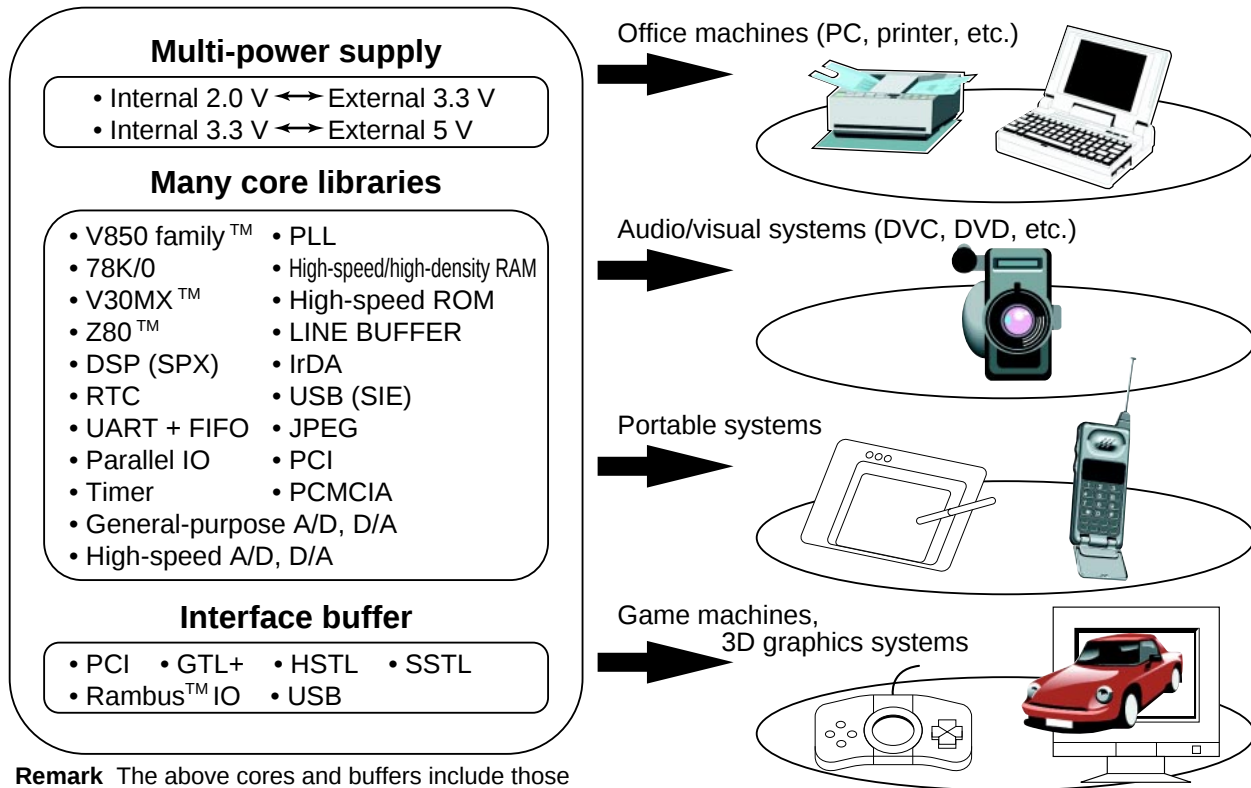
Cell-Based IC

■ CB-C9 Family VX/VM Type

● Features

The CB-C9 family VX/VM type is a collection of cell-based ICs employing a 0.35- μ m technology. The VX type realizes an I/O voltage of 3.3 V and internal voltage of 2.0 V, and the VM type realizes an I/O voltage of 5 V and internal voltage of 3.3 V. These cell-based ICs are suitable for systems where low power consumption is required.

CB-C9 family VX/VM type



Cell-Based IC

■ CB-C9 Family VX/VM Type

● Product Outline (VX/VM type)

Type name		VX type		VM type	
Part Number		μ PD822XX		μ PD826XX	
Derivative models ^{Note1}		O			
Technology		0.35 μ m rule CMOS, aluminum 2-layer/3-layer wiring			
Supply voltage I/O block		3.3 V $\pm$ 0.3 V		5.0 V $\pm$ 10 %	3.3 V $\pm$ 0.3 V
Supply voltage internal block		3.3 V $\pm$ 0.3 V	2.0 V $\pm$ 0.2 V	3.3 V $\pm$ 0.3 V	
Interface level		LVTTL, TTL, 5-V CMOS (VM Type only)			
Number of usable gates ^{Note2}		1.7-M usable gate		1.6-M usable gate	
Delay time	Internal gate ^{Note3}	114 ps	207 ps	114 ps	114 ps
	Input buffer ^{Note4}	169 ps	—	690 ps	169 ps
	Output buffer ^{Note5}	864 ps	—	2045 ps	864 ps
Power consumption (internal gate)		0.3 μ W/MHz/gate	0.12 μ W/MHz/gate	0.3 μ W/MHz/gate	

- Notes 1. ROM code changeable. O: Derivative models available
2. Number of gates if hard macro is not mounted (2-input NAND conversion)
3. 2-input NAND power gate, fanout = 2, standard wiring length
4. fanout = 2, standard wiring length
5. Load capacitance: 15 pF, I_{OL} = 18 mA

Cell-Based IC

■ Library

● CPU core

	General-purpose model	CB-C7 (5 V)	CB-C7 (3 V)	CB-C8 (HD)	CB-C8 (VX/VM)	CB-C9 (VX/VM)
Z80	μ PD70008A	O	O	O	O	O
V20HL TM	μ PD70108H	O	O	—	—	—
V30HL TM	μ PD70116H	O	O	—	—	—
V30MX		O	—	O	O	O
V30MT		—	—	—	O	△
V30MZ		—	—	—	—	O
V30MZC TM		—	—	—	—	O
78K/0		—	—	—	—	O
V851 TM		—	—	—	—	O
V853 TM		—	—	—	—	O
V850E		—	—	—	—	△
V830 family TM		—	—	—	—	
V _R series TM		—	—	—	—	

Remark O : can be supported, △: under development, — : cannot be supported, blank : under study

● Features of V850E core

CPU performance (Dhrystone): 87 MIPS (at 66 MHz)

V850 RISC CPU adopting 5-stage pipeline method. The object coding efficiency of C compilation has been improved and the program size has been reduced using 2-byte length basic instructions and instructions compatible with high-level language.

Two kinds of bus interface, VSB and NPB

- VSB: Bus operates synchronously with the CPU clock. It is used for connecting high-speed peripheral macros such as peripheral I/O provided with a memory controller and FIFO interface.
- NPB: Bus operates asynchronously with the CPU clock. It is used for connecting low-speed peripheral macros such as a timer and serial interface.

Instruction set: Completely compatible with V850E series 32-bit single-chip microcontrollers.

Cell-Based IC

■ Library

● Functional Outline of V850E Core

Item		Function
Register set		General-purpose registers 32 bits × 32 + dedicated registers 32 bits × 11
Instruction set		Upward compatible with V850 CPU Signed multiplication (32 bits × 32 bits → 64 bits) Saturated operation instruction (with overflow/underflow detection function) 32-bit shift instruction: 1clock Bit manipulation instruction Load/store instruction with long/short format Signed load instruction
Memory space		Program area: 64M bytes linear Data area: 4G byte linear Internal ROM size: 0 to 1M bytes Internal RAM size: 4K/12K/28K/60K bytes Memory bank division function
External bus interface		VSB (V850E) system bus • Separate address/data bus (28-bit address/32-bit data bus) • 32/16/8-bit bus sizing function • Bus hold function • External wait function NPB (NEC peripheral I/O bus) • Separate address/data bus (14-bit address/16-bit data bus) • Programmable wait function • Retry function
Interrupt	Non-maskable	3
	Maskable	64 (8 priority levels can be specified.)
	Exception	1
DMA control function		4-channel configuration Transfer unit: 8 bits, 16bits, 32bits Maximum number of transfer: 65536 (2^{16})times Transfer type: Fly-by (1 cycle) transfer, 2-cycle transfer Transfer mode: Single transfer, single-step transfer, line transfer, block transfer Terminal count output signal
Power save function		HALT, software STOP, hardware STOP modes

● NPB Peripheral Macro for V850E Core

Function	Macro name	CB-C9 (VX/VM)
Prescaler	PRS1	△
PWM	PWM	△
16-bit timer/counter	TMC	△
16-bit interval timer	TMD	△
UART	UART5	△
Serial I/O	SIO	△

Remark △: Under development

Cell-Based IC

Library

● Features of V851 and V853 core

CPU performance (Dhrystone): 38 MIPS (at 33 MHz)

Executes almost all instructions in 1 clock under control of a 5-stage pipeline based on RISC architecture.

Linear address space of up to 4G bytes

Supports linear address space of up to 4G bytes as data area and up to 16M bytes as program area

Instruction set: Completely compatible with V85X series 32-bit single-chip microcontrollers

● Functional Outline of V851 Core

Item		Function
Internal memory	Mask ROM ^{Note}	48K, 64K, 96K, 128K, 256K
	RAM	4K, 8K, 16K, 24K
Register set		General-purpose register 32 bits X 32 + dedicated register 32 bits X 6
Minimum instruction execution time		30 ns (at 33 MHz)
Instruction set		Signed multiplication (16 bits X 16 bits → 32 bits): 1 to 2 clocks Saturated operation instruction (with overflow/underflow detection function) 32-bit shift instruction: 1 clock Bit manipulation instruction Load/store instruction with long/short format
External bus interface		16-bit data bus (DIN/DOUT separated) 24-bit address bus
Interrupt	Non-maskable	1
	Maskable	14 (8 priority levels can be specified)
Real-time pulse unit		16-bit timer/event counter: 1 ch 16-bit interval timer: 1 ch
Serial interface		Asynchronous serial interface (UART): 1 ch Clocked serial interface (CSI): 1 ch
Power save function		HALT, STOP, IDLE modes Clock output stop function

Note ROM may not be provided.

Cell-Based IC

■ Library

● Functional Outline of V853 Core

Item		Function
Internal memory	Mask ROM ^{Note}	48K, 64K, 96K, 128K, 256K
	RAM	4K, 8K, 16K, 24K
Register set		General-purpose register 32 bits X 32 + dedicated register 32 bits X 6
Minimum instruction execution time		30 ns (at 33 MHz)
Instruction set		Signed multiplication (16 bits X 16 bits → 32 bits): 1 to 2 clocks Saturated operation instruction (with overflow/underflow detection function) 32-bit shift instruction: 1 clock Bit manipulation instruction Load/store instruction with long/short format
External bus interface		16-bit data bus (DIN/DOUT separated) 24-bit address bus
Interrupt	Non-maskable	1
	Maskable	31 (8 priority levels can be specified)
Real-time pulse unit		16-bit timer/event counter: 4 ch 16-bit interval timer: 1 ch
Serial interface		Asynchronous serial interface (UART) Clocked serial interface (CSI) UART/CSI: 2 ch CSI: 2 ch
PWM output		8/9/10/12-bit resolution PWM: 2 ch
Power save function		HALT, STOP, IDLE modes Clock output stop function

Note ROM may not be provided.

Cell-Based IC

■ Library

● Features of 78K/0 core

- Instruction set: Completely compatible with 78K/0 series 8-bit single-chip microcontrollers
- Many peripheral units such as timer, serial interface, and interrupt controller
- Software development environments available

● Functional Outline of 78K/0 Core

Item		Function
General-purpose register		8 bits X 32
Minimum instruction execution time		238.4 ns (at 8.38 MHz)
Instruction set		Multiplication/division (8 bits X 8 bits, 16 bits ÷ 8 bits) Bit manipulation instruction (set, reset, test, Boolean operation)
External bus interface		8-bit data bus (DIN/DOUT separated) 16-bit address bus
Interrupt	Maskable	Internal : 17 External : 12
Port		128 bits MAX. Input : 64 bits (8 bits X 8) Output : 64 bits (8 bits X 8)
Timer		16-bit timer/event counter: 1 ch 8-bit timer (PWM output): 2 chs Watch timer: 1 ch Watchdog timer: 1 ch
Serial interface		Asynchronous serial interface (UART): 2 chs Clocked serial interface (CSI): 2 chs I ² C bus interface: 2 chs
Standby function		HALT, STOP modes

Cell-Based IC

Library

● V851, V853, and 78K/0 core dedicated peripheral macros

Function	Macro Name	CB-C9 (VX/VM)
UART	UART	○
Serial I/O	SIO	○
16-bit timer	TM4	○
8/16-bit timer	TM5	○

Remark ○: can be supported

	UART	SIO(CSI)	TM4	TM5
Features	7/8-bit character length 1/2-bit stop bit length Parity bit specification None/0/odd/even Baud rate generator IrDA mode	3-wire synchronous serial Transfer clock External clock fx/2 fx/8 fx/32	16-bit interval timer	8/16-bit timer/event counter 8-bit PWM output External pulse output

Dedicated external bus interface for V851, V853, or 78K/0 core is provided with each peripheral macro.
Each peripheral macro can be directly connected to each CPU core.

Cell-Based IC

■ Library

● Features of V30MX series

V30MX core

V30HL upward compatible

2-clock bus cycle realized by separating the address bus and data bus which are multiplexed in the V30HL.

V30MT core

Small and low-power model of V30MX

- Software compatible with V30HL and V30MX
- Low power consumption realized by deleting internal Hi-Z signal

V30MZ core

- Processing performance comparable to RISC thanks to internal pipeline processing
35 MIPS (66 MHz, 0 wait)
- 1-clock bus cycle
- ICE conforming to N-Wire
- Software compatible with V30HL and V30MX
- 2.0 V supported for CB-C9VX/VM ($f_{\text{MAX}} = 32 \text{ MHz}$)

V30MZC core

V30MZ with cache memory

- Cache memory capacity: 4K bytes
- 20 MIPS (50 MHz)
- Burst transfer mode supported

CPU core	V30MX	V30MT	V30MZ	V30MZC
Operating frequency	33 MHz	16 MHz	66 MHz	50 MHz
Performance (0 wait)	4.3 MIPS	2.6 MIPS	35 MIPS	20 MIPS
Current consumption	1.0 mA/MHz	0.8 mA/MHz	1.2 mA/MHz	T.B.D.
Bus cycle	2 clocks	2 clocks	1 clock	4 clocks (external) 1 clock between cache and CPU

Remark Specification for CB-C9VX/VM. However, V30MT only is for CB-C8VX/VM

Cell-Based IC

Library

Peripheral macros

Function	General-purpose model	CB-C7 (5 V)	CB-C7 (3 V)	CB-C8 (VX/VM)	CB-C9 (VX/VM)
Serial I/O	μ PD71051	O	O	O	O
Timer	μ PD71054	O	O	O	O
Parallel I/O	μ PD71055	O	O	O	—
Interrupt controller	μ PD71059	O	O	O	O
DMAC (8 bits)	μ PD71037	O	O	O	—
Watch	μ PD4991AL	O	O	O	O
UART + FIFO	NS16550	O	—	O	O
FDC + DVFO	μ PD72065B	Δ	—	Δ	Δ
IrDA1.1		—	—	O	O
SIE for USB1.1 full speed		—	—	—	O
USB function controller for printer		—	—	—	Δ
USB function controller for display				—	Δ
Line buffer for PPC (7.5 kW)		—	—	—	O

Remark O : can be supported, Δ : under development, — : cannot be supported, blank : under study

Analog macros

Function	Performance	CB-C7	CB-C8 (VX/VM)	CB-C9 (VX/VM)
A/D	8 bits, 100 kHz	O	O	O
	10 bits, 100 kHz	—	—	O
	12 bits, 300 kHz	—	—	Δ
	8 bits, 50 MHz	—	—	Δ
	10 bits, 30 MHz	—	—	Δ
D/A	8 bits, 100 kHz (1 ch)	O	O	O
	10 bits, 100 kHz (1 ch)	—	—	O
	8 bits, 20 MHz (3 chs)	O	—	—
	8 bits, 30 MHz (3 chs)	—	O	O
	9 bits, 30 MHz (2 chs)	—	O	—
	10 bits, 30 MHz (3 chs)	—	—	O
	10 bits, 85 MHz (1 ch)	—	—	Δ
PLL	For multiplication	O	O	O
	For skew adjustment	—	—	O
Analog switch		O	O	O
Comparator		O		—

Remark O : can be supported, Δ : under development, — : cannot be supported, blank : under study

Cell-Based IC

■ Library

● Compiled macros

Function	Performance	CB-C7 (5 V)	CB-C7 (3 V)	CB-C8 (VX/VM)	CB-C9 (VX/VM)
Multiplier	Signed (32 X 32 MAX.)	O	O	—	
Register file (2 ports)	8K bits MAX.	O	O	O	△
Register file (3 ports)	8K bits MAX.	O	O	O	△
Low-power synchronous 1-port RAM	128K bits MAX.	O	O	O	—
High-density synchronous 1-port RAM	64K bits MAX.	—	—	—	O
High-density synchronous 2-port (R + W) RAM	32K bits MAX.	—	—	—	O
High-speed synchronous 1-port RAM	64K bits MAX.	O	—	—	O
High-speed synchronous 2-port (R/W + R) RAM	64K bits MAX.	—	—	O	O
Super high-speed synchronous 1-port RAM	16K bits MAX.	—	—	—	O
Low-power asynchronous 1-port ROM	512K bits MAX.	O	O	O	—
High-speed synchronous 1-port ROM	512K bits MAX.	—	—	—	O

Remark O: can be supported, △: under development, —: cannot be supported, blank : under study

Embedded Array

■ EA-C9HD Family

● Features (1/2)

High-density, super high-speed, and low-power consumption embedded array using the most advanced 0.35 μm technology

- High-level function and high-performance LSI compatible to cell-based IC
- Easy development and modification of derivative models
- Short turn around time equivalent to gate array
- Macro maintenance common to cell-based IC (CB-C9/9VX)

The EA-C9HD family is a collection of embedded arrays employing a 0.35- μm technology.

This family consists of 10 masters with 76K to 1.6M gates.

The gate density of this family is about 2.5 times higher than that of the existing EA-C9 family 0.35- μm embedded arrays, thanks to improvement of the cell structure.

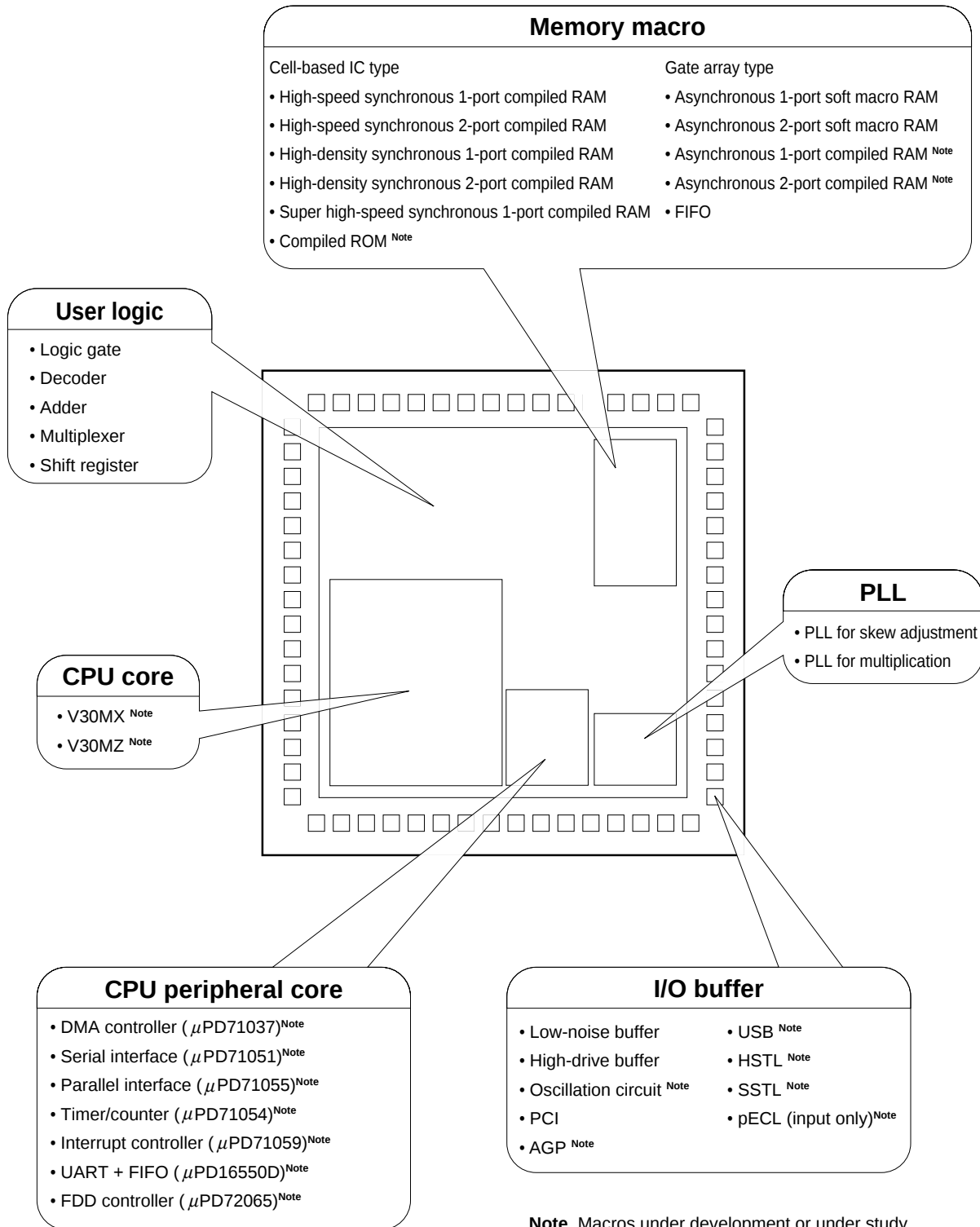
In addition, the power consumption is 40 % lower, and thanks to new I/O pad layout technology, this family offers a large number of pins in addition to the high density.

Embedded Array

■ EA-C9HD Family

● Features (2/2)

Wide variety of macro libraries



Embedded Array

■ EA-C9HD Family

● Available Models (3-layer wiring)

		μ PD65443	μ PD65444	μ PD65445	μ PD65446	μ PD65448	μ PD65449	μ PD65451	μ PD65454	μ PD65456	μ PD65458
Density	Internal gates*	76720	103032	128872	207000	314104	440832	592020	840768	1104432	1626628
	Number of usable gates**	38360	51516	64436	103500	157052	220416	296010	420384	552216	813314
	Number of pads ^{Note1}	172	196	216	268	324	380	436	516	588	708
Delay time	Internal gate	131 ps (2-input NAND, fanout: 1, standard wiring length)									
	Power gate	107 ps (2-input NAND, fanout: 1, standard wiring length)									
	Input buffer	229 ps (fanout: 2, standard wiring length)									
	Output buffer	1396 ps ($C_L = 15$ pF, $I_{OL} = 9$ mA)									
Output drive capability		$I_{OL} = 1, 2, 3, 6, 9, 12, 18, 24$ mA									
Supply voltage		$3.3V \pm 0.3V$									
Remark		*2-input NAND conversion, **Cell utilization rate: 50 to 70 % ^{Note2}									

Notes 1. Including the power supply and GND pins. The number of pins that can be actually used differs depending on the type of package.
 2. Differs depending on the number of pin pairs and the occupation rate of the macro.

Analog Master

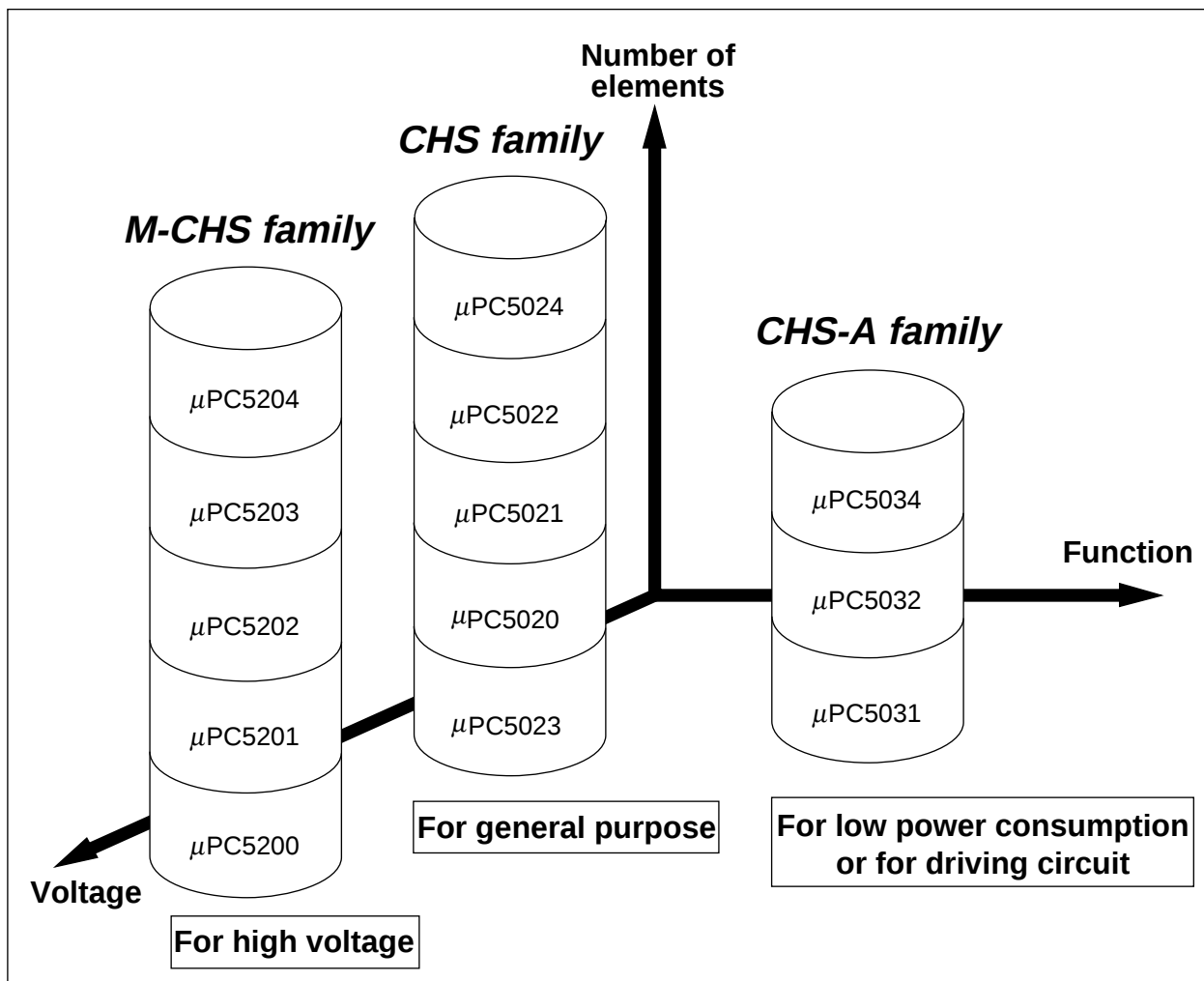
■ Analog Master Line-Up

NEC's analog master is classified into the following 3 families (refer to the figure below).

- CHS family and CHS-A family for wide application field
- M-CHS family for high voltage

From this wide line-up (3 families 13 masters), user can find the optimum one to realize the user-desired analog LSI.

Line-up and features

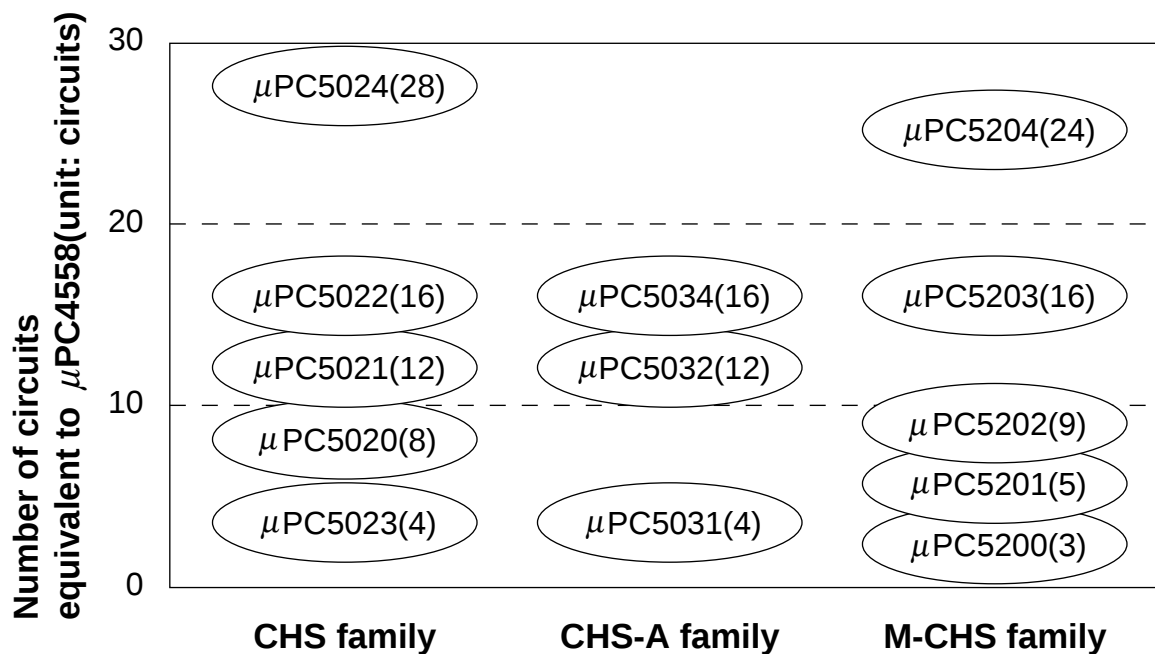


Analog Master

■ Circuit Scale of Each Family

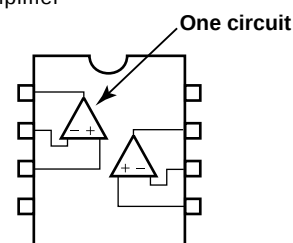
The scale of the circuit that can be integrated on the analog master differs depending on the model of each family.

The scale of the circuit that can be integrated shown below is roughly calculated in terms of the number of circuits where one circuit is equivalent to the general-purpose operational amplifier μPC4558 ^{Note 1}.



(Numbers in the parentheses indicate the number of circuits^{Notes 2} that can be integrated.)

Notes 1. One of the two operational amplifiers in the general-purpose operational amplifier μPC4558 package (8-pin DIP) is counted as one circuit.



- 2.** The number of circuits shown above is a guideline in which only operational amplifiers are integrated, and does not include operational amplifier peripheral circuits (such as feedback circuits).
When selecting a model, estimate the circuit scale by taking these peripheral circuits into consideration.

Analog Master

■ Available Models

Item	Family Name	CHS Family					CHS-A Family		
Technology	High-speed bipolar								
Absolute maximum ratings	14 V								
Features	• High-speed analog signal processing circuit can be created. • $f \leq$ several 10 MHz					• Many pins • Internal driver • High resistance			
Part number	μ PC5020	μ PC5021	μ PC5022	μ PC5023	μ PC5024	μ PC5031	μ PC5032	μ PC5034	
Total number of elements	1628	2328	3042	727	6152	576	1472	2252	
NPN transistor ^{Note1}	260	368	476	129	836	118(13)	298(18)	446(26)	
PNP transistor	224	320	416	116	672	105	280	450	
Resistor	1116	1600	2098	468	4560	338	854	1266	
Capacitor	28	40	52	14	84	15	40	90	
Macro library	Operational amplifiers, comparators, regulators, switches, timers					Operational amplifiers, comparators, regulators, switches, super white TEG ^{Note2}			

Item	M-CHS Family				
Technology	High voltage bipolar				
Absolute maximum ratings	44 V				
Features	- High voltage: $V_{CC(MAX.)} = 44$ V $f \leq$ several MHz				
Part number	μ PC5200	μ PC5201	μ PC5202	μ PC5203	μ PC5204
Total number of elements	654	1030	1787	3088	4562
NPN transistor	105	163	283	484	710
PNP transistor	84	140	252	448	672
Resistor	456	712	1225	2108	3108
Capacitor	9	15	27	48	72
Macro library	Operational amplifiers, comparators, regulators, switches				

Notes 1. (): Products with driver

2. Super white TEG: TEG (Test Element Group) containing analog function macros (operational amplifiers, comparators, regulators, switches, drivers, and reset circuits) used as peripherals of microcontroller in one package

Mixed Signal ASIC

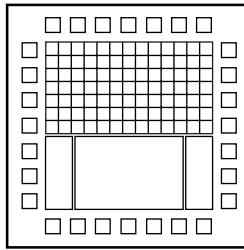
■ Mixed Signal ASIC Product Lines (1/2)

NEC offers mixed digital ASICs that employ the BiCMOS technology with a technology rule of 0.6 μm to 0.35 μm .

Furthermore, NEC supports the world's first analog IP cores through the use of a leading-edge 0.35- μm BiCMOS technology, applying its rich analog circuit design know-how.

An extensive line-up of products is available to answer the wide-ranging needs of users.

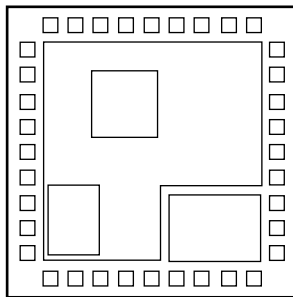
5-V power supply
for small-scale circuits



MA-8 family ($\mu\text{PD680XX}$)

0.6- μm BiCMOS technology
Gate array
+ Analog master slice form

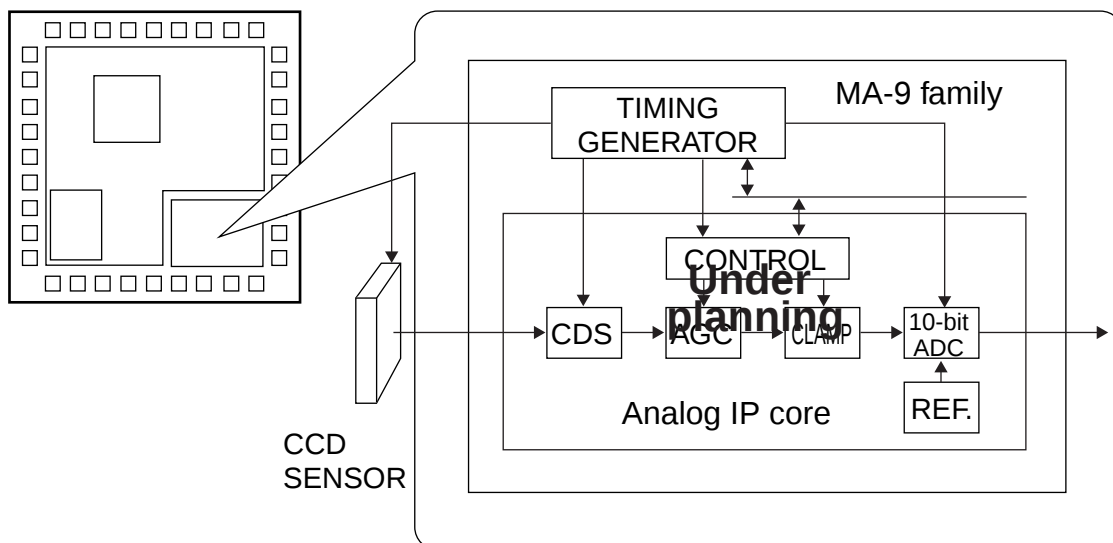
3.3-V power supply
for large-scale systems

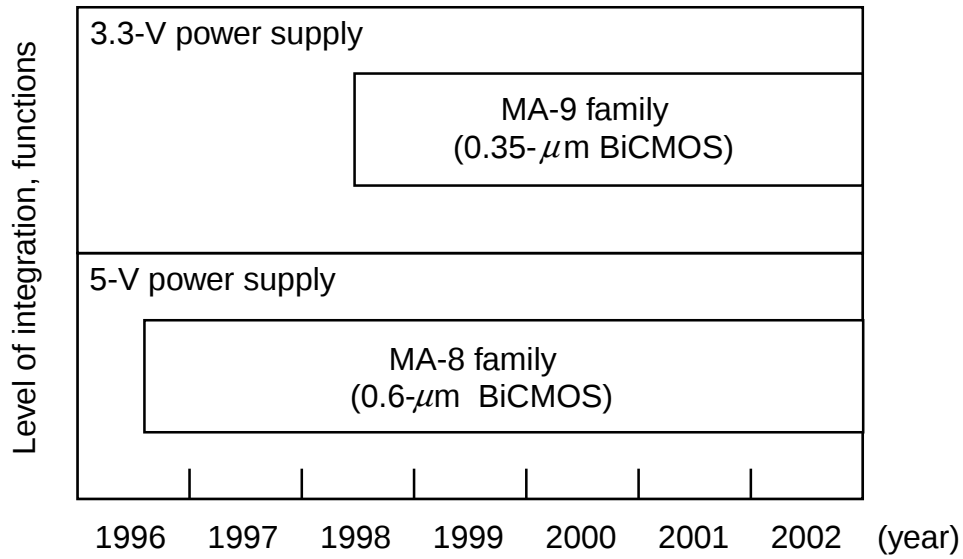
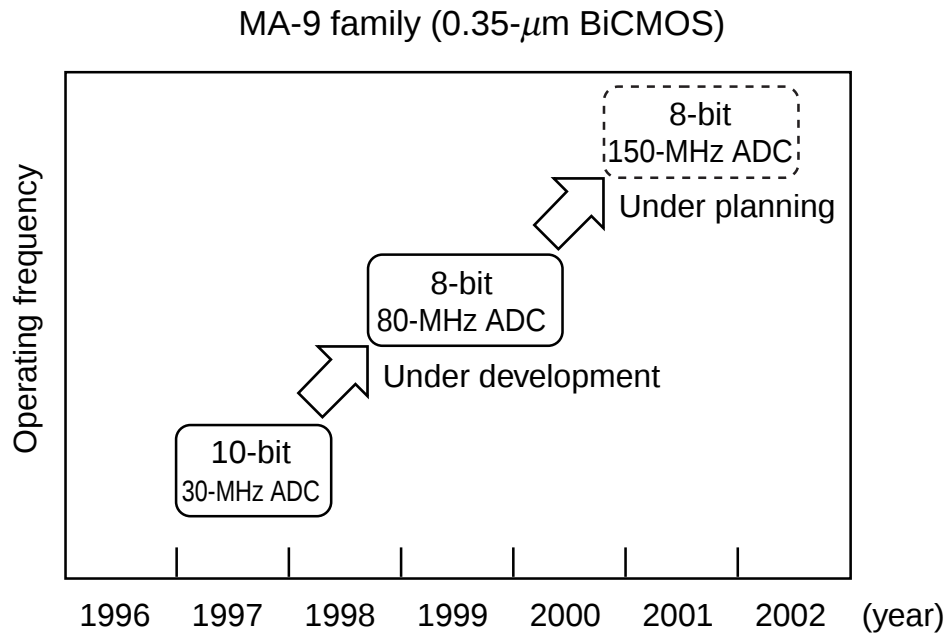


MA-9 family ($\mu\text{PD681XXX}$)

0.35- μm BiCMOS technology
Cell-based form

● MA-9 Family Analog IP Core



Mixed Signal ASIC**■ Mixed Signal ASIC Product Lines (2/2)****● Mixed Signal ASIC Family Evolution****● Mixed Signal ASIC Analog Core Evolution**

Mixed Signal ASIC**■ MA-8 Family (0.6- μ m Mixed Signal ASIC)****● Features**

The MA-8 Family (μ PD680xx) consists of top-level mixed signal ASICs that employ the latest high-cost-performance BiCMOS technology.

This family achieves the integration of mixed digital/analog circuits on a single chip, which will be pivotal for the development of the multimedia market.

Support of digital/analog mixed circuits

By employing the latest BiCMOS technology, the MA-8 Family realizes the integration of 0.6- μ m CMOS gate array and analog ASIC (analog master) on a single chip.

Analog block element configuration prioritizing circuit functions

Analog circuits that mix bipolar transistors and CMOS transistors can be created through the use of the BiCMOS technology:

- High input impedance operational amplifiers
- Sample and hold circuits
- Analog switches, etc.

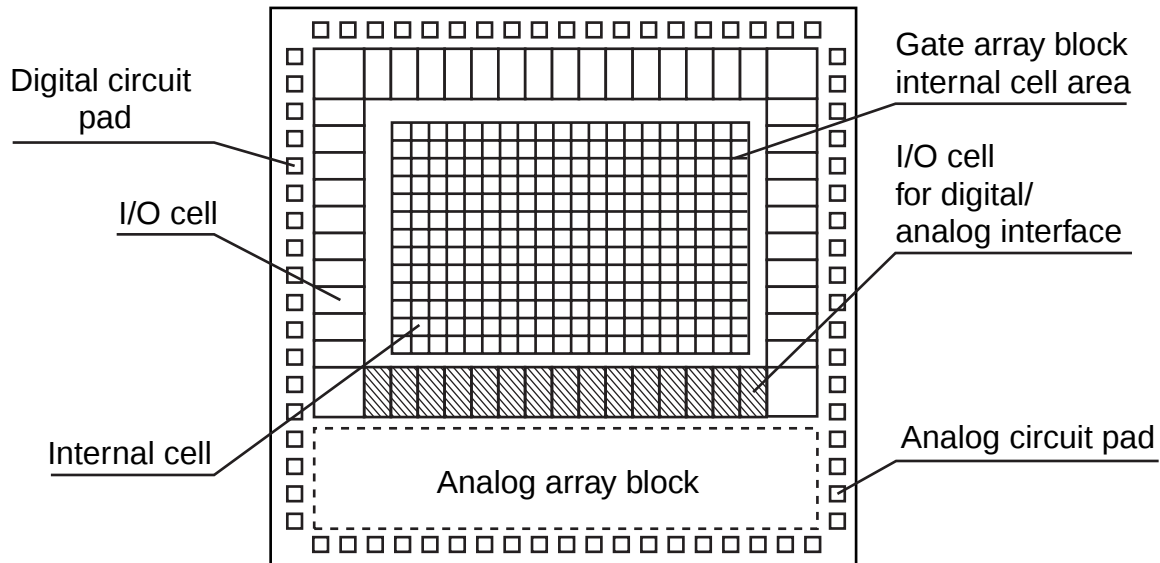
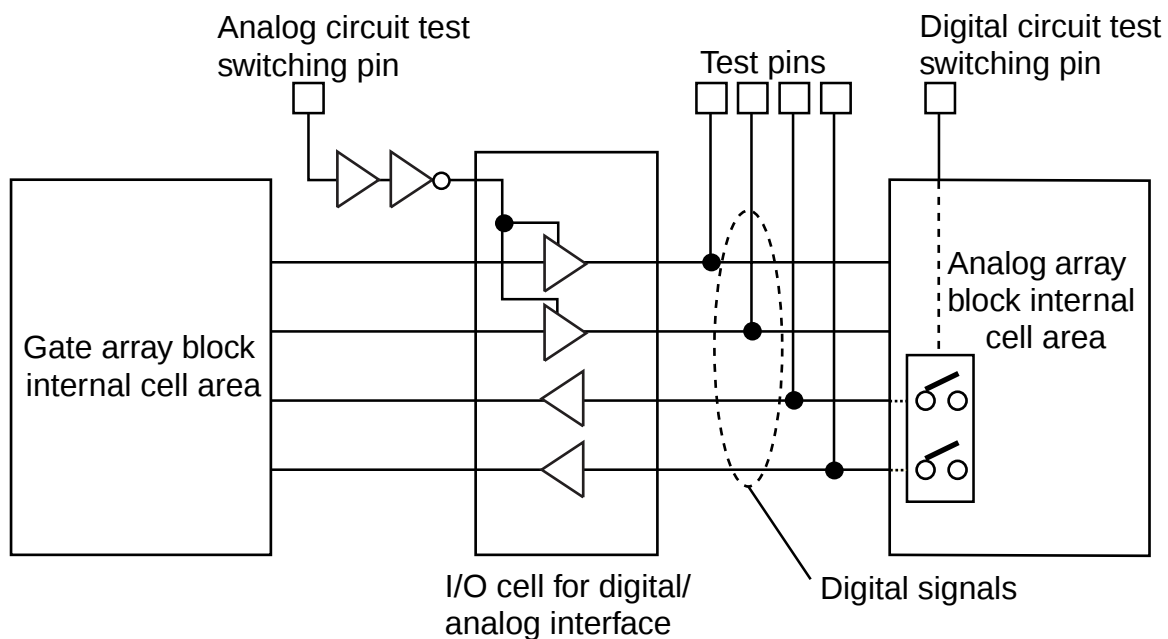
Simple design and short development time

The logic block can be easily developed with OPENCAD (NEC' s original CAE tool).

Furthermore, a short development time can be achieved, which is another advantage of ASICs.

Mixed Signal ASIC**■ MA-8 Family (0.6- μ m Mixed Signal ASIC)****● Chip Configuration**

The MA-8 Family is mainly composed of a gate array block and an analog array block. The I/O cells for the digital/analog interface perform input/output of digital signals between the gate array block and the analog array block.

**I/O Cells for Digital/Analog Interface**

Mixed Signal ASIC

■ MA-8 Family (0.6- μm Mixed Signal ASIC)

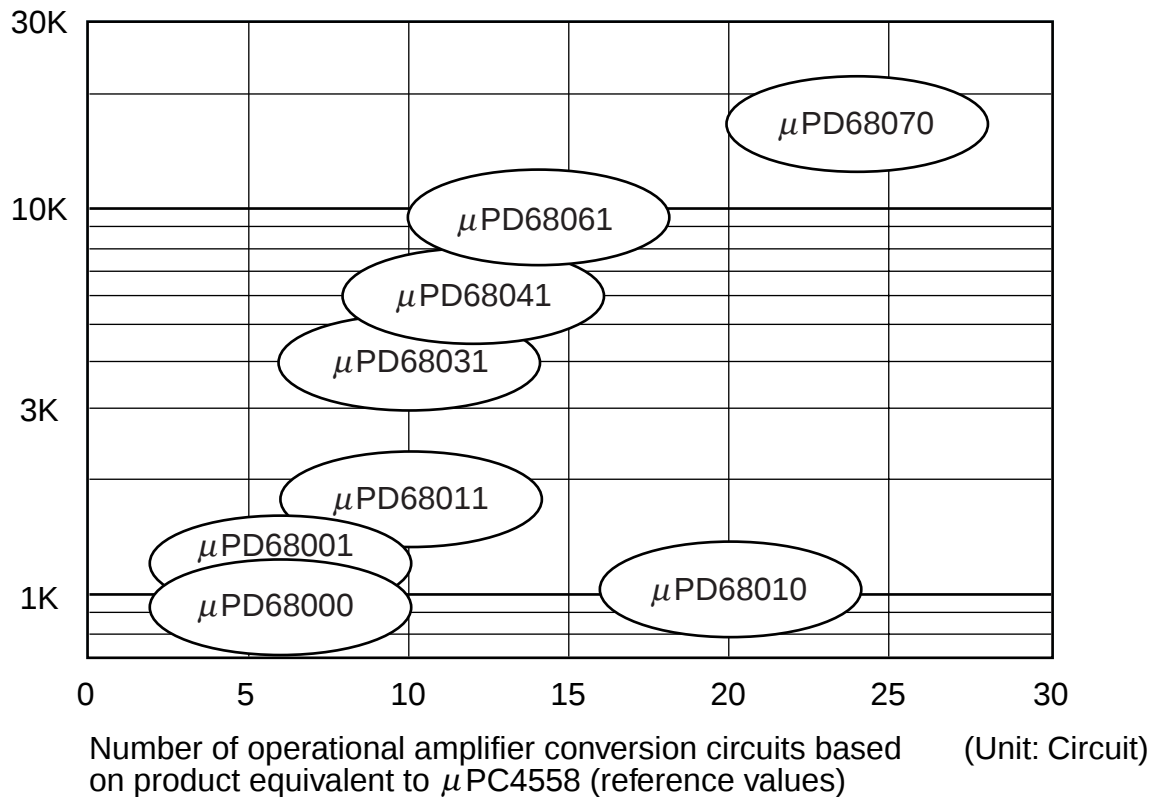
● Master Size

The MA-8 Family offers eight masters, based on the gate array block size, the analog array block size, and whether the analog array block has MOS transistors.

The figure below shows the master block size in terms of the number of usable gates and the number of circuits^{Note 1} calculated as general-purpose operational amplifier circuits corresponding to the μPC4558 .

MA-8 Family Master Sizes

Number of usable gates^{Note 2}
(Unit: Gates)

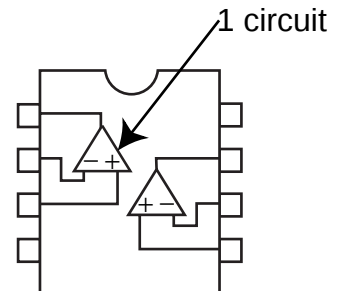


Notes 1. The two operational amplifiers mounted on the package (8-pin DIP) of the μPC4558 general-purpose amplifier are each treated as one circuit. Moreover, the numbers of conversion circuits indicated in the figure above are merely reference values for the case when only operational amplifiers are mounted on the analog array block, and operational amplifier peripheral circuits (such as feedback circuits) are not included. In particular when selecting products, estimate the circuit scale considering their peripheral circuits.

2. Gate utilization rate: 60%

Remark The presence of analog MOS transistors and analog switches on the analog array block.

- Mounted : $\mu\text{PD68000}$, 68010, 68070
- Not mounted : $\mu\text{PD68001}$, 68011, 68031, 68041, 68061



Mixed Signal ASIC

■ MA-8 Family (0.6- μ m Mixed Signal ASIC)

● Element List

Part Number	μ PD68000	μ PD68001	μ PD68010	μ PD68011	μ PD68031	μ PD68041	μ PD68061	μ PD68070
Technology	High-performance BiCMOS technology							
Maximum supply voltage	6.0 V (absolute maximum rating)							
Number of pads	68	68	108	84	96	108	128	168
Logic block								
Number of gates	1520	1520	1680	2880	6720	9520	16512	28320
Number of usable gates ^{Note}	912	912	1008	1728	4032	5712	9907	16992
Number of logic I/Os	23	23	31	32	44	53	68	88
Analog block								
Total number of elements	912	1264	4614	2016	2016	2304	2736	5017
NPN transistor	(Standard)	150	210	756	336	336	384	816
	(Large type)	25	35	126	56	56	64	136
PNP transistor (Lateral)		200	280	1008	448	448	512	1088
Polysilicon resistor	(1 k Ω)	150	210	756	336	336	384	816
	(5 k Ω)	300	420	1512	672	672	768	1632
Capacitor (5 pF)	25	35	126	56	56	64	76	136
P-ch MOS transistor	50	70	252	112	112	128	152	272
Analog SW	4	0	24	0	0	0	0	15
P-ch MOS transistor for analog	4	2	28	0	0	0	0	58
N-ch MOS transistor for analog	4	2	26	0	0	0	0	48
Digital/analog junction block								
Digital/analog I/F (Maximum)	14	14	36	14	14	14	14	24

Note Gate utilization rate: 60%

Remark The last digit in the part number of MA-8 Family products indicates the presence/absence of analog MOS transistors and analog switches in the analog array block, as follows:

Last digit = 0 $\rightarrow$ Mounted

Last digit = 1 $\rightarrow$ Not mounted

Mixed Signal ASIC

■ MA-8 Family (0.6- μ m Mixed Signal ASIC)

● Basic Specifications

Logic Block

Product Name		μ PD680XX
Technology		0.6- μ m BiCMOS technology
Supply Voltage		5.0 V $\pm$ 0.5 V (I/O block, internal gates)
Maximum integration (logic only)		17K gates (usable)
Interface level		CMOS, TTL
Delay time	Internal gates ^{Note 1}	190 ps (TYP.)
	Input buffer ^{Note 2}	340 ps (TYP.)
	Output buffer ^{Note 3}	2.13 ns (TYP.)

Notes 1. Value assuming 2-input NAND power gate, fanout: 1, and wiring length: 0.6 mm/1 pin pair.

2. Value assuming fanout: 2, wiring length: 0.6 mm/1 pin pair.

3. Value assuming load capacitance: 15 pF, block name: FO01.

Analog Block

Product Name		μ PD680XX
Technology		0.6- μ m BiCMOS technology
Supply Voltage		5.0 V $\pm$ 0.5 V
Transistor	NPN type	$f_T = 10$ GHz, $h_{FE} = 80$ (all TYP.)
	PNP type (Lateral)	$f_T = 10$ MHz, $h_{FE} = 70$ (all TYP.)
	MOS	N-ch type, P-ch type for analog circuit
Polysilicon resistor ^{Note}		Absolute precision: $\pm 20\%$, relative precision: $\pm 2\%$ (all MAX.)
Capacitor (MOS type) ^{Note}		Absolute precision: $\pm 15\%$, relative precision: $\pm 2\%$ (all MAX.)

Note Values indicated are for reference only. The relative precision applies only to when the pin is positioned in an adjacent location.

Mixed Signal ASIC

■ MA-8 Family (0.6- μ m Mixed Signal ASIC)

● Electrical Characteristics

Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Supply voltage	V_{DD}, V_{CC}		-0.5 to +6.0	V
Input/output voltage (logic block)	V_i / V_o		-0.5 to $V_{DD} + 0.5$	V
Input current (logic block)	I_i		20	mA
Output current (logic block)	I_o	$I_{OL} = 3 \text{ mA}$	10	mA
		$I_{OL} = 6 \text{ mA}$	15	mA
		$I_{OL} = 9 \text{ mA}$	20	mA
		$I_{OL} = 12 \text{ mA}$	30	mA
		$I_{OL} = 18 \text{ mA}$	40	mA
		$I_{OL} = 24 \text{ mA}$	60	mA
Operating ambient temperature	T_A		-40 to +85	°C
Storage temperature	T_{stg}		-65 to +150	°C

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

Definition of absolute maximum rating terms

Item	Symbol	Meaning
Supply voltage	V_{DD}	The range of voltage that, even if applied to the V_{DD} pin, will not cause destruction or lower reliability.
Input voltage	V_i	The range of voltage that, even if applied to the input pin, will not cause destruction or lower reliability.
Output voltage	V_o	The range of voltage that, even if applied to the output pin, will not cause destruction or lower reliability.
Input current	I_i	The absolute value of current capacity that, even if applied to the input pin, will not cause latchup to occur.
Output current	I_o	The absolute value of DC current capacity that, even if output from or input to the output pin, will not cause destruction or lower reliability.
Operating ambient temperature	T_A	Range of ambient temperature in which normal logical operation will occur.
Storage temperature	T_{stg}	Range of pin temperature that will not cause destruction or lower reliability when voltage and current are not applied.

Mixed Signal ASIC

■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products

● Features

The MA-9 Family (μ PD68155) consists of leading-edge mixed signal ASICs that aim for system-on-a-chip through the use of a leading-edge 0.35- μ m BiCMOS technology pioneered by NEC.

While aiming for ultra-high integration for large-scale digital/analog mixed systems in the field of multimedia, the MA-9 Family realizes high-speed, high-accuracy stable signal processing.

Support of world's first analog IP core

NEC supports the world's first analog IP core, using its rich analog circuit design resources.

Mixed signal ASICs aiming for system-on-a-chip

Large-scale mixed signal systems can now be created on a single chip using the cell-based form.

NEC supports mixed signal cores that include an analog IP core, high-speed ADC and DAC and other analog cores, digital/analog mixed circuits, etc.

Leading-edge BiCMOS technology

High-speed digital circuits and high-accuracy, sophisticated analog circuits can now be realized on a single chip by employing NEC's leading-edge 0.35- μ m BiCMOS technology.

Low power consumption

A low power consumption is achieved for LSIs by employing a low-voltage operation technology (3.3 V)

Flexible mixed signal development environment

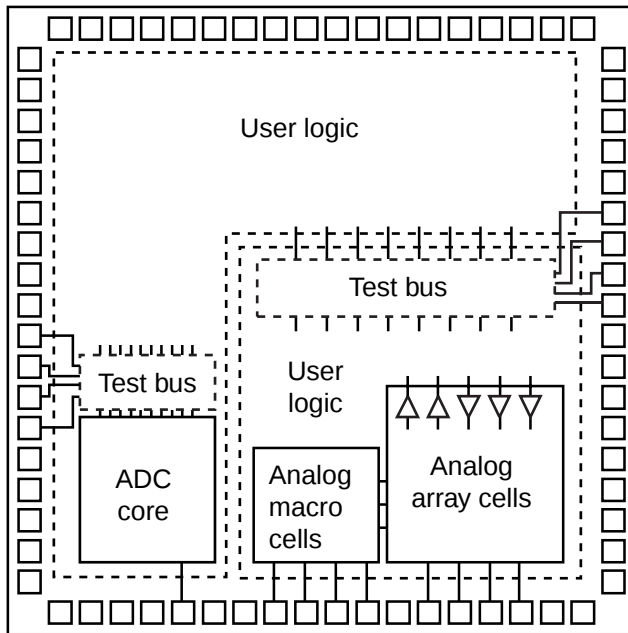
NEC's development environment for cell-based ICs can be used for the internal logic.

For mixed signal cores, NEC supports a development environment using analog arrays that enables a short turn around time comparable to that of embedded arrays.

Moreover, for circuit blocks, for which analog characteristics particularly matter, NEC supports a development environment that enables the use of macro cells.

Mixed Signal ASIC**■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products****● Chip Configuration**

The MA-9 Family features a digital/analog mixed circuit configured as a core (mixed signal core) as its internal logic.

**Internal Logic**

- User logic
Logic gates, decoder, adder, multiplexer, counter, shift register, etc.
- I/O buffer
- Cores
Analog core
Mixed signal core

Mixed signal core**Analog array cells**

(analog macro)

Operational amplifier, comparator, reference voltage source, analog switches, sample and hold, VCA, filters, etc.

+

User logic

(analog circuit operation and related logic circuits)

Logic gates, decoder, latches, shift registers, etc.

Mixed Signal ASIC

■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products

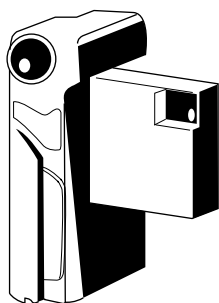
● Analog IP Cores (1/2)

The MA-9 Family combines NEC's rich analog circuit design technology and NEC's analog ASIC technology cultivated through its analog master products, supporting analog IP cores through the use of the world's first leading-edge BiCMOS technology.

In the area of digital/analog mixed circuits, NEC provides already custom designed analog circuits that require advanced circuit technology as IP cores, thereby reducing the development load of users and supporting the creation of high-quality mixed signal systems within a short time.

Analog Front-End Cores for CCD Signal Processing

Through the use of bipolar transistors, which have outstanding analog characteristics compared to CMOS transistors, NEC offers cores with superb low-noise characteristics made possible only by the use of the BiCMOS technology.

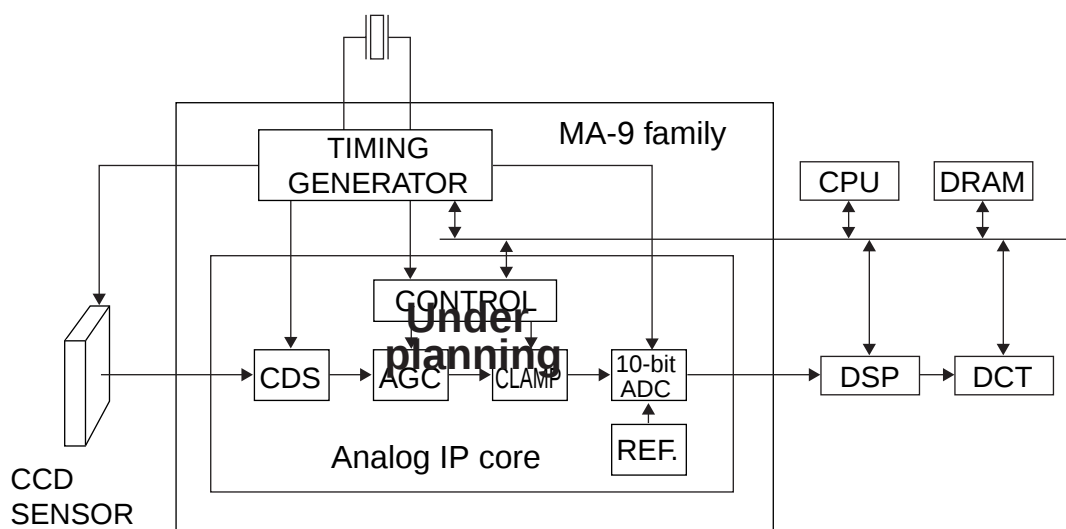


Features

- CDS optimum for digital still cameras (correlated double sampling)
- High-gain AGC for higher sensitivity
- Low-consumption-power-type 10-bit ADC and reference voltage
- Controller circuit inside DAC for analog circuit characteristics correction

Under planning

Application Example (Digital Still Camera)



Mixed Signal ASIC

■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products

● Analog IP Cores (2/2)

High-Speed ADC Cores for Video

The MA-9 Family supports high-speed ADC cores as ASIC cores through the use of the world's most advanced 0.35- μ m BiCMOS technology.

NEC has realized high-speed ADC, which is difficult to realize with a CMOS technology, through optimum design using CMOS transistors and bipolar transistors that can be created only by employing the BiCMOS technology.

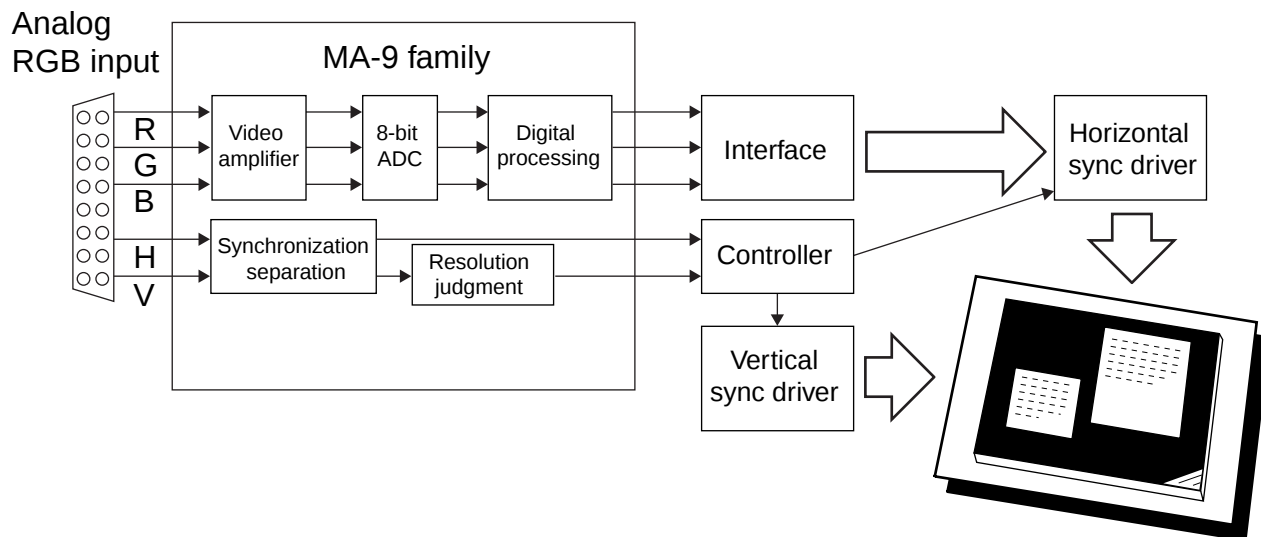
Moreover, by offering these ADCs as cores, NEC makes these products available for a wide range of applications.

For video	8-bit 80-MHz	Under development
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Application Example (LDC Display Video Signal Input)

By combining an analog circuit and a high-speed ADC core on a single chip, it is possible to realize high-precision analog/digital conversion by avoiding the attenuation and degradation of high-speed analog signals caused by the capacitance load of the package I/O pins of analog LSIs and high-speed ADC LSIs externally connected to conventional LSIs and the capacitance load of the printed wiring board.

Moreover, the reduction of these load capacitances enables the simplification of the output stage of the analog circuit, thereby making it relatively easy to achieve high bandwidth analog circuits and enabling the reduction of the power consumption of the LSI.



Mixed Signal ASIC

■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products

● Analog Core

ADC Core

NEC provides both video and general-purpose ADC cores.

For video	10-bit 30 MHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 60 \text{ mA (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 2.0 \text{ LSB (MAX)}$ Analog input range : 0.8 to 1.8 V
	10-bit 15 MHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 30 \text{ mA (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 2.0 \text{ LSB (MAX)}$ Analog input range : 0.8 to 1.8 V
General-purpose	10-bit 100 kHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 1.5 \text{ mA (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 2.0 \text{ LSB (MAX)}$ Analog input range : 0.3 to 3.0 V
	8-bit 100 kHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 0.6 \text{ mA (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 2.0 \text{ LSB (MAX)}$ Analog input range : 0.3 to 3.0 V

DAC Core

NEC provides both video and general-purpose DAC cores.

For video	10-bit 30 MHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 7 \text{ mA (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 2.0 \text{ LSB (MAX)}$ Analog output voltage : 1.2 to 2.2 V
	8-bit 30 MHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 5 \text{ mA (TYP)}$
		Differential linearity error : $\pm 0.5 \text{ LSB (MAX)}$ Integral linearity error : $\pm 1.5 \text{ LSB (MAX)}$ Analog output voltage : 1.4 to 2.4 V
General-purpose	10-bit 100 kHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 40 \mu\text{A (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Analog output voltage : 0 to 3.2 V
	8-bit 100 kHz	$V_{DD} = 3.3 \text{ V (TYP)}$, $I_{DD} = 20 \mu\text{A (TYP)}$
		Differential linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Integral linearity error : $\pm 1.0 \text{ LSB (MAX)}$ Analog output voltage : 0 to 3.2 V

Mixed Signal ASIC

■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products

● Basic Specifications

Logic Block

Product Name		μ PD681XX
Technology		0.35- μ m BiCMOS technology
Supply Voltage		3.3 V $\pm$ 0.3 V (I/O block, internal gates)
Maximum integration (logic only)		1.7 million gates (usable)
Interface level		LVTTL
Delay time	Internal gates ^{Note 1}	114 ps (TYP)
	Input buffer ^{Note 2}	169 ps (TYP)
	Output buffer ^{Note 3}	864 ps (TYP)

Notes 1. Value assuming 2-input NAND power gate, fanout 2, and standard wiring length.

2. Value assuming fanout 2 and standard wiring length.

3. Value assuming load capacitance 15 pF, $I_{OL} = 18$ mA.

Analog Block

Product Name		μ PD681XX
Technology		0.35- μ m BiCMOS technology
Supply Voltage		3.3 V $\pm$ 0.3 V
Transistors	NPN type	$f_T = 10$ GHz, $h_{FE} = 70$ (all TYP)
	PNP type (Vertical type)	$f_T = 2$ GHz, $h_{FE} = 30$ (all TYP)
	MOS	N-ch type, P-ch type for analog circuit
Polysilicon resistor ^{Note}		Absolute precision: $\pm 20\%$, relative precision: $\pm 2\%$
Capacitor (MIM type) ^{Note}		Absolute precision: $\pm 20\%$, relative precision: $\pm 2\%$

Note Values indicated are for reference only. The relative precision applies only to when the pin is positioned in an adjacent location.

Mixed Signal ASIC

■ MA-9 Family (0.35- μ m Mixed Signal ASIC) New Products

● Electrical Characteristics

Absolute Maximum Ratings

Item	Symbol	Conditions	Rating	Unit
Supply voltage	V_{DD}			
3.3-V			−0.5 to +4.6	V
I/O voltage	V_i/V_o			
LVTTL buffer		$V_i/V_o < V_{DD} + 0.5 \text{ V}$	−0.5 to +4.6	V
Output current	I_o	$I_{OL} = 1 \text{ mA}$	3	mA
		$I_{OL} = 2 \text{ mA}$	7	mA
		$I_{OL} = 3 \text{ mA}$	10	mA
		$I_{OL} = 6 \text{ mA}$	20	mA
		$I_{OL} = 9 \text{ mA}$	30	mA
		$I_{OL} = 12 \text{ mA}$	40	mA
		$I_{OL} = 18 \text{ mA}$	60	mA
		$I_{OL} = 24 \text{ mA}$	75	mA
Operating ambient temperature	T_A		−40 to +85	°C
Storage temperature	T_{stg}		−65 to +150	°C

Caution If any of the parameters exceeds the absolute maximum ratings, even momentarily, the quality of the product may be impaired. The absolute maximum ratings are values that may physically damage the product(s). Be sure to use the product(s) within the ratings.

Definition of absolute maximum rating terms

Item	Symbol	Meaning
Supply voltage	V_{DD}	The range of voltage that, even if applied to the V_{DD} pin, will not cause destruction or lower reliability.
Input voltage	V_i	The range of voltage that, even if applied to the input pin, will not cause destruction or lower reliability.
Output voltage	V_o	The range of voltage that, even if applied to the output pin, will not cause destruction or lower reliability.
Input current	I_i	The absolute value of current capacity that, even if applied to the input pin, will not cause latchup to occur.
Output current	I_o	The absolute value of DC current capacity that, even if output from or input to the output pin, will not cause destruction or lower reliability.
Operating ambient temperature	T_A	Range of ambient temperature in which normal logical operation will occur.
Storage temperature	T_{stg}	Range of pin temperature that will not cause destruction or lower reliability when voltage and current are not applied.

[MEMO]

Particular Purpose IC

DSP	240
CCD Linear Image Sensor.....	243
Communication IC.....	245
Mass Storage IC	250
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Display IC	251
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Multisync Monitor IC.....	262
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Video Camera IC	265
Remote Control IC.....	266
Clock IC	266
Rotary Encoder IC	266
A/D Converter IC	267
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Line Driver Receiver IC	267

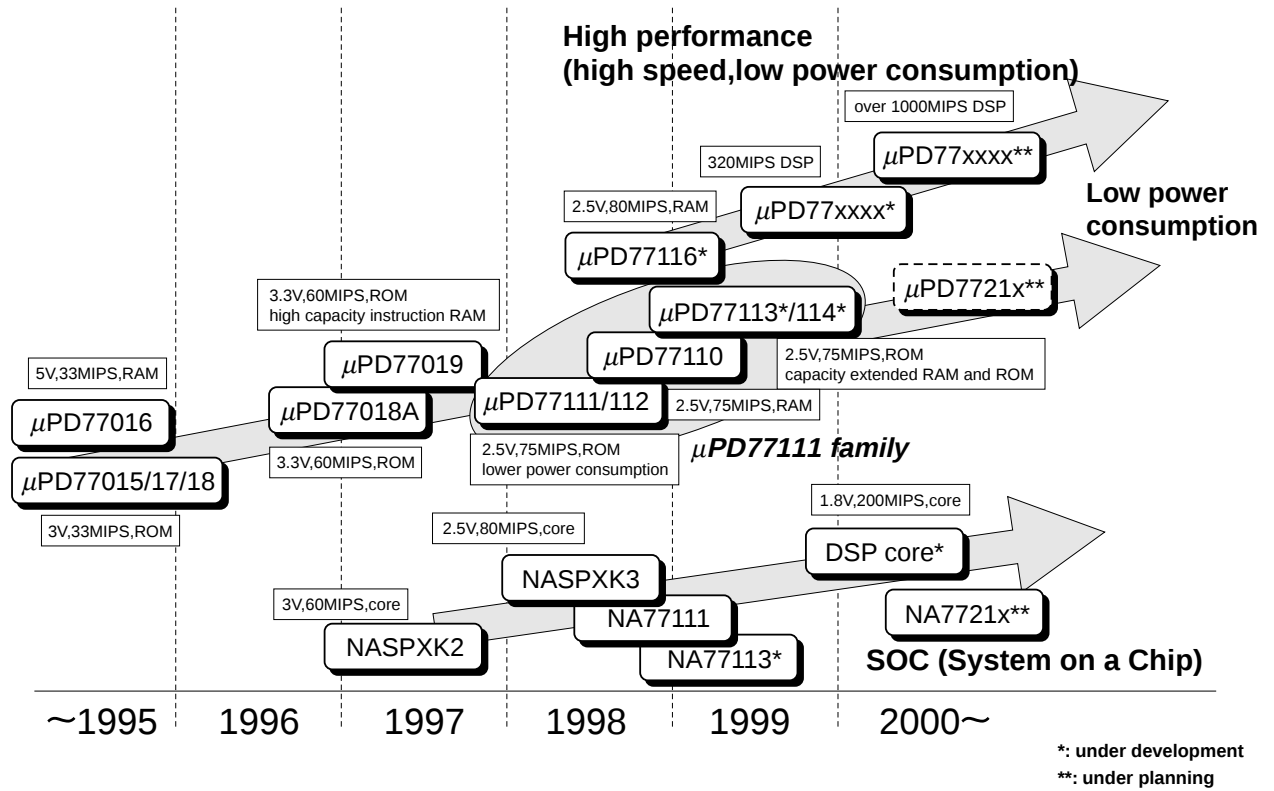
DSP

	μ PD77016	μ PD77018A	μ PD77019	μ PD77019-013
Instruction cycle (ns)	30	16.7	16.7	16.7
Data type	fixed point decimal	fixed point decimal	fixed point decimal	fixed point decimal
Multiplier precision (bits)	$40 + 16 \times 16 \rightarrow 40$	$40 + 16 \times 16 \rightarrow 40$	$40 + 16 \times 16 \rightarrow 40$	$40 + 16 \times 16 \rightarrow 40$
ALU precision (bits)	40	40	40	40
Internal memory (words $\times$ bits)	Program ROM	24K $\times$ 32	24K $\times$ 32	—
	Program RAM	1.5K $\times$ 32	4K $\times$ 32	4K $\times$ 32
	Data ROM	24K $\times$ 16	24K $\times$ 16	—
	Data RAM	4K $\times$ 16	6K $\times$ 16	6K $\times$ 16
External memory (words $\times$ bits)	48K $\times$ 32 (program) 96K $\times$ 16 (data)	32K $\times$ 16 (data)	32K $\times$ 16 (data)	32K $\times$ 16 (data)
Power supply	5.0 V	3.0 V	3.0 V	3.0 V
Power consumption (TYP.)	4.2 mA/MHz (@5.0 V)	1.0 mA/MHz (@3.0 V)	1.1 mA/MHz (@3.0 V)	1.1 mA/MHz (@3.0 V)
Package	• 160-pin QFP	• 100-pin TQFP • 116-pin FBGA	• 100-pin TQFP	• 100-pin TQFP

	μ PD77110	μ PD77111	μ PD77112
Instruction cycle (ns)	13.3	13.3	13.3
Data type	fixed point decimal	fixed point decimal	fixed point decimal
Multiplier precision (bits)	$40 + 16 \times 16 \rightarrow 40$	$40 + 16 \times 16 \rightarrow 40$	$40 + 16 \times 16 \rightarrow 40$
ALU precision (bits)	40	40	40
Internal memory (words $\times$ bits)	Program ROM	32K $\times$ 32	32K $\times$ 32
	Program RAM	35.5K $\times$ 32	1K $\times$ 32
	Data ROM	32K $\times$ 16	32K $\times$ 16
	Data RAM	6K $\times$ 16	6K $\times$ 16
External memory (words $\times$ bits)	64K $\times$ 16 (data)	—	32K $\times$ 16 (data)
Power supply	DSP core: 2.5 V I/O pins: 3.0 V	DSP core: 2.5 V I/O pins: 3.0 V	DSP core: 2.5 V I/O pins: 3.0 V
Power consumption (TYP.)	0.5 mA/MHz (@2.5 V)	0.4 mA/MHz (@2.0 V) 0.5 mA/MHz (@2.5 V)	0.4 mA/MHz (@2.0 V) 0.5 mA/MHz (@2.5 V)
Package	• 100-pin TQFP	• 80-pin TQFP • 80-pin FBGA	• 100-pin TQFP

DSP

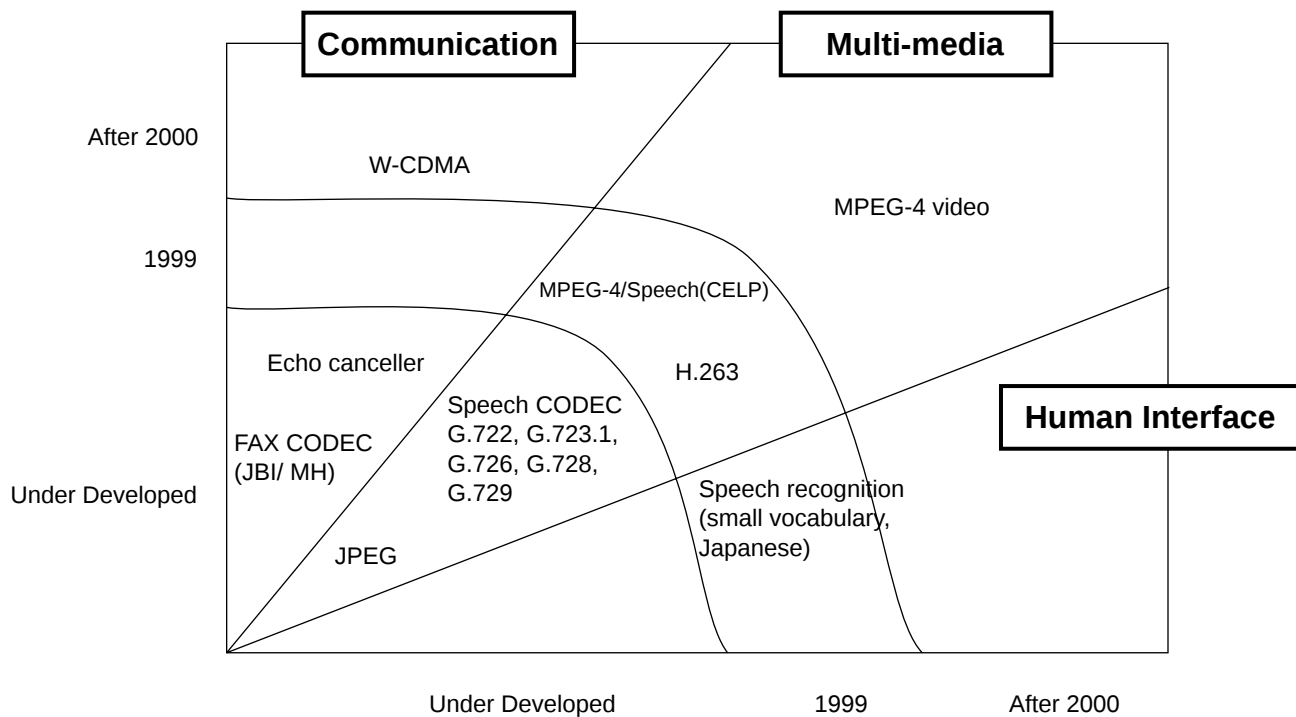
■ DSP Development Plan



DSP**■ DSP Middleware**

Field	Middleware		μPD77016 family
Image	JPEG		sample
	H.263		△
Speech	G.722		◎
	G.723.1		◎
	G.723.1 ANNEX A/C		◎
	G.726 (ADPCM)		◎
	G.728 (LDCELP)		◎
	G.729		◎
	G.729 ANNEX A/B		◎
	MPEG-4/Speech (CELP)		○
	Echo canceller (for hands-free operation)		◎
	Speech recognition (Japanese)	Small vocabulary	△
		1000 words	—

Remark ◎: Developed, ○: Under development, △: Under planning

■ DSP Middleware Development Plan

CCD Linear Image Sensor

■ Monochrome

Part number	μ PD3753	μ PD3734A	μ PD3739
Pixel number	2088	2660	5000
Resolution (dpi/sheet)	200/B4	300/A4	400/A3
Pixel size (μ m)	14 × 14	11 × 11	7 × 7
Sensitivity (TYP.) (V/lx•s)	90	70	9.0
Data rate (MAX.) (MHz)	2	5	40 (20 × 2)
Readout method	single-sided	dual-sided	
Output (ch)	1		2 (in or out of phase)
S/H circuit	—	○	—
Package	22-pin plastic DIP (400 mil)	22-pin plastic DIP (400 mil)	22-pin ceramic DIP (CERDIP) (400 mil)
Features	5 V power supply	Low image lag	μ PD35H71A pin compatible

Light source of the Sensitivity: Daylight color fluorescent lamp

■ Color

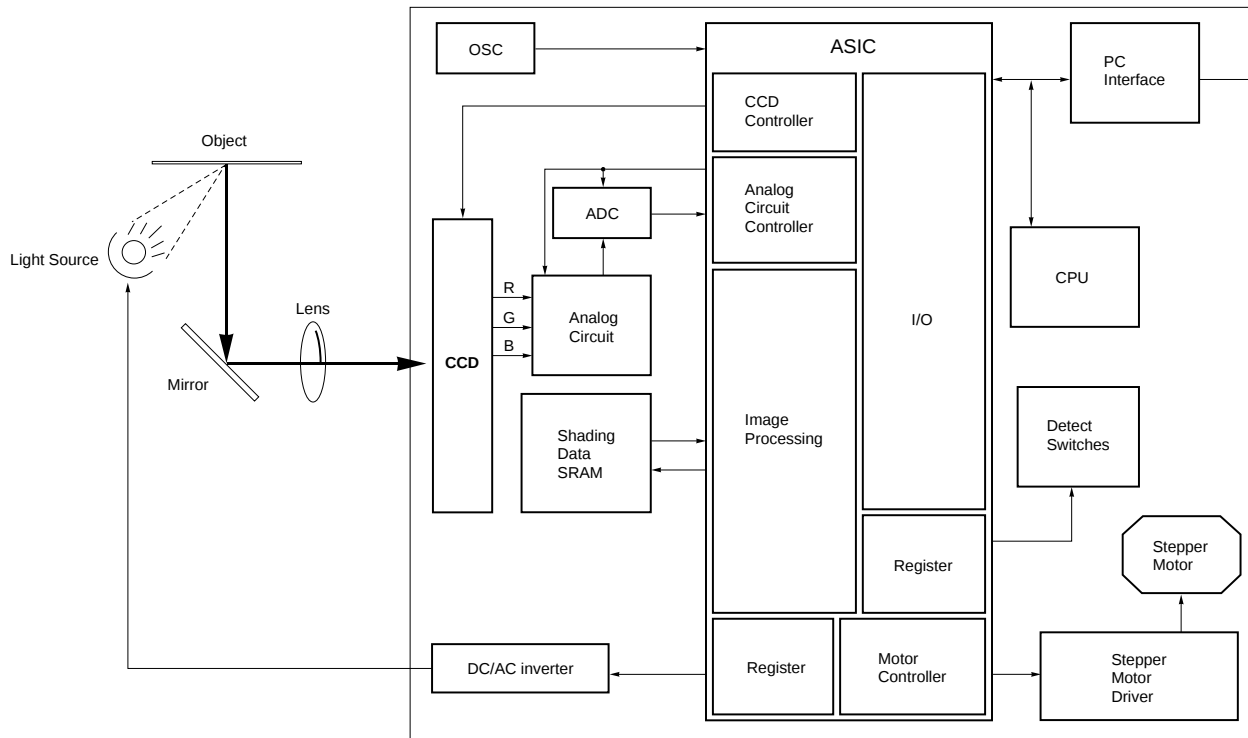
Part number	μ PD3794	μ PD3797	μ PD3799
Pixel number	2700 × 3	5300 × 3	
Resolution (dpi/sheet)	300/A4	600/A4	
Pixel size (μ m)	8 × 8	7 × 7	
Sensitivity (TYP.) (V/lx•s)	R	14.6	11.2
	G	13.3	10.2
	B	8.00	6.10
Line spacing	4 (32 μ m)	4 (28 μ m)	
Data rate (MAX.) (MHz)	4	3	4
Readout method	single-sided		
Output (ch)	1	3	
Clamp pulse generator	○	—	○
Package	22-pin plastic DIP (400 mil)	32-pin plastic DIP (glass cap) (400 mil)	32-pin plastic DIP (plastic cap) (400 mil)
Features	On-chip multiplexer	On-chip S/H circuit	upgraded from μ PD3797

Part number		μPD3719	μPD3729	μPD3728
Pixel number		10600 × 3	5000 × 3	7300 × 3
Resolution (dpi/sheet)		1200/A4	400/A3	600/A3
Pixel size (μm)		7 × 7	10 × 10	
Sensitivity (TYP.) (V/lx•s)	R	9.70	6.20	5.60
	G	8.80	5.40	5.10
	B	5.30	6.80	6.40
Line spacing		10 (70 μm)	4 (40 μm)	
Data rate (MAX.) (MHz)		2	30 (15 × 2)	40 (20 × 2)
Readout method		single-sided	dual-sided	
Output (ch)		3	6 (2-output/color (in phase))	
Clamp pulse generator		—		
Package		36-pin ceramic DIP (600 mil)	24-pin ceramic DIP (400 mil)	36-pin ceramic DIP (600 mil)
Features		Vsat: 4.0 V (MIN.), 15 V power supply, for professional color image scanners	High speed, for digital copiers	

Light source of the Sensitivity: 3200K halogen lamp + C-500S (infrared cut filter, t = 1 mm)

CCD Linear Image Sensor

■ CCD Linear Image Sensor System Block Diagram

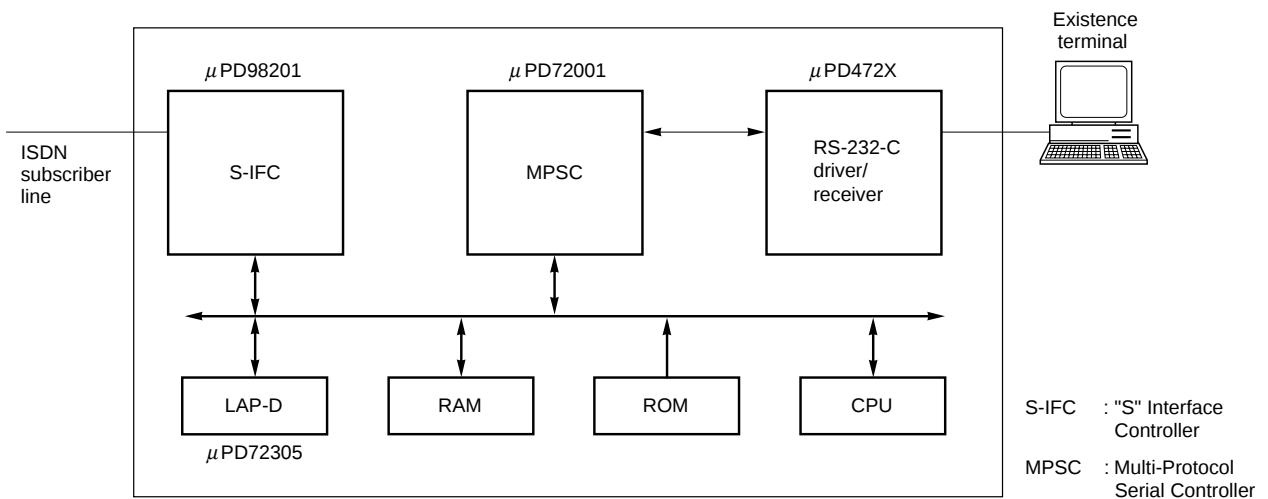


Communication IC

■ Communication LSI

Part number	Function	Features	Package
μ PD72001-11	Multi-protocol serial controller	Allows communication in ASYNC, COP, and BOP mode (2 ch) μ PD72001-11: 5 V Operation μ PD72001-A8: 3.3 V Operation	• 40-pin DIP • 52-pin QFP • 52-pin QFJ • 44-pin TQFP
μ PD72001-A8			• 40-pin DIP • 44-pin TQFP • 52-pin QFP
μ PD72002-11	Multi-protocol serial controller	Allows communication in ASYNC, COP, and BOP mode (1 ch)	• 40-pin DIP • 44-pin QFP • 44-pin QFJ • 44-pin TQFP
μ PD72103A	HDLC controller	HDLC frame control, link/separation are possible, internal DMA controller 8 Mbps operation	• 68-pin QFJ • 80-pin QFP
μ PD72107	Packet communication control LSI (X.25 communication control)	Conforms ITU-T recommendation X.25 (LAP-B '84 ver)	• 64-pin shrink DIP • 68-pin QFJ • 80-pin QFP
μ PD72305	LAP-D protocol processing LSI	Supports LAP-D protocol of ITU-T recommendation	• 64-pin shrink DIP • 68-pin QFJ • 80-pin QFP
μ PD98201	S interface transceiver for NT or TE	4-wire full duplexed communication (basic access) Conforms to ITU-T recommendation I430	• 64-pin QFP
μ PD98203	S interface transceiver for NT	Conforms to ITU-T recommendation I430	• 20-pin DIP
μ PD6708	IE Bus™ controller/driver	Transmit data buffer: 4 bytes Receive data buffer: 20 bytes	• 16-pin SOP • 16-pin DIP
μ PD72042A		Transmit data buffer: 33 bytes Receive data buffer: 40 bytes	• 16-pin SOP
μ PD72042B			

■ ISDN Terminal Adapter

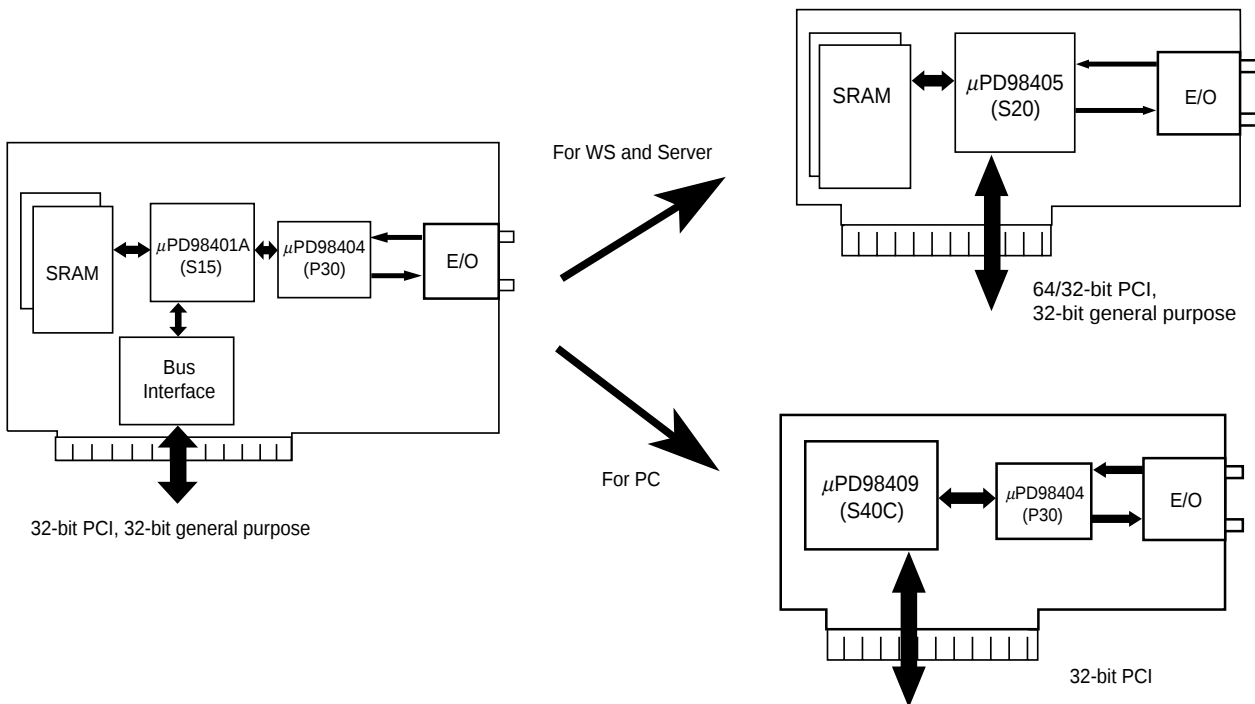


Communication IC

■ Chip Set for ATM

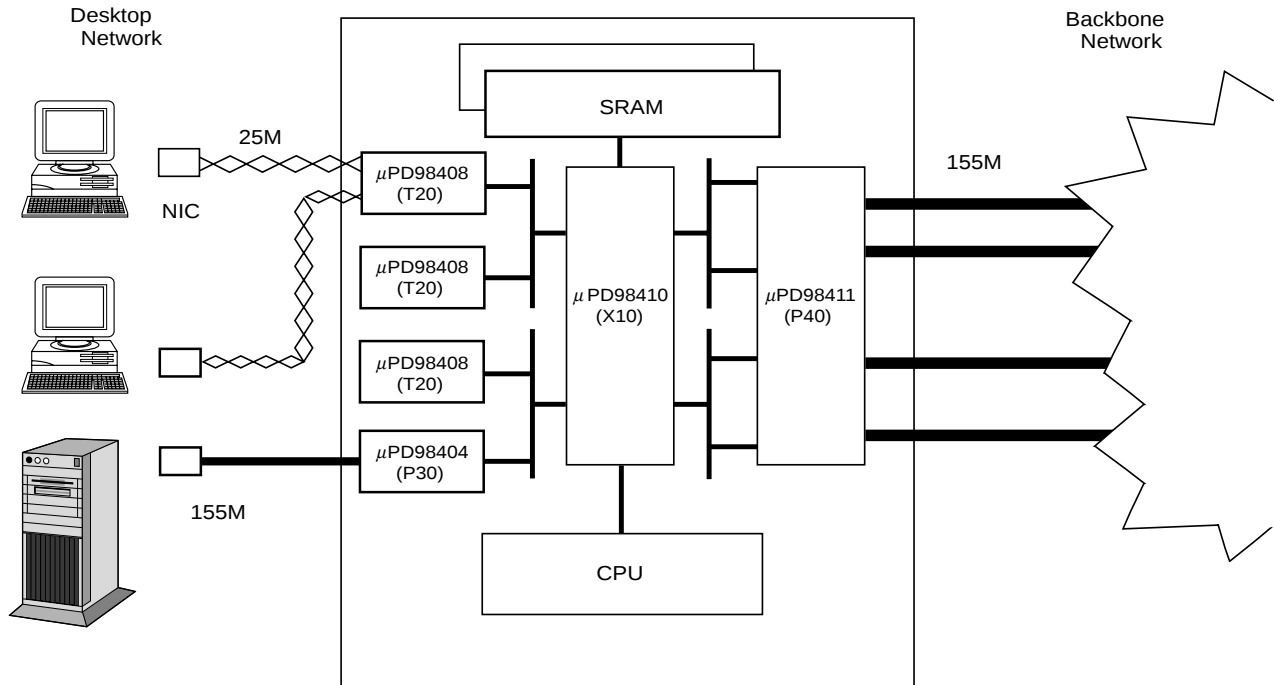
Part number	Function	Features	Package
μPD98401A	ATM SAR Chip	- Upward compatible with μPD98401 - Conforms to ATM Forum recommendations - Implements AAL-5 SAR sublayer and ATM layer functions	208-pin QFP (Fine Pitch)
μPD98404	ATM Advanced SONET Framer	- Supports TC sublayer in PHY layer - Implements SONET STS-3c/SDH STM-1 (155 Mbps) framer function - Integrated Clock recovery/Clock synthesis function - UTOPIA Level 2 interface	144-pin QFP (Fine Pitch)
μPD98405	ATM Integrated SAR controller	- SONET STS-3c/SDH STM-1 (155M bps), Framer and SAR controller with ABR function in a single-chip - Support both PCI bus and generic bus	304-pin QFP (Fine Pitch)
μPD98408	6 port 25M ATM PHY	25.6 Mbps ATM PHY (PMD & TC) function for 6 circuits - UTOPIA Level 2 interface	208-pin QFP (Fine Pitch)
μPD98409	ATM Light SAR Controller	- Implements AAL-5 SAR sublayer and ATM layer function - Supports PCI bus interface - MPEG packet transfer engine	240-pin QFP (Fine Pitch)
μPD98410	1.2 Gbps ATM Switch	- ATM switching function in a single-chip 1.2 Gbps with non blocking - ABR traffic control	580-pin BGA
μPD98411	ATM QUAD SONET FRAMER	Implements 4 ports SONET STS-3c/SDH-1 (155M bps) framer function on chip	240-pin QFP (Fine Pitch)

■ PCI Bus Supporting ATM-NIC



Communication IC

■ ATM Switch



■ Ethernet LSI

Part number	Function	Features	Package
μ PD98421	High Speed Address Search Engine	- CAM (64-bit $\times$ 8K Entry) - Implements three search modes	240-pin QFP (Fine Pitch) 240-pin FPBGA™
μ PD98431	8-port 10/100 Mbps Ethernet Controller	8-port 10/100 Mbps Ethernet MAC - MII and 10 Mbps serial interface	352-pin BGA

■ Standard USB

Part number	Function	Features	Package
μ PD72011	USB Hub Controller	- All USB HUB function in a single-chip - Compliance with USB Specification 1.0 - Supports Self-powered and Bus-powered 4 or 5 down-port selectable	42-pin SDIP 44-pin QFP
μ PD72012		- Up-grade LSI of μPD72011 - Compliant with USB specification 1.1 - Built-in Mask-ROM for Generic HUB Descriptor Selectable to use Standard or User-Defined	42-pin SDIP 44-pin QFP

Communication IC

■ LSI for IEEE1394

Part number	Function	Features	Package
μ PD72850	IEEE1394 400M PHY	- Compliant with P1394a draft2.0 - Selectable for 1-port, 2-port, 3-port - Data Rate: 100/200/400 Mbps - Compliant with MD8405 (FFM)	• 80-pin TQFP
μ PD72861	IEEE1394 OHCI Host Controller	- Compliant with Open HCI for IEEE1394-1995 1.0 - Compliant with P1394a draft2.0 - Data Rate: 100/200/400 Mbps - Supports PCI-Bus/Cardbus	• 100-pin TQFP
μ PD72870/71★	IEEE1394 1-chip OHCI Host Controller	- Integrated OHCI LINK and .aPHY in a single chip 3-port: μPD72870, 1-port: μPD72871	160-pin LQFP 192-pin FPBGA

★: Under development

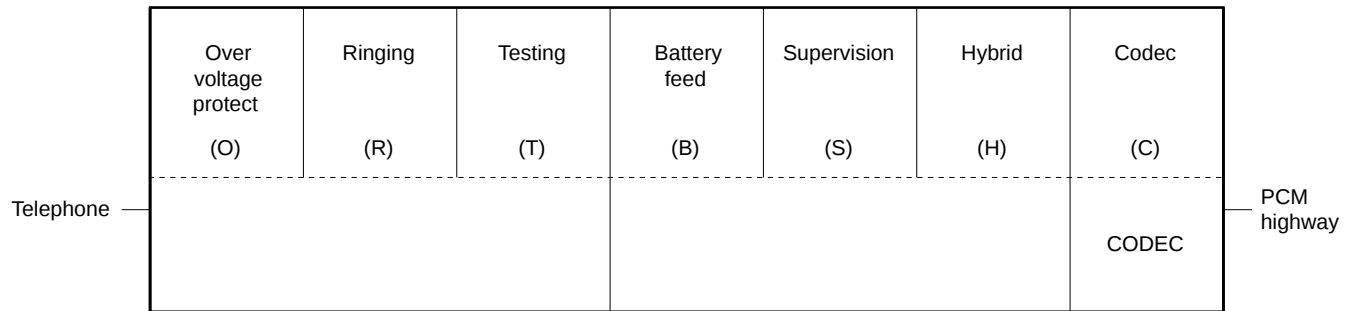
■ Power Switch for USB Application

Part number	Function	Internal circuit	Input voltage (V)	Circuit current (mA)	Output current (A)	Over current detect (A)	Package	Main application
μ PD16855A	Pch High-side switch for USB (High active)	2	4.0 to 5.5	1.5	0.5	0.6 to 1.25	• 8-pin SOP (225 mil)	Note PC CRT monitor LCD monitor
μ PD16855B	Pch High-side switch for USB (Low active)	2					• 8-pin DIP (300 mil) • 8-pin SOP (225 mil)	
μ PD16855C	Pch High-side switch for USB (High active, instant switch off)	2					• 8-pin SOP (225 mil)	
μ PD16855D	Pch High-side switch for USB (Low active, instant switch off)	2					• 8-pin SOP (225 mil)	
μ PD16874★	Pch High-side switch for USB (Low active)	4		2.5			• 16-pin DIP (300 mil) • 16-pin SOP (300 mil)	CRT monitor LCD monitor
μ PD16875★	Pch High-side switch for USB (Low active)	2		0.1			• 8-pin DiP (300 mil) • 8-pin SOP (225 mil)	Key board HUB BOX

★: Under development

Communication IC

■ Analog Line Card LSI

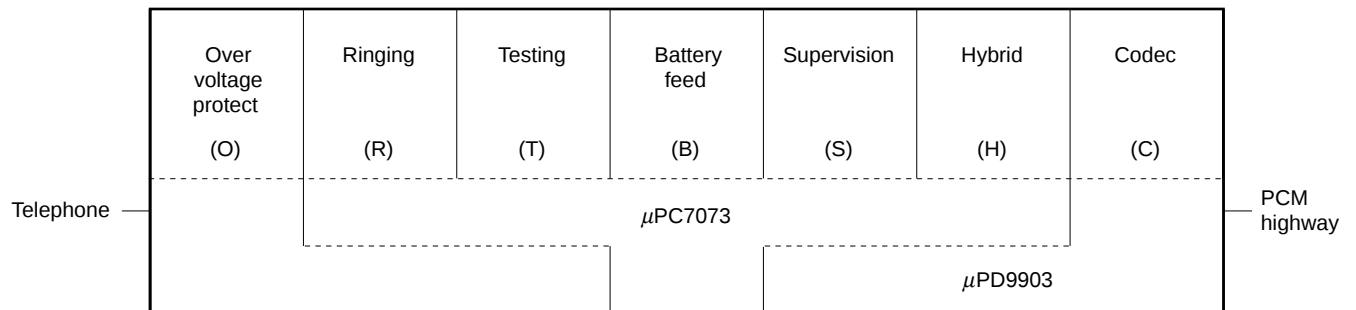


CODEC
(PCM CODEC)

μPD9611

programmable control (DGS, power-down, A/μ-law),
4-ch PCM CODEC, Single 5 V power supply

• 48-pin SSOP



BS-SLIC

μPC7073

• 3 relay drivers

• 48-pin SSOP

Digital CODEC

μPD9903

• Terminal impedance and Hybrid balance network
can be selected by combining μPC7073

• 48-pin SSOP

Mass Storage IC

Part number	Function	Features	Package
μPC2575	RF amplifier for 24X speed CD-ROM	RF amplifier, error amplifier for 24X speed CD-ROM	• 36-pin SSOP
μPC2576	RF amplifier for 32X speed CD-ROM	RF amplifier, error amplifier for 32X speed CD-ROM Supports CD-RW Lens error amplifier Supports voltage output type pickup Power management	• 38-pin SSOP
μPD63724A	1 chip CD-ROM controller	Digital Servo, Data Processor, CD-ROM Decoder, Host I/F on 1 chip Supports 24X speed operation Automatic adjustment function Wide capture range High speed CAV audio playback Supports PIO mode 4, DMA mode 2 (Enhanced IDE/ATAPI) Power management Digital audio interface output	• 160-pin LQFP
μPD63725		Digital Servo, Data Processor, AudioDAC, CD-ROM Decoder, Host I/F, 1MbitSRAM on 1 chip Supports 32X speed operation Automatic adjustment function with μPC2576 Wide capture range by analog PLL High speed CAV audio playback Supports PIO mode 4, DMA mode 2 (Enhanced IDE/ATAPI) Supports UltraDMA mode 2 Supports CD TEXT Power management	• 176-pin QFP

Global Positioning System IC

RF IC for GPS receiver

Type	Part number	Function (frequency unit: MHz)	V _{CC} (V)	I _{CC} (mA)	CG (dB)	Package
General purpose wideband separate IC	μPC2756	RF downconverter with osc. Tr	2.7 to 3.3	6	14	• 6-pin mini-mold • 6-pin super mini-mold
	μPC2753	IF downconverter with gain control amplifier	2.7 to 3.3	6.5	60 to 79	• 20-pin plastic SSOP (225 mil)
Clock frequency specific 1 chip IC	μPB1005	RF/IF downconverter + PLL synthesizer TCXO = 16.368/1stIF = 61.380/ 2ndIF = 4.092	2.7 to 3.3	45	72 to 92	• 36-pin plastic QFN

Typical performance. (T_A = +25°C, V_{CC} = 3.0 V)

Display IC

Fluorescent indicator panel (FIP) driver IC

Part number	Drives	Number of outputs	Withstand voltage (V)	Output current (mA)	Output type	Package	Main applications
μPD6320	Static	39	18	1	CMOS	• 52-pin QFP	Car stereo
μPD6321			25	5	Pch-O.D	• 28-pin DIP	Automotive
μPD6323	Static	21	40				
μPD6323B							
μPD6340	Dynamic	20	80	25	NPN+Nch	• 52-pin QFP	ECR, PPC
μPD6700	Static	47	18	1	CMOS	• 56-pin QFP	Car stereo
μPD16304	Dynamic	40	200	20	CMOS	• 80-pin QFP*	Graphic FIP module
μPD16306	Dynamic	64	80	50	CMOS	• 100-pin QFP	
μPD16306A	Dynamic	64	80	25	CMOS	• 100-pin QFP	
μPD16310	Dynamic	40	80	50	CMOS	• 80-pin QFP*	
μPD16326	Dynamic	32	130	20	CMOS	• 44-pin QFP	
μPD16326A	Dynamic	32	150	20	CMOS	• 44-pin QFP	

※: Three direction lead

Fluorescent indicator panel (FIP) controller/driver IC

Part number	Drives	Duty (Max.)	Number of outputs		Number of characters*	Logic voltage (V)/ Drive voltage (V)	Package	Main application	Remarks
			Segments	Grids					
μPD16311	Segment	1/16	12	16	192 segments	5/35	• 52-pin QFP	VCR	Included key scan
μPD16312	Segment	1/11	11	11	121 segments	5/35	• 44-pin QFP	VCR	
μPD16313	Segment	1/11	11	11	121 segments	5/35	• 44-pin QFP	VCR	Included key scan (μPD16312 mirror)
μPD16314	DOT character	1/24	80	24	24 × 2 characters	5/50	• 144-pin QFP	OA, FA	
μPD16315*	Segment	1/14	16	14	224 segments	5/35	• 44-pin QFP	VCR	Included key scan

※: At maximum duty

★: Under development

Display IC

■ Liquid crystal display (LCD) controller/driver IC

Part number	Drives	Duty (MAX.)	Number of outputs		Number of characters*1	Logic voltage (V)/ Drive voltage (V)	Package	Main application	Remarks
			Segments	Commons					
μPD7225	Segment	1/4	32	4	128 segments	2.7 to 5.5/ 2.7 to 5.5	• 52-pin QFP • 56-pin QFP	Car audio	Included key scan
μPD16430A			60	4	240 segments	3.5 to 6/ 3.5 to 14	• 80-pin QFP		
μPD16431A			56	4	224 segments	2.7 to 5.5/ 2.7 to 6.5	• 80-pin QFP		
μPD16432B	DOT character	1/15			12 × 2 characters + 60 pictographs	2.7 to 5.5/12	• 100-pin QFP		
μPD16434		1/16	42	16	8 × 2 characters	2.7 to 5.5/12	• 80-pin QFP		
μPD16435	Graphic	1/73	119	73	119 × 71 dots + 119 × 2 pictographs	2.7 to 5.5/10*2	• TCP		Included DC/DC Converter
μPD16435A							• CHIP		
μPD16435B									
μPD16670	DOT character	1/36	60	33	12 × 4 characters + 60 pictographs	2.7 to 3.6/12*2	• CHIP	Mobile phone	
μPD16675A	Graphic		128	34	128 × 32 dots + 128 × 2 pictographs	2.7 to 5.5/10*2		Pager	
μPD16676			1/16 1/32	61	16	61 × 16 dots			
μPD16680		1/53	100	53	100 × 51 dots + 100 × 2 pictographs	2.7 to 3.6/12*2		Mobile phone	Included DC/DC Converter
μPD16681		1/52	96	52	96 × 52 dots + 96 pictographs (8 × 4 Japanese Kanji character)	2.45 to 4.0/12*2			• Included DC/DC Converter • Included Japanese Kanji ROM
μPD16682		1/65	132	65	132 × 64 dots + 132 pictographs	2.4 to 5.5/12*2	• CHIP • TCP		Included DC/DC Converter

*1: At maximum duty

*2: Internal DC/DC Converter

Display IC

■ Liquid crystal display (LCD) driver IC

Part number	Drives	Number of outputs	Withstand voltage (V)	Logic voltage (V)	Package	Main applications
μ PD6320	Static	39	18	5.0	• 52-pin QFP	Car stereo
μ PD6321						
μ PD16448A	TFT (source) Analog	240	5.0	3.3	• TCP	LCD-TV
μ PD16780 [★]		288/300	5.0	3.3/5.0		LCD-TV
μ PD16633B	TFT (source) 64 gray scale	312	10.5	3.3		XGA
μ PD16634A		300	8.5	3.3		SVGA
μ PD16638A		300/309	8.5	3.3		SVGA/XGA
μ PD16640A		300/309	3.3/5.0	3.3		SVGA/XGA
μ PD16640B						
μ PD16640C		384	5.0	3.3		XGA
μ PD16644						
μ PD16647 [★]		402	3.3/5.0	3.3		SVGA
μ PD16710		300/309	12.0	3.3		SVGA/XGA
μ PD16715		384	13.5	3.3		XGA/SXGA
μ PD16715A [★]						
μ PD16732		384	8.5	3.3		XGA/SXGA
μ PD16732A						
μ PD16732B		384	8.5	3.3		XGA/SXGA
μ PD16740	TFT (source) 256 gray scale					
μ PD16750	384	8.5	3.3	XGA		
μ PD16650	TFT (gate)	120/128	40	3.3/5.0		—
μ PD16652 [★]		192/200	31	3.3		—
μ PD16654		150/154	40	3.3		—
μ PD16655		240	31	3.3		—
μ PD16661A	STN (column) 4 gray scale	160	5	3.3		PDA (1/8 VGA to VGA)
μ PD16666A	STN (row)	240	36	5.0		PDA (1/8 VGA to VGA)
μ PD16662	STN (column) 4 gray scale	240	5	3.3		PDA (1/8 VGA to 1/2 VGA)
μ PD16667	STN (row)	160	36	5.0		PDA (1/8 VGA to 1/2 VGA)
μ PD16663	STN (column) 16 gray scale	240	5	3.3		PDA (1/8 VGA to 1/2 VGA)
μ PD16664 [★]	STN (column) 4 gray scale	208	5	3.3		PDA (144 × 128 to 416 × 320 dots)

★: Under development

■ Plasma display, EL display driver IC

Part number	Drives	Number of outputs	Withstand voltage (V)	Output current (mA)	Output type	Package
μ PD16305	AC-PDP row	40	200	400	CMOS	• 80-pin QFP*
μ PD16306B	AC-PDP/EL column	64	80	50		• 100-pin QFP
μ PD16306A		64	80	25		• 100-pin QFP • 100-pin QFP
μ PD16310	AC-PDP/EL	40	80	50		• 80-pin QFP*
μ PD16327	AC-PDP column	64	100	40		• 100-pin QFP • 100-pin QFP
μ PD16331		40	100	150		• 80-pin QFP • 80-pin QFP
μ PD16334		96	80	50		• For COB
μ PD16335		96	80	50		• For COB
μ PD16337		64	150	40		• 100-pin QFP
μ PD16364*		160	60	25		• TCP

*: Three direction lead

★: Under development

Display IC

Other driver IC

Part number	Number of outputs	Withstand voltage (V)	Output current (mA)	Output type	Package	Main applications
μ PD6320 μ PD6321	4 × 4	18	20	NPN+Nch	• 52-pin QFP	Car stereo (LED)
μ PD6345	8	40	100	NPN-O.C	• 16-pin DIP • 16-pin SOP	Thermal head, LED, solenoid

NPN-O.C: NPN open-collector output (sink driver)

Intelligent Power MOS LSI

Motor Driver

Part number	Function	Recommended operation voltage range (V)		Output current (A)	Package	Main application
		Control part	Output part			
μ PD16804	DC motor driver	3 to 6	Up to 7.5	±0.5	• 16-pin SOP	Camera, DSC
μ PD16805		3 to 6	Up to 7.5	±1.0		
μ PD16823		2.5 to 6	Up to 7.5	±0.5		
μ PD16803	stepping motor driver	4 to 6	4 to 13.2	±0.38	• 20-pin SOP	FDD (2 aspects excitation)
μ PD16808		4 to 6	4 to 13.2	±0.45		FDD (1-2 aspects excitation)
μ PD16813		4 to 6		±0.31	• 16-pin SOP	FDD (2 aspects excitation)
μ PD16814		4 to 6		±0.415		FDD (1-2 aspects excitation)
μ PD16818		2.7 to 6		±0.38	• 20-pin SOP • 20-pin SSOP	FDD (2 aspects excitation)
μ PD16833		2.5 to 5.5	2.7 to 5.5	±0.3	• 30-pin SSOP	camcorder 4 ch-H bridge
μ PD16833A		2.5 to 5.5	2.7 to 5.5	±0.3	• 30-pin SSOP • 26-pin TSSOP	camcorder 4 ch-H bridge
μ PD16835		2.7 to 5.5	4.8 to 11	±0.15	• 38-pin SSOP	camcorder microstep drive
μ PD16836	3 aspects blush-less DC motor driver	4.5 to 5.5	10.8 to 13.2	±1.3 peak	• 24-pin SOP (375 mil)	CD-ROM PWM drive
μ PD16837	stepping motor driver	4 to 6	10.8 to 13.2	±1.0 peak	• 30-pin SSOP (0.8 mm pitch)	CD-ROM/DVD actuator drive
μ PD16853B	3 aspects blush-less DC motor driver	4.5 to 5.5		±1.9 peak		CD-ROM PWM drive
μ PD16856	3 aspects blush-less DC motor driver	4.5 to 5.5	10.8 to 13.2	±2.0 peak		CD-ROM PWM drive
μ PD16857	stepping motor driver	3.0 to 3.6	10.8 to 13.2	±1.0 peak	• 38-pin SSOP	DVD-RAM
μ PD16858B μ PD16858C	3 aspects blush-less DC motor driver	4.5 to 5.5		±1.5 peak	• 30-pin SSOP	CD-ROM PWM drive
μ PD16877	stepping motor driver	2.5 to 5.5	2.7 to 5.5	±0.25	• 24-pin TSSOP	camcorder 4-ch-H bridge

Power MOS IC for Voltage Regulator

Part number	Function	Input voltage (V)	Output voltage (V)	Output current (mA)	Package	Main application
μ PD16901	Step-up type DC/DC converter for PCMCIA	4.5 to 5.5	11.72 to 12.28	140	• 14-pin SOP	Note PC

Power Switch for USB Application

Part number	Function	Internal circuit	Input voltage (V)	Circuit current (mA)	Output current (A)	Over current detect (A)	Package	Main application
μ PD16855A	Pch High-side switch for USB (H-active)	2	4.0 to 5.5	1.5	0.5	0.6 to 1.25	• 8-pin SOP (225 mil)	Note PC CRT monitor LCD monitor
μ PD16855B	Pch High-side switch for USB (L-active)	2					• 8-pin DIP (300 mil) • 8-pin SOP (225 mil)	
μ PD16855C	Pch High-side switch for USB (H-active, instant switch off)	2					• 8-pin SOP (225 mil)	
μ PD16855D	Pch High-side switch for USB (L-active, instant switch off)	2					• 8-pin SOP (225 mil)	
μ PD16874★	Pch High-side switch for USB (L-active)	4		2.5			• 16-pin DIP (300 mil) 16-pin SOP (300 mil)	CRT monitor LCD monitor
μ PD16875★	Pch High-side switch for USB (L-active)	2		0.1			• 8-pin DIP (225 mil) • 8-pin SOP (225 mil)	Key board HUB BOX

★: Under development

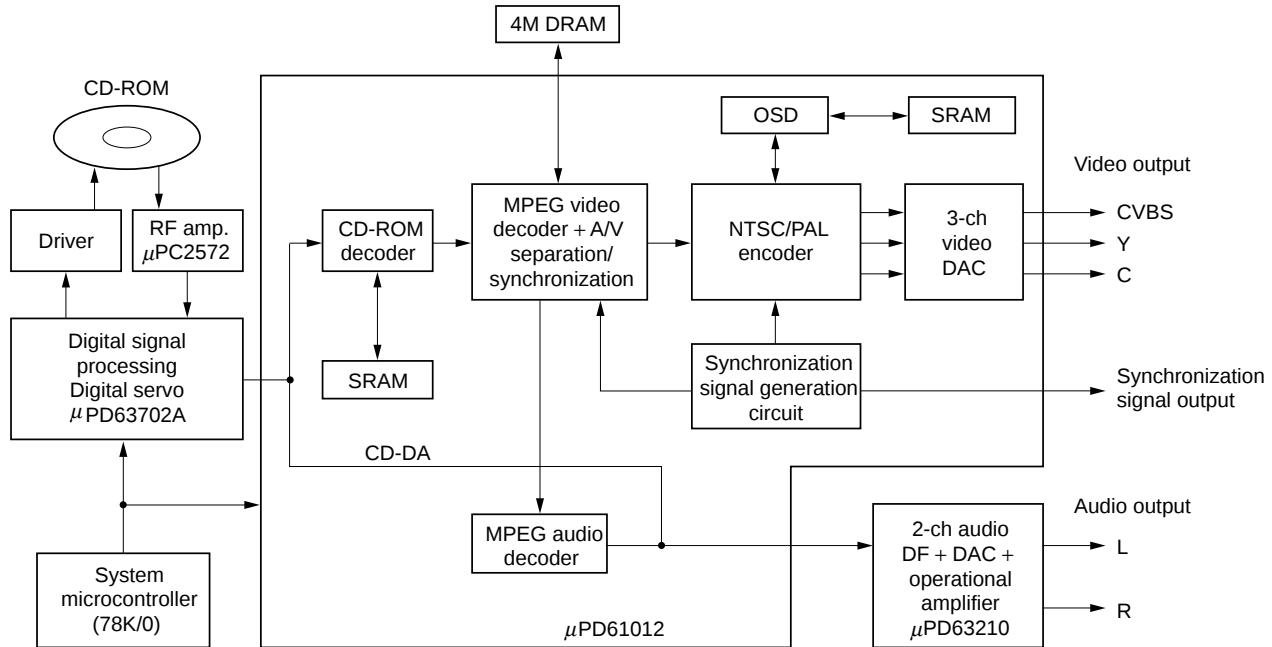
Image IC

Part number	Function	Package
μ PD72254Y★	Graphics LSI	• 208-pin QFP

★: Under development

MPEG IC

Part number	Function	Package
μPD61012	MPEG1 Audio/Video decoder for Video-CD	• 100-pin LQFP
μPD61030	Signal processing for STB, includes MPEG2 Audio/Video decoder, TS demultiplexer, Graphics and V _R 4110CPU	• 304-pin QFP

■ Video CD

Audio IC

■ Radio frequency amplification

Part number	Recommended operating voltage range (V)	Function					Recom-mended ap-plication	Package
		AM tuner	FM front end	FM IF amplification	FM detection	Other functions		
μPC2533	7.5 to 8.5	●				Double super heterodyne DTS use	●	• 36-pin SOP

■ Pre-amplifier

Part number	Recommended operating voltage range (V)	Function				Recommended application		Package
		Play back amplifier	Recording amplifier	MIC amplifier	Other functions	Radio cassette recorder	Car radio	
μPC1228	6 to 16	●			Dual	●	●	• 8-pin SIP

■ Power amplifier

Part number	Recommended operating voltage range (V)	Electrical characteristics (typical value)			Function	Recommended application			Package
		P _o (W)	V _{cc} (V)	R _L (Ω)		Home stereo	Radio cassette recorder	Car radio	
μPC1316	3 to 16	1.2	9	8	Dual		●		• 14-pin DIPTAB
		0.5	6	8	Low pop noise				

■ D/A converter for audio system

Part number	Recommended operating voltage range (V)	Function	Recommended application			Package
			Home stereo	Portable	Car stereo	
μPD6376	4.5 to 5.5	16-bit D/A converter	●	●	●	• 16-pin SOP
μPD6379 μPD6379A	4.5 to 5.5	16-bit D/A converter	●	●	●	• 8-pin SOP
μPD6379L μPD6379AL	3.0 to 5.5					
μPD63200	4.5 to 5.5	18-bit D/A converter	●	●	●	• 16-pin SOP
μPD63210 μPD63210L	4.5 to 5.5 3.0 to 5.5	16-bit D/A converter with digital filter	●	●	●	• 28-pin SOP

■ Sound CODEC

Part number	Function	Features	Package
μPD63310	Sound codec	- ΔΣ type ADCs and DACs are incorporated. - Mixers are incorporated into the analog input section and analog output section. - Low-noise microphone amplifiers are incorporated. - Sampling frequency: 2 to 48 kHz (master clock: 256 fs) - Single power source: +3 to 5.5 V - Operating temperature range: -20 to +80°C	• 80-pin TQFP

Audio IC
■ Device kit for CD

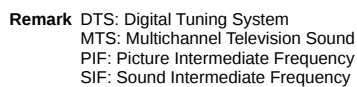
Part number	Recommended operating voltage range (V)	Function	Recommended application			Package
			Home stereo	Portable	Car stereo	
μPC2572	4.5 to 5.5	RF amp, error amp, APC for CD player	●		●	• 38-pin SOP
μPD63702A	4.5 to 5.5	Digital servo, data processor, DAC for CD player	●		●	• 80-pin QFP
μPD63710	4.5 to 5.5	RF amp, servo, data processor, ATT, DAC for CD player	●		●	• 100-pin LQFP

■ Other functions

Part number	Recommended operating voltage range (V)	Function	Recommended application			Package
			Home stereo	Tape deck	Radio cassette recorder	
μPC1237	25 to 60	Stereo power amplifier protection circuit	●			• 8-pin SIP

US MTS: Multi Television Sound for USA specifications

■ US MTS (TV) System Block Diagram

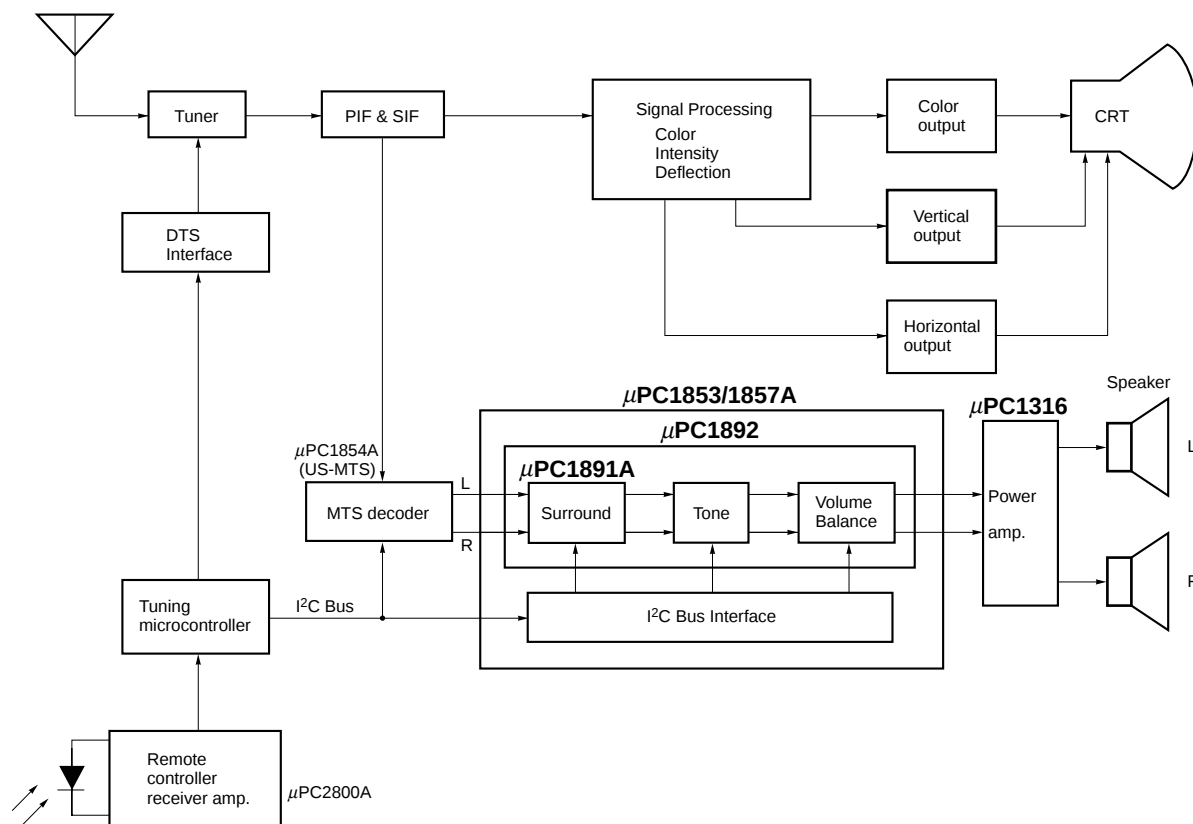


TV IC

■ Matrix Surround

Part number	Function	Package
μ PC1891A	Matrix Surround (Phase Shift)	• 20-pin DIP
μ PC1892	Matrix Surround (Phase Shift), Tone/Balance/Volume, L + R output	• 30-pin SDIP
μ PC1853	I ² C bus, BASS boost, Matrix Surround, Tone/Balance/Volume, Audio output, L + R output	• 30-pin SDIP
μ PC1857A	I ² C bus, Matrix Surround, Tone/Balance/Volume, Mixer input	• 30-pin SDIP

■ Matrix Surround (TV) System Block Diagram



Remark DTS: Digital Tuning System
 MTS: Multichannel Television Sound
 PIF: Picture Intermediate Frequency
 SIF: Sound Intermediate Frequency

TV IC

■ Digital Satellite Broadcasting

Part number	Function	Package
μ PD61511	A/D Converter, QPSK demodulation, Viterbi decoder, Reed-Solomon error correction	• 100-pin QFP
μ PC2781	AGC amplifier + Quadrature demodulator	• 20-pin SSOP
μ PC2782	L band frequency down converter + IF-AGC amplifier	• 20-pin SSOP
μ PC2795	L band frequency down converter	• 8-pin SSOP (175 mil)
μ PC3205	AGC amplifier + Quadrature demodulator	• 20-pin SSOP

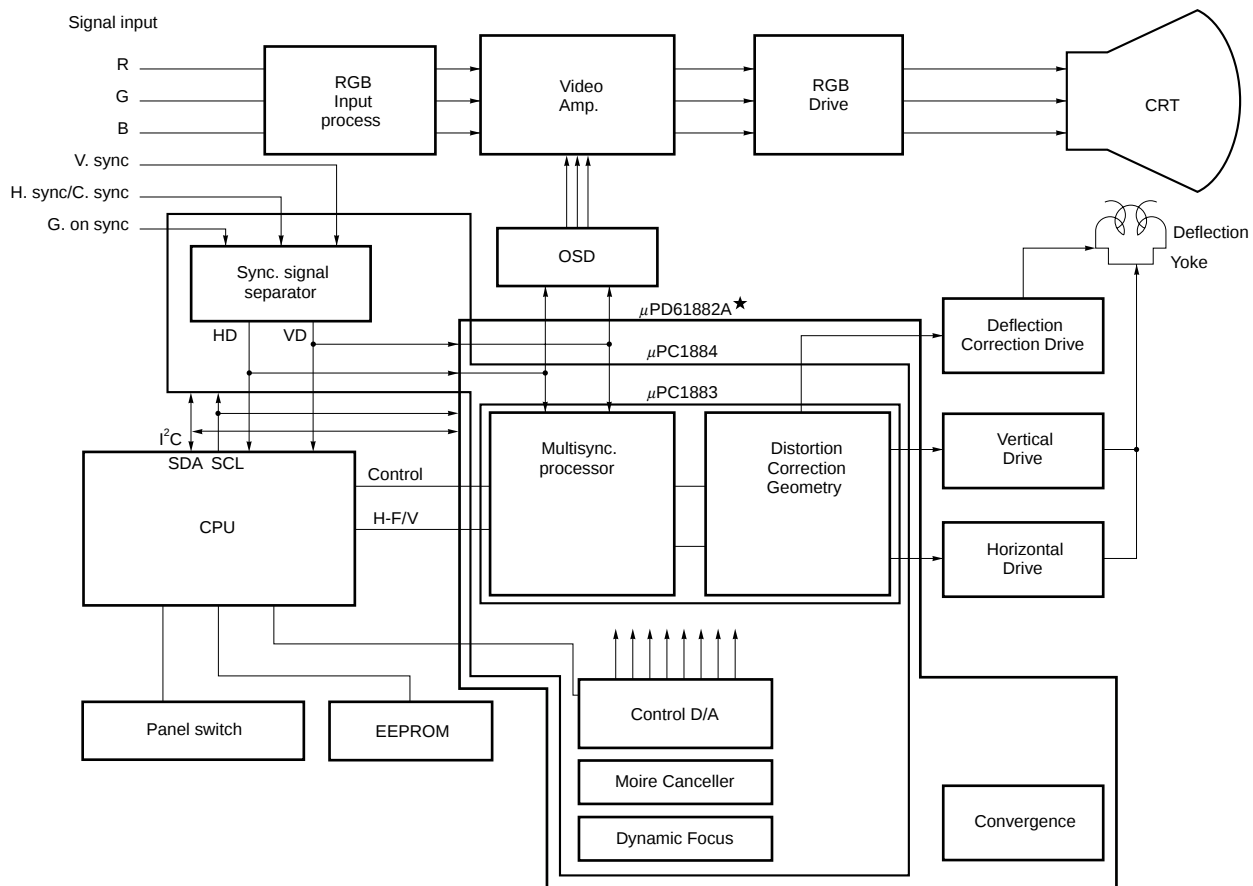
■ Digital CATV

Part number	Function	Package
μ PC2798GR	QAM IF down converter (AGC amplifier + MIX/OSC + Video amplifier)	• 20-pin SSOP
μ PC3206GR	50 dB AGC amplifier + Video amplifier	• 20-pin SSOP
μ PC3211GR	AGC amplifier for Return-pass	• 20-pin SSOP

Multisync Monitor IC

Part number	Function	Package
μ PC1883	Horizontal Vertical sync. processor, Picture geometry processor	• 30-pin SDIP
μ PC1884	Horizontal Vertical sync. processor, Picture geometry processor (I ² C bus)	• 30-pin SDIP
μ PD61882A★	Horizontal Vertical sync. processor, Picture geometry processor (I ² C bus)	• 64-pin QFP

★: Under development



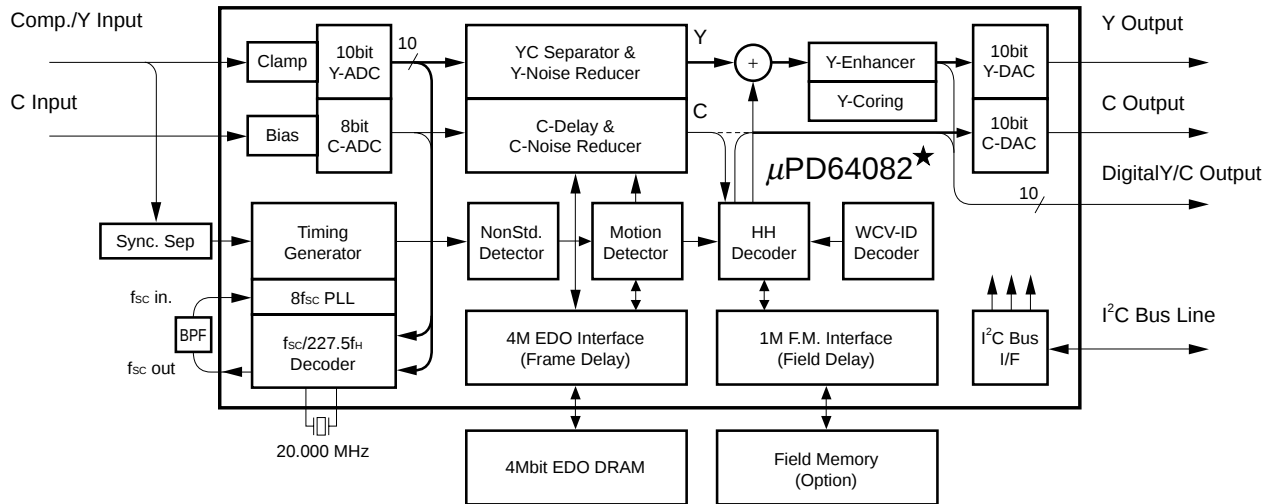
★: Under development

Digital Image IC

■ 3D Y/C Separator

Part number	Function	Package
μ PD64082★	3D Y/C separator and noise reducer with 10 bit A/D converter	• 100-pin QFP

★: Under development



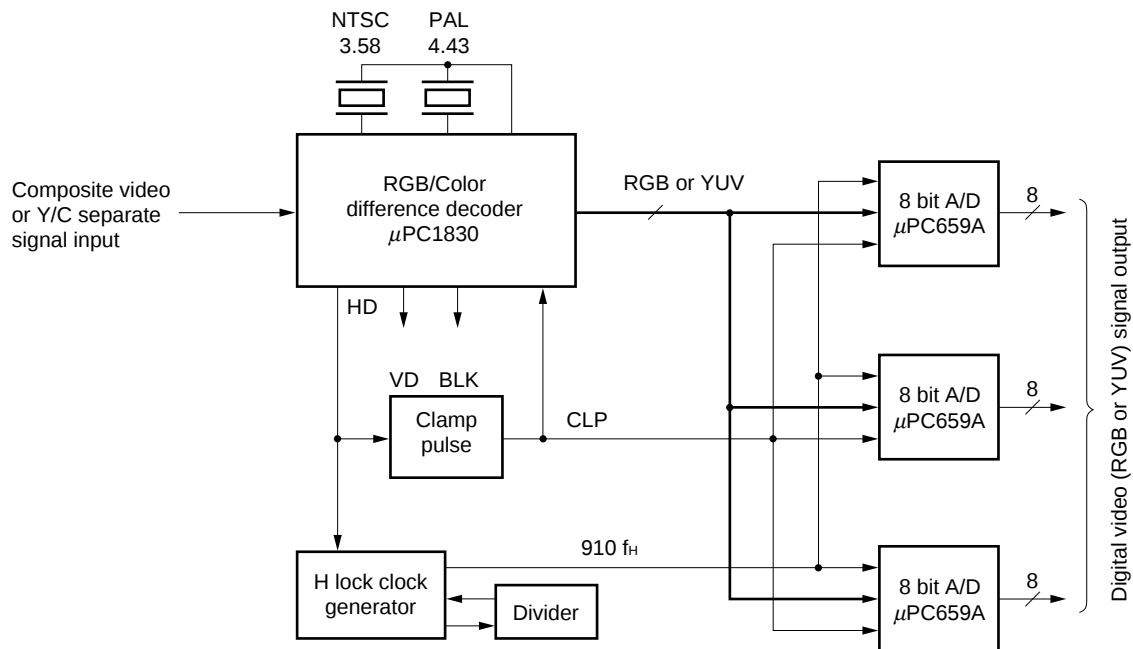
★: Under development

Digital Image IC

■ Analog Frontend IC

Part number	Function	Package
μ PC1830	5 V operation chroma decoder NTSC/PAL, 525/625 line, 50/60 Hz selectable, Matrix circuit	• 42-pin SOP

■ Video capture system block diagram



On-Screen Character Display IC

■ Video type

Function \ Part number	μ PD6464A	μ PD6465
Number of character types	128 (ROM)	256 (ROM)
Number of display characters	288 (12 lines $\times$ 24 digits)	
Character configuration	12 $\times$ 18	
Character color	Single (white, the luminance level of a character can be set in 2 stages.)	
Character size	1 dot/1H, 2H (per line)	
Internal video signal color	White/Black/Blue/Green	
Background	None/Fringed/Squared/Solid (per field)	
Applicable video signal mode	NTSC/PAL/PAL-M/SECAM	
Supply Voltage	4.5 to 5.5 V	
Package	• 24-pin SDIP (300 mil) • 24-pin SOP (375 mil)	

- μ PD6464A adapts PAL-N.

■ RGB type

Function \ Part number	μ PD6461	μ PD6462	μ PD6466
Number of character types	256 (ROM)	128 (ROM)	512 (ROM)
Number of display characters	288 (12 lines $\times$ 24 digits)		
Character configuration	12 $\times$ 18		
Character color	8 colors		
Character size (per line)	1 dot/1H, 2H		1 dot/1H, 2H, 3H, 4H
Character color reverse (per character)	Black character/No fringed		Black character/No fringed White character/Fringed
Background (per frame)	None Square (8 colors) Solid (8 colors)		
Fringed (per frame)	Two colors (Black, White)		
Supply voltage	2.7 to 5.5 V		
Package	• 20-pin SSOP (300 mil) • 24-pin SOP (375 mil)	• 20-pin SSOP (300 mil)	• 20-pin SSOP (300 mil) • 24-pin SOP (375 mil)

- Making ideally suited for camcoders (μ PD6461, μ PD6462)
- μ PD6461 and μ PD6462 are commands conpertible and pins conpertible for 20-pin SSOP package.
- μ PD6466 has a blue background and character mirror reverse function.

Video Camera IC

■ CCD driver circuit

Part number	Function	Package
μ PD16501	Area sensor vertical drive interface	• 16-pin SOP (300 mil)
μ PD16502	Area sensor vertical drive interface	• 20-pin SOP (300 mil)
μ PD16510	Area sensor vertical, VOD shutter driver, for low voltage logic	• 22-pin SSOP (225 mil)
μ PD16520*	Area sensor vertical driver 10ch (3 state: 6, 2 state: 4), VOD shutter driver, for low voltage logic	• 38-pin SSOP (300 mil)

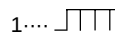
★: Under development

Remote Control IC

■ Infrared remote control preamplifiers IC

Part number	Supply voltage	Features	Package	Remarks
μ PC2800A	5 V $\pm$ 10%	Internal high trap circuit	• 8-pin SOP	Active low type

■ Infrared remote control IC

Part number	μ PD6121G-001		μ PD6122G-001					
Operating voltage range	2.0 to 3.3 V							
Operation clock (fosc)	400 to 500 kHz ceramic oscillator							
Transmission format	<table border="1"><tr><td>Leader</td></tr></table>	Leader	<table border="1"><tr><td>Custom code 16-bit</td></tr></table>	Custom code 16-bit	<table border="1"><tr><td>Data code 8-bit</td></tr></table>	Data code 8-bit	<table border="1"><tr><td>Data code 8-bit</td></tr></table>	Data code 8-bit
Leader								
Custom code 16-bit								
Data code 8-bit								
Data code 8-bit								
Modulation mode	P.P.M. 0  1....  38 kHz • carrier modulation(fosc = 455 kHz)							
Custom code	16-bit set*							
Data code	32 × 2		64 × 2					
Number of keys	32		64					
Package	• 20-pin SOP		• 24-pin SOP					

※: All codes except code "00FFH" are managed by NEC.

Clock IC

Part number	I/O	Alarm	Supply voltage (V)	Circuit Current (μ A)	Package
μ PD4990A	Serial	X	2.0 to 5.5	20	• 14-pin DIP • 16-pin SOP
μ PD4991A	4-bit • Parallel	○		14	• 18-pin DIP • 20-pin SOP
μ PD4992	8-bit • Parallel	X	2.4 to 5.5	6	• 20-pin DIP • 20-pin SOP

Rotary Encoder IC

Part number	Axis	Counter-bit	Supply voltage (V)	Package
μ PD4701A	2	12	5.0	• 24-pin DIP • 24-pin SOP
μ PD4702	1	8		• 20-pin DIP • 20-pin SOP
μ PD4704	1 (Expansion for μ PD4702)			

A/D Converter IC**■ A/D Converter for Video processing**

Part number	Resolution (bits)	Linearity (%FSR)	Sampling time (MSPS)	Supply voltage (V)	Data format	Output format	Package	Remarks
μ PC659A	8	0.2	20	+5	Binary	8-bit parallel	• 24-pin SOP	Parallel approximation Video processing

D/A Converter IC**■ D/A Converter**

Part number	Resolution (bits)	Linearity (%FSR)	Settling time (μ s)	Supply voltage (V)	Input format	Output format	Package	Remarks
μ PD6325	6	Monotonicity	200	+5 to +15 +5	Binary	Voltage output	• 16-pin DIP • 16-pin SOP	Serial input, CMOS
μ PD6335	(4 circuits)							
μ PD6326	6	Monotonicity	200	+5 to +15 +5	Binary	Voltage output	• 16-pin DIP	Serial input, CMOS
μ PD6336	(8 circuits)							
μ PD6221	8 (8 circuits)	0.31	100	+5	Binary	Voltage output	• 20-pin DIP • 20-pin SOP	I ² C-bus compatible Internal Output CMOS' Buffer
μ PD6222	8 (12 circuits)	0.31	100	+5	Binary	Voltage output	• 24-pin SDIP • 24-pin SOP	I ² C-bus compatible Internal Output CMOS' Buffer

■ D/A Converter for Video processing

Part number	Resolution (bits)	Linearity (%FSR)	Sampling rate (MSPS)	Supply voltage (V)	Input format	Output format	Package	Remarks
μ PC667	10	0.1	60	+5	Binary	Voltage output	• 30-pin SDIP	Parallel input Video processing

Line Driver Receiver IC

Part number	Driver	Receiver	Capacitor (μF)	Supply voltage (V)	Package
μPD4711B	2	2	1.0 to 4.7 (4 pcs)	5.0	• 20-pin DIP • 20-pin SOP
μPD4712C	4	4	4.7 to 47 (4 pcs)		• 28-pin DIP • 28-pin SOP
μPD4712D	4	4			• 24-pin DIP • 24-pin SOP
μPD4713A	3	3			• 28-pin DIP • 28-pin SOP
μPD4714A	3	5			
μPD4715A	5	3			
μPD4721	2	2	0.33 to 4.7 (4 or 5 pcs)	3.3/5.0	• 20-pin SSOP
μPD4722	4	4	0.47 to 4.7 (4 or 5 pcs)		• 30-pin SSOP
μPD4723	3	3	0.33 to 4.7 (4 or 5 pcs)		
μPD4724	3	5			
μPD4726	4	7	1.0 to 4.7 (4 pcs)		

[MEMO]

General Purpose Linear IC

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Operational Amplifier

Part number		Number of circuits*1	V _± (recom- mended value) (V)*2	V _{IO} (MAX.) (mV)	I _{CC} (MAX.) (mA)	SR (TYP.) (V/μs)	Features and Functions	Packages*3			Number of pins
Communi- cation/ industry use	General use							C	G2	HA	
μPC151	μPC741	1	±7.5 to ±16	±6	2.8	0.5	General purpose	○	○		8
μPC251	μPC1458	1	±7.5 to ±16	±6	5.6	0.5	General purpose	○	○		8
μPC258	μPC4558	2	±4 to ±16	±6	—	1.0	Low noise	○	○		8
μPC259	μPC4560	2	±4 to ±16	±6	—	2.8	Low noise, high output current	○	○		8
μPC451	μPC324	4	+3 to +30	±7	2.0	0.3	Single supply voltage	○	○		14
μPC452	μPC3403	4	+3 to +32	±7	7.0	0.8	Single supply voltage, high speed	○	○		14
μPC458	μPC4741	4	±4 to ±16	±5	7.0	1.0	Low noise	○	○		14
μPC801	μPC4081	1	±5 to ±16	±15	2.8	13	J-FET input	○	○		8
μPC802	μPC4250	1	±1 to ±16	±6	0.1	0 to 1.0	Micro-power	○	○		8
μPC803	μPC4082	2	±5 to ±16	±15	5.6	13	J-FET input	○	○		8
μPC804	μPC4084	4	±5 to ±16	±15	11.2	13	J-FET input	○			14
μPC811	μPC4091	1	±5 to ±16	±2.5	3.4	15	High accuracy, J-FET input	○	○		8
μPC812	μPC4092	2	±5 to ±16	±3	6.8	15	High accuracy, J-FET input	○	○		8
μPC813	μPC4093	1	±5 to ±16	±2.5	3.4	25	High accuracy, high speed, J-FET input	○	○		8
μPC814	μPC4094	2	±5 to ±16	±3	6.8	25	High accuracy, high speed, J-FET input	○	○		8
μPC815	—	1	±3 to ±20	±0.06	4.6	1.6	Super high accuracy	○			8
μPC816	—	1	±3 to ±20	±0.06	4.6	7.6	Super high accuracy	○			8
μPC821	μPC4071	1	±5 to ±16	±10	2.7	13	Low noise, J-FET input	○	○		8
μPC822	μPC4072	2	±5 to ±16	±10	5.0	13	Low noise, J-FET input	○	○	○	8*4
μPC824	μPC4074	4	±5 to ±16	±10	10.0	13	Low noise, J-FET input	○	○		14
μPC831	μPC4061	1	±2 to ±16	±10	0.25	3.0	Micro-power, J-FET input	○	○		8
μPC832	μPC4062	2	±2 to ±16	±10	0.5	3.0	Micro-power, J-FET input	○	○		8
μPC834	μPC4064	4	±2 to ±16	±10	1.0	3.0	Micro-power, J-FET input	○	○		14
μPC842	μPC4742	2	+3 to +32	±5	5.5	7.0	Single supply voltage, high speed, wide band	○	○		8
μPC844	μPC4744	4	+3 to +32	±5	11.0	7.0	Single supply voltage, high speed, wide band	○	○		14
μPC1251	μPC358	2	+3 to +30	±7	1.2	0.3	Single supply voltage	○	○	○	8*4
—	μPC4556	2	±4 to ±16	±6	—	5.0	Low noise, wide band	○	○		8
—	μPC4557	2	±4 to ±16	±6	—	1.0	Low noise, high output current	○			8
—	μPC4559	2	±4 to ±16	±6	—	2.0	Low noise, wide band	○			8
—	μPC4570	2	±4 to ±16	±5	8.0	7.0	Super low noise, wide band	○	○	○	8*4
—	μPC4572	2	±2 to ±7	±5	7.0	6.0	Super low noise, low voltage	○	○	○	8*4
—	μPC4574	4	±4 to ±16	±5	12.0	6.0	Super low noise, wide band	○	○		14

*1 : Single type has a offset adjust pin.

*2 : For product indicated by +/– voltage, single supply voltage operation is possible if the input/output voltage range is observed.

*3 : C, G2 or HA shows Package Type, as follows.

C : Plastic DIP (300 mil)

G2 : Plastic SOP (225 mil)

HA : 9-pin plastic slim SIP

*4 : HA has 9 pins.

Comparator

Part number		Number of circuits	V _± (recommended value) (V)	V _{IO} (MAX.) (mV)	I ⁺ (MAX.) (mA)	t _d (TYP.) (μs)	Features and Functions	Packages*1			Number of pins
Communication/industry use	General use							C	G2	HA	
μPC177	μPC339	4	+2 to +32	±5.0	2.0	1.3	Single supply voltage	○	○		14
μPC271	μPC311	1	+5 to +32	±7.5	7.5	0.2	High speed	○	○		8
μPC272	μPC319	2	+5 to +32	±8.0	12.5	0.08	High speed	○	○		14
μPC277	μPC393	2	+2 to +32	±5.0	1.0	1.3	Single supply voltage	○	○	○	8*2

*1: C, G2 or HA shows Package Type, as follows.

C : Plastic DIP (300 mil)

G2 : Plastic SOP (225 mil)

HA : 9-pin plastic slim SIP

*2: HA has 9 pins.

Fixed Output Voltage, 3-Terminal Regulator

Type	Part number	Output current (A)	Output voltage (V)														Absolute maximum ratings		Package	Remarks
			3	3.3	4	5	6	7	8	9	9.3	10	12	15	18	24	Input voltage (V)	Total power dissipation (W)*1		
Positive voltage output	μPC78L00	0.1				○	○	○	○				○	○	○		30	0.7/2*3	• TO-92 • TO-243	
													○	○	○		35			
	μPC78N00	0.3				○			○				○	○	○	○	35	12.5	• TO-126	
																○	40			
	μPC78M00A	0.5				○	○	○	○	○			○	○	○	○	35	15	• MP-45*2	Improved version of μPC78M00
																○	40			
	μPC7800A	1.0				○			○		○		○	○	○		35	15	• MP-45*2	Improved version of μPC7800
																○	40			
	μPC29L00	0.1	○	○	○	○											16	0.7/2*3	• TO-92 • TO-243	Low dropout voltage type
	μPC29M00	0.5	○	○		○	○	○	○	○			○	○			20	1.0/2.0*4 15	• TO-251 • TO-252 • MP-45*2	Low dropout voltage type
Negative voltage output	μPC2900	1.0	○	○		○	○	○	○	○			○	○			20	1.0/2.0*4 15	• TO-251 • TO-252 • MP-45*2	Low dropout voltage type
	μPC24A00	2.0				○							○	○			36	20	• MP-45*2	Low dropout voltage type
	μPC24M00A	0.5				○	○	○	○	○			○	○	○	○	36	15	• MP-45*2	Low dropout voltage type
	μPC2400A	1.0				○	○	○	○	○			○	○	○	○	36	15	• MP-45*2	Low dropout voltage type
Negative voltage output	μPC79L00	0.1				○			○								-30	0.7	• TO-92	
													○	○			-35			
	μPC79N00	0.3				○			○				○	○	○		-35	12.5	• TO-126	
																○	-40			
	μPC79M00	0.5				○			○				○	○	○		-35	15	• MP-45*2	
																○	-40			
	μPC7900A	1.0				○			○				○	○	○		-35	15	• MP-45*2	Improved version of μPC7900
																○	-40			

*1 : Limited by internal circuit

*2 : TO-220 Plastic insulated package

*3 : With 16 cm² × 0.7 mm ceramic substrate

*4 : With 7.5 cm² × 0.7 mm ceramic substrate

Variable Output Voltage Regulator

Type	Part number	Output current (A)	Output voltage range (V)	Absolute maximum ratings		Package	Remarks
				Input voltage (V)	Total power dissipation (W)		
Positive voltage output	μ PC305	0.05	4.5 to 30	40	0.35, 0.44	• 8-pin DIP • 8-pin SOP	
	μ PC317	1.5	1.3 to 30	40	15* ¹	• MP-45* ²	3-pin regulator
	μ PC1093	0.15	2.5 to 36	37	0.48, 0.7, 2* ³ , 0.2	• 8-pin SOP • TO-92 • TO-243 • 5-pin mini mold	Shunt regulator
	μ PC1943	0.05	1.26 to 24	25	1.6* ³	• TO-243	Shunt regulator for Low Voltage
	μ PC1944	0.05	1.26 to 24	25	0.385, 0.56, 1.6* ³	• 8-pin SOP • TO-92 • TO-243	Shunt regulator for Low Voltage
	μ PC1945*	0.015	0.4 to 9	12	0.41* ⁴	• 5-pin mini mold	Shunt regulator for Low Voltage
Negative voltage output	μ PC337	1.5	-1.3 to -30	-40	15* ¹	• MP-45* ²	3-pin regulator

*1 : Limited by internal circuit

*: Under development

*2 : TO-220 Plastic insulated package

*3 : When mounted on 16 cm² (0.7 mm thick) ceramic board*4 : When mounted on 75 mm² (0.7 mm thick) ceramic board

Regulator with System Reset

Type	Part number	Output current (A)	Output voltage (V)	Reset start voltage (V)	Reset output logic		Absolute maximum ratings		Package	Remarks
					Active low	Active high	Input voltage (V)	Total power dissipation (W)		
Positive voltage output	μ PC2251	0.1	3	2.85	○		12	1.2*	• TO-126 (4-pin)	Low dropout type
	μ PC2253	0.1	5	2.85	○		12	1.2*	• TO-126 (4-pin)	Low dropout type
	μ PC2255	0.1	5	4.75	○		12	1.2*	• TO-126 (4-pin)	Low dropout type
	μ PC2260	0.5	5	4.85	○		35	20*	• TO-220 (5-pin)	Low dropout type

*: Limited by internal circuit

Regulator with ON/OFF Function

Part number	Output current (A)	Output voltage (V)	ON/OFF voltage (V)		Absolute maximum ratings		Package
			Output ON	Output OFF	Input voltage (V)	Total power dissipation (W)	
μ PC29S78	0.1	7.8	2.0	0.8	20	1.2*	• TO-126 (4-pin) • TO-126 Gullwing (4-pin)
μ PC29S10	0.1	10	2.0	0.8	20	0.48*	• 8-pin SOP

*: Limited by internal circuit

High Precision Reference Voltage

Part number	Input voltage range (V)	Output voltage (V)	Output current (mA)	Total power dissipation (mW)	Output voltage vs. temperature (ppm/°C)	Package
μ PC1060	4.5 to 40	2.5 $\pm$ 0.025	10	350, 500	40	• 8-pin DIP

Switching Regulator Control Circuit

Part number	Input voltage range (V)	Absolute maximum ratings		Package	Output circuit operation mode	Applications
		Output current (mA)	Total power dissipation (W)			
μ PC494	7 to 40	250	1, 0.78*2, 0.65*2	• 16-pin DIP • 16-pin SOP*1 (375 mil/300 mil)	Push-pull/single selectable	General purpose
μ PC1094	11 to 24	1200 (peak)	0.57, 0.55	• 14-pin DIP • 14-pin SOP	Totem pole circuit configuration Single mode	Can operate up to 500 kHz General purpose
μ PC1099	11.5 to 24	1200 (peak)	1, 0.694	• 16-pin DIP • 16-pin SOP	Totem pole circuit configuration Single mode	Can operate up to 500 kHz General purpose
μ PC1905	12 to 30	1200 (peak)	1, 0.694	• 16-pin DIP • 16-pin SOP	Totem pole circuit configuration Single mode	Can operate up to 500 kHz General purpose
μ PC1909*	7 to 24	1200 (peak)	1, 0.694	• 16-pin DIP • 16-pin SOP	Totem pole circuit configuration Q, $\bar{Q}$ output	Can operate up to 500 kHz ZCS, Half bridge
μ PC1100	3.6 to 40	25	1, 0.694	• 16-pin DIP • 16-pin SOP	2 outputs (synchronous control possible) If one output is shorted, both outputs will be turned OFF.	DC/DC converter
μ PC1150	3.6 to 40	25	1, 0.694	• 16-pin DIP • 16-pin SOP	2 outputs (synchronous control possible) If one output is shorted, only the output will be turned OFF.	DC/DC converter
μ PC1933	2.5 to 20	21	0.48	• 8-pin SOP	Open drain 1 output	DC/DC converter
μ PC1934	2.5 to 20	21	0.4, 0.417	• 16-pin SSOP • 16-pin T-SSOP	Open drain 2 outputs	DC/DC converter
μ PC1935	2.5 to 20	21	0.417	• 16-pin T-SSOP	Open drain 3 outputs	DC/DC converter
μ PC16902*	5.2 to 25	1000 (peak)	0.625	• 30-pin SSOP	High side: necessary drivers Low side: push-pull drivers	5 V, 3.3 V Synchronous rectifier controller

*1 : μ PC494G is 375 mil. μ PC494GS is 300 mil.

*: Under development

*2 : When mounted on 5×5 cm² (1.6 mm thick) glass epoxy board.

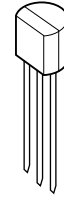
Functional Block

Function	Part number	Features	Package
Analog Multiplexer	μPD5205	Single-pole 8 position mode/double-pole 4 position mode Supply Voltage: 44 V, ON Resistance: 270 Ω TYP.	• 24-pin shrink DIP • 24-pin SOP
Precision Timer	μPC1555	CR Timer, Operating Temperature: -20 ~ +80°C Supply Voltage: 4.5 ~ 16 V, Free Running Frequency: 0.1 ~ 100 kHz	• 8-pin DIP • 8-pin SOP
	μPD5555	CMOS CR Timer, CMOS Type of μPC1555 Supply Voltage: 3 ~ 16 V, Free Running Frequency: 0.1 ~ 500 kHz	• 8-pin DIP • 8-pin SOP
	μPD5556	CMOS CR Timer Dual Type of μPD5555	• 14-pin DIP • 14-pin SOP

Transistor/Diode/Thyristor

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Transistor with Internal Resistor	309
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Transistor Array	315
Zener Diode	317
Noise Clipping Diode	319
Thyristor	321

Quick Reference by Package



TO-92

■ TO-92 Type Transistor

V_{CE0} (V) I_C (A)	~15	~30	~50	~70	~100	~150	~200	~250	~400
~20 m		2SC1674							
~50 m	2SA1206**					2SA988 2SA992 2SC1841 2SC1845			
~100 m			2SA733 2SA990 2SC945 2SC1842 2SC1843 AA1[] AN1[]		2SA675 ¹⁾		2SA1376 2SA1376A 2SC3478 2SC3478A	2SA1544	
~200 m	2SC2901**		2SC3622* (150 mA) 2SC3622A* (150 mA)						
~500 m			2SC3615* (300 mA)	2SA953 2SC2002	2SA954 2SC2003				2SA1625
~1.0		2SA952 2SC2001 2SC3616* (25 V/ 700 mA) AB1[] (25 V/ 700 mA) AP1[] (25 V/ 700 mA)	2SB1116 2SD1616	AD1[] AD2[]*** AR1[] 2SB1116A (60 V) 2SD1616A (60 V)*** 2SD1701 (60 V)	2SD1698 (80 V)				
~2.0		2SD1513 (16 V/2.0 A) 2SB1068 (16 V/2.0 A) AQ1[] (20 V/2.0 A)							
~3.0		2SB1300 (16 V/3 A)							

1) V_{CES} : Darlington transistor, *: High h_{FE} transistor, **: High speed switching, ***: Contains internal zener diode

Quick Reference by Package



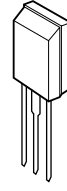
SST

■ SST Type Transistor

V_{CEO} (V) I_C (A)	~15	~20	~30	~50	~120
~20 m	2SC2786		2SC2787		
~50 m	2SA1459**				2SC2784
~100 m				2SA1175 2SC2785 2SC3623* BA1[] BN1[]	
~200 m	2SC3732**			2SA1458** (40 V) 2SC3623A* (150 mA) 2SC3731** (40 V)	
~700 m		2SB810 2SD1020	BB1[] (25 V) BP1[] (25 V)		

*: High h_{FE} transistor, **: High speed switching

Quick Reference by Package



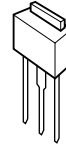
SP-8

■ SP-8 Type Transistor

V_{CE0} (V) I_c (A)	~16	~25	~50	~80	~140	~160	~300	~400	~600
~50 m					2SA915 2SC1940	2SA916 2SC1941			
~200 m							2SC3209 2SC4000 (250 V/ 100 mA)		
~500 m					2SA1221 2SC2958	2SA1222 2SC2959			
~700 m			2SB605 2SD571 2SC2721						
~1.0		2SB564 2SD471	2SA1460** 2SB734 2SC3733** 2SD774 2SD1582*	2SB984 2SB1093 2SD1312 2SD1579 2SD1697 (800 mA) 2SD1700*** (60 V/ 800 mA) 2SD1843*** (60 V)					2SA1627
~2.0	2SB733 2SD773	2SD1581*	2SD2463	2SD1779* (60 V) 2SD1780* (60 V) CE1[]*** (60 V) CE2[]* (60 V)				2SA1626	
~3.0		2SB1117			2SB1318 (100 V)				
~5.0		2SA1897							

 : Darlington transistor, *: High hFE transistor, **: High speed switching, ***: Internal zener diode

Quick Reference by Package



MP-3

■ MP-3 Type Transistor

V_{CEO} (V) $I_{C(DC)}$ (A)	~20	~40	~60	~100	~150	~300	~400	~600
~0.5							{ 2SA1400 2SC3588	
~1.0			{ 2SB963 2SD1286					{ 2SA1413 2SC3632
~2.0	2SD1583	2SD992	2SD1164		{ 2SB768 2SD1033	2SC2885 2SC2946	{ 2SA1412 2SC3631	
~3.0		2SB962 ◎	2SD1584 { 2SB1261 ◎ 2SD1899 ◎					
~5.0			{ 2SA1385 ◎ 2SC3518 ◎ 2SA1648 ◎	{ 2SA1647 ◎ 2SC4331 ◎			2SC4346	
~10	2SA1615 ◎	2SA1649 ◎						

□ : Darlington transistor, { : Complementary pair, ○ : Single High h_{FE} , ◎ : Low $V_{CE(sat)}$

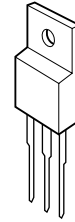
MP-5
(TO-126)

■ MP-5 (TO-126) Type Transistor

V_{CEO} (V) $I_{C(DC)}$ (A)	~45	~60	~80	~120	~160	~300	~400	~600
~1.0						{ 2SA1546 2SC4001		
~0.5						2SC2688	{ 2SA1156 2SC2752	
~1.0		2SD1630 *		2SD415				{ 2SA1486 2SC3840
~2.0	2SD1695 *	{ 2SB794 2SD985	{ 2SB795 2SD986	2SC2690	2SC2690A			
~3.0	2SD794 { 2SB772 ◎ 2SD882 ◎	2SD794A { 2SB1150 * 2SD1693 * 2SD1694 ○ { 2SB1217 ◎ 2SD1818 ◎		{ 2SB1149 2SD1692 2SC4342				
~5.0		{ 2SB1151 ◎ 2SD1691 ◎						

□ : Darlington transistor, { : Complementary pair, *: Internal zener diode between C-B, ◎ : Low $V_{CE(sat)}$,
○ : Single High h_{FE}

Quick Reference by Package



MP-25
(TO-220)

■ MP-25 (TO-220) Type Transistor

V_{CE0} (V) $I_{C(DC)}$ (A)	~40	~60	~80	~100	~150	~300	~400
~0.5						2SC1505	
~2.0				{ 2SA1008 2SC2331	{ 2SB546A 2SD401A	2SA1009	2SA1009A 2SC2333
~5.0		2SA1069	2SA1069A	{ 2SB601 2SD560 2SC2517			2SC2518
~7.0	2SA1129	2SB707	2SB708	{ 2SA1010 2SC2334 2SA1645 ◎			2SC2335
~7.0				2SA1646 ◎			

□ : Darlington transistor, { : Complementary pair, *: Internal zener diode between C-B, ◎: Low $V_{CE(sat)}$



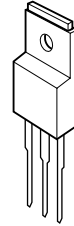
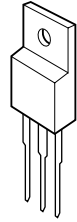
MP-40

■ MP-40 Type Transistor

V_{CE0} (V) $I_{C(DC)}$ (A)	~60	~100	~400
~5.0	2SD1392*	2SD1308	
~7.0	2SC4305		2SC3158
~8.0		2SD1309	
~10		{ 2SA1261 2SC3157 2SC4350	2SC3159

□ : Darlington transistor, { : Complementary pair, *: Internal zener diode between C-B

Quick Reference by Package

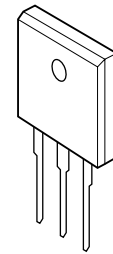
MP-45
(MP-25 Insulated type)MP-45F
(MP-25 Insulated type)

■ MP-45, MP-45F (TO-220 Insulated Type) Transistor

V _{CE0} (V) I _{C(DC)} (A) Package	~60		~100		~300	~400
	MP-45	MP-45F	MP-45	MP-45F	MP-45	MP-45
~2.0			{ 2SA1395 2SC3567			2SC3569
~3.0	{ 2SB1094 2SD1585 2SD1593 ○	2SB1453 2SD2164 ○				
~5.0	{ 2SA1394 2SA1441 ◎ 2SC3691 ◎ 2SC4351 *	{ 2SA1741 ◎ 2SC4549 ◎	{ 2SB1098 2SD1589 2SA1650 ◎	{ 2SB1430 2SD2161	2SD1592	2SC3570
~6.0			2SD1594 ○	2SD2165 ○		
~7.0	{ 2SB1097 2SD1588 2SA1442 ◎ 2SC3692 ◎	{ 2SA1742 ◎ 2SC4550 ◎	2SC4062 ○	2SC4553 ○		2SC3571
~8.0			{ 2SB1099 2SD1590	{ 2SB1431 2SD2162		
~10	{ 2SA1443 ◎ 2SC3693 ◎	{ 2SA1743 ◎ 2SC4551 ◎	{ 2SA1396 2SC3568 2SA1652 ◎ 2SC4336 ◎ 2SA1720 2SB1100 2SD1591	{ 2SB1432 2SD2163		2SC3572
~15	{ 2SA1444 ◎ 2SC3694	{ 2SA1744 ◎ 2SC4552 ◎	2SC4063 ○	2SC4554 ○		

□ : Darlington transistor, { : Complementary pair, *: Internal zener diode between C-B, ◎: Low V_{CE(sat)},○: Single High h_{FE}

Quick Reference by Package

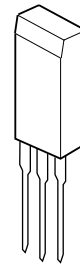


MP-80

■ MP-80 Type Transistor

V_{CEO} (V) $I_{C(DC)}$ (A)	~100	~400
~5.0	2SC2908	
~1.0	2SB897 □ 2SD1210	2SC2749
~15	2SC2750 2SD1296	2SC2751

□: Darlington transistor, *: MP-88



MP-10

■ MP-10 Type Transistor

V_{CEO} (V) $I_{C(DC)}$ (A)	~60	~100
2.5		2SC4814 ○
~5	2SA1843 ◎ 2SC4815 ◎	2SA1840 □ 2SC4810 □ 2SA1845 ◎
~7		2SC4813 ○
~8		2SA1841 □ 2SC4811 □
~10		2SA1847 ◎

□: Darlington transistor, { : Complementary pair, ○: Low $V_{CE(sat)}$ High h_{FE} , ◎: Low $V_{CE(sat)}$

Quick Reference by Package

Mini mold
SC-59

■ Mini-Mold Transistor

V_{CE0} (V) I_C (mA)	~15	~20	~30	~40	~50	~60	~80	~120	~200	~300
~20		2SC2223								2SD2383
~30				2SA1226						
~50	2SA1462		2SC1009A					2SA811A 2SA1247 2SC1622A 2SC3115	2SC1653 (130 V) 2SC1654 (160 V)	
~100					2SA812 2SC1623 FA1[] FN1[]				2SA1330 2SC3360	
~150					2SC3624 2SC3624A					
~200	2SC3735	2SC1621		2SA1461 2SC3734						
~300						2SB736 2SD780	2SB736A 2SD780A			
~500				2SA1464 2SC3739						
~700			2SB624 (-25 V) 2SD596 (25 V) FB1[] (25 V) FP1[] (-25 V)							

Quick Reference by Package

Power mini mold
SC-62

■ Power Mini-Mold Transistor

V_{CE0} (V) I_C (A)	~20	~25	~50	~60	~80	~100	~120	~140	~300
~50 m								2SA1173 2SC2780	
~200 m									2SC3554
~300 m			2SC3617		2SB800 2SD1001				
~0.7		2SC3618	2SB799 2SD1000			2SB805 2SD1006	2SB806 2SD1007		
~1.0		2SB798 2SD999	2SA1463 2SB1115 2SC3736 2SD1615 2SD1702	2SB1115A 2SD1615A HD1[] HD2[] HR1[]	2SB804 2SD1005 2SD1699				
~2.0	2SB1114 2SD1614 HQ1[]	2SD1950							
~3.0	2SB1628			2SB1572 2SD2403					
~5.0			2SB1571 2SD2402						

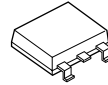
: Darlington connection

MP-2
SC-84

■ MP-2 Type Transistor

V_{CE0} (V) I_C (A)	~60	~600
~1.0		2SA1871 2SC4942
~5.0	2SB1578 2SD2425	

Quick Reference by Package



MP-3

■ MP-3 Type (SC-63) Transistor

V_{CE0} (V) I_c (A)	~20	~30	~45	~60	~200	~400	~600
~0.5						2SA1400-Z 2SC3588-Z	
~1.0				2SB963-Z 2SD1286-Z			2SA1413-Z 2SC3632-Z
~2.0	2SD1583-Z			2SD1164-Z (1.5 A)	2SB768 (150 V) 2SD1033 (150 V) 2SC2946(1)	2SA1412-Z 2SC3631-Z	
~3.0		2SB962-Z		2SB1261-Z 2SD1584-Z 2SD1899-Z			
~5.0				2SA1385-Z 2SC3518-Z			
~10	2SA1615-Z						

: Darlington connection

Small mini mold
SC-70

■ Small Mini-Mold Transistor

V_{CE0} (V) I_c (mA)	~15	~20	~30	~40	~50	~120
~20		2SC4178				
~50	2SA1610		2SC4179			2SA1612 2SC4180
~100					2SA1611 2SC4177 GA1[] GN1[]	
~150					2SC4181	
~200	2SC4176	2SC4175				
~500			2SB1475 (-25 V) 2SD2228 (25 V)	2SA1608 2SC4173		

■ Ultra Small Mini-Mold Transistor

V_{CE0} (V) I_c (mA)	~50
~100	2SA1836 2SC4783



Ultra small mini mold

Quick Reference Table by Function/Application

Small Signal Transistor

■ Small Signal Transistor (1/2)

	TO-92	SP-8	SST	SMALL MINI MOLD	MINI MOLD	POWER MINI
FM/FM RF RF/MIX/CON	2SC1674		2SC2786	2SC4178	2SC2223	
FM AM/FM/AM MIX/OSC/IF			2SC2787	2SC4179	2SC1009A	
Audio Frequency Amplification	2SA733		2SA1175	2SA1611	2SA812	
					(2SA812)	
	2SA988			2SA1612	2SA811A	
	2SC945		2SC2785	2SC4177	2SC1623	
					(2SC1623)	
	2SC1841				2SC1622A	
	2SC3622/A		2SC3623/A	2SC4181	2SC3624/A	
Low Noise Amplification	2SA992		2SA1174		2SA1247	
	2SC1845		2SC2784		2SC3115	
Driver Output	2SA952		2SB810		2SB624	
	2SA953				2SB736	
	2SA954				2SB736A	2SB800
	2SA1376				2SA1330	
		2SB564	2SB811			2SB798
		2SB605				2SB799
	2SB1068					2SB1114
	2SB1116					2SB1115
	2SB1116A					2SB1115A
	2SC2001		2SD1020		2SD596	
	2SC2002				2SD780	
	2SC2003				2SD780A	2SD1001
	2SC3478				2SC3360	
		2SC1940			2SC1653	2SC2780
		2SC1941			2SC1654	
		2SC3209				2SC3554
	2SC3615					2SC3617
	2SC3616					2SC3618
		2SD471				2SD999
		2SD571				2SD1000
	2SD1513					2SD1614
	2SD1616					2SD1615
	2SD1616A					2SD1615A
	2SD1698	2SD1697				2SD1699
	2SD1701	2SD1700				2SD1702
		2SD1581				2SD1950

Quick Reference Table by Function/Application
Small Signal Transistor
■ Small Signal Transistor (2/2)

	TO-92	SP-8	SST	SMALL MINI MOLD	MINI MOLD	POWER MINI
Switching	2SA1206		2SA1459	2SA1610	2SA1462	
				2SA1608	2SA1464	
		2SA1460				2SA1463
			2SA1458		2SA1461	
				2SC4173	2SC3739	
	2SC2901		2SC3732	2SC4176	2SC3735	
		2SC3733				2SC3736
			2SC3731		2SC3734	

Quick Reference Table by Function/Application

Power Transistor

■ Low $V_{CE(sat)}$ Transistor

Charac- teristics V_{CEO} , $I_{C(DC)}$	SP-8	MP-2	MP-3	MP-5 (TO-126)	MP-25	MP-10	MP-45	MP-45F
16 V, 3 A		2SB1581						
20 V, 10 A	2SA1897 (5A)		2SA1615					
25 V, 3 A	2SB1117							
30 V, 3 A			2SB962	2SB772 2SD882				
30 V, 10 A			2SA1649					
60 V, 3 A			2SB1261 2SD1899	2SB1217 2SD1818				
60 V, 5 A		2SB1578 2SD2425	2SA1385 2SC3518	2SB1151 2SD1691		2SA1843 2SC4815		
			2SA1648			2SA1441 2SC3691	2SA1741 2SC4549	
60 V, 7 A						2SA1442 2SC3692	2SA1742 2SC4550	
60 V, 10 A						2SA1443 2SC3693	2SA1743 2SC4551	
60 V, 15 A						2SA1444 2SC3694	2SA1744 2SC4552	
100 V, 5 A			2SA1647 2SC4331			2SA1845	2SA1650	
100 V, 7 A					2SA1645			
100 V, 10 A						2SA1847	2SA1652 2SC4336	

■ High h_{FE} Transistor

Charac- teristics V_{CEO} , $I_{C(DC)}$	SP-8	MP-3	MP-5 (TO-126)	MP-10	MP-45	MP-45F
20 V, 2 A		2SD1583				
25 V, 2 A	2SD1581					
50 V, 1 A	2SD1582					
60 V, 3 A		2SD1584	2SD1694		2SD1593	2SD2164
100 V, 2.5 A				2SC4814*		
100 V, 6 A					2SD1594	2SD2165
100 V, 7.5 A				2SC4813*	2SC4062	2SC4553*
100 V, 15 A					2SC4063	2SC4554*

*: Low $V_{CE(sat)}$ & High h_{FE}

Quick Reference Table by Function/Application
Power Transistor
■ Low Voltage, High Speed Switching Transistor

Characteristics V _{CEO} , I _C (DC)	SP-8	MP-25	MP-45	MP-80
45 V, 1 A	2SA1460 2SC3733			
60 V, 5 A		2SA1069	2SA1394	
100 V, 2 A		2SA1008 2SC2331	2SA1395 2SC3567	
100 V, 5 A		2SC2517		
100 V, 7 A		2SA1010 2SC2334		
100 V, 10			2SA1396 2SC3568	
100 V, 15 A				2SC2750

■ High Voltage, High Speed Switching Transistor

Characteristics V _{CEO} , I _C (DC)	MP-3	MP-5 (TO-126)	MP-25 (TO-220)	MP-40	MP-45	MP-80
200 V, 2 A	2SC2885 2SC2946 2SC2946(1)					
350 V, 2 A			2SA1009			
400 V, 0.5 A	2SA1400 2SC3588	2SA1156 2SC2752				
400 V, 2 A	2SC3631		2SA1009A 2SC2333		2SC3569	
400 V, 5 A	2SC4346		2SC2518		2SC3570	
400 V, 7 A				2SC3158	2SC3571	
400 V, 10 A				2SC3159	2SC3572	2SC2749
400 V, 15 A						2SC2751
600 V, 2 A	2SA1413 2SC3632	2SA1486 2SC3840				

Quick Reference Table by Function/Application

Power Transistor

■ Audio Frequency Amplification Transistor

Characteristics V _{CEO} , I _{C(DC)}	MP-3	MP-5 (TO-126)	MP-25 (TO-220)	MP-45
45 V, 3 A		2SD794		
60 V, 3 A		2SD794A		{ 2SB1094 2SD1585
60 V, 7 A			2SB707	{ 2SB1097 2SD1588
80 V, 0.8 A		2SD414		
80 V, 7 A			2SB708	
100 V, 0.8 A		2SD415		
150 V, 2 A	{ 2SB768 2SD1033		{ 2SB546A 2SD401A	

■ High Frequency Amplification Transistor

Characteristics V _{CEO} , I _{C(DC)}	SP-8	MP-5 (TO-126)	MP-25 (TO-220)
40 V, 7 A			2SA1129
120 V, 1.2 A		2SC2690	
160 V, 1.2 A		2SC2690A	
250 V, 0.1 A	2SC4000	{ 2SA1546 2SC4001	
300 V, 0.2 A	2SC2802	2SC2688	2SC1505

Quick Reference Table by Function/Application

Power Transistor

■ Darlington Transistor

Charac- teristics V _{CEO} , I _{C(DC)}	SP-8	MP-3	MP-5 (TO-126)	MP-25 (TO-220)	MP-10	MP-40	MP-45	MP-45F	MP-80
31 V, 2 A	2SD2463*		2SD1695*						
60 V, 0.8 A	2SD1700*								
60 V, 1 A	2SD1843	{ 2SB963 2SD1286	2SD1630*						
60 V, 1.5 A		2SD1164	{ 2SB794 2SD985						
60 V, 3 A			{ 2SB1150* 2SD1693*						
60 V, 5 A						2SD1392*	2SC4351◎		
80 V, 0.8 A	2SD1697								
80 V, 1.5 A	{ 2SB1093 2SD1579		{ 2SB795 2SD986						
100 V, 3 A			{ 2SB1149 2SD1692 2SC4342◎						
100 V, 5 A				{ 2SB601 2SD560	{ 2SA1840 2SC4810	2SD1308	{ 2SB1098 ◎ 2SD1589 ◎	{ 2SB1430 2SD2161	
100 V, 8 A					{ 2SA1841 2SC4811	2SD1309	{ 2SB1099 2SD1590	{ 2SB1431 2SD2162	
100 V, 10 A							{ 2SA1720 ◎ 2SB1100 2SD1591	{ 2SB1432 2SD2163	{ 2SB897 2SD1210
100 V, 15 A									2SD1296
100 V, 25 A									2SD1297
300 V, 5 A							2SD1592		

◎: High speed darlington transistor, *: Internal zener diode between C-B

Field Effect Transistor

Small Signal FET

■ 2SK type (MOS type) (1/2)

Part number	Package	Absolute maximum rating (T _A = 25 °C)				Electrical characteristics (T _A = 25 °C)							Applications
		V _{DSS} (V)	I _D		P _T (W)	y _{fs} (S)			R _{DS(on)} (Ω)				
			DC (A)	Pulse (A)		V _{DS} (V)	I _D (A)	MIN.	V _{GS} (V)	I _D (A)			
											TYP.	MAX.	
2SK679A	TO-92	30	±0.5	±1.5	0.75	10	0.5	0.4	4	0.5	0.6	1.0	Switching
2SK680A	SC-62	30	±1.0	±2.0	1.0	10	0.5	0.4	4	0.5	0.6	1.0	
2SK681A	SP-8	30	±1.0	±2.0	1.0	10	0.5	0.4	4	0.5	0.6	1.0	
2SK1132	SST	50	0.1	0.2	0.25	5	0.02	0.03	4	0.02	30	50	
2SK1133	SC-59	50	0.1	0.2	0.2	5	0.02	0.03	4	0.02	30	50	
2SK1272	TO-92	60	±1.0	±2.0	0.75	10	0.5	0.4	4	0.5	—	1.0	
2SK1273	SC-62	60	±2.0	±4.0	2.0	10	0.5	0.4	4	0.5	—	1.0	
2SK1274	SP-8	60	±1.5	±3.0	1.0	10	0.5	0.4	4	0.5	—	1.0	
2SK1398	SST	50	0.1	0.2	0.25	3	0.01	0.02	2.5	0.005	20	40	
2SK1399	SC-59	50	0.1	0.2	0.2	3	0.01	0.02	2.5	0.005	20	40	
2SK1482	TO-92	30	±1.5	±3.0	0.75	10	0.5	0.4	4	0.5	0.19	0.8	
2SK1483	SC-62	30	±2.0	±4.0	2.0	10	0.5	0.4	4	0.5	0.19	0.8	
2SK1484	TO-92	100	±0.5	±1.0	0.75	10	0.5	0.4	4	0.5	0.62	1.2	
2SK1485	SC-62	100	±1.0	±2.0	2.0	10	0.5	0.4	4	0.5	0.62	1.2	
2SK1580	SC-70	16	0.1	0.2	0.15	3	0.01	0.02	2.5	0.001	9	15	
2SK1581	SC-59	16	0.2	0.4	0.2	3	0.01	0.02	2.5	0.001	3.2	5	
2SK1582	SC-59	30	0.2	0.4	0.2	5	0.01	0.02	4	0.01	2.2	5	
2SK1583	SC-62	16	±0.5	±1.0	2.0	5	0.3	0.4	2.5	0.3	1.2	2.0	
2SK1584	SC-62	30	±0.5	±1.0	2.0	5	0.3	0.4	2.5	0.3	1.2	2.0	
2SK1585	SC-62	16	±1.0	±2.0	2.0	5	0.5	0.4	2.5	0.5	0.8	1.2	
2SK1586	SC-62	30	±1.0	±2.0	2.0	5	0.5	0.4	4	0.5	—	1.0	
2SK1587	SC-62	16	±2.0	±4.0	2.0	5	1.0	0.4	2.5	1.0	0.55	0.8	
2SK1588	SC-62	16	±3.0	±6.0	2.0	3	1.0	0.4	2.5	1.0	0.34	0.5	
2SK1589	SC-59	100	0.1	0.2	0.2	5	0.01	0.02	4	0.01	19	30	
2SK1590	SC-59	60	0.2	0.4	0.2	5	0.01	0.02	4	0.01	3.2	6	
2SK1591	SC-59	100	0.2	0.4	0.2	5	0.01	0.02	4	0.01	5.8	8	
2SK1592	SC-62	60	±0.5	±1.0	2.0	10	0.5	0.4	4	0.5	1.6	2.5	
2SK1593	SC-62	100	±0.5	±1.0	2.0	10	0.5	0.4	4	0.5	4.0	6.0	
2SK1656	SST	30	0.1	0.2	0.25	3	0.01	0.02	2.5	0.01	25	45	
2SK1657	SC-59	30	0.1	0.2	0.2	3	0.01	0.02	2.5	0.01	25	45	
2SK1658	SC-70	30	0.1	0.2	0.15	3	0.01	0.02	2.5	0.01	25	45	
2SK1824	3-pin ultra super mini	30	0.1	0.2	0.2	3	0.01	0.02	2.5	0.001	7	13	
2SK1958	SC-70	16	0.1	0.2	0.15	3	0.01	0.02	1.5	0.001	30	50	
2SK1959	SC-62	16	±2.0	±4.0	2.0	3	1.0	1.0	1.5	0.05	0.08	0.8	
2SK1960	SC-62	16	±3.0	±6.0	2.0	3	1.5	2.0	1.5	0.1	0.35	0.8	

Field Effect Transistor

Small Signal FET

■ 2SK type (MOS type) (2/2)

Part number	Package	Absolute maximum rating (T _A = 25 °C)				Electrical characteristics (T _A = 25 °C)							Applications
		V _{DSS} (V)	I _D		P _T (W)	y _{fs} (S)			R _{DS(on)} (Ω)				
			DC (A)	Pulse (A)		V _{DS} (V)	I _D (A)	MIN.	V _{GS} (V)	I _D (A)			
											TYP.	MAX.	
2SK2053	MP-2	16	±5	±10	2.0	3	2.5	0.4	1.5	0.5	0.2	0.4	Switching
2SK2054	MP-2	60	±3	±6	2.0	10	1.5	2.0	4	1.5	0.18	0.25	
2SK2055	MP-2	100	±2	±4	2.0	10	1.0	2.0	4	1.0	0.28	0.45	
2SK2070	SP-8	100	±1	±2	2.0	10	1.0	2.0	4	1.0	0.28	0.45	
2SK2090	SC-70	50	±0.1	±0.2	0.15	3	0.01	0.02	2.5	0.01	20	40	
2SK2109	SC-62	60	±0.5	±1.0	2.0	10	0.3	0.4	4	0.3	0.55	1.5	
2SK2110	SC-62	100	±0.5	±1.0	2.0	10	0.3	0.4	4	0.3	0.90	2.0	
2SK2111	SC-62	60	±1.0	±2.0	2.0	10	0.5	0.4	4	0.5	0.35	1.0	
2SK2112	SC-62	100	±1.0	±2.0	2.0	10	0.5	0.4	4	0.5	0.67	1.5	
2SK2157	MP-2	30	±5	±10	2.0	10	2.5	2.0	4	2.5	0.08	0.15	
2SK2158	SC-59	50	0.1	0.2	0.2	3	0.01	0.02	1.5	0.001	21	50	
2SK2159	SC-62	60	±2	±4	2.0	10	1.0	0.4	1.5	0.1	0.26	0.7	
2SK2541	SST	50	±0.1	±0.2	0.2	3	0.01	0.02	1.5	0.001	21	50	
2SK2857*	SC-62	60	±4	±16	2.0	10	1	1	4	1.5	0.15	0.22	
2SK2858*	SC-70	30	±0.1	±0.4	0.15	3	0.01	0.02	2.5	0.001	10	15	

★: Under development

Field Effect Transistor

Small Signal FET

■ 2SJ type (MOS type)

Part number	Package	Absolute maximum rating (T _A = 25 °C)				Electrical characteristics (T _A = 25 °C)							Applications
		V _{DSS} (V)	I _D		P _T T _C = 25 °C (W)	y _{fs} (S)			R _{DS(on)} (Ω)				
			DC (A)	Pulse (A)		V _{DS} (V)	I _D (A)	MIN.	V _{GS} (V)	I _D (A)			
											TYP.	MAX.	
2SJ165	SST	−50	±0.1	±0.2	0.25	−5	−0.02	0.03	−4	−0.02	22	50	Switching
2SJ166	SC-59	−50	±0.1	±0.2	0.2	−5	−0.02	0.03	−4	−0.02	22	50	
2SJ178	TO-92	−30	±1.0	±2.0	0.75	−10	−0.5	0.4	−4	−0.5	—	1.5	
2SJ179	SC-62	−30	±1.5	±3.0	2.0	−10	−0.5	0.4	−4	−0.5	—	1.5	
2SJ180	SP-8	−30	±1.0	±2.0	1.0	−10	−0.5	0.4	−4	−0.5	—	1.5	
2SJ184	SST	−50	±0.1	±0.2	0.25	−5	−0.02	0.02	−2.5	−0.05	25	40	
2SJ185	SC-59	−50	±0.1	±0.2	0.2	−5	−0.02	0.02	−2.5	−0.05	25	40	
2SJ196	TO-92	−60	±1.0	±2.0	0.75	−10	−0.5	0.4	−4	−0.5	0.89	1.5	
2SJ197	SC-62	−60	±1.5	±3.0	2.0	−10	−0.5	0.4	−4	−0.5	0.89	1.5	
2SJ198	TO-92	−100	±0.5	±1.0	0.75	−10	−0.5	0.4	−4	−0.5	1.7	2.0	
2SJ199	SC-62	−100	±1.0	±2.0	2.0	−10	−0.5	0.4	−4	−0.5	1.7	2.0	
2SJ202	SC-70	−16	±0.1	±0.2	0.15	−3	−0.01	0.02	−2.5	−0.001	—	60	
2SJ203	SC-59	−16	±0.2	±0.4	0.2	−3	−0.01	0.02	−2.5	−0.001	16	20	
2SJ204	SC-59	−30	±0.2	±0.4	0.2	−3	−0.01	0.02	−2.5	−0.001	8.8	15	
2SJ205	SC-62	−16	±0.5	±1.0	2.0	−5	−0.3	0.4	−2.5	−0.3	2.2	5.0	
2SJ206	SC-62	−30	±0.5	±1.0	2.0	−5	−0.3	0.4	−2.5	−0.3	2.8	3.0	
2SJ207	SC-62	−16	±1.0	±2.0	2.0	−5	−0.5	0.4	−2.5	−0.5	1.5	2.0	
2SJ208	SC-62	−16	±2.0	±4.0	2.0	−5	−1.0	0.4	−2.5	−1.0	0.6	1.5	
2SJ209	SC-59	−100	±0.1	±0.2	0.2	−5	−0.01	0.02	−4	−0.01	60	100	
2SJ210	SC-59	−60	±0.2	±0.4	0.2	−5	−0.01	0.02	−4	−0.01	10	15	
2SJ211	SC-59	−100	±0.2	±0.4	0.2	−5	−0.01	0.02	−4	−0.01	18	30	
2SJ212	SC-62	−60	±0.5	±1.0	2.0	−10	−0.5	0.4	−4	−0.5	1.8	4.0	
2SJ213	SC-62	−100	±0.5	±1.0	2.0	−10	−0.5	0.4	−4	−0.5	2.7	5.0	
2SJ243	3-pin ultra super mini	−30	±0.1	±0.2	0.2	−3	−0.01	0.02	−2.5	−0.0005	55	100	
2SJ353	SP-8	−60	±1.5	±3.0	1.0	−10	−1	1.0	−4	−0.8	0.58	0.68	
2SJ355	SC-62	30	2	4	2.0	−10	−1	1.0	4.0	1.0	0.50	0.60	
2SJ356	SC-62	60	2	4	2.0	−10	−1	1.0	4.0	1.0	0.65	0.95	
2SJ357	MP-2	30	3	6	2.0	−10	−1	1.8	4.0	1.5	0.23	0.35	
2SJ358	MP-2	60	3	6	2.0	−10	−1	1.8	4.0	1.5	0.29	0.40	
2SJ411	SP-8	−30	±5	±20	1.0	−10	−2.5	3.0	−4	−2.5	0.096	0.24	
2SJ460	SST	−50	±0.1	±0.2	0.25	−3	−0.01	0.01	−2.5	−0.003	75	100	
2SJ461	SC-59	−50	±0.1	±0.2	0.2	−3	−0.01	0.01	−2.5	−0.003	75	100	
2SJ462	MP-2	−12	±2.5	±5.0	2.0	−3	−1	1.5	−2.5	−0.5	0.23	0.3	
2SJ463A	SC-70	−30	±0.1	±0.4	0.15	−3	−0.01	0.02	−2.5	−0.001	23	60	

Field Effect Transistor

Power MOS FET

■ N6-L series Product Map

DC drain current I _{D(DC)} (A)	Drain to source voltage V _{DSS} (V)		Package
	30	60	
to 20	△ 2SK2981 (27 m/40 m)*		△ : TO-251 (MP-3) ● : Isolated TO-220 (MP-45F) ○ : TO-220AB (MP-25)
to 30	△ 2SK2982 (12.5 m/16.5 m)* ○ 2SK2983 (20 m/27 m)*	● 2SK3055 (34 m/50 m)	
to 40	○ 2SK2984 (10 m/13 m)*	○ 2SK3056 (34 m/50 m)	
to 50		● 2SK2057 (17 m/27 m) ● 2SK3059 (13 m/20 m)	
to 60		○ 2SK2058 (17 m/27 m)	
to 70		○ 2SK3060 (13 m/20 m) ● 2SK3061 (8.5 m/12 m) ○ 2SK3062 (8.5 m/12 m) ○ 2SK2826 (6.5 m/10.5 m)	

(): R_{DS(on)} MAX (Ω) (@V_{GS} = 10 V/V_{GS} = 4 V)* : (@V_{GS} = 10 V/V_{GS} = 4.5 V)

■ N5-L series/P5-L series/N4-L series Product Map

DC drain current I _{D(DC)} (A)	Drain to source voltage V _{DSS} (V)			Package
	30	60	100	
8.0		△ 2SK2415 (0.1/0.15)		△ : TO-251 (MP-3) ● : Isolated TO-220 (MP-45F) ○ : TO-220AB (MP-25) ◎ : MP-10 ▣ : TO-3P (MP-88)
10		◎ 2SK2413 (70 m/95 m) △ 2SK2414 (70 m/95 m)		
15			● 2SK2462 (0.14/0.17)	
20		● 2SK2412 (70 m/95 m) ○ 2SJ492 (0.1/0.19)* ● 2SJ494 (50 m/88 m)*	● 2SK2461 (80 m/0.1)	
25		● 2SK2723 (40 m/60 m)*		
30		● 2SK2410 (40 m/60 m) ○ 2SK2411 (40 m/60 m) ● 2SJ495 (30 m/56m)*		
35	○ 2SK2941 (20 m/33 m)*	● 2SK2724 (27 m/40 m)*		
40		● 2SK2409 (27m/40 m) ● 2SK2510 (20 m/30 m)* ▣ 2SK2511 (27 m/40 m)*		
45		● 2SK2512 (15 m/23 m)* ○ 2SK2513 (15 m/23 m)*		
50		● 2SK2498 (9 m/14 m)* ○ 2SK2499 (9 m/14 m)* ▣ 2SK2514 (15 m/23 m)* ▣ 2SK2515 (9 m/14 m)*		

(): R_{DS(on)} MAX (Ω) (@V_{GS} = 10 V/V_{GS} = 4 V)

* : N5-L series

Field Effect Transistor

Power MOS FET

■ N3-L series/P3-L series Product Map

DC drain current I _D (DC) (A)	Drain to source voltage V _{DS} (V)			Package
	30	60	100/[150]	
~ 4.0	△ 2SJ324 (0.25/0.52) △ 2SJ325 (0.11/0.24)	△ 2SK1282 (0.18/0.24) ◇ 2SK1283 (0.18/0.24) △ 2SJ326 (0.37/0.68) △ 2SJ327 (0.17/0.34)	△ 2SK1284 (0.32/0.40) ◇ 2SK1285 (0.32/0.40)	◇ : TO-126 (MP-5) △ : TO-251 (MP-3) ● : Isolated TO-220 (MP-45F) ○ : TO-220AB (MP-25) ◎ : MP-10 ▣ : TO-3P (MP-88)
~ 8.0		◎ 2SK1748 (0.11/0.16)		
~ 10		◎ 2SK1850 (70 m/95 m)	◎ 2SK1852 (0.15/0.20)	
~ 15		2SK1851 (45 m/60 m) ● 2SK1286 (70 m/95 m) ● 2SJ303 (0.1/0.24) ● 2SJ329 (60 m/0.11)	◎ 2SK1853 (80 m/0.10) ● 2SK1288 (0.15/0.20) [● 2SK2131 (0.12/0.20)]	
~ 20	● 2SK1594 (50 m/80 m)	○ 2SK1287 (70 m/95 m) ○ 2SJ302 (0.1/0.24) ○ 2SJ328 (60 m/0.11) ● 2SJ330 (50 m/90 m)	○ 2SK1289 (0.15/0.20) ● 2SK1292 (80 m/0.10)	
~ 25		● 2SK1290 (45 m/60 m)		
~ 30		▣ 2SJ331 (30 m/55 m)	○ 2SK1293 (80 m/0.10) ● 2SK1295 (50 m/70 m)	
~ 40	● 2SK1596 (20 m/30 m)	● 2SK1294 (27 m/50 m) ▣ 2SK1123 (27 m/50 m)	▣ 2SK1122 (50 m/70 m)	
~ 50		▣ 2SK1749 (18 m/25 m)		

(): R_{DS(on)} MAX (Ω) (@V_{GS} = 10 V/V_{GS} = 4 V)

Field Effect Transistor

Power MOS FET

■ N6-L Series (Low Voltage N channel 6th generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics					
		V _{DSS} (V)	I _D (DC) (A)	P _T @T _C = 25 °C (W)	R _{DS(on)} @V _{GS} = 10 V		R _{DS(on)} @V _{GS} = 4 V		C _{iss} (pF)	C _{rss} (pF)
					TYP. (Ω)	MAX. (Ω)	TYP. (Ω)	MAX. (Ω)		
2SK2981	TO-251	30	20	20	20 m	27 m	30 m	40 m*	860	160
2SK2982	TO-251		30	20	9.8 m	12.5 m	13.2 m	16.5 m*	2290	440
2SK2983	TO-220AB		30	50	13 m	20 m	18 m	27 m*	1200	250
2SK2984	TO-220AB		40	60	6.5 m	10 m	8.5 m	13 m*	2600	500
2SK3053	Isolated TO-220	60	25	25	29 m	45 m	46 m	70 m	790	100
2SK3055	Isolated TO-220		30	25	28 m	34 m	42 m	50 m	990	90
2SK3056	TO-220AB		32	34	28 m	34 m	42 m	50 m	990	90
2SK3057	Isolated TO-220		45	30	14 m	17 m	21 m	27 m	2040	190
2SK3058	TO-220AB		55	58	14 m	17 m	21 m	27 m	2040	190
2SK3059	Isolated TO-220		50	30	11 m	13 m	16 m	20 m	2550	250
2SK3060	TO-220AB		70	70	11 m	13 m	16 m	20 m	2550	250
2SK3061	Isolated TO-220		70	35	6.3 m	8.5 m	9.8 m	12 m	5020	460
2SK3062	TO-220AB		70	100	6.3 m	8.5 m	9.8 m	12 m	5020	460
2SK2826	TO-220AB		70	100	5.5 m	6.5 m	7 m	10.5 m	7260	660

*: V_{GS} = 4.5 V

■ N5-L Series (Low Voltage N channel 5th generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics					
		V _{DSS} (V)	I _D (DC) (A)	P _T @T _C = 25 °C (W)	R _{DS(on)} @V _{GS} = 10 V		R _{DS(on)} @V _{GS} = 4 V		C _{iss} (pF)	C _{rss} (pF)
					TYP. (Ω)	MAX. (Ω)	TYP. (Ω)	MAX. (Ω)		
2SK2941	TO-220AB	30	35	60	14 m	20 m	22 m	33 m	1250	460
2SK2723	Isolated TO-220	60	25	25	28 m	40 m	45 m	60 m	830	185
2SK2724	Isolated TO-220		35	30	20 m	27 m	33 m	40 m	1200	270
2SK2510	Isolated TO-220		40	35	16 m	20 m	24 m	30 m	1600	350
2SK2511	TO-3P		40	80	22 m	27 m	32 m	40 m	1210	270
2SK2512	Isolated TO-220		45	35	11 m	15 m	16 m	23 m	2100	500
2SK2513	TO-220AB		45	75	11 m	15 m	16 m	23 m	2100	500
2SK2498	Isolated TO-220		50	35	7.3 m	9 m	11 m	14 m	3400	770
2SK2499	TO-220AB		50	75	7.3 m	9 m	11 m	14 m	3400	770
2SK2514	TO-3P		50	150	11 m	15 m	16 m	23 m	2100	500
2SK2515	TO-3P		50	150	7.3 m	9 m	11 m	14 m	3400	770

Field Effect Transistor

Power MOS FET

■ P5-L Series (Low Voltage P channel 5th generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics					
		V _{DSS} (V)	I _D (DC) (A)	P _T @T _C = 25 °C (W)	R _{DS(on)} @V _{GS} = 10 V		R _{DS(on)} @V _{GS} = 4 V		C _{iss} (pF)	C _{rss} (pF)
					TYP. (Ω)	MAX. (Ω)	TYP. (Ω)	MAX. (Ω)		
2SJ492	TO-220AB	-60	-20	70	70 m	0.10	0.12	0.185	1210	180
2SJ493	Isolated TO-220		-16	30	70 m	0.10	0.12	0.185	1210	180
2SJ494	Isolated TO-220		-20	35	39 m	50 m	61 m	88 m	2360	350
2SJ495	Isolated TO-220		-30	35	24 m	30 m	38 m	56 m	4120	580

■ N4-L Series (Low Voltage N channel 4th generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics					
		V _{DSS} (V)	I _D (DC) (A)	P _T @T _C = 25 °C (W)	R _{DS(on)} @V _{GS} = 10 V		R _{DS(on)} @V _{GS} = 4 V		C _{iss} (pF)	C _{rss} (pF)
					TYP. (Ω)	MAX. (Ω)	TYP. (Ω)	MAX. (Ω)		
2SK2409	Isolated TO-220	60	40	35	21 m	27 m	30 m	40 m	1800	350
2SK2410	Isolated TO-220		30	35	28 m	40 m	40 m	60 m	1300	250
2SK2411	TO-220AB		30	75	28 m	40 m	40 m	60 m	1300	250
2SK2412	Isolated TO-220		15	30	53 m	70 m	70 m	0.10	700	150
2SK2413	MP-10		10	1.8*	53 m	70 m	70 m	0.10	700	150
2SK2414	TO-251		10	20	53 m	70 m	70 m	0.10	700	150
2SK2415	TO-251		8.0	20	70 m	0.10	0.11	0.15	440	85
2SK2461	Isolated TO-220	100	20	35	60 m	80 m	70 m	0.10	1510	140
2SK2462	Isolated TO-220		15	30	0.10	0.14	0.12	0.17	870	80

*: T_A = 25°C

■ P3-L Series (Low Voltage P channel 3rd generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics					
		V _{DSS} (V)	I _D (DC) (A)	P _T @T _C = 25 °C (W)	R _{DS(on)} @V _{GS} = 10 V		R _{DS(on)} @V _{GS} = 4 V		C _{iss} (pF)	C _{rss} (pF)
					TYP. (Ω)	MAX. (Ω)	TYP. (Ω)	MAX. (Ω)		
2SJ324	TO-251	-30	-2.0	20	0.20	0.25	0.40	0.52	330	100
2SJ325	TO-251		-4.0	20	85 m	0.11	0.15	0.24	800	250
2SJ326	TO-251	-60	-2.0	20	0.28	0.37	0.50	0.68	320	75
2SJ327	TO-251		-4.0	20	0.13	0.17	0.22	0.34	750	165
2SJ303	Isolated TO-220		-14	35	75 m	0.1	0.17	0.24	1200	290
2SJ302	TO-220AB		-16	60	75 m	0.1	0.17	0.24	1200	290
2SJ328	TO-220AB		-20	75	48 m	60 m	85 m	0.11	2150	530
2SJ329	Isolated TO-220		-15	35	48 m	60 m	85 m	0.11	2150	530
2SJ330	Isolated TO-220		-20	35	38 m	50 m	65 m	90 m	2570	640
2SJ331	TO-3P		-30	150	25 m	30 m	40 m	55 m	4300	1110

Field Effect Transistor

Power MOS FET

■ N3-L Series (Low Voltage 3rd generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics					
		V _{DSS} (V)	I _{D(DC)} (A)	P _T @T _C = 25 °C (W)	R _{DS(on)} @V _{GS} = 10 V		R _{DS(on)} @V _{GS} = 4 V		C _{iss} (pF)	C _{rss} (pF)
					TYP. (Ω)	MAX. (Ω)	TYP. (Ω)	MAX. (Ω)		
2SK1594	Isolated TO-220	30	20	30	37 m	50 m	50 m	80 m	1300	280
2SK1596	Isolated TO-220		40	35	14 m	20 m	20 m	30 m	3400	960
2SK1282	TO-251	60	3.0	20	0.15	0.18	0.18	0.24	500	40
2SK1283	TO-126		3.0	20	0.15	0.18	0.18	0.24	500	40
2SK1748	TO-251		8.0	20	80 m	0.11	0.11	0.16	850	350
2SK1850	MP-10		10	1.8*	55 m	70 m	80 m	95 m	1400	130
2SK1851	MP-10		15	1.8*	35 m	45 m	45 m	60 m	2200	180
2SK1286	Isolated TO-220		15	30	55 m	70 m	80 m	95 m	1400	130
2SK1287	TO-251		20	60	55 m	70 m	80 m	95 m	1400	130
2SK1290	Isolated TO-220		25	35	35 m	45 m	45 m	60 m	2200	180
2SK1294	Isolated TO-220		40	35	22 m	27 m	30 m	50 m	3250	380
2SK1123	TO-3P		40	100	22 m	27 m	30 m	50 m	3250	380
2SK1749	TO-3P		50	150	16 m	18 m	22 m	25 m	5400	620
2SK1284	TO-251		3.0	20	0.26	0.32	0.32	0.40	500	20
2SK1285	TO-126		3.0	20	0.26	0.32	0.32	0.40	500	20
2SK1852	MP-10		10	1.8*	0.12	0.15	0.15	0.20	1400	50
2SK1853	MP-10		15	1.8*	70 m	80 m	80 m	0.10	2200	90
2SK1288	Isolated TO-220	100	15	30	0.12	0.15	0.15	0.20	1400	50
2SK1289	TO-220AB		20	60	0.12	0.15	0.15	0.20	1400	50
2SK1292	Isolated TO-220		20	35	70 m	80 m	80 m	0.10	2200	90
2SK1293	TO-220AB		30	75	70 m	80 m	80 m	0.10	2200	90
2SK1295	Isolated TO-220		30	35	42 m	50 m	50 m	70 m	3300	200
2SK1122	TO-3P		40	100	42 m	50 m	50 m	70 m	3300	200
2SK2131	Isolated TO-220	150	15	35	0.10	0.12	0.13	0.20	2300	140

*: T_A = 25°C

Field Effect Transistor

Power MOS FET

■ N5-H series Product Map

(): $R_{DS(on)}$ MAX (Ω) (@ $V_{GS} = 10$ V)

DC drain current $I_{D(DC)}$ (A)	Drain to source voltage V_{DS} (V)				Package
	200/250 V	400/500 V	600 V	900 V	
2			△ 2SK3113 (4.4) ● 2SK3221 (4.4)		△ : TO-251 (MP-3) ● : Isolated TO-220 (MP-45F) ○ : TO-220AB (MP-25) □ : TO-3P (MP-88)
4			● 2SK3114 (2.2)		
5		● 2SK3306 (1.5)* ○ 2SK3305 (1.5)*	● 2SK3297 (1.6)*		
6			● 2SK3115 (1.2)	□ 2SK3304 (2.0)*	
7					
7.5			○ 2SK3116 (1.2) ● 2SK3298 (0.75)*		
8	● 2SK3108 (0.4)				
10	○ 2SK3109 (0.4)		○ 2SK3299 (0.75)*		
14	● 2SK3110 (0.18)				
20	○ 2SK3111 (0.18) ○ 2SK3294 (0.12)*1*		□ 2SK3300 (0.4)*		
25	○ 2SK3112 (0.11)*				

*1: 250 V *2: 450 V

*: Under development

■ N4-H series/P4-H series Product Map

DC drain current $I_{D(DC)}$ (A)	Drain to source voltage V_{DS} (V)						Package
	[180]/200	250	450	500	600	[800]/900	
2.0					● 2SK1953 (5.0) △ 2SK2040 (5.0)	● 2SK2478 (7.5)	△ : TO-251 (MP-3) ● : Isolated TO-220 (MP-45F) ○ : TO-220AB (MP-25) ◎ : MP-10 □ : TO-3P (MP-88)
3.0						[● 2SK2476 (5.0)] ○ 2SK2479 (7.5) ● 2SK2480 (4.0)	
4.0	[△ 2SK1954 (0.65)] [◎ 2SK2132 (0.65)]	● 2SJ448 (2.0)			● 2SK2137 (2.4)	○ 2SK2481 (4.0) ● 2SK2483 (2.8) (3.5 A)	
4.5			● 2SK2353 (1.4)	● 2SK2354 (1.5)			
5.0			○ 2SK2355 (1.4)	○ 2SK2356 (1.5)	○ 2SK2138 (2.4) ● 2SK2139 (1.5)	□ 2SK2482 (4.0) ○ 2SK2484 (2.8)	
6.0		● 2SJ449 (0.8)	● 2SK2357 (0.9)	● 2SK2358 (1.0)	● 2SK2141 (1.1)	□ 2SK2485 (2.8)	
7.0			○ 2SK2359 (0.9)	○ 2SK2360 (1.0)	○ 2SK2140 (1.5)	□ 2SK2486 (2.0)	
8.0			● 2SK2363 (0.5)	● 2SK2364 (0.6)		□ 2SK2487 (1.6)	
10			□ 2SK2361 (0.9) ○ 2SK2365 (0.5)	□ 2SK2362 (1.0) ○ 2SK2366 (0.6)		[□ 2SK2477 (1.0)] □ 2SK2488 (1.2)	
11		● 2SK2341 (0.26)					
13	○ 2SK2134 (0.4)						
14	● 2SK2135 (0.18)						
15			□ 2SK2367 (0.5)	□ 2SK2368 (0.6)			
16		○ 2SK2133 (0.26)					
20	○ 2SK2136 (0.18)		□ 2SK2369 (0.35)	□ 2SK2370 (0.4)			
25			□ 2SK2371 (0.25)	□ 2SK2372 (0.27)			

(): $R_{DS(on)}$ MAX (Ω) (@ $V_{GS} = 10$ V)

Field Effect Transistor

Power MOS FET

■ N3-H series Product Map

DC drain current I _{D(DC)} (A)	Drain to source voltage V _{DSS} (V)					Package
	250	450	500	600	900	
2.0				● 2SK1758 (4.2)	● 2SK1994 (7.5)	△: TO-251 (MP-3) ●: Isolated TO-220 (MP-45F) ○: TO-220AB (MP-25) □: TO-3P (MP-88)
2.5		● 2SK1988 (2.8)	● 2SK1989 (3.0)			
3.0		○ 2SK1493 (2.8)	○ 2SK1494 (3.0)		○ 2SK1793 (7.5) ● 2SK1995 (4.0)	
3.5					● 2SK2275 (2.8)	
4.0					○ 2SK1501 (4.0)	
4.5		● 2SK1990 (1.4)	● 2SK1991 (1.5)			
5.0		○ 2SK1750 (1.4)	○ 2SK1751 (1.5)		□ 2SK1760 (4.0)	
6.0		● 2SK1992 (0.9)	● 2SK1993 (1.0)		□ 2SK1794 (2.8)	
7.0		○ 2SK1495 (0.9)	○ 2SK1496 (1.0)		□ 2SK1502 (2.0)	
8.0			● 2SK2234 (0.6)		□ 2SK1795 (1.6)	
10		□ 2SK1752 (0.9)	□ 2SK1753 (1.0)		□ 2SK1796 (1.2)	
12		□ 2SK1784 (0.6)	□ 2SK1785 (0.7)			
15		□ 2SK1756 (0.5)	□ 2SK1757 (0.6)			
20		□ 2SK1497 (0.35)	□ 2SK1498 (0.4)			
25	□ 2SK1491 (0.15)	□ 2SK1499 (0.25)	□ 2SK1500 (0.27)			
35	□ 2SK1492 (0.10)					

(): R_{DS(on)} MAX (Ω) (@V_{GS} = 10 V)

Field Effect Transistor

Power MOS FET

■ N5-H Series (High Voltage N channel 5th generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics			
		V _{DSS} (V)	I _D (DC) (A)	P _T (W)	R _{DS(on)} @V _{GS} = 10 V		C _{iss} (pF)	Q _g (nC)
					TYP. (Ω)	MAX. (Ω)		
2SK3108	Isolated TO-220	200	8	25	0.33	0.4	400	15
2SK3109	TO-220AB	200	10	50	0.33	0.4	400	15
2SK3110	Isolated TO-220	200	14	35	0.13	0.18	1000	40
2SK3111	TO-220AB	200	20	65	0.13	0.18	1000	40
2SK3112	TO-220AB	200	25	70	0.08	0.11	1600	65
2SK3294*	TO-220AB	250	20	70	0.12	0.16	1600	65
2SK3305*	TO-220AB	500	5	50	1.35	1.5	570	20
2SK3306*	Isolated TO-220	500	5	30	1.35	1.5	570	20
2SK3113	TO-251	600	2	20	3.3	4.4	290	9
2SK3221	Isolated TO-220	600	2	25	3.3	4.4	290	9
2SK3114	Isolated TO-220	600	4	30	1.6	2.2	550	15
2SK3297*	Isolated TO-220	600	5	35	1.28	1.6	690	24
2SK3115	Isolated TO-220	600	6	35	0.9	1.2	1100	26
2SK3116	TO-220AB	600	7.5	70	0.9	1.2	1100	26
2SK3298*	TO-220AB	600	7.5	40	0.6	0.75	1500	51
2SK3299*	TO-220AB	600	10	70	0.6	0.75	1500	51
2SK3300*	TO-3P	600	20	150	0.32	0.4	3300	80
2SK3304*	TO-3P	900	7	120	1.6	2.0	1500	50

★: Under development

Field Effect Transistor

Power MOS FET

■ N4-H Series (High Voltage N channel 4th generation Series) (1/2)

Part number	Package	Absolute maximum ratings			Electrical characteristics			
		V _{DSS} (V)	I _D (DC) (A)	P _T (W)	R _{DS(on)} @V _{GS} = 10 V		C _{iss} (pF)	Q _g (nC)
					TYP. (Ω)	MAX. (Ω)		
2SK1954	TO-251	180	4.0	20	0.52	0.65	300	10
2SK2132	MP-10		4.0	1.8*	0.52	0.65	300	10
2SK2134	TO-220AB	200	13	70	0.32	0.40	540	15
2SK2135	Isolated TO-220		14	35	0.14	0.18	1100	30
2SK2136	TO-220AB		20	75	0.14	0.18	1100	30
2SK2341	Isolated TO-220	250	11	35	0.21	0.26	1090	33
2SK2133	TO-220AB		16	75	0.21	0.26	1090	25
2SK2353	Isolated TO-220	450	4.5	30	1.0	1.4	670	20
2SK2355	TO-220AB		5.0	50	1.0	1.4	670	20
2SK2357	Isolated TO-220		6.0	35	0.7	0.9	1050	27
2SK2359	TO-220AB		7.0	75	0.7	0.9	1050	27
2SK2361	TO-3P		10	100	0.7	0.9	1050	26
2SK2363	Isolated TO-220		8.0	35	0.4	0.5	1600	42
2SK2365	TO-220AB		10	75	0.4	0.5	1600	42
2SK2367	TO-3P		15	120	0.4	0.5	1600	43
2SK2369	TO-3P		20	120	0.28	0.40	2400	65
2SK2371	TO-3P		25	160	0.20	0.25	3600	95
2SK2354	Isolated TO-220		4.5	30	1.1	1.5	670	20
2SK2356	TO-220AB		5.0	50	1.1	1.5	670	20
2SK2358	Isolated TO-220	500	6.0	35	0.8	1.0	1050	27
2SK2360	TO-220AB		7.0	75	0.8	1.0	1050	27
2SK2362	TO-3P		10	100	0.8	1.0	1050	26
2SK2364	Isolated TO-220		8.0	35	0.5	0.6	1600	42
2SK2366	TO-220AB		10	75	0.5	0.6	1600	42
2SK2368	TO-3P		15	120	0.5	0.6	1600	43
2SK2370	TO-3P		20	120	0.32	0.40	2400	65
2SK2372	TO-3P		25	160	0.22	0.27	3600	95
2SK1953	Isolated TO-220	600	2.0	25	4.2	5.0	275	12
2SK2040	TO-251		2.0	20	4.2	5.0	275	12
2SK2137	Isolated TO-220		4.0	30	2.0	2.4	550	20
2SK2138	TO-220AB		5.0	70	2.0	2.4	550	20
2SK2139	Isolated TO-220		5.0	35	1.25	1.5	930	30
2SK2141	Isolated TO-220		6.0	40	0.9	1.1	1150	40
2SK2140	TO-220AB		7.0	75	1.25	1.5	930	30
2SK2476	Isolated TO-220	800	3.0	40	3.4	5.0	590	20
2SK2477	TO-3P		10	150	0.65	1.0	2950	90
2SK2478	Isolated TO-220	900	2.0	30	5.0	7.5	485	17
2SK2479	TO-220AB		3.0	70	5.6	7.5	485	17
2SK2480	Isolated TO-220		3.0	35	3.2	4.0	900	30
2SK2481	TO-220AB		4.0	75	3.2	4.0	900	30

*: T_A = 25°C

Field Effect Transistor

Power MOS FET

■ N4-H Series (High Voltage N channel 4th generation Series) (2/2)

Part number	Package	Absolute maximum ratings			Electrical characteristics			
		V _{DSS} (V)	I _{D(DC)} (A)	P _T (W)	R _{DS(on)} @V _{GS} = 10 V		C _{iss} (pF)	Q _g (nC)
					TYP. (Ω)	MAX. (Ω)		
2SK2482	TO-3P	900	5.0	100	3.2	4.0	900	30
2SK2483	Isolated TO-220		3.5	40	2.2	2.8	1200	40
2SK2484	TO-220AB		5.0	75	2.2	2.8	1200	40
2SK2485	TO-3P		6.0	100	2.2	2.8	1200	40
2SK2486	TO-3P		7.0	120	1.4	2.0	1830	55
2SK2487	TO-3P		8.0	140	1.1	1.6	2100	65
2SK2488	TO-3P		10	160	1.0	1.2	2900	90

■ P4-H Series (High Voltage P channel 4th generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics			
		V _{DSS} (V)	I _{D(DC)} (A)	P _T (W)	R _{DS(on)} @V _{GS} = 10 V		C _{iss} (pF)	Q _g (nC)
					TYP. (Ω)	MAX. (Ω)		
2SJ448	Isolated TO-220	-250	±4.0	30	1.5	2.0	470	15
2SJ449	Isolated TO-220	-250	±6.0	35	0.55	0.8	1040	23.4

Field Effect Transistor

Power MOS FET

■ N3-H Series (High Voltage N channel 3rd generation Series)

Part number	Package	Absolute maximum ratings			Electrical characteristics			
		V _{DSS} (V)	I _D (DC) (A)	P _T (W)	R _{DS(on)} @V _{GS} = 10 V		C _{iss} (pF)	Q _g (nC)
					TYP. (Ω)	MAX. (Ω)		
2SK1491	TO-3P	250	25	120	0.12	0.15	1950	55
2SK1492	TO-3P	250	35	140	0.08	0.1	3000	80
2SK1988	Isolated TO-220	450	2.5	30	2.2	2.8	350	12
2SK1493	TO-220AB	450	3	50	2.2	2.8	350	12
2SK1990	Isolated TO-220	450	4.5	30	1.1	1.4	610	22
2SK1750	TO-220AB	450	5	50	1.1	1.4	610	22
2SK1992	Isolated TO-220	450	6	35	0.7	0.9	1060	36
2SK1495	TO-220AB	450	7	70	0.7	0.9	1060	36
2SK1752	TO-3P	450	10	100	0.7	0.9	1060	36
2SK1784	TO-3P	450	12	100	0.5	0.6	1330	46
2SK1756	TO-3P	450	15	120	0.4	0.5	1500	50
2SK1497	TO-3P	450	20	120	0.28	0.35	2460	85
2SK1499	TO-3P	450	25	160	0.2	0.25	3300	115
2SK1989	Isolated TO-220	500	2.5	30	2.4	3	350	12
2SK1494	TO-220AB	500	3	50	2.4	3	350	12
2SK1991	Isolated TO-220	500	4.5	30	1.2	1.5	610	22
2SK1751	TO-220AB	500	5	50	1.2	1.5	610	22
2SK1993	Isolated TO-220	500	6	35	0.8	1	1060	36
2SK1496	TO-220AB	500	7	70	0.8	1	1500	57
2SK2234	Isolated TO-220	500	8	40	0.5	0.6	1060	36
2SK1753	TO-3P	500	10	100	0.8	1	1060	36
2SK1785	TO-3P	500	12	100	0.6	0.7	1330	46
2SK1757	TO-3P	500	15	120	0.5	0.6	1500	50
2SK1498	TO-3P	500	20	120	0.32	0.4	2460	85
2SK1500	TO-3P	500	25	160	0.22	0.27	3300	115
2SK1758	Isolated TO-220	600	2	30	2.8	4.2	360	17
2SK1994	Isolated TO-220	900	2	30	5.5	7.5	430	15.5
2SK1793	TO-220AB	900	3	75	5.5	7.5	430	19
2SK1995	Isolated TO-220	900	3	35	3	4	790	28
2SK2275	Isolated TO-220	900	3.5	35	2.2	2.8	1000	42
2SK1501	TO-220AB	900	4	70	2.8	4	790	33
2SK1760	TO-3P	900	5	100	3.1	4	790	34
2SK1794	TO-3P	900	6	100	2.4	2.8	1000	42
2SK1502	TO-3P	900	7	120	1.7	2	1550	80
2SK1795	TO-3P	900	8	140	1.3	1.6	1740	66
2SK1796	TO-3P	900	10	150	1	1.2	2500	90
2SK1271*	TO-3P	1400	5	240	3.5	4	1800	125

*: 2nd Generation

Field Effect Transistor

Power MOS FET

■ 8-pin SOP Type Power MOS FET

On-Resistance R _{DS(on)} (mΩ) (TYP.) @V _{GS} = 10 V	Drain to source voltage V _{DSS} (V)		
	20	30	60
up to 600			μPA1790 (Nch + Pch)
up to 150			μPA1759 (Nch Dual)
up to 90		μPA1750 (P-ch Dual)	
up to 70		μPA1710 (P-ch Single) μPA1710A (P-ch Single) μPA1754 (N-ch Dual)	
up to 50		μPA1713 (P-ch Single)	
up to 40	μPA1752 (N-ch Dual)*1	μPA1711 (P-ch Single)	
up to 30	μPA1753 (N-ch Dual)*1 μPA1756 (N-ch Dual)*1	μPA1751 (N-ch Dual) μPA1714 (P-ch Single) μPA1755 (N-ch Dual) μPA1758 (N-ch Dual)*1	
up to 20	μPA1701 (N-ch Single)*1 μPA1701A (N-ch Single) μPA1757 (N-ch Dual)*1	μPA1700 (N-ch Single) μPA1700A (N-ch Single) μPA1712 (P-ch Single) μPA1716 (P-ch Single) μPA1705 (N-ch Single)*2	
up to 10		μPA1702 (N-ch Single) μPA1703 (N-ch Single) μPA1704 (N-ch Single) μPA1706 (N-ch Single) μPA1707 (N-ch Single) μPA1715 (P-ch Single)	

*1: 2.5 V drive is possible. Otherwise 4 V drive is possible. *2: 4.5 V drive

Field Effect Transistor

Power MOS FET

■ Power SOP8 series

Part number	Configuration	Absolute maximum rating (T _A = 25 °C)				Electrical characteristics (T _A = 25 °C)				Applications
		V _{DSS} (V)	I _D		P _T T _C = 25 °C (W)	R _{DS(on)} (Ω)				
			DC (A)	Pulse (A)		V _{GS} (V)	I _D (A)	TYP.	MAX.	
μPA1700	N-ch Single	30	±7	±28	2.0*1	4	3.5	0.040	0.050	Switching
μPA1700A	N-ch Single	30	±7	±28	2.0*1	4	3.5	0.028	0.05	
μPA1701	N-ch Single	20	±7	±28	2.0*1	2.5	3.5	0.03	0.04	
μPA1701A	N-ch Single	20	±7	±28	2.0*1	2.5	3.5	0.026	0.04	
μPA1702	N-ch Single	30	±8	±32	2.0*1	4	4	0.018	0.025	
μPA1703	N-ch Single	30	±10	±40	2.0*1	4	5.0	0.012	0.017	
μPA1704	N-ch Single	30	±10	±40	2.0*1	2.5	5.0	0.0125	0.016	
μPA1705	N-ch Single	30	±7	±28	2.0*1	4.5	3.5	0.031	0.04	
μPA1706	N-ch Single	30	±13	±52	2.0*1	4	7.0	0.008	0.012	
μPA1707	N-ch Single	30	±10	±40	2.0*1	4	5.0	0.014	0.021	
μPA1710	P-ch Single	−30	±5	±20	2.0*1	−4	−2.5	0.11	0.16	
μPA1710A	P-ch Single	−30	±5	±20	2.0*1	−4	−2.0	0.091	0.16	
μPA1711	P-ch Single	−30	±7	±28	2.0*1	−4	−3.5	0.049	0.07	
μPA1712	P-ch Single	−30	±8	±32	2.0*1	−4	−4.0	0.027	0.048	
μPA1713	P-ch Single	30	±5	±20	2.0*1	−4	2.5	0.10	0.16	
μPA1714	P-ch Single	−30	±7	±28	2.0*1	−4	3.5	0.049	0.07	
μPA1715	P-ch Single	−30	±11	±44	2.0*1	−4.5	−6.0	0.011	0.016	
μPA1716	P-ch Single	−30	±8	±32	2.0*1	−4.5	−4	0.017	0.023	
μPA1750	P-ch Dual	−30	±3.5	±14	2.0*2	−4	−1.8	0.125	0.18	
μPA1751	N-ch Dual	30	±5	±20	2.0*2	4	2.5	0.044	0.064	
μPA1752	N-ch Dual	20	±5	±20	2.0*2	2.5	2.5	0.042	0.061	
μPA1753	N-ch Dual	20	±6	±24	2.0*2	2.5	3.0	0.028	0.04	
μPA1754	N-ch Dual	30	±7	±28	2.0*2	4	3.5	0.029	0.053	
μPA1755	N-ch Dual	−30	±7	±28	2.0*2	4.5	3.5	0.028	0.045	
μPA1756	N-ch Dual	30	±6	±24	2.0*2	2.5	3.0	0.028	0.04	
μPA1757	N-ch Dual	20	±7	±28	2.0*2	2.5	3.5	0.022	0.032	
μPA1758	N-ch Dual	30	±6	±24	2.0*2	2.5	3.0	0.026	0.04	
μPA1759	N-ch Dual	60	±5	±20	2.0*2	10	2.5	0.11	0.15	
μPA1790	N-ch + P-ch	60/−60	±1.0/±0.7	±4.0/±2.8	1.0*2	10	0.5/0.35	0.12/0.44	0.26/0.6	

*1: T_A = 25°C, Mounted on ceramic substrate of 1200 mm² × 0.7 mm*2: T_A = 25°C, 2 circuits, Mounted on ceramic substrate of 2000 mm² × 1.1 mm

Field Effect Transistor

Power MOS FET

■ 8-pin TSSOP Type Power MOS FET

On-Resistance R _{DS(on)} (mΩ) (MAX.) @V _{GS} = 4.5 V	Drain to source voltage V _{DSS} (V)		
	12	20	30
~210		μPA1851 (P-ch Dual)	
~190			μPA1853 (P-ch Dual)
~115	μPA1850 (P-ch Dual)		
~75		μPA1811 (P-ch Single)	μPA1812 (P-ch Single)
~60	μPA1854 (P-ch Dual) μPA1810 (P-ch Single)		
~40		μPA1852 (N-ch Dual)	μPA1800 (N-ch Single)
~30			μPA1814 (P-ch Single)*
~25	μPA1813 (P-ch Single)	μPA1801 (N-ch Single) μPA1855 (N-ch Dual)* μPA1802 (N-ch Single) μPA1815 (P-ch Single)*	μPA1803 (N-ch Single)*

*: Under development

■ 8-pin TSSOP Type Power MOS FET

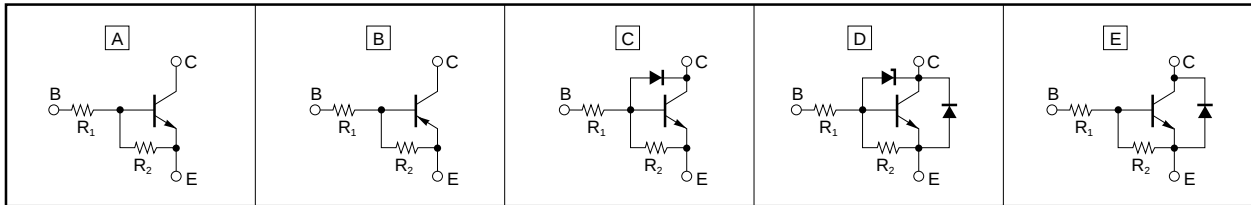
Part number	Configuration	Absolute maximum rating (T _A = 25 °C)				Electrical characteristics (T _A = 25 °C)				Applications
		V _{DSS} (V)	V _{GSS} (V)	I _{D(DC)} (A)	P _T * (W)	R _{DS(on)} (mΩ) MAX.				
						V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 10 V	
μPA1800	N-ch Single	30	±20	±5	2	—	45	39	27	Switching
μPA1801	N-ch Single	20	±8	±6	2	34	25	24	—	
μPA1802	N-ch Single	20	±12	±7	2	32	25	23	—	
μPA1803*	N-ch Single	30	±20	±7	2	—	—	16	21	
μPA1810	P-ch Single	−12	−10/+5	±4	2	100	60	55	—	
μPA1811	P-ch Single	−20	−12/+5	±4	2	120	80	75	—	
μPA1812	P-ch Single	−30	−20/+5	±5	2	—	90	70	40	
μPA1813	P-ch Single	−12	−10/+5	±5	2	40	30	25	—	
μPA1814*	P-ch Single	−30	−20/+5	±7	2	—	—	30	19	
μPA1815*	P-ch Single	−20	−12/+3	±7	2	30	23	22	—	
μPA1850	P-ch Dual	−12	−10/+5	±2.5	2	200	130	115	—	
μPA1851	P-ch Dual	−20	−20/+5	±2.5	2	—	250	210	105	
μPA1852	N-ch Dual	20	±12	±5	2	60	45	40	—	
μPA1853	P-ch Dual	−30	−20/+5	±2.5	2	—	220	190	85	
μPA1854	P-ch Dual	−12	−10/+5	±2.5	2	105	70	60	—	
μPA1855*	N-ch Dual	20	±12	±6	2	29	24	23	—	

*: Mounted on ceramic substrate of 50 cm² × 1.1 mm

*: Under development

Transistor with Internal Resistor

Equivalent circuit



AA1[], AN1[], BA1[], BN1[] series (TO-92, SST)

Part number		Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)					Electrical characteristics (T _A = 25 °C)							
			V _{CB0} (V)	V _{CEO} (V)	V _{EB0} (V)	I _C (mA)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (mA)	Remarks	
TO-92	SST														
AA1A4M	BA1A4M	Refer to equivalent circuit 	60	50	10	100	250	150	10	10	35 to 100	5.0	5.0		
AA1A4P	BA1A4P		60	50	5	100	250	150	10	47	35 to 340	5.0	5.0		
AA1F4M	BA1F4M		60	50	10	100	250	150	22	22	60 to 195	5.0	5.0		
AA1F4N	BA1F4N		60	50	5	100	250	150	22	47	85 to 340	5.0	5.0		
AA1L4M	BA1L4M		60	50	10	100	250	150	47	47	85 to 340	5.0	5.0		
AA1L4L	BA1L4L		60	50	15	100	250	150	47	22	60 to 195	5.0	5.0		
AA1L3Z	BA1L3Z		60	50	5	100	250	150	4.7	—	135 to 600	5.0	5.0		
AA1A4Z	BA1A4Z		Switching	60	50	5	100	250	150	10	—	135 to 600	5.0	5.0	
AA1F4Z	BA1F4Z			60	50	5	100	250	150	22	—	135 to 600	5.0	5.0	
AA1L4Z	BA1L4Z			60	50	5	100	250	150	47	—	135 to 600	5.0	5.0	
AA1L3M	BA1L3M			60	50	10	100	250	150	4.7	4.7	20 to 80	5.0	5.0	
AA1L3N	BA1L3N			60	50	5	100	250	150	4.7	10	35 to 100	5.0	5.0	
AA1A3Q	BA1A3Q			60	50	5	100	250	150	1.0	10	35 to 100	5.0	5.0	
AN1A4M	BN1A4M	Refer to equivalent circuit 	–60	–50	–10	–100	250	150	10	10	35 to 100	–5.0	–5.0		
AN1A4P	BN1A4P		–60	–50	–5	–100	250	150	10	47	85 to 340	–5.0	–5.0		
AN1F4M	BN1F4M		–60	–50	–10	–100	250	150	22	22	60 to 195	–5.0	–5.0		
AN1F4N	BN1F4N		–60	–50	–5	–100	250	150	22	47	85 to 340	–5.0	–5.0		
AN1L4M	BN1L4M		–60	–50	–10	–100	250	150	47	47	85 to 340	–5.0	–5.0		
AN1L4L	BN1L4L		–60	–50	–15	–100	250	150	47	22	60 to 195	–5.0	–5.0		
AN1L3Z	BN1L3Z		–60	–50	–5	–100	250	150	4.7	—	135 to 600	–5.0	–5.0		
AN1A4Z	BN1A4Z		–60	–50	–5	–100	250	150	10	—	135 to 600	–5.0	–5.0		
AN1F4Z	BN1F4Z		–60	–50	–5	–100	250	150	22	—	135 to 600	–5.0	–5.0		
AN1L4Z	BN1L4Z		–60	–50	–5	–100	250	150	47	—	135 to 600	–5.0	–5.0		
AN1L3M	BN1L3M		–60	–50	–10	–100	250	150	4.7	4.7	20 to 80	–5.0	–5.0		
AN1L3N	BN1L3N		–60	–50	–5	–100	250	150	4.7	10	35 to 100	–5.0	–5.0		
AN1A3Q	BN1A3Q		–60	–50	–5	–100	250	150	1.0	10	35 to 100	–5.0	–5.0		

Transistor with Internal Resistor

■ AB1[], AP1[], BB1[], BP1[] series (TO-92, SST)

Part number		Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)							Electrical characteristics (T _A = 25 °C)					
			V _{CB0} (V)	V _{CEO} (V)	V _{EB0} (V)	I _C (A)	P _T (mW)		T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	Re- marks
TO-92	SST						TO-92	SST							
AB1A4A	BB1A4A	Refer to equivalent circuit [A]	30	25	10	0.7	750	250	150	—	10	300 ~	2.0	0.5	
AB1L2Q	BB1L2Q		30	25	10	0.7	750	250	150	0.47	4.7	300 ~	2.0	0.5	
AB1A3M	BB1A3M		30	25	10	0.7	750	250	150	1.0	1.0	100 ~	2.0	0.5	
AB1F3P	BB1F3P		30	25	10	0.7	750	250	150	2.2	10	300 ~	2.0	0.5	
AB1J3P	BB1J3P		30	25	10	0.7	750	250	150	3.3	10	300 ~	2.0	0.5	
AB1L3N	BB1L3N	Switching	30	25	10	0.7	750	250	150	4.7	10	300 ~	2.0	0.5	
AB1A4M	BB1A4M		30	25	10	0.7	750	250	150	10	10	300 ~	2.0	0.5	
AP1A4A	BP1A4A	Refer to equivalent circuit [B]	–25	–25	–10	–0.7	750	250	150	—	10	100 ~	–2.0	–0.5	
AP1L2Q	BP1L2Q		–25	–25	–10	–0.7	750	250	150	0.47	4.7	100 ~	–2.0	–0.5	
AP1A3M	BP1A3M		–25	–25	–10	–0.7	750	250	150	1.0	1.0	100 ~	–2.0	–0.5	
AP1F3P	BP1F3P		–25	–25	–10	–0.7	750	250	150	2.2	10	100 ~	–2.0	–0.5	
AP1J3P	BP1J3P		–25	–25	–10	–0.7	750	250	150	3.3	10	100 ~	–2.0	–0.5	
AP1L3N	BP1L3N	Switching	–25	–25	–10	–0.7	750	250	150	4.7	10	100 ~	–2.0	–0.5	
AP1A4M	BP1A4M		–25	–25	–10	–0.7	750	250	150	10	10	100 ~	–2.0	–0.5	

■ AQ1[] series (TO-92)

Part number		Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)						Electrical characteristics (T _A = 25 °C)					
			V _{CB0} (V)	V _{CEO} (V)	V _{EB0} (V)	I _C (A)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	Remarks
TO-92														
AQ1A4A		Refer to equivalent circuit [B]	–20	–20	–10	–2.0	750	150	—	10	150 ~	–2.0	–1.0	
AQ1F2Q			–20	–20	–10	–2.0	750	150	0.22	2.2	150 ~	–2.0	–1.0	
AQ1L2N			–20	–20	–10	–2.0	750	150	0.47	1.0	150 ~	–2.0	–1.0	
AQ1L2Q			–20	–20	–20	–10	750	150	0.47	4.7	150 ~	–2.0	–1.0	
AQ1A3M			–20	–20	–10	–2.0	750	150	1.0	1.0	150 ~	–2.0	–1.0	
AQ1F3M		Switching	–20	–20	–10	–2.0	750	150	2.2	2.2	150 ~	–2.0	–1.0	
AQ1F3P			–20	–20	–10	–2.0	750	150	4.7	10	150 ~	–2.0	–1.0	

Transistor with Internal Resistor

■ AD1[], AD2[], AR1[] series (TO-92)

Part number	Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)						Electrical characteristics (T _A = 25 °C)					
		V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _C (A)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	Remarks
TO-92													
AD1A3M	Refer to equivalent circuit [A]	80	60	10	1.0	750	150	1.0	1.0	200 ~	2.0	0.5	
AD1F3P		80	60	10	1.0	750	150	2.2	10	300 ~	2.0	0.5	
AD1L3N		80	60	10	1.0	750	150	4.7	10	300 ~	2.0	0.5	
AD1A4M		80	60	10	1.0	750	150	10	10	300 ~	2.0	0.5	
AD1L2Q		80	60	10	1.0	750	150	0.47	4.7	300 ~	2.0	0.5	
AD1F2Q		80	60	10	1.0	750	150	0.22	2.2	300 ~	2.0	0.5	
AD1A4A		80	60	10	1.0	750	150	—	10	300 ~	2.0	0.5	
AD2A3M	Refer to equivalent circuit [C]	60 ±10	60 ±10	10	1.0	750	150	1.0	1.0	200 ~	2.0	0.5	
AD2F3P		60 ±10	60 ±10	10	1.0	750	150	2.2	10	300 ~	2.0	0.5	
AD2L3N		60 ±10	60 ±10	10	1.0	750	150	4.7	10	300 ~	2.0	0.5	
AD2A4M		60 ±10	60 ±10	10	1.0	750	150	10	10	300 ~	2.0	0.5	
AD2L2Q		60 ±10	60 ±10	10	1.0	750	150	0.47	4.7	300 ~	2.0	0.5	
AD2F2Q		60 ±10	60 ±10	10	1.0	750	150	0.22	2.2	300 ~	2.0	0.5	
AD2A4A		60 ±10	60 ±10	10	1.0	750	150	—	10	300 ~	2.0	0.5	
AR1A3M	Refer to equivalent circuit [B]	−60	−60	−10	−1.0	750	150	1.0	1.0	100 ~	−2.0	−0.5	
AR1F3P		−60	−60	−10	−1.0	750	150	2.2	10	100 ~	−2.0	−0.5	
AR1L3N		−60	−60	−10	−1.0	750	150	4.7	10	100 ~	−2.0	−0.5	
AR1A4M		−60	−60	−10	−1.0	750	150	10	10	100 ~	−2.0	−0.5	
AR1L2Q		−60	−60	−10	−1.0	750	150	0.47	4.7	100 ~	−2.0	−0.5	
AR1F2Q		−60	−60	−10	−1.0	750	150	0.22	2.2	100 ~	−2.0	−0.5	
AR1A4A		−60	−60	−10	−1.0	750	150	—	10	100 ~	−2.0	−0.5	

■ CE1[], CE2[] series (SP-8)

Part number	Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)						Electrical characteristics (T _A = 25 °C)					
		V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _C (A)	P _T (W)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	
SP-8													
CE1A3Q	Refer to [D]	60 ±10	60 ±10	15	±2.0	1.0	150	1.0	10	1000 to 3000	5.0	1.0	
CE1F3P		60 ±10	60 ±10	15	±2.0	1.0	150	2.2	10	1000 to 3000	5.0	1.0	
CE1N2R		60 ±10	60 ±10	15	±2.0	1.0	150	0.68	10	1000 to 3000	5.0	1.0	
CE2A3Q	Refer to [E]	60	60	15	±2.0	1.0	150	1.0	10	1000 to 3000	5.0	1.0	
CE2F3P		60	60	15	±2.0	1.0	150	1.0	10	1000 to 3000	5.0	1.0	

Transistor with Internal Resistor

■ FA1[], FN1[], GA1[], GN1[] series (SC-59, SC-70)

Part number		Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)					Electrical characteristics (T _A = 25 °C)						Remarks
			V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _C (mA)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (mA)	
SC-59	SC-70													
FA1A4M	GA1A4M	Refer to equivalent circuit [A]	60	50	10	100	200 (SC-59)	150	10	10	35 to 100	5.0	5.0	
FA1A4P	GA1A4P		60	50	5	100		150	10	47	35 to 340	5.0	5.0	
FA1F4M	GA1F4M		60	50	10	100		150	22	22	60 to 195	5.0	5.0	
FA1F4N	GA1F4N		60	50	5	100		150	22	47	85 to 340	5.0	5.0	
FA1L4M	GA1L4M		60	50	10	100		150	47	47	85 to 340	5.0	5.0	
FA1L4L	GA1L4L		60	50	15	100		150	47	22	60 to 195	5.0	5.0	
FA1L3Z	GA1L3Z		60	50	5	100		150	4.7	—	135 to 600	5.0	5.0	
FA1A4Z	GA1A4Z		60	50	5	100		150	10	—	135 to 600	5.0	5.0	
FA1F4Z	GA1F4Z	Switching	60	50	5	100	150 (SC-70)	150	22	—	135 to 600	5.0	5.0	
FA1L4Z	GA1L4Z		60	50	5	100		150	47	—	135 to 600	5.0	5.0	
FA1L3M	GA1L3M		60	50	10	100		150	4.7	4.7	20 to 80	5.0	5.0	
FA1L3N	GA1L3N		60	50	5	100		150	4.7	10	35 to 100	5.0	5.0	
FA1A3Q	GA1A3Q		60	50	5	100		150	1.0	10	35 to 100	5.0	5.0	
FN1A4M	GN1A4M	Refer to equivalent circuit [B]	−60	−50	−10	−100	200 (SC-59)	150	10	10	35 to 100	−5.0	−5.0	
FN1A4P	GN1A4P		−60	−50	−5	−100		150	10	47	85 to 340	−5.0	−5.0	
FN1F4M	GN1F4M		−60	−50	−10	−100		150	22	22	60 to 195	−5.0	−5.0	
FN1F4N	GN1F4N		−60	−50	−5	−100		150	22	47	85 to 340	−5.0	−5.0	
FN1L4M	GN1L4M		−60	−50	−10	−100		150	47	47	85 to 340	−5.0	−5.0	
FN1L4L	GN1L4L		−60	−50	−15	−100		150	47	22	60 to 195	−5.0	−5.0	
FN1L3Z	GN1L3Z		−60	−50	−5	−100		150	4.7	—	135 to 600	−5.0	−5.0	
FN1A4Z	GN1A4Z		−60	−50	−5	−100		150	10	—	135 to 600	−5.0	−5.0	
FN1F4Z	GN1F4Z	Switching	−60	−50	−5	−100	150 (SC-70)	150	22	—	135 to 600	−5.0	−5.0	
FN1L4Z	GN1L4Z		−60	−50	−5	−100		150	47	—	135 to 600	−5.0	−5.0	
FN1L3M	GN1L3M		−60	−50	−10	−100		150	4.7	4.7	20 to 80	−5.0	−5.0	
FN1L3N	GN1L3N		−60	−50	−5	−100		150	4.7	10	35 to 100	−5.0	−5.0	
FN1A3Q	GN1A3Q		−60	−50	−5	−100		150	1.0	10	35 to 100	−5.0	−5.0	

■ FB1[] series (SC-59)

Part number		Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)					Electrical characteristics (T _A = 25 °C)						Remarks
			V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _C (A)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	
FB1A4A		Refer to equivalent circuit [A]	30	25	10	0.7	200	150	—	10	300	2.0	0.5	
FB1L2Q			30	25	10	0.7		150	0.47	4.7	300	2.0	0.5	
FB1A3M			30	25	10	0.7		150	1.0	1.0	100	2.0	0.5	
FB1F3P			30	25	10	0.7		150	2.2	10	300	2.0	0.5	
FB1J3P			30	25	10	0.7		150	3.3	10	300	2.0	0.5	
FB1L3N		Switching	30	25	10	0.7	200	150	4.7	10	300	2.0	0.5	
FB1A4M			30	25	10	0.7		150	10	10	300	2.0	0.5	
FP1A4A			−25	−25	−10	−0.7		150	—	10	100	−2.0	−0.5	
FP1L2Q		Refer to equivalent circuit [B]	−25	−25	−10	−0.7	200	150	0.47	4.7	100	−2.0	−0.5	
FP1A3M			−25	−25	−10	−0.7		150	1.0	1.0	100	−2.0	−0.5	
FP1F3P			−25	−25	−10	−0.7		150	2.2	10	100	−2.0	−0.5	
FP1J3P			−25	−25	−10	−0.7		150	3.3	10	100	−2.0	−0.5	
FP1L3N			−25	−25	−10	−0.7		150	4.7	10	100	−2.0	−0.5	
FP1A4M		Switching	−25	−25	−10	−0.7		150	10	10	100	−2.0	−0.5	

Transistor with Internal Resistor

■ HD1[], HD2[], HR1[] series (SOT-89)

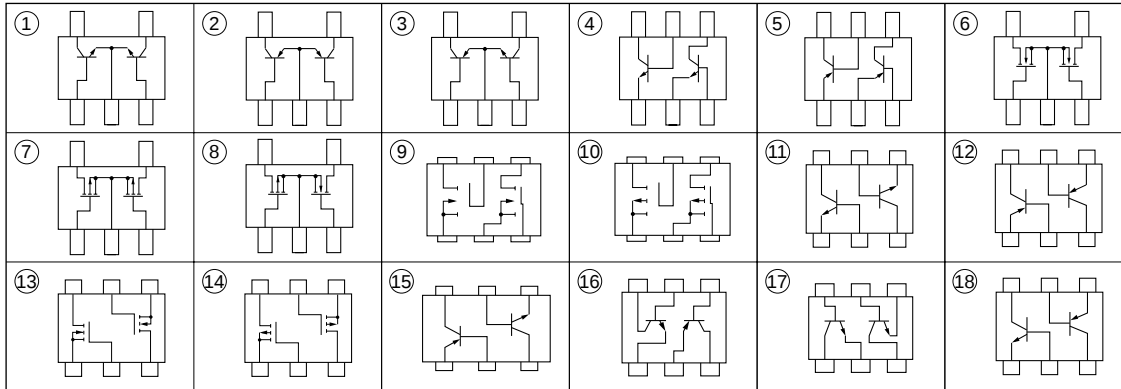
Part number	Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)						Electrical characteristics (T _A = 25 °C)					
		V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _C (A)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	Remarks
HD1A3M	Refer to equivalent circuit [A]	80	60	10	1.0	2.0	150	1.0	1.0	200	2.0	0.5	
HD1F3P		80	60	10	1.0		150	2.2	10	300	2.0	0.5	
HD1L3N		80	60	10	1.0		150	4.7	10	300	2.0	0.5	
HD1A4M		80	60	10	1.0		150	10	10	300	2.0	0.5	
HD1L2Q	Switching	80	60	10	1.0		150	0.47	4.7	300	2.0	0.5	
HD1F2Q		80	60	10	1.0		150	0.22	2.2	300	2.0	5.0	
HD1A4A		80	60	10	1.0		150	—	10	300	2.0	0.5	
HD2A3M	Refer to equivalent circuit [C]	60±10	60±10	10	1.0	2.0	150	1.0	1.0	200	2.0	0.5	
HD2F3P		60±10	60±10	10	1.0		150	2.2	10	300	2.0	0.5	
HD2L3N		60±10	60±10	10	1.0		150	4.7	10	300	2.0	0.5	
HD2A4M		60±10	60±10	10	1.0		150	10	10	300	2.0	0.5	
HD2L2Q	Switching	60±10	60±10	10	1.0		150	0.47	4.7	300	2.0	0.5	
HD2F2Q		60±10	60±10	10	1.0		150	0.2	2.2	300	2.0	0.5	
HD2A4A		60±10	60±10	10	1.0		150	—	10	300	2.0	0.5	
HR1A3M	Refer to equivalent circuit [B]	−60	−60	−10	−1.0	2.0	150	1.0	1.0	100	−2.0	−0.5	
HR1F3P		−60	−60	−10	−1.0		150	2.2	10	100	−2.0	−0.5	
HR1L3N		−60	−60	−10	−1.0		150	4.7	10	100	−2.0	−0.5	
HR1A4M		−60	−60	−10	−1.0		150	10	10	100	−2.0	−0.5	
HR1L2Q	Switching	−60	−60	−10	−1.0		150	0.47	4.7	100	−2.0	−0.5	
HR1F2Q		−60	−60	−10	−1.0		150	0.22	2.2	100	−2.0	−0.5	
HR1A4A		−60	−60	−10	−1.0		150	—	10	100	−2.0	−0.5	

■ HQ1[] series (SOT-89)

Part number	Equivalent circuit and applications	Absolute maximum ratings (T _A = 25 °C)						Electrical characteristics (T _A = 25 °C)					
		V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _C (A)	P _T (mW)	T _J (°C)	R ₁ (kΩ)	R ₂ (kΩ)	h _{FE}	V _{CE} (V)	I _C (A)	Remarks
HQ1A4A	Refer to equivalent circuit [B]	−20	−20	−10	−2.0	2.0	150	—	10	150	−2.0	−1.0	
HQ1F2Q		−20	−20	−10	−2.0		150	0.22	2.2	150	−2.0	−1.0	
HQ1L2N		−20	−20	−10	−2.0		150	0.47	1.0	150	−2.0	−1.0	
HQ1L2Q		−20	−20	−20	−10		150	0.47	4.7	150	−2.0	−1.0	
HQ1A3M	Switching	−20	−20	−10	−2.0		150	1.0	1.0	150	−2.0	−1.0	
HQ1F3M		−20	−20	−10	−2.0		150	2.2	2.2	150	−2.0	−1.0	
HQ1F3P		−20	−20	−10	−2.0		150	4.7	10	150	−2.0	−1.0	

Transistor for Array

Equivalent Circuit



■ Bipolar Transistor

Part number	Equivalent circuit	V _{CEO} (V)	I _{C(DC)} (mA)	P _T * (mW)	h _{FE}			Package
						V _{CE} (V)	I _C (mA)	
μPA570T	①	50	100	200	90 to 600	6	1	• 5-pin Super Mini-Mold SC-88A
μPA571T	②	−50	−100	200		−6	−1	
μPA574T	③	50/−50	100/−100	300		6/−6	1/−1	
μPA670T	⑪	50	100	200		6	1	• 6-pin Super Mini-Mold SC-88
μPA671T	⑫	−50	−100	200		−6	−1	
μPA500T	①	50	100	300		6	1	• 5-pin Mini-Mold SC-74A
μPA501T	②	−50	−100	300		−6	−1	
μPA504T	③	50/−50	100/−100	300		6/−6	1/−1	
μPA600T	④	50	100	300		6	1	• 6-pin Mini-Mold SC-74
μPA601T	⑤	−50	−100	300		−6	−1	
μPA604T	⑪	50	100	300		6	1	
μPA605T	⑫	−50	−100	300		−6	−1	
μPA608T	⑮	50 −16	100 −500	300	90 to 600 110 to 400	6 −1	1 −100	
μPA609T	⑮	40 −40	500 −500	300	75 to 300 75 to 300	1 −1	150 −150	• 6-pin Super Mini-Mold SC-88
μPA673T	⑰	15	200	200	82 to 180	6	1	
μPA674T	⑱	15 −15	200 −50	200	40 to 200 50 to 150	1 −1	10 −10	

*: Total

■ MOS FET

Part number	Equivalent circuit	V _{DSS} (V)	I _D (DC) (mA)	P _T * (mW)	R _{DS} (on) (Ω) MAX			Package
						V _{GS} (V)	I _D (mA)	
μPA572T	⑥	30	100	200	13	2.5	10	• 5-pin Super Mini-Mold SC-88A
μPA573T	⑦	−30	−100	200	60	−2.5	−10	
μPA502T	⑥	50	100	300	30	4	10	
μPA503T	⑦	−50	−100	300	100	−4	−10	• 5-pin Mini-Mold SC-74A
μPA505T	⑧	50/−50	100/−100	300	30/100	4/−4	10/−10	
μPA602T	⑨	50	100	300	30	4	10	• 6-pin Mini-Mold SC-74
μPA603T	⑩	−50	−100	300	100	−4	−10	
μPA606T	⑬	50	100	300	30	4	10	
μPA607T	⑭	−50	−100	300	100	−4	−10	
μPA610TA	⑩	−30	−100	300	60	−2.5	−1	
μPA611TA	⑨	30	100	300	15	2.5	1	
μPA672T	⑬	50	100	200	40	2.5	10	• 6-pin Super Mini-Mold SC-88

*: Total

Transistor Array

■ Signal transistor array Product Map (Monolithic)

I_o (mA) V_o (V)	500
50	μ PA2981 μ PA2982 μ PA2987
60	μ PA2001 μ PA2002 μ PA2003 μ PA2004

■ Signal transistor array (Monolithic)

Part number	Number of circuits				Output voltage V_o (V)	Output current I_o (mA/Unit)	Surge absorber diode	Input impedance	Active level		Input/output relationship		Output current relationship		Remarks	Number of pins
	5	6	7	8					"H"	"L"	Inverter type	Non-inverter type	Source type	Sink type		
μ PA80C, GR				○	60	50	—	20 k Ω		○	○		○		Darlington	16
μ PA81C				○	45	400*2	—	20 k Ω	○		○			○	FIP driver	18
μ PA2001C, GR				○	60	500	○	—	○		○			○	Darlington	16
μ PA2002C, GR				○	60	500	○	7VZDi +10.5 k Ω	○		○			○	Darlington	16
μ PA2003C, GR				○	60	500	○	2.7 k Ω	○		○			○	Darlington	16
μ PA2004C, GR				○	60	500	○	10.5 k Ω	○		○			○	Darlington	16
μ PA2981C				○	50	500	○	3 k Ω	○			○	○		Darlington output stage	18
μ PA2982C				○	50	500	○	8.5 k Ω	○			○	○		Darlington output stage	18
μ PA2987C				○	50	500	○	3 k Ω	○			○	○		Darlington output stage	16

*1: PW $\leq$ 30 ms, duty cycle $\leq$ 10% (7 circuits operation)

*2: PW $\leq$ 10 ms, duty cycle $\leq$ 10% (7 circuits operation)

■ Power transistor array Product Map (Multi-chip, 4 circuits)

V _{CEO} (V)	I _C (DC) (A)	2.0	3.0	5.0
	Polarity			
30	NPN	μPA1478H ○		
	PNP			
60	NPN	μPA1428AH ○	μPA1434H ●	μPA1458H ○
	PNP			μPA1453H ☆
100	NPN	μPA1476H ○	μPA1436AH	μPA1454H ● μPA1456H
	PNP		μPA1437H	

○ : with Zenner Diode ☆ : Low $V_{CE(sat)}$ ● : Single High h_{FE}

■ Power transistor array (Multi-chip, 4 circuits)

Part number	Number of circuits	Collector-emitter voltage V_{CE} (V)	Collector current I_C (A)	Surge absorber diode	Input impedance	Output current relationship		Remarks	Number of pins
						Source type	Sink type		
μ PA1428AH	4	60 $\pm$ 10	$\pm$ 2.0	○	—		○	Darlington	10
μ PA1434H	4	60	3.0	—	—		○	High beta	10
μ PA1436AH	4	100	$\pm$ 3.0	—	—		○	Darlington	10
μ PA1437H	4	—100	$\mp$ 3.0	—	—	○		Darlington	10
μ PA1453H	4	—60	5.0	—	—	○		Low $V_{CE(sat)}$	10
μ PA1454H	4	100	5.0	—	—		○	High beta	10
μ PA1456H	4	100	$\pm$ 5.0	—	—		○	Darlington	10
μ PA1458H	4	60 $\pm$ 10	$\pm$ 5.0	○	—		○	Darlington	10
μ PA1476H	4	100 $\pm$ 15	$\pm$ 2.0	○	—		○	Darlington	10
μ PA1478H	4	31 $\pm$ 4	$\pm$ 2.0	○	—		○	Darlington	10

Transistor Array

■ Power MOS FET array Product Map (Multi-chip, 4 circuits)

I_D (DC) (A) V_{DSS} (V)	2.0	3.0	5.0
30	• μ PA1520BH (0.25)		• μ PA1550H (0.15)
60	• μ PA1522H (0.35) • μ PA1572BH (0.8) • μ PA1523BH (1.3)	• μ PA1500BH (0.24)	• μ PA1552BH (0.24)
80	• μ PA1524H (1.0)		
100	• μ PA1526H (0.6) • μ PA1576H (1.5) • μ PA1527H (1.5)		• μ PA1556AH (0.33)
120		• μ PA1501H (0.53) • μ PA1560H (0.165)	

(): $R_{DS(on)}$ (@ $V_{GS} = 4$ V) [Ω MAX.] Underlined: P-channel

■ Power MOS FET array (Multi-chip, 4 circuits)

Part number	Number of circuits			V_{DSS} (V)	I_D (A/Unit)	Surge absorber diode	4 V driving	Active level		Input/output relationship		Output current relationship		Number of pins
	4	7	8					"H"	"L"	Inverter type	Non-inverter type	Source type	Sink type	
μ PA1500BH	○			60	± 3	○	○	○		○			○	12
μ PA1501H	○			120	± 3	○	○	○		○			○	12
μ PA1520BH	○			30	± 2	—	○	○		○			○	10
μ PA1522H	○			60	± 2	—	○	○		○			○	10
μ PA1523BH	○			—60	∓ 2	—	○		○		○	○		10
μ PA1524H	○			80	± 2	—	○	○		○			○	10
μ PA1526H	○			100	± 2	—	○	○		○			○	10
μ PA1527H	○			—100	∓ 2	—	○		○		○	○		10
μ PA1550H	○			30	± 5	—	○	○		○			○	10
μ PA1552BH	○			60	± 5	—	○	○		○			○	10
μ PA1556AH	○			100	± 5	—	○	○		○			○	10
μ PA1572BH	○			60	± 2	—	○	○		○			○	10
μ PA1576H	○			100	± 2	—	○	○		○			○	10
μ PA1560H	○			120	± 3		○	○		○			○	10

■ Power MOS FET array Product Map (Monolithic)

I_D (DC) (A) V_{DSS} (V)	0.43	0.5	0.87
30	• μ PA1601 (5.3 Ω , 7CH) (DIP, SOP) • μ PA1602 (5.3 Ω , 7CH) (DIP, SOP)	• μ PA1600 (4.0 Ω , 8CH) (DIP, SOP)	• μ PA1603 (1.3 Ω , 4CH) (DIP, SOP)

■ Power MOS FET array (Monolithic)

Part number	Number of circuits			V_{DSS} (V)	I_D (A/Unit)	Surge absorber diode	4 V driving	Active level		Input/output relationship		Output current relationship		Number of pins
	4	7	8					"H"	"L"	Inverter type	Non-inverter type	Source type	Sink type	
μ PA1600CX/GS			○	30	0.5	—	○	○		○			○	20
μ PA1601CX/GS		○		30	0.43	—	○	○		○			○	16
μ PA1602CX/GS		○		30	0.43	—	○		○		○		○	16
μ PA1603CX	○			30	0.87	○	○	○		○			○	16
μ PA1604CX	○			30	0.87	○	○		○		○		○	16

Zener Diode

■ Zener Diode Quick Reference (1/2) (Surface-Mount Type)

Vz (V)	P (W)							
TYP.	0.15		0.2				1.0	
2.0		RD2.0UM	RD2.0M	RD2.0MW	RD2.0S		RD2.0P	RD2.0FM
2.2		RD2.2UM	RD2.2M	RD2.2MW	RD2.2S		RD2.2P	RD2.2FM
2.4		RD2.4UM	RD2.4M	RD2.4MW	RD2.4S		RD2.4P	RD2.4FM
2.7		RD2.7UM	RD2.7M	RD2.7MW	RD2.7S		RD2.7P	RD2.7FM
3.0		RD3.0UM	RD3.0M	RD3.0MW	RD3.0S		RD3.0P	RD3.0FM
3.3		RD3.3UM	RD3.3M	RD3.3MW	RD3.3S		RD3.3P	RD3.3FM
3.6		RD3.6UM	RD3.6M	RD3.6MW	RD3.6S		RD3.6P	RD3.9FM
3.9		RD3.9UM	RD3.9M	RD3.9MW	RD3.9S		RD3.9P	RD4.3FM
4.3		RD4.3UM	RD4.3M	RD4.3MW	RD4.3S		RD4.3P	RD4.7FM
4.7	RD4.7UJ	RD4.7UM	RD4.7M	RD4.7MW	RD4.7S	RD4.7SL	RD4.7P	RD4.7FM
5.1	RD5.1UJ	RD5.1UM	RD5.1M	RD5.1MW	RD5.1S	RD5.1SL	RD5.1P	RD5.1FM
5.6	RD5.6UJ	RD5.6UM	RD5.6M	RD5.6MW	RD5.6S	RD5.6SL	RD5.6P	RD5.6FM
6.2	RD6.2UJ	RD6.2UM	RD6.2M	RD6.2MW	RD6.2S	RD6.2SL	RD6.2P	RD6.2FM
6.8	RD6.8UJ	RD6.8UM	RD6.8M	RD6.8MW	RD6.8S	RD6.8SL	RD6.8P	RD6.8FM
7.5	RD7.5UJ	RD7.5UM	RD7.5M	RD7.5MW	RD7.5S	RD7.5SL	RD7.5P	RD7.5FM
8.2	RD8.2UJ	RD8.2UM	RD8.2M	RD8.2MW	RD8.2S	RD8.2SL	RD8.2P	RD8.2FM
9.1	RD9.1UJ	RD9.1UM	RD9.1M	RD9.1MW	RD9.1S	RD9.1SL	RD9.1P	RD9.1FM
10	RD10UJ	RD10UM	RD10M	RD10MW	RD10S	RD10SL	RD10P	RD10FM
11	RD11UJ	RD11UM	RD11M	RD11MW	RD11S	RD11SL	RD11P	RD11FM
12	RD12UJ	RD12UM	RD12M	RD12MW	RD12S	RD12SL	RD12P	RD12FM
13	RD13UJ	RD13UM	RD13M	RD13MW	RD13S	RD13SL	RD13P	RD13FM
15	RD15UJ	RD15UM	RD15M	RD15MW	RD15S	RD15SL	RD15P	RD15FM
16	RD16UJ	RD16UM	RD16M	RD16MW	RD16S	RD16SL	RD16P	RD16FM
18	RD18UJ	RD18UM	RD18M	RD18MW	RD18S	RD18SL	RD18P	RD18FM
20	RD20UJ	RD20UM	RD20M	RD20MW	RD20S	RD20SL	RD20P	RD20FM
22	RD22UJ	RD22UM	RD22M	RD22MW	RD22S	RD22SL	RD22P	RD22FM
24	RD24UJ	RD24UM	RD24M	RD24MW	RD24S	RD24SL	RD24P	RD24FM
27	RD27UJ	RD27UM	RD27M	RD27MW	RD27S	RD27SL	RD27P	RD27FM
30	RD30UJ	RD30UM	RD30M	RD30MW	RD30S	RD30SL	RD30P	RD30FM
33	RD33UJ	RD33UM	RD33M	RD33MW	RD33S	RD33SL	RD33P	RD33FM
36	RD36UJ	RD36UM	RD36M	RD36MW	RD36S	RD36SL	RD36P	RD36FM
39	RD39UJ	RD39UM	RD39M	RD39MW	RD39S	RD39SL	RD39P	RD39FM
43			RD43M		RD43S		RD43P	RD43FM
47			RD47M		RD47S		RD47P	RD47FM
51					RD51S		RD51P	RD51FM
56					RD56S		RD56P	RD56FM
62					RD62S		RD62P	RD62FM
68					RD68S		RD68P	RD68FM
75					RD75S		RD75P	RD75FM
82					RD82S		RD82P	RD82FM
91					RD91S		RD91P	RD91FM
100					RD100S		RD100P	RD100FM
110					RD110S		RD110P	RD110FM
120					RD120S		RD120P	RD120FM
Package	2-pin ultra mini-mold		Mini-mold (SC-59)		2-pin super mini-mold		Power mini-mold (SC-62)	2-pin power mini-mold
	Low noise	General Purpose			General Purpose	Low noise		

Zener Diode

■ Zener Diode Quick Reference (2/2) (Through-Hole Type)

V _Z (V)	P (W)			
TYP.	0.4	0.4	0.5	1.0
2.0		RD2.0ES	RD2.0E	RD2.0F
2.2		RD2.2ES	RD2.2E	RD2.2F
2.4		RD2.4ES	RD2.4E	RD2.4F
2.7		RD2.7ES	RD2.7E	RD2.7F
3.0		RD3.0ES	RD3.0E	RD3.0F
3.3		RD3.3ES	RD3.3E	RD3.3F
3.6		RD3.6ES	RD3.6E	RD3.6F
3.9		RD3.9ES	RD3.9E	RD3.9F
4.3		RD4.3ES	RD4.3E	RD4.3F
4.7	RD4.7JS	RD4.7ES	RD4.7E	RD4.7F
5.1	RD5.1JS	RD5.1ES	RD5.1E	RD5.1F
5.6	RD5.6JS	RD5.6ES	RD5.6E	RD5.6F
6.2	RD6.2JS	RD6.2ES	RD6.2E	RD6.2F
6.8	RD6.8JS	RD6.8ES	RD6.8E	RD6.8F
7.5	RD7.5JS	RD7.5ES	RD7.5E	RD7.5F
8.2	RD8.2JS	RD8.2ES	RD8.2E	RD8.2F
9.1	RD9.1JS	RD9.1ES	RD9.1E	RD9.1F
10	RD10JS	RD10ES	RD10E	RD10F
11	RD11JS	RD11ES	RD11E	RD11F
12	RD12JS	RD12ES	RD12E	RD12F
13	RD13JS	RD13ES	RD13E	RD13F
15	RD15JS	RD15ES	RD15E	RD15F
16	RD16JS	RD16ES	RD16E	RD16F
18	RD18JS	RD18ES	RD18E	RD18F
20	RD20JS	RD20ES	RD20E	RD20F
22	RD22JS	RD22ES	RD22E	RD22F
24	RD24JS	RD24ES	RD24E	RD24F
27	RD27JS	RD27ES	RD27E	RD27F
30	RD30JS	RD30ES	RD30E	RD30F
33	RD33JS	RD33ES	RD33E	RD33F
36	RD36JS	RD36ES	RD36E	RD36F
39	RD39JS	RD39ES	RD39E	RD39F
43			RD43E	RD43F
47			RD47E	RD47F
51			RD51E	RD51F
56			RD56E	RD56F
62			RD62E	RD62F
68			RD68E	RD68F
75			RD75E	RD75F
82			RD82E	RD82F
91			RD91E	
100			RD100E	
110			RD110E	
120			RD120E	
Package	DO-34	DO-34	DO-35	DO-41

Noise Clipping Diode

■ Surface-Mount Type Quick Reference

V _{BR} (V)	P (W)					Application
TYP.	0.15	0.2				
3.3	NNCD3.3C	NNCD3.3D	NNCD3.3E	NNCD3.3F	NNCD3.3G	• E.S.D. absorber • Surge absorber
3.6	NNCD3.6C	NNCD3.6D	NNCD3.6E	NNCD3.6F	NNCD3.6G	
3.9	NNCD3.9C	NNCD3.9D	NNCD3.9E	NNCD3.9F	NNCD3.9G	
4.3	NNCD4.3C	NNCD4.3D	NNCD4.3E	NNCD4.3F	NNCD4.3G	
4.7	NNCD4.7C	NNCD4.7D	NNCD4.7E	NNCD4.7F	NNCD4.7G	
5.1	NNCD5.1C	NNCD5.1D	NNCD5.1E	NNCD5.1F	NNCD5.1G	
5.6	NNCD5.6C	NNCD5.6D	NNCD5.6E	NNCD5.6F	NNCD5.6G	
6.2	NNCD6.2C	NNCD6.2D	NNCD6.2E	NNCD6.2F	NNCD6.2G	
6.8	NNCD6.8C	NNCD6.8D	NNCD6.8E	NNCD6.8F	NNCD6.8G	
7.5	NNCD7.5C	NNCD7.5D	NNCD7.5E	NNCD7.5F	NNCD7.5G	
8.2	NNCD8.2C	NNCD8.2D	NNCD8.2E	NNCD8.2F		
9.1	NNCD9.1C	NNCD9.1D	NNCD9.1E	NNCD9.1F		
10	NNCD10C	NNCD10D	NNCD10E	NNCD10F		
11	NNCD11C	NNCD11D	NNCD11E	NNCD11F		
12	NNCD12C	NNCD12D	NNCD12E	NNCD12F		
27					NNCD27G	
Package	2-pin ultra mini-mold	2-pin super mini-mold	3-pin mini-mold (SC-59)		5-pin mini-mold (SC-74A quarto)	
			Single	Twin		

■ Surface-Mount Type (Low Capacitance) Quick Reference

V _{BR} (V)	P (W)		Application
TYP.	0.2		
5.6	NNCD5.6LG	NNCD5.6LH	• E.S.D. absorber
6.2	NNCD6.2LG	NNCD6.2LH	
6.8	NNCD6.8LG	NNCD6.8LH	
Package	5-pin mini-mold (SC-74A quad)	5-pin super mini-mold (SC-88A quad)	

■ Surface-Mount Type (Low Capacitance and High ESD Endurance Type) Quick Reference

V _{BR} (V)	P (W)		Application
TYP.	0.2		
5.6		NNCD5.6MG	• E.S.D. absorber
6.2	NNCD6.2MF	NNCD6.2MG	
6.8		NNCD6.8MG	
Package	3-pin mini-mold (SC-59 twin)	5-pin mini-mold (SC-74A quad)	

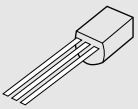
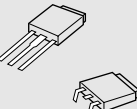
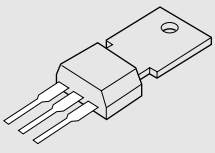
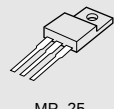
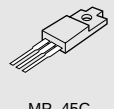
Noise Clipping Diode

■ Through Hole Type Quick Reference

V _{BR} (V)	P (W)		Application
TYP.	0.4	0.5	
3.3	NNCD3.3A	NNCD3.3B	• E.S.D. protection • Surge absorber
3.6	NNCD3.6A	NNCD3.6B	
3.9	NNCD3.9A	NNCD3.9B	
4.3	NNCD4.3A	NNCD4.3B	
4.7	NNCD4.7A	NNCD4.7B	
5.1	NNCD5.1A	NNCD5.1B	
5.6	NNCD5.6A	NNCD5.6B	
6.2	NNCD6.2A	NNCD6.2B	
6.8	NNCD6.8A	NNCD6.8B	
7.5	NNCD7.5A	NNCD7.5B	
8.2	NNCD8.2A	NNCD8.2B	
9.1	NNCD9.1A	NNCD9.1B	
10	NNCD10A	NNCD10B	
11	NNCD11A	NNCD11B	
12	NNCD12A	NNCD12B	
Package	DO-34	DO-35	

Thyristor

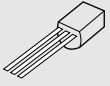
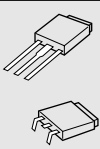
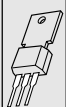
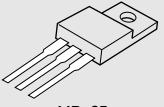
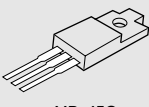
■ SCR

Package																	
	SOT-89	TO-92		MP-3			TO-202AA					TO-220AB		TO-220-like insulated type			
Electrical characteristics																	
$I_{T(RMS)}$ (A)	0.47	0.47		4.7	8	12.6	4	4	4	4.7	4.7	8	12.6	8	12.6		
$I_{T(AV)}$ (A)	0.3	0.3		3	5	8	2	2	2.5	3	3	5	8	5	8		
I_{TSM} (A)	6	8		40	65	80	20	20	45	65	65	80	100	80	100		
T_J (°C)	125	125		125			125					125		125			
V_{DRM} V_{RRM} (V)	200	03P2J	03P2M	—	—	—	—	—	2S2M	—	—	—	—	8P2M	—	8P2SM	
	400	03P4J	03P4M	03P4MF*1	03P4MG	3P4J 3P4J-Z	5P4J 5P4J-Z	8P4J 8P4J-Z	2P4M	2S4M	2V5P4M	3P4MH	3S4M	5P4M	8P4M	5P4SM	8P4SM
	500	03P5J	—	—	03P5MG	—	—	—	2P5M	—	—	3P5MH	—	5P5M	—	—	—
	600	—	—	—	03P6MG	—	5P6J 5P6J-Z	—	2P6M	—	—	3P6MH	—	5P6M	—	5P6SM	—
I_{GT} (mA)	0.2	0.2	100 μ A	3-50 μ A	0.1	0.2	10	0.2	0.3	0.1	0.2	30	10	10	10	10	
t_q (TYP.) (μ s)	25	25	40	60	30	80	50	30	15*2	80	80	5*2	50	100	50	100	

*1: $V_{RRM} = 5$ V

*2: indicates MAX.

■ TRIAC

Package																				
		SOT-89		TO-92		MP-3		TO-202AA		TO-220AB					TO-220AB-like insulated type					
Electrical characteristics		I _{T(RMS)} (A)		1.0	0.8	1.0	3	5	3	5	8	10	12	16	3	5	8	10	12	16
		I _{TSM} (50 Hz) (A)		7.0	7	9	30	50	30	50	80	80	100	150	30	50	80	80	100	150
		T _J (°C)		125	125		125		125	125					125					
V _{DRM} V _{RRM} (V)	400	AC01DJM	AC0V8DGM	AC01DGM	AC03DJM AC03DJM-Z	AC05DJM AC05DJM-Z	AC03DGM	AC05DGM	AC08DGM	AC10DGM	AC12DGM	AC16DGM	AC03DSM	AC05DSM	AC08DSM	AC10DSM	AC12DSM	AC16DSM		
	500	—	—	—	—	—	AC03EGM	AC05EGM	AC08EGM	AC10EGM	AC12EGM	AC16EGM	—	AC05ESM	AC08ESM	AC10ESM	AC12ESM	—		
	600	—	—	—	AC03FJM AC03FJM-Z	AC05FJM AC05FJM-Z	AC03FGM	AC05FGM	AC08FGM	AC10FGM	AC12FGM	AC16FGM	AC03FSM	AC05FSM	AC08FSM	AC10FSM	AC12FSM	AC16FSM		
I _{GT} (mA)	I	5	5	3	12	10	12	10	20	20	20	30	12	10	20	20	20	30		
	II	10	10	5	—	—	—	—	—	—	—	—	—	—	—	—	—	—		
	III	5	5	3	12	10	12	10	20	20	20	30	12	10	20	20	20	30		
	IV	10	10	3	12	10	12	10	20	20	20	30	12	10	20	20	20	30		
(dv/dt) _C (V/μs)		MIN.	0.5	1	0.5	5	5	5	5	10	10	10	10	5	5	10	10	10	10	

[MEMO]

RF and Microwave Devices

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IC

■ AGC AMP. (μ PCxxxx, μ PGxxxx)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC8119T	Mobile Comm.	3	11	100–1920	$G_P(\text{MAX.})=12.5\text{dB}$, $G_{CR}=50\text{dB}$, $P_{O(1\text{dB})}=3\text{dBm@f=950MHz}$	6-pin minimold
μ PC8120T	Mobile Comm.	3	11	100–1920	$G_P(\text{MAX.})=13\text{dB}$, $G_{CR}=50\text{dB}$, $P_{O(1\text{dB})}=3.5\text{dBm@f=950MHz}$	
μ PC8130TA	Mobile Comm.	3	11	800–1500	$G_P(\text{MAX.})=12.5\text{dB}$, $G_{CR}=50\text{dB}$, $P_{O(1\text{dB})}=5\text{dBm@f=950MHz}$	
μ PC8131TA	Mobile Comm.	3	11	800–1500	$G_P(\text{MAX.})=12\text{dB}$, $G_{CR}=45\text{dB}$, $P_{O(1\text{dB})}=5\text{dBm@f=950MHz}$	
μ PG175TA	Mobile Comm.	3	20	925–960	$G_P=30\text{dB}$, $G_{CR}=35\text{dB}$, $P_O=8\text{dBm}$	6-pin minimold
μ PC2723T	BS Tuner, Mobile Comm.	5	15	1100	$G_P=13\text{dB}$, $NF=11\text{dB}$, $P_{O_2}=-2\text{dBm@f=500MHz}$	20-pin SSOP
μ PC3206GR	CATV Tuner, Video Amp.	5	34.5	100 or less	$G_{CR}=50\text{dB}(\text{MIN.})$, $G_P(\text{MAX.})=38.5\text{dB}(\text{@AGC block})$	
μ PC3211GR	CATV Tuner	9	38	5–100	$G_{CR}=55\text{dB}$, $IM_2=44\text{dBc}$, $IM_3=57\text{dBc}$	

■ IQ Modulator/Demodulator (μ PCxxxx)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC8101GR	Mobile Comm. IQ Modulator	3	15	150	$LOL=-49\text{dBc}$, $ImR=37.5\text{dBc}$, $P_O=-11\text{dBm}$	20-pin SSOP
μ PC8104GR	Mobile Comm. IQ Modulator	3	28	900–2000	$LOL=-40\text{dBc}$, $ImR=-40\text{dBc}$, $P_O=-13.5\text{dBm}$	16-pin SSOP
μ PC8105GR	Mobile Comm. IQ Modulator	3	16	400	$LOL=-40\text{dBc}$, $ImR=-40\text{dBc}$, $P_O=-18.5\text{dBm}$	
μ PC8110GR	Mobile Comm. IQ Modulator	3	24	900	$LOL=-35\text{dBc}$, $ImR=-40\text{dBc}$, $P_O=-10\text{dBm}$	20-pin SSOP
μ PC8125GR	Mobile Comm. IQ Modulator	3	36	1800–2000	$LOL=-37\text{dBc}$, $ImR=-35\text{dBc}$, $P_{RFOUT}=-9\text{dBm}$	
μ PC8126GR	Mobile Comm. IQ Modulator	3	35	915–960	$LOL=-35\text{dBc}$, $ImR=-40\text{dBc}$, $P_{RFOUT}=-9\text{dBm}$	
μ PC8126K	Mobile Comm. IQ Modulator	3	35	889–960	$LOL=-35\text{dBc}$, $ImR=-40\text{dBc}$, $P_{RFOUT}=-9\text{dBm}$	28-pin QFN
μ PC8129GR	Mobile Comm. IQ Modulator	3	28	800–1900	$LOL=-40\text{dBc}$, $ImR=-30\text{dBc}$, $P_{RFOUT}=-5\text{dBm}$	20-pin SSOP
μ PC8139GR-7JH	PHS Transceiver	3	32.5	1800–2000	$LOL=-40\text{dBc}$, $ImR=-40\text{dBc}$, $P_{TX-MIXOUT}=-13\text{dBm}$	30-pin TSSOP
μ PC8158K	Mobile Comm. IQ Modulator	3	28	800–1500	$LOL=-40\text{dBc}$, $ImR=-40\text{dBc}$, $P_{RFOUT}=-11.5\text{dBm}$	28-pin QFN
μ PC2766GR/GS	BS Tuner IQ Demodulator	5	60	DC–1000	$\Delta\phi \leq \pm 1.5^\circ$, $\Delta V \leq \pm 0.5\text{dB}$	20-pin SSOP/SOP
μ PC2781GR	BS Tuner IQ Demodulator	5	70	440–520	$\Delta\phi \leq \pm 2^\circ$, $\Delta V \leq \pm 0.5\text{dB}$	20-pin SSOP
μ PC3205GR	BS Tuner IQ Demodulator	5	65	440–520	$\Delta\phi \leq \pm 2^\circ$, $\Delta V \leq \pm 0.5\text{dB}$	

■ Up Converter (μ PCxxxx)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC8100GR	Mobile Comm. Up/Down	3	15	800–900	$CG(\text{UP})=20.5\text{dB}$, $CG(\text{DOWN})=18\text{dB}$	20-pin SSOP
μ PC8106T	Mobile Comm.	3	9	400–2000	$CG=7\text{dB}$, $P_{O(\text{sat})}=-4\text{dBm@f}_{\text{RFOUT}}=1900\text{MHz}$	6-pin minimold
μ PC8106TB	Mobile Comm.	3	9	400–2000	$CG=7\text{dB}$, $P_{O(\text{sat})}=-4\text{dBm@f}_{\text{RFOUT}}=1900\text{MHz}$	6-pin super minimold
μ PC8109T	Mobile Comm.	3	5	400–2000	$CG=5\text{dB}$, $P_{O(\text{sat})}=-7.5\text{dBm@f}_{\text{RFOUT}}=1900\text{MHz}$	6-pin minimold
μ PC8109TB	Mobile Comm.	3	5	400–2000	$CG=4\text{dB}$, $P_{O(\text{sat})}=-7.5\text{dBm@f}_{\text{RFOUT}}=1900\text{MHz}$	6-pin super minimold
μ PC8163TB	Mobile Comm.	3	16.5	800–2000	$CG=9\text{dB}$, $P_{O(\text{sat})}=0.5\text{dBm}$, $OIP_3=9.5\text{dBm@f=830MHz}$	
μ PC2799GR	CATV Tuner	5	60	250–850	$G_{CR}=14.5\text{dB}$, $P_{O(\text{sat})}=6\text{dBm}$ ($@V_{\text{AGC}}=5\text{V}$)	20-pin SSOP

IC

■ Prescaler (μ PBxxxx, μ PGxxxx)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PB1502GR	Mobile Comm. 1.7GHz 64/65, 128/129	3	6.7	500–1700	64/65, 128/129, $V_o=0.8V_{p-p}$	8-pin SOP
μ PB1502GR(1)	Mobile Comm. 2.0GHz 64/65, 128/129	3	6.7	500–2000	64/65, 128/129, $V_o=0.8V_{p-p}$	
μ PB1504GR	Mobile Comm. 1.1GHz 64/65, 128/129	3	2.47@64/65 2.24@128/129	500–1100	64/65, 128/129, $V_o=0.9V_{p-p}$	
μ PB1509GV	Mobile Comm. 1GHz, +2, +4, +8	3	5	500–1000@1/8	1/2, 1/4, 1/8 $V_o=0.3V_{p-p}$	8-pin SSOP
μ PB1505GR	BS Tuner 3GHz, +64, +128, +256	5	14	500–3000	1/256, 1/128, 1/64, $V_o=1.6V_{p-p}$	8-pin SOP
μ PB1506GV	BS Tuner 3GHz, +64, +128, +256	5	19	500–3000	1/256, 1/128, 1/64, $V_o=1.6V_{p-p}$	8-pin SSOP
μ PB1507GV	BS Tuner 3GHz, +64, +128, +256	5	19	500–3000	1/256, 1/128, 1/64, $V_o=1.6V_{p-p}$	
μ PB1508GV	BS Tuner 3GHz, +2	5	12	500–3000	1/2, $P_o=-7dBm$	
μ PB1510GV	BS Tuner 3GHz, +4	5	14	500–3000	1/4, $P_o=-7dBm$	
μ PG501B	Microwave Comm. 5GHz, +4	10	70	1300–5000	1/4 Static, $P_{in}=10dBm$, $P_o=2dBm$	K-12, 8-pin ceramic
μ PG502B	Microwave Comm. 5GHz, +2	10	100	1000–5000	1/2 Static, $P_{in}=10dBm$, $P_o=2dBm$	
μ PG503B	Microwave Comm. 9GHz, +4	3.8, –2.2	80	4000–8000	1/2 Dynamic, $P_{in}=10dBm$, $P_o=2dBm$	
μ PG504B	Microwave Comm. 9GHz, +2	3.8, –2.2	55	2500–8000	1/2 Dynamic, $P_{in}=10dBm$, $P_o=-1dBm$	
μ PG506B	Microwave Comm. 14GHz, +8	3.8, –2.2	105	8200–13200	1/8 Dynamic, $P_{in}=6dBm$, $P_o=1dBm$	
μ PG508B	Microwave Comm. 13GHz, +4	3.8, –2.2	100	8500–12200	1/4 Dynamic, $P_{in}=6dBm$, $P_o=1dBm$	

IC

■ Down Converter (μ PCxxxx) (1/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC2721GR/GV	General Purpose L-Band	5	38	900–2000	$G_P=21\text{dB}$, $N_F=9\text{--}11\text{dB}$, Emitter follower Output	8-pin SOP/SSOP
μ PC2722GR/GV	General Purpose L-Band	5	28	900–2000	$G_P=18\text{dB}$, $N_F=9\text{--}11\text{dB}$, Open Collector Output	
μ PC2795GV	General Purpose L-Band	5	35	950–2150	$CG=11\text{dB}$, $N_F=13.5\text{dB}@f=950\text{MHz}$	8-pin SSOP
μ PC1694GR	General Purpose 1GHz	5	40	55–1000	$CG=18\text{dB}$, $N_F=12.5\text{--}13.5\text{dB}$, $P_{O(\text{sat})}=10\text{dBm}$	14-pin SOP
μ PC2757T	Mobile Comm.	3	5.6	100–2000	$CG=15\text{dB}$, $N_F=10\text{dB}@f=800\text{MHz}$	6-pin minimold
μ PC2757TB	Mobile Comm.	3	5.6	100–2000	$CG=15\text{dB}$, $N_F=10\text{dB}@f=800\text{MHz}$	6-pin super minimold
μ PC2758T	Mobile Comm.	3	11	100–2000	$CG=19\text{dB}$, $N_F=9\text{dB}@f=800\text{MHz}$	6-pin minimold
μ PC2758TB	Mobile Comm.	3	11	100–2000	$CG=19\text{dB}$, $N_F=9\text{dB}@f=800\text{MHz}$	6-pin super minimold
μ PC8001	Mobile Comm.	3	2.1	470	$f_{\text{out}}=455\text{kHz}$, $RSS_{\text{out}}=0.79\text{--}2.75\text{V}$	14-pin SSOP
μ PC8002	Mobile Comm.	3	1.7	250	$f_{\text{out}}=10.7\text{MHz}$, $RSS_{\text{out}}=1.08\text{--}2.68\text{V}$	20-pin SSOP
μ PC8112T	Mobile Comm.	3	8.5	800–2000	$CG=13\text{dB}$, $N_F=11.2\text{dB}@f_{\text{RFIn}}=1900\text{MHz}$	6-pin minimold
μ PC8112TB	Mobile Comm.	3	8.5	800–2000	$CG=13\text{dB}$, $P_{O(\text{sat})}=3\text{dBm}@f_{\text{RFIn}}=1900\text{MHz}$	6-pin super minimold
μ PC8100GR	Mobile Comm. Up/Down	3	15	800–900	$CG(\text{UP})=20.5\text{dB}$, $CG(\text{DOWN})=18\text{dB}$	20-pin SSOP
μ PC2743GS	TV/VCR Tuner UHF/VHF	9	47@VHF 49@UHF	55–890	$CG=20/23\text{dB}$, $N_F=13/12\text{dB}$, (VHF/UHF)	20-pin SOP
μ PC2744GS	TV/VCR Tuner UHF/VHF	9	47@VHF 49@UHF	55–890	$CG=25/31\text{dB}$, $N_F=11/10\text{dB}$, (VHF/UHF)	
μ PC2775GR/GS	TV/VCR Tuner UHF/VHF	9	35@VHF 36@UHF	55–890	$CG=22/28\text{dB}$, $N_F=10/10\text{dB}$, (VHF/UHF)	20-pin SSOP/SOP
μ PC2794GS	TV/VCR Tuner UHF/VHF	9	48@VHF 50@UHF	55–890	$CG=23/32\text{dB}$, $N_F=11/10\text{dB}$, (VHF/UHF)	20-pin SOP
μ PC2797GR	TV/VCR Tuner UHF/VHF	9	38	55–890	$CG=22/28\text{dB}$, $N_F=11/10\text{dB}$, (VHF/UHF)	20-pin SSOP
μ PC3200GS	TV/VCR Tuner UHF/VHF	9	38	55–890	$CG=22/28\text{dB}$, $N_F=11/10\text{dB}$, (VHF/UHF)	20-pin SOP
μ PC3202GR	TV/VCR Tuner UHF/VHF	5	41	55–800	$CG=25/29\text{dB}$, $N_F=10.5/10\text{dB}$, (VHF/UHF)	20-pin SSOP
μ PC3207GR	TV/VCR Tuner UHF/VHF	9	38	55–890	$CG=22/28\text{dB}$, $N_F=11/10\text{dB}$, (VHF/UHF)	
μ PC1686G	TV/VCR Tuner VHF	5	38	55–500	$CG=19.5\text{dB}$, $N_F=11\text{dB}$, $P_{O(\text{sat})}=10\text{dBm}@f=200\text{MHz}$	8-pin SOP
μ PC1686GV	TV/VCR Tuner VHF	5	38	55–500	$CG=19.5\text{dB}$, $N_F=11\text{dB}$, $P_{O(\text{sat})}=10\text{dBm}@f=200\text{MHz}$	8-pin SSOP
μ PC1687G	TV/VCR Tuner UHF	5	38	500–900	$CG=26\text{dB}$, $N_F=9\text{dB}$, $P_{O(\text{sat})}=10\text{dBm}@f=500\text{MHz}$	8-pin SOP
μ PC1687GV	TV/VCR Tuner UHF	5	38	500–900	$CG=26\text{dB}$, $N_F=9\text{dB}$, $P_{O(\text{sat})}=10\text{dBm}@f=500\text{MHz}$	8-pin SSOP
μ PC2731GS	BS Tuner AGC	5	69	900–2000	$CG=14.5\text{dB}$, $N_F=12\text{dB}@f=900\text{MHz}$	20-pin SOP
μ PC2734GR	BS Tuner	5	40	900–2100	$CG=12\text{dB}$, $N_F=10\text{dB}$, $f_{\text{in}}=480\text{MHz}@f=900\text{MHz}$	20-pin SSOP
μ PC2782GR	BS Tuner AGC	5	66	900–2100	$CG=10\text{dB}$, $N_F=11\text{dB}@f=900\text{MHz}$	
μ PC2798GR	CATV Tuner Video Amp.	5	35.5	30–250	$GCR=32\text{dB}$, $V_o=3V_{p-p}(@R_L=1k\Omega)$	
μ PC2753GR	GPS	3	6.9	DC–400	$CG=38\text{dB}$, $N_F=12\text{dB}$	
μ PC2756T	GPS	3	6	100–2000	$CG=14\text{dB}$, $N_F=10\text{dB}$, $P_o=-8\text{dBm}@f=900\text{MHz}$	6-pin minimold
μ PC2756TB	GPS	3	6	100–2000	$CG=14\text{dB}$, $N_F=10\text{dB}$, $P_o=-8\text{dBm}@f=900\text{MHz}$	6-pin super minimold

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■ Down Converter (μ PCxxxx) (2/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC2768GR	Keyless Entry	3	6.8	DC-450	CG=36dB, NF=12dB@f=450MHz	20-pin SSOP
μ PC8116GR	Keyless Entry	3	4.1	100-500	G _{MIX} =11dB, RSSI _{sen} =-95dBm	
μ PC8103T	Pager	1.05	1	150-330	CG=15.5dB@f _{RFIn} =280MHz	6-pin minimold
μ PC8108T	Pager	1.05	1.5	150-930	CG=15dB@f _{RFIn} =930MHz	

■ PLL Synthesizer (μ PBxxxx)

Part Number	Functions	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PB1005K	PLL Synthesizer +Down Converters	GPS	3	45	1575.42	f _{2ndIF} =4.092MHz, f _{TCXOin} =16.368MHz	36-pin QFN

■ Switch (μ PGxxxx)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PG132G	Mobile Comm. SPDT	0, +3	0.05	100-2500	L _{INS} =0.6dB, ISL=22dB, P _{in(1dB)} =30dBm	8-pin SSOP
μ PG133G	Mobile Comm. SPDT	0, -3	0.05	100-2500	L _{INS} =0.6dB, ISL=25dB, P _{in(1dB)} =25dBm	
μ PG137GV	Mobile Comm. SPDT	0, +3	0.005	100-2500	L _{INS} =0.55dB, ISL=25dB, P _{in(1dB)} =32dBm MIN.@f=1GHz	
μ PG138GV	Mobile Comm. SPDT	0, -3	0.005	100-2500	L _{INS} =0.55dB, ISL=30dB, P _{in(1dB)} =32dBm MIN.@f=1GHz	
μ PG139GV	Mobile Comm. DPDT	V _{CONT} = 3.6V/0V, V _{DD} =3V	0.015	100-2500	TXL _{INS} =0.7dB, TXISL=15.5dB, TXP _{in(1dB)} =34dBm@f=1GHz	8-pin SOP
μ PG152TA	Mobile Comm. SPDT	0, +3	0.005	100-2500	L _{INS} =0.6dB, ISL=22dB, P _{in(1dB)} =30dBm@f=2GHz	6-pin minimold
μ PG153TB	Mobile Comm. SPDT	V _{CONT} = 3.0V/0V	0.02	100-2500	L _{INS} =0.7dB, ISL=13dB, P _{in(1dB)} =33dBm@f=2GHz	6-pin super minimold
μ PG154TB	Mobile Comm. SPDT	V _{CONT} = 3.0V/0V, V _{DD} =3V	0.002	100-2500	L _{INS} =0.65dB, ISL=21dB, P _{in(1dB)} =30dBm@f=2GHz	
μ PG155TB	Mobile Comm. SPDT	V _{CONT} = 3.0V/0V	0.02	100-2500	L _{INS} =0.75dB, ISL=16dB, P _{in(1dB)} =34dBm@f=2GHz	

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■ Wide Band AMP. (μ PCxxxx, μ PGxxxx) (1/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC1652G	General Purpose	5	20	1200	$G_P=18\text{dB}$, $N_F=5.5\text{dB}$, $P_O=+5\text{dBm}@f=500\text{MHz}$	8-pin SOP
μ PC1658G	General Purpose	10	9–18	1000	$G_P=31\text{dB}$, $N_F=1.5\text{dB}$	
μ PC1663	General Purpose Video Amp.	6	13	200	$BW=700\text{MHz}$, $A_{vd}=320$ Gain determined by external resistor. Input noise $3\mu\text{V r.m.s.}$	8-pin SOP/SSOP
μ PC1675G	General Purpose	5	17	1900	$G_P=12\text{dB}$, $N_F=5.5\text{dB}$, $P_O=+4\text{dBm}@f=500\text{MHz}$	4-pin super small package
μ PC1676G	General Purpose	5	19	1200	$G_P=22\text{dB}$, $N_F=4.5\text{dB}$, $P_O=+5\text{dBm}@f=500\text{MHz}$	
μ PC1678G	General Purpose Medium Output	5	49	2000	$G_P=23\text{dB}$, $N_F=6\text{dB}$, $P_O=+17.5\text{dBm}@f=500\text{MHz}$	8-pin SOP
μ PC1678GV	General Purpose Medium Output	5	49	2000	$G_P=23\text{dB}$, $N_F=6\text{dB}$, $P_O=+17.5\text{dBm}@f=500\text{MHz}$	8-pin SSOP
μ PC1679G	General Purpose Medium Output	5	40	1800	$G_P=21.5\text{dB}$, $N_F=6\text{dB}$, $P_O=+15.5\text{dBm}@f=500\text{MHz}$	8-pin SOP
μ PC1688G	General Purpose	5	19	1100	$G_P=21\text{dB}$, $N_F=4\text{dB}$, $P_O=+4\text{dBm}@f=500\text{MHz}$	4-pin super small package
μ PC2708T	General Purpose Medium Output	5	26	2900	$G_P=15\text{dB}$, $N_F=6.5\text{dB}$, $P_O=+10\text{dBm}@f=1\text{GHz}$	6-pin minimold
μ PC2708TB	General Purpose Medium Output	5	26	2900	$G_P=15\text{dB}$, $N_F=6.5\text{dB}$, $P_O=+10\text{dBm}@f=1\text{GHz}$	6-pin super minimold
μ PC2709T	General Purpose Medium Output	5	25	2300	$G_P=23\text{dB}$, $N_F=5\text{dB}$, $P_O=+11.5\text{dBm}@f=1\text{GHz}$	6-pin minimold
μ PC2709TB	General Purpose Medium Output	5	25	2300	$G_P=23\text{dB}$, $N_F=5\text{dB}$, $P_O=+11.5\text{dBm}@f=1\text{GHz}$	6-pin super minimold
μ PC2710T	General Purpose Medium Output	5	22	1000	$G_P=33\text{dB}$, $N_F=3.5\text{dB}$, $P_O=+13.5\text{dBm}@f=500\text{MHz}$	6-pin minimold
μ PC2710TB	General Purpose	5	22	1000	$G_P=33\text{dB}$, $N_F=3.5\text{dB}$, $P_O=+13.5\text{dBm}@f=500\text{MHz}$	6-pin super minimold
μ PC2711T	General Purpose	5	12	2900	$G_P=13\text{dB}$, $N_F=5\text{dB}$, $P_O=+1\text{dBm}@f=1\text{GHz}$	6-pin minimold
μ PC2711TB	General Purpose	5	12	2900	$G_P=13\text{dB}$, $N_F=5\text{dB}$, $P_O=+1\text{dBm}@f=1\text{GHz}$	6-pin super minimold
μ PC2712T	General Purpose	5	12	2600	$G_P=20\text{dB}$, $N_F=4.5\text{dB}$, $P_O=+3\text{dBm}@f=1\text{GHz}$	6-pin minimold
μ PC2712TB	General Purpose	5	12	2600	$G_P=20\text{dB}$, $N_F=4.5\text{dB}$, $P_O=+3\text{dBm}@f=1\text{GHz}$	6-pin super minimold
μ PC2713T	General Purpose	5	12	1200	$G_P=29\text{dB}$, $N_F=3.2\text{dB}$, $P_O=+7\text{dBm}@f=500\text{MHz}$	6-pin minimold
μ PC2714T	General Purpose	3.4	4.5	1800	$G_P=11.5\text{dB}$, $N_F=5\text{dB}$, $P_O=-7\text{dBm}@f=500\text{MHz}$	
μ PC2715T	General Purpose	3.4	4.5	1200	$G_P=19\text{dB}$, $N_F=4.5\text{dB}$, $P_O=-6\text{dBm}@f=500\text{MHz}$	
μ PC2726T	General Purpose Differential Amp.	5	11.5	1600	$G_P=15\text{dB}$, $N_F=4.5\text{dB}$, $P_O=-2\text{dBm}@f=400\text{MHz}$	
μ PC3210TB	General Purpose	5	15	2300	$G_P=20\text{dB}$, $N_F=3.4\text{dB}$, $P_O=+3.5\text{dBm}@f=1.5\text{GHz}$	6-pin super minimold
μ PG100B	General Purpose	± 5	45	50–3000	$N_F=2.7\text{dB}$, $G_P=16\text{dB}$, $P_{O(1\text{dB})}=6\text{dBm}$	T-31, 8-pin ceramic
μ PG101B	General Purpose	8, -5	100	50–3000	$N_F=5\text{dB}$, $G_P=14\text{dB}$, $P_{O(1\text{dB})}=18\text{dBm}$	
μ PG103B	General Purpose	± 5	55	50–3000	$N_F=4.5\text{dB}$, $G_P=10\text{dB}$, $P_{O(1\text{dB})}=9\text{dBm}$	
μ PG110B	General Purpose	8	135	2000–8000	$G_P=15\text{dB}$, $P_{O(1\text{dB})}=14\text{dBm}$	4-pin ceramic

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■ Wide Band AMP. (μ PCxxxx, μ PGxxxx) (2/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PC2745T	Mobile Comm.	3	7.5	2700	$G_P=12\text{dB}$, $NF=6\text{dB}$, $P_o=-1\text{dBm}@f=500\text{MHz}$	6-pin minimold
μ PC2745TB	Mobile Comm.	3	7.5	2700	$G_P=12\text{dB}$, $NF=6\text{dB}$, $P_o=-1\text{dBm}@f=500\text{MHz}$	6-pin super minimold
μ PC2746T	Mobile Comm.	3	7.5	1500	$G_P=19\text{dB}$, $NF=4\text{dB}$, $P_o=0\text{dBm}@f=500\text{MHz}$	6-pin minimold
μ PC2746TB	Mobile Comm.	3	7.5	1500	$G_P=19\text{dB}$, $NF=4\text{dB}$, $P_o=0\text{dBm}@f=500\text{MHz}$	6-pin super minimold
μ PC2747T	Mobile Comm.	3	5	1800	$G_P=12\text{dB}$, $NF=3.3\text{dB}$, $P_o=-7\text{dBm}@f=900\text{MHz}$	6-pin minimold
μ PC2747TB	Mobile Comm.	3	5	1800	$G_P=12\text{dB}$, $NF=3.3\text{dB}$, $P_o=-7\text{dBm}@f=900\text{MHz}$	6-pin super minimold
μ PC2748T	Mobile Comm.	3	6	200–1500	$G_P=19\text{dB}$, $NF=2.8\text{dB}$, $P_o=-3.5\text{dBm}@f=900\text{MHz}$	6-pin minimold
μ PC2748TB	Mobile Comm.	3	6	200–1500	$G_P=19\text{dB}$, $NF=2.8\text{dB}$, $P_o=-3.5\text{dBm}@f=900\text{MHz}$	6-pin super minimold
μ PC2749T	Mobile Comm.	3	6	2900	$G_P=16\text{dB}$, $NF=4\text{dB}$, $P_o=-6\text{dBm}@f=1900\text{MHz}$	6-pin minimold
μ PC2749TB	Mobile Comm.	3	6	2900	$G_P=16\text{dB}$, $NF=4\text{dB}$, $P_o=-6\text{dBm}@f=1900\text{MHz}$	6-pin super minimold
μ PC2762T	Mobile Comm. Medium Output	3	26.5	2900	$G_P=13\text{dB}$, $NF=6.5\text{dB}$, $P_o=+8\text{dBm}@f=900\text{MHz}$	6-pin minimold
μ PC2762TB	Mobile Comm. Medium Output	3	26.5	2900	$G_P=13\text{dB}$, $NF=6.5\text{dB}$, $P_o=+8\text{dBm}@f=900\text{MHz}$	6-pin super minimold
μ PC2763T	Mobile Comm. Medium Output	3	27	2700	$G_P=20\text{dB}$, $NF=5.5\text{dB}$, $P_o=+9.5\text{dBm}@f=900\text{MHz}$	6-pin minimold
μ PC2763TB	Mobile Comm. Medium Output	3	27	2700	$G_P=20\text{dB}$, $NF=5.5\text{dB}$, $P_o=+9.5\text{dBm}@f=900\text{MHz}$	6-pin super minimold
μ PC2771T	Mobile Comm. Medium Output	3	36	2200	$G_P=21\text{dB}$, $NF=6\text{dB}$, $P_o=+12.5\text{dBm}@f=900\text{MHz}$	6-pin minimold
μ PC2771TB	Mobile Comm. Medium Output	3	36	2200	$G_P=21\text{dB}$, $NF=6\text{dB}$, $P_o=+12.5\text{dBm}@f=900\text{MHz}$	6-pin super minimold
μ PC8128TB	Mobile Comm. Buff Amp.	2.4–3.3	2.8	100–1900	$G_P=12.5\text{dB}$, $ISL=39\text{dB}$, $P_{o(1\text{dB})}=-4\text{dBm}$, $NF=6.0\text{dB}$, $I_{CC}=2.8\text{mA}@f=1000\text{MHz}$	
μ PC8151TB	Mobile Comm. Buff Amp.	2.4–3.3	4.2	100–1900	$G_P=12.5\text{dB}$, $ISL=38\text{dB}$, $P_{o(1\text{dB})}=+2.5\text{dBm}$, $NF=6.0\text{dB}$, $I_{CC}=4.2\text{mA}@f=1000\text{MHz}$	
μ PC8152TB	Mobile Comm. Buff Amp.	2.4–3.3	5.6	100–1900	$G_P=23\text{dB}$, $ISL=40\text{dB}$, $P_{o(1\text{dB})}=-4.5\text{dBm}$, $NF=3.5\text{dB}$, $I_{CC}=5.6\text{mA}@f=1000\text{MHz}$	
μ PG170TB	Mobile Comm.	3.6	30	800–1500	$GL=11\text{dB}$, $P_{o(1\text{dB})}=14.5\text{dBm}$	6-pin super minimold
μ PC2776T	BS Converter Medium Output	5	25	2700	$G_P=23\text{dB}$, $NF=6\text{dB}$, $P_o=+6.5\text{dBm}@f=1\text{GHz}$	
μ PC2776TB	BS Converter Medium Output	5	25	2700	$G_P=23\text{dB}$, $NF=6\text{dB}$, $P_o=+6.5\text{dBm}@f=1\text{GHz}$	
μ PC2791TB	BS Converter	5	17	1900	$G_P=12\text{dB}$, $NF=5.5\text{dB}$, $P_o=+4\text{dBm}@f=500\text{MHz}$	
μ PC2792TB	BS Converter	5	19	1200	$G_P=20\text{dB}$, $NF=3.5\text{dB}$, $P_o=+5\text{dBm}@f=500\text{MHz}$	6-pin minimold
μ PC8102T	Pager	1	0.5	150–330	$G_P=14.7\text{dB}$, $NF=4.0\text{dB}@f=280\text{MHz}$	

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■ Driver AMP. (μ PG××××)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PG173TA	Mobile Comm.	2.8	25	800–1000	$P_o=9\text{dBm}$, $G_P=27\text{dB}$ MIN. $f=889\text{--}960\text{MHz}$	6-pin minimold
μ PG174TA	Mobile Comm.	3	30	1400–2000	$P_o=10\text{dBm}$, $G_P=32\text{dB}$ MIN. $f=1429\text{--}1453\text{MHz}$	
μ PG175TA	Mobile Comm.	3	20	925–960	$G_P=30\text{dB}$, $GCR=35\text{dB}$, $P_o=8\text{dBm}$	

■ Power AMP. (μ PG××××, MC-××××)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PG171GV	Mobile Comm.	3, -2	160	1895–1918	$G_P=20\text{dB}$, $P_o=21\text{dBm}$, $P_{adj}=-60\text{dBc}$	8-pin SSOP
MC-7712	CATV	24	240	50–750	$NF=7.0\text{dB}$, $GL=18.5\text{dB}$	7-pin special package
MC-7716	CATV	24	240	50–750	$NF=6.5\text{dB}$, $GL=22.0\text{dB}$	
MC-7722	CATV	24	395	50–750	$NF=7.0\text{dB}$, $GL=18.5\text{dB}$	
MC-7726	CATV	24	395	50–750	$NF=6.5\text{dB}$, $GL=22.0\text{dB}$	
MC-7852	CATV	24	240	50–860	$NF=7.0\text{dB}$, $GL=18.0\text{dB}$	
MC-7856	CATV	24	240	50–860	$NF=7.0\text{dB}$, $GL=21.5\text{dB}$	
MC-7862	CATV	24	395	50–860	$NF=7.0\text{dB}$, $GL=18.5\text{dB}$	
MC-7866	CATV	24	395	50–860	$NF=6.5\text{dB}$, $GL=21.5\text{dB}$	

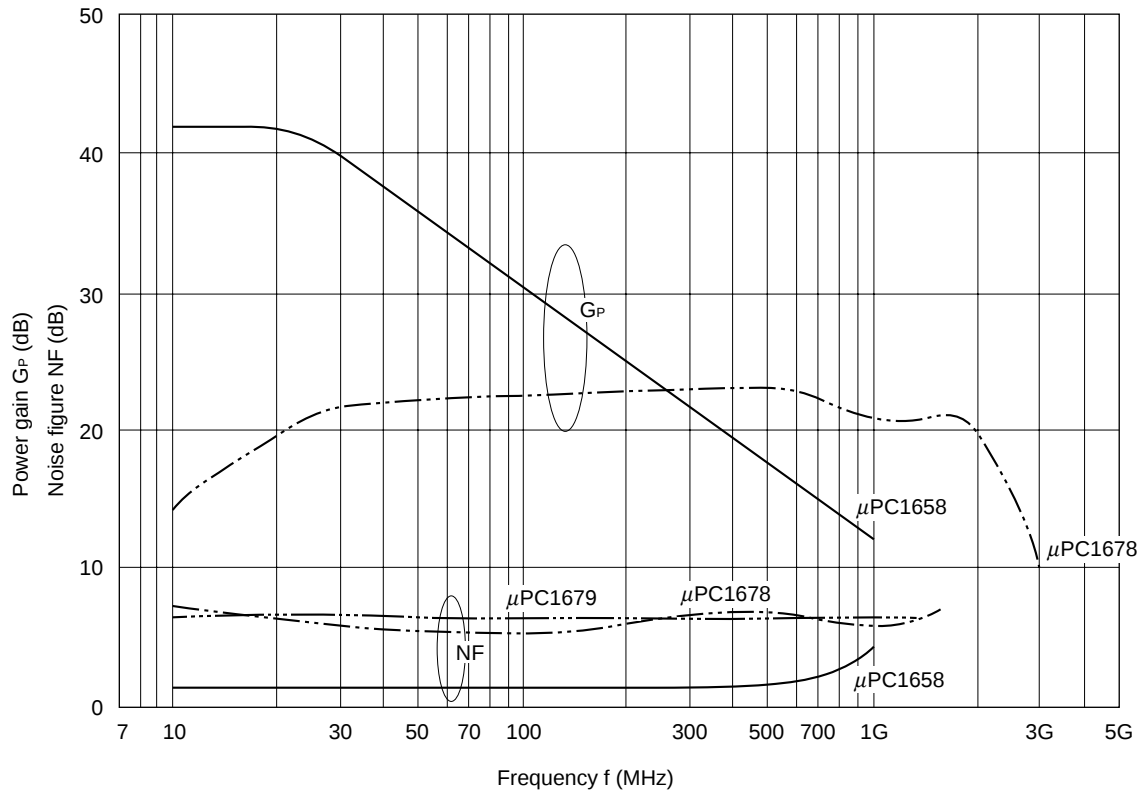
■ Transistor Array (μ PA×××)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μ PA101	General Purpose	3	0.001	9000	$f_r=9\text{GHz}$	14-pin ceramic, 8-pin miniflat
μ PA102	General Purpose	3	0.001	9000	$f_r=9\text{GHz}$	
μ PA103	General Purpose	3	0.001	9000	$f_r=9\text{GHz}$	
μ PA104	General Purpose	3	0.001	9000	$f_r=9\text{GHz}$	

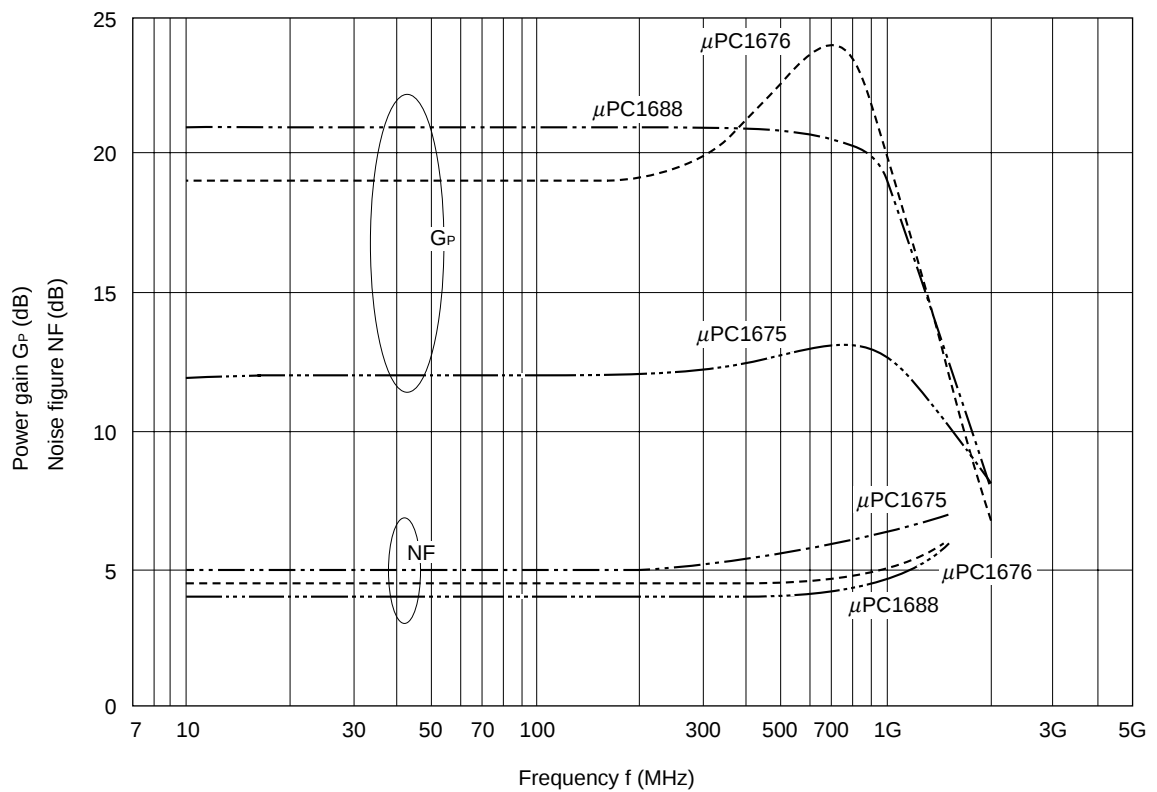
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■ Typical Characteristics

• POWER GAIN, NOISE FIGURE vs. FREQUENCY (1/4)



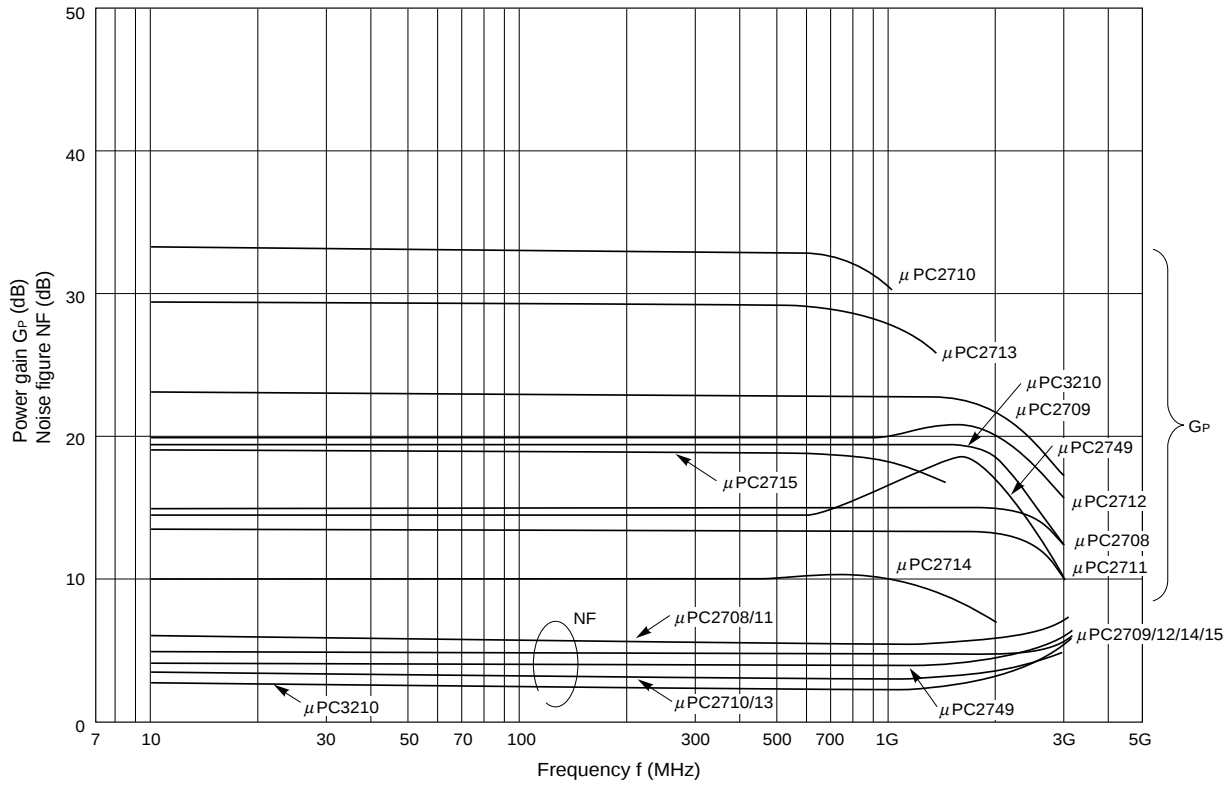
• POWER GAIN, NOISE FIGURE vs. FREQUENCY (2/4)



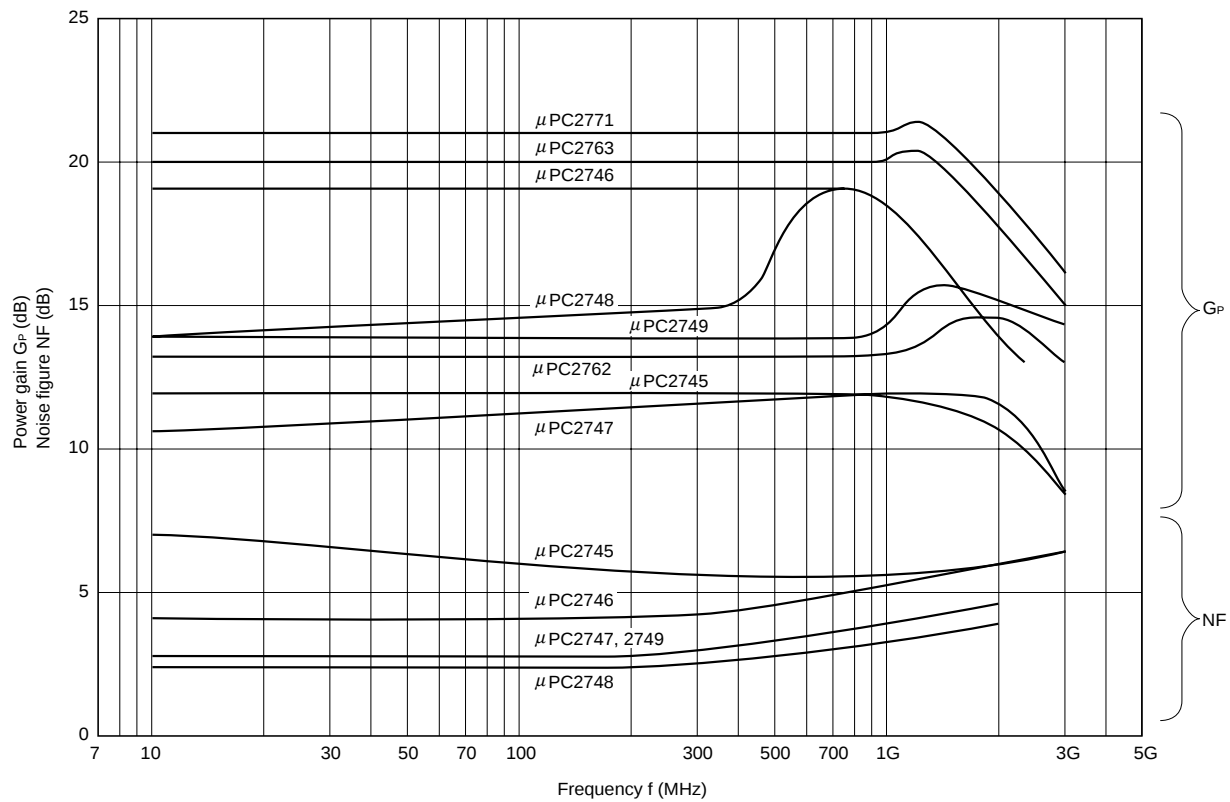
IC

■ Typical Characteristics

• POWER GAIN, NOISE FIGURE vs. FREQUENCY (3/4)



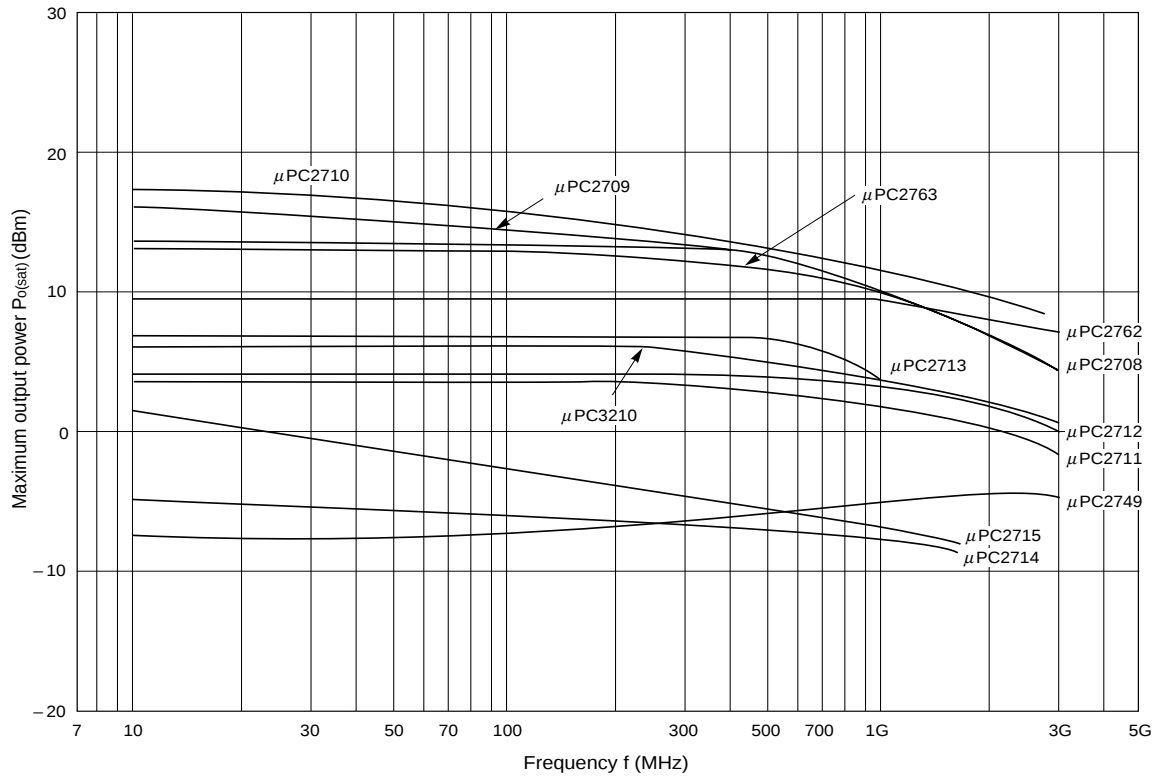
• POWER GAIN, NOISE FIGURE vs. FREQUENCY (4/4)



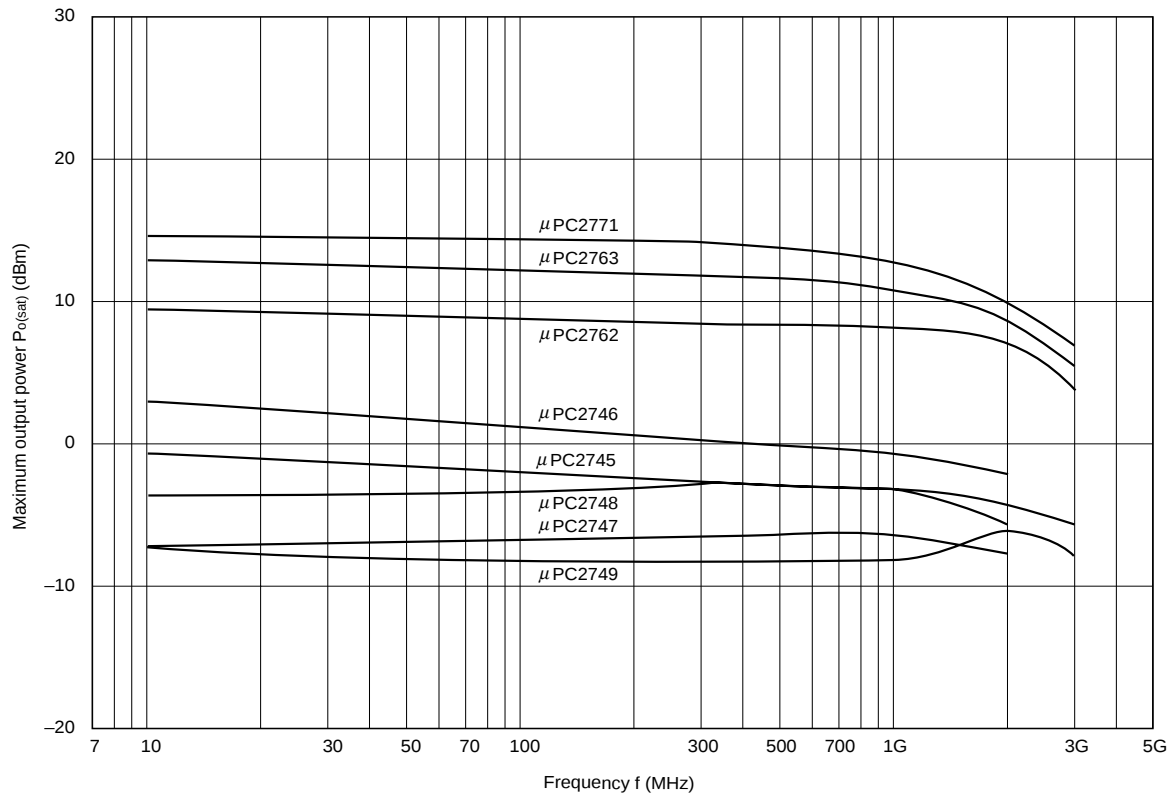
IC

■ Typical Characteristics

• MAXIMUM OUTPUT POWER vs. FREQUENCY (1/2)



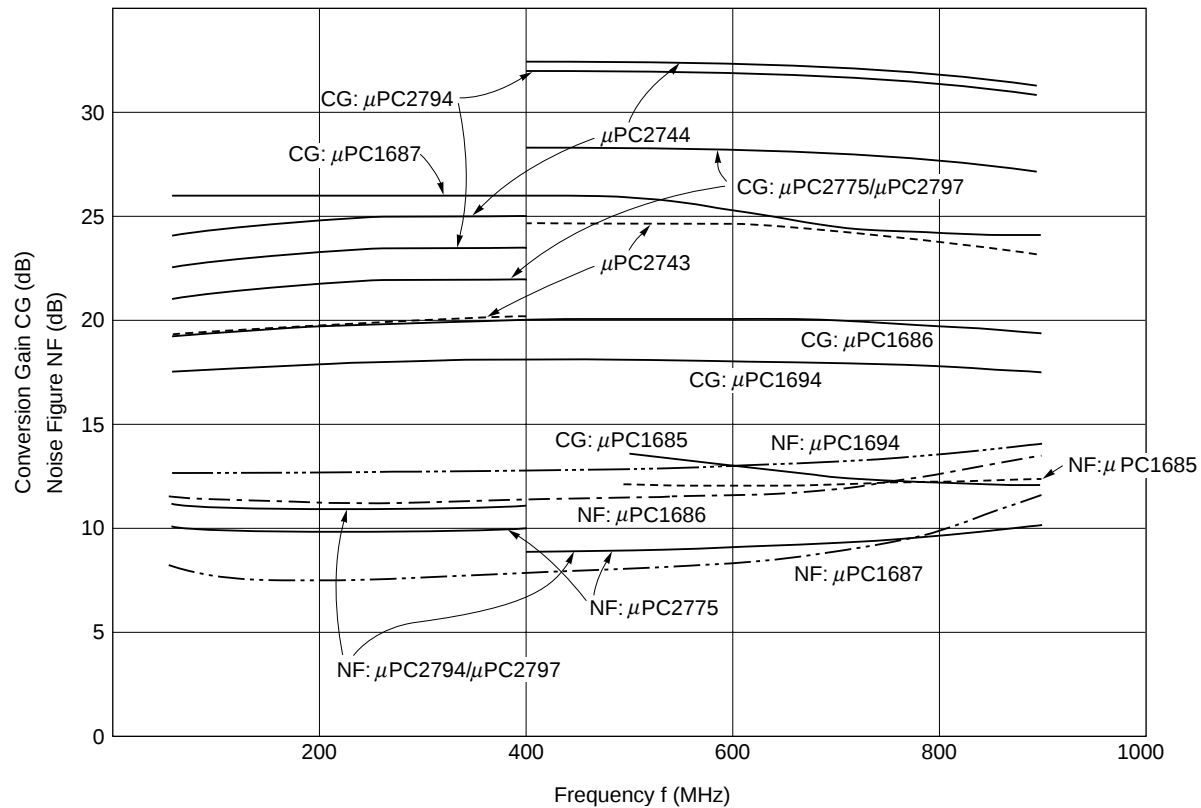
• MAXIMUM OUTPUT POWER vs. FREQUENCY (2/2)



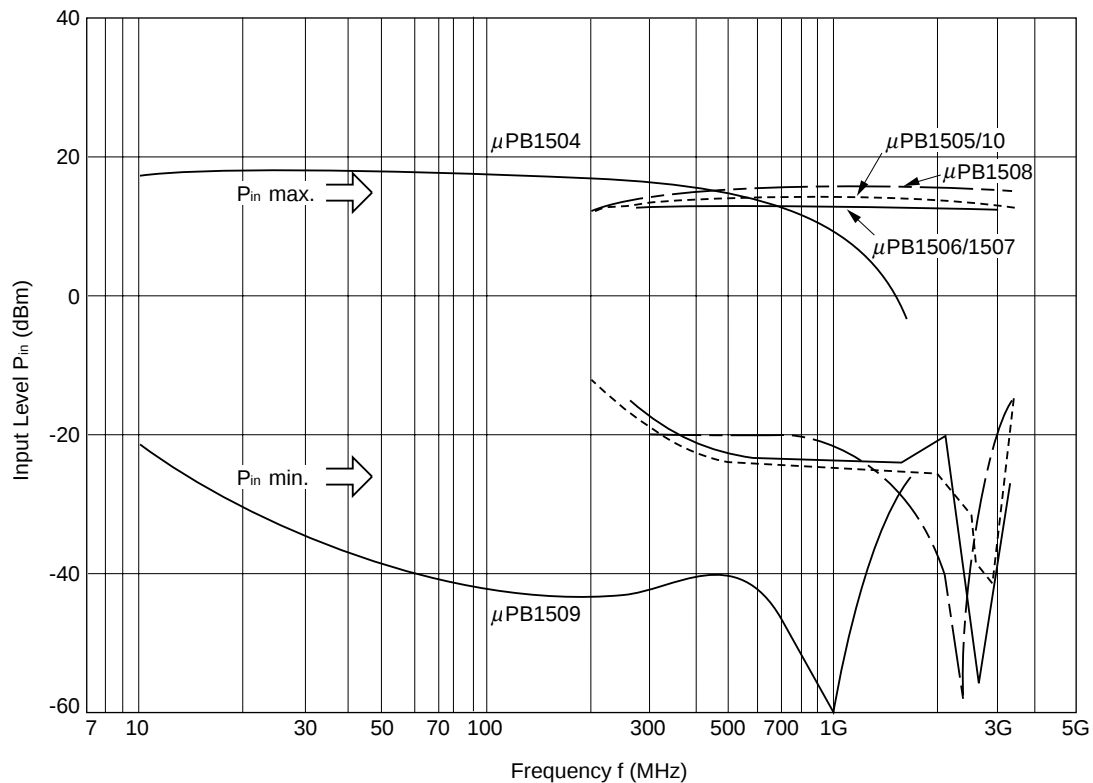
IC

■ Typical Characteristics

• CONVERSION GAIN, NOISE FIGURE vs. FREQUENCY



• INPUT LEVEL vs. FREQUENCY



Discrete

■ Dual Gate MES/MOS FET

• Dual Gate MES FET

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
3SK177 (NE25139)	TV/VCR Tuner	5	10	900	NF=1.1dB	4-pin minimold
3SK206 (NE25339)	TV/VCR Tuner	5	10	900	NF=1.1dB	
3SK299 (NE25118)	TV/VCR Tuner	5	10	900	NF=1.1dB	4-pin super minimold

• Dual Gate MOS FET

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
3SK131 (NE92939)	TV/VCR Tuner	10	10	200	NF=1.3dB	4-pin minimold
3SK134B (NE92739)	TV/VCR Tuner	10	10	900	NF=2.1dB	
3SK135A	TV/VCR Tuner	10	10	900	NF=2.7dB	
3SK176A	TV/VCR Tuner	6	3	470	NF=2.0dB	
3SK222 (NE92039)	TV/VCR Tuner	6	10	200	NF=1.2dB	
3SK223 (NE92239)	TV/VCR Tuner	6	10	470	NF=2.2dB	
3SK224 (NE92439)	TV/VCR Tuner	6	10	900	NF=1.8dB	
3SK230 (NE93039)	TV/VCR Tuner	6	10	470	NF=2.2dB	
3SK231 (NE93139)	TV/VCR Tuner	6	10	900	NF=2.0dB	
3SK252 (NE93239)	TV/VCR Tuner	3.5	7	470	NF=2.0dB	
3SK253 (NE93339)	TV/VCR Tuner	3.5	7	900	NF=1.8dB	
3SK254 (NE93218)	TV/VCR Tuner	3.5	7	470	NF=2.0dB	4-pin super minimold
3SK255 (NE93318)	TV/VCR Tuner	3.5	7	900	NF=1.8dB	

Discrete

■ Low Noise BIP. TR. (2SC, NE) (1/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
2SC1927 (NE73440B)	General Purpose	10	10	—	2 × 2SC1275	40(Ceramic)
2SC2148 (NE73435)	General Purpose	10	3	500	NF=2.1dB	μ-X
2SC2149 (NE02135)	General Purpose	10	20	2000	NF=2.6dB	
2SC2351 (NE02133)	General Purpose	10	5	1000	NF=1.5dB	3-pin minimold
2SC2954	General Purpose	10	30	500	NF=2.4dB	Power minimold
2SC3355 (NE85632)	General Purpose	10	7	1000	NF=1.1dB	TO-92
2SC3356 (NE85633)	General Purpose	10	7	1000	NF=1.1dB	3-pin minimold
2SC3357 (NE85634)	General Purpose	10	7	1000	NF=1.1dB	Power minimold
2SC3545 (NE94433)	General Purpose	10	—5	31.9	Cc·rb $\bar{b}$ '=4ps	3-pin minimold
2SC3582 (NE68132)	General Purpose	8	7	1000	NF=1.2dB	TO-92
2SC3583 (NE68133)	General Purpose	8	7	1000	NF=1.2dB	3-pin minimold
2SC3585 (NE68033)	General Purpose	6	5	2000	NF=1.8dB	μ-X
2SC3587 (NE68035)	General Purpose	6	5	2000	NF=1.7dB	
2SC3603 (NE85635)	General Purpose	10	7	2000	NF=2.1dB	
2SC3604 (NE68135)	General Purpose	8	7	2000	NF=1.6dB	
2SC3663	General Purpose	1	0.25	1000	NF=3.0dB	3-pin minimold
2SC3809 (NE85641)	General Purpose	10	20	—	2 × 2SC3603	41(Ceramic)
2SC3810 (NE68141)	General Purpose	8	20	—	2 × 2SC3604	
2SC3841	General Purpose	10	—5	31.9	Cc·rb $\bar{b}$ '=4ps	3-pin minimold
2SC4092 (NE02139E)	General Purpose	10	5	1000	NF=1.5dB	4-pin minimold
2SC4093 (NE85639E)	General Purpose	10	7	1000	NF=1.1dB	
2SC4094 (NE68139E)	General Purpose	8	7	1000	NF=1.2dB	
2SC4095 (NE68039E)	General Purpose	6	5	2000	NF=1.8dB	
2SC4182	General Purpose	3	—5	31.9	Cc·rb $\bar{b}$ '=9ps	3-pin super minimold
2SC4183 (NE58030)	General Purpose	5	2	900	NF=3.0dB	
2SC4184	General Purpose	3	—5	31.9	Cc·rb $\bar{b}$ '=3.5ps	
2SC4185 (NE73430)	General Purpose	10	5	1000	f $\bar{r}$ =2GHz	
2SC4186	General Purpose	10	—5	31.9	Cc·rb $\bar{b}$ '=5ps (MAX.)	
2SC4187 (NE68330)	General Purpose	1	0.25	1000	NF=3.0dB	
2SC4225	General Purpose	3	5	1000	NF=1.5dB	
2SC4226 (NE85630)	General Purpose	3	7	1000	NF=1.2dB	
2SC4227 (NE68130)	General Purpose	3	7	1000	NF=1.4dB	
2SC4228 (NE68030)	General Purpose	3	5	2000	NF=1.9dB	
2SC4536 (NE46134)	General Purpose	10	50	500	NF=2.5dB	Power minimold
2SC4568 (NE58133)	General Purpose	10	5	1000	S $\bar{z}$ $\bar{1e}$ ² =5.0dB (MIN.)	3-pin minimold
2SC4569 (NE58233)	General Purpose	5	5	1000	S $\bar{z}$ $\bar{1e}$ ² =5.0dB (MIN.)	
2SC4570 (NE58130)	General Purpose	5	5	1000	S $\bar{z}$ $\bar{1e}$ ² =5.0dB (MIN.)	4-pin minimold
2SC4571 (NE58230)	General Purpose	5	5	1000	S $\bar{z}$ $\bar{1e}$ ² =5.0dB (MIN.)	
2SC4703 (NE46234)	General Purpose	5	50	1000	NF=2.3dB	Power minimold
2SC4885 (NE61030)	General Purpose	5	5	1000	NF=3.0dB	4-pin minimold
2SC4954 (NE68433)	General Purpose	3	3	2000	NF=2.5dB	
2SC4955 (NE68533)	General Purpose	3	3	2000	NF=1.5dB	
2SC4956 (NE68439E)	General Purpose	3	3	2000	NF=2.5dB	
2SC4957 (NE68539E)	General Purpose	3	3	2000	NF=1.5dB	
2SC4958 (NE68430)	General Purpose	3	3	2000	NF=2.5dB	
2SC4959 (NE68530)	General Purpose	3	3	2000	NF=1.5dB	
2SC5004 (NE58219)	General Purpose	5	5	1000	S $\bar{z}$ $\bar{1e}$ ² =5.0dB (MIN.)	3-pin ultra super minimold
2SC5005 (NE58119)	General Purpose	5	5	1000	S $\bar{z}$ $\bar{1e}$ ² =5.0dB (MIN.)	
2SC5006 (NE85619)	General Purpose	3	7	1000	NF=1.2dB	
2SC5007 (NE68119)	General Purpose	3	7	1000	NF=1.4dB	
2SC5008 (NE68019)	General Purpose	3	5	2000	NF=1.9dB	
2SC5009 (NE68419)	General Purpose	3	3	2000	NF=2.5dB	
2SC5010 (NE68519)	General Purpose	3	3	2000	NF=1.5dB	

Discrete

■ Low Noise BIP. TR. (2SC, NE) (2/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
2SC5011 (NE85618)	General Purpose	10	7	1000	NF=1.1dB	4-pin super minimold
2SC5012 (NE68118)	General Purpose	8	7	1000	NF=1.2dB	
2SC5013 (NE68018)	General Purpose	6	5	2000	NF=1.8dB	
2SC5014 (NE68418)	General Purpose	3	3	2000	NF=2.5dB	
2SC5015 (NE68518)	General Purpose	3	3	2000	NF=1.5dB	
2SC5177 (NE68633)	General Purpose	1	3	2000	NF=1.5dB	3-pin minimold
2SC5178 (NE68639)	General Purpose	1	3	2000	NF=1.5dB	4-pin minimold
2SC5179 (NE68630)	General Purpose	1	3	2000	NF=1.5dB	3-pin super minimold
2SC5180 (NE68618)	General Purpose	1	3	2000	NF=1.5dB	4-pin super minimold
2SC5181 (NE68619)	General Purpose	1	3	2000	NF=1.5dB	3-pin ultra super minimold
2SC5182 (NE68733)	General Purpose	1	3	2000	NF=1.3dB	3-pin minimold
2SC5183 (NE68739)	General Purpose	1	3	2000	NF=1.3dB	4-pin minimold
2SC5184 (NE68730)	General Purpose	1	3	2000	NF=1.3dB	3-pin super minimold
2SC5185 (NE68718)	General Purpose	1	3	2000	NF=1.3dB	4-pin super minimold
2SC5186 (NE68719)	General Purpose	1	3	2000	NF=1.3dB	3-pin ultra super minimold
2SC5191 (NE68833)	General Purpose	3	7	2000	NF=1.5dB	3-pin minimold
2SC5192 (NE68839)	General Purpose	3	7	2000	NF=1.5dB	4-pin minimold
2SC5193 (NE68830)	General Purpose	3	7	2000	NF=1.5dB	3-pin super minimold
2SC5194 (NE68818)	General Purpose	3	7	2000	NF=1.5dB	4-pin super minimold
2SC5195 (NE68819)	General Purpose	3	7	2000	NF=1.5dB	3-pin ultra super minimold
2SC5336	General Purpose	10	20	1000	$ S_{21e} ^2=12\text{dB}$ (TYP.)	4-pin power minimold
2SC5337	General Purpose	10	50	1000	$ S_{21e} ^2=7.0\text{dB}$ (MIN.)	
2SC5338	General Purpose	5	50	1000	$ S_{21e} ^2=8.5\text{dB}$ (MIN.)	
2SC5369 (NE696M01)	General Purpose	3	3	2000	NF=1.3dB	6-pin super minimold
2SC5408	Mobile Comm. LNA PA-Driver	2	1	2000	NF=1.1dB	
2SC5409	Mobile Comm. LNA PA-Driver	2	3	2000	NF=1.1dB	
2SC5431	Mobile Comm. VCO	5	5	1000	$ S_{21e} ^2=5.0\text{dB}$ (MIN.)	3-pin thin-type ultra super minimold
2SC5432	Mobile Comm. VCO	3	7	1000	NF=1.4dB	
2SC5433	Mobile Comm. VCO	3	7	1000	NF=1.4dB	
2SC5434	Mobile Comm. VCO	3	5	2000	NF=1.9dB	
2SC5435	Mobile Comm. VCO	3	3	2000	NF=1.5dB	
2SC5436	Mobile Comm. VCO	2	3	2000	NF=1.4dB	
2SC5437	Mobile Comm. VCO	1	3	2000	NF=1.9dB	
2SC5454	BS Tuner Buff Amp.	3	5	2000	NF=1.5dB	4-pin minimold
2SC5455	BS Tuner Buff Amp.	3	7	2000	NF=1.5dB	
2SC5507	LNA, VCO	2	2	2000	NF=1.2dB	4-pin thin-type super minimold
2SC5508	LNA, VCO	2	5	2000	NF=1.1dB	
2SC5509	Buff Amp.	2	10	2000	NF=1.2dB	

Discrete

■ Twin TR. ($\mu\text{PA}\times\times\times$)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
μPA800T	General Purpose	1	3	2000	NF=1.9dB	6-pin super minimold
μPA801T	General Purpose	3	7	1000	NF=1.2dB	
$\mu\text{PA801TC}$	General Purpose	3	7	1000	NF=1.2dB	6-pin thin-type ultra super minimold
μPA802T	General Purpose	3	7	1000	NF=1.4dB	6-pin super minimold
μPA803T	General Purpose	5	5	1000	$ S_{21e} ^2=5.0\text{dB (MIN.)}$	
μPA804T	General Purpose	5	5	1000	$ S_{21e} ^2=5.0\text{dB (MIN.)}$	
$\mu\text{PA804TC}$	General Purpose	5	5	1000	$ S_{21e} ^2=5.0\text{dB (MIN.)}$	
μPA805T	General Purpose	3	3	2000	NF=2.5dB	6-pin super minimold
μPA806T	General Purpose	3	3	2000	NF=1.5dB	
μPA807T	General Purpose	2	3	2000	NF=1.5dB	
μPA808T	General Purpose	2	3	2000	NF=1.3dB	
μPA809T	General Purpose	1	3	2000	NF=1.7dB	
μPA810T	General Purpose	3	7	1000	NF=1.2dB	
$\mu\text{PA810TC}$	General Purpose	3	7	1000	NF=1.2dB	6-pin thin-type ultra super minimold
μPA811T	General Purpose	3	5	2000	NF=1.9dB	6-pin super minimold
μPA812T	General Purpose	3	7	1000	NF=1.4dB	
μPA813T	General Purpose	5	5	1000	$ S_{21e} ^2=5.0\text{dB (MIN.)}$	
μPA814T	General Purpose	3	7	2000	NF=1.5dB	
$\mu\text{PA814TC}$	General Purpose	3	7	2000	NF=1.5dB	6-pin thin-type ultra super minimold
$\mu\text{PA821TC}$	Mobile Comm. VCO	3	7	1000	NF=1.2dB	6-pin thin-type ultra super minimold
$\mu\text{PA821TF}$	Mobile Comm. VCO	3	7	1000	NF=1.2dB	6-pin thin-type ultra super minimold
$\mu\text{PA826TC}$	Mobile Comm. VCO	3	3	2000	NF=1.5dB	6-pin thin-type ultra super minimold
$\mu\text{PA826TF}$	Mobile Comm. VCO	3	3	2000	NF=1.5dB	6-pin thin-type ultra super minimold
$\mu\text{PA827TF}$	Mobile Comm. VCO	2	3	2000	NF=1.5dB	
$\mu\text{PA828TF}$	Mobile Comm. VCO	2	3	2000	NF=1.3dB	
$\mu\text{PA831TC}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:7, Q2:7	Q1:1000, Q2:1000	Q1:NF=1.2dB Q2:NF=1.4dB	6-pin thin-type ultra super minimold
$\mu\text{PA831TF}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:7, Q2:7	Q1:1000, Q2:1000	Q1:NF=1.2dB Q2:NF=1.4dB	6-pin thin-type ultra super minimold
$\mu\text{PA832TF}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:7, Q2:3	Q1:1000, Q2:2000	Q1:NF=1.2dB Q2:NF=1.5dB	
$\mu\text{PA833TF}$	Mobile Comm. VCO	Q1:1, Q2:3	Q1:3, Q2:3	Q1:2000, Q2:2000	Q1:NF=1.7dB Q2:NF=1.5dB	
$\mu\text{PA834TF}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:7, Q2:7	Q1:1000, Q2:1000	Q1:NF=1.4dB Q2:NF=1.2dB	
$\mu\text{PA835TC}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:3, Q2:7	Q1:2000, Q2:1000	Q1:NF=1.5dB Q2:NF=1.2dB	6-pin thin-type ultra super minimold
$\mu\text{PA835TF}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:3, Q2:7	Q1:2000, Q2:1000	Q1:NF=1.5dB Q2:NF=1.2dB	6-pin thin-type ultra super minimold
$\mu\text{PA836TC}$	Mobile Comm. VCO	Q1:3, Q2:1	Q1:3, Q2:3	Q1:2000, Q2:2000	Q1:NF=1.5dB Q2:NF=1.7dB	6-pin thin-type ultra super minimold
$\mu\text{PA836TF}$	Mobile Comm. VCO	Q1:3, Q2:1	Q1:3, Q2:3	Q1:2000, Q2:2000	Q1:NF=1.5dB Q2:NF=1.7dB	6-pin thin-type ultra super minimold
$\mu\text{PA840TC}$	Mobile Comm. VCO	Q1:3, Q2:3	Q1:3, Q2:7	Q1:2000, Q2:1000	Q1:NF=1.5dB Q2:NF=1.4dB	6-pin thin-type ultra super minimold

Discrete

■ Low Noise GaAs/HJ FET (NE) (1/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
NE674	General Purpose GaAs FET	3	10	4000–12000	NF=1.4dB, Ga=10dB@f=12GHz	Chip, 83B
NE71300	General Purpose GaAs FET	3	10	12000	NF=1.6dB	Chip
NE71383B	General Purpose GaAs FET	3	10	12000	NF=1.6dB	83B
NE76118	General Purpose GaAs FET	3	10	2000	NF=0.8dB	18
NE23383B	General Purpose HJ-FET	2	10	4000–12000	NF=0.35dB, Ga=15dB@f=4GHz	83B
NE24200	General Purpose HJ-FET	2	10	12000	NF=0.6dB	Chip
NE24283B	General Purpose HJ-FET	2	10	4000–18000	NF=0.6dB, Ga=11dB@f=12GHz	83B
NE27200	General Purpose HJ-FET	2	10	12000	NF=0.45dB	Chip
NE32500	General Purpose HJ-FET	2	10	12000	NF=0.45dB	
NE32900	General Purpose HJ-FET	2	10	4000–18000	NF=0.35dB, Ga=13dB@f=12GHz	
NE34018	Mobile Comm. HJ-FET	2	5	800–3000	NF=0.6dB, Ga=16dB, G _s =18dB@f=2GHz	18
NE38018	Mobile Comm. HJ-FET	2	5	800–3000	NF=0.55dB, Ga=14.5dB, G _s =16dB@f=2GHz	
NE72118	BS Converter OSC Stage GaAs FET	3	30	4000–12000	G _s =5.5dB, P _{o(1dB)} =13.5dBm@f=12GHz	
NE721S01	BS Converter OSC Stage GaAs FET	3	30	12000	G _s =7dB	S01
NE72218	BS Converter OSC Stage GaAs FET	3	30	4000–12000	G _s =4.5dB, P _{o(1dB)} =15.0dBm@f=12GHz	18
NE76000	BS Converter GaAs FET	3	10	12000	NF=1.6dB	Chip
NE76038	BS Converter GaAs FET	3	10	12000	NF=1.7dB	38
NE76083A	BS Converter GaAs FET	3	10	12000	NF=1.6dB	83A
NE76084	BS Converter GaAs FET	3	10	12000	NF=1.6dB	84
NE76184A	BS Converter GaAs FET	3	10	4000	NF=0.8dB, Ga=12dB	84A
NE32484A	BS Converter HJ-FET	2	10	12000	NF=0.6dB, Ga=11.0dB	
NE32584C	BS Converter HJ-FET	2	10	12000	NF=0.45dB, Ga=12.5dB	84C
NE325S01	BS Converter HJ-FET	2	10	12000	NF=0.45dB, Ga=12.5dB	S01
NE329S01	BS Converter HJ-FET	2	10	4000–18000	NF=0.35dB, Ga=13.0dB@f=12GHz	
NE3210S01	BS Converter HJ-FET	2	10	4000–18000	NF=0.35dB, Ga=13.5dB@f=12GHz	
NE33284A	BS Converter HJ-FET	2	10	4000	NF=0.35dB, Ga=15.0dB	84A
NE334S01	BS Converter HJ-FET	2	15	4000	NF=0.25dB, Ga=16.0dB	S01

Discrete

■ Low Noise GaAs/HJ FET (NE) (2/2)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
NE42484A	BS Converter HJ-FET	2	10	12000	NF=0.8dB, $G_a=10.5\text{dB}$	84A
NE42484C	BS Converter HJ-FET	2	10	12000	NF=0.7dB, $G_a=12.0\text{dB}$	84C
NE425S01	BS Converter HJ-FET	2	10	12000	NF=0.6dB, $G_a=12.0\text{dB}$	S01
NE428M01	BS Converter HJ-FET	2	10	4000–12000	NF=0.9dB, $G_a=8.5\text{dB}@f=12\text{GHz}$	M01
NE429M01	BS Converter HJ-FET	2	10	4000–12000	NF=0.9dB, $G_a=10\text{dB}@f=12\text{GHz}$	
NE4210M01	BS Converter HJ-FET	2	10	4000–12000	NF=0.8dB, $G_a=11\text{dB}@f=12\text{GHz}$	
NE434S01	BS Converter HJ-FET	2	15	4000	NF=0.35dB, $G_a=15.5\text{dB}$	S01

Discrete

■ Power TR./FET (2SC, NE, NEL, NEM, NES, NEZ) (1/3)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
2SC5288 (NE68939)	General Purpose Medium Po. Bip. Tr.	3.6	I _q =1	1900	P _{in(1dB)} =24dBm (class AB)	4-pin minimold
2SC5289 (NE69039)	General Purpose Medium Po. Bip. Tr.	3.6	I _q =1	1900	P _{in(1dB)} =27dBm (class AB)	
NE850R599A	C-Band Po. Amp. Power GaAs FET	10	100	2000–10000	P _{o(1dB)} =25.5dBm	99
NE8500199	C-Band Po. Amp. Power GaAs FET	10	200	2000–10000	P _{o(1dB)} =28.5dBm	
NE8500295-4	C-Band Po. Amp. Power GaAs FET	10	450	3500–5500	P _{o(1dB)} =33.8dBm	95
NE8500295-6	C-Band Po. Amp. Power GaAs FET	10	450	5500–7500	P _{o(1dB)} =33.8dBm	
NE8500295-8	C-Band Po. Amp. Power GaAs FET	10	450	7500–8500	P _{o(1dB)} =33.5dBm	
NEZ3642-15D	C-Band Po. Amp. Power GaAs FET	10	≤6000	3600–4200	P _{o(1dB)} =42.5dBm	T-65
NEZ3642-15DD	C-Band Po. Amp. Power GaAs FET	10	≤6000	3600–4200	P _{o(1dB)} =42.5dBm	
NEZ3642-4D	C-Band Po. Amp. Power GaAs FET	10	≤1500	3600–4200	P _{o(1dB)} =36.5dBm	T-61
NEZ3642-8D	C-Band Po. Amp. Power GaAs FET	10	≤3000	3600–4200	P _{o(1dB)} =39.5dBm	
NEZ3642-8DD	C-Band Po. Amp. Power GaAs FET	10	≤3000	3600–4200	P _{o(1dB)} =39.5dBm	
NEZ4450-15D	C-Band Po. Amp. Power GaAs FET	10	≤6000	4400–5000	P _{o(1dB)} =42.5dBm	T-65
NEZ4450-15DD	C-Band Po. Amp. Power GaAs FET	10	≤6000	4400–5000	P _{o(1dB)} =42.5dBm	
NEZ4450-4D	C-Band Po. Amp. Power GaAs FET	10	≤1500	4400–5000	P _{o(1dB)} =36.5dBm	T-61
NEZ4450-4DD	C-Band Po. Amp. Power GaAs FET	10	≤1500	4400–5000	P _{o(1dB)} =36.5dBm	
NEZ4450-8D	C-Band Po. Amp. Power GaAs FET	10	≤3000	4400–5000	P _{o(1dB)} =39.5dBm	
NEZ4450-8DD	C-Band Po. Amp. Power GaAs FET	10	≤3000	4400–5000	P _{o(1dB)} =39.5dBm	
NEZ5964-15D	C-Band Po. Amp. Power GaAs FET	10	≤6000	5900–6450	P _{o(1dB)} =42.5dBm	T-65
NEZ5964-15DD	C-Band Po. Amp. Power GaAs FET	10	≤6000	5900–6450	P _{o(1dB)} =42.5dBm	
NEZ5964-4D	C-Band Po. Amp. Power GaAs FET	10	≤1500	5900–6450	P _{o(1dB)} =36.5dBm	T-61
NEZ5964-4DD	C-Band Po. Amp. Power GaAs FET	10	≤1500	5900–6450	P _{o(1dB)} =36.5dBm	
NEZ5964-8D	C-Band Po. Amp. Power GaAs FET	10	≤3000	5900–6450	P _{o(1dB)} =39.5dBm	
NEZ5964-8DD	C-Band Po. Amp. Power GaAs FET	10	≤3000	5900–6450	P _{o(1dB)} =39.5dBm	
NEZ6472-15D	C-Band Po. Amp. Power GaAs FET	10	≤6000	6400–7200	P _{o(1dB)} =42.5dBm	T-65
NEZ6472-15DD	C-Band Po. Amp. Power GaAs FET	10	≤6000	6400–7200	P _{o(1dB)} =42.5dBm	

Discrete

■ Power TR./FET (2SC, NE, NEL, NEM, NES, NEZ) (2/3)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
NEZ6472-4D	C-Band Po. Amp. Power GaAs FET	10	≤ 1500	6400–7200	$P_{o(1dB)}=36.5dBm$	T-61
NEZ6472-4DD	C-Band Po. Amp. Power GaAs FET	10	≤ 1500	6400–7200	$P_{o(1dB)}=36.5dBm$	
NEZ6472-8D	C-Band Po. Amp. Power GaAs FET	10	≤ 3000	6400–7200	$P_{o(1dB)}=39.5dBm$	
NEZ6472-8DD	C-Band Po. Amp. Power GaAs FET	10	≤ 3000	6400–7200	$P_{o(1dB)}=39.5dBm$	
NEZ7177-4D	C-Band Po. Amp. Power GaAs FET	10	≤ 1500	7100–7700	$P_{o(1dB)}=36.5dBm$	
NEZ7177-4DD	C-Band Po. Amp. Power GaAs FET	10	≤ 1500	7100–7700	$P_{o(1dB)}=36.5dBm$	
NEZ7177-8D	C-Band Po. Amp. Power GaAs FET	10	≤ 3000	7100–7700	$P_{o(1dB)}=39.5dBm$	
NEZ7177-8DD	C-Band Po. Amp. Power GaAs FET	10	≤ 3000	7100–7700	$P_{o(1dB)}=39.5dBm$	
NEZ7785-15D	C-Band Po. Amp. Power GaAs FET	10	≤ 6000	7700–8500	$P_{o(1dB)}=42.5dBm$	T-65
NEZ7785-4D	C-Band Po. Amp. Power GaAs FET	10	≤ 1500	7700–8500	$P_{o(1dB)}=36.5dBm$	T-61
NEZ7785-4DD	C-Band Po. Amp. Power GaAs FET	10	≤ 1500	7700–8500	$P_{o(1dB)}=36.5dBm$	
NEZ7785-8D	C-Band Po. Amp. Power GaAs FET	10	≤ 3000	7700–8500	$P_{o(1dB)}=39.5dBm$	
NEZ7785-8DD	C-Band Po. Amp. Power GaAs FET	10	≤ 3000	7700–8500	$P_{o(1dB)}=39.5dBm$	
NE1280100	K-Band Medium Po. Amp. Power GaAs FET	5	60	18700	$P_{out}=21.5dBm$	Chip
NE1280200	K-Band Medium Po. Amp. Power GaAs FET	5	120	18700	$P_{out}=24.5dBm$	
NE1280400	K-Band Medium Po. Amp. Power GaAs FET	5	240	18700	$P_{out}=27.5dBm$	
NEZ1414-2E	Ku-Band Po. Amp. Power GaAs FET	9	700	14000–14500	$P_{o(1dB)}=34.0dBm$	T-78
NEZ1414-3E	Ku-Band Po. Amp. Power GaAs FET	10	700	14000–14500	$P_{o(1dB)}=34.0dBm$	
NEZ1414-4E	Ku-Band Po. Amp. Power GaAs FET	9	1000	14000–14500	$P_o=37.5dBm$	
NEZ1414-5E	Ku-Band Po. Amp. Power GaAs FET	10	1500	14000–14500	$P_{o(1dB)}=37.0dBm$	
NEZ1414-8E	Ku-Band Po. Amp. Power GaAs FET	9	2800	14000–14500	$P_o=39.5dBm$	T-61
2SC3817 (NEL150181-12)	L-Band Po. Amp. Power Bip. Tr.	13.5	$I_q=3$	1550	$P_{out}=30dBm$ (Class AB)	81 (Ceramic)
NEL2001	L-Band Po. Amp. Power Bip. Tr.	24	$I_q=20$	1970	$P_{in(1dB)}=2.5W$ (Class AB)	01
NEL2004	L-Band Po. Amp. Power Bip. Tr.	24	$I_q=40$	1970	$P_{in(1dB)}=7W$ (Class AB)	F02
NEL2012	L-Band Po. Amp. Power Bip. Tr.	24	$I_q=75$	1970	$P_{in(1dB)}=16W$ (Class AB)	
NEL2012F03-24	L-Band Po. Amp. Power Bip. Tr.	24	$I_q=75$	1970	$P_{in(1dB)}=16W$	F03
NEL2035	L-Band Po. Amp. Power Bip. Tr.	24	$I_q=100$	1970	$P_{in(1dB)}=33W$ (Class AB)	

Discrete

■ Power TR./FET (2SC, NE, NEL, NEM, NES, NEZ) (3/3)

Part Number	Applications	Supply Voltage (V)	Supply Current (mA)	Operating Frequency (MHz)	Performances	Package
NE650R279A	L, S-Band Po. Amp. Power GaAs FET	6	50	800–2500	$P_{o(1dB)}=23dBm$, $GL=16dB$, $\eta_{add}=45\%$ @ $f=1.9GHz$	79A
NE650R479A	L, S-Band Po. Amp. Power GaAs FET	6	100	800–2500	$P_{o(1dB)}=26dBm$, $GL=14dB$, $\eta_{add}=45\%$ @ $f=1.9GHz$	
NE6500379A	L, S-Band Po. Amp. Power GaAs FET	6	500	800–2500	$P_{o(1dB)}=35dBm$, $GL=10dB$, $\eta_{add}=50\%$ @ $f=1.9GHz$	
NE6500496	L, S-Band Po. Amp. Power GaAs FET	10	≤ 400	2300	$P_{o(1dB)}=36dBm$	96
NE6501077	L, S-Band Po. Amp. Power GaAs FET	10	≤ 1000	2300	$P_{o(1dB)}=39.5dBm$	77
NE651R479A	L-Band Po. Amp. Power GaAs HJ-FET	3.5	230	800–2500	$P_o=27dBm$, $GL=12dB$, $\eta_{add}=60\%$ @ $f=1.9GHz$	79A
NE6510179A	L-Band Po. Amp. Power GaAs HJ-FET	3.5	200	800–2500	$P_o=32.5dBm$, $GL=10dB$, $\eta_{add}=58\%$ @ $f=1.9GHz$	
NE6510379A	L-Band Po. Amp. Power GaAs HJ-FET	3.5	760	800–2500	$P_o=32.5dBm$, $GL=8dB$, $\eta_{add}=52\%$ @ $f=1.9GHz$	
NES1417B-30	L-Band Po. Amp. Power GaAs FET	10	1000	1500	$P_o=45dBm$	T-79
NES1821B-30	L-Band Po. Amp. Power GaAs FET	10	1000	1900	$P_o=45dBm$	
NES1821P-30	L, S-Band Po. Amp. Power GaAs FET	10	4000	1800-2300	$P_o=45dBm$, $GL=13dB$, $\eta_D=40\%$ @ $f=1.96GHz$	T-86
NES1821P-50	L, S-Band Po. Amp. Power GaAs FET	10	2000	1800-2200	$P_o=47dBm$, $GL=10.5dB$, $\eta_D=52\%$ @ $f=1.96GHz$	
NES1823P-100	L, S-Band Po. Amp. Power GaAs FET	10	6000	1800-2300	$P_o=50dBm$, $GL=11dB$, $\eta_D=50\%$ @ $f=2.2GHz$	T-92
NES2527B-30	S-Band Po. Amp. Power GaAs FET	10	6000	2500-2700	$P_{o(1dB)}=45.0dBm$	T-79
2SC2586 (NE050214E-12)	UHF Po. Amp. Power Bip. Tr.	12.6	–	500	$P_{out}=32dBm$ (Class C)	CAN
2SC2762 (NE050214-12)	UHF Po. Amp. Power Bip. Tr.	12.6	–	500	$P_{out}=31.5dBm$ (Class C)	
2SC3218-M (NEM085068-28)	UHF Po. Amp. Power Bip. Tr.	28	$I_q=2 \times 150$	860	$P_{out}=47.2dBm$ (Class AB)	68 (Ceramic)
2SC3286-M (NEM0214068-28)	VHF Po. Amp. Power Bip. Tr.	28	$I_q=2 \times 500$	230	$P_{out}=51.4dBm$ (Class AB)	Ceramic
NEM0899F06-30	UHF Po. Amp. Power Bip. Tr.	30	$I_q=2 \times 150$	860	$P_{out}=100W$	F06
NEM0995F06-30	UHF Po. Amp. Power Bip. Tr.	30	$I_q=2 \times 200$	960	$P_{out}=90W$	
2SK2597 (NEM0995F01-30)	UHF Po. Amp. Power MOS FET	30	$I_q=2 \times 200$	960	$P_o=90W$	F01
NEZ1011-2E	X-Band Po. Amp. Power GaAs FET	9	700	10700–11700	$P_{o(1dB)}=34.5dBm$	T-78
NEZ1011-3E	X-Band Po. Amp. Power GaAs FET	10	700	10700–11700	$P_{o(1dB)}=34.0dBm$	
NEZ1011-4E	X-Band Po. Amp. Power GaAs FET	9	1000	10700–11700	$P_o=36.5dBm$, $GL=8.0dB$ @ $f=10.7\text{--}11.7GHz$	
NEZ1011-5E	X-Band Po. Amp. Power GaAs FET	10	1500	10700–11700	$P_{o(1dB)}=37.0dBm$	
NEZ1011-8E	X-Band Po. Amp. Power GaAs FET	9	2000	10700–11700	$P_o=40.5dBm$	T-61
NE960R275	X, Ku-Band Po. Amp. Power GaAs FET	9	90	8000–16000	$P_{o(1dB)}=25.0dBm$	75
NE960R575	X, Ku-Band Po. Amp. Power GaAs FET	9	180	8000–16000	$P_{o(1dB)}=27.5dBm$	

Discrete

■ Cross-reference Table

• Dual Gate MES FET

Remarks	4-pin minimold	4-pin super minimold
$W_g = 400 \mu\text{m}$	3SK177	3SK299
$W_g = 800 \mu\text{m}$	3SK206	

• Dual Gate MOS FET

Applications		4-pin minimold	4-pin super minimold
VHF Band (to 200 MHz)		3SK131	3SK242
		3SK222	3SK246
CATV Band (to 470 MHz)		3SK223	3SK243
		3SK230	
		3SK252	3SK254
UHF Band (to 900 MHz)	$\lambda/4$ matching	3SK135A	
		3SK224	3SK244
		3SK231	
		3SK253	3SK255
	$\lambda/2$ matching	3SK134B	3SK245

Remark: Devices listed in the same row are the same chip.

Example: 3SK131, 3SK242

• Dual Gate MES/MOS FET, Low Noise BIP. TR. (for TV tuner)

Applications		BIP. TR.		Dual Gate FET	
		Minimold (3-pin)	Small minimold (3-pin)	Minimold (4-pin)	Super minimold (4-pin)
VHF band	RF			3SK131 3SK222 3SK223 3SK230 3SK252	3SK254
	MIX	2SC3545	2SC4182 2SC4184	3SK131	3SK242
	OSC	2SC3545	2SC4182 2SC4184		
UHF band	RF ($\lambda/4$)		2SC4183	3SK135A 3SK224 3SK231 3SK253	3SK255
	RF ($\lambda/2$)			3SK134B	
	RF (GaAs FET)			3SK177 3SK206	
	MIX	2SC3545 2SC3841	2SC4183 2SC4185 2SC4184 2SC4186		
	OSC	2SC3545 2SC3841	2SC4182 2SC4184 2SC4185		

Discrete

■ Cross-reference Table

• Low Noise BIP. TR. (1/2)

Applications	Part Number						Electrical Characteristics	
	TO-92	Minimold		Super minimold		Ultra super minimold	f _T (GHz)	NF (dB)
		3-pin	4-pin	3-pin	4-pin	3-pin		
Pre Amp.	2SC3355	2SC3356	2SC4093	2SC4228	2SC5013	2SC5008	7 (20 mA)	1.1 (1 GHz)
	2SC2570A	2SC2351	2SC4092				5 (20 mA)	1.5 (1 GHz)
Buffer Amp.				2SC4185			2 (5 mA)	3 (0.5 GHz)
	2SC2570A	2SC2351	2SC4092				5 (20 mA)	1.5 (1 GHz)
1st IF Amp.	2SC3355	2SC3356	2SC4093	2SC4226	2SC5011	2SC5006	7 (20 mA)	1.1 (1 GHz)
	2SC2570A	2SC2351	2SC4092				5 (20 mA)	1.5 (1 GHz)
1st and 2nd OSC		2SC3545		2SC4184			1.8 (5 mA)	
				2SC4185			2 (5 mA)	
		2SC4568		2SC4570		2SC5005	5.5 (5 mA)	
		2SC4569		2SC4571		2SC5004	5 (5 mA)	
2nd IF Amp.				2SC4185			2 (5 mA)	

• Low Noise BIP. TR. (2/2)

Frequency (MHz)	NF (dB)		
	2.5	3.5	4.0
500	—	2SC2148	—
2000	2SC3604	2SC3603	2SC2149
4000	2SC3587	—	—

• Twin TR.

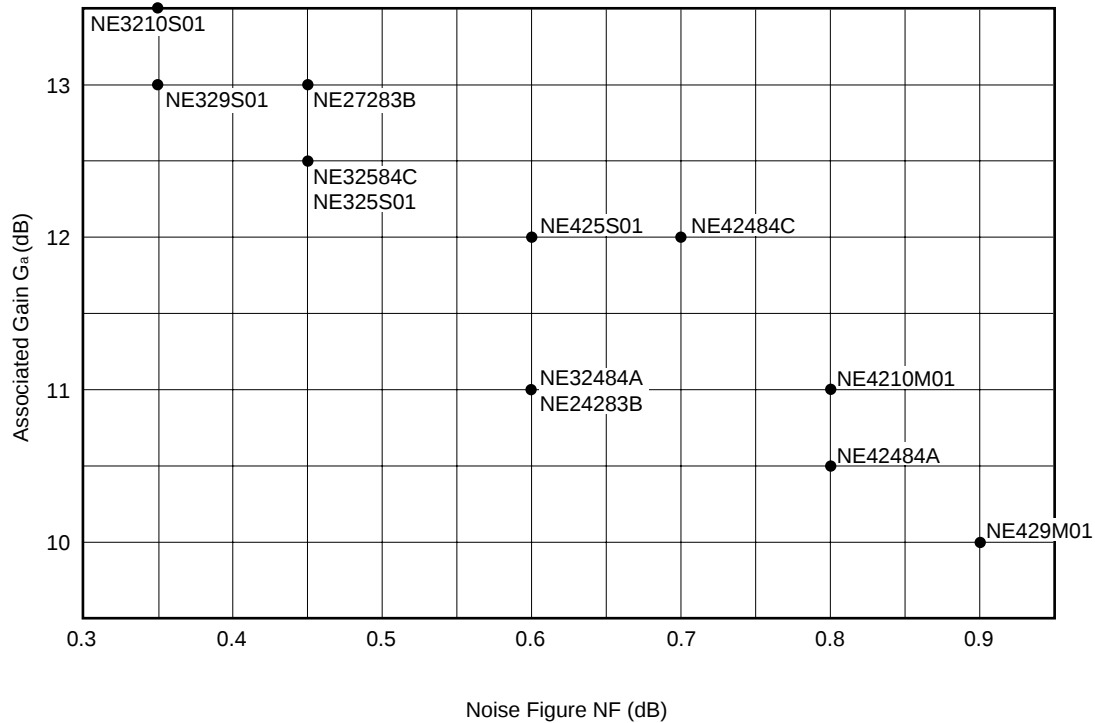
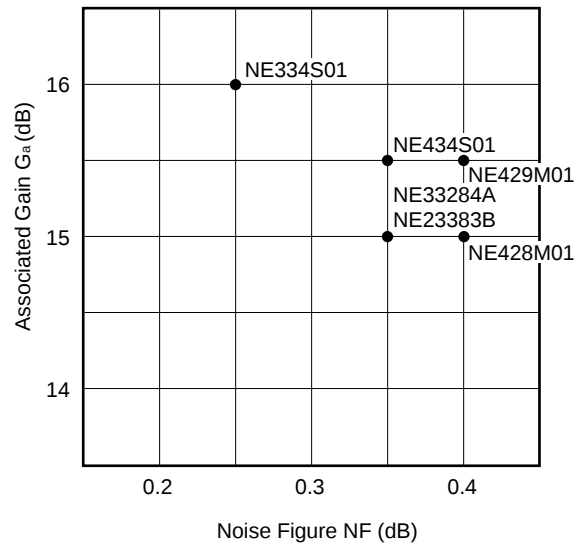
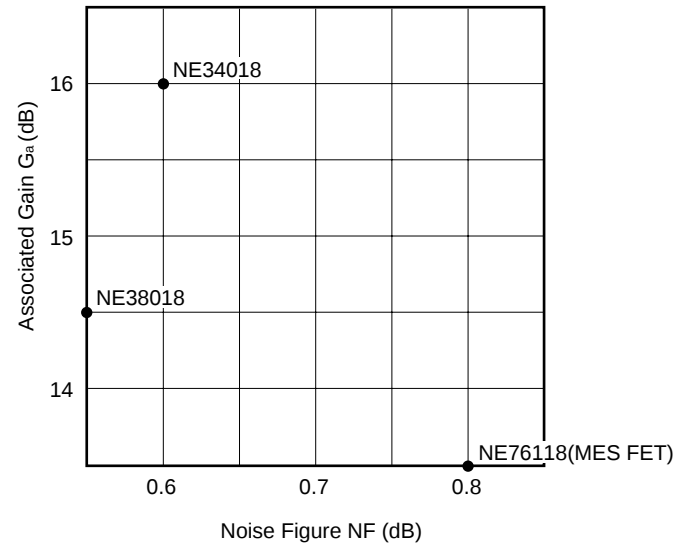
for pager		for VCO		for Mobile Communications		for VCO		
Same Chip								
Part Number	2SC No. (×2)	Part Number	2SC No. (×2)	Part Number	2SC No. (×2)	Part Number	2SC No. (×2)	
							Q1	Q2
μPA800T, TF	2SC5008	μPA811T	2SC5008					
μPA801T,TC,TF	2SC5006	μPA810T,TC,TF	2SC5006	μPA821TC, TF	2SC5006	μPA831TC, TF	2SC5006	2SC5007
μPA802T	2SC5007	μPA812T	2SC5007	μPA822TF	2SC5007	μPA832TF	2SC5006	2SC5010
μPA803T	2SC5005	μPA813T	2SC5005			μPA833TF	2SC5195	2SC5010
μPA804T,TC,TF	2SC5004					μPA834TF	2SC5007	2SC5006
μPA805T	2SC5009					μPA835TC, TF	2SC5010	2SC5006
μPA806T	2SC5010			μPA826TC, TF	2SC5010	μPA836TC, TF	2SC5010	2SC5195
μPA807T	2SC5181			μPA827TF	2SC5181	μPA837TF	2SC5181	2SC5195
μPA808T	2SC5186			μPA828TF	2SC5186	μPA838TF	2SC5195	2SC5186
μPA809T, TF	2SC5195	μPA814T,TC,TF	2SC5195	μPA829TF	2SC5195	μPA839TF	2SC5008	2SC5006
						μPA840TC	2SC5010	2SC5007

Package size T : 2.0 × 1.25 × 0.9 (mm)
 TC: 1.5 × 1.1 × 0.55 (mm)
 TF: 2.0 × 1.25 × 0.6 (mm)

Discrete

■ Cross-reference Table

• Low Noise GaAs/HJ FET

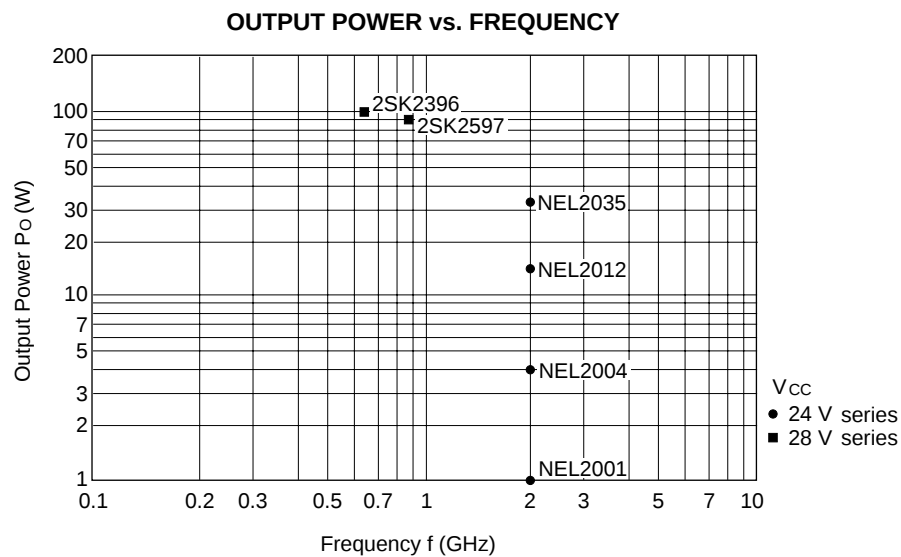
ASSOCIATED GAIN vs. NOISE FIGURE @ $f = 12$ GHzASSOCIATED GAIN vs. NOISE FIGURE @ $f = 4$ GHzASSOCIATED GAIN vs. NOISE FIGURE @ $f = 2$ GHz

• : In mass production

Discrete

■ Cross-reference Table

• Power TR. (for mobile and portable radio station)



• Power TR. (for fixed radio station)

Frequency	Output Power	
	10 W or higher	
800 MHz or higher	2SK2396	
900 MHz or higher	2SK2597	
1900 MHz or higher	NEL2000 SERIES	

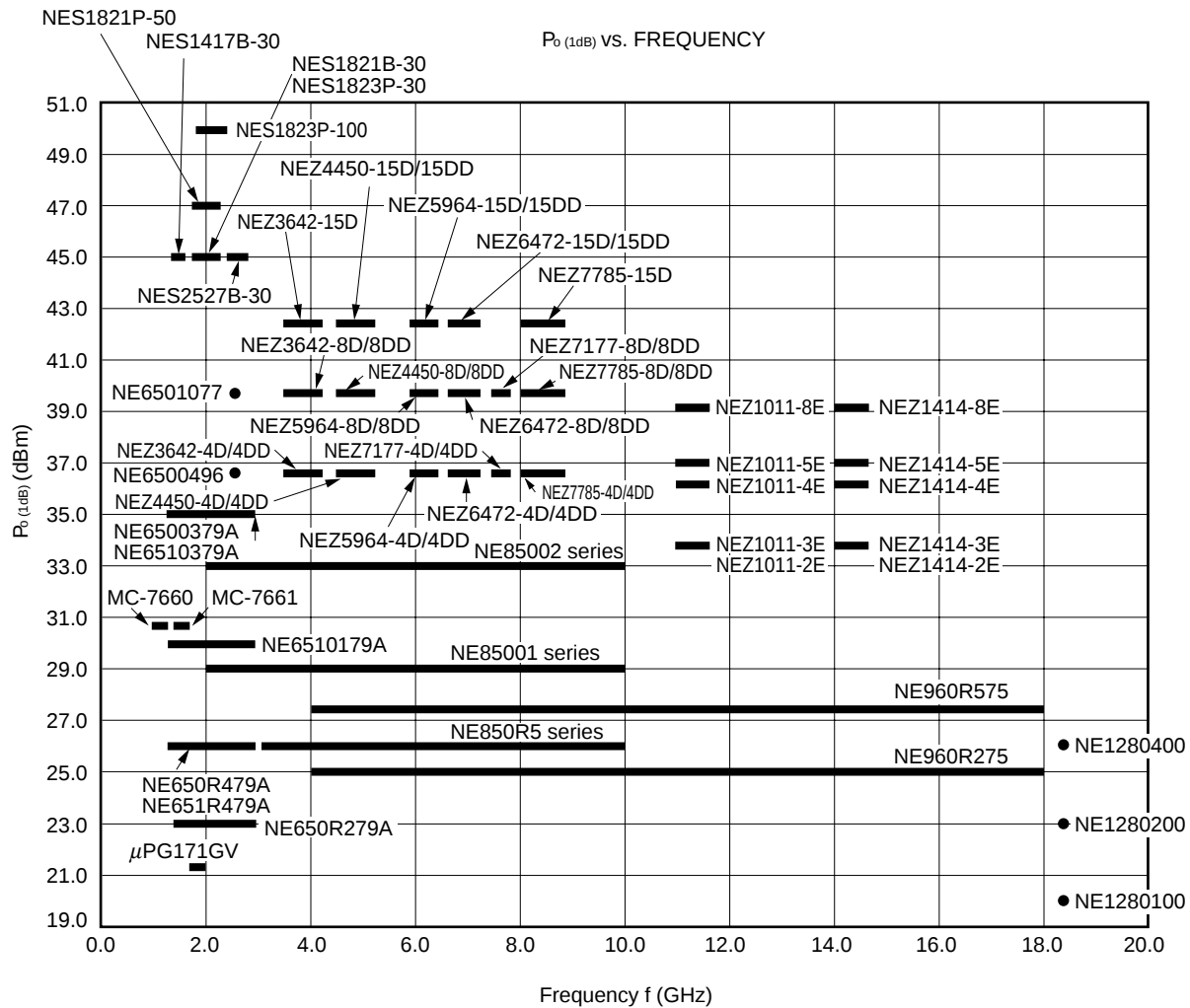
• Power TR. (for mobile and portable radio station)

Frequency	Output Power	
	0.1 W or higher	1 W or higher
1000 MHz or higher	2SC5288 2SC5289	—

Discrete

■ Cross-reference Table

• Power FET



Discrete

■ Cross-reference Table

• Silicon Microwave Single Transistor

Package fr (GHz)	μ -X	TO-92	Power MM (3-pin)	New Power MM (4-pin)	3-pin MM	3-pin SMM	4-pin MM	4-pin SMM	3-pin USMM (1608)	3-pin Thin USMM (1408)	6-pin SMM High Gain	4-pin SMM (R type)
1.0					2SC2758	2SC4183						
1.1					2SC2757	2SC4182						
2.0					2SC2759	2SC4185						
					2SC3545	2SC4184						
2.8	2SC2148											
4.0		2SC2408A	2SC2954									
					2SC3841	2SC4186						
					2SC3663	2SC4187	2SC4091					
4.5	2SC2149				2SC2351	2SC4225	2SC4092					
5.0		2SC2570A										
					2SC4569	2SC4571			2SC5004	2SC5431		
5.3			2SC4536	2SC5337								
5.5					2SC4568	2SC4570			2SC5005			
6.0			2SC4703	2SC5338								
7.0	2SC3603	2SC3355	2SC3357	2SC5336	2SC3356	2SC4226	2SC4093	2SC5011	2SC5006	2SC5432		
8.5	2SC3604	2SC3582			2SC3583	2SC4227	2SC4094	2SC5012	2SC5007	2SC5433		
10.0 ^{*1}	2SC3587				2SC3585	2SC4228	2SC4095	2SC5013	2SC5008	2SC5434		
					2SC5191	2SC5193	2SC5192	2SC5194	2SC5195	2SC5437		
11.0							2SC5455					
12.0 ^{*2}					2SC4954	2SC4958	2SC4956	2SC5014	2SC5009			
					2SC4955	2SC4959	2SC4957	2SC5015	2SC5010	2SC5435		
14.0 ^{*2}							2SC5454				2SC5369	
15.5 ^{*2}					2SC5177	2SC5179	2SC5178	2SC5180	2SC5181			
					2SC5182	2SC5184	2SC5183	2SC5185	2SC5186	2SC5436		
16.0											2SC5409 (2SC5533 ^{*3})	
17.0											2SC5408	2SC5509
25.0												2SC5507
												2SC5508

*1: Lower stage: Low operation voltage and low phase noise type.

*2: Upper stage: Low power dissipation type. Lower stage: Low noise figure type.

*3: 2SC5533 is a thin type of 2SC5409.

Discrete

■ Cross-reference Table

• NE Part No.-EIAJ No.

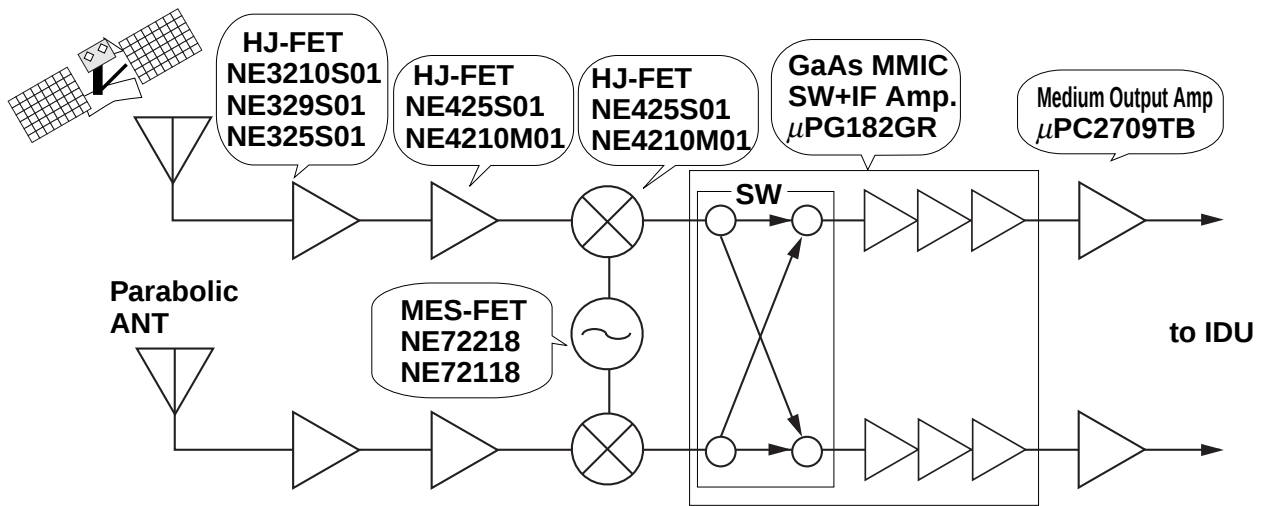
NE Part No.	EIAJ* No.
NE73416	2SC1733
NE73440A	2SC1926
NE73440B	2SC1927
NE73435	2SC2148
NE02135	2SC2149
NE02133	2SC2351
NE050214E-12	2SC2586
NE050214-12	2SC2762
NEM085068-28	2SC3218-M
NEM0214068-28	2SC3286-M
NE85632	2SC3355
NE85633	2SC3356
NE85634	2SC3357
NE94433	2SC3545
NE68132	2SC3582
NE68133	2SC3583
NE68033	2SC3585
NE68035	2SC3587
NE85635	2SC3603
NE68135	2SC3604
NE85641	2SC3809
NE68141	2SC3810
NEL150181-12	2SC3817
NE02139E	2SC4092
NE85639E	2SC4093
NE68139	2SC4094
NE68039	2SC4095
NE58030	2SC4183
NE73430	2SC4185
NE68330	2SC4187
NE85630	2SC4226
NE68130	2SC4227
NE68030	2SC4228
NE46134	2SC4536
NE58133	2SC4568
NE58233	2SC4569
NE58130	2SC4570
NE58230	2SC4571
NE46234	2SC4703
NE61030	2SC4885
NE68433	2SC4954
NE68533	2SC4955
NE68439E	2SC4956
NE68539E	2SC4957
NE68430	2SC4958
NE68530	2SC4959
NE58219	2SC5004
NE58119	2SC5005

NE Part No.	EIAJ* No.
NE85619	2SC5006
NE68119	2SC5007
NE68019	2SC5008
NE68419	2SC5009
NE68519	2SC5010
NE85618	2SC5011
NE68118	2SC5012
NE68018	2SC5013
NE68418	2SC5014
NE68518	2SC5015
NE68633	2SC5177
NE68639	2SC5178
NE68630	2SC5179
NE68618	2SC5180
NE68619	2SC5181
NE68733	2SC5182
NE68739	2SC5183
NE68730	2SC5184
NE68718	2SC5185
NE68719	2SC5186
NE68833	2SC5191
NE68839	2SC5192
NE68830	2SC5193
NE68818	2SC5194
NE68819	2SC5195
NE68939	2SC5288
NE69039	2SC5289
NE696M01	2SC5369
NEM0995F01-30	2SC2597
NE92939	3SK131
NE92739	3SK134B
NE25139	3SK177
NE25339	3SK206
NE92039	3SK222
NE92239	3SK223
NE92439	3SK224
NE93039	3SK230
NE93139	3SK231
NE92918	3SK242
NE92218	3SK243
NE92418	3SK244
NE92718	3SK245
NE92018	3SK246
NE93239	3SK252
NE93339	3SK253
NE93318	3SK255
NE25118	3SK299

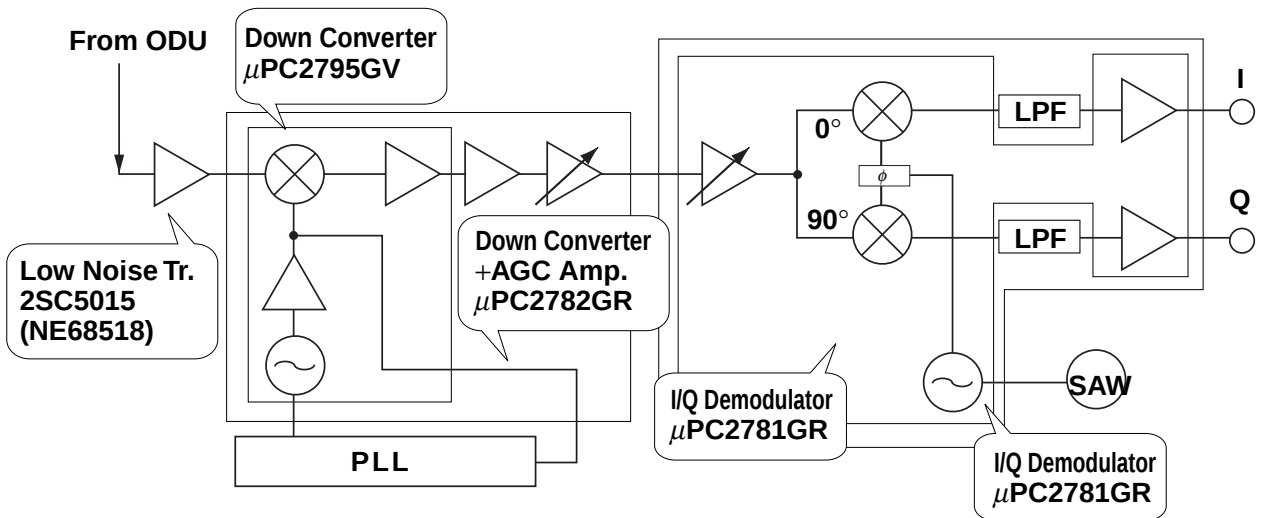
* : EIAJ = Electronics Industry Association Japan

Application

■ Digital DBS (1/2)

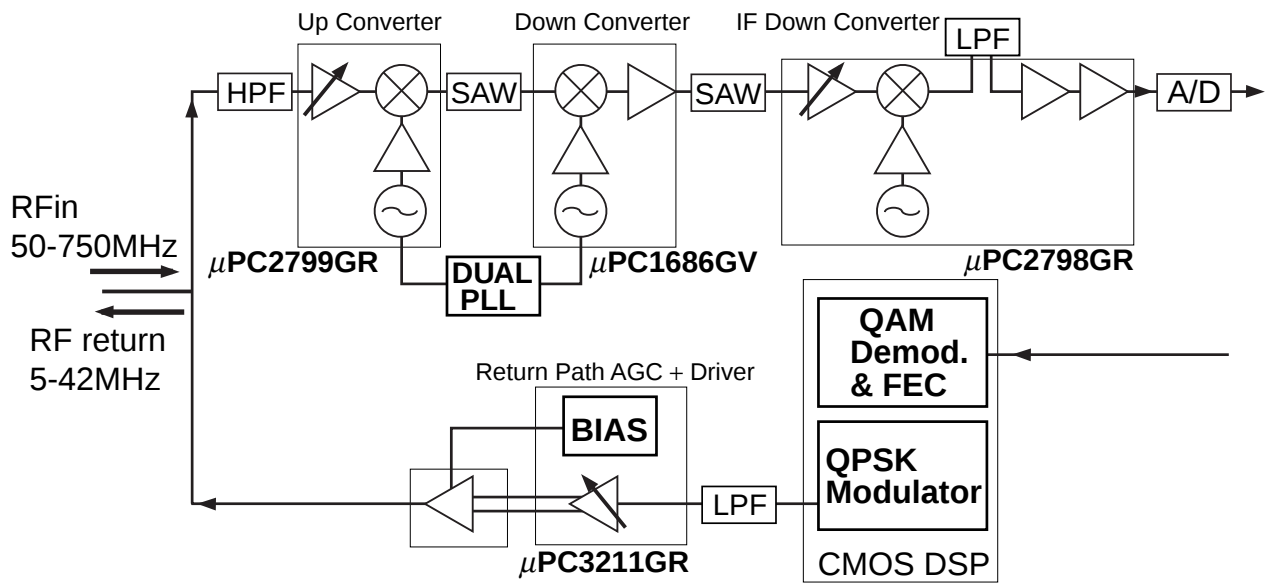


■ Digital DBS (2/2)



Application

■ Transceiver Block for Digital Cable Modem/CATV Set-top-box

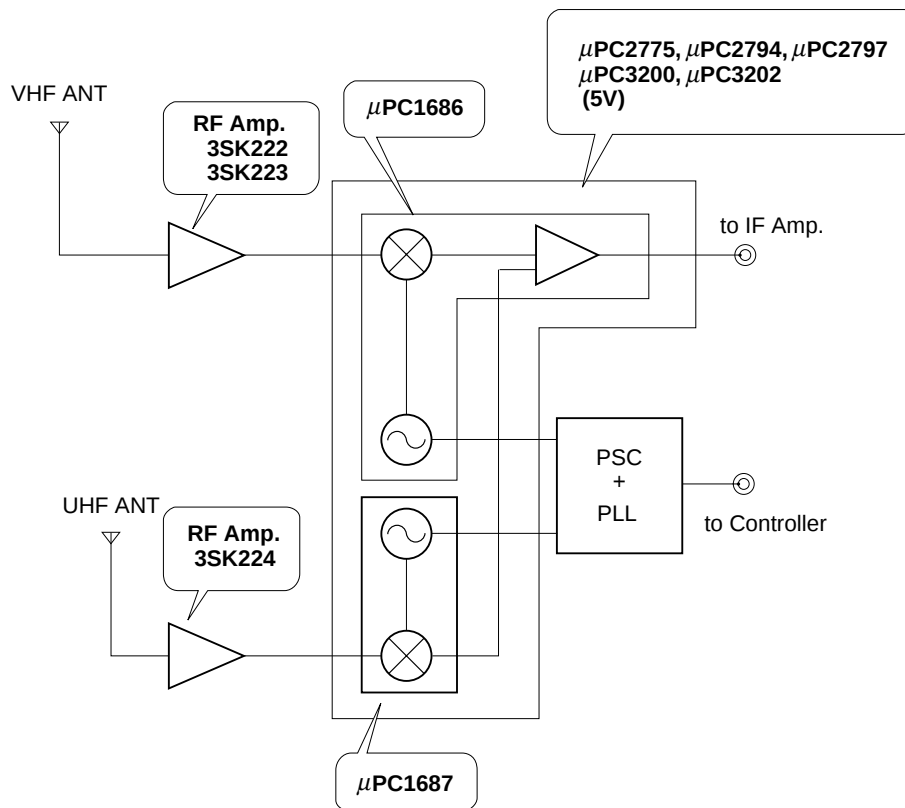


The diagram illustrates the receiver architecture. The signal path starts with an HPF (High Pass Filter) feeding into the Up Converter. The Up Converter consists of a variable gain amplifier, a mixer (represented by a circle with an 'X'), and a local oscillator (represented by a circle with a sine wave). The output of the Up Converter passes through a SAW (Surface Acoustic Wave) filter into the Down Converter. The Down Converter consists of a mixer, a local oscillator, and a variable gain amplifier. The output of the Down Converter passes through another SAW filter into the IF Down Converter. The IF Down Converter consists of a variable gain amplifier, a mixer, and a local oscillator. The output of the IF Down Converter passes through a LPF (Low Pass Filter) and then through two more variable gain amplifiers before entering the A/D (Analog-to-Digital) converter. The A/D converter output is fed into the QAM Demod. & FEC block. The control logic involves three microcontrollers: μPC2799GR, μPC1686GV, and μPC2798GR. μPC2799GR is connected to the HPF and the Up Converter. μPC1686GV is connected to the DUAL PLL, which in turn is connected to the local oscillators of the Up and Down Converters. μPC2798GR is connected to the local oscillator of the IF Down Converter and the LPF.

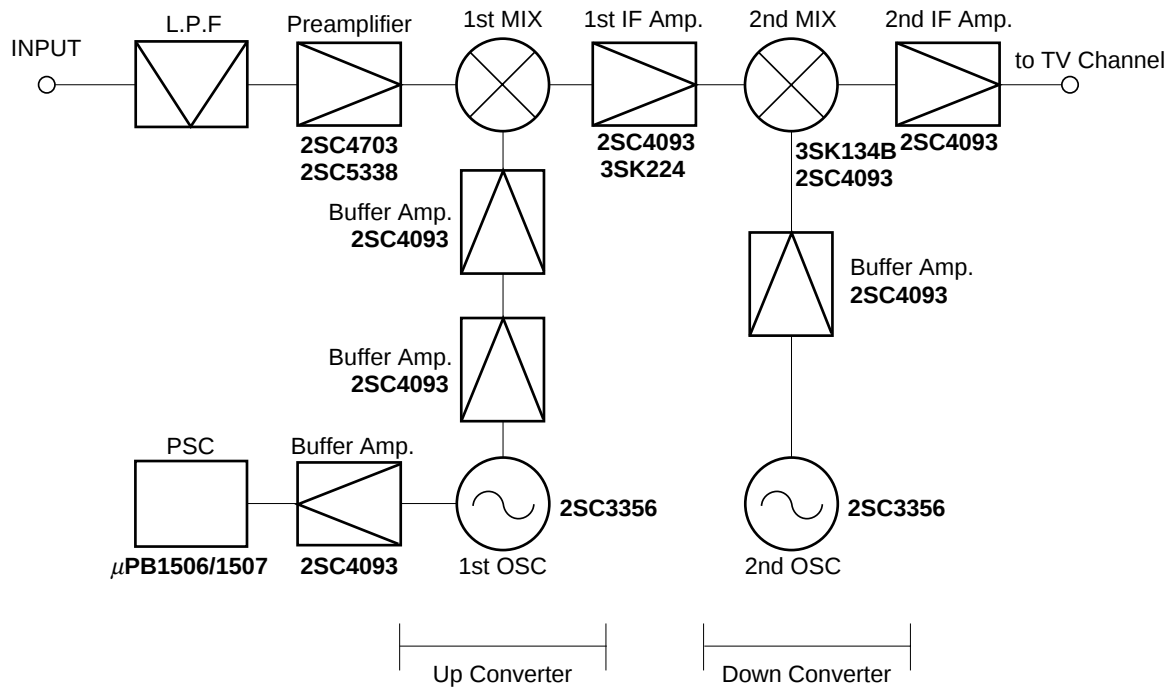
The diagram illustrates the receiver architecture of the $\mu\text{PC3206GR}$. The signal path begins with an HPF (High Pass Filter) leading into an Up Converter. The Up Converter is controlled by the $\mu\text{PC2799GR}$ and includes a variable gain amplifier, a mixer, and a local oscillator (represented by a sine wave symbol). The output of the Up Converter passes through a SAW (Surface Acoustic Wave) filter. This is followed by a Down Converter, which is controlled by the $\mu\text{PC1686GV}$ and also includes a variable gain amplifier, a mixer, and a local oscillator. The output of the Down Converter passes through another SAW filter. The signal then enters the IF AGC + Video Amp. block, which is controlled by the $\mu\text{PC3206GR}$. This block contains two variable gain amplifiers and a 50dB AGC (Automatic Gain Control) section. The output of the IF AGC + Video Amp. block passes through a LPF (Low Pass Filter) and then an A/D (Analog-to-Digital) converter. Finally, the digital signal is processed by the ASIC (Application Specific Integrated Circuit) for QAM Demod. & FEC (Forward Error Correction). A DUAL PLL (Dual Phase-Locked Loop) block is shown at the bottom, providing clock signals to the Up Converter, Down Converter, and the $\mu\text{PC3206GR}$.

Application

■ Terrestrial TV



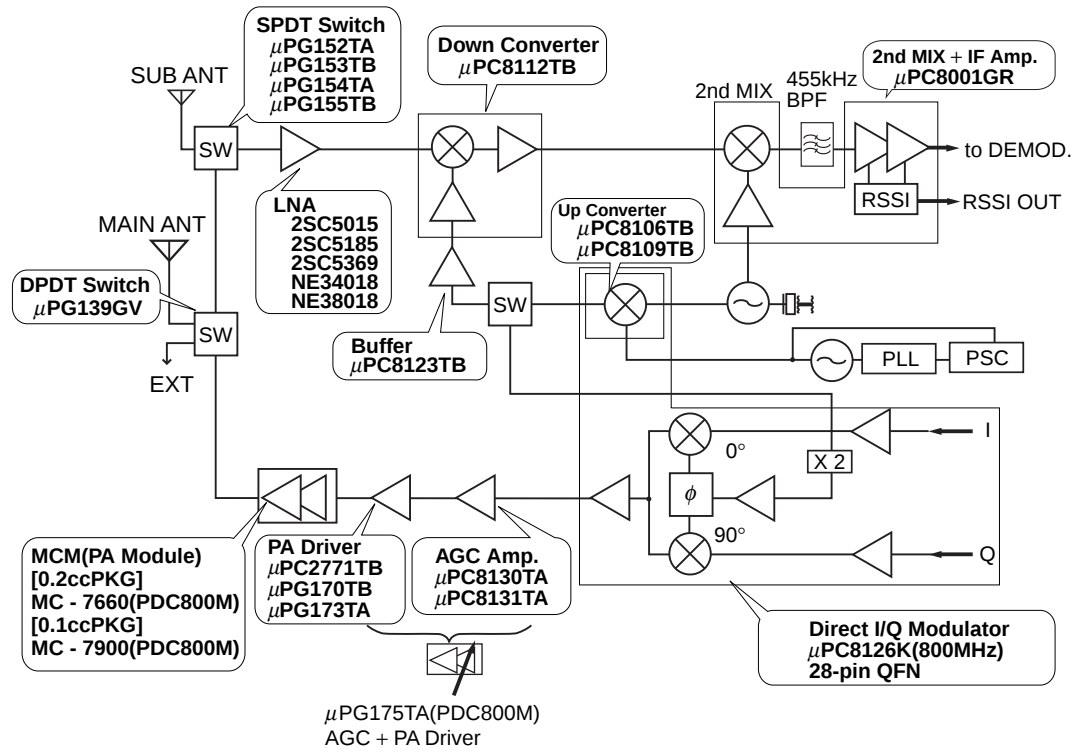
■ Block for Digital Cable Modem/CATV Converter



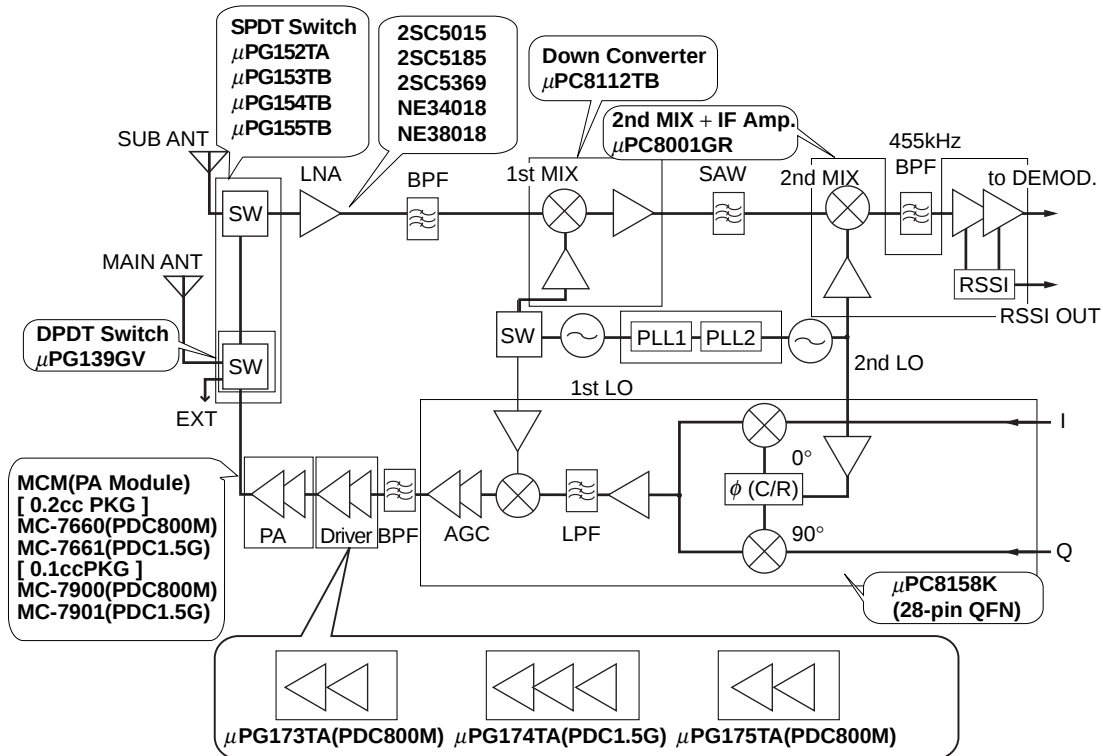
Application

■ PDC (RF Modulation System)

PDC 800M Direct Modulation System

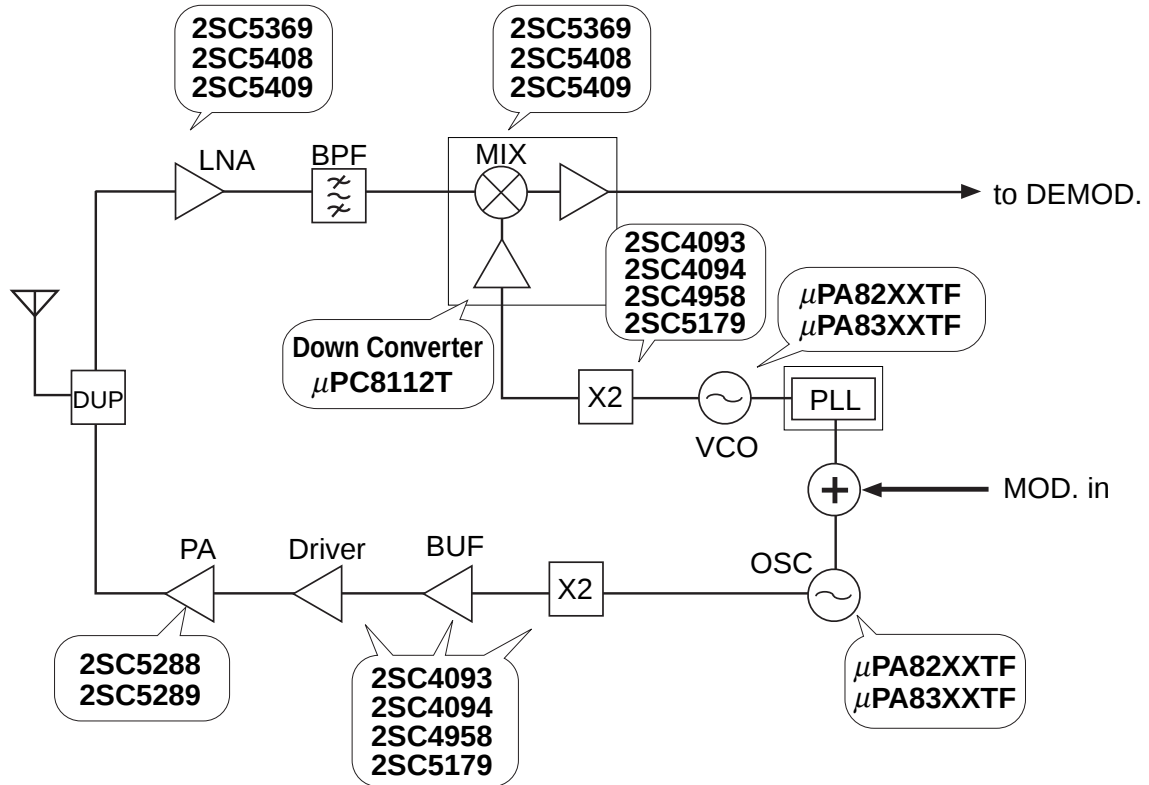


■ PDC (IF Modulation System)

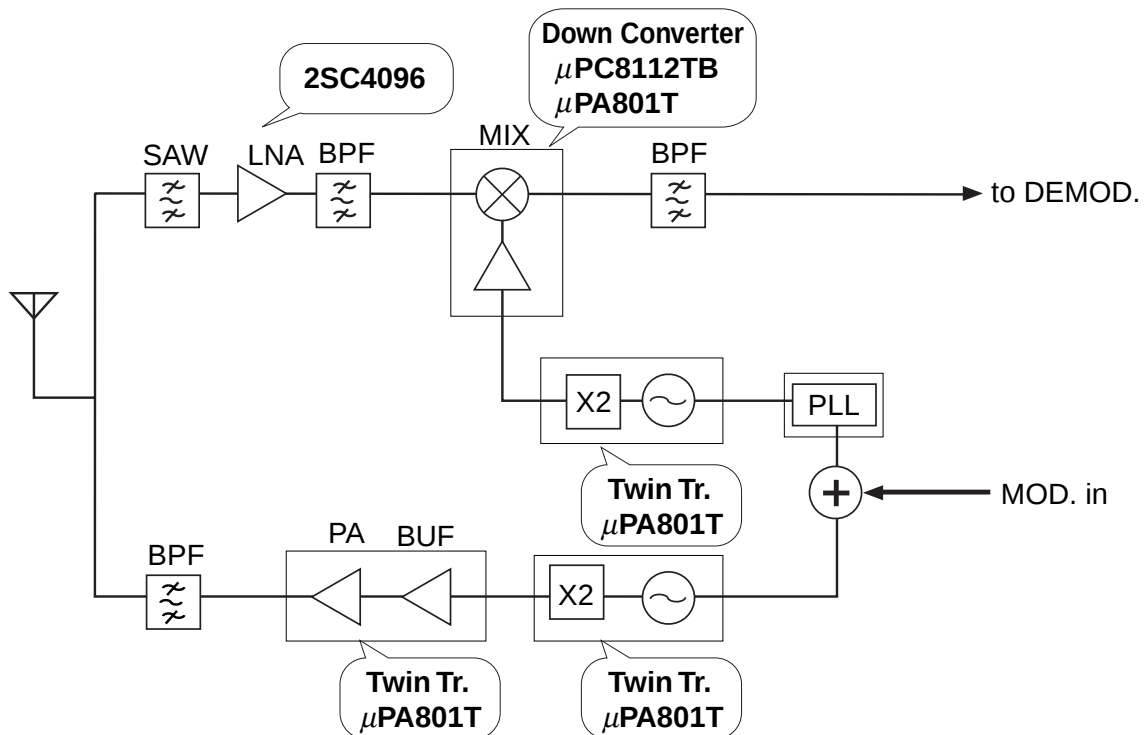


Application

■ 900 MHz Cordless Phone (1/2)



■ 900 MHz Cordless Phone (2/2)



[MEMO]

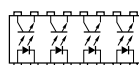
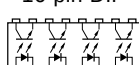
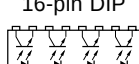
Optical Device

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Photocoupler

Tr. Output Type

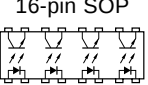
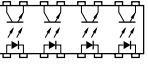
■ Standard Type (Single Tr.) (1/2)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages			
		BV (Vr.m.s.)	IF (mA)	V _{CEO} (V)	IC (mA)	CTR (%)	t _r , t _f (μs) TYP.				
PS2501-1	High isolation voltage High V _{CEO} UL approved	5 k	80	80	50	80 to 600	3, 5 (R _L = 100 Ω)	4-pin DIP 			
PS2501-2								8-pin DIP 			
PS2501-4								16-pin DIP 			
PS2511-1	High isolation voltage UL approved		50			100 to 300		80 to 400	4-pin DIP 		
PS2511-2									8-pin DIP 		
PS2511-4									16-pin DIP 		
PS2561-1	High isolation voltage UL, VDE (Option), CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved		80						4-pin DIP 		
PS2561-2										8-pin DIP 	
PS2571-1	High isolation voltage UL, CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved		50			100 to 300		80 to 400	4-pin DIP 		
PS2571-4									16-pin DIP 		
PS2581L1 PS2581L2	High isolation voltage Outer creepage distance: 8 mm UL, VDE (Standard), CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved		80						80 to 400	4-pin DIP 	
PS2601	High isolation voltage High V _{CEO} UL approved									80 to 600	6-pin DIP 
PS2602											6-pin DIP 

Photocoupler

Tr. Output Type

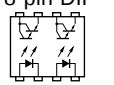
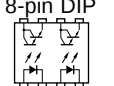
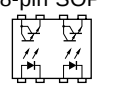
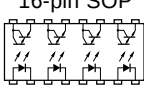
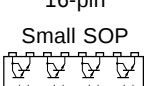
■ Standard Type (Single Tr.) (2/2)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	I _F (mA)	V _{CEO} (V)	I _C (mA)	CTR (%)	t _r , t _f (μs) TYP.	
PS2651	High isolation voltage UL, VDE (Option), CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved	5 k	80	80	50	50 to 400	3, 5 (R _L = 100 Ω)	6-pin DIP 
PS2652								6-pin DIP 
PS2701-1	UL, VDE (Option), BSI approved	3.75 k	50	40	80	50 to 300	3, 5 (R _L = 100 Ω)	4-pin SOP 
PS2701-2								8-pin SOP 
PS2701-4								16-pin SOP 
PS2801-1	Pin pitch: 1.27 mm UL, BSI approved	2.5 k	50	80	50	80 to 600	3, 5 (R _L = 100 Ω)	4-pin Small SOP 
PS2801-4	Pin pitch: 1.27 mm UL, VDE (Option), BSI approved							16-pin Small SOP 

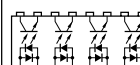
Photocoupler

Tr. Output Type

■ Standard Type (Darlington Tr.)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	IF (mA)	VCEO (V)	IC (mA)	CTR (%)	tr, trf (μs) TYP.	
PS2502-1	High isolation voltage High CTR UL approved	5 k	80	40	200	200 or above	100, 100 (RL = 100 Ω)	4-pin DIP 
PS2502-2					160			8-pin DIP 
PS2502-4								16-pin DIP 
PS2562-1	High isolation voltage UL, VDE (Option), CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved				200			4-pin DIP 
PS2562-2					160			8-pin DIP 
PS2603	High isolation voltage High CTR UL approved				200			6-pin DIP 
PS2604								6-pin DIP 
PS2653	High isolation voltage High CTR UL, VDE (Option), CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved							6-pin DIP 
PS2654								6-pin DIP 
PS2702-1	High CTR UL, VDE (Option), BSI approved	3.75 k	50	40	200	200 or above	200, 200 (RL = 100 Ω)	4-pin SOP 
PS2702-2					160			8-pin SOP 
PS2702-4								16-pin SOP 
PS2802-1	Pin pitch: 1.27 mm UL, BSI approved	2.5 k	50	40	90	200 or above	200, 200 (RL = 100 Ω)	4-pin Small SOP 
PS2802-4	Pin pitch: 1.27 mm UL, VDE (Option), BSI approved				100			16-pin Small SOP 

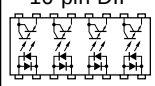
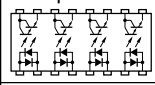
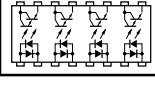
Photocoupler**Tr. Output Type****■ AC Input Type (Single Tr.)**

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	IF (mA)	VCEO (V)	IC (mA)	CTR (%)	tr, tf (μs) TYP.	
PS2505-1	High isolation voltage AC input High VCEO	5 k	±80	80	50	80 to 600	3, 5 (RL = 100 Ω)	4-pin DIP 
PS2505-2	UL approved							8-pin DIP 
PS2505-4								16-pin DIP 
PS2565-1	High isolation voltage AC input UL, VDE (Option), CSA,					80 to 400		4-pin DIP 
PS2565-2	BSI, SEMKO, FIMKO, NEMKO, DEMKO approved							8-pin DIP 
PS2605	High isolation voltage AC input High VCEO					80 to 600		6-pin DIP 
PS2606	UL approved							6-pin DIP 
PS2705-1	AC input UL, VDE (Option), BSI approved	3.75 k	±50	40	80	50 to 300	3, 5 (RL = 100 Ω)	4-pin SOP 
PS2705-2								8-pin SOP 
PS2705-4								16-pin SOP 
PS2805-1	Pin pitch: 1.27 mm AC input UL, BSI approved	2.5 k	±50	80	50	80 to 600	3, 5 (RL = 100 Ω)	4-pin Small SOP 
PS2805-4	Pin pitch: 1.27 mm AC input UL, VDE (Option), BSI approved							16-pin Small SOP 

Photocoupler

Tr. Output Type

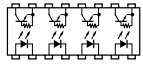
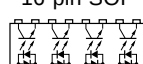
■ AC Input Type (Darlington Tr.)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	IF (mA)	VCEO (V)	IC (mA)	CTR (%)	tr, tr (μs) TYP.	
PS2506-1	High isolation voltage AC input High CTR	5 k	±80	40	200	200 or above	100, 100 (RL = 100 Ω)	4-pin DIP 
PS2506-2	UL approved				160			8-pin DIP 
PS2506-4								16-pin DIP 
PS2566-1	High isolation voltage AC input				200			4-pin DIP 
PS2566-2	UL, VDE (Option), CSA, BSI, SEMKO, FIMKO, NEMKO, DEMKO approved				160			8-pin DIP 
PS2607	High isolation voltage AC input High CTR				200			6-pin DIP 
PS2608	UL approved							6-pin DIP 
PS2706-1	High CTR AC input UL, VDE (Option), BSI approved	3.75 k	±50	40	200	200 or above	200, 200 (RL = 100 Ω)	4-pin SOP 
PS2706-2					160			8-pin SOP 
PS2706-4								16-pin SOP 
PS2806-1	Pin pitch: 1.27 mm AC input UL, BSI approved	2.5 k	±50	40	90	200 or above	200, 200 (RL = 100 Ω)	4-pin Small SOP 
PS2806-4	Pin pitch: 1.27 mm AC input UL, VDE (Option), BSI approved				100			16-pin Small SOP 

Photocoupler

Tr. Output Type

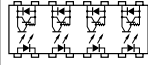
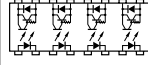
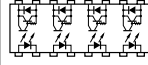
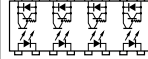
■ Low Input Current Type (Single Tr.)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	IF (mA)	V _{CEO} (V)	IC (mA)	CTR (%)	tr, tr (μs) TYP.	
PS2503-1	High isolation voltage High-speed UL approved	5 k	80	40	30	100 to 400	20, 30 (R _L = 10 kΩ)	4-pin DIP 
PS2503-2								8-pin DIP 
PS2503-4								16-pin DIP 
PS2703-1	High V _{CEO} (120 V) UL, VDE (Option), BSI approved	3.75 k	50	120	30	50 to 400	10, 10 (R _L = 1 kΩ)	4-pin SOP 
PS2703-2								8-pin SOP 
PS2703-4								16-pin SOP 
PS2707-1	AC input High V _{CEO} (120 V) UL, VDE (Option), BSI approved	3.75 k	±50	120	30	50 to 400	10, 10 (R _L = 1 kΩ)	4-pin SOP 
PS2707-2								8-pin SOP 
PS2707-4								16-pin SOP 

Photocoupler

Tr. Output Type

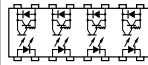
■ High Collector to Emitter Voltage Type (1/2)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages								
		BV (Vr.m.s.)	IF (mA)	V _{CEO} (V)	I _C (mA)	CTR (%)	t _r , t _f (μs) TYP.									
PS2532-1	High isolation voltage High V _{CEO} (300 V) Darlington Tr.	5 k	80	300	150	1500 to 6500	100, 100 (R _L = 100 Ω)	4-pin DIP 								
PS2532-2	UL, VDE, (Option), BSI, SEMKO, FIMKO, NEMKO, DEMKO			350				8-pin DIP 								
PS2532-4	approved							16-pin DIP 								
PS2533-1	High isolation voltage High V _{CEO} (350 V) Darlington Tr.							4-pin DIP 								
PS2533-2	UL, VDE (Option), BSI, SEMKO, FIMKO, NEMKO, DEMKO approved							8-pin DIP 								
PS2533-4								16-pin DIP 								
PS2633	High isolation voltage High V _{CEO} (300 V) High CTR			300		1000 to 15000		6-pin DIP 								
PS2634	Darlington Tr. UL approved			350				6-pin DIP 								
PS2732-1	High isolation voltage Darlington Tr. High V _{CEO} (300 V)							2.5 k	50	300	150	1500 or above	100, 100 (R _L = 100 Ω)	4-pin SOP 		
PS2732-2	UL, VDE (Option), BSI approved									350				8-pin SOP 		
PS2732-4		16-pin SOP 														
PS2733-1	High isolation voltage Darlington Tr. High V _{CEO} (350 V)	4-pin SOP 														
PS2733-2	UL, VDE (Option), BSI approved	8-pin SOP 														
PS2733-4		16-pin SOP 														

Photocoupler

Tr. Output Type

■ High Collector to Emitter Voltage Type (2/2)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	I _F (mA)	V _{CEO} (V)	I _C (mA)	CTR (%)	t _r , t _f (μs) TYP.	
PS2832-1	Pin pitch: 1.27 mm Darlington Tr. High V _{CEO} (300 V) UL approved	2.5 k	50	300	120	400 or above	100, 100 (R _L = 100 Ω)	4-pin Small SOP 
PS2832-4	Pin pitch: 1.27 mm Darlington Tr. High V _{CEO} (300 V) UL, BSI approved							16-pin Small SOP 

Photocoupler

Tr. Output Type

■ Large Input Current Type (DC Input, Single Tr.)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	IF (mA)	V _{CEO} (V)	IC (mA)	CTR (%)	t _r , t _f (μs) TYP.	
PS2521-1	High isolation voltage Large input current UL approved	5 k	150	80	50	20 to 80	3, 5 (R _L = 100 Ω)	4-pin DIP 
PS2521-2								8-pin DIP 
PS2521-4								16-pin DIP 
PS2621	High isolation voltage Large input current UL approved	5 k	150	80	50	20 to 50	3, 5 (R _L = 100 Ω)	6-pin DIP 
PS2622								6-pin DIP 

■ Large Input Current Type (AC Input, Single Tr.)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	IF (mA)	V _{CEO} (V)	IC (mA)	CTR (%)	t _r , t _f (μs) TYP.	
PS2525-1	High isolation voltage Large input current AC input UL approved	5 k	±150	80	50	20 to 80	3, 5 (R _L = 100 Ω)	4-pin DIP 
PS2525-2								8-pin DIP 
PS2525-4								16-pin DIP 
PS2625	High isolation voltage Large input current AC input UL approved	5 k	±150	80	50	20 to 50	3, 5 (R _L = 100 Ω)	6-pin DIP 
PS2626								6-pin DIP 

Photocoupler

IC Output Type

■ High-Speed Type 1Mbps (Analog Output)

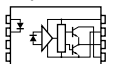
Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics			Packages
		BV (Vr.m.s.)	I _F (mA)	V _{CC} (V)	I _O (mA)	CTR (%)	t _{PHL} (μs) MAX. (R _L = 1.9 kΩ)	t _{PLH} (μs) MAX. (R _L = 1.9 kΩ)	
PS8601	8-pin base connection UL, VDE (Option), BSI approved	5 k	25	35	8	15 or above	0.8 (R _L = 1.9 kΩ)	0.8 (R _L = 1.9 kΩ)	8-pin DIP 
PS8602	8 pins High CMR (2 kV/μs) UL, VDE (Option), BSI approved								8-pin DIP 
PS8701	5 pins High CMR (10 kV/μs) UL, VDE (Option) approved	2.5 k	25	35	8	15 to 35	0.8 (R _L = 2.2 kΩ)	1.2 (R _L = 2.2 kΩ)	5-pin SOP 

■ High-Speed Type 10Mbps (Digital Output)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	I _F (mA)	V _{CC} (V)	I _O (mA)	I _{FLH} (mA) MAX.	t _{PLH} , t _{PHL} (ns) MAX.	
PS9601	Ultra high-speed type UL approved	5 k	30	7	50	5.0	75	8-pin DIP 
PS9701	Ultra high-speed type UL, VDE (option) approved	2.5 k	30	7	50	5.0	75	5-pin SOP 
PS9611★	Ultra high-speed type High CMR (10 kV/μs TYP.)	5 k	30	7	13	6.0	75	8-pin DIP 
PS9711★		2.5 k	30	7	13	6.0	75	5-pin SOP 

★ : Under development

■ High-Power Type (Inverter)

Part Number	Features	Absolute Maximum Ratings				Electrical Characteristics		Packages
		BV (Vr.m.s.)	I _F (mA)	V _{CC} (V)	I _{O1} /I _{O2} (A)	CM _H , CM _L (kV/μs)	t _{PLH} , t _{PHL} (μs) MAX.	
PS9634	Inverter circuit UL approved	5 k	30	18	0.5/ 0.8	1.0	5.0	8-pin DIP 

Photocoupler

■ Safety Standards Approval List (Made in Japan, as of January 1999) (1/2)

Part Number	Safety Standards								
	UL		VDE	CSA	BSI	SEMKO	FIMKO	NEMKO	DEMKO
	UL1577 E72422(S)		VDE0884	CL 9073 × 0030, CA 101391	EN 60065 /IEC 65, EN 60950 /IEC 950	EN 60065 /IEC 60065, EN 60950 /IEC 60950	EN 60065 /IEC 65, EN 60950 /IEC 950	EN 60065 /IEC 65, EN 60950 /IEC 950	EN 60065 /IEC 60665, EN 60950 /IEC 950
	Single protection	Double protection							
PS2501-1, -2, -4	●	●							
PS2502-1, -2, -4	●	●							
PS2503-1, -2, -4	●								
PS2505-1, -2, -4	●	●							
PS2506-1, -2, -4	●	●							
PS2511-1, -2, -4	●								
PS2521-1, -2, -4	●								
PS2525-1, -2, -4	●								
PS2532-1, -2, -4	●		●		●	●	●	●	●
PS2533-1, -2, -4	●		●		●	●	●	●	●
PS2561-1, -2	●	●	●	●	●	●	●	●	●
PS2562-1, -2	●	●	●	●	●	●	●	●	●
PS2565-1, -2	●	●	●	●	●	●	●	●	●
PS2566-1, -2	●	●	●	●	●	●	●	●	●
PS2571-1, -4	●		△	●	●	●	●	●	●
PS2581L1, L2	●	●	●	●	●	●	●	●	●
PS2601	●								
PS2602	●								
PS2603	●								
PS2604	●								
PS2605	●								
PS2606	●								
PS2607	●								
PS2608	●								
PS2621	●								
PS2622	●								
PS2625	●								
PS2626	●								

Remark ●: Approved △: Awaiting approval

Photocoupler

■ Safety Standards Approval List (Made in Japan, as of January 1999) (2/2)

Part Number	Safety Standards								
	UL		VDE	CSA	BSI	SEMKO	FIMKO	NEMKO	DEMKO
	UL1577 E72422(S)		VDE0884	CL 9073 × 0030, CA 101391	EN 60065 /IEC 65, EN 60950 /IEC 950	EN 60065 /IEC 60065, EN 60950 /IEC 60950	EN 60065 /IEC 65, EN 60950 /IEC 950	EN 60065 /IEC 65, EN 60950 /IEC 950	EN 60065 /IEC 60665, EN 60950 /IEC 950
	Single protection	Double protection							
PS2633	●								
PS2634	●								
PS2651	●		●	●	●	●	●	●	●
PS2652	●		●	●	●	●	●	●	●
PS2653	●		●	●	●	●	●	●	●
PS2654	●		●	●	●	●	●	●	●
PS2701-1, -2, -4	●		●		●				
PS2702-1, -2, -4	●		●		●				
PS2703-1, -2, -4	●		●		●				
PS2705-1, -2, -4	●		●		●				
PS2706-1, -2, -4	●		●		●				
PS2707-1, -2, -4	●		●		●				
PS2732-1, -2, -4	●		●		●				
PS2733-1, -2, -4	●		●		●				
PS2801-1	●				●				
PS2802-1	●				●				
PS2805-1	●				●				
PS2806-1	●				●				
PS2801-4	●		●		●				
PS2802-4	●		●		●				
PS2805-4	●		●		●				
PS2806-4	●		●		●				
PS2832-1	●								
PS2832-4	●				●				
PS8601	●		●		●				
PS8602	●		●		●				
PS8701	●		●						
PS9601	●								
PS9634	●								
PS9701	●		●						

Remark ●: Approved

Photocoupler

■ Safety Standards Approval List (Made in Taiwan, as of January 1999)

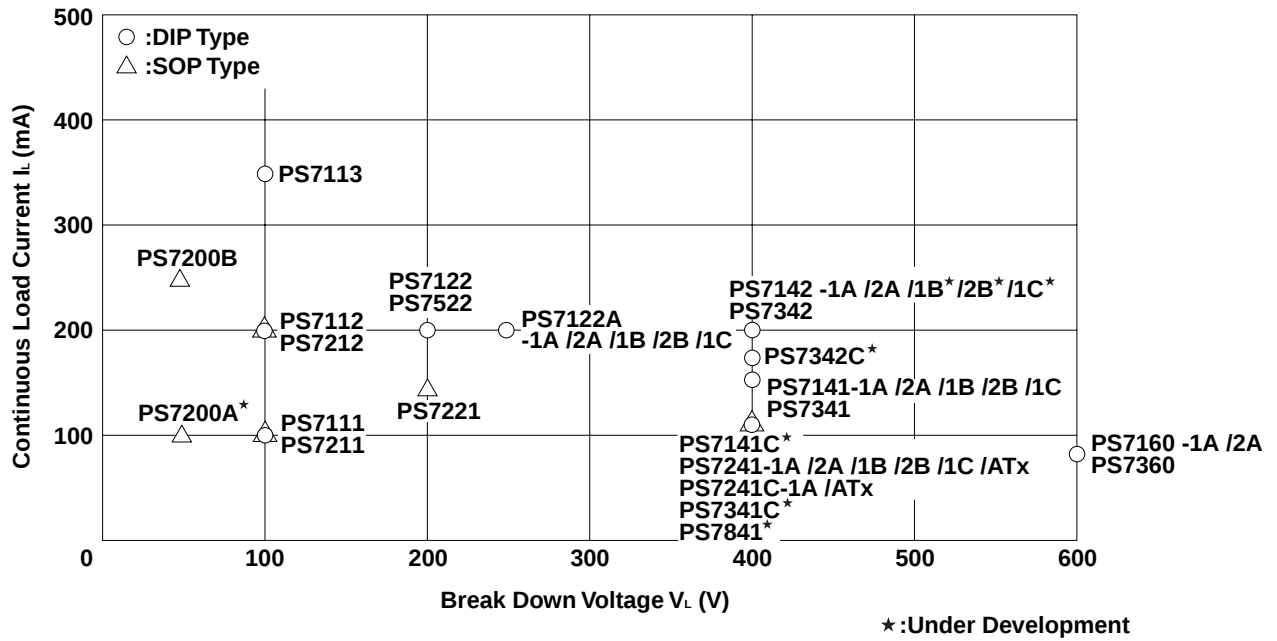
Part Number	Safety Standards								
	UL		VDE	CSA	BSI	SEMKO	FIMKO	NEMKO	DEMKO
	UL1577 E72422(S)		VDE0884	CL	EN 60065	EN 60065	EN 60065	EN 60065	EN 60065
	Single protection	Double protection		9073 × 0030, CA 101391	/IEC 65, EN 60950 /IEC 950	/IEC 60065, EN 60950 /IEC 60950	/IEC 65, EN 60950 /IEC 950	/IEC 65, EN 60950 /IEC 950	/IEC 60665, EN 60950 /IEC 950
PS2501-1, -2, -4	●								
PS2502-1, -2, -4	●								
PS2503-1, -2, -4	●								
PS2505-1, -2, -4	●								
PS2506-1, -2, -4	●								
PS2521-1, -2, -4	●								
PS2525-1, -2, -4	●								
PS2532-1, -2, -4	●		●		●				
PS2533-1, -2, -4	●		●		●				
PS2561-1, -2	●	●	●			●	●	●	●
PS2562-1, -2	●	●	●			●	●	●	●
PS2565-1, -2	●	●	●			●	●	●	●
PS2566-1, -2	●	●	●			●	●	●	●

Remark ●: Approved

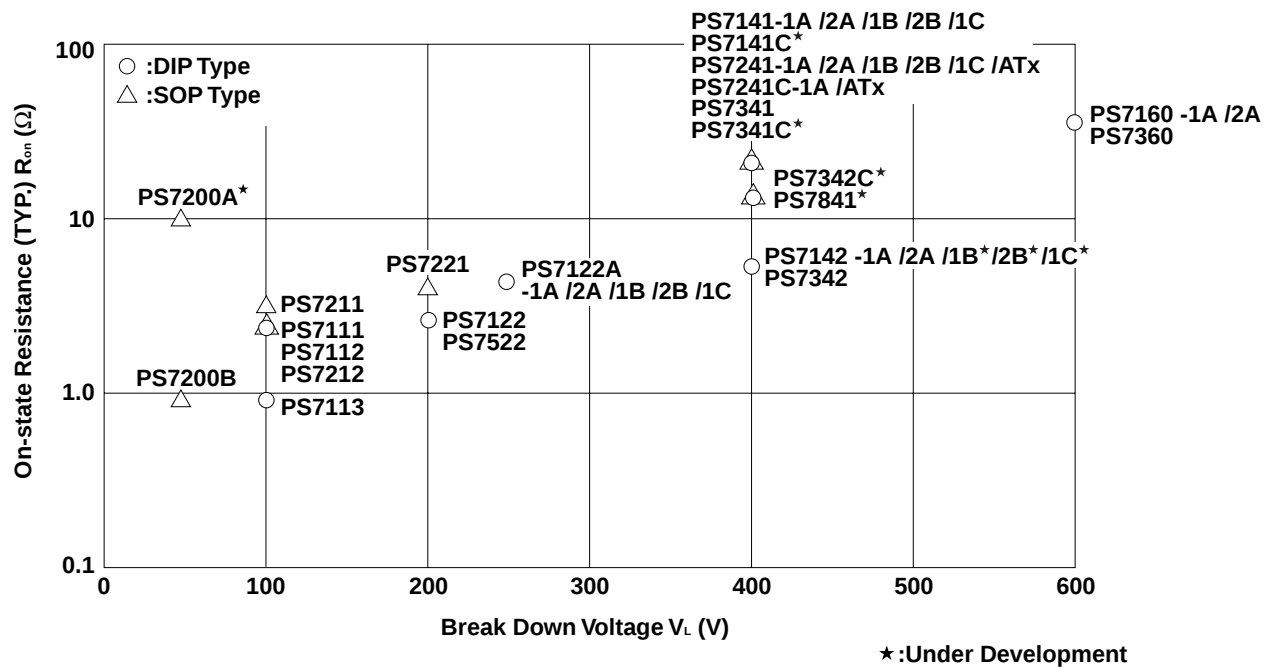
OCMOS FET™ (Opto-Coupled MOS FET Relay)

OCMOS FET Product Map

Continuous Load Current vs. Break Down Voltage



On-state Resistance vs. Break Down Voltage



OCMOS FET (Opto-Coupled MOS FET Relay)

■ Standard Type

Part Number	Features	Output Type	Absolute Maximum Ratings					Electrical Characteristics						Packages
			V _L (V)	I _L (mA)	BV (Vr.m.s.)	T _A (°C)	T _{stg} (°C)	Diode		MOSFET	Coupled			
								V _F (V) MAX.	I _R (μA) MAX.	I _{Loff} (μA) MAX.	R _{on} (Ω) TYP.	t _{on} (ms) MAX.	t _{off} (ms) MAX.	
PS7111-2A	Standard DIP,	2a	100	100	1.5 k	−40 to +80	−40 to +100	1.4	5	1	3.0	0.4	0.2	8-pin DIP
PS7112-1A	Normally open	1a	100	200							3.0	0.4	0.2	6-pin DIP
PS7113-1A		1a	100	350							0.9	3.0	0.2	6-pin DIP
PS7113-2A		2a	100	350							0.9	3.0	0.2	8-pin DIP
PS7122-1A		1a	200	200							3.0	2.0	0.2	6-pin DIP
PS7122-2A		2a	200	200							3.0	2.0	0.2	8-pin DIP
PS7122A-1A		1a	250	200							4.5	1.5	0.2	6-pin DIP
PS7122A-2A		2a	250	200							4.5	1.5	0.2	8-pin DIP
PS7141-1A		1a	400	150							20.0	1.0	0.2	6-pin DIP
PS7141-2A		2a	400	150							20.0	1.0	0.2	8-pin DIP
PS7142-1A		1a	400	200							6.0	5.0	0.2	6-pin DIP
PS7142-2A		2a	400	200							7.5	2.0	0.2	8-pin DIP
PS7160-1A		1a	600	90							42.0	1.5	0.2	6-pin DIP
PS7160-2A		2a	600	90							42.0	1.5	0.2	8-pin DIP
PS7211-2A		Standard SOP,	2a	100	100	1.5 k	−40 to +80	−40 to +100	1.4	5	1	3.4	1.0	0.2
PS7212-1A	Normally open	1a	100	200	3.0							1.0	0.2	4-pin SOP
PS7221-2A		2a	200	150	4.0							1.5	0.2	8-pin SOP
PS7241-1A		1a	400	120	18.0							2.0	0.2	4-pin SOP
PS7241-2A		2a	400	120	21.0							1.0	0.2	8-pin SOP
PS7200A-1A★	Low CxR type	1a	40	100	1.5 k	−40 to +80	−40 to +100	1.4	5	0.1	9.3	0.5	0.2	4-pin SOP
PS7200B-1A		1a	40	250							0.8	1.0	0.2	4-pin SOP
PS7122A-1B	Standard, Normally close	1b	250	200	1.5 k	−40 to +80	−40 to +100	1.4	5	1	4.5	0.2	1.5	6-pin DIP
PS7122A-2B		2b	250	200							4.5	0.2	1.5	8-pin DIP
PS7141-1B		1b	400	150							24.0	0.2	1.0	6-pin DIP
PS7141-2B		2b	400	150							24.0	0.2	1.0	8-pin DIP
PS7142-1B★		1b	400	200							7.0	0.2	5.0	6-pin DIP
PS7142-2B★		2b	400	200							7.0	0.2	5.0	8-pin DIP
PS7241-1B		1b	400	120							24.0	0.2	2.0	4-pin SOP
PS7241-2B		2b	400	120							21.0	0.2	1.0	8-pin SOP
PS7122A-1C	Standard, Transfer	1a+1b	250	200	1.5 k	−40 to +80	−40 to +100	1.4	5	1	4.5	1.5 (N.O.) 0.2 (N.C.)	0.2 (N.O.) 1.5 (N.C.)	8-pin DIP
PS7141-1C		1a+1b	400	150							20.0 (N.O.) 24.0 (N.C.)	1.0 (N.O.) 0.2 (N.C.)	0.2 (N.O.) 1.0 (N.C.)	8-pin DIP
PS7142-1C★		1a+1b	400	200							8.0 (N.O.) 7.0 (N.C.)	2.0 (N.O.) 0.2 (N.C.)	0.2 (N.O.) 2.0 (N.C.)	8-pin DIP
PS7241-1C		1a+1b	400	120							21.0	1.0 (N.O.) 0.2 (N.C.)	0.2 (N.O.) 1.0 (N.C.)	8-pin SOP

★: Under development

OCMOS FET (Opto-Coupled MOS FET Relay)

■ High Isolation Voltage Type

Part Number	Features	Output Type	Absolute Maximum Ratings					Electrical Characteristics						Packages
			V _L (V)	I _L (mA)	BV (Vr.m.s.)	T _A (°C)	T _{stg} (°C)	Diode		MOSFET	Coupled			
								V _F	I _R	I _{Loff}	R _{on}	t _{on}	t _{off}	
								(V) MAX.	(μA) MAX.	(μA) MAX.	(Ω) TYP.	(ms) MAX.	(ms) MAX.	
PS7341-1A	High isolation voltage	1a	400	150	3.75 k	−40 to +85	−40 to +125	1.4	5	1	20.0	1.0	0.2	6-pin DIP
PS7342-1A			400	200							6.0	2.5	0.2	
PS7360-1A			600	90							41.0	2.0	0.2	

■ Slow Speed Type

Part Number	Features	Output Type	Absolute Maximum Ratings					Electrical Characteristics						Packages
			V _L (V)	I _L (mA)	BV (Vr.m.s.)	T _A (°C)	T _{stg} (°C)	Diode		MOSFET	Coupled			
								V _F	I _R	I _{Loff}	R _{on}	t _{on}	t _{off}	
								(V) MAX.	(μA) MAX.	(μA) MAX.	(Ω) TYP.	(ms) MAX.	(ms) MAX.	
PS7522-1A	Slow speed	1a	200	200	1.5 k	−40 to +80	−40 to +100	1.4	5	1	3.0	12.0	6.5	6-pin DIP
PS7522-2A		2a	200	200	1.5 k	−40 to +80	−40 to +100	1.4	5	1	3.0	12.0	6.5	8-pin DIP

■ Hybrid (Multi Function) Type

Part Number	Features	BV (Vr.m.s.)	OCMOS FET (1a type)			Photocoupler		Diode Bridge		Darlington Tr.			Packages
			V _L	I _L	R _{on}	V _{CEO}	CTR	V _R	V _F	V _{CEO}	I _C	h _{FE}	
			(V)	(mA)	(Ω) TYP.	(V)	(%)	(V) MAX.	(V) MAX.	(V)	(mA)		
PS7241-AT1* ¹	DC Input	1.5 k	400	120	20.0	40	50	-	-	-	-	-	8-pin SOP
PS7241-AT5* ¹	AC Input						to 400						
PS7841-A15* ²	for DAA		400	120	16	40	50 to 400	100	1.2	40	120	10000 to 30000	16-pin SOP Lead pitch: 1.27 mm

★: Under development

- *1: Solid state relays containing a GaAs LED on light emitting side (input side) and MOSFET's (+Photo transistor) on output side.
- *2: The PS7841-A15 is a solid state relay for optical DAA (Data Access Arrangement) containing a diode bridge, MOS FET, photocoupler, Darlington transistor and LED.

OCMOS FET (Opto-Coupled MOS FET Relay)

■ Current Limit Type

• Standard Type

Part Number	Output Type	Absolute Maximum Ratings					Electrical Characteristics							Packages
		V _L (V)	I _L (mA)	BV (Vr.m.s.)	T _A (°C)	T _{stg} (°C)	Diode		MOSFET	Coupled				
							V _F	I _R	I _{Loff}	R _{on}	t _{on}	t _{off}	I _{LMT}	
							(V)	(μA)	(μA)	(Ω)	(ms)	(ms)	(mA)	
							MAX.	MAX.	MAX.	TYP.	MAX.	MAX.		
PS7141C-2A★	2a	400	120	1.5 k	−40 to +80	−40 to +100	1.4	5	1	26.0	1.0	1.0	170 to 250 mA/ch	8-pin DIP
PS7241C-1A	1a	400	120	1.5 k	−40 to +80	−40 to +100	1.4	5	1	28.0	2.0	0.2	125 to 180	4-pin SOP

★: Under development

• High Isolation Voltage Type

Part Number	Output Type	Absolute Maximum Ratings					Electrical Characteristics							Packages
		V _L (V)	I _L (mA)	BV (Vr.m.s.)	T _A (°C)	T _{stg} (°C)	Diode		MOSFET	Coupled				
							V _F (V)	I _R (μA)	I _{Loff} (μA)	R _{on} (Ω)	t _{on} (ms)	t _{off} (ms)	I _{LMT} (mA)	
							MAX.	MAX.	MAX.	TYP.	MAX.	MAX.		
PS7341C-1A★	1a	400	120	3.75 k	−40 to	−40 to	1.4	5	1	27.0	1.0	1.0	125 to 250	6-pin DIP
PS7342C-1A★		400	170		+85	+125					12.0	5.0	1.0	

★: Under development

• Hybrid (Multi Function) Type

Part Number	Features	BV (Vr.m.s.)	OCMOS FET (1a type)				Photocoupler		Packages
			V _L (V)	I _L (mA)	R _{on} (Ω) TYP.	I _{LMT} (mA)	V _{CEO} (V)	CTR (%)	
PS7241C-AT1*	DC Input	1.5 k	400	120	28.0	125 to 180	40	50 to 400	8-pin SOP
PS7241C-AT5*	AC Input								

*: Solid state relays containing a GaAs LED on light emitting side (input side) and MOSFET's (+Photo transistor) on output side.

OCMOS FET (Opto-Coupled MOS FET Relay)

■ Safety Standards Approval List (as of January 1999)

Part Number	Safety Standards		
	UL	VDE	BSI
	UL1577	VDE0884	BS415 BS7002
PS7111-2A	●	△	●
PS7112-1A	●	△	●
PS7113-1A	●	△	●
PS7113-2A	●	△	●
PS7122-1A	●	△	●
PS7122-2A	●	△	●
PS7122A-1A	△	△	△
PS7122A-1B	△	△	△
PS7122A-1C	△	△	△
PS7122A-2A	△	△	△
PS7122A-2B	△	△	△
PS7141-1A	●	△	●
PS7141-1B	●	△	●
PS7141-1C	●	△	●
PS7141-2A	●	△	●
PS7141-2B	●	△	●
PS7141C-2A★	△	△	△
PS7142-1A	●	△	●
PS7142-2A	●	△	●
PS7142-1B★	△	△	△
PS7142-2B★	△	△	△
PS7142-1C★	△	△	△
PS7160-1A	●	△	●
PS7160-2A	●	△	●
PS7200A-1A★	△	△	●
PS7200B-1A	△	△	●
PS7211-2A	●	△	●
PS7212-1A	△	△	△
PS7221-2A	●	△	●
PS7241-1A	●	△	●
PS7241-1B	●	△	●
PS7241-1C	△	△	●
PS7241-2A	△	△	●
PS7241-2B	△	△	●
PS7241-AT1	●	△	●
PS7241-AT5	●	△	●
PS7241C-1A	●	△	△
PS7241C-AT1	△	△	△
PS7241C-AT5	△	△	△
PS7341-1A	●	△	●
PS7341C-1A★	●	△	△
PS7342-1A	●	△	●
PS7342C-1A★	●	△	△
PS7360-1A	●	△	●
PS7522-1A	●	△	●
PS7522-2A	●	△	●
PS7841-A15★	△	△	△

★: Under development

Remark ●: Approved △: Awaiting approval

Infrared Transceivers

■ Infrared Transceivers

Part Number	IrDA Ver.	Absolute Maximum Ratings (T _A = 25 °C)		Electro-Optical Characteristics (T _A = 25 °C)					Remarks
		T _A (°C)	T _{stg} (°C)	V _{CC} (V)	I _{LED} (mA) TYP.	I _{EH} (mW/Sr) TYP.	I _{CC} (A) TYP.	Data Rate (bps)	
NL1000★	1.0	0 to +70	−25 to +85	3.3	150	80	150 μ	2.4 k to 115.2 k	Standard: with Shield Case
NL1100	1.1	0 to +70	−25 to +85	5.0	300	160	4.0 m	A Port: 2.4 k to 115.2 k B Port: 0.576 M to 4.0 M	Option: Shield Case

★: Under development

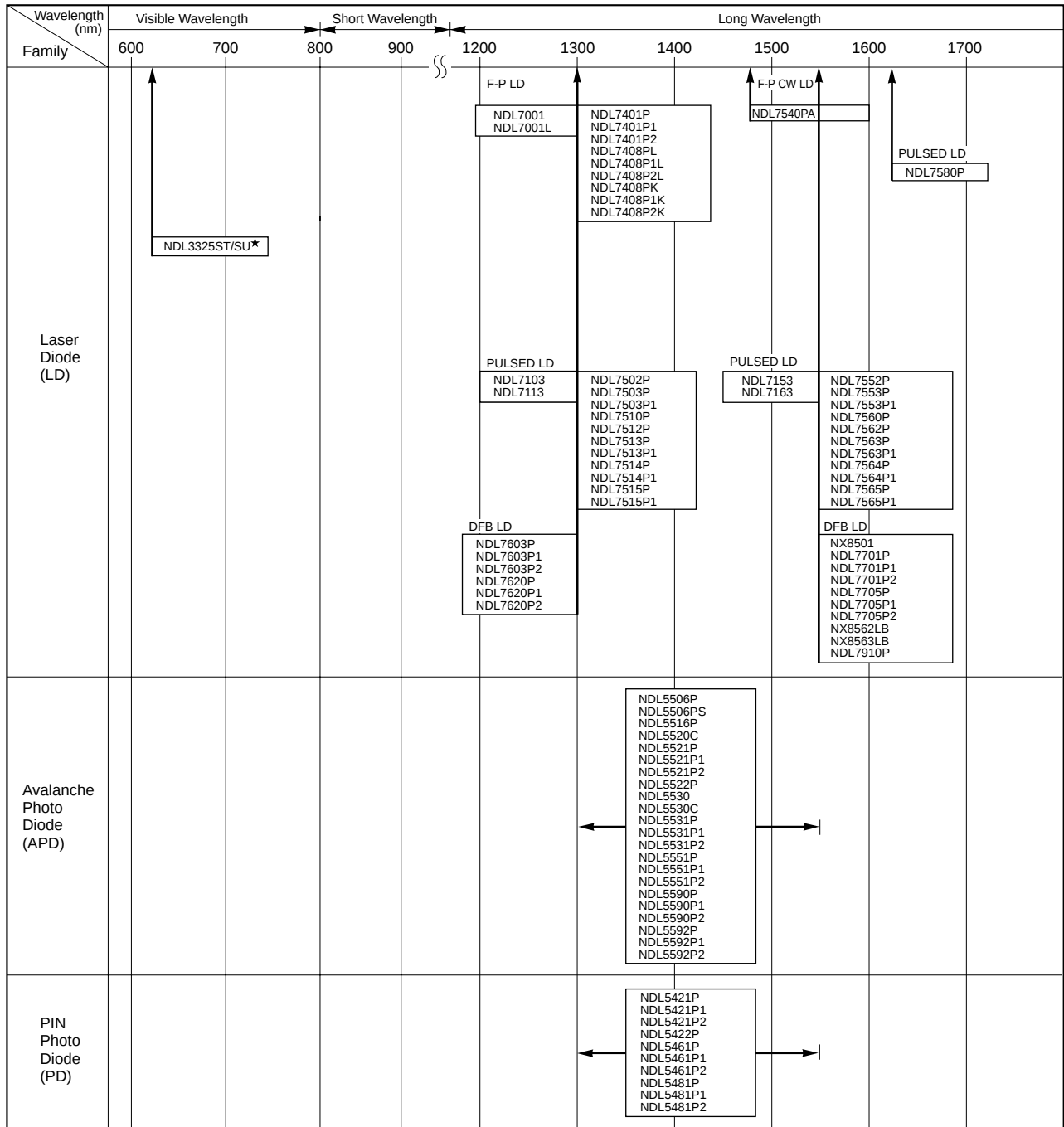
Plastic Fiber Link

■ Plastic Fiber Link

Part Number	Absolute Maximum Ratings (T _C = 25 °C)		Electro-Optical Characteristics (T _C = 25 °C)		
	V _{CC} (V)	T _C (°C)	Transmission Speed (Mbps)	Transmission Distance (m)	
				@ SI-POF	@ SI-HPCF
NL2100	−0.5 to +7.0	0 to +70	1 to 156	50	100
NL2110	−0.5 to +7.0	0 to +70	1 to 250	50	100

Visible Lasers/Fiberoptic Devices

Visible Lasers/Fiberoptic Devices Product Map



→ : Mark wavelength or operating range

★ : Under development

Modules are available with FC-PC or SC-PC connector.

Visible Lasers

■ Visible Lasers

Part Number	Peak Wavelength λ_p (nm)	Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)			Electro-Optical Characteristics ($T_c = 25^\circ\text{C}$)					Applications
		P_o (mW)	T_c ($^\circ\text{C}$)	T_{stg} ($^\circ\text{C}$)	I_{th} (mA)	I_{op} (mA)	P_o (mW)	$\theta_{\perp}$ (deg.)	$\theta_{\parallel}$ (deg.)	
NDL3325ST/SU★	650	8	-20 to +80	-40 to +85	30	40	5	30	8	for DVD

★: Under development

Fiberoptic Devices

■ Lasers (Digital)

• Digital Optical Fiber Communications FP-LD

Part Number	Absolute Maximum Ratings			Electro-Optical Characteristics ($T_c = 25^\circ\text{C}$)						Package
	I_F (mA)	T_c ($^\circ\text{C}$)	T_{stg} ($^\circ\text{C}$)	I_{th} (mA)	I_{op} (mA)	P_o/P_r (mW)	λ_c (nm)	σ^* (nm)	t_r/t_f (ns)	
				TYP.	TYP.	MIN.	TYP.	TYP.	MAX.	
NDL7001	—	-40 to +85	-55 to +125	10	$I_{th}+12$	5	1310	1.0	0.5/0.5	CAN
NDL7001L	—	-40 to +85	-55 to +125	10	$I_{th}+15$	5	1310	1.0	0.5/0.5	CAN with lens
NDL7401P Series	$I_{th}+50$	-40 to +85	-40 to +85	10	$I_{th}+15$	2.0	1310	1.3	0.5/0.5	Coaxial
NDL7408PL Series	$I_{th}+50$	-40 to +85	-40 to +85	10	$I_{th}+15$	0.2	1310	1.3	0.5/0.5	Coaxial
NDL7408PK Series	$I_{th}+50$	-40 to +85	-40 to +85	10	$I_{th}+20$	1.0	1310	1.3	0.5/0.5	Coaxial

*: RMS (-20 dB)

• Digital Optical Fiber Communications DFB-LD

Part Number	Absolute Maximum Ratings			Electro-Optical Characteristics ($T_c = 25^\circ\text{C}$)				Package
	I_F (mA)	T_c ($^\circ\text{C}$)	T_{stg} ($^\circ\text{C}$)	I_{th} (mA)	P_o/P_r (mW)	λ_p (nm)	t_r/t_f (ns)	
				TYP.	MIN.	TYP.	MAX.	
NDL7603P Series	150	-40 to +85	-40 to +85	15	2	1310	0.5/0.5	Coaxial
NDL7620P Series	150	0 to +70	-40 to +85	45*1	2	1310	0.04/0.1*2	Coaxial
NX8501 Series	200	0 to +65	-40 to +85	20	2	1510	0.5/0.5	Coaxial
NDL7701P Series	150	-20 to +85	-40 to +85	15	2	1550	0.5/0.5	Coaxial
NDL7705P Series	$I_{th}+50$	-40 to +85	-40 to +85	15	2	1550	0.5/0.5	Coaxial
NX8562LB	300	-20 to +65	-40 to +85	20	20	1550*3	—	Butterfly
NX8563LB Series	300	-20 to +65	-40 to +85	20	10	ITU-T*4	—	Butterfly
NDL7910P (EA Modulator integrated type)	150	-20 to +70	-40 to +85	7	0.5	1550*3	0.125/0.125	Butterfly

*1: MAX.

*2: TYP.

*3: Wavelength selectable for ITU-T standards upon request.

*4: Wavelength selectable for ITU-T standards.

Fiberoptic Devices

■ Pump Laser

• EDFA Pumping Applications FP-LD

Part Number	Absolute Maximum Ratings			Electro-Optical Characteristics (T _c = 25 °C)						Package
	I _F	T _c	T _{stg}	I _{th}	I _{op}	P _r	λ _c	σ*	t _r /t _f	
	(mA)	(°C)	(°C)	(mA)	(mA)	(mW)	(nm)	(nm)	(ns)	
				TYP.	TYP.	TYP.	TYP.	MAX.	MAX.	
NDL7540PA	600	−20 to +65	−40 to +85	40	500	110	1480	8	—	Butterfly

*: RMS (−20 dB)

■ Pulsed Lasers for OTDR

• OTDR Applications FP-LD

Part Number	Absolute Maximum Ratings			Electro-Optical Characteristics (T _c = 25 °C)						Package
	I _F *1	T _c	T _{stg}	I _{th}	I _{op} *1	P _o /P _r *1	λ _c *1	σ*2	t _r /t _f	
	(mA)	(°C)	(°C)	(mA)	(mA)	(mW)	(nm)	(nm)	(ns)	
				TYP.	TYP.	TYP.	TYP.	MAX.	MAX.	
NDL7103	1200	−40 to +70	−55 to +125	35	1000	320	1310	7	2/2	CAN
NDL7113	600	−40 to +70	−55 to +125	20	400	175	1310	10	1/1	CAN
NDL7153	1200	−40 to +70	−55 to +125	45	1000	240	1550	8	2/2	CAN
NDL7163	600	−40 to +70	−55 to +125	30	400	120	1550	10	1/1	CAN
NDL7502P	1200	−20 to +65	−40 to +70	35	1000	190	1310	10	2/2	DIP
NDL7503P Series	1200	−20 to +60	−40 to +85	35	1000	180	1310	10	2/2	Coaxial
NDL7510P	600	−20 to +65	−40 to +70	20	400	55	1310	10	1/1	DIP
NDL7512P	600	−20 to +65	−40 to +70	20	400	110	1310	10	1/1	DIP
NDL7513P Series	600	−20 to +60	−40 to +85	20	400	110	1310	10	1/1	Coaxial
NDL7514P Series	600	−20 to +60	−40 to +85	20	400	50	1310	10	1/1	Coaxial
NDL7515P Series	600	−20 to +60	−40 to +85	20	400	30	1310	10	1/1	Coaxial
NDL7552P	1200	−20 to +65	−40 to +70	40	1000	125	1550	10	2/2	DIP
NDL7553P Series	1200	−20 to +60	−40 to +85	45	1000	145	1550	10	2/2	Coaxial
NDL7560P	600	−20 to +65	−40 to +70	20	400	30	1550	10	1/1	DIP
NDL7562P	600	−20 to +65	−40 to +70	40	400	80	1550	10	1/1	DIP
NDL7563P Series	600	−20 to +60	−40 to +85	45	400	80	1550	10	1/1	Coaxial
NDL7564P Series	600	−20 to +60	−40 to +85	40	400	40	1550	10	1/1	Coaxial
NDL7565P Series	600	−20 to +60	−40 to +85	20	400	11	1550	10	1/1	Coaxial
NDL7580P	1200	−20 to +65	−40 to +70	30	1000	100*3	1625	15	2/2	DIP

*1: Pulse drive: Pulse width = 10 μs, duty = 1 % (Coaxial, DIP)

Pulse width = 1 μs, duty = 1 % (CAN)

*2: RMS (−20 dB)

*3: MIN.

Fiberoptic Devices

■ Detectors

• InGaAs PIN-PD

Part Number	Absolute Maximum Ratings			Electro-Optical Characteristics (T _c = 25 °C)								Package
	P _{in} (mW)	T _c (°C)	T _{stg} (°C)	Detecting area size (μm)	I _D (nA)		C _t (pF)		S (A/W)		f _c (GHz) MIN.	
					VR (V)	TYP.	VR (V)	TYP.	λ (nm)	TYP.		
NDL5421P Series	8	−40 to +85	−40 to +85	ϕ 50	5	0.1	5	0.7	1300	0.89	2.5	Coaxial
									1550	0.94		
NDL5422P	−	−40 to +70	−40 to +85	ϕ 50	5	0.1	−	−	1300	0.89	2.5	Butterfly with AMP
									1550	1.00		
NDL5461P Series	8	−40 to +85	−40 to +85	ϕ 80	5	0.1	5	1.0	1300	0.89	2.5	Coaxial
									1550	0.94		
NDL5481P Series	8	−40 to +85	−40 to +85	ϕ 80	10	0.1	10	0.7	1300	0.85	2.5	Coaxial

• InGaAs APD

Part Number	Absolute Maximum Ratings			Electro-Optical Characteristics (T _c = 25 °C)						Package
	I _R (mA)	T _C (°C)	T _{stg} (°C)	Detecting area size (μm)	V _{(BR)R} (V) TYP.	I _D (nA)* TYP.	S (A/W)		f _c (GHz) MIN.	
							λ (nm)	TYP.		
NDL5506P Series	0.5	−20 to +55	−40 to +85	ϕ 50	70	2	1300	0.89	1.0	DIP with internal cooler
							1550	1.00		
NDL5516P	0.5	−20 to +55	−40 to +85	ϕ 80	75	2	1300	0.89	0.7	DIP with internal cooler
							1550	1.00		
NDL5520C	0.5	−40 to +70	−55 to +100	ϕ 50	70	5	1300	0.89	2.5	Chip on carrier
							1550	1.00		
NDL5521P Series	0.5	−40 to +85	−40 to +85	ϕ 50	55	5	1300	0.94	2.5	Coaxial
							1550	0.96		
NDL5522P	0.5	−40 to +70	−40 to +85	ϕ 50	55	5	1310	0.89	2.5	Butterfly with AMP
							1550	1.00		
NDL5530	0.5	−40 to +85	−55 to +100	ϕ 30	70	5	1300	0.94	2.5	CAN
							1550	0.96		
NDL5530C	0.5	−40 to +85	−55 to +100	ϕ 30	70	5	1300	0.94	2.5	Chip on carrier
							1550	0.96		
NDL5531P Series	0.5	−40 to +85	−40 to +85	ϕ 30	70	5	1300	0.94	2.5	Coaxial
							1550	0.96		
NDL5551P Series	0.5	−40 to +85	−40 to +85	ϕ 50	70	5	1300	0.94	1.0	Coaxial
							1550	0.96		
NDL5590P Series	0.5	−40 to +85	−40 to +85	ϕ 50	70	5	1310	0.94	1.0	Coaxial with AMP
							1550	0.96		
NDL5592P Series	0.5	−40 to +85	−40 to +85	ϕ 30	70	5	1310	0.94	2.5	Coaxial with AMP
							1550	0.96		

*: Conditions: V_{(BR)R} × 0.9

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